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INDEX VOLUME 26, 1990

Author index

A

Abbasi, F., Young, M.C.J., Lu, W.X., Tredgold, R.H., and Hodge, P. see Young, M.C.J.
Abe, Y., Ohishi, T., Sugimoto, H., Ohtsuka, K., and Matsui, T. see Ohishi, T.
Abernathy, C.R., Hobson, W.S., Levi, A.F.J., O'Gorman, J., Pearton, S.J., and Swaminathan, V. see Hobson, W.S.
Abernathy, C.R., Ren, F., Pearton, S.J., Fullowan, T.R., Lothian, J., and Jordan, A.S. see Ren, F.
Abeysekera, S.S. Computation of Wigner–Ville distribution for complex data p1315
Abraham, A., Hyben, P., Ceskovic, R., Kabos, P., and Cermak, J. see Hyben, P.
Accard, A., Chusseau, L., Xie, J.M., Duvillaret, L., Lourtioz, J.M., and Hebert, J-P. see Chusseau, L.
Accard, A., Mersali, B., Gelly, G., Lafragette, J.-L., Doussiere, P., Lambert, M., and Fernier, B. see Mersali, B.
Accard, A., Perales, A., Goldstein, L., Fernier, B., Leblond, F., Gourdain, C., and Brosson, P. see Perales, A.
Accornero, R., Artiglia, M., Coppa, G., Di Vita, P., Lapenta, G., Potenza, M., and Ravetto, P. Finite difference methods for the analysis of integrated optical waveguides p1959
Achour, B., Noonan, J.P., and Tzannes, M.A. see Noonan, J.P.
Achurch, N.E. Optical TAP based on D-fibre p1909
Achurch, N.E., Rowe, C.J., Moore, M.W., and Wilkinson, I.J. see Rowe, C.J.
Acioli, L.H., Gomes, A.S.L., and de Araújo, C.B. Observation of femtosecond beats using Raman radiation from SiO_2 optical fibres p92
Ackaert, A., Pollentier, I., Buydens, L., Demeester, P., Van Daele, P., De Pestel, F., Lootens, D., and Baets, R. see Pollentier, I.
Ackaert, A., Pollentier, I., Demeester, P., Buydens, L., Van Daele, P., and Baets, R. see Pollentier, I.
Ackerman, D.A., Kuo, C.Y., Henry, C.H., Shani, Y., Dahbura, M.I., Kistler, R., and Wagner, E.J. see Kuo, C.Y.
Ackerman, E., Kasemsei, D., Wanuga, S., and Chinn, S. High gain, wide dynamic range L-band externally modulated fibre optic p1339
Adachi, S., Sawaya, K., and Yatabe, S. see Sawaya, K.
Adamovsky, G., and Carr, T.W. Intensity to frequency conversion technique in intensity modulated fibre optic sensing systems p1450
Adams, A.R., Crookes, C.G., Lancefield, D., Waterhouse, K., Greene, P.D., and Glew, R.W. see Crookes, C.G.
Adams, A.R., Czajkowski, I.K., and Allam, J. see Czajkowski, I.K.
Adams, C., Aronhime, P., and Nelson, D. see Aronhime, P.
Adams, J.A., Thayne, I.G., Taylor, M.R.S., Wilkinson, C.D.W., Beaumont, S.P., Johnson, N.P., Kean, A.H., and Stanley, C.R. Very high frequency performance of nanometre scale GaAs MESFETs p1019
Adams, M.J., Hedges, S.J., Nicholson, B.F., and Chew, N.G. see Hedges, S.J.
Adde, R., Ouslimani, A., Vernet, G., and Hafdallah, H. see Ouslimani, A.
Adde, R., Zounon, A., and Crozat, P. see Zounon, A.
Adler, C.L., and Lawandy, N.M. New electro-optic materials using guest-host systems p217
Adler, E.L., and Oliveira, J.E.B. see Oliveira, J.E.B.
Adomi, K., Ünlü, M.S., Strite, S., Gao, G.B., and Morkoç, H. see Ünlü, M.S.
Aga, K., Yano, H., Kamei, H., Sasaki, G., and Hayashi, H. see Yano, H.
Aggoun, A., and Ibrahim, M.K. see Ibrahim, M.K.
Agnew, G.B., Mullin, R.C., and Vanstone, S.A. Improved digital signature scheme based on discrete exponentiation p1024
Agnew, M.J., Lee, W.S., Spear, D.A.H., Dawe, P.J.G., and Bland, S.W. see Lee, W.S.
Agrawal, A.P. Potential use of optimal polarisations in sensing the canting angle distribution of raindrops p157
Agrawal, G.P. Fundamental limitation on large-signal modulation of semiconductor lasers and its implications for lightwave transmission p916
Ahlbom, G., Egnell, L., and Wickman, C. Digital demodulation for optical FSK signals p290
Ahmed, H., Kelly, M.J., Brown, R.J., Pepper, M., Hasko, D.G., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Kelly, M.J.
Ahmed, H., Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Pepper, M., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Ahmed, R.E. New design technique for two-step flash A/D convertors p1185
Ahn, H.S., and Choi, C.H. Iterative learning controller for linear systems with a periodic disturbance p1542
Aidemirski, P.P., and Vasilev, V.N. see Vasilev, V.N.
Aikawa, S., Takanashi, H., and Nakamura, Y. see Takanashi, H.
Aina, L., Serio, M., Mattingly, M., Hempfling, E., and Chien, H. DC and microwave performance of OMVPE-grown AlInAs/InP HEMTs p1912
Aina, O., Serio, M., Mattingly, M., and Hempfling, E. Novel AlInAs/InP HEMT p651
Ainslie, B.J., Blow, K.J., Gouveia-Neto, A.S., Wigley, P.G.J., Sombra, A.S.B., and Taylor, J.R. Femtosecond soliton amplification in erbium doped silica fibre p186
Ainslie, B.J., Craig-Ryan, S.P., and Millar, C.A. see Craig-Ryan, S.P.
Ainslie, B.J., Davey, S.T., Williams, D.L., and Spirit, D.M. see Davey, S.T.
Ainslie, B.J., Massicott, J.F., Armitage, J.R., Wyatt, R., and Craig-Ryan, S.P. see Massicott, J.F.
Ainslie, B.J., Massicott, J.F., Wyatt, R., and Craig-Ryan, S.P. see Massicott, J.F.
Ainslie, B.J., Spirit, D.M., Blank, L.C., Williams, D.L., and Davey, S.T. see Spirit, D.M.
Ainslie, B.J., Williams, D.L., Davey, S.T., and Spirit, D.M. see Williams, D.L.
Ait-Boudaoud, D., Ibrahim, M.K., and Hayes-Gill, B.R. Novel pipelined serial/parallel multiplier p582
Ait-Boudaoud, D., and Ibrahim, M.K. Novel systolic array for realising a second-order digital filter p388
Aitchison, C.S. Potential of the distributed amplifier as a photo-diode detector amplifier in high bit rate optical communication systems p1693
Aite, K., Ragay, F.W., and Middelhoek, J. Novel low temperature RF plasma annealing using NH_3–N_2 gas mixture p733
Aizawa, T., Kikugawa, T., Ravikumar, K.G., Arai, S., and Suematsu, Y. see Kikugawa, T.
Akagi, J., Kuriyama, Y., Morizuka, K., Asaka, M., Tsuda, K., Obara, M., and Yamakawa, H. 10 Gbit/s AlGaAs/GaAs heterojunction bipolar transistor decision circuit IC p122
Akagi, J., Yamakawa, H., Ibe, H., Kuriyama, Y., Morizuka, K., and Obara, M. see Yamakawa, H.
Akamatsu, B., Martins, R.B., and Henoc, P. see Martins, R.B.
Akinwande, T., Zou, J., Gopinath, A., and Shur, M.S. see Zou, J.
Akita, K., Hidaka, H., Taneya, M., and Sugimoto, Y. see Hidaka, H.
Al-Chalabi, S.A., Mellis, J., Hollier, M., Cameron, K.H., Wyatt, R., Regnault, J.E., Devlin, W.J., and Brain, M.C. Temperature and mechanical vibration characteristics of a miniature long external cavity semiconductor laser p1159
Al-Jabri, A.K. Coding and interleaving for meteor-burst communications p1907
Al Chalabi, S., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Al Chalabi, S., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Alameh, K., and Minasian, R.A. Optimum optical modulation index of laser transmitters in SCM systems p1273
Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. 44-ary FSK coherent optical communication system p1346
Alexander, S.B., Castagnozzi, D.M., Colagiuri, E.P., Bucher, E.A., and Jeromin, L.L. see Castagnozzi, D.M.
Alexandre, F., Benchimol, J.L., Dangla, J., Dubon-Chevallier, C., and Amarger, V. Heavily doped base GaInP/GaAs heterojunction bipolar transistor grown by chemical beam epitaxy p1753
Ali, H.O., Mgombelo, H.R., and Kissaka, M.M. see Mgombelo, H.R.
Ali Khatibzadeh, M., and Bayraktaroglu, B. Low phase noise heterojunction bipolar transistor oscillator p1246
Allain, J.Y., Monerie, M., Georges, T., Francois, P.L., and Neveux, D. see Monerie, M.
Allain, J.Y., Monerie, M., and Poignant, H. Blue upconversion fluorozirconate fibre laser p166
Allain, J.Y., Monerie, M., and Poignant, H. Room temperature CW tunable green upconversion holmium fibre laser p261
Allain, J.Y., Ronarc'h, D., Guibert, M., Monerie, M., and Poignant, H. see Ronarc'h, D.
Allam, J., Czajkowski, I.K., and Adams, A.R. see Czajkowski, I.K.
Allam, R., and Pribetich, J. Temperature dependence of electron saturation velocity in GaAs p688
Allard, P.E., Bhargava, V.K., and Séguin, G. see Bhargava, V.K.
Allison, S.W., Ramos, P.A., and Gillies, G.T. Microchannel plate intensifier response in transverse magnetic field p770
Allnutt, J.E., Dissanayake, A.W., and McCarthy, D.K. see Dissanayake, A.W.
Allnutt, J.E., Vogel, W.J., and Torrence, G.W. see Vogel, W.J.
Allnutt, J.E., and Bryant, D.L. see Bryant, D.L.
Allovon, M., Bigan, E., Carre, M., and Carenco, A. see Bigan, E.
Allovon, M., Kazmierski, C., Blez, M., Quillec, M., and Sermage, B. see Kazmierski, C.
Alonso, J.I., and Pérez, F. Inclusion of dispersive effects of microstrip lines in formulation using state-space approach of nonlinear microwave circuits p795
Alparone, L., Argenti, F., and Benelli, G. Fast calculation of co-occurrence matrix parameters for image segmentation p23
Alparone, L., and Argenti, F. see Argenti, F.
Alquie, G., Vasilescu, G., and Krim, M. see Vasilescu, G.
Alsuwailem, A.M. Simple microprocessor-based load angle measurement instrument p1336
Alves, A.P., Pereira, M.S., and Vasconcelos, N.M. see Pereira, M.S.
Alves, A.P., and Corte-Real, L. see Corte-Real, L.
Alwan, J.J., Favaro, M.E., Bryan, R.P., Miller, L.M., Coleman, J.J., Kim, J., and Wayman, C.M. see Favaro, M.E.
Amada, E., Takahashi, Y., Ando, K., and Miyata, M. see Takahashi, Y.
Amann, M.-C. Linewidth enhancement in distributed-feedback semiconductor lasers p569
Amann, M.-C., Illek, S., Thulke, W., Schanen, C., and Lang, H. see Illek, S.
Amann, M.-C., Wolf, T., and Westermeier, H. see Wolf, T.
Amann, M.-C., and Schimpe, R. Excess linewidth broadening in wavelength-tunable laser diodes p279
Amano, M., and Kaino, T. Second-order nonlinearity of a disazo dye attached polymer p981
Amantea, R., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Amarger, V., Alexandre, F., Benchimol, J.L., Dangla, J., and Dubon-Chevallier, C. see Alexandre, F.
Amran, Y., Ben-Yaakov, S., Edry, D., and Shimony, O. see Ben-Yaakov, S.
Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., Michelakis, C., and Morgan, D.V. Laser-annealed refractory metal silicide films on GaAs p62
Ando, K., Takahashi, Y., Miyata, M., and Amada, E. see Takahashi, Y.
Andreadakis, N., Reichenbach, D., Zah, C.E., Favire, F.J., Menocal, S.G., Vodhanel, R., Yi-Yan, A., and Lee, T.P. see Reichenbach, D.
Andrejco, M.J., Way, W.I., Maeda, M.W., Yi-Yan, A., Choy, M.M., Saifi, M., and Lin, C. see Way, W.I.
Andrekson, P.A., Olsson, N.A., Simpson, J.R., Tanbun-Ek, T., Logan, R.A., Becker, P.C., and Wecht, K.W. Soliton collision interaction force dependence on wavelength separation in fibre amplifier based systems p1499
Angenent, J.H. Simple model for calculation of distortion in an optical analogue subcarrier multiplexed CATV system p2049
Anido, G., Hughes, D.A., and Bradlow, H.S. see Hughes, D.A.
Ankiewicz, A., and Peng, G.-D. see Peng, G.-D.
Antar, Y.M.M., Martin, J.T.H. St., Kishk, A.A., Ittipiboon, A., and Cuhaci, M. see Martin, J.T.H. St.

Antar, Y.M.M., Oostlander, R., Ittipiboon, A., and Cuhaci, M. see Oostlander, R.

Antoniou, G.E. Minimal state space realisation of product factorable 2-D systems p1232

Antoniou, G.E., Manikopoulos, C.N., and Mentzelopoulou, S.E. Two-dimensional modified Cauer form: circuit and state space realisation p258

Antweiler, M., and Bömer, L. Merit factor of Chu and Frank sequences p2068

Anupindi, N., Narayanan, S.B., and Prabhu, K.M.M. New radix-3 FHT algorithm p1537

Anupindi, N., and Prabhu, K.M.M. Split-radix FHT algorithm for real-symmetric data p1973

Anzill, W., Goeller, T., Kaertner, F.X., Russer, P., and Buechler, J. Self-consistent simulation of a high-power 73 GHz integrated IMPATT oscillator p1697

Aoki, H., Maruyama, O., and Asahara, Y. Glass waveguide laser operated around 1·3 μm p1910

Aoki, M., Uomi, K., Sasaki, S., Tsuchiya, T., Okai, M., and Chinone, N. see Uomi, K.

Aoki, M., Uomi, K., Tsuchiya, T., Suzuki, M., and Chinone, N. Enhanced relaxation oscillation frequency and reduced nonlinear K-factor in InGaAs/InGaAsP MQW λ/4-shifted DFB lasers p1841

Aoki, T., Kameyama, M., and Higuchi, T. Interconnection-free set logic network based on a bio-device model p1015

Appleyard, A.P., Scrivener, P.L., Maton, P.D., and Tarbox, E.J. see Scrivener, P.L.

Arai, S., Kikugawa, T., Ravikumar, K.G., Aizawa, T., and Suematsu, Y. see Kikugawa, T.

Arakawa, T., Fukuda, H., and Ohno, S. see Fukuda, H.

Aramaki, S., Assanto, G., and Stegeman, G.I. Fine tuning of wavevector conservation in guided wave devices by photobleaching p1300

Archer, J.A. Gallium arsenide MBE structure comprising mixer diodes and FETs for monolithic millimetre-wave receivers p384

Archer, V.D., Lunardi, L.M., Swartz, R.G., Kuo, J.M., Kopf, R.F., Malik, R.J., and Smith, P.R. see Lunardi, L.M.

Arevalo-Galarza, J.B., and Muñoz-Rodriguez, D. see Muñoz-Rodriguez, D.

Argenti, F., Alparone, L., and Benelli, G. see Alparone, L.

Argenti, F., and Alparone, L. Coarse-to-fine least squares stereo matching for 3-D reconstruction p812

Argüello, F., and Zapata, E.L. Fast cosine transform based on the successive doubling method p1616

Arjavalingam, G., Pastol, Y., and Halbout, J.-M. see Pastol, Y.

Arkwright, J.W., Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Wyatt, R., Massicott, J.F., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. see Hill, A.M.

Arkwright, J.W., and Mortimore, D.B. see Mortimore, D.B.

Arkwright, J.W., and Mortimore, D.B. 7 × 7 monolithic single-mode star coupler p1534

Armistead, C.J., White, I.H., Nyairo, K.O., and Kirkby, P.A. see White, I.H.

Armistead, C.J., White, I.H., Watts, J.J.S., Carroll, J.E., Moule, D.J., and Champelovier, J.A. see White, I.H.

Armitage, J.R., Kashyap, R., Wyatt, R., Davey, S.T., and Williams, D.L. see Kashyap, R.

Armitage, J.R., Massicott, J.F., Wyatt, R., Ainslie, B.J., and Craig-Ryan, S.P. see Massicott, J.F.

Armitage, J.R., Smith, K., Wyatt, R., Doran, N.J., and Kelly, S.M.J. see Smith, K.

Armstrong, G.A., and French, W.D. Optimised design for a 0·5 μm gate length n-channel SOI MOSFET p1196

Aronhime, P., Nelson, D., and Adams, C. Applications of a first-generation current conveyor in current-mode circuits p1456

Arsenault, L., Ünlü, M.S., Kishino, K., Chyi, J.-I., Reed, J., and Morkoç, H. see Ünlü, M.S.

Artiglia, M., Accornero, R., Coppa, G., Di Vita, P., Lapenta, G., Potenza, M., and Ravetto, P. see Accornero, R.

Artigue, C., Zamkotsian, F., Peyre, J.-L., Lievin, J.-L., Lambert, M., Bonnevie, D., and Benoit, J. see Zamkotsian, F.

Asahara, Y., Aoki, H., and Maruyama, O. see Aoki, H.

Asai, H., Fukano, H., Kawamura, Y., Takanashi, Y., and Fujimoto, M. see Fukano, H.

Asai, K., Imai, Y., Tokumitsu, M., and Onodera, K. see Imai, Y.

Asaka, M., Akagi, J., Kuriyama, Y., Morizuka, K., Tsuda, K., Obara, M., and Yamakawa, H. see Akagi, J.

Asaka, T., Ogura, M., Mukai, S., Shimada, M., Yamasaki, Y., Seki, T., and Iwano, H. see Ogura, M.

Ashburn, P., and Post, I.R.C. see Post, I.R.C.

Asom, M.T., Lee, Y.H., Tell, B., Brown-Goebeler, K., Jewell, J.L., Leibenguth, R.E., Livescu, G., Luther, L., and Mattera, V.D. see Lee, Y.H.

Asonen, H., Keskinen, J., Näppi, J., and Pessa, M. see Keskinen, J.

Assanto, G., Aramaki, S., and Stegeman, G.I. see Aramaki, S.

Ata, O.W., Benson, T.M., and Marincic, A. Sidelobe suppression in an E-plane sectoral horn antenna p231

Atlas, D.A., and Kazovsky, L.G. 2 Gbit/s PSK heterodyne communication system using optical phase-locked loop p1030

Auchterlonie, L.J., Fletcher, P.N., and Hume, A.L. Microwave scattering by metal cubes and the effect of perturbing the cube geometry p295

Audibert, G., Loualiche, S., and Clerot, F. see Loualiche, S.

Auffret, R., Chawki, M.J., and Berthou, L. see Chawki, M.J.

Auge, A., Clesca, B., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.

Auge, J., Marcerou, J.F., Fevrier, H., Ramos, J., and Dursin, A. see Marcerou, J.F.

Auracher, F., Noé, R., Rodler, H., Gaukel, G., and Ebberg, A. see Noé, R.

Aussel, J.-D. Noise reduction and deconvolution with sequency diversity p737

Avitabile, G., and Manetti, S. Some structures for neural based A/D conversion p1516

Avramov, I.D., Edmonson, P.J., and Smith, P.M. Surface transverse wave based FM modulator/demodulator p364

Azoulay, R., Dangla, J., Dubon-Chevallier, C., and Filoche, M. see Dangla, J.

B

Bødtker, E., Hoffmann, B., Jensen, N.G., Nielsen, S.K., and Broberg, B. see Hoffmann, B.

Baba, T., Tanaka, S., Hayama, N., Furukawa, A., Mizuta, M., and Honjo, K. see Tanaka, S.

Babbage, S. On the relevance of the strict avalanche criterion p461

Baca, L.J., and McInerney, J.G. Design of a broadband high-frequency antenna on gallium arsenide using the effective index method p1083

Baden Fuller, A.J., and Runham, M. Computer design of broadband lumped component microwave phase shifter amplifiers p1849

Baets, R., David, K., Morthier, G., and Vankwikelberge, P. see David, K.

Baets, R., Pollentier, I., Buydens, L., Ackaert, A., Demeester, P., Van Daele, P., De Pestel, F., and Lootens, D. see Pollentier, I.

Baets, R., Pollentier, I., Demeester, P., Ackaert, A., Buydens, L., and Van Daele, P. see Pollentier, I.

Bagheri, M. High speed low power GaAs crosspoint switch design p1142

Bagheri, M., Lo, Y.H., Lin, P.S.D., Grabbe, P., Bhat, R., Stoffel, N.G., Lee, T.P., and Kong, D.T. see Lo, Y.H.

Bagheri, M., Runge, K., Young, J., Millicker, D., Kipnis, I., and Snapp, C. see Runge, K.

Bagley, M., Sherlock, G., Cooper, D.M., Westbrook, L.D., Elton, D.J., Wickes, H.J., Spurdens, P.C., and Devlin, W.J. Broadband operation of InGaAsP–InGaAs GRIN-SC-MQW BH amplifiers with 115 mW output power p512

Bagley, M., Wyatt, R., Elton, D.J., Wickes, H.J., Spurdens, P.C., Seltzer, C.P., Cooper, D.M., and Devlin, W.J. 242 nm continuous tuning from a GRIN-SC-MQW-BH InGaAsP laser in an extended cavity p267

Bailbé, J.P., Vannel, J.P., Marty, A., Tasselli, J., and Cazarré, A. see Vannel, J.P.

Bajon, D., and Gammand, P.G. see Gammand, P.G.

Baker, D.C. Extension of the multiparabolic ionospheric model to the F1-layer L-condition p1301

Balestra, F., Hafez, I.M., Emrani, A., and Ghibaudo, G. see Hafez, I.M.

Ball, G.A., Morey, W.W., and Waters, J.P. Nd^{3+} fibre laser utilising intra-core Bragg reflectors p1829

Ballance, J.W., Rogers, P.H., and Halls, M.F. ATM access through a passive optical network p558

Ballantyne, J.M., Yellen, S.L., Waters, R.G., Chen, Y.C., Soltz, B.A., Fischer, S.E., and Fekete, D. see Yellen, S.L.

Ballingall, J.M., Chao, P.C., Ho, P., Duh, K.H.G., Smith, P.M., Jabra, A.A., Lewis, N., and Hall, E.L. see Chao, P.C.

Bandy, S., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Silverman, S., Weng, S., Pao, Y.C., Zdasiuk, G., and Tan, Z. see Majidi-Ahy, R.

Bandy, S., Yuen, C., Pao, Y.C., Day, M., Nishimoto, C., Glenn, M., and Zdasiuk, G. see Yuen, C.

Banerjee, C., Devasirvatham, D.M.J., Krain, M.J., and Rappaport, D.A. see Devasirvatham, D.M.J.

Banu, M., Nottenburg, R.N., Jalali, B., Humphrey, D.A., Montgomery, R.K., Hamm, R.A., and Panish, M.B. see Nottenburg, R.N.

Bar-Chaim, N., Chen, T.R., Zhuang, Y.H., Yariv, A., and Blauvelt, H. see Chen, T.R.

Bar-Chaim, N., Ungar, J., Mazed, M., Mittelstein, M., Oh, S., and Ury, I. see Ungar, J.

Bar-Joseph, I., Goossen, K.W., Zucker, J.E., Kuo, J.M., Kopf, R.M., Miller, D.A.B., and Chemla, D.S. see Goossen, K.W.

Barbaliscia, F., and Boumis, M. Very low rain statistics for the design of low availability satellite communication systems p417

Barbarossa, S. New autofocusing technique for SAR images based on the Wigner-Ville distribution p1533

Barbier, E., Schmidt, P.E., Collot, P., Gaonach, C., Champagne, M., and Pons, D. see Schmidt, P.E.

Bardyn, J.-P., and Kaiser, A. Fully differential operational amplifiers using CMOS compatible lateral bipolar transistors with improved common-mode regulation p798

Barnes, N., Healey, P., Rejman-Greene, M.A.Z., Scott, E.G., and Webb, R.P. 16-channel parallel optical interconnect demonstration with an InGaAs/InP MQW modulator array p1126

Barnes, N.M., Healey, P., McKee, P., O'Neill, A.W., Rejman-Greene, M.A.Z., Scott, E.G., Webb, R.P., and Wood, D. High speed opto-electronic neural network p1110 e1739

Barnes, W.L., Grubb, S.G., Taylor, E.R., and Payne, D.N. see Grubb, S.G.

Barnes, W.L., and Townsend, J.E. Highly tunable and efficient diode pumped operation of Tm^{3+} doped fibre lasers p746

Barnsley, P.E., Isaac, J.J., and Elton, D.J. Ultra-low reflectivity broadband 1·5 μm GaInAsP semiconductor optical amplifiers p825

Barry, P., and Eggers, P. see Eggers, P.

Barry, R., Alexander, S.B., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.

Barski, S., Delavaux, J.-M.P., Park, Y.K., Lefevre, H., Failes, M., and Warner, C. see Delavaux, J.-M.P.

Barski, S., Delavaux, J.M., Park, Y.K., Tench, R.E., Owen, B., Tzeng, L.D., and Twu, Y. see Delavaux, J.M.

Barsotti, E.L., Dunn, J.M., and Kuester, E.F. Strip edge shape effects on conductor loss calculations using the Lewin/Vainshtein method p983

Bartenlian, B., Constant, M., Boussekey, L., Decoster, D., and Pascal, D. see Constant, M.

Bartenlian, B., Zirngibl, M., Bischoff, J.C., Ilegems, M., Hirtz, J.P., Beaud, P., and Hodel, W. see Zirngibl, M.

Bartolucci, G., and Piotrowski, J. Full-wave analysis of shielded coplanar waveguide short-end p1615 e1922

Barton, J.S., Morgan, R., Harper, P.G., and Jones, J.D.C. see Morgan, R.

Batsele, T., and Moeneclaey, M. see Moeneclaey, M.

Battersby, N.C., Toumazou, C., and Maglaras, C. see Toumazou, C.

Baudrand, H., Tao, J.W., and Chan, B. see Tao, J.W.

Baur, B., Heinecke, H., Höger, R., and Miklis, A. see Heinecke, H.

Baus, A., Jestel, D., and Voges, E. see Jestel, D.

Bayraktaroglu, B., and Ali Khatibzadeh, M. see Ali Khatibzadeh, M.

Bayruns, R., Toumazou, C., Haigh, D.G., Harrold, S.J., Steptoe, K., and Sewell, J.I. see Toumazou, C.

Bayvel, P., and Radmore, P.M. Solutions of the SBS equations in single mode optical fibres and implications for fibre transmission systems p434

Beat, I.F., and Lucas, T.N. see Lucas, T.N.

Beaud, P., Zirngibl, M., Bischoff, J.C., Ilegems, M., Hirtz, J.P., Bartenlian, B., and Hodel, W. see Zirngibl, M.

Beaumont, S.P., Adams, J.A., Thayne, I.G., Taylor, M.R.S., Wilkinson, C.D.W., Johnson, N.P., Kean, A.H., and Stanley, C.R. see Adams, J.A.

Becker, P.C., Andrekson, P.A., Olsson, N.A., Simpson, J.R., Tanbun-Ek, T., Logan, R.A., and Wecht, K.W. see Andrekson, P.A.

Beddow, D.M., Violas, M.A.R., Heatley, D.J.T., and Duarte, A.M.O. see Violas, M.A.R.

Behe, R., Sabatier, C., and Brachat, P. see Sabatier, C.

Bell, J., and Ironside, C.N. Semiconductor-doped glass waveguide electro-absorption modulator p976

Bellaouar, A., and Elmasry, M.I. Novel merged BiCMOS circuit structures p1555

Belogortsev, A.B., Poliashenko, M.F., Tret'jakov, O.A., and Vavriv, D.M. Stochastic instability of oscillator with coupled stabilising resonator p1354

Ben-Tzvi, D., and Sandler, M.B. Counter-based Hough transform p751

Ben-Yaakov, S., Edry, D., Amran, Y., and Shimony, O. SPICE simulation of quasi-resonant zero-current-switching DC–DC convertors p847

Benchimol, J.L., Alexandre, F., Dangla, J., Dubon-Chevallier, C., and Amarger, V. see Alexandre, F.

Benedetto, S., and Poggiolini, P. Combined amplitude and polarisation shift keying optical coherent modulation p918

Benedetto, S., and Poggiolini, P. Highly bandwidth efficient transmission through continuous polarisation modulation p1392

Benedetto, S., and Poggiolini, P. Performance evaluation of multilevel polarisation shift keying modulation schemes p244

Benedetto, S., and Poggiolini, P. Performance evaluation of polarisation shift keying modulation schemes p256

Benelli, G., Alparone, L., and Argenti, F. see Alparone, L.

Benjamin, R., Zaglanikis, C.D., and Seeds, A.J. Optical beam former for phased arrays with independent control of radiated frequency and phase p1853

Benner, A.F. Digital optical logic using optically switched directional couplers p1037

Bennett, J.C., Shaw, D.I., and Clements, A.M. see

Shaw, D.I.
Bennion, I., Reid, D.C.J., Ragdale, C.M., Robbins, D.J., Buus, J., and Stewart, W.J. see Reid, D.C.J.
Benoit, J., Flaarønning, N., Frorud, J.O., Sotom, M., Vendrôme, G., Da Loura, G., Gabriagues, J.M., Jacquet, J., and Leclerc, D. see Flaarønning, N.
Benoit, J., Zamkotsian, F., Artigue, C., Peyre, J.-L., Lievin, J.-L., Lambert, M., and Bonnevie, D. see Zamkotsian, F.
Benson, T.M., Ata, O.W., and Marincic, A. see Ata, O.W.
Bergmans, J.W.M., and Mita, S. Two new equalisation schemes for high-density digital magnetic recording systems with quad-phase modulation code p13
Bergvall, K., Granestrand, P., Lagerström, B., Svensson, P., Thylén, L., Stoltz, B., Falk, J.-E., and Olofsson, H. see Granestrand, P.
Berkoff, T.A., and Kersey, A.D. see Kersey, A.D.
Berkoff, T.A., and Kersey, A.D. Interferometric fibre displacement/strain sensor based on source coherence synthesis p452
Bernklau, D., Riechert, H., Reithmaier, J.-P., and Schnell, R.D. see Riechert, H.
Berolo, E., Stapleton, S.P., Deen, M.J., and Hardy, R.H.S. see Stapleton, S.P.
Bertheau Johannessen, A., Bons, J.H., Weyland, N.B.J., and Prasad, R. Multiring differential chain codes for line drawings p677
Berthou, L., Chawki, M.J., and Auffret, R. see Chawki, M.J.
Bertsch, P., Selle, D., Carisetti, D., Ducourant, T., and Boissenot, P. see Selle, D.
Besch, V., and Wlodarczyk, W. see Wlodarczyk, W.
Bestwick, P.R., Davies, I., and Vanner, K.C. Novel integral heatsink structures for power MMICs p1050
Betti, S., Curti, F., De Marchis, G., and Iannone, E. Exploiting fibre optics transmission capacity: 4-quadrature multilevel signalling p992
Betts, A.K., and Taylor, J.T. Finite-gain-insensitive circulating-delay type pseudo-N-path filter p1941
Betts, R.A., Lui, F., and Gauja, E. Tunable couplers fabricated in K^+/Na^+ ion exchanged glass p786
Betts, R.A., and Lui, F. Broadband polarisation splitting couplers in ion-exchanged glass p450
Bhargava, V.K., Séguin, G., and Allard, P.E. Class of shortened cyclic codes over $GF(2^8)$ for byte-oriented systems p438
Bhargava, V.K., and Yang, Q. see Yang, Q.
Bhaskar, D.R., Senani, R., Tripathi, M.P., and Kumar, B.A. see Senani, R.
Bhat, R., Lin, P.S.D., Hong, W.-P., Kim, O.-H., Van Der Gaag, B., and Schumacher, H. see Lin, P.S.D.
Bhat, R., Lo, Y.H., Bagheri, M., Lin, P.S.D., Grabbe, P., Stoffel, N.G., Lee, T.P., and Kong, D.T. see Lo, Y.H.
Bhat, R., Schumacher, H., Soole, J.B.D., LeBlanc, H.P., and Koza, M.A. see Schumacher, H.
Bhat, R., Shantharama, L.G., Schumacher, H., Leblanc, H.P., Esagui, R., and Koza, M. see Shantharama, L.G.
Bhat, R., Soole, J.B.D., Tsang, H.K., White, I.H., LeBlanc, H.P., and Koza, M.A. see Soole, J.B.D.
Bhatgadde, L.G., and Choudhury, D. Structures and microwave losses in Ni/Cu/Ni/Au coatings on alumina p1203
Bhattacharyya, A.K. Control of radar cross-section and crosspolarisation characteristics of an isotropic chiral sphere p1066
Bhumbra, B.S., Glew, R.W., Greene, P.D., Henshall, G.D., Lowney, C.M., and Whiteaway, J.E.A. High power operation of GaInAsP/GaInAs MQW ridge lasers emitting at 1·48 μm p1755
Bi, Z.-Q., Wu, K.-L., and Litva, J. Application of the FD-TD method to the analysis of H-plane waveguide discontinuities p1897
Bien, Z., Oh, Y.S., and Suh, I.H. see Oh, Y.S.
Bien, Z., and Jang, W. see Jang, W.
Bigan, E., Allovon, M., Carre, M., and Carenco, A. Strained-layer InGaAs/InAlAs multiple quantum wells for efficient optical waveguide modulation at 1·55 μm p355
Bignell, A.M., and Todd, T.D. Analytic node model for deflection routing networks p67
Bijker, W., Sevenhans, J., Vorenkamp, P., and Steyaert, M. see Sevenhans, J.
Bilodeau, F., Hill, K.O., Malo, B., Vineberg, K.A., Johnson, D.C., and Skinner, I. see Hill, K.O.
Bimberg, D., Kuhl, D., Hieronymi, F., Böttcher, E.H., Wolf, T., and Krost, A. see Kuhl, D.
Binari, S.C., Boos, J.B., Kruppa, W., and Hier, H. see Boos, J.B.
Bingulac, S., and Cooper, D.L. see Cooper, D.L.
Bingulac, S., and Cooper, D.L. Derivation of discrete and continuous time ramp invariant representations p664
Biotteau, B., Clesca, B., Auge, A., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Bird, D.M., Ellis, A.D., Cox, J.D., Cameron, K., Elton, D.J., Sherlock, G., and Stallard, W.A. see Ellis, A.D.
Bird, D.M., Fatah, R.M., Cox, M.K., Constantine, P.D., Regnault, J.C., and Cameron, K.H. Miniature packaged actively mode-locked semiconductor laser with tunable 20 ps transform limited pulses p2086
Bird, T.S., and Hay, S.G. Mismatch in dielectric-loaded rectangular waveguide antenna p59
Bird, T.S., and Sprey, M.A. Scan limitations of shaped dual-offset reflector antennas for multiple satellite access p228
Birks, T.A., Kenny, R.P., Oakley, K.P., and Cryan, C.V. Elimination of water peak in optical fibre taper components p1761
Bischoff, J.C., Zirngibl, M., Ilegems, M., Hirtz, J.P., Bartenlian, B., Beaud, P., and Hodel, W. see Zirngibl, M.
Biswas, A., Thorburn, M., and Tripathi, V.K. see Thorburn, M.
Bjarklev, A., Povlsen, J.H., Pedersen, B., Vendeltorp-Pommer, H., and Rottwitt, K. see Povlsen, J.H.
Blaauw, C., Devenyi, T.F., Capron, B., Shepherd, F.R., and Springthorpe, A.J. Reliable 1·3 μm gain guided stripe lasers grown by MOCVD using ethyldimethylindium as the In source p1291
Blanchard, P., Zengo, P.-H., and Facq, P. Accurate reflectance and optical fibre backscatter parameter measurements using an OTDR p2060
Bland, S.W., Lee, W.S., Spear, D.A.H., Agnew, M.J., and Dawe, P.J.G. see Lee, W.S.
Bland, S.W., Lee, W.S., Spear, D.A.H., and Dawe, P.J.G. see Lee, W.S.
Blank, L.C., Spirit, D.M., Williams, D.L., Davey, S.T., and Ainslie, B.J. see Spirit, D.M.
Blau, W., Rossi, B., O'Gorman, J., König, S., Westland, D., and Skarda, V. see Rossi, B.
Blauvelt, H., Chen, T.R., Zhuang, Y.H., Yariv, A., and Bar-Chaim, N. see Chen, T.R.
Blez, M., Kazmierski, C., Quillec, M., Allovon, M., and Sermage, B. see Kazmierski, C.
Blondeau, R., Rondi, D., Krakowski, M., Glastre, G., and Vilain, G. New laser structure on semi-insulating substrate, grown by MOCVD, for high speed operation p458
Bloom, D.M., Marsland, R.A., and Shakouri, M.S. see Marsland, R.A.
Bloom, D.M., Özbay, E., and Diamond, S.K. see Özbay, E.
Blow, K.J., Ainslie, B.J., Gouveia-Neto, A.S., Wigley, P.G.J., Sombra, A.S.B., and Taylor, J.R. see Ainslie, B.J.
Blow, K.J., Doran, N.J., and Nelson, B.P. Demonstration of the nonlinear fibre loop mirror as an ultrafast all-optical demultiplexer p962
Blyth, K.J., Hill, A.M., Payne, D.B., Forrester, D.S., Arkwright, J.W., Wyatt, R., Massicott, J.F., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. see Hill, A.M.
Blyth, K.J., Hill, A.M., Wyatt, R., Massicott, J.F., Forrester, D.S., Lobbett, R.A., Smith, P.J., and Payne, D.B. see Hill, A.M.
Böck, A.M. Design criteria for video sampling rate conversion filters p1259
Bömer, L., and Antweiler, M. see Antweiler, M.
Böttcher, E.H., Kuhl, D., Hieronymi, F., Wolf, T., Krost, A., and Bimberg, D. see Kuhl, D.
Bochkarev, A., Both, W., Drakin, A., and Sverdlov, B. see Both, W.
Bockenhoff, E., Bouregba, R., Lippens, D., Palmateer, L., Bogey, M., Destombes, J.L., and Lecluse, A. see Bouregba, R.
Boermans, M.J.B., Hagen, S.H., Valster, A., Finke, M.N., and van der Heyden, J.M.M. Investigation of TE and TM polarised laser emission in GaInP/AlGaInP lasers by growth-controlled strain p1438 e1986
Bogey, M., Bouregba, R., Lippens, D., Palmateer, L., Bockenhoff, E., Destombes, J.L., and Lecluse, A. see Bouregba, R.
Boggis, J., Lord, A., Violas, M., Heatley, D., and Stallard, W.A. Broadband, high sensitivity erbium amplifier receiver for operation over wide wavelength range p532
Boggis, J.M., Cox, J.D., Bryant, E.G., Hunter, C.A., and Stallard, W.A. see Cox, J.D.
Boissenot, P., Selle, D., Carisetti, D., Ducourant, T., and Bertsch, P. see Selle, D.
Bolle, A., Höök, A., Grosso, G., and Martinelli, M. see Höök, A.
Bolognesi, C.R., Mand, R.S., and Boothroyd, A.R. Room temperature negative differential resistance in a triple well rectifying resonant tunnelling diode p1163
Bonde, A., Iñigo, R.M., and Holcombe, B. see Iñigo, R.M.
Bonek, E., Crohn, I., and Weinrichter, H. see Crohn, I.
Bonek, E., Schultes, G., Weger, P., and Herzog, W. see Schultes, G.
Bonnevie, D., Zamkotsian, F., Artigue, C., Peyre, J.-L., Lievin, J.-L., Lambert, M., and Benoit, J. see Zamkotsian, F.
Bons, J.H., Bertheau Johannessen, A., Weyland, N.B.J., and Prasad, R. see Bertheau Johannessen, A.
Boonzaaier, J.J., and Pistorius, C.W.I. Thin wire dipoles—a finite-difference time-domain approach p1891
Boos, J.B., Binari, S.C., Kruppa, W., and Hier, H. InAlAs/InGaAs/InP junction HEMTs p1172
Booth, R.C., McGuire, A., and Thomas, A.P. see McGuire, A.
Boothroyd, A.R., Bolognesi, C.R., and Mand, R.S. see Bolognesi, C.R.
Borghs, G., Dobbelaere, W., De Boeck, J., Van Hove, M., Deneffe, K., De Raedt, W., and Mertens, R. see Dobbelaere, W.
Borghs, G., Kuijk, M., Pereira, R., Van Hove, M., Mertens, R.P., and Pankove, J.I. see Kuijk, M.
Borghs, G., Van Hoof, C., Genoe, J., Van Hove, M., Jansen, Ph., and Van Rossum, M. see Van Hoof, C.
Bortz, G., van Schalkwyk, J.J., and Louw, W. Range determination in a multipath prone environment p1253
Bossert, D.J., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., and DeFreez, R.K. see Evans, G.A.
Bossert, D.J., Evans, G.A., Carlson, N.W., Bour, D.P., Lurie, M., and DeFreez, R.K. see Evans, G.A.
Both, W., Bochkarev, A., Drakin, A., and Sverdlov, B. Thermal resistivity of quaternary solid solutions InGaSbAs and GaAlSbAs lattice-matched to GaSb p418
Botha, L., Ferreira, H.C., and Whalley, M. Two new ternary line codes p1989
Botha, L., and McNamara, D.A. see McNamara, D.A.
Boucaud, P., Yang, D.D., Julien, F.H., Chusseau, L., Lourtioz, J.-M., and Planel, R. see Yang, D.D.
Bouchon, D., Chusseau, L., Duvillaret, L., and Lourtioz, J.M. see Chusseau, L.
Boulbry, J.C., Calvez, L.C., and Vilbe, P. see Calvez, L.C.
Boumis, M., and Barbaliscia, F. see Barbaliscia, F.
Bour, D.P., Carlson, N.W., Patterson, D.R., Stabile, P.J., Liew, S.K., and Evans, G.A. see Carlson, N.W.
Bour, D.P., Evans, G.A., Carlson, N.W., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Bour, D.P., Evans, G.A., Carlson, N.W., Lurie, M., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Bouregba, R., Lippens, D., Palmateer, L., Bockenhoff, E., Bogey, M., Destombes, J.L., and Lecluse, A. Frequency multiplication using resonant tunnelling diode with output at submillimetre wavelengths p1804
Boussekey, L., Constant, M., Decoster, D., Bartenlian, B., and Pascal, D. see Constant, M.
Boussekey, L., Constant, M., Decoster, D., and Vilcot, J.P. see Constant, M.
Bousselet, P., Clesca, B., Auge, A., Biotteau, B., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Bouthinon, M., Ndagijimana, F., and Saguet, P. see Ndagijimana, F.
Bower, R.W., Ismail, M.S., Veteran, J.L., and Marsh, O.J. see Ismail, M.S.
Bowers, J.E., Derickson, D.J., and Mar, A. see Derickson, D.J.
Bowers, J.E., Mar, A., and Morton, P.A. see Mar, A.
Boyd, I.W., Ghisoni, M., Gibson, M., Rivers, A., Parry, G., and Roberts, J.S. see Ghisoni, M.
Boyd, I.W., Nayar, V., and Patel, P. see Nayar, V.
Bracewell, R.N., and Villasenor, J.D. see Villasenor, J.D.
Brachat, P., Sabatier, C., and Behe, R. see Sabatier, C.
Bradley, M.A., Julien, F.H., Gilles, J.P., Gao, Y., Rao, E.V.K., Razeghi, M., and Omnes, F. Interdiffusion of InGaAs/InP quantum wells by germanium ion implantation p208
Bradlow, H.S., Hughes, D.A., and Anido, G. see Hughes, D.A.
Brain, M., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., and Trivett, D. see Creaner, M.J.
Brain, M., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., and Trivett, D. see Creaner, M.J.
Brain, M.C., Al-Chalabi, S.A., Mellis, J., Hollier, M., Cameron, K.H., Wyatt, R., Regnault, J.E., and Devlin, W.J. see Al-Chalabi, S.A.
Brennan, P.V., and Houghton, A.W. Phased array beam steering using phase-locked loops p165
Brewster, R.L., and Malyan, A.D. see Malyan, A.D.
Bridge, J.P., Ladbrooke, P.H., and Hill, A.J. see Ladbrooke, P.H.
Bridges, E., and Simons, N.R.S. see Simons, N.R.S.
Bridges, G.E. Definition of the high frequency characteristic impedance of an overhead conductor p2079
Bridgett, N., and Lewis, C.P. Effect of initial conditions on limit cycle performance of second order sampled data sigma delta modulator p817
Brierley, M., and Pedersen, J.E. see Pedersen, J.E.
Brierley, M.C., Millar, C.A., Hunt, M.H., and Carter, S.F. see Millar, C.A.
Brierley, M.C., Pedersen, J.E., Carter, S.F., and France, P.W. see Pedersen, J.E.
Brinkmeyer, E., and Ulrich, R. High-resolution OCDR in dispersive waveguides p413
Broberg, B., Hoffmann, B., Jensen, N.G., Bødtker, E., and Nielsen, S.K. see Hoffmann, B.
Broberg, B., Öberg, M., Nilsson, S., Holmberg, B., and Klinga, T. see Öberg, M.
Brock, T., Kwon, Y., Pavlidis, D., Tutt, M., Ng, G.I., and Lai, R. see Kwon, Y.
Broomhead, D.S., Jones, R., McWhirter, J.G., and Shepherd, T.J. Systolic array for nonlinear multidimensional interpolation using radial basis functions p7

Brosson, P., Perales, A., Goldstein, L., Accard, A., Fernier, B., Leblond, F., and Gourdain, C. see Perales, A.

Broughton, C., Sundaresan, H., Kwan, S., Lord, A., Duncan, W.J., Henning, I.D., and Stallard, W.A. see Sundaresan, H.

Brown, R.J., Kelly, M.J., Pepper, M., Hasko, D.G., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Kelly, M.J.

Brown, R.L., Twu, Y., Wang, S.J., Kuo, C.Y., Wynn, J.D., Gruezke, L.A., Strege, K.E., Lin, M.S., and Dutta, N.K. see Twu, Y.

Brown-Goebeler, K., Lee, Y.H., Tell, B., Jewell, J.L., Leibenguth, R.E., Asom, M.T., Livescu, G., Luther, L., and Mattera, V.D. see Lee, Y.H.

Brown-Goebeler, K., Lee, Y.H., Tell, B., Jewell, J.L., and Hove, J.V. see Lee, Y.H.

Brown-Goebeler, K., Zucker, J.E., Jones, K.L., Chang, T.Y., Sauer, N., Tell, B., Wegener, M., and Chemla, D.S. see Zucker, J.E.

Brown-Goebeler, K.F., Lee, Y.H., Jewell, J.L., Tell, B., Scherer, A., Harbison, J.P., and Florez, L.T. see Lee, Y.H.

Brownlow, M.J., Tarassenko, L., and Murray, A.F. Analogue computation using VLSI neural network devices p1297

Brugia, O., Carbonelli, M., and Perucchini, D. Performance analysis of the error monitoring methodologies recommended for SDH systems p1394 e1832

Bruguera, J.D., Pena, T.F., Cabaleiro, J.C., and Zapata, E.L. see Pena, T.F.

Bryan, R.P., Favaro, M.E., Alwan, J.J., Miller, L.M., Coleman, J.J., Kim, J., and Wayman, C.M. see Favaro, M.E.

Bryant, D.L., and Allnutt, J.E. Use of closely-spaced height diversity antennas to alleviate the effects of low angle non-absorptive fading on satellite slant paths p479

Bryant, E.G., Carter, S.F., Ellis, A.D., Stallard, W.A., Wright, J.V., and Wyatt, R. Unrepeatered 2·4 Gbit/s transmission experiment over 250 km of step-index fibre using erbium power amplifier p528

Bryant, E.G., Carter, S.F., Lewis, R.B.J., Spirit, D.M., Widdowson, T., and Wright, J.V. Two-way transmission at 2·488 Gbit/s over a 132 km operational submerged cable using erbium-doped fibre power amplifiers p1355

Bryant, E.G., Cox, J.D., Boggis, J.M., Hunter, C.A., and Stallard, W.A. see Cox, J.D.

Bühler, W., Poisel, H., Trommer, G.F., Hartl, E., and Müller, R. see Poisel, H.

Büyükaksoy, A., and İdemen, M. Generalised boundary conditions for a material sheet with both sides coated by a dielectric layer p1967

Bußmann, M., and Langmann, U. Proposal for a versatile monolithic multi-Gbit/s m-sequence test system p1625

Bucher, E.A., Castagnozzi, D.M., Alexander, S.B., Colagiuri, E.P., and Jeromin, L.L. see Castagnozzi, D.M.

Bucholtz, F., Koo, K.P., Dagenais, D.M., and Vohra, S. see Koo, K.P.

Budišin, S.Z. Complementary Huffman sequences p533

Budišin, S.Z. New complementary pairs of sequences p881

Budišin, S.Z. New multilevel complementary pairs of sequences p1861

Buechler, J., Anzill, W., Goeller, T., Kaertner, F.X., and Russer, P. see Anzill, W.

Burgess, N. Removal of sign-extension circuitry from Booth's algorithm multiplier–accumulators p1413

Burness, A.L., Redstall, R.M., Skeats, A.P., and Cooper, D.M. see Redstall, R.M.

Burns, D., and Sibbett, W. Controlled amplifier modelocked Er^{3+} fibre ring laser p505

Burns, H.O., and Fusco, V.F. see Fusco, V.F.

Burrows, E.C., and Liou, K.-Y. High resolution laser LIDAR utilising two-section distributed feedback semiconductor laser as a coherent source p577

Butler, C.M., and Silvestro, J. see Silvestro, J.

Butler, J.K., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.

Butler, R.A., and Cochrane, P. Correlation of interference and bit error activity in a digital transmission system p363

Button, C., McIlvaney, K., Marsh, J.H., and Roberts, J.S. see McIlvaney, K.

Button, C., O'Neill, M., Marsh, J.H., De La Rue, R.M., Roberts, J.S., and Gwilliam, R. see O'Neill, M.

Button, C., Zouganeli, P., Whitehead, M., Stevens, P.J., Rivers, A., Parry, G., and Roberts, J.S. see Zouganeli, P.

Button, C.C., Thirstrup, C., Wa, P.L.K., Roberts, J.S., and Robson, P.N. see Thirstrup, C.

Button, J.E. Performance of CT2/CAI systems in small cell environments p1434

Button, T.W., Smith, P.A., Davis, L.E., and McN Alford, N. see Smith, P.A.

Buus, J., Farries, M.C., and Kearley, M. see Farries, M.C.

Buus, J., Farries, M.C., and Robbins, D.J. see Farries, M.C.

Buus, J., Reid, D.C.J., Ragdale, C.M., Bennion, I., Robbins, D.J., and Stewart, W.J. see Reid, D.C.J.

Buydens, L., Pollentier, I., Ackaert, A., Demeester, P., Van Daele, P., De Pestel, F., Lootens, D., and Baets, R. see Pollentier, I.

Buydens, L., Pollentier, I., Demeester, P., Ackaert, A., Van Daele, P., and Baets, R. see Pollentier, I.

Bylsma, R., Jeong, J., Lum, R.M., Klingert, J.K., Vella-Coleiro, G.P., and Smith, P.R. see Jeong, J.

C

Cabaleiro, J.C., Pena, T.F., Bruguera, J.D., and Zapata, E.L. see Pena, T.F.

Cabon, B., Vu Dinh, T., and Chilo, J. see Vu Dinh, T.

Cacopardi, S., Caporicci, L., Falzini, S., and Soddu, C. GPS relative navigation in rendezvous operations p1640

Cada, M., Keyworth, B.P., Glinski, J.M., Spring-Thorpe, A.J., Rolland, C., and Hill, K.O. see Keyworth, B.P.

Cahill, L.W., and Tobin, G.R. see Tobin, G.R.

Cai, Y., Mizumoto, T., and Naito, Y. Perturbation feedback method for analysing rectangular dielectric waveguides p521

Cain, G.D., Taori, R., and Lever, K.V. see Taori, R.

Calvani, R., and Caponi, R. $x^{(3)}$ measurements in a bistable GaAlAs Fabry–Perot amplifier p1513

Calvez, L.C., Vilbe, P., and Boulbry, J.C. Optimal property of class of finite-energy signals with application to estimation of duration, power and amplitude of transients e219 e219

Cameron, K., Ellis, A.D., Cox, J.D., Bird, D.M., Elton, D.J., Sherlock, G., and Stallard, W.A. see Ellis, A.D.

Cameron, K.H., Al-Chalabi, S.A., Mellis, J., Hollier, M., Wyatt, R., Regnault, J.E., Devlin, W.J., and Brain, M.C. see Al-Chalabi, S.A.

Cameron, K.H., Bird, D.M., Fatah, R.M., Cox, M.K., Constantine, P.D., and Regnault, J.C. see Bird, D.M.

Camisa, R.L., Liu, S.G., Taylor, G.C., Klatskin, J., and Capewell, D.R. see Liu, S.G.

Campbell, J.C., Deppe, D.G., Kuchibhotla, R., Rogers, T.J., and Streetman, B.G. see Deppe, D.G.

Canali, C., Magistrali, F., Sangalli, M., Tedesco, C., and Zanoni, E. Electron detrapping enhanced by electric field in AlGaAs/GaAs HEMTs p313

Canali, C., Tedesco, C., Zanoni, E., Castellaneta, G., Magistrali, F., and Sangalli, M. Kink effect, transconductance increase and field enhanced electron emission in AlGaAs/GaAs HEMTs p1520

Caneau, C., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Zah, C.E., Menocal, S.G., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.

Cao, C., Van Lil, E., Van de Capelle, A., and Van't Klooster, K. see Van Lil, E.

Caorsi, S., Gragnani, G.L., and Pastorino, M. Overconstrained version of moment method for prediction of electromagnetic energy deposition inside dielectric objects p1997

Capewell, D.R., Liu, S.G., Taylor, G.C., Klatskin, J., and Camisa, R.L. see Liu, S.G.

Capmany, J., and Muriel, M.A. Analysis of the interference signal arising from the transmission of a pulse sequence through a monomode fibre p149

Capmany, J., and Muriel, M.A. Investigation on spectral behaviour of novel direct coupling compound fibre ring resonator p772

Caponi, R., and Calvani, R. see Calvani, R.

Caporicci, L., Cacopardi, S., Falzini, S., and Soddu, C. see Cacopardi, S.

Cappy, A., Dambrine, G., Cordier, Y., Druelle, Y., and Legry, P. Ultra high transconductance 0·25 μm gate MESFET with strained InGaAs buffer layer p161

Capron, B., Blaauw, C., Devenyi, T.F., Shepherd, F.R., and Springthorpe, A.J. see Blaauw, C.

Carbonelli, M., Brugia, O., and Perucchini, D. see Brugia, O.

Cardinal, M., Welch, D.F., Streifer, B., and Scifres, D. see Welch, D.F.

Cardinal, M.R., Sakamoto, M., Endriz, J.G., Welch, D.F., and Scifres, D.R. see Sakamoto, M.

Carenco, A., Bigan, E., Allovon, M., and Carre, M. see Bigan, E.

Carisetti, D., Selle, D., Ducourant, T., Bertsch, P., and Boissenot, P. see Selle, D.

Carlosena, A., Martinez, P., Porta, S., and Celma, S. see Martinez, P.

Carlson, N.W., Evans, G.A., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.

Carlson, N.W., Evans, G.A., Bour, D.P., Lurie, M., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.

Carlson, N.W., Patterson, D.R., Stabile, P.J., Liew, S.K., Bour, D.P., and Evans, G.A. Demonstration of digital pulse modulation of a grating-surface-emitting diode laser p1695

Carr, A.D., O'Donnell, A.C., Pollentier, I., Demeester, P., and Van Daele, P. see O'Donnell, A.C.

Carr, T.W., and Adamovsky, G. see Adamovsky, G.

Carre, M., Bigan, E., Allovon, M., and Carenco, A. see Bigan, E.

Carre, M., Saulnier, J., Huet, F., Riviere, L., and Caumont, G. see Saulnier, J.

Carroll, J.E., White, I.H., Watts, J.J.S., Armistead, C.J., Moule, D.J., and Champelovier, J.A. see White, I.H.

Carroll, J.E., and Zheng, X.H. see Zheng, X.H.

Carter, A.C., Williams, P.J., Charles, P.M., Griffith, I., and Considine, L. see Williams, P.J.

Carter, J.N., Smart, R.G., Hanna, D.C., and Tropper, A.C. see Smart, R.G.

Carter, J.N., Smart, R.G., Hanna, D.C., and Tropper, A.C. CW diode-pumped operation of 1·97 μm thulium-doped fluorozirconate fibre laser p599

Carter, J.N., Smart, R.G., Hanna, D.C., and Tropper, A.C. Lasing and amplification in the 0·8 μm region in thulium doped fluorozirconate fibres p1759

Carter, L.J., Wu, Z., Maclean, T.S.M., Jayasundere, N., and Williamson, A.G. see Wu, Z.

Carter, S.F., Bryant, E.G., Ellis, A.D., Stallard, W.A., Wright, J.V., and Wyatt, R. see Bryant, E.G.

Carter, S.F., Bryant, E.G., Lewis, R.B.J., Spirit, D.M., Widdowson, T., and Wright, J.V. see Bryant, E.G.

Carter, S.F., Millar, C.A., Brierley, M.C., and Hunt, M.H. see Millar, C.A.

Carter, S.F., Moore, M.W., Szebesta, D., Williams, J.R., Ranson, D., and France, P.W. Low loss fluoride fibre by reduced pressure casting p2115

Carter, S.F., Pedersen, J.E., Brierley, M.C., and France, P.W. see Pedersen, J.E.

Carter, S.F., Spirit, D.M., Walker, G.R., France, P.W., and Szebesta, D. see Spirit, D.M.

Case, M., Yu, R.Y., Kamegawa, M., Sundaram, M., Rodwell, M.J.W., and Gossard, A.W. see Yu, R.Y.

Castagnozzi, D.M., Alexander, S.B., Barry, R., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.

Castagnozzi, D.M., Alexander, S.B., Colagiuri, E.P., Bucher, E.A., and Jeromin, L.L. Error correcting coding of a 220 Mbit/s coherent optical communication channel p1288

Castellaneta, G., Canali, C., Tedesco, C., Zanoni, E., Magistrali, F., and Sangalli, M. see Canali, C.

Caumont, G., Saulnier, J., Huet, F., Riviere, L., and Carre, M. see Saulnier, J.

Cavaillès, J.A., Renaud, M., Jarry, P., Erman, M., Vinchant, J.F., and Goutelle, A. Integration of detectors with GaInAsP/InP carrier depletion optical switches p1783

Cazarré, A., Vannel, J.P., Marty, A., Tasselli, J., and Bailbé, J.P. see Vannel, J.P.

Celma, S., Martinez, P., Carlosena, A., and Porta, S. see Martinez, P.

Cermak, J., Hyben, P., Ceskovic, R., Kabos, P., and Abraham, A. see Hyben, P.

Červeň, J., and Kukuča, R. PC sampling oscillograph for subnanosecond time region p1950

Ceskovic, R., Hyben, P., Kabos, P., Cermak, J., and Abraham, A. see Hyben, P.

Cha, H.-W., Chung, W.-S., and Kim, K.-H. see Chung, W.-S.

Cha, H.-W., and Chung, W.-S. see Chung, W.-S.

Chadha, D., and Ramakrishna, P.V. see Ramakrishna, P.V.

Chakrabarti, N.B., Ray, S.K., and Maiti, C.K. see Ray, S.K.

Chakrabarti, S., and Maskara, S.L. Performance evaluation of high-speed concatenated codes of low complexity p1799

Chamberlain, J.M., Sellai, A., Raven, M.S., Steenson, D.P., Henini, M., and Hughes, O.H. see Sellai, A.

Chamberlain, J.M., Zarea, A., Sellai, A., Raven, M.S., Steenson, D.P., Henini, M., and Hughes, O.H. see Zarea, A.

Champagne, M., Schmidt, P.E., Barbier, E., Collot, P., Gaonach, C., and Pons, D. see Schmidt, P.E.

Champelovier, J.A., White, I.H., Watts, J.J.S., Carroll, J.E., Armistead, C.J., and Moule, D.J. see White, I.H.

Chan, B., Tao, J.W., and Baudrand, H. see Tao, J.W.

Chan, C.-K., and Po, L.-M. see Po, L.-M.

Chan, C.K., and Po, L.M. see Po, L.M.

Chan, D.A.S., and Shore, K.A. see Shore, K.A.

Chan, E., Mantz, J., Hager, H., and Hong, C.S. see Mantz, J.

Chan, H.P., Pun, E.Y.B., Kong, T.C., and Chung, P.S. see Pun, E.Y.B.

Chan, P.K., and Wilson, G. see Wilson, G.

Chan, S.C., and Ho, K.L. Fast odd discrete cosine transform algorithms p503

Chan, S.C., and Ho, K.L. On computing the discrete Wigner–Ville distribution p636

Chan, S.C., and Ho, K.L. Polynomial transform fast Hartley transform p1914

Chan, V.W.S., Alexander, S.B., Barry, R., Castagnozzi, D.M., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.

Chan, W.K., Shah, D.M., Gmitter, T.J., Florez, L.T., Schumacher, H., and Van der Gaag, B.P. see Shah, D.M.

Chan, Y.-H., and Siu, W.-C. Algorithm for prime length discrete cosine transforms p206

Chandler, P.J., Field, S.J., Hanna, D.C., Shepherd, D.P., Tropper, A.C., Townsend, P.D., and Zhang, L. see Field, S.J.

Chandler, P.J., Townsend, P.D., Wood, R.A., Zhang, L., McCallum, J., and McHargue, C.W.

see Townsend, P.D.
Chandler, P.S., Zhang, L., and Townsend, P.D. Ion implanted waveguides in doped $LiNbO_3$ p332
Chandrasekhar, S., Dentai, A.G., Joyner, C.H., Johnson, B.C., Gnauck, A.H., and Qua, G.J. 4 Gbit/s *pin*/HBT monolithic photoreceiver p1880
Chang, C.-J., and Wang, J.-I. Error control strategies for cut-through switching network p1894
Chang, F.R., and Fang, C.H. see Fang, C.H.
Chang, G.-K., Rao, M.V., and Hong, W.-P. see Rao, M.V.
Chang, J., Tan, M.R.T., Kim, I., and Wang, S.Y. see Tan, M.R.T.
Chang, J.-L., Yang, C-D., and Chung, H.-Y. see Yang, C-D.
Chang, K., and Gopalakrishnan, G.K. see Gopalakrishnan, G.K.
Chang, K., and Klein, J.L. see Klein, J.L.
Chang, M.-W., Jen, B.-S., Sun, S.-W., Shih, C.-H., and Wu, T.-M. see Jen, B.-S.
Chang, N.S., Maekawa, Y., Miyazaki, A., and Segawa, T. see Maekawa, Y.
Chang, T.-C., Lin, M.-C., and Fu, H.-L. see Lin, M.-C.
Chang, T.Y., Zucker, J.E., Jones, K.L., Sauer, N., Tell, B., Brown-Goebeler, K., Wegener, M., and Chemla, D.S. see Zucker, J.E.
Chang, W.S.C., and Lin, Z.-Q. see Lin, Z.-Q.
Chang-Hasnain, C.J., Maeda, M.W., Stoffel, N.G., Harbison, J.P., Florez, L.T., and Jewell, J. Surface emitting laser arrays with uniformly separated wavelengths p940
Chantre, A., Giroult-Matlakowski, G., Degors, N., Marty, A., and Nouailhat, A. see Giroult-Matlakowski, G.
Chao, J.H.C., and Neudeck, G.W. Optical fibre microbending sensors by micromachining techniques p513
Chao, P.C., Ho, P., Duh, K.H.G., Smith, P.M., Ballingall, J.M., Jabra, A.A., Lewis, N., and Hall, E.L. Very low-noise $Al_{0.3}Ga_{0.7}As/Ga_{0.65}In_{0.35}As/GaAs$ single quantum-well pseudomorphic HEMTs p27
Chapuran, T.E., Kobrinski, H., Vecchi, M.P., Georges, J.B., Zah, C.E., Caneau, C., Menocal, S.G., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.
Chapuran, T.E., and Wagner, S.S. see Wagner, S.S.
Charles, P.M., Williams, P.J., Griffith, I., Considine, L., and Carter, A.C. see Williams, P.J.
Chatenoud, F., Janega, P.L., and Wasilewski, Z. see Janega, P.L.
Chatenoud, F., Normandin, R., and Williams, R.L. see Normandin, R.
Chawki, M.J., Auffret, R., and Berthou, L. 1·5 Gbit/s FSK transmission system using two electrode DFB laser as a tunable FSK discriminator/photodetector p1146
Cheeke, J.D.N., Wang, Z., and Jen, C.K. see Wang, Z.
Cheetham, B.M.G., Leigh, S.P., and Mellor, P.H. see Leigh, S.P.
Chemla, D.S., Goossen, K.W., Zucker, J.E., Bar-Joseph, I., Kuo, J.M., Kopf, R.M., and Miller, D.A.B. see Goossen, K.W.
Chemla, D.S., Zucker, J.E., Jones, K.L., Chang, T.Y., Sauer, N., Tell, B., Brown-Goebeler, K., and Wegener, M. see Zucker, J.E.
Chen, C.-H., and Li, H. see Li, H.
Chen, C.L., Turner, G.W., Connors, M.K., Mahoney, L.J., and McGilvary, W.L. see Turner, G.W.
Chen, G.-S., Wu, J.-L., and Lee, L.-S. Signal extrapolation from Hartley transform magnitudes p793
Chen, J., Gao, G.B., Ünlü, M.S., and Morkoç, H. High-frequency output characteristics of AlGaAs/GaAs heterojunction bipolar transistors p2058
Chen, J.F., Yang, L., and Cho, A.Y. see Yang, L.
Chen, K., and Stuart, T.A. Soft switch-avalanche IGBT convertor p1623
Chen, S., Meggitt, B.T., and Rogers, A.J. Electronically-scanned white light interferometry with enhanced dynamic range p1663
Chen, S., Meggitt, B.T., and Rogers, A.J. Novel electronic scanner for coherence multiplexing in a quasi-distributed pressure sensor p1367 e1738
Chen, S., and Giles, I.P. 'On-spot' interferometric optical coherence domain polarimetry for quasi-distribute temperature sensors p1607
Chen, S.-H., and Huang, S.-H. see Huang, S.-H.
Chen, S.X., Smith, P.J., Shafi, M., and Vere-Jones, D. Some improvements to conventional importance sampling techniques for coded systems using Viterbi decoding p802
Chen, T.R., Zhuang, Y.H., Yariv, A., Blauvelt, H., and Bar-Chaim, N. Combined high power and high frequency operation of InGaAsP/InP lasers at 1·3 μm p985
Chen, Y. Twin core nonlinear couplers with saturable nonlinearity p1374
Chen, Y., Mitchell, D.J., and Snyder, A.W. see Mitchell, D.J.
Chen, Y., Snyder, A.W., Poladian, L., and Mitchell, D.J. see Snyder, A.W.
Chen, Y., Snyder, A.W., and Mitchell, D.J. Ideal optical switching by nonlinear multiple (parasitic) core couplers p77
Chen, Y., Snyder, A.W., and Mitchell, D.J. Power flow in triple-core couplers p76
Chen, Y.C., Waters, R.G., and Dalby, R.J. Single-quantum-well laser with 11·2 degree transverse beam divergence p1348
Chen, Y.C., Yellen, S.L., Waters, R.G., Soltz, B.A., Fischer, S.E., Fekete, D., and Ballantyne, J.M. see Yellen, S.L.
Chen, Y.C., and Hwang, J.K. see Hwang, J.K.
Chen, Y.K., Tsang, W.T., Wu, M.C., Yang, L., and Sergent, A.M. see Tsang, W.T.
Cheng, K.K.M., and Everard, J.K.A. Nonlinear circuit analysis using the Newton-SOR continuation method p2120
Cheng, S-X., and Yu, X-H. see Yu, X-H.
Cheng, Y.H., and Okoshi, T. Multichannel DPSK coherent optical communication systems p1378
Cheung, N.K., Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Young, J., and Tarbox, E.J. see Righetti, A.
Cheung, R., Tang, Y.S., and Wilkinson, C.D.W. see Tang, Y.S.
Chew, N.G., Hedges, S.J., Adams, M.J., and Nicholson, B.F. see Hedges, S.J.
Chi, S., and Lin, M.-C. Optimum transmission conditions of solitons by pre-emphasis technique p1473
Chi, S., and Shi, T.-T. Nonlinear Y-junction coupler p339
Chi, S., and Wang, S.-C. Maximum bitrate-length product in the high density WDM optical fibre communication system p1509
Chia, S.T.S. 1·7 GHz propagation measurements for highway microcells p1279
Chiang, K.S., Wong, D., and Chu, P.L. Strain-induced birefringence in a highly birefringent optical fibre p1344
Chiang, K.S., and Wong, D. Hydrostatic pressure induced birefringence in a highly birefringent optical fibre p1952
Chicharo, J.F. Error surface analysis of adaptive comb filter p587
Chidgey, P.J., Kilkelly, P.D.D., and Hill, G. see Kilkelly, P.D.D.
Chidgey, P.J., and Hill, G.R. Diverse routing in wavelength selective networks p1709
Chien, H., Aina, L., Serio, M., Mattingly, M., and Hempfling, E. see Aina, L.
Chien, M., Koren, U., Oron, M., Young, M.G., Miller, B.I., De Miguel, J.L., and Raybon, G. see Koren, U.
Chihara, H., Mizumoto, T., Tokui, N., and Naito, Y. see Mizumoto, T.
Chikama, T., Naito, T., Ishikawa, G., and Kuwahara, H. see Naito, T.
Chikyow, T., Takahashi, S., Koguchi, N., Kiyosawa, T., Fujiwara, J., and Yoshihara, K. see Takahashi, S.
Chilo, J., Vu Dinh, T., and Cabon, B. see Vu Dinh, T.
Chinn, S., Ackerman, E., Kasemsei, D., and Wanuga, S. see Ackerman, E.
Chinone, N., Aoki, M., Uomi, K., Tsuchiya, T., and Suzuki, M. see Aoki, M.
Chinone, N., Uomi, K., Sasaki, S., Tsuchiya, T., Okai, M., and Aoki, M. see Uomi, K.
Chiu, J.-H., and Lee, L.-S. Simplified data transition tracking loop—a new NRZ maximum likelihood symbol synchroniser p1417
Chiu, T.H., Kuo, T.Y., Cunningham, J.E., Goossen, K.W., Fonstad, C.G., and Ren, F. see Kuo, T.Y.
Chiueh, T.D., Jeng, Y.-J., and Yeh, C.-C. see Jeng, Y.-J.
Cho, A.Y., Dutta, N.K., Wynn, J.D., Lopata, J., and Sivco, D.L. see Dutta, N.K.
Cho, A.Y., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., and Gamelin, J. see Hasnain, G.
Cho, A.Y., Tai, K., Hasnain, G., Wynn, J.D., Fischer, R.J., Wang, Y.H., Weir, B., and Gamelin, J. see Tai, K.
Cho, A.Y., Yang, L., and Chen, J.F. see Yang, L.
Cho, G.H., Kim, I.D., and Nho, E.C. see Kim, I.D.
Cho, G.H., and Cho, J.G. see Cho, J.G.
Cho, G.H., and Park, S.S. see Park, S.S.
Cho, J.G., and Cho, G.H. Cyclic quasi-resonant convertor: a new quasi-resonant DC/DC convertor with improved characteristics p1821
Cho, K.-Y., Hong, S.-S., Oh, D.-S., and Youn, M.-J. Speed control of permanent magnet synchronous motor using boundary layer state observer p2081
Cho, Y., Ohke, S., and Nishihara, S. see Ohke, S.
Cho, Y.B., Kurokawa, T., Lee, K.C., and Takefuji, Y. see Kurokawa, T.
Cho, Y.K., Hong, J.P., and Son, H. New radiating edges coupling model for the gap between two rectangular microstrip patch antennas p1295
Choi, C.H., and Ahn, H.S. see Ahn, H.S.
Choi, Y.-I., Chung, M.-H., and Chung, S.-K. see Chung, M.-H.
Chong, T.C., Wan, H.W., and Chua, S.J. Polarisation dependence of field-induced refractive index variation in strained and unstrained quantum well structures p1060
Chou, J.-J., and Lee, T.-H. see Lee, T.-H.
Choudhury, D., and Bhatgadde, L.G. see Bhatgadde, L.G.
Choy, M.M., Way, W.I., Maeda, M.W., Yi-Yan, A., Andrejco, M.J., Saifi, M., and Lin, C. see Way, W.I.
Christou, A., Anderson, W.T., Thompson, P.E., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Christou, A., Goostray, J., Thomas, H., Morgan, D.V., Kohn, E., and Mottet, S. see Goostray, J.
Chu, P.L., Chiang, K.S., and Wong, D. see Chiang, K.S.
Chu, P.L., Peng, G.D., and Tjugiarto, T. see Peng, G.D.
Chu, P.L., and Wong, D. see Wong, D.
Chu, S.F., and Gao, Z.D. New transmitter-receiver for power system protection based on microprocessor p1006
Chua, S.J., Chong, T.C., and Wan, H.W. see Chong, T.C.
Chung, F.L., and Lee, T. see Lee, T.
Chung, G.S., Kawahito, S., Ishida, M., and Nakamura, T. Novel pressure sensors with multilayer SOI structures p775
Chung, H.-Y., Yang, C-D., and Chang, J.-L. see Yang, C-D.
Chung, M.-H., Choi, Y.-I., and Chung, S.-K. Lateral Si avalanche photodiode fabricated over an etched interdigital mesa p1946
Chung, M.J., and Yoo, D.S. see Yoo, D.S.
Chung, P.S., Pun, E.Y.B., Kong, T.C., and Chan, H.P. see Pun, E.Y.B.
Chung, S.-K., Chung, M.-H., and Choi, Y.-I. see Chung, M.-H.
Chung, W.-S., Cha, H.-W., and Kim, K.-H. Temperature-stable VCO based on operational transconductance amplifiers p1900
Chung, W.-S., and Cha, H.-W. Bipolar linear transconductor p619
Chung, Y., and Dagli, N. Explicit finite difference beam propagation method: Application to semiconductor rib waveguide Y-junction analysis p711
Churchill, F.E. Effect of unequal rise and fall times on the autocorrelation function of a PN sequence p1838
Chusseau, L., Bouchon, D., Duvillaret, L., and Lourtioz, J.M. Autocorrelation at 1·3–1·5 μm using POM crystal p589
Chusseau, L., Xie, J.M., Duvillaret, L., Lourtioz, J.M., Accard, A., and Hebert, J-P. Bandwidth-limited 0·3W picosecond pulses (4 ps) from a 1·53 μm microwave modulated DFB laser with fibre compression p1085
Chusseau, L., Yang, D.D., Boucaud, P., Julien, F.H., Lourtioz, J.-M., and Planel, R. see Yang, D.D.
Chyi, J.-I., Ünlü, M.S., Kishino, K., Reed, J., Arsenault, L., and Morkoç, H. see Ünlü, M.S.
Cichocki, A., and Unbehauen, R. New analogue four-quadrant voltage divider p1580
Ciric, I.R., and Cooray, M.F.R. see Cooray, M.F.R.
Claassen, M., and Heinrich, M. see Heinrich, M.
Clarke, R.J., and Wang, Q. see Wang, Q.
Clarke, R.N., Jenkins, S., Hodgetts, T.E., Symm, G.T., Warham, A.G.P., and Preece, A.W. see Jenkins, S.
Clarkson, T.G. Frequency-hopping radio filter design using the DSP16 processor p586
Claxton, P.A., Woodhead, J., Grey, R., Sale, T.E., David, J.P.R., Liu, L., Pate, M.A., Hill, G., and Robson, P.N. see Woodhead, J.
Cleland, D., Lord, A., Wilkinson, I.J., Ellis, A., Garnham, R.A., and Stallard, W.A. see Lord, A.
Clements, A.M., Shaw, D.I., and Bennett, J.C. see Shaw, D.I.
Clergeaud, C., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Clerot, F., Loualiche, S., Le Corre, A., Ginudi, A., Henry, L., and Vaudry, C. see Loualiche, S.
Clerot, F., Loualiche, S., and Audibert, G. see Loualiche, S.
Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. Repeaterless transmission with 62·9 dB power budget using a highly efficient erbium-doped fibre amplifier module p1426
Cloude, S.R. Polarimetric optimisation based on the target covariance matrix p1670
Cochrane, P., Deslandes, J.E., and Jones, E.V. see Deslandes, J.E.
Cochrane, P., and Butler, R.A. see Butler, R.A.
Coenen, A.J.R.M. Maximum SQNR formula for delta-sigma modulation p1115
Coetzee, J.C., and Malherbe, J.A.G. Generalised theory of a non-TEM transmission line taper without discontinuities p1549 e2056
Cohen, D., and Shawe-Taylor, J. Daugman's Gabor transform as a simple generative back propagation network p1241
Cohen, M.M., and Lau, P.-K. see Lau, P.-K.
Colagiovanni, L., and Shaout, A. Cache memory replacement policy for a uniprocessor system p509
Colagiuri, E.P., Castagnozzi, D.M., Alexander, S.B., Bucher, E.A., and Jeromin, L.L. see Castagnozzi, D.M.
Cole, S., Duncan, W.J., Marsh, E.M., Skevington, P.J., and Spiller, G.D.T. Doping level anomalies in *p*-InP resulting from exposure to dopant precursors during cool-down in MOVPE p391
Coleman, J.J., Favaro, M.E., Alwan, J.J., Bryan, R.P., Miller, L.M., Kim, J., and Wayman, C.M. see Favaro, M.E.
Coles, A.N., Cunningham, D.G., and White, I.H. see

Cunningham, D.G.
Colinge, J.P., Martino, J.A., Lauwers, L., and De Meyer, K. see Martino, J.A.
Collot, P., Schmidt, P.E., Barbier, E., Gaonach, C., Champagne, M., and Pons, D. see Schmidt, P.E.
Compton, R.C., York, R.A., and Martinez, R.D. see York, R.A.
Condie, A., Kearney, M.J., Kelly, M.J., and Dale, I. see Kearney, M.J.
Condie, A., Syme, R.T., Kelly, M.J., and Dale, I. see Syme, R.T.
Conn, D.R., and Xie, S. Speed limitations of multilayer digital packages p1751
Connors, M.K., Turner, G.W., Chen, C.L., Mahoney, L.J., and McGilvary, W.L. see Turner, G.W.
Considine, L., Williams, P.J., Charles, P.M., Griffith, I., and Carter, A.C. see Williams, P.J.
Constant, E., Vanbremeersch, J., Zimmermann, J., Valin, I., Godts, P., and Leroy, A. see Vanbremeersch, J.
Constant, M., Boussekey, L., Decoster, D., Bartenlian, B., and Pascal, D. Detectivity of gallium arsenide on silicon substrate photoconductive detectors p239
Constant, M., Boussekey, L., Decoster, D., and Vilcot, J.P. GaAs photoconductor array as new detector in multichannel spectroscopic system p56
Constantine, P.D., Bird, D.M., Fatah, R.M., Cox, M.K., Regnault, J.C., and Cameron, K.H. see Bird, D.M.
Cook, G.G., Khamas, S., Kingsley, S.P., and Woods, R.C. see Khamas, S.
Cook, J.W., and Foster, K.T. Crosstalk injection when testing transmission systems p1181
Cooper, A.J. 'Fibre/radio' for the provision of cordless/mobile telephony services in the access network p2054
Cooper, D.L., and Bingulac, S. see Bingulac, S.
Cooper, D.L., and Bingulac, S. Computational improvement in the calculation of the natural log of a square matrix p861
Cooper, D.M., Bagley, M., Sherlock, G., Westbrook, L.D., Elton, D.J., Wickes, H.J., Spurdens, P.C., and Devlin, W.J. see Bagley, M.
Cooper, D.M., Bagley, M., Wyatt, R., Elton, D.J., Wickes, H.J., Spurdens, P.C., Seltzer, C.P., and Devlin, W.J. see Bagley, M.
Cooper, D.M., Redstall, R.M., Skeats, A.P., and Burness, A.L. see Redstall, R.M.
Cooray, M.F.R., and Ciric, I.R. Approximate solution to wave scattering by two coaxial spheroids p1371
Copeland, J.M., Diemeer, M.B.J., Suyten, F.M.M., Trommel, E.S., McDonach, A., Jenneskens, L.W., and Horsthuis, W.H.G. see Diemeer, M.B.J.
Coppa, G., Accornero, R., Artiglia, M., Di Vita, P., Lapenta, G., Potenza, M., and Ravetto, P. see Accornero, R.
Coppin, P., and Hodgkinson, T.G. see Hodgkinson, T.G.
Coppin, P., and Hodgkinson, T.G. Novel optical frequency comb synthesis using optical feedback p28
Cordier, Y., Cappy, A., Dambrine, G., Druelle, Y., and Legry, P. see Cappy, A.
Corte-Real, L., and Alves, A.P. Vector quantisation of image sequences using variable size and variable shape blocks p1483
Costa, D., Liu, W.U., Hill, D., and Harris, Jun, J.S. see Liu, W.U.
Costa, D., Liu, W.U., and Harris, J. see Liu, W.U.
Cotter, D., and Girdlestone, H.P. Electroabsorption by semiconductor microcrystallites in glass: observation of Franz–Keldysh oscillations p183
Cowle, G.J., Morkel, P.R., Laming, R.I., and Payne, D.N. Spectral broadening due to fibre amplifier phase noise p424
Cowle, G.J., Morkel, P.R., and Payne, D.N. see Morkel, P.R.
Cox, J.D., Boggis, J.M., Bryant, E.G., Hunter, C.A., and Stallard, W.A. First field demonstration of in-service fault location/supervisory using optical time domain reflectometry p110
Cox, J.D., Ellis, A.D., Bird, D.M., Cameron, K., Elton, D.J., Sherlock, G., and Stallard, W.A. see Ellis, A.D.
Cox, M.K., Bird, D.M., Fatah, R.M., Constantine, P.D., Regnault, J.C., and Cameron, K.H. see Bird, D.M.
Craig, R., Parke, R., Welch, D., Mehuys, D., Waarts, R., and Scifres, D. see Parke, R.
Craig, R., Welch, D., Streifer, W., and Scifres, D. see Welch, D.
Craig-Ryan, S., Smyth, P.P., Wyatt, R., Fidler, A., Eardley, P., and Sayles, A. see Smyth, P.P.
Craig-Ryan, S.P., Ainslie, B.J., and Millar, C.A. Fabrication of long lengths of low excess loss erbium-doped optical fibre p185
Craig-Ryan, S.P., Fermann, M.E., Hofer, M., and Haberl, F. see Fermann, M.E.
Craig-Ryan, S.P., Massicott, J.F., Armitage, J.R., Wyatt, R., and Ainslie, B.J. see Massicott, J.F.
Craig-Ryan, S.P., Massicott, J.F., Wyatt, R., and Ainslie, B.J. see Massicott, J.F.
Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. Field demonstration of coherent transmission system with diode-pumped erbium doped fibre amplifiers p442
Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. Field demonstration of two channel coherent transmission with a diode-pumped fibre amplifier repeater p1621
Crohn, I., Bonek, E., and Weinrichter, H. Modified scatterer distribution model for fast fading mobile communication channel p1575
Croituro, N., Iztkovich, M., Tur, M., and Hardy, A. see Iztkovich, M.
Crookes, C.G., Lancefield, D., Waterhouse, K., Adams, A.R., Greene, P.D., and Glew, R.W. Hydrogen passivation of high purity *n*-type InP p369
Croq, F., and Papiernik, A. Large bandwidth aperture-coupled microstrip antenna p1293
Cross, P.S., Streifer, W., Hardy, A., Welch, D.F., and Scifres, D.R. see Streifer, W.
Croston, I.R., and Young, T.P. Design of an InGaAlAs/InP '3mi' wavelength division demultiplexer employing a novel mode transformer p336
Crozat, P., Zounon, A., and Adde, R. see Zounon, A.
Crozat, P., and Henaux, J.C. see Henaux, J.C.
Cryan, C.V., Birks, T.A., Kenny, R.P., and Oakley, K.P. see Birks, T.A.
Cuhaci, M., Martin, J.T.H. St., Antar, Y.M.M., Kishk, A.A., and Ittipiboon, A. see Martin, J.T.H. St.
Cuhaci, M., Oostlander, R., Antar, Y.M.M., and Ittipiboon, A. see Oostlander, R.
Culverhouse, D., St J Russell, P., and Farahi, F. see St J Russell, P.
Cunningham, D.G., Coles, A.N., and White, I.H. Noise characteristics of polarisation sensitive optically preamplified receivers p1619
Cunningham, J.E., Kuo, T.Y., Chiu, T.H., Goossen, K.W., Fonstad, C.G., and Ren, F. see Kuo, T.Y.
Cunningham, J.E., Kuo, T.Y., Goossen, K.W., Jan, W.Y., Fonstad, C.G., and Ren, F. see Kuo, T.Y.
Curti, F., Betti, S., De Marchis, G., and Iannone, E. see Betti, S.
Czajkowski, I.K., Allam, J., and Adams, A.R. Role of satellite valleys in ionisation rate enhancement in multiple quantum well avalanche photodiodes p1311
Czarnul, Z., and Fujii, N. Highly-linear transconductor cell realised by double MOS transistor differential pairs p1819
Czarnul, Z., and Takagi, S. Design of linear tunable CMOS differential transconductor cells p1809

D

D'Ottavi, A., Hui, R., Mecozzi, A., and Spano, P. see Hui, R.
Dämbkes, H., Marschall, P., Zhang, Y.H., and Ploog, K. High performance $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As$ HFETs p488
Da Loura, G., Flaarønning, N., Frorud, J.O., Sotom, M., Vendrôme, G., Gabriagues, J.M., Jacquet, J., Leclerc, D., and Benoit, J. see Flaarønning, N.
da Rocha, V.C., and Farrell, P.G. Extension of the Smith construction for self orthogonal array codes p1313
Dagenais, D.M., Koo, K.P., Vohra, S., and Bucholtz, F. see Koo, K.P.
Dagli, N., and Chung, Y. see Chung, Y.
Dahbura, M.I., Kuo, C.Y., Ackerman, D.A., Henry, C.H., Shani, Y., Kistler, R., and Wagner, E.J. see Kuo, C.Y.
Dahlman, E. New adaptive Viterbi detector for fast-fading mobile-radio channels p1572
Dalby, R.J., Chen, Y.C., and Waters, R.G. see Chen, Y.C.
Dale, I., Kearney, M.J., Kelly, M.J., and Condie, A. see Kearney, M.J.
Dale, I., Syme, R.T., Kelly, M.J., and Condie, A. see Syme, R.T.
Dalle, C., Pöbl, M., Freyer, J., and Harth, W. see Pöbl, M.
Dalman, G.C. New waveguide-to-coplanar waveguide transition for centimetre and millimetre wave applications p830
Dambrine, G., Cappy, A., Cordier, Y., Druelle, Y., and Legry, P. see Cappy, A.
Dandridge, A., and Mermelstein, M.D. see Mermelstein, M.D.
Dangla, J., Alexandre, F., Benchimol, J.L., Dubon-Chevallier, C., and Amarger, V. see Alexandre, F.
Dangla, J., Dubon-Chevallier, C., Filoche, M., and Azoulay, R. Electrical characterisation of the p-type dopant diffusion of highly doped AlGaAs/GaAs heterojunction bipolar transistors grown by MOCVD p1061
Daniel, D. Novel 4:1 multiplexer circuit for Gbit/s data rates p1092
Daniel, J.P., Khellaf, A., and Thouroude, D. see Khellaf, A.
Daniel, J.P., Thouroude, D., and Himdi, M. see Thouroude, D.
Daniels, R.R., Griem, H.T., Fuji, H.S., Williams, T.J., Harrang, J.P., Ray, S., LaGasse, M.J., and West, D.L. see Griem, H.T.
Darnell, M., Honary, B., and Shaw, M. see Honary, B.
Darnell, M., and Grayson, M. see Grayson, M.
Darzi, A., Valera, J., Walker, A.C., Krug, W., Miao, E., Derstine, M., and Polky, J.N. see Valera, J.
Das, K., Humphreys, T.P., Nemanich, R.J., Parikh, N.R., and Posthill, J.B. see Humphreys, T.P.
Das, N., Pattnaik, S.S., and Mishra, R.K. see Pattnaik, S.S.
Davey, S.T., Kashyap, R., Armitage, J.R., Wyatt, R., and Williams, D.L. see Kashyap, R.
Davey, S.T., Spirit, D.M., Blank, L.C., Williams, D.L., and Ainslie, B.J. see Spirit, D.M.
Davey, S.T., Williams, D.L., Spirit, D.M., and Ainslie, B.J. see Williams, D.L.
Davey, S.T., Williams, D.L., Spirit, D.M., and Ainslie, B.J. Lossless transmission over 10 km of low-dispersion erbium doped fibre using only 15 mW pump power p1148
David, J.P.R., Woodhead, J., Claxton, P.A., Grey, R., Sale, T.E., Liu, L., Pate, M.A., Hill, G., and Robson, P.N. see Woodhead, J.
David, K., Morthier, G., Vankwikelberge, P., and Baets, R. Yield analysis of non-AR-coated DFB lasers with combined index and gain coupling p238
Davies, I., Bestwick, P.R., and Vanner, K.C. see Bestwick, P.R.
Davies, R., Simpson, A., and McGeehan, J.P. Propagation measurements at 1·7 GHz for microcellular urban communications p1053
Davies, W.D. Monte Carlo estimates of incidence of basic access ISDN generated EMI p1048
Davis, F., Hardcastle, I., Large, Y., and Hadjifotiou, A. see Hardcastle, I.
Davis, L.E., Smith, P.A., McN Alford, N., and Button, T.W. see Smith, P.A.
Dawe, P.J.G., Lee, W.S., Spear, D.A.H., Agnew, M.J., and Bland, S.W. see Lee, W.S.
Dawe, P.J.G., Lee, W.S., Spear, D.A.H., and Bland, S.W. see Lee, W.S.
Dawson, E., Sridharan, S., and Goldburg, B. see Sridharan, S.
Day, M., Yuen, C., Pao, Y.C., Nishimoto, C., Glenn, M., Bandy, S., and Zdasiuk, G. see Yuen, C.
DeFreez, R.K., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., and Bossert, D.J. see Evans, G.A.
DeFreez, R.K., Evans, G.A., Carlson, N.W., Bour, D.P., Lurie, M., and Bossert, D.J. see Evans, G.A.
de Araújo, C.B., Acioli, L.H., and Gomes, A.S.L. see Acioli, L.H.
De Boeck, J., Dobbelaere, W., Van Hove, M., Deneffe, K., De Raedt, W., Mertens, R., and Borghs, G. see Dobbelaere, W.
De Jong, F. BITL format: A way of representing boundary scan test vectors p1072
De La Rue, R.M., Keys, R.W., Loni, A., Ironside, C.N., Marsh, J.H., Luff, B.J., and Townsend, P.D. see Keys, R.W.
De La Rue, R.M., Keys, R.W., and Loni, A. see Keys, R.W.
De La Rue, R.M., O'Neill, M., Marsh, J.H., Roberts, J.S., Button, C., and Gwilliam, R. see O'Neill, M.
De Marchis, G., Betti, S., Curti, F., and Iannone, E. see Betti, S.
De Meyer, K., Martino, J.A., Lauwers, L., and Colinge, J.P. see Martino, J.A.
De Micheli, M., Lallier, E., Pocholle, J.P., Papuchon, M., Li, M.J., He, Q., Ostrowsky, D.B., Grezes-Besset, C., and Pelletier, E. see Lallier, E.
De Miguel, J.L., Koren, U., Oron, M., Young, M.G., Miller, B.I., Raybon, G., and Chien, M. see Koren, U.
de Oliveira, M.C.F., and Fleming, P.J. Effective mapping of continuous-time controllers to their discrete equivalents p562
De Pestel, F., Pollentier, I., Buydens, L., Ackaert, A., Demeester, P., Van Daele, P., Lootens, D., and Baets, R. see Pollentier, I.
de Potter, M., Pereira, R., Van Hove, M., and Van Rossum, M. see Pereira, R.
De Raedt, W., Dobbelaere, W., De Boeck, J., Van Hove, M., Deneffe, K., Mertens, R., and Borghs, G. see Dobbelaere, W.
De Saint Pol, L., Vanbesien, O., and Lippens, D. Estimation of temperature limit for negative differential resistance using resonant tunnelling p342
de Villiers, M.C., and Malherbe, J.A.G. Position of the travelling wave lobes in the backscatter pattern of cylinders p147
de Waal, A.G., Dharmadi, J.J., Mulder, H., and Diekema, A. see Dharmadi, J.J.
Debus, W., Siller, Jun, C.A., and Reeve, H.C. see Siller, Jun, C.A.
Decoster, D., Constant, M., Boussekey, L., Bartenlian, B., and Pascal, D. see Constant, M.
Decoster, D., Constant, M., Boussekey, L., and Vilcot, J.P. see Constant, M.
Deen, M.J. Anomalous drain-induced barrier lowering in short channel nmos devices at 77K p1493
Deen, M.J., Stapleton, S.P., Berolo, E., and Hardy, R.H.S. see Stapleton, S.P.
Deen, M.J., Stapleton, S.P., and Hardy, R.H.S. see Stapleton, S.P.
Deen, M.J., and Zuo, Z.P. Low temperature dependence of the hole impact ionisation constants determined from PMOS transistors p1975
Degors, N., Giroult-Matlakowski, G., Marty, A., Chantre, A., and Nouailhat, A. see Giroult-Matlakowski, G.
Dejun, H. Lateral nonuniform doping technique and its application to the fabrication of GaAs

MESFETs with a lateral linear doping channel p432
Delacourt, D., Papillon, D., Pocholle, J.P., Schnell, J.P., and Papuchon, M. Room temperature observation of mid-infrared inter-subband absorption activated by near-infrared illumination in multiple quantum wells p277
Delavaux, J-M.P., and Riggs, R. High performance packaged optical coherent hybrid p1022
Delavaux, J.-M.P., Park, Y.K., Barski, S., Lefevre, H., Failes, M., and Warner, C. All-fibre optical hybrid for coherent polarisation diversity receivers p1303
Delavaux, J.M., Park, Y.K., Tench, R.E., Barski, S., Owen, B., Tzeng, L.D., and Twu, Y. 1·7 Gbit/s, 1·5 μm Coherent lightwave regenerator p1480
Delrosso, G., Righetti, A., Fontana, F., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Young, J., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Demeester, P., O'Donnell, A.C., Pollentier, I., Van Daele, P., and Carr, A.D. see O'Donnell, A.C.
Demeester, P., Pollentier, I., Ackaert, A., Buydens, L., Van Daele, P., and Baets, R. see Pollentier, I.
Demeester, P., Pollentier, I., Buydens, L., Ackaert, A., Van Daele, P., De Pestel, F., Lootens, D., and Baets, R. see Pollentier, I.
Deneffe, K., Dobbelaere, W., De Boeck, J., Van Hove, M., De Raedt, W., Mertens, R., and Borghs, G. see Dobbelaere, W.
Denis, H., Grand, G., Jadot, J.P., Valette, S., Fournier, A., and Grouillet, A.M. see Grand, G.
Dentai, A.G., Chandrasekhar, S., Joyner, C.H., Johnson, B.C., Gnauck, A.H., and Qua, G.J. see Chandrasekhar, S.
Deoraj, B.M., and Dhariwal, S.R. see Dhariwal, S.R.
Deppe, D.G., Campbell, J.C., Kuchibhotla, R., Rogers, T.J., and Streetman, B.G. Optically-coupled mirror-quantum well InGaAs-GaAs light emitting diode p1665
Deri, R.J., Yasuoka, N., Makiuchi, M., Kuramata, A., and Wada, O. Bend performance of fibre-matched optical waveguides on InP p321
Derickson, D.J., Mar, A., and Bowers, J.E. Residual and absolute timing jitter in actively mode-locked semiconductor lasers p2026
Derr, F. Optical QPSK homodyne transmission of 280 Mbit/s p401
Derstine, M., Valera, J., Darzi, A., Walker, A.C., Krug, W., Miao, E., and Polky, J.N. see Valera, J.
Desai, R.A., and Naylor, P. see Naylor, P.
Desclos, S., Dubost, G., and Zerguerras, A. see Dubost, G.
Deslandes, J.E., Cochrane, P., and Jones, E.V. Error propagation through the European demultiplexer hierarchy—An analysis p1469
Destombes, J.L., Bouregba, R., Lippens, D., Palmateer, L., Bockenhoff, E., Bogey, M., and Lecluse, A. see Bouregba, R.
Desurvire, E., Goel, K.K., Prucnal, P.R., Shimazu, Y., Milbrodt, M., and Tell, B. see Goel, K.K.
Devasirvatham, D.M.J., Krain, M.J., Rappaport, D.A., and Banerjee, C. Radio propagation measurements at 850 MHz, 1·7 GHz and 4 GHz inside two dissimilar office buildings p445
Devenyi, T.F., Blaauw, C., Capron, B., Shepherd, F.R., and Springthorpe, A.J. see Blaauw, C.
Devlin, W.J., Al-Chalabi, S.A., Mellis, J., Hollier, M., Cameron, K.H., Wyatt, R., Regnault, J.E., and Brain, M.C. see Al-Chalabi, S.A.
Devlin, W.J., Bagley, M., Sherlock, G., Cooper, D.M., Westbrook, L.D., Elton, D.J., Wickes, H.J., and Spurdens, P.C. see Bagley, M.
Devlin, W.J., Bagley, M., Wyatt, R., Elton, D.J., Wickes, H.J., Spurdens, P.C., Seltzer, C.P., and Cooper, D.M. see Bagley, M.
Dhariwal, S.R., and Deoraj, B.M. Frequency dependence of admittance of distributed surface states in MOS structures p2110
Dharmadi, J.J., Mulder, H., Diekema, A., and de Waal, A.G. Transfer matrix model for evaluation of optical switch structures p6
DiGiovanni, D.J., Ko, Y.T., MacChesney, J.B., and Simpson, J.R. see Ko, Y.T.
Di Vita, P., Accornero, R., Artiglia, M., Coppa, G., Lapenta, G., Potenza, M., and Ravetto, P. see Accornero, R.
Diamond, S.K., Özbay, E., and Bloom, D.M. see Özbay, E.
Dianov, E.M., Khrushchëv, I.Yu., Grudinin, A.B., Korobkin Jun, D.V., Seménov, V.A., and Prokhorov, A.M. see Khrushchëv, I.Yu.
Diekema, A., Dharmadi, J.J., Mulder, H., and de Waal, A.G. see Dharmadi, J.J.
Diemeer, M.B.J., Suyten, F.M.M., Trommel, E.S., McDonach, A., Copeland, J.M., Jenneskens, L.W., and Horsthuis, W.H.G. Photoinduced channel waveguide formation in nonlinear optical polymers p379
Dietrich, H.B., Klein, P.B., and Moore, F.G. see Klein, P.B.
Digonnet, M., Fesler, K., Liu, K., Kim, B.Y., and Shaw, H.J. see Fesler, K.
Dillon, B.M., Ferrari, R.L., and Young, T.P. Hybrid finite element/boundary element method for analysis of discontinuities in planar dielectric waveguides p47
Dintelmann, F., Ortgies, G., and Rücker, F. see Ortgies, G.
Dissanayake, A.W., Allnutt, J.E., and McCarthy, D.K. Radiometric rain attenuation measurements at 11·6 GHz in Peru p168
Ditchek, B.M., Levinson, M., Rossoni, P., and Rock, F. see Levinson, M.
Djinovic, Z., Djuric, Z., Jaksic, Z., and Totovski, D. see Djuric, Z.
Djupsjöbacka, A. Novel type of baseband phase-reversal electrode for optical modulators with linear phase response p318
Djuric, Z., Djinovic, Z., Jaksic, Z., and Totovski, D. Local growth of HgCdTe Layers by isothermal vapour phase epitaxy p1005
Djuric, Z., Jovic, V., Matic, M., and Jaksic, Z. IR photodetector with exclusion effect and self-filtering n^+ layer p929
Djuric, Z., and Piotrowski, J. Room temperature IR photodetector with electromagnetic carrier depletion p1689
Dlay, S.S., Forster, C.H.N., and Gorgui-Naguib, R.N. see Forster, C.H.N.
Dobbelaere, W., De Boeck, J., Van Hove, M., Deneffe, K., De Raedt, W., Mertens, R., and Borghs, G. Long wavelength infra-red photoconductive InAsSb detectors grown in Si wells by molecular beam epitaxy p259
Dodds, D.E., and Pan, S.M. Robust framing receiver for 2·048 Mbit/s PCM systems p1077
Dodge, J., Schiebel, R.A., and Gooch, R. see Schiebel, R.A.
Doernberg, J., Hauenschild, J., Rein, H.-M., McFarland, W., and Pettengill, D. see Hauenschild, J.
Dombek, K.-P., Hombach, V., Scheffer, H., and Thielen, H. Corrugated dual feed for offset reflector antennas p1679
Dooi, Y., Sekine, K., Iso, A., Funaki, H., and Takei, I. see Sekine, K.
Doran, N.J., Blow, K.J., and Nelson, B.P. see Blow, K.J.
Doran, N.J., Smith, K., Armitage, J.R., Wyatt, R., and Kelly, S.M.J. see Smith, K.
Dossi, L. Real-time prediction of attenuation for applications to fade countermeasures in satellite communications p250
Doussiere, P., Mersali, B., Gelly, G., Accard, A., Lafragette, J.-L., Lambert, M., and Fernier, B. see Mersali, B.
Doyle, B.S., and Krakauer, D. see Krakauer, D.
Drača, D., and Stefanović, M. Bit error probability of phase-coherent communication systems in the presence of noise and interference p1234
Drakin, A., Both, W., Bochkarev, A., and Sverdlov, B. see Both, W.
Drapak, S.I., Manasson, V.A., Kovalyuk, Z.D., and Katerinchuk, V.N. see Manasson, V.A.
Dressler, H.-J. Interpolative bandpass A/D conversion—Experimental results p1652
Drewery, J.O., Sandbank, C.P., and Weston, M. see Sandbank, C.P.
Driessen, A., Hammes, P.C.A., Krijnen, G.J.M., and Smit, M.K. see Hammes, P.C.A.
Druelle, Y., Cappy, A., Dambrine, G., Cordier, Y., and Legry, P. see Cappy, A.
Du, G., Hsin, W., Gamelin, J.K., Malloy, K.J., Wang, S., Whinnery, J.R., Yang, Y.J., Dziura, T.G., and Wang, S.C. see Hsin, W.
Du, J., and Vucetic, B. New M-PSK trellis codes for fading channels p1267
Dütting, K., Schilling, M., Schweizer, H., Idler, W., Kühn, E., Nowitzki, A., and Wünstel, K. see Schilling, M.
Duan, D.W., and Rahmat-Samii, Y. Generalised formulas for beam squint prediction in conic-section reflector antennas p722
Duarte, A.M.O., Violas, M.A.R., Heatley, D.J.T., and Beddow, D.M. see Violas, M.A.R.
Dubon-Chevallier, C., Alexandre, F., Benchimol, J.L., Dangla, J., and Amarger, V. see Alexandre, F.
Dubon-Chevallier, C., Dangla, J., Filoche, M., and Azoulay, R. see Dangla, J.
Dubost, G., Desclos, S., and Zerguerras, A. Radiation of arbitrary shape symmetrical patch antenna coupled with a director p1539
Dubost, G., and Zerguerras, A. Transmission line model analysis of arbitrary shape symmetrical patch antenna coupled with a director p952
Duchet, C., and Flaarønning, N. New TE/TM polarisation splitter made in Ti:$LiNbO_3$ using X-cut and Z-axis propagation p995
Ducourant, T., Selle, D., Carisetti, D., Bertsch, P., and Boissenot, P. see Selle, D.
Duh, K.H.G., Chao, P.C., Ho, P., Smith, P.M., Ballingall, J.M., Jabra, A.A., Lewis, N., and Hall, E.L. see Chao, P.C.
Duncan, R.A., Smith, K.C., and Sedra, A.S. Gallium arsenide pseudo-current-mode logic p2130
Duncan, W.J., Cole, S., Marsh, E.M., Skevington, P.J., and Spiller, G.D.T. see Cole, S.
Duncan, W.J., Sundaresan, H., Kwan, S., Lord, A., Henning, I.D., Stallard, W.A., and Broughton, C. see Sundaresan, H.
Duncan, W.J., Wake, D., Judge, S.N., Spooner, T.P., Harlow, M.J., Henning, I.D., and O'Mahony, M.J. see Wake, D.
Dunlop, J., and Khan, J.Y. Performance of packet reservation multiple access for digital mobile radio using variable rate speech coder p2074
Dunn, J.M., Barsotti, E.L., and Kuester, E.F. see Barsotti, E.L.
Duque-Carrillo, J.F., and Perez-Aloe, R. High-bandwidth CMOS test buffer with very small input capacitance p2084
Durrani, T., Liu, Y., and Soraghan, J.J. see Liu, Y.
Dursin, A., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Dursin, A., Marcerou, J.F., Fevrier, H., Auge, J., and Ramos, J. see Marcerou, J.F.
Duthie, P.J., Edge, C., and Wale, M.J. see Edge, C.
Dutta, N.K., Twu, Y., Wang, S.J., Kuo, C.Y., Wynn, J.D., Brown, R.L., Gruezke, L.A., Strege, K.E., and Lin, M.S. see Twu, Y.
Dutta, N.K., Wang, S.J., Piccirilli, A.B., and Wang, Y.J. see Wang, S.J.
Dutta, N.K., Wang, S.J., Piccirilli, A.B., and Werner, W.V. Crosstalk measurements for a dual emitter laser p1643
Dutta, N.K., Wang, S.J., Twu, Y., and Hartman, R.L. see Wang, S.J.
Dutta, N.K., Wynn, J.D., Lopata, J., Sivco, D.L., and Cho, A.Y. High power InGaAs/GaAs laser array p1816
Duvillaret, L., Chusseau, L., Bouchon, D., and Lourtioz, J.M. see Chusseau, L.
Duvillaret, L., Chusseau, L., Xie, J.M., Lourtioz, J.M., Accard, A., and Hebert, J-P. see Chusseau, L.
Dyott, R.B. Cut-off of the first higher order modes in elliptical dielectric waveguide: An experimental approach p1721
Dziura, T.G., Hsin, W., Du, G., Gamelin, J.K., Malloy, K.J., Wang, S., Whinnery, J.R., Yang, Y.J., and Wang, S.C. see Hsin, W.

E

Eardley, P., Smyth, P.P., Wyatt, R., Fidler, A., Sayles, A., and Craig-Ryan, S. see Smyth, P.P.
Eastman, L.F., Offsey, S.D., Tasker, P.J., Schaff, W.J., Kapitan, L., and Shealy, J.R. see Offsey, S.D.
Ebberg, A., Noé, R., Rodler, H., Gaukel, G., and Auracher, F. see Noé, R.
Ebberg, A., Noé, R., Rodler, H., Gaukel, G., and Noll, B. see Noé, R.
Ebberg, A., and Noé, R. Novel high precision alignment technique for polarisation maintaining fibres using a frequency modulated tunable laser p2009
Edagawa, N., Taga, H., Yoshida, Y., Yamamoto, S., and Wakabayashi, H. see Taga, H.
Edagawa, N., Yoshida, Y., Taga, H., Yamamoto, S., Mochizuki, K., and Wakabayashi, H. 904 km, 1·2 Gbit/s non-regenerative optical fibre transmission experiment using 12 Er-doped fibre amplifiers p66
Edge, C., Duthie, P.J., and Wale, M.J. Passive integrated optical polarisation mode-splitter in lithium niobate employing a resonant metal-loaded structure p1855
Edmonson, P.J., Avramov, I.D., and Smith, P.M. see Avramov, I.D.
Edry, D., Ben-Yaakov, S., Amran, Y., and Shimony, O. see Ben-Yaakov, S.
Efstratiadis, S.N., and Katsaggelos, A.K. Formula for the steady-state gain of a recursive estimator p1682
Efthimiopoulos, T., Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Kudumas, M., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Eggers, P., and Barry, P. Comparison of a diffraction based radiowave propagation model with measurements p530 e1097
Egnell, L., Ahlbom, G., and Wickman, C. see Ahlbom, G.
Ehlers, E., Lee Russell, J., Kellert, F., and Monahan, D. see Lee Russell, J.
Ehrlich, W., and Nawrocki, R. see Nawrocki, R.
Eisele, H. GaAs W-band impatt diodes for very low-noise oscillators p109
Ekanayake, N. Performance of M-ary PSK signals in slow Rayleigh fading channels p618
El-Hennawey, M.S., Zerguine, A., and Hassan, E.E. Non-equally fractionally-spaced equalisers p1254
El-Masry, E., and Maundy, B. see Maundy, B.
El-Rabaie, S., and Ibrahim, S.A. see Ibrahim, S.A.
Elcherif, Y., and Kamar, I. see Kamar, I.
Eldolil, S., Steele, R., and Nofal, M. see Steele, R.
Ellis, A., Lord, A., Wilkinson, I.J., Cleland, D., Garnham, R.A., and Stallard, W.A. see Lord, A.
Ellis, A.D., Bryant, E.G., Carter, S.F., Stallard, W.A., Wright, J.V., and Wyatt, R. see Bryant, E.G.
Ellis, A.D., Cox, J.D., Bird, D.M., Cameron, K., Elton, D.J., Sherlock, G., and Stallard, W.A. 565 Mbit/s 219 km transmission experiment using four gain controlled packaged semiconductor laser amplifiers p385
Elmasry, M.I., and Bellaouar, A. see Bellaouar, A.
Elsässer, W., Nietzke, R., Sacher, J., and Göbel, E.O. see Nietzke, R.
Elton, D.J., Bagley, M., Sherlock, G., Cooper, D.M., Westbrook, L.D., Wickes, H.J., Spurdens, P.C., and Devlin, W.J. see Bagley, M.
Elton, D.J., Bagley, M., Wyatt, R., Wickes, H.J., Spurdens, P.C., Seltzer, C.P., Cooper, D.M., and Devlin, W.J. see Bagley, M.
Elton, D.J., Barnsley, P.E., and Isaac, J.J. see Barnsley, P.E.
Elton, D.J., Ellis, A.D., Cox, J.D., Bird, D.M., Cameron, K., Sherlock, G., and Stallard, W.A. see Ellis, A.D.

Emplit, Ph., Hamaide, J.P., and Gabriagues, J.M. see Hamaide, J.P.
Emrani, A., Hafez, I.M., Ghibaudo, G., and Balestra, F. see Hafez, I.M.
Endo, K., Ueno, Y., Fujii, H., Kobayashi, K., Hara, K., and Yuasa, T. see Ueno, Y.
Endriz, G., Sakamoto, M., Welch, D.F., Yao, H., and Scifres, D.R. see Sakamoto, M.
Endriz, J.G., Sakamoto, M., Cardinal, M.R., Welch, D.F., and Scifres, D.R. see Sakamoto, M.
Eng, L., Sanders, S., and Yariv, A. see Sanders, S.
Eng, L.E., Mehuys, D.G., Mittelstein, M., and Yariv, A. Broadband tuning (170 nm) of InGaAs quantum well lasers p1675
Engheta, N., Jaggard, D.L., and Liu, J. see Jaggard, D.L.
Engheta, N., and Zablocky, P.G. A step towards determining transient response of chiral materials: Kramers–Kronig relations for chiral parameters p2132
Engvik, A.H., Lin, M.S., and Loos, J.S. see Lin, M.S.
Engvik, A.H., Lin, M.S., and Tai, K.L. see Lin, M.S.
Enoki, T., Ohhata, M., Yamane, Y., Sugitani, S., Kato, N., Hagimoto, K., and Hirayama, M. see Ohhata, M.
Enoki, T., Ohhata, M., Yamane, Y., Sugitani, S., Kato, N., and Hirayama, M. see Ohhata, M.
Er, M.H. Computer-aided design of array pattern p2113
Eridon, J.M., Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Erman, M., Cavaillès, J.A., Renaud, M., Jarry, P., Vinchant, J.F., and Goutelle, A. see Cavaillès, J.A.
Ertüzün, A., Kayran, A.H., and Panayirci, E. Stable quarter-plane 2-D lattice filters p806
Esagui, R., Shantharama, L.G., Schumacher, H., Leblanc, H.P., Bhat, R., and Koza, M. see Shantharama, L.G.
Eto, Y., Kinoshita, T., and Nakahashi, T. see Kinoshita, T.
Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. Two dimensional grating surface emitting laser arrays with wide lateral extent p907
Evans, G.A., Carlson, N.W., Bour, D.P., Lurie, M., DeFreez, R.K., and Bossert, D.J. 14 W peak power grating surface-emitting laser array p1380
Evans, G.A., Carlson, N.W., Patterson, D.R., Stabile, P.J., Liew, S.K., and Bour, D.P. see Carlson, N.W.
Everard, J.K.A., and Cheng, K.K.M. see Cheng, K.K.M.
Everard, J.K.A., and Page-Jones, M.A. see Page-Jones, M.A.

F

Fabre, A., Martin, F., and Hanafi, M. Current mode allpass/notch and bandpass filters with reduced sensitivities p1495
Facq, P., Blanchard, P., and Zongo, P.-H. see Blanchard, P.
Facq, P., Zongo, P.-H., and Yu, Q. see Zongo, P.-H.
Failes, M., Delavaux, J.-M.P., Park, Y.K., Barski, S., Lefevre, H., and Warner, C. see Delavaux, J.-M.P.
Faist, J., Wüthrich, C., and Reinhart, F.K. see Wüthrich, C.
Falk, J.-E., Granestrand, P., Lagerström, B., Svensson, P., Thylén, L., Stoltz, B., Bergvall, K., and Olofsson, H. see Granestrand, P.
Fallon, M., Walton, A.J., Gammie, W., Ward, D., and Holwill, R.J. see Walton, A.J.
Falzini, S., Cacopardi, S., Caporicci, L., and Soddu, C. see Cacopardi, S.
Fan, Pingzhi, and Jin, Fan New class of codes suitable for computer error control d1215
Fan, Z., and Lee, K.F. Hankel transform domain analysis of dual-frequency stacked circular disc microstrip antenna p1467
Fang, C.H., and Chang, F.R. Determination of solutions to Bezout identity through eigenvalue placement p644
Farahi, F., St J Russell, P., and Culverhouse, D. see St J Russell, P.
Farrell, P.G., and Peng, X.H. see Peng, X.H.
Farrell, P.G., and da Rocha, V.C. see da Rocha, V.C.
Farries, M.C., Buus, J., and Kearley, M. Design and fabrication of two layer anti-reflection coatings for semiconductor optical amplifiers p1626
Farries, M.C., Buus, J., and Robbins, D.J. Analysis of antireflection coatings on angled facet semiconductor laser amplifiers p381
Fatah, R.M., Bird, D.M., Cox, M.K., Constantine, P.D., Regnault, J.C., and Cameron, K.H. see Bird, D.M.
Favaro, M.E., Alwan, J.J., Bryan, R.P., Miller, L.M., Coleman, J.J., Kim, J., and Wayman, C.M. Strained layer AlGaAs–GaAs–InGaAs real-space transferred electron devices p1264
Favennec, P.N., Kechouane, M., L'Haridon, H., Salvi, M., Moutonnet, D., Gauneau, M., and Mercier, J.P. see Kechouane, M.
Favennec, P.N., Quemerais, A., Jezequel, G., L'Haridon, H., and Salvi, M. see Quemerais, A.
Favennnec, P.N., L'Haridon, H., Moutonnet, D., Salvi, M., and Papadopoulo, A.C. Luminescent Er doped microparticles in a semiconductor matrix p1556
Favire, F.J., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Zah, C.E., Caneau, C., Menocal, S.G., Lin, P.S.D., and Gozdz, A.S. see Kobrinski, H.
Favire, F.J., Reichenbach, D., Zah, C.E., Andreadakis, N., Menocal, S.G., Vodhanel, R., Yi-Yan, A., and Lee, T.P. see Reichenbach, D.
Feher, K., and Makrakis, D. see Makrakis, D.
Fekete, D., Yellen, S.L., Waters, R.G., Chen, Y.C., Soltz, B.A., Fischer, S.E., and Ballantyne, J.M. see Yellen, S.L.
Felder, A., Weger, P., Kerber, M., and Klose, H. see Weger, P.
Felicio, D., Schöpflin, A., Kugelmeier, S., Gottwald, E., and Fischer, G. see Schöpflin, A.
Fenelon, J.P., and Papiernik, A. Dispersion characteristics of ring line through the conformal mapping approach p621
Feng, M., Wang, G.W., Kaliski, R., and Kuang, J.B. see Wang, G.W.
Fenning, S.C., and Rosher, P.A. see Rosher, P.A.
Ferguson, A.I., and Zhou, F. see Zhou, F.
Fermann, M.E., Hofer, M., Haberl, F., and Craig-Ryan, S.P. Femtosecond fibre laser p1738
Fernandez, F.A., and Lu, Y. Variational finite element analysis of dielectric waveguides with no spurious solutions p2125
Fernier, B., Mersali, B., Gelly, G., Accard, A., Lafragette, J.-L., Doussiere, P., and Lambert, M. see Mersali, B.
Fernier, B., Perales, A., Goldstein, L., Accard, A., Leblond, F., Gourdain, C., and Brosson, P. see Perales, A.
Ferrari, R.L., Dillon, B.M., and Young, T.P. see Dillon, B.M.
Ferreira, H.C., Botha, L., and Whalley, M. see Botha, L.
Fesler, K., Digonnet, M., Liu, K., Kim, B.Y., and Shaw, H.J. Spectrum stability of a broadband 1060 nm Nd-doped fibre laser p870
Fevrier, H., Marcerou, J.F., Auge, J., Ramos, J., and Dursin, A. see Marcerou, J.F.
Fidler, A., Smyth, P.P., Wyatt, R., Eardley, P., Sayles, A., and Craig-Ryan, S. see Smyth, P.P.
Field, S.J., Hanna, D.C., Shepherd, D.P., Tropper, A.C., Chandler, P.J., Townsend, P.D., and Zhang, L. Ion-implanted Nd : YAP planar waveguide laser p1826
Figueras, J., Rubio, A., and Segura, J. see Rubio, A.
Filippi, E., and Reyneri, L.M. see Reyneri, L.M.
Filippov, V.N., Kotov, O.I., and Nikolayev, V.M. Measurement of polarisation beat length in single-mode optical fibres with a polarisation modulator p658
Filoche, M., Dangla, J., Dubon-Chevallier, C., and Azoulay, R. see Dangla, J.
Finke, M.N., Boermans, M.J.B., Hagen, S.H., Valster, A., and van der Heyden, J.M.M. see Boermans, M.J.B.
Fischer, G. Switched-capacitor lowpass filters based on recursive running sum cells p557
Fischer, G., Schöpflin, A., Kugelmeier, S., Gottwald, E., and Felicio, D. see Schöpflin, A.
Fischer, R.J., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Fischer, R.J., Tai, K., Hasnain, G., Wynn, J.D., Wang, Y.H., Weir, B., Gamelin, J., and Cho, A.Y. see Tai, K.
Fischer, S.E., Yellen, S.L., Waters, R.G., Chen, Y.C., Soltz, B.A., Fekete, D., and Ballantyne, J.M. see Yellen, S.L.
Flaarønning, N., Frorud, J.O., Sotom, M., Vendrôme, G., Da Loura, G., Gabriagues, J.M., Jacquet, J., Leclerc, D., and Benoit, J. Multichannel FSK transmission experiment at 565 Mbit/s using tunable three-electrode DFB lasers p869
Flaarønning, N., and Duchet, C. see Duchet, C.
Fleming, P.J., and de Oliveira, M.C.F. see de Oliveira, M.C.F.
Fletcher, N.C., and Sundaresan, H. see Sundaresan, H.
Fletcher, P.N., Auchterlonie, L.J., and Hume, A.L. see Auchterlonie, L.J.
Florez, L.T., Chang-Hasnain, C.J., Maeda, M.W., Stoffel, N.G., Harbison, J.P., and Jewell, J. see Chang-Hasnain, C.J.
Florez, L.T., Lee, Y.H., Jewell, J.L., Tell, B., Brown-Goebeler, K.F., Scherer, A., and Harbison, J.P. see Lee, Y.H.
Florez, L.T., Shah, D.M., Chan, W.K., Gmitter, T.J., Schumacher, H., and Van der Gaag, B.P. see Shah, D.M.
Florez, L.T., Yi-Yan, A., Seto, M., Gmitter, T.J., and Hwang, D.M. see Yi-Yan, A.
Florez, L.T., Yoo, H.-J., Hayes, J.R., Paek, E.G., Harbison, J.P., and Kwon, Y.-S. see Yoo, H.-J.
Foley, B.M., Melman, P., and Vo, K.T. Technique for alignment of semiconductor lasers to bevelled single-mode fibres p2118
Fonstad, C.G., Kuo, T.Y., Chiu, T.H., Cunningham, J.E., Goossen, K.W., and Ren, F. see Kuo, T.Y.
Fonstad, C.G., Kuo, T.Y., Cunningham, J.E., Goossen, K.W., Jan, W.Y., and Ren, F. see Kuo, T.Y.
Fontana, F., Righetti, A., Delrosso, G., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Young, J., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Fopma, J.M., Toumazou, C., and Haigh, D.G. see Toumazou, C.
Forchel, A., Korn, M., Körfer, T., and Roentgen, P. see Korn, M.
Forrester, D.S., Hill, A.M., Payne, D.B., Blyth, K.J., Arkwright, J.W., Wyatt, R., Massicott, J.F., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. see Hill, A.M.
Forrester, D.S., Hill, A.M., Wyatt, R., Massicott, J.F., Blyth, K.J., Lobbett, R.A., Smith, P.J., and Payne, D.B. see Hill, A.M.
Forssén, U. Simple derivation of adaptive algorithms for arbitrary filter structures p1764
Forster, C.H.N., Dlay, S.S., and Gorgui-Naguib, R.N. Carry delayed save adders for computing the product $A \cdot B$ modulo N in $\log_2 N$ steps p1544
Forti, M., Manetti, S., and Marini, M. Neural network for adaptive FIR filtering p1018
Foster, K.T., and Cook, J.W. see Cook, J.W.
Fournier, A., Grand, G., Jadot, J.P., Denis, H., Valette, S., and Grouillet, A.M. see Grand, G.
Fralich, R., Wang, J., Wu, G., and Litva, J. see Wang, J.
Franca, J.E., and Leme, C.A. see Leme, C.A.
France, P.W., Carter, S.F., Moore, M.W., Szebesta, D., Williams, J.R., and Ranson, D. see Carter, S.F.
France, P.W., Pedersen, J.E., Brierley, M.C., and Carter, S.F. see Pedersen, J.E.
France, P.W., Spirit, D.M., Walker, G.R., Carter, S.F., and Szebesta, D. see Spirit, D.M.
France, P.W., and Millar, C.A. see Millar, C.A.
Francois, P.L., Monerie, M., Georges, T., Allain, J.Y., and Neveux, D. see Monerie, M.
Franz, J., Wallmeroth, K., Wandernoth, B., Meier, H., and Schorp, B. see Wallmeroth, K.
Frayne, P.G., and Potter, J. Efficient power transfer through small apertures p2070
French, P.M.W., Wigley, P.G.J., and Taylor, J.R. see Wigley, P.G.J.
French, W.D., and Armstrong, G.A. see Armstrong, G.A.
Frey, J., Urai, T., Peng, Z.Z., and Goldsman, N. see Urai, T.
Freyer, J., Pöbl, M., Dalle, C., and Harth, W. see Pöbl, M.
Fricke, K., and Hartnagel, H.-L. Pressure measurement by GaAs piezoelectric sensors p693
Friedman, L., Lareau, R.D., and Soref, R.A. see Lareau, R.D.
Frorud, J.O., Flaarønning, N., Sotom, M., Vendrôme, G., Da Loura, G., Gabriagues, J.M., Jacquet, J., Leclerc, D., and Benoit, J. see Flaarønning, N.
Frost, J.E.F., Kelly, M.J., Brown, R.J., Pepper, M., Hasko, D.G., Ahmed, H., Peacock, D.C., Ritchie, D.A., and Jones, G.A.C. see Kelly, M.J.
Frost, J.E.F., Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Pepper, M., Ahmed, H., Peacock, D.C., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Fu, H.-L., Lin, M.-C., and Chang, T.-C. see Lin, M.-C.
Fuji, H.S., Griem, H.T., Williams, T.J., Harrang, J.P., Daniels, R.R., Ray, S., LaGasse, M.J., and West, D.L. see Griem, H.T.
Fujii, H., Ueno, Y., Endo, K., Kobayashi, K., Hara, K., and Yuasa, T. see Ueno, Y.
Fujii, N., and Czarnul, Z. see Czarnul, Z.
Fujimoto, M., Fukano, H., Kawamura, Y., Asai, H., and Takanashi, Y. see Fukano, H.
Fujimura, M., Suhara, T., Kinoshita, K., and Nishihara, H. see Suhara, T.
Fujita, S., Shimizu, J., Suzaki, T., Terakado, T., Kasahara, K., Itoh, T., and Suzuki, A. see Shimizu, J.
Fujita, S., Suzaki, T., Matsuoka, A., Miyazaki, S., Torikai, T., Nakata, T., and Shikada, M. High sensitivity 5 Gbit/s optical receiver module using Si IC and GaInAs APD p175
Fujita, S., Suzaki, T., Suzuki, Y., Yamada, H., Hida, H., Kitamura, M., and Shikada, M. see Suzaki, T.
Fujiwara, J., Takahashi, S., Koguchi, N., Chikyow, T., Kiyosawa, T., and Yoshihara, K. see Takahashi, S.
Fukai, I., Kashiwa, T., and Yoshida, N. see Kashiwa, T.
Fukano, H., Kawamura, Y., Asai, H., Takanashi, Y., and Fujimoto, M. Improving the characteristics of InAlAs/InGaAs heterojunction bipolar transistors by employing thin base and collector layers p1101
Fukuda, H., Arakawa, T., and Ohno, S. Highly reliable thin nitrided SiO_2 films formed by rapid thermal processing in an N_2O ambient p1505
Fukuda, H., Uchiyama, A., Hayashi, T., Iwabuchi, T., and Ohno, S. see Uchiyama, A.
Fukui, Y., Himura, A., Ishida, M., and Higashimura, M. see Himura, A.
Fullowan, T.R., Ren, F., Abernathy, C.R., Pearton, S.J., Lothian, J., and Jordan, A.S. see Ren, F.
Funaki, H., Sekine, K., Dooi, Y., Iso, A., and Takei, I. see Sekine, K.
Furukawa, A., Tanaka, S., Hayama, N., Baba, T., Mizuta, M., and Honjo, K. see Tanaka, S.
Furuno, T., and Ogose, S. Field test measurement for 128 Kbit/s QPSK signal transmission and delay time spread in 1·5 GHz-band land mobile radio p789

Furutsu, M., Soda, H., Sato, K., Okazaki, N., Yamazaki, S., Nishimoto, H., and Ishikawa, H. see Soda, H.
Furuya, K., Yamamoto, T., Miyamoto, Y., Ogawa, M., and Inamura, E. see Yamamoto, T.
Furuya, K., Yamaura, S., and Miyamoto, Y. see Yamaura, S.
Fusco, V.F., and Burns, H.O. Synthesis procedure for active integrated radiating elements p263

G

Gaĭdukov, M.M., Kolesov, S.G., Kowalewicz, L., Kozyrev, A.B., and Vendik, O.G. Microwave power limiter based on high-T_c superconductive film p1229
Gabla, P., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., and Leclerc, E. see Clesca, B.
Gabriagues, J.M., Flaarønning, N., Frorud, J.O., Sotom, M., Vendrôme, G., Da Loura, G., Jacquet, J., Leclerc, D., and Benoit, J. see Flaarønning, N.
Gabriagues, J.M., Hamaide, J.P., and Emplit, Ph. see Hamaide, J.P.
Galiński, B. Minimisation of MOSFET-C filters sensitivity by changing connections of capacitors p784
Gamelin, J., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., and Cho, A.Y. see Hasnain, G.
Gamelin, J., Tai, K., Hasnain, G., Wynn, J.D., Fischer, R.J., Wang, Y.H., Weir, B., and Cho, A.Y. see Tai, K.
Gamelin, J.K., Hsin, W., Du, G., Malloy, K.J., Wang, S., Whinnery, J.R., Yang, Y.J., Dziura, T.G., and Wang, S.C. see Hsin, W.
Gammand, P.G., and Bajon, D. Slow wave propagation using interconnexions for IC technologies p1443
Gammie, W., Walton, A.J., Fallon, M., Ward, D., and Holwill, R.J. see Walton, A.J.
Ganesh, R., Zhang, K., and Pahlavan, K. see Zhang, K.
Ganesh, R., and Pahlavan, K. Effects of traffic and local movements on multipath characteristics of an indoor radio channel p810
Ganière, J.D., Wüthrich, C., James, J.H., and Reinhart, F.K. see Wüthrich, C.
Ganley, M.J. Note on the generation of p_0 for RSA keysets p369
Gao, G.B., Chen, J., Ünlü, M.S., and Morkoç, H. see Chen, J.
Gao, G.B., Ünlü, M.S., Strite, S., Adomi, K., and Morkoç, H. see Ünlü, M.S.
Gao, Y., Bradley, M.A., Julien, F.H., Gilles, J.P., Rao, E.V.K., Razeghi, M., and Omnes, F. see Bradley, M.A.
Gao, Z.D., and Chu, S.F. see Chu, S.F.
Gaonach, C., Schmidt, P.E., Barbier, E., Collot, P., Champagne, M., and Pons, D. see Schmidt, P.E.
Garnham, R.A., Lord, A., Wilkinson, I.J., Ellis, A., Cleland, D., and Stallard, W.A. see Lord, A.
Garrett, C. Automatic production of the pseudo-circuit Boolean for the failure bounds analogue diagnosis scheme p1377
Garrett, C. Reduction of internal current measurements within the failure bounds analogue diagnosis scheme p583
Gaston, F.M.F., and Irwin, G.W. Systolic linear quadratic optimal controller p1000
Gatti, U., Liberali, V., Maloberti, F., and O'Leary, P. Automatic switching of substrate bias or well bias in CMOS-ICs p1381
Gauja, E., Betts, R.A., and Lui, F. see Betts, R.A.
Gaukel, G., Noé, R., Rodler, H., Ebberg, A., and Auracher, F. see Noé, R.
Gaukel, G., Noé, R., Rodler, H., Noll, B., and Ebberg, A. see Noé, R.
Gauneau, M., Kechouane, M., L'Haridon, H., Salvi, M., Favennec, P.N., Moutonnet, D., and Mercier, J.P. see Kechouane, M.
Gautheron, O., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Gelly, G., Mersali, B., Accard, A., Lafragette, J.-L., Doussiere, P., Lambert, M., and Fernier, B. see Mersali, B.
Genoe, J., Van Hoof, C., Van Hove, M., Jansen, Ph., Van Rossum, M., and Borghs, G. see Van Hoof, C.
Georges, J.B., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Zah, C.E., Caneau, C., Menocal, S.G., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.
Georges, T., Monerie, M., Francois, P.L., Allain, J.Y., and Neveux, D. see Monerie, M.
German, F.J., Gothard, G.K., and Riggs, L.S. Modelling of materials with electric and magnetic losses with the symmetrical condensed TLM method p1307
German, F.J., Gothard, G.K., and Riggs, L.S. RCS of three-dimensional scatterers using the symmetrical condensed TLM method p673
Gevorgian, S.S. Microwave conductivity of optically excited gap in a semiconductor microstrip p1921
Gevorgian, S.S., and Mironenko, I.G. Asymmetric coplanar-strip transmission lines for MMIC and integrated optic applications p1916
Gevorgyan, S., and Hovsepyan, A. Power distribution in symmetric integrated optic X junction p788
Gevorgyan, S.S. Single-step buried waveguides in glass by field-assisted copper ion-exchange p38
Ghaffari, H.T., Lin, M.S., and Paterson, A.S. see Lin, M.S.
Ghanbari, M., and Maslamani, S. see Maslamani, S.
Ghanbari, M., and Seferidis, V. see Seferidis, V.
Ghibaudo, G., Hafez, I.M., Emrani, A., and Balestra, F. see Hafez, I.M.
Ghioni, M., Ripamonti, G., and Vanoli, S. see Ripamonti, G.
Ghisoni, M., Gibson, M., Rivers, A., Boyd, I.W., Parry, G., and Roberts, J.S. Post growth tailoring of the optical properties of GaAs-AlGaAs multiple quantum wells p1058
Ghiti, A., and O'Reilly, E.P. Nonlinear gain effects in strained-layer lasers p1978
Gholkar, V.A. Mean square convergence analysis of LMS algorithm p1705
Gibson, A.A.P. Electric, magnetic and open-wall cylindrical gyromagnetic resonators p2073
Gibson, A.J. Day-to-day variation of HF signal strength and noise p761
Gibson, G., Shepherd, C., and Hayes, D. see Shepherd, C.
Gibson, J.K. Some comments on Damgard's hashing principle p1178
Gibson, M., Ghisoni, M., Rivers, A., Boyd, I.W., Parry, G., and Roberts, J.S. see Ghisoni, M.
Gilbert, S.S., Marsan, M.J., and Hess, G.C. see Marsan, M.J.
Gildenblat, G.S., and Huang, C.-L. see Huang, C.-L.
Giles, I.P., and Chen, S. see Chen, S.
Gilles, J.P., Bradley, M.A., Julien, F.H., Gao, Y., Rao, E.V.K., Razeghi, M., and Omnes, F. see Bradley, M.A.
Gillies, G.T., Allison, S.W., and Ramos, P.A. see Allison, S.W.
Gilman, J.M.A., and O'Neill, A.G. Delta doped tunnel diode: A new negative differential resistance device p601
Gimlett, J.L., Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Iqbal, M.Z., Standley, R.D., Young, J., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Ginudi, A., Loualiche, S., Le Corre, A., Henry, L., Vaudry, C., and Clerot, F. see Loualiche, S.
Girard, P., and Nouet, P. Evaluation of currents in the fA range p844
Girdlestone, H.P., and Cotter, D. see Cotter, D.
Giroult-Matlakowski, G., Degors, N., Marty, A., Chantre, A., and Nouailhat, A. Influence of the interfacial oxide layer on the gain of polycrystalline silicon emitter bipolar transistors processed in VLSI BiCMOS technology p1002
Glance, B., and Vicente de Vera, E.G. see Vicente de Vera, E.G.
Glastre, G., Blondeau, R., Rondi, D., Krakowski, M., and Vilain, G. see Blondeau, R.
Glenn, J.L., and Neudeck, G.W. High-speed fully self-aligned single-crystal contacted silicon bipolar transistor p1677
Glenn, M., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Silverman, S., Weng, S., Pao, Y.C., Zdasiuk, G., Bandy, S., and Tan, Z. see Majidi-Ahy, R.
Glenn, M., Yuen, C., Pao, Y.C., Day, M., Nishimoto, C., Bandy, S., and Zdasiuk, G. see Yuen, C.
Glew, R.W., Bhumbra, B.S., Greene, P.D., Henshall, G.D., Lowney, C.M., and Whiteaway, J.E.A. see Bhumbra, B.S.
Glew, R.W., Crookes, C.G., Lancefield, D., Waterhouse, K., Adams, A.R., and Greene, P.D. see Crookes, C.G.
Glinski, J.M., Keyworth, B.P., Cada, M., Spring-Thorpe, A.J., Rolland, C., and Hill, K.O. see Keyworth, B.P.
Gmitter, T.J., Shah, D.M., Chan, W.K., Florez, L.T., Schumacher, H., and Van der Gaag, B.P. see Shah, D.M.
Gmitter, T.J., Yi-Yan, A., Seto, M., Hwang, D.M., and Florez, L.T. see Yi-Yan, A.
Gnauck, A.H., Chandrasekhar, S., Dentai, A.G., Joyner, C.H., Johnson, B.C., and Qua, G.J. see Chandrasekhar, S.
Göbel, E.O., Nietzke, R., Sacher, J., and Elsässer, W. see Nietzke, R.
Gökçek, C., and Ünver, Z. Design method for optimal data transmission filters p373
Godts, P., Vanbremeersch, J., Constant, E., Zimmermann, J., Valin, I., and Leroy, A. see Vanbremeersch, J.
Goel, K.K., Prucnal, P.R., Shimazu, Y., Milbrodt, M., Desurvire, E., and Tell, B. Demonstration of packet switching through an integrated-optic tree switch using photo-conductive logic gates p287
Goeller, T., Anzill, W., Kaertner, F.X., Russer, P., and Buechler, J. see Anzill, W.
Goldburg, B., Sridharan, S., and Dawson, E. see Sridharan, S.
Goldsman, N., Urai, T., Frey, J., and Peng, Z.Z. see Urai, T.
Goldstein, L., Perales, A., Accard, A., Fernier, B., Leblond, F., Gourdain, C., and Brosson, P. see Perales, A.
Gomes, A.S.L., Acioli, L.H., and de Araújo, C.B. see Acioli, L.H.
Gong, J., Maclean, T.S.M., and Wu, Z. Radio propagation over trapeozoidal plateau with sloping front face p604
Gong, M., Xu, G., Han, K., and Zhai, G. Nd : MgO : $LiNbO_3$ self-frequency-doubled laser pumped by a flashlamp at room temperature p2062
Gooch, R., Schiebel, R.A., and Dodge, J. see Schiebel, R.A.
Goodman, R.M., and Sayano, M. Size limits on phased burst error correcting array codes p55
Goodwin, M.J., Moseley, A.J., Thompson, J., Kearley, M.Q., and Robbins, D.J. see Moseley, A.J.
Goossen, K.W., Kuo, T.Y., Chiu, T.H., Cunningham, J.E., Fonstad, C.G., and Ren, F. see Kuo, T.Y.
Goossen, K.W., Kuo, T.Y., Cunningham, J.E., Jan, W.Y., Fonstad, C.G., and Ren, F. see Kuo, T.Y.
Goossen, K.W., White, A.E., and Short, K.T. Proposed ultrahigh frequency microstrip utilising buried silicide groundplane p49 e555 e555
Goossen, K.W., Zucker, J.E., Bar-Joseph, I., Kuo, J.M., Kopf, R.M., Miller, D.A.B., and Chemla, D.S. Photocurrent saturation in short-period superlattice modulators p736
Goostray, J., Thomas, H., Morgan, D.V., Kohn, E., Christou, A., and Mottet, S. Deep level transient spectroscopy of n-AlGaAs/GaAs high electron mobility transistors p159
Gopalakrishnan, G.K., and Chang, K. Bandpass characteristics of split-modes in asymmetric ring resonators p774
Gopinath, A., Zou, J., Akinwande, T., and Shur, M.S. see Zou, J.
Gopinathan, V., Tsividis, Y.P., and Tóth, L. see Tsividis, Y.P.
Gordon, J., and Srikanthan, S. Novel algorithm for Clos-type networks p1770
Gordon, J., and Srikanthan, S. Single sided switching networks p248
Gorgui-Naguib, R.N., Forster, C.H.N., and Dlay, S.S. see Forster, C.H.N.
Gossard, A.W., Yu, R.Y., Case, M., Kamegawa, M., Sundaram, M., and Rodwell, M.J.W. see Yu, R.Y.
Gossett, C.R., Anderson, W.T., Christou, A., Thompson, P.E., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Gothard, G.K., German, F.J., and Riggs, L.S. see German, F.J.
Goto, N., and Yip, G.L. Y-branch wavelength multi/demultiplexer for $\lambda = 1{\cdot}30$ and $1{\cdot}55\,\mu m$ p102
Gotoh, H., Suzuki, Y., Yajima, H., Shimoyama, K., Inoue, Y., and Katoh, M. see Suzuki, Y.
Gottwald, E., Schöpflin, A., Kugelmeier, S., Felicio, D., and Fischer, G. see Schöpflin, A.
Gourdain, C., Perales, A., Goldstein, L., Accard, A., Fernier, B., Leblond, F., and Brosson, P. see Perales, A.
Goutelle, A., Cavaillès, J.A., Renaud, M., Jarry, P., Erman, M., and Vinchant, J.F. see Cavaillès, J.A.
Gouveia-Neto, A.S., Ainslie, B.J., Blow, K.J., Wigley, P.G.J., Sombra, A.S.B., and Taylor, J.R. see Ainslie, B.J.
Gozdz, A.S., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Zah, C.E., Caneau, C., Menocal, S.G., Lin, P.S.D., and Favire, F.J. see Kobrinski, H.
Grabbe, P., Lo, Y.H., Bagheri, M., Lin, P.S.D., Bhat, R., Stoffel, N.G., Lee, T.P., and Kong, D.T. see Lo, Y.H.
Gragnani, G.L., Caorsi, S., and Pastorino, M. see Caorsi, S.
Grand, G., Jadot, J.P., Denis, H., Valette, S., Fournier, A., and Grouillet, A.M. Low-loss PECVD silica channel waveguides for optical communications p2135
Grandpierre, G., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Leclerc, E., and Gabla, P. see Clesca, B.
Granestrand, P., Lagerström, B., Svensson, P., Thylén, L., Stoltz, B., Bergvall, K., Falk, J.-E., and Olofsson, H. Integrated optics 4×4 switch matrix with digital optical switches p4
Grasso, G., Righetti, A., Fontana, F., Delrosso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Young, J., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Grayson, M., and Darnell, M. Synchronisation preamble design: new results p1775
Green, D.H. Derivation of the feedback taps of an LFSR from a sequence fragment p1352
Greene, P.D., Bhumbra, B.S., Glew, R.W., Henshall, G.D., Lowney, C.M., and Whiteaway, J.E.A. see Bhumbra, B.S.
Greene, P.D., Crookes, C.G., Lancefield, D., Waterhouse, K., Adams, A.R., and Glew, R.W. see Crookes, C.G.
Greer, E.J., Wigley, P.G.J., and Taylor, J.R. Tunable CW fibre Raman ring laser centred at $1{\cdot}41\,\mu m$ p579
Grey, R., Woodhead, J., Claxton, P.A., Sale, T.E., David, J.P.R., Liu, L., Pate, M.A., Hill, G., and Robson, P.N. see Woodhead, J.
Grezes-Besset, C., Lallier, E., Pocholle, J.P., Papuchon, M., De Micheli, M., Li, M.J., He, Q., Ostrowsky, D.B., and Pelletier, E. see Lallier, E.
Griem, H.T., Fuji, H.S., Williams, T.J., Harrang, J.P., Daniels, R.R., Ray, S., LaGasse, M.J., and West, D.L. Monolithically integrated $In_{0.53}Ga_{0.47}As/In_{0.52}Al_{0.48}As$ (on InP) MSM/HFET photoreceiver grown by MBE p1198

Griffioen, W. Water and hydrogen equilibrium for different cable constructions p1122
Griffith, I., Williams, P.J., Charles, P.M., Considine, L., and Carter, A.C. see Williams, P.J.
Grosso, G., Höök, A., Bolle, A., and Martinelli, M. see Höök, A.
Grouillet, A.M., Grand, G., Jadot, J.P., Denis, H., Valette, S., and Fournier, A. see Grand, G.
Grubb, S.G., Barnes, W.L., Taylor, E.R., and Payne, D.N. Diode-pumped 1·36 μm Nd-doped fibre laser p121
Grudinin, A.B., Khrushchëv, I.Yu., Dianov, E.M., Korobkin Jun, D.V., Semënov, V.A., and Prokhorov, A.M. see Khrushchëv, I.Yu.
Gruezke, L.A., Twu, Y., Wang, S.J., Kuo, C.Y., Wynn, J.D., Brown, R.L., Strege, K.E., Lin, M.S., and Dutta, N.K. see Twu, Y.
Gu, K., and Wang, Y. Analysis of dispersion characteristics of cylindrical microstrip line with method of lines p748
Guibert, M., Ronarc'h, D., Allain, J.Y., Monerie, M., and Poignant, H. see Ronarc'h, D.
Gulliver, T.A. New class of codes suitable for computer error control d1215
Guo, G., and Shen, Q. Fuzzy algorithm for error-correcting estimation of radar signals p1321
Guoxiang, C., Yie, H., and Yuanming, W. see Yie, H.
Gupta, A., and Unnikrishnan, R. see Unnikrishnan, R.
Guu, J.-A., and Wei, C.-H. Simple parameter estimation technique in manoeuvring target tracking system p508
Gwilliam, R., O'Neill, M., Marsh, J.H., De La Rue, R.M., Roberts, J.S., and Button, C. see O'Neill, M.
Gwynn, P.J., Leech, P.W., Pain, G.N., Petkovic, N., and Thompson, J. see Leech, P.W.
Gwynn, P.J., Leech, P.W., Petkovic, N., Pain, G.N., and Thompson, J. see Leech, P.W.

H

Haberl, F., Fermann, M.E., Hofer, M., and Craig-Ryan, S.P. see Fermann, M.E.
Hadjifotiou, A., Hardcastle, I., Large, Y., and Davis, F. see Hardcastle, I.
Hadjifotiou, A., and Hardcastle, I. see Hardcastle, I.
Hafdallah, H., Ouslimani, A., Vernet, G., and Adde, R. see Ouslimani, A.
Hafez, I.M., Emrani, A., Ghibaudo, G., and Balestra, F. Modelling of electron mobility in silicon MOS inversion and accumulation layers at liquid helium temperature p1633
Hagen, S.H., Boermans, M.J.B., Valster, A., Finke, M.N., and van der Heyden, J.M.M. see Boermans, M.J.B.
Hager, H., Mantz, J., Chan, E., and Hong, C.S. see Mantz, J.
Hagimoto, K., Miyamoto, Y., and Kagawa, T. see Miyamoto, Y.
Hagimoto, K., Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., Kato, N., and Hirayama, M. see Ohhata, M.
Haigh, D.G., Toumazou, C., Harrold, S.J., Steptoe, K., Sewell, J.I., and Bayruns, R. see Toumazou, C.
Haigh, D.G., Toumazou, C., and Fopma, J.M. see Toumazou, C.
Haigh, D.G., and Toumazou, C. see Toumazou, C.
Haigh, D.G., and Toumazou, C. High frequency gallium arsenide linearised transconductor for communications p497
Hailin, Z., and Yumin, W. Adaptive dummy spectrum insertion method used in asynchronous speech scrambling p1949
Hakamata, Y., Isido, K., and Takemoto, K. Transmission experiment at 5 Gbit/s using 1300 nm Fabry–Perot type LD and PIN PD p739
Hakamata, Y., Yokota, N., and Takemoto, K. see Yokota, N.
Halbout, J.-M., Pastol, Y., and Arjavalingam, G. see Pastol, Y.
Hale, W., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Hale, W., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Hall, E.L., Chao, P.C., Ho, P., Duh, K.H.G., Smith, P.M., Ballingall, J.M., Jabra, A.A., and Lewis, N. see Chao, P.C.
Hall, R.C., and Mosig, J.R. Rigorous feed model for coaxially fed microstrip antenna p64 e345
Haller, B., and Kaufmann, H. Digital DPSK demodulator employing bandpass subsampling p1536
Halls, M.F., Ballance, J.W., and Rogers, P.H. see Ballance, J.W.
Hamaguchi, H., Wada, O., Kumai, T., Makiuchi, M., Kuramata, A., and Mikawa, T. see Wada, O.
Hamaide, J.P., Emplit, Ph., and Gabriagues, J.M. Limitations in long haul IM/DD optical fibre systems caused by chromatic dispersion and nonlinear Kerr effect p1451
Hamao, N., Tashiro, Y., Ogura, I., Sugimoto, M., and Kasahara, K. see Tashiro, Y.
Hamm, R.A., Nottenburg, R.N., Banu, M., Jalali, B., Humphrey, D.A., Montgomery, R.K., and Panish, M.B. see Nottenburg, R.N.
Hammer, J.M., Evans, G.A., Carlson, N.W., Bour, D.P., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Hammes, P.C.A., Krijnen, G.J.M., Driessen, A., and Smit, M.K. High efficiency small-size planar hyperbolical lenses p1064
Han, I.K., Lee, J.I., Lee, M.B., Lee, Y.J., Kang, K.N., and Park, K.O. see Lee, J.I.
Han, K., Gong, M., Xu, G., and Zhai, G. see Gong, M.
Han, S., Kim, C.-M., Ji, J.-K., and Kim, Y. see Kim, C.-M.
Hanafi, M., Fabre, A., and Martia, F. see Fabre, A.
Hanafusa, H., Horiguchi, M., Shimizu, M., Yamada, M., and Yoshino, K. see Horiguchi, M.
Hanbing, J. Velocity field computation using neural networks p1787
Hand, D.P., and Russell, P.St. J. see Russell, P.St. J.
Hanna, D.C., Carter, J.N., Smart, R.G., and Tropper, A.C. see Carter, J.N.
Hanna, D.C., Field, S.J., Shepherd, D.P., Tropper, A.C., Chandler, P.J., Townsend, P.D., and Zhang, L. see Field, S.J.
Hanna, D.C., Smart, R.G., Carter, J.N., and Tropper, A.C. see Smart, R.G.
Haond, M., and Le Néel, O. see Le Néel, O.
Hara, K., Ueno, Y., Endo, K., Fujii, H., Kobayashi, K., and Yuasa, T. see Ueno, Y.
Harbison, J.P., Chang-Hasnain, C.J., Maeda, M.W., Stoffel, N.G., Florez, L.T., and Jewell, J. see Chang-Hasnain, C.J.
Harbison, J.P., Lee, Y.H., Jewell, J.L., Tell, B., Brown-Goebeler, K.F., Scherer, A., and Florez, L.T. see Lee, Y.H.
Harbison, J.P., Yoo, H.-J., Hayes, J.R., Paek, E.G., Florez, L.T., and Kwon, Y.-S. see Yoo, H.-J.
Hardcastle, I., Large, Y., Davis, F., and Hadjifotiou, A. High performance 140 Mbit/s FSK coherent system p1523
Hardcastle, I., and Hadjifotiou, A. Low noise balanced receiver for coherent transmission systems p750
Hardy, A., Iztkovich, M., Tur, M., and Croituro, N. see Iztkovich, M.
Hardy, A., Parke, R., Waarts, R., Welch, D.F., and Streifer, W. see Parke, R.
Hardy, A., Streifer, W., Welch, D.F., Scifres, D.R., and Cross, P.S. see Streifer, W.
Hardy, A., Waarts, R.G., Welch, D.F., Parke, R., and Streifer, W. see Waarts, R.G.
Hardy, A., Welch, D.F., Parke, R., Waarts, R., Streifer, W., and Scifres, D.R. see Welch, D.F.
Hardy, R.H.S., Stapleton, S.P., Deen, M.J., and Berolo, E. see Stapleton, S.P.
Hardy, R.H.S., Stapleton, S.P., and Deen, M.J. see Stapleton, S.P.
Hariman, T., Juy, M., Maurel, R., Rooryck, M., and Nugroho, I.A. see Juy, M.
Haritantis, I., and Psychalinos, C. see Psychalinos, C.
Harlow, M.J., Wake, D., Judge, S.N., Spooner, T.P., Duncan, W.J., Henning, I.D., and O'Mahony, M.J. see Wake, D.
Harn, L., and Kiesler, T. see Kiesler, T.
Harn, L., and Lin, H.Y. Noninteractive oblivious transfer p635
Harper, P.G., Morgan, R., Barton, J.S., and Jones, J.D.C. see Morgan, R.
Harrang, J.P., Griem, H.T., Fuji, H.S., Williams, T.J., Daniels, R.R., Ray, S., LaGasse, M.J., and West, D.L. see Griem, H.T.
Harris, J., Liu, W.U., and Costa, D. see Liu, W.U.
Harris, Jun, J.S., Liu, W.U., Hill, D., and Costa, D. see Liu, W.U.
Harrold, S.J., Toumazou, C., Haigh, D.G., Steptoe, K., Sewell, J.I., and Bayruns, R. see Toumazou, C.
Harth, W., Pöbl, M., Dalle, C., and Freyer, J. see Pöbl, M.
Hartl, E., Poisel, H., Trommer, G.F., Bühler, W., and Müller, R. see Poisel, H.
Hartley, M.G., and Qiu, B. see Qiu, B.
Hartman, D.H., Takahashi, Y., and Inoue, H. InP optical switch array module high frequency performance: Measurements and analysis p436
Hartman, R.L., Wang, S.J., Twu, Y., and Dutta, N.K. see Wang, S.J.
Hartnagel, H.-L., and Fricke, K. see Fricke, K.
Hartnagel, H.L., Schütz, R., Matsushita, K., Longère, J.Y., and Krawczyk, S.K. see Schütz, R.
Hashimoto, J., Katsuyama, T., Yoshida, I., Shinkai, J., and Hayashi, H. see Katsuyama, T.
Hashimoto, K., Ogawa, K., Ikeda, H., Ishizaki, T., and Ota, Y. see Ogawa, K.
Hashimoto, K., Ogawa, K., Uwano, T., and Ota, Y. see Ogawa, K.
Hashimoto, K.-Y., Yamaguchi, M., and Kaneda, H. see Yamaguchi, M.
Hasko, D.G., Kelly, M.J., Brown, R.J., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Kelly, M.J.
Hasko, D.G., Matthews, P., Kelly, M.J., Law, V.J., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Hasnain, G., Tai, K., Wynn, J.D., Fischer, R.J., Wang, Y.H., Weir, B., Gamelin, J., and Cho, A.Y. see Tai, K.
Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. Continuous wave top surface emitting quantum well lasers using hybrid metal/semiconductor reflectors p1590
Hassan, E.E., El-Hennawey, M.S., and Zerguine, A. see El-Hennawey, M.S.
Hassan, M.A. Simple-iterative method for pattern synthesis using nonuniformly spaced arrays p891
Hatakoshi, G., Itaya, K., Watanabe, Y., Ishikawa, M., and Uematsu, Y. see Itaya, K.
Hatzopoulos, Z., Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Eridon, J.M., Efthimiopoulos, T., Kudumas, M., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Hauenschild, J., Rein, H.-M., McFarland, W., Doernberg, J., and Pettengill, D. 20 Gbit/s time-division multiplexer IC in silicon bipolar technology e2137
Hauenschild, J., Rein, H.-M., Schmidt, L., and Wörner, K. Versatile silicon bipolar XOR gate for signal processing up to 8 Gbit/s p114
Hauff, T.M., Oehler, A.M., Moratzky, M., and Heinlein, W.E. see Oehler, A.M.
Haug, A. Auger recombination in quantum well InGaAs p1415
Havlicek, J.P., Sarkady, K.A., Katz, G.R., and McKeeman, J.C. Fast, efficient median filters with even length windows p1736
Hawbaker, D.A., and Rappaport, T.S. Indoor wideband radiowave propagation measurements at 1·3 GHz and 4·0 GHz p1800
Hawkins, R.T. Generation of <3 ps optical pulses by fibre compression of gain-switched InGaAsP DFB laser diode pulses p292
Haworth, D.T., Josse, F., Kelkar, U.R., and Shana, Z.A. see Josse, F.
Hay, S.G., and Bird, T.S. see Bird, T.S.
Hayama, N., Tanaka, S., Furukawa, A., Baba, T., Mizuta, M., and Honjo, K. see Tanaka, S.
Hayashi, H., Katsuyama, T., Yoshida, I., Shinkai, J., and Hashimoto, J. see Katsuyama, T.
Hayashi, H., Nishiyama, N., Yano, H., and Nakajima, S. see Nishiyama, N.
Hayashi, H., Yano, H., Aga, K., Kamei, H., and Sasaki, G. see Yano, H.
Hayashi, T., Uchiyama, A., Fukuda, H., Iwabuchi, T., and Ohno, S. see Uchiyama, A.
Hayashi, Y., Imai, T., Ohkawa, N., Sugie, T., Ichihashi, Y., and Ito, T. see Imai, T.
Hayat, L., and Sandler, M.B. Image compression algorithm for fast parallel thinning of binary images p1056
Hayata, K., and Koshiba, M. Cerenkov third-harmonic generation in optical glass fibre p1566
Haycocks, P.R., Wicks, M.C., and Hori, T. see Wicks, M.C.
Hayes, D., Shepherd, C., and Gibson, G. see Shepherd, C.
Hayes, J.R., Yoo, H.-J., Paek, E.G., Harbison, J.P., Florez, L.T., and Kwon, Y.-S. see Yoo, H.-J.
Hayes, J.R., Yoo, H.-J., and Kwon, Y.-S. see Yoo, H.-J.
Hayes-Gill, B.R., Ait-Boudaoud, D., and Ibrahim, M.K. see Ait-Boudaoud, D.
He, Q., Lallier, E., Pocholle, J.P., Papuchon, M., De Micheli, M., Li, M.J., Ostrowsky, D.B., Grezes-Besset, C., and Pelletier, E. see Lallier, E.
Healey, P., Barnes, N., Rejman-Greene, M.A.Z., Scott, E.G., and Webb, R.P. see Barnes, N.
Healey, P., Barnes, N.M., McKee, P., O'Neill, A.W., Rejman-Greene, M.A.Z., Scott, E.G., Webb, R.P., and Wood, D. see Barnes, N.M.
Heatley, D., Boggis, J., Lord, A., Violas, M., and Stallard, W.A. see Boggis, J.
Heatley, D.J.T., Violas, M.A.R., Duarte, A.M.O., and Beddow, D.M. see Violas, M.A.R.
Hebert, J.-P., Chusseau, L., Xie, J.M., Duvillaret, L., Lourtioz, J.M., and Accard, A. see Chusseau, L.
Hedges, S.J., Adams, M.J., Nicholson, B.F., and Chew, N.G. Power dependent effects observed for a superconducting stripline resonator p977
Heinecke, H., Höger, R., Baur, B., and Miklis, A. Growth of high quality InP with metal organic molecular beam epitaxy p213
Heinlein, W.E., Oehler, A.M., Hauff, T.M., and Moratzky, M. see Oehler, A.M.
Heinrich, M., and Claassen, M. Chirp and linewidth enhancement factor α of current modulated Ga(Al)As-GRINSCH-SQW-MCRW flared waveguide lasers p1598
Hempfling, E., Aina, L., Serio, M., Mattingly, M., and Chien, H. see Aina, L.
Hempfling, E., Aina, O., Serio, M., and Mattingly, M. see Aina, O.
Henaux, J.C., and Crozat, P. Dimensional correction of high dielectric and magnetic constants determined by S parameters measurements p1151
Henini, M., Sellai, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., and Hughes, O.H. see Sellai, A.
Henini, M., Zarea, A., Sellai, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., and Hughes, O.H. see Zarea, A.
Henning, I.D., Sundaresan, H., Kwan, S., Lord, A., Duncan, W.J., Stallard, W.A., and Broughton, C. see Sundaresan, H.
Henning, I.D., Wake, D., Judge, S.N., Spooner, T.P., Harlow, M.J., Duncan, W.J., and O'Mahony, M.J. see Wake, D.
Henoc, P., Martins, R.B., and Akamatsu, B. see Martins, R.B.
Henry, C.H., Kuo, C.Y., Ackerman, D.A., Shani, Y.,

Dahbura, M.I., Kistler, R., and Wagner, E.J. see Kuo, C.Y.
Henry, L., Loualiche, S., Le Corre, A., Ginudi, A., Vaudry, C., and Clerot, F. see Loualiche, S.
Henry, R.M., and Zhang, L. Short delay measurement by polarity cross correlation p202
Henry, W.M., and Love, J.D. see Love, J.D.
Henshall, G.D., Bhumbra, B.S., Glew, R.W., Greene, P.D., Lowney, C.M., and Whiteaway, J.E.A. see Bhumbra, B.S.
Herd, J.S. Modelling of wideband proximity coupled microstrip array elements p1282
Herdeg, W.F., and Wendel, H. Bistatic high resolution imaging on a monostatic range p1476
Herzog, W., Schultes, G., Bonek, E., and Weger, P. see Schultes, G.
Hess, G.C., Marsan, M.J., and Gilbert, S.S. see Marsan, M.J.
Hewett, N.P., Learmouth, M.D., Reid, I., and Robertson, M.J. see Learmouth, M.D.
Hewett, N.P., MacBean, M.D.A., Learmouth, M.D., and Reid, I. see MacBean, M.D.A.
Hibino, Y., LaRochelle, S., Mizrahi, V., and Stegeman, G.I. see LaRochelle, S.
Hibino, Y., Mizrahi, V., and Stegeman, G.I. Temperature dependence of second harmonic generation in germania-doped silica optical fibres p1578
Hida, H., Suzaki, T., Suzuki, Y., Yamada, H., Fujita, S., Kitamura, M., and Shikada, M. see Suzaki, T.
Hida, Y., Kobayashi, S., Kitoh, T., Suzuki, S., and Yamaguchi, M. see Kobayashi, S.
Hidaka, H., Akita, K., Taneya, M., and Sugimoto, Y. Damaged depth in GaAs processed by Ar plasma etching p1112
Hier, H., Boos, J.B., Binari, S.C., and Kruppa, W. see Boos, J.B.
Hieronymi, F., Kuhl, D., Böttcher, E.H., Wolf, T., Krost, A., and Bimberg, D. see Kuhl, D.
Higashimura, M., Himura, A., Fukui, Y., and Ishida, M. see Himura, A.
Higuchi, T., Aoki, T., and Kameyama, M. see Aoki, T.
Hill, A.J., Ladbrooke, P.H., and Bridge, J.P. see Ladbrooke, P.H.
Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Wyatt, R., Massicott, J.F., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. 7203-user WDM broadcast network employing one erbium-doped fibre power amplifier p605
Hill, A.M., Wright, J.V., and Srikanthan, S. Integrated structure for generalised connection networks employing optical switches p1474 e1831
Hill, A.M., Wyatt, R., Massicott, J.F., Blyth, K.J., Forrester, D.S., Lobbett, R.A., Smith, P.J., and Payne, D.B. 39·5 million-way WDM broadcast network employing two stages of erbium-doped fibre amplifiers p1882
Hill, D., Liu, W.U., Costa, D., and Harris, Jun, J.S. see Liu, W.U.
Hill, G., Kilkelly, P.D.D., and Chidgey, P.J. see Kilkelly, P.D.D.
Hill, G., Woodhead, J., Claxton, P.A., Grey, R., Sale, T.E., David, J.P.R., Liu, L., Pate, M.A., and Robson, P.N. see Woodhead, J.
Hill, G.R., and Chidgey, P.J. see Chidgey, P.J.
Hill, J.C., and Stuckman, B.E. see Stuckman, B.E.
Hill, K.O., Keyworth, B.P., Cada, M., Glinski, J.M., SpringThorpe, A.J., and Rolland, C. see Keyworth, B.P.
Hill, K.O., Malo, B., Vineberg, K.A., Bilodeau, F., Johnson, D.C., and Skinner, I. Efficient mode conversion in telecommunication fibre using externally written gratings p1270
Hills, P.C. Intrinsic safety of optical fibres in combustible environments p1982
Himdi, M., Thouroude, D., and Daniel, J.P. see Thouroude, D.
Himeno, A., Nishikido, J., and Okuno, M. see Nishikido, J.
Himeno, T., Yonezu, H., Kanamori, K., Pak, K., and Takano, Y. see Yonezu, H.
Himura, A., Fukui, Y., Ishida, M., and Higashimura, M. Series impedance simulators using one CCII p269
Hirabayashi, M. Nondestructive measurement of phase velocity of surface acoustic waves using matched filters p411
Hirano, Y., and Inada, T. Growth of single crystal β-SiC films on a Si substrate by a direct carbonisation method p1638
Hirayama, M., Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., Kato, N., and Hagimoto, K. see Ohhata, M.
Hirayama, M., Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., and Kato, N. see Ohhata, M.
Hirooka, T., Yamauchi, J., Kikuchi, S., and Nakano, H. see Yamauchi, J.
Hirose, K., Horiuchi, H., and Nakano, H. Dual-loop slot array antenna radiating circularly polarised wave p179
Hirose, T., Ota, Y., Ryoji, A., and Inada, M. see Ota, Y.
Hirtz, J.P., Zirngibl, M., Bischoff, J.C., Ilegems, M., Bartenlian, B., Beaud, P., and Hodel, W. see Zirngibl, M.
Ho, F.D. Simple model for space-charge region capacitance of an exponential-constant p–n junction p2063
Ho, H.-L., and Smith, K.C. SC and pass transistor combined circuits p769
Ho, K.L., and Chan, S.C. see Chan, S.C.
Ho, P., Chao, P.C., Duh, K.H.G., Smith, P.M., Ballingall, J.M., Jabra, A.A., Lewis, N., and Hall, E.L. see Chao, P.C.
Höger, R., Heinecke, H., Baur, B., and Miklis, A. see Heinecke, H.
Höök, A., Bolle, A., Grosso, G., and Martinelli, M. Influence of stimulated Brillouin scattering on phase modulated signals in optical fibres p470
Hobson, L., Leisten, J.M., and Lefedjiev, A.K. see Leisten, J.M.
Hobson, W.S., Levi, A.F.J., O'Gorman, J., Pearton, S.J., Abernathy, C.R., and Swaminathan, V. GRINSCH GaAs/AlGaAs laser structures grown by OMVPE using a novel aluminium source p1762
Hodel, W., Zirngibl, M., Bischoff, J.C., Ilegems, M., Hirtz, J.P., Bartenlian, B., and Beaud, P. see Zirngibl, M.
Hodge, P., Young, M.C.J., Lu, W.X., Tredgold, R.H., and Abbasi, F. see Young, M.C.J.
Hodgetts, T.E., Jenkins, S., Symm, G.T., Warham, A.G.P., Clarke, R.N., and Preece, A.W. see Jenkins, S.
Hodgkinson, T.G., Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Wyatt, R., Massicott, J.F., Lobbett, R.A., and Smith, P. see Hill, A.M.
Hodgkinson, T.G., and Coppin, P. see Coppin, P.
Hodgkinson, T.G., and Coppin, P. Optical domain frequency translation of a modulated optical carrier p1262
Hodgkinson, T.G., and Coppin, P. Pulsed operation of an optical feedback frequency synthetiser p1155
Hodsdon, D.M., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.
Hoefer, W.J.R., and Kim, I.S. see Kim, I.S.
Hoepfner, A., Tews, H., Zwicknagl, P., Neumann, R., Jaeger, G., Schleicher, L., and Packeiser, G. see Tews, H.
Hofer, M., Fermann, M.E., Haberl, F., and Craig-Ryan, S.P. see Fermann, M.E.
Hoffmann, B., Jensen, N.G., Bødtker, E., Nielsen, S.K., and Broberg, B. Comparison of NRZ and AMI coding schemes using three-electrode and conventional DFB laser transmitters in a 636 Mbit/s SF-FSK coherent system p1903
Hogari, K., Noguchi, K., Sakano, T., and Matsumoto, T. see Noguchi, K.
Holcombe, B., Iñigo, R.M., and Bonde, A. see Iñigo, R.M.
Hollier, M., Al-Chalabi, S.A., Mellis, J., Cameron, K.H., Wyatt, R., Regnault, J.E., Devlin, W.J., and Brain, M.C. see Al-Chalabi, S.A.
Holmberg, B., Öberg, M., Nilsson, S., Klinga, T., and Broberg, B. see Öberg, M.
Holmes, M.J., Payne, F.P., and Spirit, D.M. Matching fibres for low loss coupling into fibre amplifiers p2102
Holmes, M.J., Spirit, D.M., and Payne, F.P. Optimisation of refractive index profile for high gain fibre amplifiers p1873
Holmes, S., and Petrovic, R. see Petrovic, R.
Holmstrom, R., Meland, E., Schlafer, J., Lauer, R.B., and Powazinik, W. see Meland, E.
Holmstrom, R., Rideout, W., LaCourse, J., Meland, E., and Powazinik, W. see Rideout, W.
Holt, M.J.J., and Semnani, S. Convergence of back-propagation in neural networks using a log-likelihood cost function p1964
Holwill, R.J., Walton, A.J., Gammie, W., Fallon, M., and Ward, D. see Walton, A.J.
Hombach, V., Dombek, K.-P., Scheffer, H., and Thielen, H. see Dombek, K.-P.
Honary, B., Darnell, M., and Shaw, M. Combined Huffman and convolutional codes: Concatenated form without feedback p367
Honary, B., and Markarian, G. New optimisation technique of error propagation over M-PSK modem p408
Hong, C.S., Mantz, J., Hager, H., and Chan, E. see Mantz, J.
Hong, J.P., Cho, Y.K., and Son, H. see Cho, Y.K.
Hong, M., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Hong, S.-K., Park, I.-C., and Kyung, C.-M. see Park, I.-C.
Hong, S.-S., Cho, K.-Y., Oh, D.-S., and Youn, M.-J. see Cho, K.-Y.
Hong, W.-P., Lin, P.S.D., Kim, O.-H., Bhat, R., Van Der Gaag, B., and Schumacher, H. see Lin, P.S.D.
Hong, W.-P., Rao, M.V., and Chang, G.-K. see Rao, M.V.
Honjo, K., Tanaka, S., Hayama, N., Furukawa, A., Baba, T., and Mizuta, M. see Tanaka, S.
Hooijmans, P.W., Tomesen, M.T., and Wright, K.G. see Tomesen, M.T.
Hooijmans, P.W., and Tomesen, M.T. Analytical expressions for the sensitivity penalty caused by large IF bandwidth in coherent optical ASK receivers with non-coherent IF detection p1398
Hori, T., Wicks, M.C., and Haycocks, P.R. see Wicks, M.C.
Horiguchi, M., Shimizu, M., Yamada, M., Okayasu, M., Takeshita, T., Nishi, I., Uehara, S., Noda, J., and Sugita, E. see Shimizu, M.
Horiguchi, M., Shimizu, M., Yamada, M., Takeshita, T., and Okayasu, M. see Shimizu, M.
Horiguchi, M., Shimizu, M., Yamada, M., Yoshino, K., and Hanafusa, H. Highly efficient optical fibre amplifier pumped by a 0·8 μm band laser diode p1758
Horiguchi, M., Yamada, M., Shimizu, M., and Okayasu, M. see Yamada, M.
Horiuchi, H., Hirose, K., and Nakano, H. see Hirose, K.
Horsthuis, W.H.G., Diemeer, M.B.J., Suyten, F.M.M., Trommel, E.S., McDonach, A., Copeland, J.M., and Jenneskens, L.W. see Diemeer, M.B.J.
Hou, D., and Hsu, C.S. see Hsu, C.S.
Houghton, A.W., and Brennan, P.V. see Brennan, P.V.
Houselander, P., and Taylor, J.T. Calculating the upper and lower bounds on capacity of two modified Hebbian trained Hopfield networks p1266
Houselander, P., and Taylor, J.T. Improving the Hamming binary associative memory p705
Houselander, P.K., and Taylor, J.T. Comparing performance of Hebbian- and delta-trained Hopfield networks p85
Hove, J.V., Lee, Y.H., Tell, B., Brown-Goebeler, K., and Jewell, J.L. see Lee, Y.H.
Hovsepyan, A., and Gevorgyan, S. see Gevorgyan, S.
Howard, S.J., and Pahlavan, K. see Pahlavan, K.
Howard, S.J., and Pahlavan, K. Autoregressive modelling of an indoor radio channel p816
Howard, S.J., and Pahlavan, K. Doppler spread measurements of indoor radio channel p107
Howes, M.J., Xue, H., and Snowden, C.M. see Xue, H.
Hsieh, C.-H., Lu, P.-C., Shyn, J.-S., and Lu, E.-H. Motion estimation algorithm using interblock correlation p276
Hsieh, J., and Ucci, D.R. Superposition technique for the generalised stochastic Petri net modelling of degradable systems p942
Hsin, W., Du, G., Gamelin, J.K., Malloy, K.J., Wang, S., Whinnery, J.R., Yang, Y.J., Dziura, T.G., and Wang, S.C. Low threshold distributed Bragg reflector surface emitting laser diode with semiconductor air-bridge-supported top mirror p307 e828
Hsu, C.-Y., and Huang, Y.-S. see Huang, Y.-S.
Hsu, C.S., and Hou, D. Linear approximation of fractional transfer functions of distributed parameter systems p1211
Hu, J.-K., and Lee, T.-H. see Lee, T.-H.
Huang, C.-L., and Gildenblat, G.S. Engineering model of MOS transistors for the 60–300 K temperature range p365
Huang, C.I., and Liou, L.L. see Liou, L.L.
Huang, K.M., and Lin, W. Impedance of TEM cells with equipment under test p560
Huang, S.-H., and Chen, S.-H. Fast encoding algorithm for VQ-based image coding p1618
Huang, S.J., Koh, S.N., and Tang, H.K. Algorithm for generating new orthonormal transforms p1489
Huang, V.-Z. Asymmetric gain induced by longitudinal spatial carrier burning in semiconductor lasers p783
Huang, Y., Xue, L., and Lin, W. Exact singular integral equation approach for planar transmission lines p360
Huang, Y.-S., and Hsu, C.-Y. Application of Hartley transform to tracking moving objects in noisy environments p1878
Huet, F., Saulnier, J., Riviere, L., Carre, M., and Caumont, G. see Saulnier, J.
Hughes, B., Macbeth, I.C., and Pattullo, D.M. New switched-current integrator p694
Hughes, D.A., Anido, G., and Bradlow, H.S. Performance of the leaky bucket policing mechanism for small bucket depths p1305
Hughes, J.B., Toumazou, C., and Pattullo, D.M. see Toumazou, C.
Hughes, O.H., Sellai, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., and Henini, M. see Sellai, A.
Hughes, O.H., Zarea, A., Sellai, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., and Henini, M. see Zarea, A.
Hui, R., Mecozzi, A., D'Ottavi, A., and Spano, P. Novel measurement technique of α factor in DFB semiconductor lasers by injection locking p997
Hui, S.K., Lim, B.L., and Lim, Y.L. see Lim, B.L.
Hume, A.L., Auchterlonie, L.J., and Fletcher, P.N. see Auchterlonie, L.J.
Humphrey, D.A., Nottenburg, R.N., Banu, M., Jalali, B., Montgomery, R.K., Hamm, R.A., and Panish, M.B. see Nottenburg, R.N.
Humphreys, T.P., Nemanich, R.J., Das, K., Parikh, N.R., and Posthill, J.B. Photoluminescence spectroscopy measurements of elastic strain in heteroepitaxial GaAs films p835
Hung, C.Y., and Koç, C.K. see Koç, C.K.
Hung, C.Y., and Koç, Ç.K. see Koç, Ç.K.
Hunt, M.H., Millar, C.A., Brierley, M.C., and Carter, S.F. see Millar, C.A.
Hunter, C.A., Cox, J.D., Boggis, J.M., Bryant, E.G., and Stallard, W.A. see Cox, J.D.
Hur, J., and Lee, C.W. Effects on polarisation of inclined conducting strip located in front of radiating slot p713
Hwang, D.M., Yi-Yan, A., Seto, M., Gmitter, T.J.,

and Florez, L.T. see Yi-Yan, A.
Hwang, J.K., and Chen, Y.C. Real-time computation of the maximum likelihood criterion for some superimposed signals problems p1969
Hwang, T., and Tsai, Y.-W. see Tsai, Y.-W.
Hyben, P., Ceskovic, R., Kabos, P., Cermak, J., and Abraham, A. Magnetostatic wave mixer p1994

I

Iannone, E., Betti, S., Curti, F., and De Marchis, G. see Betti, S.
Ibe, H., Yamakawa, H., Akagi, J., Kuriyama, Y., Morizuka, K., and Obara, M. see Yamakawa, H.
Ibrahim, M.K., Ait-Boudaoud, D., and Hayes-Gill, B.R. see Ait-Boudaoud, D.
Ibrahim, M.K., and Aggoun, A. Six-bit DPCM video signal processing and implementation using systolic arrays p1225
Ibrahim, M.K., and Ait-Boudaoud, D. see Ait-Boudaoud, D.
Ibrahim, S.A., and El-Rabaie, S. Modelling DC characteristics of GaAs MESFET devices using a simple and accurate analytic tool p1892
Ichihashi, Y., Imai, T., Hayashi, Y., Ohkawa, N., Sugie, T., and Ito, T. see Imai, T.
Ichihashi, Y., Imai, T., Ohkawa, N., Sugie, T., and Ito, T. see Imai, T.
Ichihashi, Y., Saito, S., Imai, T., Sugie, T., Ohkawa, N., and Ito, T. see Saito, S.
Ichimura, T., Toida, M., Kondo, M., and Inaba, H. see Toida, M.
İdemen, M., and Büyükaksoy, A. see Büyükaksoy, A.
Idler, W., Schilling, M., Schweizer, H., Düttmg, K., Kühn, E., Nowitzki, A., and Wünstel, K. see Schilling, M.
Ikeda, H., Ogawa, K., Ishizaki, T., Hashimoto, K., and Ota, Y. see Ogawa, K.
Iliegems, M., Zirngibl, M., Bischoff, J.C., Hirtz, J.P., Bartenlian, B., Beaud, P., and Hodel, W. see Zirngibl, M.
Illek, S., Thulke, W., Schanen, C., Lang, H., and Amann, M.-C. Over 7nm (875GHz) continuous wavelength tuning by tunable twin-guide (TTG) laser diode p46
Illek, S., and Thulke, W. see Thulke, W.
Ilyas, M. Resource allocation in broadband ISDNs p1860
Imai, H., and Saitoh, Y. see Saitoh, Y.
Imai, T., Hayashi, Y., Ohkawa, N., Sugie, T., Ichihashi, Y., and Ito, T. Field demonstration of 2·5Gbit/s coherent optical transmission through installed submarine fibre cables p1407
Imai, T., Ohkawa, N., Ichihashi, Y., Sugie, T., and Ito, T. Over 300km CPFSK transmission experiment using 67photon/bit sensitivity receiver at 2·5Gbit/s p357
Imai, T., Saito, S., Sugie, T., Ohkawa, N., Ichihashi, Y., and Ito, T. see Saito, S.
Imai, T., Sugie, T., and Ito, T. see Sugie, T.
Imai, Y., Tokumitsu, M., Onodera, K., and Asai, K. 10GHz bandwidth, 20dB gain low-noise direct-coupled amplifier ICs using Au/WSiN GaAs MESFET p699
Imoto, K., Uetsuka, H., and Kurosawa, M. see Uetsuka, H.
Iñigo, R.M., Bonde, A., and Holcombe, B. Self adjusting weights for hardware neural networks p1630
Inaba, H., Toida, M., Kondo, M., and Ichimura, T. see Toida, M.
Inada, M., Ota, Y., Hirose, T., and Ryoji, A. see Ota, Y.
Inada, T., and Hirano, Y. see Hirano, Y.
Inamura, E., Yamamoto, T., Miyamoto, Y., Ogawa, M., and Furuya, K. see Yamamoto, T.
Inoue, H., Hartman, D.H., and Takahashi, Y. see Hartman, D.H.
Inoue, M., Kusui, S., and Kosukegawa, M. see Kusui, S.
Inoue, Y., Suzuki, Y., Yajima, H., Shimoyama, K., Katoh, M., and Gotoh, H. see Suzuki, Y.
Iqbal, M.Z., Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Gimlett, J.L., Standley, R.D., Young, J., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Ironside, C.N., Keys, R.W., Loni, A., De La Rue, R.M., Marsh, J.H., Luff, B.J., and Townsend, P.D. see Keys, R.W.
Ironside, C.N., and Bell, J. see Bell, J.
Irwin, G.W., and Gaston, F.M.F. see Gaston, F.M.F.
Isaac, J.J., Barnsley, P.E., and Elton, D.J. see Barnsley, P.E.
Ishida, M., Chung, G.S., Kawahito, S., and Nakamura, T. see Chung, G.S.
Ishida, M., Himura, A., Fukui, Y., and Higashimura, M. see Himura, A.
Ishida, M., Kawahito, S., and Nakamura, T. see Kawahito, S.
Ishida, O., Toba, H., and Kano, F. Lightwave scalar network analyser employing optical heterodyne detection p297
Ishida, T., Okayama, H., and Ushikubo, T. see Okayama, H.
Ishii, R. Derivation of Fourier transform of discrete series from z-transform p1938
Ishikawa, G., Naito, T., Chikama, T., and Kuwahara, H. see Naito, T.
Ishikawa, H., Kawamura, H., Kamite, K., Yonetani, H., Ogita, S., and Soda, H. see Kawamura, H.
Ishikawa, H., Soda, H., Furutsu, M., Sato, K., Okazaki, N., Yamazaki, S., and Nishimoto, H. see Soda, H.
Ishikawa, H., Sugano, M., Sudo, H., Soda, H., and Kusunoki, T. see Sugano, M.
Ishikawa, H., and Tabuchi, H. see Tabuchi, H.
Ishikawa, M., Itaya, K., Hatakoshi, G., Watanabe, Y., and Uematsu, Y. see Itaya, K.
Ishikawa, M., Itaya, K., and Uematsu, Y. see Itaya, K.
Ishikawa, M., Shiozawa, H., Tsuburai, Y., and Uematsu, Y. Short-wavelength (638nm) room-temperature CW operation of InGaAlP laser diodes with quaternary active layer p211
Ishizaki, T., Ogawa, K., Ikeda, H., Hashimoto, K., and Ota, Y. see Ogawa, K.
Ishizuka, O., Tang, Z., and Matsumoto, H. see Tang, Z.
Isido, K., Hakamata, Y., and Takemoto, K. see Hakamata, Y.
Ismail, M.S., Bower, R.W., Veteran, J.L., and Marsh, O.J. Silicon nitride direct bonding p1045
Iso, A., Sato, S., Orikasa, T., and Sugimoto, T. see Sato, S.
Iso, A., Sekine, K., Dooi, Y., Funaki, H., and Takei, I. see Sekine, K.
Isshiki, K., Shima, A., Kamizato, T., Takami, A., Karakida, S., and Matsubara, H. see Shima, A.
Itaya, K., Hatakoshi, G., Watanabe, Y., Ishikawa, M., and Uematsu, Y. High-power CW operation of broad area InGaAlP visible light laser diodes p214
Itaya, K., Ishikawa, M., and Uematsu, Y. 636nm room temperature CW operation by hetero-barrier blocking structure InGaAlP laser diodes p839
Ito, H. MOCVD grown carbon-doped graded-base AlGaAs/GaAs HBTs p1977
Ito, H., Sugino, T., and Shirafuji, J. see Sugino, T.
Ito, K., and Naito, M. see Naito, M.
Ito, T., Imai, T., Hayashi, Y., Ohkawa, N., Sugie, T., and Ichihashi, Y. see Imai, T.
Ito, T., Imai, T., Ohkawa, N., Ichihashi, Y., and Sugie, T. see Imai, T.
Ito, T., Saito, S., Imai, T., Sugie, T., Ohkawa, N., and Ichihashi, Y. see Saito, S.
Ito, T., Sugie, T., and Imai, T. see Sugie, T.
Itoh, T., Kong, K.-S., Kuo, C.W., and Kitazawa, T. see Kong, K.-S.
Itoh, T., Shimizu, J., Suzaki, T., Terakado, T., Fujita, S., Kasahara, K., and Suzuki, A. see Shimizu, J.
Ittipiboon, A., Martin, J.T.H. St., Antar, Y.M.M., Kishk, A.A., and Cuhaci, M. see Martin, J.T.H. St.
Ittipiboon, A., Oostlander, R., Antar, Y.M.M., and Cuhaci, M. see Oostlander, R.
Ivrissimtzis, L.P. Electromagnetic field inside a surface current distribution p1933
Iwabuchi, T., Uchiyama, A., Fukuda, H., Hayashi, T., and Ohno, S. see Uchiyama, A.
Iwano, H., Ogura, M., Mukai, S., Shimada, M., Asaka, T., Yamasaki, Y., and Seki, T. see Ogura, M.
Iwashita, K., Norimatsu, S., and Noguchi, K. see Norimatsu, S.
Iwashita, K., Takachio, N., Nakanishi, K., and Koike, S. see Takachio, N.
Iwatsuki, K., Nishi, S., Saruwatari, M., and Shimizu, M. 2·8Gbit/s optical soliton transmission employing all laser diodes p1
Iwatsuki, K., Okamura, H., and Saruwatari, M. Wavelength-tunable single-frequency and single-polarisation Er-doped fibre ring-laser with 1·4kHz linewidth p2033
Iwatsuki, K., and Okamura, H. see Okamura, H.
Izosimov, O.A., Shagurin, I.I., and Tsylyov, V.V. Physical approach to CMOS module self-timing p1835
Iztkovich, M., Tur, M., Hardy, A., and Croituro, N. In-*situ* investigation of coupling between a fibre and a slab waveguide p1104
Izumi, K., and Nakashima, S. see Nakashima, S.
Izzard, M.J., Migliorato, P., and Milne, W.K. Approximate analytical model for the poly-silicon thin film transistor p1284

J

Jäger, D., von Wendorff, W.C., and Welters, M. see von Wendorff, W.C.
Jabra, A.A., Chao, P.C., Ho, P., Duh, K.H.G., Smith, P.M., Ballingall, J.M., Lewis, N., and Hall, E.L. see Chao, P.C.
Jackson, D.A., and Sampson, D.D. see Sampson, D.D.
Jackson, R.W., Pozar, D.M., and Svitak, A. see Pozar, D.M.
Jacquet, J., Flaarønning, N., Frorud, J.O., Sotom, M., Vendrôme, G., Da Loura, G., Gabriagues, J.M., Leclerc, D., and Benoit, J. see Flaarønning, N.
Jadot, J.P., Grand, G., Denis, H., Valette, S., Fournier, A., and Grouillet, A.M. see Grand, G.
Jaeger, G., Tews, H., Zwicknagl, P., Neumann, R., Hoepfner, A., Schleicher, L., and Packeiser, G. see Tews, H.
Jaggard, D.L., Engheta, N., and Liu, J. Chiroshield: A Salisbury/Dallenbach shield alternative p1332
Jajszczyk, A. Directional-coupler-based planar concentrator networks p886
Jaksic, Z., Djuric, Z., Djinovic, Z., and Totovski, D. see Djuric, Z.
Jaksic, Z., Djuric, Z., Jovic, V., and Matic, M. see Djuric, Z.
Jalali, B., Nottenburg, R.N., Banu, M., Humphrey, D.A., Montgomery, R.K., Hamm, R.A., and Panish, M.B. see Nottenburg, R.N.
James, J.H., Wüthrich, C., Ganière, J.D., and Reinhart, F.K. see Wüthrich, C.
Jan, W.Y., Kuo, T.Y., Cunningham, J.E., Goossen, K.W., Fonstad, C.G., and Ren, F. see Kuo, T.Y.
Janega, P.L., Chatenoud, F., and Wasilewski, Z. Very low resistivity ohmic contact to *p*-type GaAs using $In_xGa_{1-x}As$ interlayer p1395
Jang, W., and Bien, Z. Estimation method for normalised feature Jacobian matrix using only one camera p2100
Jankovic, D. Heavily doped emitter as a lossy transmission line p675
Janniello, F.J., and Miller, C.M. see Miller, C.M.
Jansen, Ph., Van Hoof, C., Genoe, J., Van Hove, M., Van Rossum, M., and Borghs, G. see Van Hoof, C.
Jarry, P., Cavaillès, J.A., Renaud, M., Erman, M., Vinchant, J.F., and Goutelle, A. see Cavaillès, J.A.
Jaw, S.-B., and Pei, S.-C. see Pei, S.-C.
Jaw, S.-B., and Pei, S.-C. Two-band IIR quadrature mirror filter design p1687
Jayasumana, A.P., Menon, S.M., and Malaiya, Y.K. see Menon, S.M.
Jayasumana, A.P., and Ott, J.M. see Ott, J.M.
Jayasundere, N., Wu, Z., Maclean, T.S.M., Carter, L.J., and Williamson, A.G. see Wu, Z.
Jecko, B., Vaudon, P., and Reineix, A. see Vaudon, P.
Jedwab, J., and Mitchell, C.J. Infinite families of quasiperfect and doubly quasiperfect binary arrays p294
Jegannathan, S., and Ramamurthi, B. Scattering from a circular dielectric cylindrical shell: A fast algorithm p484
Jen, B.-S., Chang, M.-W., Sun, S.-W., Shih, C.-H., and Wu, T.-M. Optical Chinese character recognition with a hidden Markov model classifier—A novel approach p1530
Jen, C.K., Wang, Z., and Cheeke, J.D.N. see Wang, Z.
Jeng, Y.-J., Yeh, C.-C., and Chiueh, T.D. Exponential bidirectional associative memories p717
Jenkins, S., Hodgetts, T.E., Symm, G.T., Warham, A.G.P., Clarke, R.N., and Preece, A.W. Comparison of three numerical treatments for the open-ended coaxial line sensor p234
Jenneskens, L.W., Diemeer, M.B.J., Suyten, F.M.M., Trommel, E.S., McDonach, A., Copeland, J.M., and Horsthuis, W.H.G. see Diemeer, M.B.J.
Jensen, N.G., Hoffmann, B., Bødtker, E., Nielsen, S.K., and Broberg, B. see Hoffmann, B.
Jeon, H.B., and Un, C.K. Contention-based reservation protocol in fibre optic local area network with passive star topology p780
Jeong, J., Lum, R.M., Klingert, J.K., Bylsma, R., Vella-Coleiro, G.P., and Smith, P.R. High performance GaAs MESFETs grown on InP substrates by MOCVD using tertiarybutylarsine p482
Jeong, J., Vella-Coleiro, G.P., and Yee, C.M.L. GaAs MESFET amplifiers fabricated on InP substrates p135
Jeromin, L.L., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Kaufmann, J.E., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.
Jeromin, L.L., Castagnozzi, D.M., Alexander, S.B., Colagiuri, E.P., and Bucher, E.A. see Castagnozzi, D.M.
Jestel, D., Baus, A., and Voges, E. Integrated-optic interferometric microdisplacement sensor in glass with thermo-optic phase modulation p1144
Jewell, J., Chang-Hasnain, C.J., Maeda, M.W., Stoffel, N.G., Harbison, J.P., and Florez, L.T. see Chang-Hasnain, C.J.
Jewell, J.L., Lee, Y.H., Tell, B., Brown-Goebeler, K., Leibenguth, R.E., Asom, M.T., Livescu, G., Luther, L., and Mattera, V.D. see Lee, Y.H.
Jewell, J.L., Lee, Y.H., Tell, B., Brown-Goebeler, K., and Hove, J.V. see Lee, Y.H.
Jewell, J.L., Lee, Y.H., Tell, B., Brown-Goebeler, K.F., Scherer, A., Harbison, J.P., and Florez, L.T. see Lee, Y.H.
Jezequel, G., Quemerais, A., L'Haridon, H., Favennec, P.N., and Salvi, M. see Quemerais, A.
Ji, J.-K., Kim, C.-M., Han, S., and Kim, Y. see Kim, C.-M.
Jiang, P., and Zhang, X. see Zhang, X.
Jiang, Q., Wu, D.M., and Xie, L.Z. Two-channel coherent optical FDM transmission system with a new frequency stabilisation scheme p310
Jianhua, Ma, and Xinmei, Wang Generalised type-II hybrid ARQ p88
Jin, Fan, and Fan, Pingzhi see Fan, Pingzhi
Jin, H., and Jingren, Q. Simple method for calculation of stress-induced birefringence in fibres with arbitrary structures p598
Jingren, Q., and Jin, H. see Jin, H.
Jinguji, K., Takagi, A., and Kawachi, M. see Takagi, A.
Jinguji, K., Takato, N., Sugita, A., and Kawachi, M. 0Mach–Zehnder interferometer type optical

waveguide coupler with wavelength-flattened coupling ratio p1326
Johns, D.A., Wania, X.F., and Sedra, A.S. see Wania, X.F.
Johnson, B.C., Chandrasekhar, S., Dentai, A.G., Joyner, C.H., Gnauck, A.H., and Qua, G.J. see Chandrasekhar, S.
Johnson, D.C., Hill, K.O., Malo, B., Vineberg, K.A., Bilodeau, F., and Skinner, I. see Hill, K.O.
Johnson, N.P., Adams, J.A., Thayne, I.G., Taylor, M.R.S., Wilkinson, C.D.W., Beaumont, S.P., Kean, A.H., and Stanley, C.R. see Adams, J.A.
Jones, E.V., Deslandes, J.E., and Cochrane, P. see Deslandes, J.E.
Jones, G.A.C., Kelly, M.J., Brown, R.J., Pepper, M., Hasko, D.G., Ahmed, H., Peacock, D.C., Frost, J.E.F., and Ritchie, D.A. see Kelly, M.J.
Jones, G.A.C., Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., and Ritchie, D.A. see Matthews, P.
Jones, J.D.C., Morgan, R., Barton, J.S., and Harper, P.G. see Morgan, R.
Jones, K.L., Zucker, J.E., Chang, T.Y., Sauer, N., Tell, B., Brown-Goebeler, K., Wegener, M., and Chemla, D.S. see Zucker, J.E.
Jones, R., Broomhead, D.S., McWhirter, J.G., and Shepherd, T.J. see Broomhead, D.S.
Jopson, R.M., Stone, J., Stulz, L.W., and Licht, S.J. see Stone, J.
Jordan, A.S., Ren, F., Abernathy, C.R., Pearton, S.J., Fullowan, T.R., and Lothian, J. see Ren, F.
Joshi, A.B., Lo, G.Q., Kwong, D.L., and Xie, J. Polarity dependence of charge to breakdown and interface state generation of oxynitride gate dielectrics prepared by rapid thermal processing p1741
Joshi, A.B., Lo, G.Q., and Kwong, D.L. Process dependence of interface state generation due to irradiation and hot carrier stress in rapid thermally nitrided thin gate oxides p1248
Josse, F., Haworth, D.T., Kelkar, U.R., and Shana, Z.A. $LiNbO_3$ acoustic plate mode sensor for dilute ionic solutions p834
Jou, D.C., Kirkby, C.J.G., and Reid, D.C.J. see Kirkby, C.J.G.
Jovic, V., Djuric, Z., Matic, M., and Jaksic, Z. see Djuric, Z.
Joyner, C.H., Chandrasekhar, S., Dentai, A.G., Johnson, B.C., Gnauck, A.H., and Qua, G.J. see Chandrasekhar, S.
Judge, S.N., Wake, D., Spooner, T.P., Harlow, M.J., Duncan, W.J., Henning, I.D., and O'Mahony, M.J. see Wake, D.
Julien, F.H., Bradley, M.A., Gilles, J.P., Gao, Y., Rao, E.V.K., Razeghi, M., and Omnes, F. see Bradley, M.A.
Julien, F.H., Yang, D.D., Boucaud, P., Chusseau, L., Lourtioz, J.-M., and Planel, R. see Yang, D.D.
Juy, M., Maurel, R., Rooryck, M., Nugroho, I.A., and Hariman, T. Rain rate measurements in Indonesia p596
Juy, M., Maurel, R., Rooryck, M., Nugroho, I.A., and Hariman, T. Satellite Earth path attenuation at 11 GHz in Indonesia p1404

K

Kabos, P., Hyben, P., Ceskovic, R., Cermak, J., and Abraham, A. see Hyben, P.
Kado, Y., Okazaki, Y., Suzuki, M., and Kobayashi, T. 3·2 GHz 0·2 μm gate CMOS 1/8 dynamic frequency divider p1684
Kaertner, F.X., Anzill, W., Goeller, T., Russer, P., and Buechler, J. see Anzill, W.
Kagawa, T., Miyamoto, Y., and Hagimoto, K. see Miyamoto, Y.
Kaino, T., and Amano, M. see Amano, M.
Kaiser, A., and Bardyn, J.-P. see Bardyn, J.-P.
Kaiser, A., and Stefanelli, B. see Stefanelli, B.
Kaliski, R., Wang, G.W., Feng, M., and Kuang, J.B. see Wang, G.W.
Kamala, R., and Kudalkar, V. Use of constrained minimisation method in study of optical fibres p100 e1097
Kamar, I., and Elcherif, Y. Conjugate pair fast Fourier transform d541
Kamegawa, M., Yu, R.Y., Case, M., Sundaram, M., Rodwell, M.J.W., and Gossard, A.W. see Yu, R.Y.
Kamei, H., Yano, H., Aga, K., Sasaki, G., and Hayashi, H. see Yano, H.
Kameyama, M., Aoki, T., and Higuchi, T. see Aoki, T.
Kamite, K., Kawamura, H., Yonetani, H., Ogita, S., Soda, H., and Ishikawa, H. see Kawamura, H.
Kamizato, T., Shima, A., Takami, A., Karakida, S., Isshiki, K., and Matsubara, H. see Shima, A.
Kanamori, K., Yonezu, H., Himeno, T., Pak, K., and Takano, Y. see Yonezu, H.
Kaneda, H., Yamaguchi, M., and Hashimoto, K.-Y. see Yamaguchi, M.
Kaneko, Y., Kikuchi, A., Nomura, I., and Kishino, K. see Kikuchi, A.
Kaneko, Y., Kikuchi, A., Nomura, I., and Kishino, K. Yellow light (576 nm) lasing emission of GaInP/AlInP multiple quantum well lasers prepared by gas-source-molecular-beam-epitaxy p657
Kanellakis, A., Tzafestas, S., and Theodorou, N. see Tzafestas, S.
Kang, K.N., Lee, J.I., Lee, M.B., Lee, Y.J., Han, I.K., and Park, K.O. see Lee, J.I.
Kang, K.N., Lee, J.I., Lee, M.B., and Park, K.O. see Lee, J.I.
Kano, F., Ishida, O., and Toba, H. see Ishida, O.
Kao, M-S, and Wu, J. Coherent optical ring using common local oscillator p1013
Kao, M-S., and Wu, J. Coherent subcarrier multiplexed star distribution system using local oscillator p1680
Kao, M.-S. On/off ratio degradation of high density WDM systems due to raman crosstalk p1034
Kao, M.-S., and Wu, J. Gain limitation of fibre Raman amplifiers considering third Stokes wavelength generation p191
Kapitan, L., Offsey, S.D., Tasker, P.J., Schaff, W.J., Shealy, J.R., and Eastman, L.F. see Offsey, S.D.
Karakida, S., Shima, A., Kamizato, T., Takami, A., Isshiki, K., and Matsubara, H. see Shima, A.
Kasahara, K., Shimizu, J., Suzaki, T., Terakado, T., Fujita, S., Itoh, T., and Suzuki, A. see Shimizu, J.
Kasahara, K., Tashiro, Y., Ogura, I., Sugimoto, M., and Hamao, N. see Tashiro, Y.
Kasemsei, D., Ackerman, E., Wanuga, S., and Chinn, S. see Ackerman, E.
Kashiwa, T., Yoshida, N., and Fukai, I. Simulation of the reduction characteristics of scattering from an aircraft coated with a thin-type absorber by the spatial network method p289
Kashyap, R., Armitage, J.R., Wyatt, R., Davey, S.T., and Williams, D.L. All-fibre narrowband reflection gratings at 1500 nm p730
Kasper, E., Splett, A., Schmidtchen, J., Schüppert, B., Petermann, K., and Kibbel, H. see Splett, A.
Katerinchuk, V.N., Manasson, V.A., Kovalyuk, Z.D., and Drapak, S.I. see Manasson, V.A.
Kato, K., Takahashi, H., Suzuki, S., and Nishi, I. see Takahashi, H.
Kato, K., and Wada, M. see Wada, M.
Kato, N., Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., Hagimoto, K., and Hirayama, M. see Ohhata, M.
Kato, N., Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., and Hirayama, M. see Ohhata, M.
Kato, Y., and Murakami, T. Fast computational algorithm for transform coding p944
Katoh, M., Suzuki, Y., Yajima, H., Shimoyama, K., Inoue, Y., and Gotoh, H. see Suzuki, Y.
Katsaggelos, A.K., and Efstratiadis, S.N. see Efstratiadis, S.N.
Katsuyama, T., Yoshida, I., Shinkai, J., Hashimoto, J., and Hayashi, H. Very low threshold current AlGaInP/$Ga_xIn_{1-x}P$ strained single quantum well visible laser diode p1375
Katsuyama, Y., Komukai, T., and Miyajima, Y. see Komukai, T.
Katz, G.R., Havlicek, J.P., Sarkady, K.A., and McKeeman, J.C. see Havlicek, J.P.
Kaufmann, H., and Haller, B. see Haller, B.
Kaufmann, J.E., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Materna, D.M., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.
Kavehrad, M., and Neusy, P.C. see Neusy, P.C.
Kawachi, M., Jinguji, K., Takato, N., and Sugita, A. see Jinguji, K.
Kawachi, M., Takagi, A., and Jinguji, K. see Takagi, A.
Kawahito, S., Chung, G.S., Ishida, M., and Nakamura, T. see Chung, G.S.
Kawahito, S., Ishida, M., and Nakamura, T. Analogue MOS current-mode circuits for three-dimensional integrated smart image sensor p177
Kawai, Y., and Yamada, T. Low temperature-stressed aging test of 1·3–1·45 μm laser diodes under high power operation p53
Kawamura, H., Kamite, K., Yonetani, H., Ogita, S., Soda, H., and Ishikawa, H. Effect of varying threshold gain on second order intermodulation distortion in distributed feedback lasers p1720
Kawamura, S., and Shimbo, A. see Shimbo, A.
Kawamura, Y., Fukano, H., Asai, H., Takanashi, Y., and Fujimoto, M. see Fukano, H.
Kayran, A.H., Ertüzün, A., and Panayirci, E. see Ertüzün, A.
Kazmierski, C., Blez, M., Quillec, M., Allovon, M., and Sermage, B. Low-threshold GRIN-SCH AlGaInAs 1·55 μm quantum well buried ridge structure lasers grown by molecular beam epitaxy p889
Kazovsky, L.G., and Atlas, D.A. see Atlas, D.A.
Kean, A.H., Adams, J.A., Thayne, I.G., Taylor, M.R.S., Wilkinson, C.D.W., Beaumont, S.P., Johnson, N.P., and Stanley, C.R. see Adams, J.A.
Kearley, M., Farries, M.C., and Buus, J. see Farries, M.C.
Kearley, M.Q., Moseley, A.J., Thompson, J., Robbins, D.J., and Goodwin, M.J. see Moseley, A.J.
Kearney, M.J., Kelly, M.J., Condie, A., and Dale, I. Temperature dependent barrier heights in bulk unipolar diodes leading to improved temperature stable performance p671
Kearns, R.F., Shukla, V.S., and Singh, M.P. see Shukla, V.S.
Kechouane, M., L'Haridon, H., Salvi, M., Favennec, P.N., Moutonnet, D., Gauneau, M., and Mercier, J.P. Growth of Al:Er:O alloys on silicon p1067
Kegel, A., Prasad, R., and Misser, H.S. see Prasad, R.
Kelkar, U.R., Josse, F., Haworth, D.T., and Shana, Z.A. see Josse, F.
Kellert, F., Lee Russell, J., Ehlers, E., and Monahan, D. see Lee Russell, J.
Kelly, M.J., Brown, R.J., Pepper, M., Hasko, D.G., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. Room temperature negative differential resistance in the quasi-one-dimensional ballistic resistor p171
Kelly, M.J., Kearney, M.J., Condie, A., and Dale, I. see Kearney, M.J.
Kelly, M.J., Matthews, P., Law, V.J., Hasko, D.G., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Kelly, M.J., Syme, R.T., Condie, A., and Dale, I. see Syme, R.T.
Kelly, S.M.J., Smith, K., Armitage, J.R., Wyatt, R., and Doran, N.J. see Smith, K.
Kennis, P., Kinowski, D., Seguinot, C., and Pribetich, P. see Kinowski, D.
Kennis, P., Paleczny, E., Kinowski, D., Legier, J.F., and Pribetich, P. see Paleczny, E.
Kenny, R.P., Birks, T.A., Oakley, K.P., and Cryan, C.V. see Birks, T.A.
Kerber, M., Weger, P., Felder, A., and Klose, H. see Weger, P.
Kersey, A.D., and Berkoff, T.A. see Berkoff, T.A.
Kersey, A.D., and Berkoff, T.A. Novel passive phase noise cancelling technique for interferometric fibre optic sensors p640
Kersey, A.D., and Marrone, M.J. Quadrature phase sampling of a fibre interferometer by input-polarisation switching p686
Kersey, A.D., and Moeller, R.P. Open loop fibre optic gyroscope with phase shift nulling signal processing p1251
Keskinen, J., Näppi, J., Asonen, H., and Pessa, M. Methane/hydrogen metal organic reactive ion etching of GaInAsP compounds p1369 e1832
Keys, R.W., Loni, A., De La Rue, R.M., Ironside, C.N., Marsh, J.H., Luff, B.J., and Townsend, P.D. Fabrication of domain reversed gratings for SHG in $LiNbO_3$ by electron beam bombardment p188
Keys, R.W., Loni, A., and De La Rue, R.M. Measurement of the increase in the SHG coefficient of proton exchanged $LiNbO_3$ after annealing using a grating diffraction technique p624
Keyworth, B.P., Cada, M., Glinski, J.M., Spring-Thorpe, A.J., Rolland, C., and Hill, K.O. Multiple quantum well directional coupler as a self-electro-optic effect device p2011
Khachatrian, G., Vucetic, B., and Zhang, L. see Vucetic, B.
Khamas, S., Cook, G.G., Kingsley, S.P., and Woods, R.C. Significance of matching networks in enhanced performance of small antennas when supercooled p654
Khamsehpour, B., and Singer, K.E. GaAs–GaAsSb based heterojunction bipolar transistor p965
Khan, J.Y., and Dunlop, J. see Dunlop, J.
Khanarian, G., and Norwood, R.A. see Norwood, R.A.
Khellaf, A., Thouroude, D., and Daniel, J.P. Simple expression of rectangular patch's resistance at resonance p1188
Khrushchëv, I.Yu., Grudinin, A.B., Dianov, E.M., Korobkin Jun, D.V., Semënov, V.A., and Prokhorov, A.M. Amplification of femtosecond pulses in Er^{3+}-doped single-mode optical fibres p456
Khursheed, A. High speed electron-beam testing of VLSI circuits by backscattered electron detection p1657
Ki, W.-H., and Temes, G.C. Low-phase-error offset-compensated switched-capacitor integrator p957
Kibbel, H., Splett, A., Schmidtchen, J., Schüppert, B., Petermann, K., and Kasper, E. see Splett, A.
Kiesler, T., and Harn, L. RSA blocking and multi-signature schemes with no bit expansion p1490
Kikuchi, A., Kaneko, Y., Nomura, I., and Kishino, K. see Kaneko, Y.
Kikuchi, A., Kaneko, Y., Nomura, I., and Kishino, K. Room temperature continuous wave operation of GaInP/AlInP visible-light laser with GaInP/AlInP superlattice confinement layer grown by gas source molecular beam epitaxy p1668
Kikuchi, K. Generalised formula for optical-amplifier noise and its application to erbium-doped fibre amplifiers p1851
Kikuchi, S., Yamanaka, N., and Miyanaga, H. see Yamanaka, N.
Kikuchi, S., Yamauchi, J., Hirooka, T., and Nakano, H. see Yamauchi, J.
Kikugawa, T., Ravikumar, K.G., Aizawa, T., Arai, S., and Suematsu, Y. Observation of field induced refractive index variation in GaInAs/InP quantum wire (QW) structure p1012
Kilkelly, P.D.D., Chidgey, P.J., and Hill, G. Experimental demonstration of a three channel WDM system over 110 km using superluminescent diodes e2137
Kim, B.Y., Fesler, K., Digonnet, M., Liu, K., and Shaw, H.J. see Fesler, K.
Kim, C.-M., Han, S., Ji, J.-K., and Kim, Y. Operating characteristics of CW CO_2–N_2O laser p15
Kim, I., Tan, M.R.T., Chang, J., and Wang, S.Y. see Tan, M.R.T.
Kim, I.D., Nho, E.C., and Cho, G.H. New zero-voltage-switching constant-frequency PWM DC/DC convertor with low switch stress and wide linearity p1320
Kim, I.S., and Hoefer, W.J.R. Numerical dispersion

characteristics and stability factor for the TD–FD method p485
Kim, J., Favaro, M.E., Alwan, J.J., Bryan, R.P., Miller, L.M., Coleman, J.J., and Wayman, C.M. see Favaro, M.E.
Kim, K.-H., Chung, W.-S., and Cha, H.-W. see Chung, W.-S.
Kim, M., and Song, J. see Song, J.
Kim, M., and Yang, H. see Yang, H.
Kim, O.-H., Lin, P.S.D., Hong, W.-P., Bhat, R., Van Der Gaag, B., and Schumacher, H. see Lin, P.S.D.
Kim, Y., Kim, C.-M., Han, S., and Ji, J.-K. see Kim, C.-M.
Kimura, Y., Nakazawa, M., Suzuki, K., and Yamada, E. see Nakazawa, M.
Kimura, Y., Nakazawa, M., Yoshida, E., and Suzuki, K. see Nakazawa, M.
Kimura, Y., Nakazawa, M., and Suzuki, K. see Nakazawa, M.
Kimura, Y., Suzuki, K., Nakazawa, M., and Yamada, E. see Suzuki, K.
Kimura, Y., Suzuki, K., and Nakazawa, M. see Suzuki, K.
Kingsley, S.P., Khamas, S., Cook, G.G., and Woods, R.C. see Khamas, S.
Kinoshita, K., Suhara, T., Fujimura, M., and Nishihara, H. see Suhara, T.
Kinoshita, T., Nakahashi, T., and Eto, Y. 130 Mbit/s (H4 rate) HDTV CODEC based on the DCT algorithm p1245
Kinowski, D., Paleczny, E., Legier, J.F., Pribetich, P., and Kennis, P. see Paleczny, E.
Kinowski, D., Seguinot, C., Pribetich, P., and Kennis, P. Transmission line model for superconducting coplanar lines p148
Kipnis, I., Runge, K., Young, J., Bagheri, M., Millicker, D., and Snapp, C. see Runge, K.
Kirk, J.B., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Kirkby, C.J.G., Reid, D.C.J., and Jou, D.C. Programmable splice-free quasi-monolithic 2 Gbit/s optical fibre pulse code generator p1673
Kirkby, P.A. SYMFONET: ultra-high-capacity distributed packet switching network for telecoms and multiprocessor computer applications p19
Kirkby, P.A., White, I.H., Nyairo, K.O., and Armistead, C.J. see White, I.H.
Kishino, K., Kaneko, Y., Kikuchi, A., and Nomura, I. see Kaneko, Y.
Kishino, K., Kikuchi, A., Kaneko, Y., and Nomura, I. see Kikuchi, A.
Kishino, K., Ünlü, M.S., Chyi, J.-I., Reed, J., Arsenault, L., and Morkoç, H. see Ünlü, M.S.
Kishk, A.A., Martin, J.T.H. St., Antar, Y.M.M., Ittipiboon, A., and Cuhaci, M. see Martin, J.T.H. St.
Kissaka, M.M., Mgombelo, H.R., and Ali, H.O. see Mgombelo, H.R.
Kistler, R., Kuo, C.Y., Ackerman, D.A., Henry, C.H., Shani, Y., Dahbura, M.I., and Wagner, E.J. see Kuo, C.Y.
Kitajima, S., Sasaki, S., Tsushima, H., Okai, M., and Yamashita, K. Novel random access tunable heterodyne receiver using beat counting method for multichannel coherent systems p127
Kitajima, S., Tsushima, H., Sasaki, S., Takeyari, R., Kuboki, K., and Uomi, K. see Tsushima, H.
Kitamura, M., Suzaki, T., Suzuki, Y., Yamada, H., Fujita, S., Hida, H., and Shikada, M. see Suzaki, T.
Kitazawa, T., Kong, K.-S., Kuo, C.W., and Itoh, T. see Kong, K.-S.
Kitoh, T., Kobayashi, S., Hida, Y., Suzuki, S., and Yamaguchi, M. see Kobayashi, S.
Kiyosawa, T., Takahashi, S., Koguchi, N., Chikyow, T., Fujiwara, J., and Yoshihara, K. see Takahashi, S.
Klass, F. Unidirectional-flow systolic array for linear discriminant function classifier p1702
Klatskin, J., Liu, S.G., Taylor, G.C., Camisa, R.L., and Capewell, D.R. see Liu, S.G.
Klein, J.L., and Chang, K. Optimum dielectric overlay thickness for equal even- and odd-mode phase velocities in coupled microstrip circuits p274
Klein, P.B., Moore, F.G., and Dietrich, H.B. 1·54 μm electroluminescence in MeV ion implanted Er-doped GaAs p1299
Klem, J.F., Lott, J.A., Weaver, H.T., Tigges, C.P., and Radoslovich-Cibicki, V. see Lott, J.A.
Klinga, T., Öberg, M., Nilsson, S., Holmberg, B., and Broberg, B. see Öberg, M.
Klingert, J.K., Jeong, J., Lum, R.M., Bylsma, R., Vella-Coleiro, G.P., and Smith, P.R. see Jeong, J.
Klose, H., Weger, P., Felder, A., and Kerber, M. see Weger, P.
Kluitmans, J.T.M., Kuindersma, P.I., Meier, M., Mink, J., Röll, G., and Will, D.J. 2·488 Gbit/s transmission experiment at 1550 nm over 153 km standard single-mode fibre p566
Knöchel, R., and Mayer, B. see Mayer, B.
Knowles, G. VLSI architecture for the discrete wavelet transform p1184
Knowles, G., and Lewis, A.S. see Lewis, A.S.
Ko, J.H., Oh, D.S., and Youn, M.J. Improved current mode control technique for quantum series resonant convertors p936
Ko, Y.T., DiGiovanni, D.J., MacChesney, J.B., and Simpson, J.R. Polarisation-maintaining fibre using a novel glass system p876
Kögler, R., Skorupa, W., and Schmalz, K. see Skorupa, W.
König, S., Rossi, B., Blau, W., O'Gorman, J., Westland, D., and Skarda, V. see Rossi, B.
Körfer, T., Korn, M., Forchel, A., and Roentgen, P. see Korn, M.
Kobayashi, K., Ueno, Y., Endo, K., Fujii, H., Hara, K., and Yuasa, T. see Ueno, Y.
Kobayashi, S., Kitoh, T., Hida, Y., Suzuki, S., and Yamaguchi, M. Y branching silica waveguide 1 × 8 splitter module p707
Kobayashi, T., Kado, Y., Okazaki, Y., and Suzuki, M. see Kado, Y.
Kobayashi, Y., and Ohkita, M. see Ohkita, M.
Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Zah, C.E., Caneau, C., Menocal, S.G., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. Fast wavelength switching and simultaneous FSK modulation using tunable DBR laser p308
Koç, C.K., and Hung, C.Y. Carry–save adders for computing the product AB modulo N p899
Koç, C.K., and Hung, C.Y. Multi-operand modulo addition using carry save adders p361
Koga, M., and Matsumoto, T. see Matsumoto, T.
Koguchi, N., Takahashi, S., Chikyow, T., Kiyosawa, T., Fujiwara, J., and Yoshihara, K. see Takahashi, S.
Koh, S.N., Huang, S.J., and Tang, H.K. see Huang, S.J.
Kohn, E., Goostray, J., Thomas, H., Morgan, D.V., Christou, A., and Mottet, S. see Goostray, J.
Koike, S., Takachio, N., Iwashita, K., and Nakanishi, K. see Takachio, N.
Kolesov, S.G., Galdukov, M.M., Kowalewicz, L., Kozyrev, A.B., and Vendik, O.G. see Galdukov, M.M.
Kominami, M., Yakuwa, N., and Kusaka, H. Approximate analysis of electromagnetically coupled microstrip dipoles p1901
Kominato, T., Ohmori, Y., Okazaki, H., and Yasu, M. Very low-loss GeO_2-doped silica waveguides fabricated by flame hydrolysis deposition method p327
Komukai, T., Miyajima, Y., and Katsuyama, Y. 2·55 μm, 400 Mbit/s transmission experiment with single-mode fluoride optical fibre p584
Komukai, T., Miyajima, Y., and Sugawa, T. see Miyajima, Y.
Komukai, T., Sugawa, T., and Miyajima, Y. see Sugawa, T.
Kondo, M., Toida, M., Ichimura, T., and Inaba, H. see Toida, M.
Kong, D.T., Lo, Y.H., Bagheri, M., Lin, P.S.D., Grabbe, P., Bhat, R., Stoffel, N.G., and Lee, T.P. see Lo, Y.H.
Kong, K.-S., Kuo, C.W., Kitazawa, T., and Itoh, T. Analysis of the superconducting coplanar waveguide by combining spectral domain method and phenomenological equivalence method p1558
Kong, S.H., Lee, T., and Li, R. see Lee, T.
Kong, T.C., Pun, E.Y.B., Chung, P.S., and Chan, H.P. see Pun, E.Y.B.
Koo, J.M., and Un, C.K. Fuzzy smoothing of HMM parameters in speech recognition p743
Koo, K.P., Dagenais, D.M., Vohra, S., and Bucholtz, F. Dual excitation scheme for direct suppression of residual signal in fibre-optic magnetometers p1867
Koo, M.W., and Un, C.K. Speaker adaptation using learning vector quantisation p1731
Kooi, P.S., Yeo, T.S., Leong, M.S., and Ng, S.S. see Yeo, T.S.
Koonen, A.M.J., Van Eijk, P., Van Heijningen, P.H., and Mosch, T.W.M. 2.26 Gbit/s optical transmission system with 5B6B line coding p799
Kopf, R.F., Lunardi, L.M., Archer, V.D., Swartz, R.G., Kuo, J.M., Malik, R.J., and Smith, P.R. see Lunardi, L.M.
Kopf, R.M., Goossen, K.W., Zucker, J.E., Bar-Joseph, I., Kuo, J.M., Miller, D.A.B., and Chemla, D.S. see Goossen, K.W.
Koren, U., Oron, M., Young, M.G., Miller, B.I., De Miguel, J.L., Raybon, G., and Chien, M. Low threshold highly efficient strained quantum well lasers at 1·5 micrometre wavelength p465
Korn, M., Körfer, T., Forchel, A., and Roentgen, P. Fabrication and optical characterisation of first order DFB GaInP/AlGaInP laser structures at 639 nm p614
Korobkin Jun, D.V., Khrushchëv, I.Yu., Grudinin, A.B., Dianov, E.M., Semënov, V.A., and Prokhorov, A.M. see Khrushchëv, I.Yu.
Koscica, T.E. High voltage microwave DC block for microstrip ground planes p1287
Koscica, T.E. Microstrip inversion transition p2051
Koshiba, M., and Hayata, K. see Hayata, K.
Kosukegawa, M., Kusui, S., and Inoue, M. see Kusui, S.
Kotov, O.I., Filippov, V.N., and Nikolayev, V.M. see Filippov, V.N.
Kovalyuk, Z.D., Manasson, V.A., Drapak, S.I., and Katerinchuk, V.N. see Manasson, V.A.
Kowalewicz, L., Galdukov, M.M., Kolesov, S.G., Kozyrev, A.B., and Vendik, O.G. see Galdukov, M.M.
Koyamada, Y., and Nakamoto, H. High performance single mode OTDR using coherent detection and fibre amplifiers p573
Koza, M., Shantharama, L.G., Schumacher, H., Leblanc, H.P., Esagui, R., and Bhat, R. see Shantharama, L.G.
Koza, M.A., Schumacher, H., Soole, J.B.D., LeBlanc, H.P., and Bhat, R. see Schumacher, H.
Koza, M.A., Soole, J.B.D., Tsang, H.K., White, I.H., LeBlanc, H.P., and Bhat, R. see Soole, J.B.D.
Kozyrev, A.B., Galdukov, M.M., Kolesov, S.G., Kowalewicz, L., and Vendik, O.G. see Galdukov, M.M.
Krain, M.J., Devasirvatham, D.M.J., Rappaport, D.A., and Banerjee, C. see Devasirvatham, D.M.J.
Krakauer, D., and Doyle, B.S. Identification and localisation of gate oxide weaknesses in n-MOS transistors through Fowler–Nordheim tunnelling and SPICE simulation p230
Krakowski, M., Blondeau, R., Rondi, D., Glastre, G., and Vilain, G. see Blondeau, R.
Krantz, M.C., Rosen, H.J., and Lenth, W. Localised temperature dynamics of GaAlAs laser facets investigated by Raman microprobe measurements p990
Krauss, T., Laybourn, P.J.R., and Roberts, J. CW operation of semiconductor ring lasers p2095
Krawczyk, S.K., Schütz, R., Matsushita, K., Hartnagel, H.L., and Longère, J.Y. see Schütz, R.
Kreischer, L. Noise tuning of GaAs-MESFET oscillators p315
Kretzmeyer, P., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Lemaire, V., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Krijnen, G.J.M., Hammes, P.C.A., Driessen, A., and Smit, M.K. see Hammes, P.C.A.
Krim, M., Vasilescu, G., and Alquie, G. see Vasilescu, G.
Krogager, E. Absolute phase of the radar target scattering matrix p1834
Krogager, E. New decomposition of the radar target scattering matrix p1525
Krost, A., Kuhl, D., Hieronymi, F., Böttcher, E.H., Wolf, T., and Bimberg, D. see Kuhl, D.
Krug, W., Valera, J., Darzi, A., Walker, A.C., Miao, E., Derstine, M., and Polky, J.N. see Valera, J.
Kruppa, W., Boos, J.B., Binari, S.C., and Hier, H. see Boos, J.B.
Krzymien, W.A., Kusyk, R.G., and Moore, T.E. see Kusyk, R.G.
Krzymien, W.A., Moore, T.E., and Kusyk, R.G. see Moore, T.E.
Kühn, E., Schilling, M., Schweizer, H., Dütting, K., Idler, W., Nowitzki, A., and Wünstel, K. see Schilling, M.
Kuang, J.B., Wang, G.W., Feng, M., and Kaliski, R. see Wang, G.W.
Kuboki, K., Tsushima, H., Sasaki, S., Takeyari, R., Kitajima, S., and Uomi, K. see Tsushima, H.
Kubota, H., and Nakazawa, M. Maximum transmission capacity of a soliton communication system with lumped amplifiers p1454
Kuchibhotla, R., Deppe, D.G., Campbell, J.C., Rogers, T.J., and Streetman, B.G. see Deppe, D.G.
Kudalkar, V., and Kamala, R. see Kamala, R.
Kudumas, M., Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Kuester, E.F., Barsotti, E.L., and Dunn, J.M. see Barsotti, E.L.
Kugelmeier, S., Schöpflin, A., Gottwald, E., Felicio, D., and Fischer, G. see Schöpflin, A.
Kuhl, D., Hieronymi, F., Böttcher, E.H., Wolf, T., Krost, A., and Bimberg, D. Very high-speed metal–semiconductor–metal InGaAs : Fe photodetectors with InP : Fe barrier enhancement layer grown by low pressure metalorganic chemical vapour deposition p2107
Kuijk, M., Pereira, R., Van Hove, M., Mertens, R.P., Borghs, G., and Pankove, J.I. Optoelectronic switch with low holding power p280 e555 e555
Kuindersma, P.I., Kluitmans, J.T.M., Meier, M., Mink, J., Röll, G., and Will, D.J. see Kluitmans, J.T.M.
Kukuča, R., and Červeň, J. see Červeň, J.
Kumai, T., Wada, O., Hamaguchi, H., Makiuchi, M., Kuramata, A., and Mikawa, T. see Wada, O.
Kumar, A., and Mullick, S.K. Attractor dimension, entropy and modelling of speech time series p1790
Kumar, B.A., Senani, R., Tripathi, M.P., and Bhaskar, D.R. see Senani, R.
Kumar, S., and Wells, G. 2.75 GHz–4.75 GHz QPSK modulator with low amplitude and phase errors p961
Kuo, C.W., Kong, K.-S., Kitazawa, T., and Itoh, T. see Kong, K.-S.
Kuo, C.Y., Ackerman, D.A., Henry, C.H., Shani, Y., Dahbura, M.I., Kistler, R., and Wagner, E.J. Uniform frequency modulation responses in narrow linewidth ($\leq$200 kHz) compact hybrid lasers p270
Kuo, C.Y., Twu, Y., Wang, S.J., Wynn, J.D., Brown, R.L., Gruezke, L.A., Strege, K.E., Lin, M.S., and Dutta, N.K. see Twu, Y.
Kuo, J.-T., Tzuang, C.-K.C., and Lee, C.-Y. see Tzuang, C.-K.C.
Kuo, J.-T., and Tzuang, C.-K.C. see Tzuang, C.-K.C.
Kuo, J.M., Goossen, K.W., Zucker, J.E., Bar-Joseph, I., Kopf, R.M., Miller, D.A.B., and Chemla, D.S. see Goossen, K.W.
Kuo, J.M., Lunardi, L.M., Archer, V.D., Swartz, R.G., Kopf, R.F., Malik, R.J., and Smith, P.R. see

Lunardi, L.M.
Kuo, T.Y., Chiu, T.H., Cunningham, J.E., Goossen, K.W., Fonstad, C.G., and Ren, F. Heterostructure bipolar transistor employing carbon-doped base grown with trimethyl-Ga and arsine p1260
Kuo, T.Y., Cunningham, J.E., Goossen, K.W., Jan, W.Y., Fonstad, C.G., and Ren, F. Monolayer Be δ-doped heterostructure bipolar transistor fabricated using doping selective base contact p1187
Kuramata, A., Deri, R.J., Yasuoka, N., Makiuchi, M., and Wada, O. see Deri, R.J.
Kuramata, A., Wada, O., Kumai, T., Hamaguchi, H., Makiuchi, M., and Mikawa, T. see Wada, O.
Kuriyama, Y., Akagi, J., Morizuka, K., Asaka, M., Tsuda, K., Obara, M., and Yamakawa, H. see Akagi, J.
Kuriyama, Y., Yamakawa, H., Ibe, H., Akagi, J., Morizuka, K., and Obara, M. see Yamakawa, H.
Kurokawa, T., Lee, K.C., Cho, Y.B., and Takefuji, Y. CMOS layout design of the hysteresis McCulloch–Pitts neuron p2093
Kurosawa, M., Uetsuka, H., and Imoto, K. see Uetsuka, H.
Kusaka, H., Kominami, M., and Yakuwa, N. see Kominami, M.
Kusuda, Y., Tanaka, S., and Yamashita, K. Two-phase clock driven self-scanning light emitting device (SLED) p1406
Kusui, S., Kosukegawa, M., and Inoue, M. DC B–H curve tracer with error correction and constant measuring and drawing speed using microcomputer p902
Kusunoki, T., Sugano, M., Sudo, H., Soda, H., and Ishikawa, H. see Sugano, M.
Kusyk, R.G., Moore, T.E., and Krzymien, W.A. see Moore, T.E.
Kusyk, R.G., Moore, T.E., and Krzymien, W.A. Spectral analysis of waiting time jitter in the presence of stuff threshold modulation p526
Kuwahara, H., Naito, T., Chikama, T., and Ishikawa, G. see Naito, T.
Kvičera, V. Modified Lin formula for calculating fading caused by hydrometeors on terrestrial paths in Czechoslovakia p1176
Kwan, S., Sundaresan, H., Lord, A., Duncan, W.J., Henning, I.D., Stallard, W.A., and Broughton, C. see Sundaresan, H.
Kwok, S.C. Solution of Poisson equation in p-$Al_xGa_{1-x}As$/p-$Al_{0.45}Ga_{0.55}As$/n-GaAs structures p894
Kwon, Y., Pavlidis, D., Tutt, M., Ng, G.I., Lai, R., and Brock, T. W-band monolithic oscillator using InAlAs/InGaAs HEMT p1425
Kwon, Y.-J., and Kyung, C.-M. Algorithm for optimal layouts of CMOS complex logic modules p1388
Kwon, Y.-S., Yoo, H.-J., Hayes, J.R., Paek, E.G., Harbison, J.P., and Florez, L.T. see Yoo, H.-J.
Kwon, Y.-S., Yoo, H.-J., and Hayes, J.R. see Yoo, H.-J.
Kwong, D.L., Joshi, A.B., Lo, G.Q., and Xie, J. see Joshi, A.B.
Kwong, D.L., Joshi, A.B., and Lo, G.Q. see Joshi, A.B.
Kwong, D.L., Ting, W., and Lo, G.Q. see Ting, W.
Kwong, D.L., and Lo, G.Q. see Lo, G.Q.
Kwong, W.C., and Prucnal, P.R. 'Synchronous' CDMA demonstration for fibre-optic networks with optical processing p1990
Kyung, C.-M., Park, I.-C., and Hong, S.-K. see Park, I.-C.
Kyung, C.-M., and Kwon, Y.-J. see Kwon, Y.-J.

L

L'Haridon, H., Favennnec, P.N., Moutonnet, D., Salvi, M., and Papadopoulo, A.C. see Favennnec, P.N.
L'Haridon, H., Kechouane, M., Salvi, M., Favennec, P.N., Moutonnet, D., Gauneau, M., and Mercier, J.P. see Kechouane, M.
L'Haridon, H., Quemerais, A., Jezequel, G., Favennec, P.N., and Salvi, M. see Quemerais, A.
LaCourse, J., Rideout, W., Holmstrom, R., Meland, E., and Powazinik, W. see Rideout, W.
LaGasse, M.J., Griem, H.T., Fuji, H.S., Williams, T.J., Harrang, J.P., Daniels, R.R., Ray, S., and West, D.L. see Griem, H.T.
LaRochelle, S., Hibino, Y., Mizrahi, V., and Stegeman, G.I. All-optical switching of grating transmission using cross-phase modulation in optical fibres p1459
Lacaita, A., and Mastrapasqua, M. Strong dependence of time resolution on detector diameter in single photon avalanche diodes p2053
Lacquet, B.M., and Swart, P.L. Silicon-on-insulator thickness determination by parametric spectral estimation p1781
Ladbrooke, P.H., Hill, A.J., and Bridge, J.P. Negative R_s and R_d in GaAs FET and HEMT equivalent circuits p680
Lafragette, J.-L., Mersali, B., Gelly, G., Accard, A., Doussiere, P., Lambert, M., and Fernier, B. see Mersali, B.
agerström, B., Granestrand, P., Svensson, P., Thylén, L., Stoltz, B., Bergvall, K., Falk, J.-E., and Olofsson, H. see Granestrand, P.
Lai, R., Kwon, Y., Pavlidis, D., Tutt, M., Ng, G.I., and Brock, T. see Kwon, Y.
Lai, S.-L., Zhao, Z.-L., and Liu, A.-S. see Zhao, Z.-L.
Lai, S.-L., and Lin, W.-G. TM triple-mode microwave filter p2112
Laih, C.-S., and Lee, J.-Y. Efficient probabilistic public-key cryptosystem based on the Diffie–Hellman problem p326
Lallier, F., Pocholle, J.P., Papuchon, M., De Micheli, M., Li, M.J., He, Q., Ostrowsky, D.B., Grezes-Besset, C., and Pelletier, E. Efficient Nd : MgO : $LiNbO_3$ waveguide laser p927
Lam, S.P.S. Matrix and vector multiplications using a $2\frac{1}{2}$-dimensional systolic array p1453
Lambert, M., Mersali, B., Gelly, G., Accard, A., Lafragette, J.-L., Doussiere, P., and Fernier, B. see Mersali, B.
Lambert, M., Zamkotsian, F., Artigue, C., Peyre, J.-L., Lievin, J.-L., Bonnevie, D., and Benoit, J. see Zamkotsian, F.
Laming, R.I., Cowle, G.J., Morkel, P.R., and Payne, D.N. see Cowle, G.J.
Laming, R.I., Morkel, P.R., and Payne, D.N. see Morkel, P.R.
Laming, R.I., Richardson, D.J., and Payne, D.N. see Richardson, D.J.
Laming, R.I., Suyama, M., and Payne, D.N. see Suyama, M.
Lancefield, D., Crookes, C.G., Waterhouse, K., Adams, A.R., Greene, P.D., and Glew, R.W. see Crookes, C.G.
Landstorfer, F.M., and Stocker, K.E. see Stocker, K.E.
Landstorfer, F.M., and Zhu, N.Y. see Zhu, N.Y.
Lang, H., Illek, S., Thulke, W., Schanen, C., and Amann, M.-C. see Illek, S.
Langenhorst, R., Patzak, E., and Pieper, W. Balanced 3 × 3 port phase diversity receiver with reduced impact of thermal noise p595
Langmann, U., Wüppermann, B., and Pottbäcker, A. see Wüppermann, B.
Langmann, U., and Bußmann, M. see Bußmann, M.
Lapenta, G., Accornero, R., Artiglia, M., Coppa, G., Di Vita, P., Potenza, M., and Ravetto, P. see Accornero, R.
Lareau, R.D., Friedman, L., and Soref, R.A. Waveguided electro-optical intensity modulation in a $Si/Ge_xSi_{1-x}/Si$ heterojunction bipolar transistor p1653
Large, Y., Hardcastle, I., Davis, F., and Hadjifotiou, A. see Hardcastle, I.
Lau, P.-K., and Cohen, M.M. Characterisation of electromagnetic fields in buildings p1778
Lau, Y.-H., and Skellern, D.J. Calculation of third order intermodulation spectrum p1776
Lauer, R.B., Meland, E., Holmstrom, R., Schlafer, J., and Powazinik, W. see Meland, E.
Lauwers, L., Martino, J.A., Colinge, J.P., and De Meyer, K. see Martino, J.A.
Laverty, S.J., and Webb, J.A.C. see Webb, J.A.C.
Law, V.J., Matthews, P., Kelly, M.J., Hasko, D.G., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Lawandy, N.M., and Adler, C.L. see Adler, C.L.
Lawandy, N.M., and Selker, M.D. see Selker, M.D.
Laxpati, M.A. Multitone jamming of hybrid SFH/DS-MFSK communication systems p323
Laybourn, P.J.R., Krauss, T., and Roberts, J. see Krauss, T.
LeBlanc, H.P., Schumacher, H., Soole, J.B.D., Bhat, R., and Koza, M.A. see Schumacher, H.
LeBlanc, H.P., Soole, J.B.D., Tsang, H.K., White, I.H., Bhat, R., and Koza, M.A. see Soole, J.B.D.
Le Corre, A., Loualiche, S., Ginudi, A., Henry, L., Vaudry, C., and Clerot, F. see Loualiche, S.
Le Néel, O., and Haond, M. Electrical transient study of negative resistance in SOI MOS transistors p73
Learmouth, M.D., Hewett, N.P., Reid, I., and Robertson, M.J. Integrated dielectric wavelength filters on InGaAs PIN photodetectors p576
Learmouth, M.D., MacBean, M.D.A., Hewett, N.P., and Reid, I. see MacBean, M.D.A.
Leblanc, H.P., Shantharama, L.G., Schumacher, H., Esagui, R., Bhat, R., and Koza, M. see Shantharama, L.G.
Leblond, F., Perales, A., Goldstein, L., Accard, A., Fernier, B., Gourdain, C., and Brosson, P. see Perales, A.
Leclerc, D., Flaarønning, N., Frorud, J.O., Sotom, M., Vendrôme, G., Da Loura, G., Gabriagues, J.M., Jacquet, J., and Benoit, J. see Flaarønning, N.
Leclerc, E., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Lemaire, V., Gautheron, O., Grandpierre, G., and Gabla, P. see Clesca, B.
Lecluse, A., Bouregba, R., Lippens, D., Palmateer, L., Bockenhoff, E., Bogey, M., and Destombes, J.L. see Bouregba, R.
Lee, C., and Ravaioli, U. Monte Carlo comparison of heterojunction cathode Gunn oscillators p425
Lee, C.-Y., Tzuang, C.-K.C., and Kuo, J.-T. see Tzuang, C.-K.C.
Lee, C.W., and Hur, J. see Hur, J.
Lee, G.S., and Zhou, P. see Zhou, P.
Lee, H., and Ngo, B. see Ngo, B.
Lee, H.P., Liu, X., and Wang, S. see Liu, X.
Lee, J.-Y., and Laih, C.-S. see Laih, C.-S.
Lee, J.I., Lee, M.B., Kang, K.N., and Park, K.O. Simple extraction method for mobility parameters in Si-MOSFETs at 77 K p852
Lee, J.I., Lee, M.B., Lee, Y.J., Han, I.K., Kang, K.N., and Park, K.O. Simple method to extract gate voltage dependent source/drain resistance in MOSFETs p1806
Lee, J.J., Ng, W., Walston, A., Tangonan, G., and Newberg, I. see Ng, W.
Lee, K.C., Kurokawa, T., Cho, Y.B., and Takefuji, Y. see Kurokawa, T.
Lee, K.F., Lee, R.Q., and Talty, T. see Lee, R.Q.
Lee, K.F., Lee, R.Q., and Talty, T. Microstrip subarray with coplanar and stacked parasitic elements p668
Lee, K.F., and Fan, Z. see Fan, Z.
Lee, L.-S., Chen, G.-S., and Wu, J.-L. see Chen, G.-S.
Lee, L.-S., and Chiu, J.-H. see Chiu, J.-H.
Lee, L.H.C. Computation of the right-inverse of $G(D)$ and the left-inverse of $H(D)$ p904
Lee, L.H.C. Rate 1/2 180° phase-invariant convolutional coding with differentially-encoded coherent QPSK for band-limited AWGN channels p1141
Lee, M.B., Lee, J.I., Kang, K.N., and Park, K.O. see Lee, J.I.
Lee, M.B., Lee, J.I., Lee, Y.J., Han, I.K., Kang, K.N., and Park, K.O. see Lee, J.I.
Lee, M.H., and Yasuda, Y. Simple systolic array algorithm for Hadamard transform p1478
Lee, P., and O'Leary, P. Fault detection method using power supply spectrum analysis p1733
Lee, R.Q., Lee, K.F., and Talty, T. see Lee, K.F.
Lee, R.Q., Talty, T., and Lee, K.F. Circular polarisation characteristics of stacked microstrip antennas p2109
Lee, R.Q., and Simons, R.N. see Simons, R.N.
Lee, S.-C., and Yih, S.-J. see Yih, S.-J.
Lee, T., Li, R., and Kong, S.H. Recognising partially occluded objects by rigid body relaxation matching p856
Lee, T., and Chung, F.L. Determining the number of hidden nodes by progressive training p1318
Lee, T.-H. Behaviour of circuit-switched multistage network in presence of memory hot spot d546
Lee, T.-H. Behaviour of circuit-switched multistage networks in presence of memory hot spot d546
Lee, T.-H. Performance of multistage interconnection networks for integrated services p495
Lee, T.-H. Simple implementation of load-sharing banyan network and its throughput performance p79
Lee, T.-H. Throughput performance of multistage interconnection networks in presence of multiple memory hot spots p536
Lee, T.-H., and Chou, J.-J. Approximate expression for normalised throughput of multistage interconnection networks p2031
Lee, T.-H., and Hu, J.-K. Throughput performance of some continuous ARQ schemes with memory p1972
Lee, T.H. Some continuous multidestination ARQ schemes for high error rate conditions p1686
Lee, T.P., Lo, Y.H., Bagheri, M., Lin, P.S.D., Grabbe, P., Bhat, R., Stoffel, N.G., and Kong, D.T. see Lo, Y.H.
Lee, T.P., Reichenbach, D., Zah, C.E., Andreadakis, N., Favire, F.J., Menocal, S.G., Vodhanel, R., and Yi-Yan, A. see Reichenbach, D.
Lee, W.S., Spear, D.A.H., Agnew, M.J., Dawe, P.J.G., and Bland, S.W. 1·2 Gbit/s fully integrated transimpedance optical receiver OEIC for 1·3–1·55 μm transmission systems p377
Lee, W.S., Spear, D.A.H., Dawe, P.J.G., and Bland, S.W. Monolithic integration of an InP/InGaAs four-channel transimpedance optical receiver array p1833
Lee, Y.H., Jewell, J.L., Tell, B., Brown-Goebeler, K.F., Scherer, A., Harbison, J.P., and Florez, L.T. Effects of etch depth and ion implantation on surface emitting microlasers p225
Lee, Y.H., Tell, B., Brown-Goebeler, K., Jewell, J.L., Leibenguth, R.E., Asom, M.T., Livescu, G., Luther, L., and Mattera, V.D. High efficiency (1·2 mW/mA) top-surface-emitting GaAs quantum well lasers p1308
Lee, Y.H., Tell, B., Brown-Goebeler, K., Jewell, J.L., and Hove, J.V. Top-surface-emitting GaAs four-quantum-well lasers emitting at 0·85 μm p710
Lee, Y.J., Lee, J.I., Lee, M.B., Han, I.K., Kang, K.N., and Park, K.O. see Lee, J.I.
Lee Russell, J., Kellert, F., Ehlers, E., and Monahan, D. Improved InP/InGaAs/InP *pin* detector response using a transparent conductor contact p1231
Leeb, W.R. Optical 90° hybrid for Costas-type receivers p1431
Leech, P.W., Gwynn, P.J., Pain, G.N., Petkovic, N., and Thompson, J. MESFET fabrication on MOCVD grown $Hg_{1-x}Cd_xTe$ p221
Leech, P.W., Petkovic, N., Gwynn, P.J., Pain, G.N., and Thompson, J. Metal–semiconductor–metal (MSM) photodetectors fabricated on MOCVD grown $Hg_{1-x}Cd_xTe$ p1848
Lefedjiev, A.K., Leisten, J.M., and Hobson, L. see Leisten, J.M.
Lefevre, H., Delavaux, J.-M.P., Park, Y.K., Barski, S., Failes, M., and Warner, C. see Delavaux, J.-M.P.
Leggatt, J.S., Sheat, D.E., and McCartney, D.J. see Sheat, D.E.
Legier, J.F., Paleczny, E., Kinowski, D., Pribetich, P., and Kennis, P. see Paleczny, E.
Legry, P., Cappy, A., Dambrine, G., Cordier, Y., and Druelle, Y. see Cappy, A.

Leibenguth, R.E., Lee, Y.H., Tell, B., Brown-Goebeler, K., Jewell, J.L., Asom, M.T., Livescu, G., Luther, L., and Mattera, V.D. see Lee, Y.H.
Leigh, S.P., Mellor, P.H., and Cheetham, B.M.G. Distortion minimisation in pulse width modulated systems using a digital sampling process p1310
Leisten, J.M., Lefedjiev, A.K., and Hobson, L. Single ended resonant power supply for induction heating p814
Lemaire, V., Clesca, B., Auge, A., Biotteau, B., Bousselet, P., Dursin, A., Clergeaud, C., Kretzmeyer, P., Gautheron, O., Grandpierre, G., Leclerc, E., and Gabla, P. see Clesca, B.
Lemberg, H.L., Menendez, R.C., and Wagner, S.S. see Menendez, R.C.
Leme, C.A., and Franca, J.E. High performance CMOS comparator for analogue-digital convertors p1725
Leme, C.A., and Franca, J.E. Minimum area analogue-digital calibration network for high-resolution data converters p1491
Lenth, W., Krantz, M.C., and Rosen, H.J. see Krantz, M.C.
Leong, M.S., Yeo, T.S., Kooi, P.S., and Ng, S.S. see Yeo, T.S.
Leroy, A., Vanbremeersch, J., Constant, E., Zimmermann, J., Valin, I., and Godts, P. see Vanbremeersch, J.
Leung, V.C.M. Multichannel reservation protocol for packet multiple-access communications p1637
Lever, K.V., Taori, R., and Cain, G.D. see Taori, R.
Levi, A.F.J., Hobson, W.S., O'Gorman, J., Pearton, S.J., Abernathy, C.R., and Swaminathan, V. see Hobson, W.S.
Levi, A.F.J., and O'Gorman, J. see O'Gorman, J.
Levinson, M., Rossoni, P., Rock, F., and Ditchek, B.M. High voltage floating gate array transistors p777
Levy, M.F. Parabolic equation modelling of propagation over irregular terrain p1153
Lewis, A.S., and Knowles, G. Video compression using 3D wavelet transforms p396
Lewis, C.P., and Bridgett, N. see Bridgett, N.
Lewis, C.P., and Mathew, M.I. see Mathew, M.I.
Lewis, N., Chao, P.C., Ho, P., Duh, K.H.G., Smith, P.M., Ballingall, J.M., Jabra, A.A., and Hall, E.L. see Chao, P.C.
Lewis, R.B.J., Bryant, E.G., Carter, S.F., Spirit, D.M., Widdowson, T., and Wright, J.V. see Bryant, E.G.
Li, E.H., Liu, C.K., and Ng, H.C. Effect of statistical variation on threshold voltage in narrow-channel MOSFETs p1390
Li, H., and Chen, C.-H. Silicon implementation of a function of visual peripheral processes p2013
Li, H., and Telle, H.R. see Telle, H.R.
Li, J., and Manikopoulos, C.N. Nonlinear prediction in image coding with DPCM p1357
Li, M.J., Lallier, E., Pocholle, J.P., Papuchon, M., De Micheli, M., He, Q., Ostrowsky, D.B., Grezes-Besset, C., and Pelletier, E. see Lallier, E.
Li, R., Lee, T., and Kong, S.H. see Lee, T.
Li, S., and Rong, A. see Rong, A.
Li, S.F., Shen, Z.X., and Lou, X.M. see Shen, Z.X.
Liberali, V., Gatti, U., Maloberti, F., and O'Leary, P. see Gatti, U.
Licht, S.J., Stone, J., Jopson, R.M., and Stulz, L.W. see Stone, J.
Lievin, J.-L., Zamkotsian, F., Artigue, C., Peyre, J.-L., Lambert, M., Bonnevie, D., and Benoit, J. see Zamkotsian, F.
Liew, S.K., Carlson, N.W., Patterson, D.R., Stabile, P.J., Bour, D.P., and Evans, G.A. see Carlson, N.W.
Liew, S.K., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Lim, B.K., and Un, C.K. Continuous adaptive speech analysis based on a time-varying ARMA model p674
Lim, B.L., Hui, S.K., and Lim, Y.L. Bearing estimation of coherent sources by circular spatial modulation averaging (CSMA) technique p343
Lim, Y.C., and Tan, Y.K. see Tan, Y.K.
Lim, Y.L., Lim, B.L., and Hui, S.K. see Lim, B.L.
Lin, C., Way, W.I., Maeda, M.W., Yi-Yan, A., Andrejco, M.J., Choy, M.M., and Saifi, M. see Way, W.I.
Lin, C.L., Wieder, H.H., and Zuleeg, R. Anisotype, enhancement-mode, heterojunction gate field-effect transistors p846
Lin, H.Y., and Harn, L. see Harn, L.
Lin, M.-C., Chang, T.-C., and Fu, H.-L. Information rate of McEliece's public-key cryptosystem p16
Lin, M.-C., and Chi, S. see Chi, S.
Lin, M.S., Engvik, A.H., and Loos, J.S. Measurements of crosstalk between closely-packed lossy microstrips on silicon substrates p714
Lin, M.S., Engvik, A.H., and Tai, K.L. Measurements of pulse propagation on unterminated lossy microstrips with small dimensions p747
Lin, M.S., Paterson, A.S., and Ghaffari, H.T. Cryogenic performance of a CMOS 32-bit microprocessor subsystem built on the silicon-substrate-based multichip packaging technology p1025
Lin, M.S., Twu, Y., Wang, S.J., Kuo, C.Y., Wynn, J.D., Brown, R.L., Gruezke, L.A., Strege, K.E., and Dutta, N.K. see Twu, Y.
Lin, P.S.D., Hong, W.-P., Kim, O.-H., Bhat, R., Van Der Gaag, B., and Schumacher, H. Self-aligned 0·25 μm W/Ti/Au gate process for high-performance pseudomorphic InAlAs/InGaAs HEMT p763
Lin, P.S.D., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Zah, C.E., Caneau, C., Menocal, S.G., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.
Lin, P.S.D., Lo, Y.H., Bagheri, M., Grabbe, P., Bhat, R., Stoffel, N.G., Lee, T.P., and Kong, D.T. see Lo, Y.H.
Lin, T.-K., Liu, S.-I., Tsao, H.-W., and Wu, J. see Liu, S.-I.
Lin, W., Huang, Y., and Xue, L. see Huang, Y.
Lin, W., and Huang, K.M. see Huang, K.M.
Lin, W.-G., and Lai, S.-L. see Lai, S.-L.
Lin, Z.-Q., and Chang, W.S.C. Reduction of intermodulation distortion of interferometric optical modulators through incoherent mixing of optical waves p1980
Lindell, I.V., and Sihvola, A.H. see Sihvola, A.H.
Liou, K.-Y., and Burrows, E.C. see Burrows, E.C.
Liou, L.L., and Huang, C.I. Using constant base current as a boundary condition for one-dimensional AlGaAs/GaAs heterojunction bipolar transistor simulation p1501
Lippens, D., Bouregba, R., Palmateer, L., Bockenhoff, E., Bogey, M., Destombes, J.L., and Lecluse, A. see Bouregba, R.
Lippens, D., De Saint Pol, L., and Vanbesien, O. see De Saint Pol, L.
Littmann, B., and Mönich, G. see Mönich, G.
Litva, J., Bi, Z.-Q., and Wu, K.-L. see Bi, Z.-Q.
Litva, J., Wang, J., Fralich, R., and Wu, G. see Wang, J.
Litva, J., and Wu, K.-L. see Wu, K.-L.
Liu, A.-S., Zhao, Z.-L., and Lai, S.-L. see Zhao, Z.-L.
Liu, B.-D., and Shaw, G.-T. Fault equivalence in PLAs and prevention design p1925
Liu, C.K., Li, E.H., and Ng, H.C. see Li, E.H.
Liu, D.C., and Nikoonahad, M. see Nikoonahad, M.
Liu, G.-S., and Wei, C.-H. Programmable fractional sample delay filter with Lagrange interpolation p1608
Liu, J., Jaggard, D.L., and Engheta, N. see Jaggard, D.L.
Liu, K., Fesler, K., Digonnet, M., Kim, B.Y., and Shaw, H.J. see Fesler, K.
Liu, L., Woodhead, J., Claxton, P.A., Grey, R., Sale, T.E., David, J.P.R., Pate, M.A., Hill, G., and Robson, P.N. see Woodhead, J.
Liu, S.-I., Tsao, H.-W., Wu, J., and Lin, T.-K. MOSFET capacitor filters using unity gain CMOS current conveyors p1430
Liu, S.-I., Tsao, H.-W., and Wu, J. Cascadable current-mode single CCII biquads p2005
Liu, S.G., Taylor, G.C., Klatskin, J., Camisa, R.L., and Capewell, D.R. High-efficiency GaAs microwave power MESFETs with an n^+n^-n doping formed by buried-shallow-implant (BSI) p1373
Liu, W.U., Costa, D., and Harris, J. Novel doubly self-aligned AlGaAs/GaAs HBT p1361
Liu, W.U., Hill, D., Costa, D., and Harris, Jun, J.S. High frequency *Pnp* AlGaAs/InGaAs heterojunction bipolar transistor with an ultrathin strained base p2000
Liu, X., Lee, H.P., and Wang, S. Double-heterostructure AlGaAs/GaAs lasers grown on the mesas of trenched Si substrate by molecular beam epitaxy p590
Liu, Y., Soraghan, J.J., and Durrani, T. Parameter estimation using cumulants p820
Livescu, G., Lee, Y.H., Tell, B., Brown-Goebeler, K., Jewell, J.L., Leibenguth, R.E., Asom, M.T., Luther, L., and Mattera, V.D. see Lee, Y.H.
Lleida, E., and Nadeu, C. see Nadeu, C.
Lo Presti, L., and Visintin, M. Design of IIR group delay equalisers p200
Lo, C.N., Tohme, H.E., and Saifi, M.A. see Tohme, H.E.
Lo, G.Q., Joshi, A.B., Kwong, D.L., and Xie, J. see Joshi, A.B.
Lo, G.Q., Joshi, A.B., and Kwong, D.L. see Joshi, A.B.
Lo, G.Q., Ting, W., and Kwong, D.L. see Ting, W.
Lo, G.Q., and Kwong, D.L. Effects of reoxidation on the hot-carrier immunity of 0·6 μm MOSFETs with nitrided oxides p1470
Lo, G.Q., and Kwong, D.L. Gate oxide thickness dependence of high-field-induced interface state generation in thin thermal oxides p1124
Lo, K.W. Null steering in monopulse planar array using amplitude only control p1700
Lo, K.W. Reducing the effect of pointing errors on the performance of an adaptive array p1646
Lo, Y.H., Bagheri, M., Lin, P.S.D., Grabbe, P., Bhat, R., Stoffel, N.G., Lee, T.P., and Kong, D.T. High performance submicron pseudo-MODFETs and 2:1 multiplexers using GaAs on InP heteroepitaxial technology p807
Lobbett, R.A., Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Wyatt, R., Massicott, J.F., Smith, P., and Hodgkinson, T.G. see Hill, A.M.
Lobbett, R.A., Hill, A.M., Wyatt, R., Massicott, J.F., Blyth, K.J., Forrester, D.S., Smith, P.J., and Payne, D.B. see Hill, A.M.
Logan, R.A., Andrekson, P.A., Olsson, N.A., Simpson, J.R., Tanbun-Ek, T., Becker, P.C., and Wecht, K.W. see Andrekson, P.A.
Loh, W.H., Schremer, A.T., and Tang, C.L. Hysteresis and multistable behaviour in a polarisation self-modulated external ring cavity semiconductor laser p1666
Longère, J.Y., Schütz, R., Matsushita, K., Hartnagel, H.L., and Krawczyk, S.K. see Schütz, R.
Longenbach, K.F., Luo, L.F., and Wang, W.I. see Luo, L.F.
Loni, A., Keys, R.W., De La Rue, R.M., Ironside, C.N., Marsh, J.H., Luff, B.J., and Townsend, P.D. see Keys, R.W.
Loni, A., Keys, R.W., and De La Rue, R.M. see Keys, R.W.
Loos, J.S., Lin, M.S., and Engvik, A.H. see Lin, M.S.
Lootens, D., Pollentier, I., Buydens, L., Ackaert, A., Demeester, P., Van Daele, P., De Pestel, F., and Baets, R. see Pollentier, I.
Lopata, J., Dutta, N.K., Wynn, J.D., Sivco, D.L., and Cho, A.Y. see Dutta, N.K.
Lopes, L.B. Performance of the DECT system in fading dispersive channels p1416
Lord, A., Boggis, J., Violas, M., Heatley, D., and Stallard, W.A. see Boggis, J.
Lord, A., Sundaresan, H., Kwan, S., Duncan, W.J., Henning, I.D., Stallard, W.A., and Broughton, C. see Sundaresan, H.
Lord, A., Wilkinson, I.J., Ellis, A., Cleland, D., Garnham, R.A., and Stallard, W.A. Comparison of WDM coupler technologies for use in erbium doped fibre amplifier systems p900
Lothian, J., Ren, F., Abernathy, C.R., Pearton, S.J., Fullowan, T.R., and Jordan, A.S. see Ren, F.
Lott, J.A., Klem, J.F., Weaver, H.T., Tigges, C.P., and Radoslovich-Cibicki, V. Charge storage in InAlAs/InGaAs/InP floating gate heterostructures p972
Lou, X.M., Shen, Z.X., and Li, S.F. see Shen, Z.X.
Loualiche, S., Clerot, F., and Audibert, G. 40 GHz measurement on InP/air gap line by picosecond electro-optic sampling p266
Loualiche, S., Le Corre, A., Ginudi, A., Henry, L., Vaudry, C., and Clerot, F. Pseudomorphic GaInP Schottky diode and MSM detector on InP p487
Lourtioz, J.-M., Yang, D.D., Boucaud, P., Julien, F.H., Chusseau, L., and Planel, R. see Yang, D.D.
Lourtioz, J.M., Chusseau, L., Bouchon, D., and Duvillaret, L. see Chusseau, L.
Lourtioz, J.M., Chusseau, L., Xie, J.M., Duvillaret, L., Accard, A., and Hebert, J-P. see Chusseau, L.
Louw, W., Bortz, G., and van Schalkwyk, J.J. see Bortz, G.
Love, J.D., and Henry, W.M. Excess loss in practical depressed-cladding fibres p727 d1546
Lowe, K.S. High speed GaAs 32 × 8 embeddable dual port SRAM register array for 200 Mbyte/s packet switching applications p516
Lowery, A.J. Time-resolved chirp in mode-locked semiconductor lasers p939
Lowery, A.J., and Marshall, I.W. Stabilisation of mode-locked pulses using travelling-wave semiconductor laser amplifier p104
Lowery, A.J., and Scaramuzza, R. see Scaramuzza, R.
Lowney, C.M., Bhumbra, B.S., Glew, R.W., Greene, P.D., Henshall, G.D., and Whiteaway, J.E.A. see Bhumbra, B.S.
Lu, E.-H., Hsieh, C.-H., Lu, P.-C., and Shyn, J.-S. see Hsieh, C.-H.
Lu, P.-C., Hsieh, C.-H., Shyn, J.-S., and Lu, E.-H. see Hsieh, C.-H.
Lu, W.X., Young, M.C.J., Tredgold, R.H., Hodge, P., and Abbasi, F. see Young, M.C.J.
Lu, Y. New method of analysing transient processes in picosecond photoconductive switch p444
Lu, Y., and Fernandez, F.A. see Fernandez, F.A.
Lucas, T.N., and Beat, I.F. Model reduction by least-squares moment matching p1213
Luck, J., and Swanson, J.G. First-order, switched-capacitor, low-pass filter implemented with GaAs insulated-gate FET switches p1843
Ludwig, R., Moehrle, M., Rosenzweig, M., Schnabel, R., Schunk, N., and Weber, H.G. Optical travelling wave amplifiers with multi-section semiconductor-laser structures p1704
Luff, B.J., Keys, R.W., Loni, A., De La Rue, R.M., Ironside, C.N., Marsh, J.H., and Townsend, P.D. see Keys, R.W.
Lui, F., Betts, R.A., and Gauja, E. see Betts, R.A.
Lui, F., and Betts, R.A. see Betts, R.A.
Luk, W. Systolic band-matrix multipliers p403
Lum, R.M., Jeong, J., Klingert, J.K., Bylsma, R., Vella-Coleiro, G.P., and Smith, P.R. see Jeong, J.
Lun, D.P.-K., and Siu, W.-C. Novel mapping scheme for transforms with lengths equal to products of prime squares p21
Lunardi, L.M., Archer, V.D., Swartz, R.G., Kuo, J.M., Kopf, R.F., Malik, R.J., and Smith, P.R. High speed linear array circuit with AlGaAs/GaAs heterojunction bipolar transistors (HBTs) p1157
Luo, L.F., Longenbach, K.F., and Wang, W.I. Kink-free AlInAs/GaInAs/InP HEMTs grown by molecular beam epitaxy p779
Lurie, M., Evans, G.A., Carlson, N.W., Bour, D.P., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Lurie, M., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., Reichert, W.F., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.
Luther, L., Lee, Y.H., Tell, B., Brown-Goebeler, K.,

Jewell, J.L., Leibenguth, R.E., Asom, M.T., Livescu, G., and Mattera, V.D. see Lee, Y.H.
Lutovac, M., and Rabrenović, D. see Rabrenović, D.
Lutovac, M., and Rabrenović, D. Improved version of the inverse Chebyshev filter p1256
Luy, J.-F. IMPATT operation below the avalanche frequency p1960

M

Mørk, J., Semkow, M., and Tromborg, B. Measurement and theory of mode hopping in external cavity lasers p609 e1324
Ma, W. Algorithm for computing two-dimensional discrete Hartley transform of size $p^a \times p^a$ p1795
MacBean, M.D.A., Hewett, N.P., Learmouth, M.D., and Reid, I. Planar InP/InGaAs avalanche photodetector with integrated dielectric wavelength filter p804
MacChesney, J.B., Ko, Y.T., DiGiovanni, D.J., and Simpson, J.R. see Ko, Y.T.
Macbeth, I.C., Hughes, B., and Pattullo, D.M. see Hughes, B.
Mackenzie, H.S., and Payne, F.P. Evanescent field amplification in a tapered single-mode optical fibre p130
Mackenzie, H.S., and Payne, F.P. Saturable absorption in a tapered single-mode optical fibre p1744
Maclean, T.S.M., Gong, J., and Wu, Z. see Gong, J.
Maclean, T.S.M., Wu, Z., Jayasundere, N., Carter, L.J., and Williamson, A.G. see Wu, Z.
Maeda, M.W., Chang-Hasnain, C.J., Stoffel, N.G., Harbison, J.P., Florez, L.T., and Jewell, J. see Chang-Hasnain, C.J.
Maeda, M.W., Way, W.J., Yi-Yan, A., Andrejco, M.J., Choy, M.M., Saifi, M., and Lin, C. see Way, W.I.
Maekawa, Y., Chang, N.S., Miyazaki, A., and Segawa, T. Effects of ice depolarisation on Ka-band satellite–earth path in stratus rainfall events p2006
Magari, K., Noguchi, Y., Okamoto, K., Yasaka, H., Nagai, H., and Mikami, O. High efficiency 1·3 μm superluminescent diode with absorbing tapered waveguide p1445
Magistrali, F., Canali, C., Sangalli, M., Tedesco, C., and Zanoni, E. see Canali, C.
Magistrali, F., Canali, C., Tedesco, C., Zanoni, E., Castellaneta, G., and Sangalli, M. see Canali, C.
Maglaras, C., Toumazou, C., and Battersby, N.C. see Toumazou, C.
Mahbobzadeh, M., and Osiński, M. Novel distributed-feedback resonant-periodic-gain structure for vertical-cavity surface-emitting semiconductor lasers p1716
Mahdavi, S.M., and Townsend, P.D. Optical activity induced in $Bi_4Ge_3O_{12}$ waveguides by ion implantation p371
Mahoney, L.J., Turner, G.W., Chen, C.L., Connors, M.K., and McGilvary, W.L. see Turner, G.W.
Maiti, C.K., Ray, S.K., and Chakrabarti, N.B. see Ray, S.K.
Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Silverman, S., Weng, S., Pao, Y.C., Zdasiuk, G., Bandy, S., and Tan, Z. 94 GHz InP MMIC five-section distributed amplifier p91
Makino, T. Analysis of the spontaneous emission rate of multiple-phase-shift distributed feedback semiconductor lasers p629
Makiuchi, M., Deri, R.J., Yasuoka, N., Kuramata, A., and Wada, O. see Deri, R.J.
Makiuchi, M., Wada, O., Kumai, T., Hamaguchi, H., Kuramata, A., and Mikawa, T. see Wada, O.
Makrakis, D., and Feher, K. Optimal noncoherent detection of PSK signals p398
Makris, C.A., and Toumazou, C. Current-mode active compensation techniques p1792
Malacký, L., and Novák, J. see Novák, J.
Malaiya, Y.K., Menon, S.M., and Jayasumana, A.P. see Menon, S.M.
Malherbe, J.A.G., and Coetzee, J.C. see Coetzee, J.C.
Malherbe, J.A.G., and de Villiers, M.C. see de Villiers, M.C.
Malik, R.J., Lunardi, L.M., Archer, V.D., Swartz, R.G., Kuo, J.M., Kopf, R.F., and Smith, P.R. see Lunardi, L.M.
Malloy, K.J., Hsin, W., Du, G., Gamelin, J.K., Wang, S., Whinnery, J.R., Yang, Y.J., Dziura, T.G., and Wang, S.C. see Hsin, W.
Malo, B., Hill, K.O., Vineberg, K.A., Bilodeau, F., Johnson, D.C., and Skinner, I. see Hill, K.O.
Maloberti, F., Gatti, U., Liberali, V., and O'Leary, P. see Gatti, U.
Maloberti, F., and O'Leary, P. see O'Leary, P.
Malvar, H.S. Modulated QMF filter banks with perfect reconstruction p906
Malyan, A.D., and Brewster, R.L. Medium access control protocol for the integration of voice/data on a local area network p592
Malyon, D.J., and Stallard, W.A. Multichannel FSK experiment using an optical amplifier repeater and wavelength tunable direct detection receiver p1863
Manasson, V.A., Kovalyuk, Z.D., Drapak, S.I., and Katerinchuk, V.N. Polarisation-sensitive photodiode for the 632·8 nm spectral region p664
Manasson, V.A., Tovstyuk, K.D., and Shuster, E.M. Chaotic behaviour in an illuminated semiconductor–(thin insulator)–semiconductor structure p1391
Mand, R.S., Bolognesi, C.R., and Boothroyd, A.R. see Bolognesi, C.R.
Manetti, S., Forti, M., and Marini, M. see Forti, M.
Manetti, S., and Avitabile, G. see Avitabile, G.
Manikopoulos, C.N., Antoniou, G.E., and Mentzelopoulou, S.E. see Antoniou, G.E.
Manikopoulos, C.N., and Li, J. see Li, J.
Mannaerts, J.P., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Mantz, J., Hager, H., Chan, E., and Hong, C.S. Single quantum well edge emitting broadband LED p1807
Mao, Z.Q., Selviah, D.R., and Midwinter, J.E. see Selviah, D.R.
Mar, A., Derickson, D.J., and Bowers, J.E. see Derickson, D.J.
Mar, A., Morton, P.A., and Bowers, J.E. Optimum facet reflectivity for high speed lasers p1382 e1922
Marcerou, J.F., Fevrier, H., Auge, J., Ramos, J., and Dursin, A. Feasibility demonstration of low pump power operation for 1·48 μm diode-pumped erbium-doped fibre amplifier module p1102
Marincic, A., Ata, O.W., and Benson, T.M. see Ata, O.W.
Marini, M., Forti, M., and Manetti, S. see Forti, M.
Markarian, G., and Honary, B. see Honary, B.
Marrone, M.J., and Kersey, A.D. see Kersey, A.D.
Marsan, M.J., Hess, G.C., and Gilbert, S.S. Shadowing variability in an urban land mobile environment at 900 MHz p646
Marschall, P., Dämbkes, H., Zhang, Y.H., and Ploog, K. see Dämbkes, H.
Marsh, E.M., Cole, S., Duncan, W.J., Skevington, P.J., and Spiller, G.D.T. see Cole, S.
Marsh, J.H., Keys, R.W., Loni, A., De La Rue, R.M., Ironside, C.N., Luff, B.J., and Townsend, P.D. see Keys, R.W.
Marsh, J.H., McIlvaney, K., Roberts, J.S., and Button, C. see McIlvaney, K.
Marsh, J.H., O'Neill, M., De La Rue, R.M., Roberts, J.S., Button, C., and Gwilliam, R. see O'Neill, M.
Marsh, O.J., Ismail, M.S., Bower, R.W., and Veteran, J.L. see Ismail, M.S.
Marshall, I.W., and Lowery, A.J. see Lowery, A.J.
Marsi, S., Sicuranza, G.L., and Ramponi, G. see Sicuranza, G.L.
Marsland, R.A., Shakouri, M.S., and Bloom, D.M. Millimetre-wave second harmonic generation on a nonlinear transmission line p1235
Martin, F., Fabre, A., and Hanafi, M. see Fabre, A.
Martin, J.T.H. St., Antar, Y.M.M., Kishk, A.A., Ittipiboon, A., and Cuhaci, M. Dielectric resonator antenna using aperture coupling p2015
Martinelli, M., Höök, A., Bolle, A., and Grosso, G. see Höök, A.
Martinez, P., Carlosena, A., Porta, S., and Celma, S. Latch-up property and dynamic stability in sinusoidal oscillators p542
Martinez, R.D., York, R.A., and Compton, R.C. see York, R.A.
Martino, J.A., Lauwers, L., Colinge, J.P., and De Meyer, K. Model for the potential drop in the silicon substrate for thin-film SOI MOSFETs p1462
Martins, R.B., Henoc, P., and Akamatsu, B. SEM direct observation of the degradation in Ga(Al)As GRIN-SCH lasers grown on a silicon substrate p448
Marty, A., Giroult-Matlakowski, G., Degors, N., Chantre, A., and Nouailhat, A. see Giroult-Matlakowski, G.
Marty, A., Vannel, J.P., Tasselli, J., Cazarré, A., and Bailbé, J.P. see Vannel, J.P.
Maruyama, O., Aoki, H., and Asahara, Y. see Aoki, H.
Marwood, W. Generalised systolic ring serial floating point multiplier p753
Maskara, S.L., and Chakrabarti, S. see Chakrabarti, S.
Maslamani, S., and Ghanbari, M. Digital demodulation by a non-coherent differential PSK modem p2028
Massicott, J.F., Armitage, J.R., Wyatt, R., Ainslie, B.J., and Craig-Ryan, S.P. High gain, broadband, 1·6 μm Er^{3+} doped silica fibre amplifier p1645
Massicott, J.F., Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Wyatt, R., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. see Hill, A.M.
Massicott, J.F., Hill, A.M., Wyatt, R., Blyth, K.J., Forrester, D.S., Lobbett, R.A., Smith, P.J., and Payne, D.B. see Hill, A.M.
Massicott, J.F., Wyatt, R., Ainslie, B.J., and Craig-Ryan, S.P. Efficient, high power, high gain, Er^{3+} doped silica fibre amplifier p1038
Mastrapasqua, M., and Lacaita, A. see Lacaita, A.
Masuda, H., and Takada, A. High gain two-stage amplification with erbium-doped fibre amplifier p661
Masuda, I., Yanagita, H., Yamashita, T., and Toratani, H. see Yanagita, H.
Masumoto, H., and Okamoto, E. see Okamoto, E.
Materna, D.M., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Parr, R.J., Stevens, M.L., and White, D.W. see Alexander, S.B.
Mathew, M.I., and Lewis, C.P. Noise performance comparison for third and fourth order cascaded sigma–delta modulators having parameter tolerance errors p158
Matic, M., Djuric, Z., Jovic, V., and Jaksic, Z. see Djuric, Z.
Maton, P.D., Scrivener, P.L., Appleyard, A.P., and Tarbox, E.J. see Scrivener, P.L.
Matsubara, H., Shima, A., Kamizato, T., Takami, A., Karakida, S., and Isshiki, K. see Shima, A.
Matsui, T., Ohishi, T., Abe, Y., Sugimoto, H., and Ohtsuka, K. see Ohishi, T.
Matsumoto, H., Tang, Z., and Ishizuka, O. see Tang, Z.
Matsumoto, T., Noguchi, K., Hogari, K., and Sakano, T. see Noguchi, K.
Matsumoto, T., and Koga, M. Novel learning method for analogue neural networks p1136
Matsunaga, H., Obara, H., Okamoto, S., and Uematsu, H. see Obara, H.
Matsunaga, H., Obara, H., Uematsu, H., and Okamoto, S. see Obara, H.
Matsuoka, A., Fujita, S., Suzaki, T., Miyazaki, S., Torikai, T., Nakata, T., and Shikada, M. see Fujita, S.
Matsushima, Y., Tanaka, H., and Suzuki, M. see Tanaka, H.
Matsushita, K., Schütz, R., Hartnagel, H.L., Longère, J.Y., and Krawczyk, S.K. see Schütz, R.
Mattera, V.D., Lee, Y.H., Tell, B., Brown-Goebeler, K., Jewell, J.L., Leibenguth, R.E., Asom, M.T., Livescu, G., and Luther, L. see Lee, Y.H.
Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. Two-dimensional electron gas base hot electron transistor p862
Mattingly, M., Aina, L., Serio, M., Hempfling, E. and Chien, H. see Aina, L.
Mattingly, M., Aina, O., Serio, M., and Hempfling, E. see Aina, O.
Maundy, B., and El-Masry, E. Switched-capacitor neural networks using pulse based arithmetic p1118
Maurel, R., Juy, M., Rooryck, M., Nugroho, I.A., and Hariman, T. see Juy, M.
Mawira, A. Slant path 30 to 12·5 GHz copolar phase difference, first results from measurements using the Olympus satellite p1138
Mayer, B. New broadband branchline coupler p1477
Mayer, B., and Knöchel, R. Microstrip balanced diode mixers for X-band frequencies p1272
Mazed, M., Ungar, J., Bar-Chaim, N., Mittelstein, M., Oh, S., and Ury, I. see Ungar, J.
Maziar, C.M., Tasch, A.F., and Shin, H. see Tasch, A.F.
McCallum, J., Townsend, P.D., Chandler, P.J., Wood, R.A., Zhang, L., and McHargue, C.W. see Townsend, P.D.
McCarthy, D.K., Dissanayake, A.W., and Allnutt, J.E. see Dissanayake, A.W.
McCarthy, E.P. Phase lead compensator design p1817
McCartney, D.J., Sheat, D.E., and Leggatt, J.S. see Sheat, D.E.
McDonach, A., Diemeer, M.B.J., Suyten, F.M.M., Trommel, E.S., Copeland, J.M., Jenneskens, L.W., and Horsthuis, W.H.G. see Diemeer, M.B.J.
McFarland, W., Hauenschild, J., Rein, H.-M., Doernberg, J., and Pettengill, D. see Hauenschild, J.
McGeehan, J.P., Davies, R., and Simpson, A. see Davies, R.
McGeehan, J.P., and Nix, A.R. see Nix, A.R.
McGeehan, J.P., and Railton, C.J. see Railton, C.J.
McGilvary, W.L., Turner, G.W., Chen, C.L., Connors, M.K., and Mahoney, L.J. see Turner, G.W.
McGuire, A., Thomas, A.P., and Booth, R.C. Optimisation of $LiNbO_3$ BOA waveguide switches operating at 1·3 μm p2077
McHargue, C.W., Townsend, P.D., Chandler, P.J., Wood, R.A., Zhang, L., and McCallum, J. see Townsend, P.D.
McIlvaney, K., Marsh, J.H., Roberts, J.S., and Button, C. Matrix-addressed 4 × 4 spatial light modulator using the quantum confined stark effect in GaAs/AlGaAs quantum wells p1691
McInerney, J.G., and Baca, L.J. see Baca, L.J.
McKee, P., Barnes, N.M., Healey, P., O'Neill, A.W., Rejman-Greene, M.A.Z., Scott, E.G., Webb, R.P., and Wood, D. see Barnes, N.M.
McKeeman, J.C., Havlicek, J.P., Sarkady, K.A., and Katz, G.R. see Havlicek, J.P.
McKeeman, J.C., and Sweeney, D.G. see Sweeney, D.G.
McKinnon, E.R. Synthetis of single sets of 2^n mutually orthogonal phase codes p1240
McLaughlin, S., Zheng, F., and Mulgrew, B. see Zheng, F.
McLernon, D.C. Periodically time-varying two-dimensional systems p412
McN Alford, N., Smith, P.A., Davis, L.E., and Button, T.W. see Smith, P.A.
McNamara, D.A., and Botha, L. Sensitivity of the radiation pattern of a small slotted waveguide array to the finiteness of its elliptical groundplane p387
McNamara, D.A., and Olivier, J.C. see Olivier, J.C.
McWhirter, J.G., Broomhead, D.S., Jones, R., and

Shepherd, T.J. see Broomhead, D.S.
Mecozzi, A., Hui, R., D'Ottavi, A., and Spano, P. see Hui, R.
Medved, A.V., Mishkinis, R.A., and Rutkovsky, P.F. Highly sensitive electrostatic voltage sensor on SAW double-waveguides p973
Meggitt, B.T., Chen, S., and Rogers, A.J. see Chen, S.
Megson, G.M. Efficient systolic string matching p2040
Mehuys, D., Parke, R., Welch, D., Waarts, R., Craig, R., and Scifres, D. see Parke, R.
Mehuys, D., Waarts, R., Parke, R., Welch, D., Streifer, W., and Scifres, D. see Waarts, R.
Mehuys, D., Waarts, R.G., Welch, D.F., and Streifer, W. see Waarts, R.G.
Mehuys, D., Welch, D.F., Nam, D.W., and Scifres, D.R. High power (>100 mW), low crosstalk (<0·4%), individually addressed laser diodes p1955
Mehuys, D., Welch, D.F., Parke, R., Waarts, R., Scifres, D., and Streifer, W. see Welch, D.F.
Mehuys, D.G., Eng, L.E., Mittelstein, M., and Yariv, A. see Eng, L.E.
Meier, H., Wallmeroth, K., Wandernoth, B., Franz, J., and Schorp, B. see Wallmeroth, K.
Meier, M., Kluitmans, J.T.M., Kuindersma, P.I., Mink, J., Röll, G., and Will, D.J. see Kluitmans, J.T.M.
Meissner, J. Rigorous calculation of losses of single and coupled groove-guides p41
Mekonnen, G., Trommer, D., Umbach, A., Passenberg, W., and Unterbörsch, G. see Trommer, D.
Meland, E., Holmstrom, R., Schlafer, J., Lauer, R.B., and Powazinik, W. Extremely high-frequency (24 GHz) InGaAsP diode lasers with excellent modulation efficiency p1827
Meland, E., Rideout, W., Holmstrom, R., LaCourse, J., and Powazinik, W. see Rideout, W.
Mellis, J., Al-Chalabi, S.A., Hollier, M., Cameron, K.H., Wyatt, R., Regnault, J.E., Devlin, W.J., and Brain, M.C. see Al-Chalabi, S.A.
Mellis, J., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Mellis, J., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Mellor, P.H., Leigh, S.P., and Cheetham, B.M.G. see Leigh, S.P.
Melman, P., Foley, B.M., and Vo, K.T. see Foley, B.M.
Menendez, R.C., Wagner, S.S., and Lemberg, H.L. Passive fibre-loop architecture providing both switched and broadcast transport p273
Menocal, S.G., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Zah, C.E., Caneau, C., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.
Menocal, S.G., Reichenbach, D., Zah, C.E., Andreadakis, N., Favire, F.J., Vodhanel, R., Yi-Yan, A., and Lee, T.P. see Reichenbach, D.
Menon, S.M., Jayasumana, A.P., and Malaiya, Y.K. Fault modelling of ECL devices p1105
Mentzelopoulou, S.E., Antoniou, G.E., and Manikopoulos, C.N. see Antoniou, G.E.
Mercer, L.B. Adaptive coherent optical receiver array p1518
Mercier, J.P., Kechouane, M., L'Haridon, H., Salvi, M., Favennec, P.N., Moutonnet, D., and Gauneau, M. see Kechouane, M.
Mermelstein, M.D., and Dandridge, A. Metallic glass ribbon probe for the measurement of the magnetic field, first and second order field gradients p501
Mersali, B., Gelly, G., Accard, A., Lafragette, J.-L., Doussiere, P., Lambert, M., and Fernier, B. 1·55 μm high-gain polarisation-insensitive semiconductor travelling wave amplifier with low driving current p124
Mertens, R., Dobbelaere, W., De Boeck, J., Van Hove, M., Deneffe, K., De Raedt, W., and Borghs, G. see Dobbelaere, W.
Mertens, R.P., Kuijk, M., Pereira, R., Van Hove, M., Borghs, G., and Pankove, J.I. see Kuijk, M.
Mgombelo, H.R., Ali, H.O., and Kissaka, M.M. New impedance transforming rat-race hybrid ring p837
Miao, E., Valera, J., Darzi, A., Walker, A.C., Krug, W., Derstine, M., and Polky, J.N. see Valera, J.
Michaeli, A. Asymptotic solution for line source radiation from a curved perfectly conducting wedge p1249 e1832
Michalski, K.A., and Zheng, D. see Zheng, D.
Michelakis, C., Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., and Morgan, D.V. see Anderson, W.T.
Middelhoek, J., Aite, K., and Ragay, F.W. see Aite, K.
Midwinter, J.E., Selviah, D.R., and Mao, Z.Q. see Selviah, D.R.
Migliora, C.G.S., Pontes, M.S., and Silva Mello, L.A.R. Results of site-diversity radiometric measurements at Ku-band in Brazil p1552
Migliorato, P., Izzard, M.J., and Milne, W.K. see Izzard, M.J.
Mikami, O., Magari, K., Noguchi, Y., Okamoto, K., Yasaka, H., and Nagai, H. see Magari, K.
Mikami, O., Wakatsuki, A., and Okamoto, K. see Wakatsuki, A.
Mikawa, T., Wada, O., Kumai, T., Hamaguchi, H., Makiuchi, M., and Kuramata, A. see Wada, O.
Miklis, A., Heinecke, H., Höger, R., and Baur, B. see Heinecke, H.
Milbrodt, M., Goel, K.K., Prucnal, P.R., Shimazu, Y., Desurvire, E., and Tell, B. see Goel, K.K.
Millar, C.A., Brierley, M.C., Hunt, M.H., and Carter, S.F. Efficient up-conversion pumping at 800 nm of an erbium-doped fluoride fibre laser operating at 850 nm p1871
Millar, C.A., Craig-Ryan, S.P., and Ainslie, B.J. see Craig-Ryan, S.P.
Millar, C.A., and France, P.W. Diode-laser pumped erbium-doped fluorozirconate fibre amplifier for the 1530 nm communications window p634
Miller, B.I., Koren, U., Oron, M., Young, M.G., De Miguel, J.L., Raybon, G., and Chien, M. see Koren, U.
Miller, C.M., and Janniello, F.J. Passively temperature-compensated fibre Fabry–Perot filter and its application in wavelength division multiple access computer network p2122
Miller, D.A.B., Goossen, K.W., Zucker, J.E., Bar-Joseph, I., Kuo, J.M., Kopf, R.M., and Chemla, D.S. see Goossen, K.W.
Miller, L.M., Favaro, M.E., Alwan, J.J., Bryan, R.P., Coleman, J.J., Kim, J., and Wayman, C.M. see Favaro, M.E.
Millicker, D., Runge, K., Young, J., Bagheri, M., Kipnis, I., and Snapp, C. see Runge, K.
Milne, W.K., Izzard, M.J., and Migliorato, P. see Izzard, M.J.
Min, Q., Xue, K.Z., and Wu, P.H. Application of Kramers–Kronig transform to determination of cavity impedance for both small and large couplings p44
Minagawa, S., and Tanaka, T. see Tanaka, T.
Minasian, R.A., and Alameh, K. see Alameh, K.
Minelly, J.D., and Suyama, M. Wavelength combining fused-taper couplers with low sensitivity to polarisation for use with 1480 nm-pumped erbium-doped fibre amplifiers p523
Mink, J., Kluitmans, J.T.M., Kuindersma, P.I., Meier, M., Röll, G., and Will, D.J. see Kluitmans, J.T.M.
Mironenko, I.G., and Gevorgian, S.S. see Gevorgian, S.S.
Mishkinis, R.A., Medved, A.V., and Rutkovsky, P.F. see Medved, A.V.
Mishra, R.K., Pattnaik, S.S., and Das, N. see Pattnaik, S.S.
Mishra, R.K., and Pattnaik, S.S. Resonant frequency of wedge shaped microstrip antenna p912
Misser, H.S., Prasad, R., and Kegel, A. see Prasad, R.
Mita, S., and Bergmans, J.W.M. see Bergmans, J.W.M.
Mitchell, C.J., and Jedwab, J. see Jedwab, J.
Mitchell, D.J., Chen, Y., and Snyder, A.W. see Chen, Y.
Mitchell, D.J., Snyder, A.W., Chen, Y., and Poladian, L. see Snyder, A.W.
Mitchell, D.J., Snyder, A.W., and Chen, Y. Nonlinear triple core couplers p1164 e1831
Mittelstein, M., Eng, L.E., Mehuys, D.G., and Yariv, A. see Eng, L.E.
Mittelstein, M., Ungar, J., Bar-Chaim, N., Mazed, M., Oh, S., and Ury, I. see Ungar, J.
Miyajima, Y., Komukai, T., and Katsuyama, Y. see Komukai, T.
Miyajima, Y., Komukai, T., and Sugawa, T. 1·31–1·36 μm optical amplification in Nd^{3+}-doped fluorozirconate fibre p194
Miyajima, Y., Sugawa, T., and Komukai, T. see Sugawa, T.
Miyajima, Y., Sugawa, T., and Komukai, T. 20 dB Gain at 1·55 μm wavelength in 50 cm long Er^{3+}-doped fluoride fibre amplifier p1527
Miyajima, Y., Sugawa, T., and Komukai, T. Efficient 1·3 μm-band amplification in a Nd^{3+}-doped single-mode fluoride fibre p1397
Miyamoto, Y., Hagimoto, K., and Kagawa, T. Gigabit high sensitivity receiver using InGaAs/InAlAs superlattice APD p491
Miyamoto, Y., Yamamoto, T., Ogawa, M., Inamura, E., and Furuya, K. see Yamamoto, T.
Miyamoto, Y., Yamaura, S., and Furuya, K. see Yamaura, S.
Miyanaga, H., Yamanaka, N., and Kikuchi, S. see Yamanaka, N.
Miyata, M., Takahashi, Y., Ando, K., and Amada, E. see Takahashi, Y.
Miyazaki, A., Maekawa, Y., Chang, N.S., and Segawa, T. see Maekawa, Y.
Miyazaki, S., Fujita, S., Suzaki, T., Matsuoka, A., Torikai, T., Nakata, T., and Shikada, M. see Fujita, S.
Miyazawa, H., and Takada, A. see Takada, A.
Mizrahi, V., Hibino, Y., and Stegeman, G.I. see Hibino, Y.
Mizrahi, V., LaRochelle, S., Hibino, Y., and Stegeman, G.I. see LaRochelle, S.
Mizumoto, T., Cai, Y., and Naito, Y. see Cai, Y.
Mizumoto, T., Chihara, H., Tokui, N., and Naito, Y. Verification of waveguide-type optical circulator operation p199
Mizuta, M., Tanaka, S., Hayama, N., Furukawa, A., Baba, T., and Honjo, K. see Tanaka, S.
Mizuuchi, K., Yamamoto, K., and Taniuchi, T. High-efficiency coupling of laser diodes in tapered proton-exchanged waveguides p1992
Mönich, G., and Littmann, B. Helical antenna and spiral antenna with fast switch selection of the polarisation sense p1918
Mochizuki, K., Edagawa, N., Yoshida, Y., Taga, H., Yamamoto, S., and Wakabayashi, H. see Edagawa, N.
Moehrle, M., Ludwig, R., Rosenzweig, M., Schnabel, R., Schunk, N., and Weber, H.G. see Ludwig, R.
Moeller, R.P., and Kersey, A.D. see Kersey, A.D.
Moeneclaey, M., and Batsele, T. Symbol synchronisation for binary baseband PAM operating at only one sample per symbol p691
Mohamed, S.S., and Porter, B. see Porter, B.
Moharir, P.S., Rajeswari, K.R., and Rao, K.V. Progressive bounds on merit factors p1584
Mokhtar, M.M., and Parker, E.A. Conjugate gradient computation of the current distribution on a tripole FSS array element p227
Monahan, D., Lee Russell, J., Kellert, F., and Ehlers, E. see Lee Russell, J.
Monerie, M., Allain, J.Y., and Poignant, H. see Allain, J.Y.
Monerie, M., Georges, T., Francois, P.L., Allain, J.Y., and Neveux, D. Ground-state and excited-state absorption in rare-earth doped optical fibres p320
Monerie, M., Ronarc'h, D., Allain, J.Y., Guibert, M., and Poignant, H. see Ronarc'h, D.
Montgomery, R.K., Nottenburg, R.N., Banu, M., Jalali, B., Humphrey, D.A., Hamm, R.A., and Panish, M.B. see Nottenburg, R.N.
Moonen, M., and Vandewalle, J. Hexagonally connected processor array for Jacobi-type matrix algorithms p400
Moore, F.G., Klein, P.B., and Dietrich, H.B. see Klein, P.B.
Moore, M.W., Carter, S.F., Szebesta, D., Williams, J.R., Ranson, D., and France, P.W. see Carter, S.F.
Moore, M.W., Rowe, C.J., Wilkinson, I.J., and Achurch, N.E. see Rowe, C.J.
Moore, T.E., Kusyk, R.G., and Krzymien, W.A. see Kusyk, R.G.
Moore, T.E., Kusyk, R.G., and Krzymien, W.A. Waiting time jitter results for a reduced complexity SONET interface circuit p1884
Moratzky, M., Oehler, A.M., Hauff, T.M., and Heinlein, W.E. see Oehler, A.M.
Morey, W.W., Ball, G.A., and Waters, J.P. see Ball, G.A.
Morgan, D.P. Directivity of group-type single phase unidirectional SAW transducers p1201
Morgan, D.P. Performance trade-offs in SAW group-type SPUDTs p1200
Morgan, D.V., Anderson, W.T., Christou, A., Thompson, P.E., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., and Michelakis, C. see Anderson, W.T.
Morgan, D.V., Goostray, J., Thomas, H., Kohn, E., Christou, A., and Mottet, S. see Goostray, J.
Morgan, R., Barton, J.S., Harper, P.G., and Jones, J.D.C. Temperature dependence of bending loss in monomode optical fibres p937
Morizuka, K., Akagi, J., Kuriyama, Y., Asaka, M., Tsuda, K., Obara, M., and Yamakawa, H. see Akagi, J.
Morizuka, K., Yamakawa, H., Ibe, H., Akagi, J., Kuriyama, Y., and Obara, M. see Yamakawa, H.
Morkel, P.R., Cowle, G.J., Laming, R.I., and Payne, D.N. see Cowle, G.J.
Morkel, P.R., Cowle, G.J., and Payne, D.N. Travelling-wave erbium fibre ring laser with 60 kHz linewidth p632
Morkel, P.R., Laming, R.I., and Payne, D.N. Noise characteristics of high-power doped-fibre superluminescent sources p96
Morkel, P.R., Taylor, E.M., Townsend, J.E., and Payne, D.N. Wavelength stability of Nd^{3+}-doped fibre fluorescent sources p873
Morkoç, H., Chen, J., Gao, G.B., and Ünlü, M.S. see Chen, J.
Morkoç, H., Ünlü, M.S., Kishino, K., Chyi, J.-I., Reed, J., and Arsenault, L. see Ünlü, M.S.
Morkoç, H., Ünlü, M.S., Strite, S., Adomi, K., and Gao, G.B. see Ünlü, M.S.
Morris, J.M., and Qian, S.-E. see Qian, S.-E.
Morthier, G., David, K., Vankwikelberge, P., and Baets, R. see David, K.
Mortimore, D.B., and Arkwright, J.W. see Arkwright, J.W.
Mortimore, D.B., and Arkwright, J.W. Performance tuning of 1 × 7 wavelength-flattened fused fibre couplers p1442
Morton, P.A., Mar, A., and Bowers, J.E. see Mar, A.
Mosch, T.W.M., Koonen, A.M.J., Van Eijk, P., and Van Heijningen, P.H. see Koonen, A.M.J.
Moseley, A.J., Thompson, J., Kearley, M.Q., Robbins, D.J., and Goodwin, M.J. Low voltage InGaAs/InP multiple quantum well reflective Fabry–Perot modulator p913
Mosig, J.R., and Hall, R.C. see Hall, R.C.
Mottet, S., Goostray, J., Thomas, H., Morgan, D.V., Kohn, E., and Christou, A. see Goostray, J.
Moule, D.J., White, I.H., Watts, J.J.S., Carroll, J.E., Armistead, C.J., and Champelovier, J.A. see White, I.H.
Moutonnet, D., Favennec, P.N., L'Haridon, H., Salvi, M., and Papadopoulo, A.C. see Favennnec, P.N.
Moutonnet, D., Kechouane, M., L'Haridon, H.,

Salvi, M., Favennec, P.N., Gauneau, M., and Mercier, J.P. see Kechouane, M.
Müller, G., Stoll, L., Schulte-Roth, G., and Wolff, U. Low current plasma effect optical switch on InP p115
Müller, R., Poisel, H., Trommer, G.F., Bühler, W., and Hartl, E. see Poisel, H.
Muir, A., and Tepereck, R.J. Analysis of stripline/slot transition p1160 e1923
Mukai, S., Ogura, M., Shimada, M., Asaka, T., Yamasaki, Y., Seki, T., and Iwano, H. see Ogura, M.
Mulder, H., Dharmadi, J.J., Diekema, A., and de Waal, A.G. see Dharmadi, J.J.
Mulgrew, B., Zheng, F., and McLaughlin, S. see Zheng, F.
Mullick, S.K., and Kumar, A. see Kumar, A.
Mullin, R.C., Agnew, G.B., and Vanstone, S.A. see Agnew, G.B.
Muñoz-Rodriguez, D., and Arevalo-Galarza, J.B. Line coding for very high speed LANs p2051
Murakami, T., and Kato, Y. see Kato, Y.
Muriel, M.A., and Capmany, J. see Capmany, J.
Murray, A.F., Brownlow, M.J., and Tarassenko, L. see Brownlow, M.J.
Mwarania, E.K., Reekie, L., Wang, J., and Wilkinson, J.S. Low-threshold monomode ion-exchanged waveguide lasers in neodymium-doped BK-7 glass p1317

N

Näppi, J., Keskinen, J., Asonen, H., and Pessa, M. see Keskinen, J.
Nadeu, C., and Lleida, E. On the Cramer–Rao bound of finite-length cepstrum spectral estimators p987
Nagai, H., Magari, K., Noguchi, Y., Okamoto, K., Yasaka, H., and Mikami, O. see Magari, K.
Nagaoka, S. Latching type single-mode fibre switch p744
Nagasako, Y., and Nakashima, T. Fast timing extraction method for an optical passive bus p1168
Nagatsuma, T., and Shinagawa, M. see Shinagawa, M.
Naito, M., and Ito, K. Improved feed-system for a printed antenna composed of strip dipoles and slots p1228
Naito, T., Chikama, T., Ishikawa, G., and Kuwahara, H. 4 Gbit/s, 233-km optical fibre transmission experiment using newly proposed direct-modulation PSK p1734
Naito, Y., Cai, Y., and Mizumoto, T. see Cai, Y.
Naito, Y., Mizumoto, T., Chihara, H., and Tokui, N. see Mizumoto, T.
Nakahashi, T., Kinoshita, T., and Eto, Y. see Kinoshita, T.
Nakajima, H. Demodulation of multi-gigahertz frequency-modulated optical signals in an injection-locked distributed feedback laser oscillator p1129
Nakajima, S., Nishiyama, N., Yano, H., and Hayashi, H. see Nishiyama, N.
Nakamoto, H., and Koyamada, Y. see Koyamada, Y.
Nakamura, M.S., and Ohshima, S. Frequency-stabilised LD module with a Z-cut quartz Fabry–Perot resonator for coherent communication p405
Nakamura, T., Chung, G.S., Kawahito, S., and Ishida, M. see Chung, G.S.
Nakamura, T., Kawahito, S., and Ishida, M. see Kawahito, S.
Nakamura, Y., Takanashi, H., and Aikawa, S. see Takanashi, H.
Nakanishi, K., Takachio, N., Iwashita, K., and Koike, S. see Takachio, N.
Nakanishi, K., Toba, H., Oda, K., Shibata, N., Nosu, K., Takato, N., and Sato, K. see Toba, H.
Nakano, H., Hirose, K., and Horiuchi, H. see Hirose, K.
Nakano, H., Tsuji, S., Uomi, K., Sasaki, S., and Yamashita, K. 10 Gbit/s, 100 km nonrepeatered fibre transmission experiment using a high-sensitivity semiconductor optical preamplifier p1364
Nakano, H., Uomi, K., Yamashita, K., and Yagiu, Y. Hybrid-integrated laser/driver module for 10 Gbit/s optical fibre transmission p145
Nakano, H., Vichien, K., Sugiura, T., and Yamauchi, J. Singly-fed patch antenna radiating a circularly polarised conical beam p638
Nakano, H., Yamauchi, J., Kikuchi, S., and Hirooka, T. see Yamauchi, J.
Nakano, H., and Yamauchi, J. see Yamauchi, J.
Nakashima, S., and Izumi, K. Practical reduction of dislocation density in SIMOX wafers p1647
Nakashima, T., and Nagasako, Y. see Nagasako, Y.
Nakata, T., Fujita, S., Suzaki, T., Matsuoka, A., Miyazaki, S., Torikai, T., and Shikada, M. see Fujita, S.
Nakazawa, M., Kimura, Y., Yoshida, E., and Suzuki, K. Efficient erbium-doped fibre amplifier pumped at 820 nm p1936
Nakazawa, M., Kimura, Y., and Suzuki, K. High gain erbium fibre amplifier pumped by 800 nm band p548
Nakazawa, M., Suzuki, K., Yamada, E., and Kimura, Y. see Suzuki, K.
Nakazawa, M., Suzuki, K., Yamada, E., and Kimura, Y. 20 Gbit/s soliton transmission over 200 km using erbium-doped fibre repeaters p1592
Nakazawa, M., Suzuki, K., and Kimura, Y. see Suzuki, K.
Nakazawa, M., Suzuki, K., and Yamada, E. Femtosecond optical pulse generation using a distributed-feedback laser diode p2038
Nakazawa, M., and Kubota, H. see Kubota, H.
Nakazawa, M., and Suzuki, K. see Suzuki, K.
Nam, D.W., Mehuys, D., Welch, D.F., and Scifres, D.R. see Mehuys, D.
Nam, S.H., and Un, C.K. Multichannel local lightwave network with grouping property p1436
Nandi, A.K. Quality of signals reconstructed from degraded Fourier transform phase p1460
Nandi, A.K., and Vaughan, R.C. Theorem with applications in coding and matching problems p1928
Narayanan, S.B., Anupindi, N., and Prabhu, K.M.M. see Anupindi, N.
Nauta, B. CMOS VHF transconductance-C lowpass filter p421
Nawrocki, R., and Ehrlich, W. Waiting time jitter reduction by fill locking p1227
Nayar, V., Patel, P., and Boyd, I.W. Atmospheric pressure, low temperature (< 500°C) UV/ozone oxidation of silicon p205 e828
Naylor, P., and Desai, R.A. New three dimensional symmetrical condensed lossy node for solution of electromagnetic wave problems by TLM p492
Nazarathy, M., Newton, S.A., and Trutna, W.R. Complementary correlation OTDR with three codewords p70
Ndagijimana, F., Saguet, P., and Bouthinon, M. Tapered slot antenna analysis with 3-D TLM method p468
Neidlinger, S. DPSK polarisation diversity receiver with novel switching-demodulators and maximal-ratio combining p1070
Neikirk, D.P., Reddy, V.K., and Tsao, A.J. see Reddy, V.K.
Nelson, B.P., Blow, K.J., and Doran, N.J. see Blow, K.J.
Nelson, D., Aronhime, P., and Adams, C. see Aronhime, P.
Nemanich, R.J., Humphreys, T.P., Das, K., Parikh, N.R., and Posthill, J.B. see Humphreys, T.P.
Neri, A., and Rizzoli, V. see Rizzoli, V.
Neudeck, G.W., and Chao, J.H.C. see Chao, J.H.C.
Neudeck, G.W., and Glenn, J.L. see Glenn, J.L.
Neumann, R., Tews, H., Zwicknagl, P., Jaeger, G., Hoepfner, A., Schleicher, L., and Packeiser, G. see Tews, H.
Neusy, P.C., and Kavehrad, M. Proposal for an all-optical code-division multiple access for local area networks p1471
Neveux, D., Monerie, M., Georges, T., Francois, P.L., and Allain, J.Y. see Monerie, M.
Newberg, I., Ng, W., Walston, A., Tangonan, G., and Lee, J.J. see Ng, W.
Newton, S.A., Nazarathy, M., and Trutna, W.R. see Nazarathy, M.
Ng, B.P. Array synthesis using a simple computer-aided approach p337
Ng, D., Vai, M.-K., and Prasad, S. see Vai, M.-K.
Ng, G.I., Kwon, Y., Pavlidis, D., Tutt, M., Lai, R., and Brock, T. see Kwon, Y.
Ng, G.I., Weiss, M., and Pavlidis, D. see Weiss, M.
Ng, H.C., Li, E.H., and Liu, C.K. see Li, E.H.
Ng, S.S., Yeo, T.S., Kooi, P.S., and Leong, M.S. see Yeo, T.S.
Ng, W., Walston, A., Tangonan, G., Lee, J.J., and Newberg, I. Optical steering of dual band microwave phased array antenna using semiconductor laser switching p791
Ngo, B., and Lee, H. Analysis of a pre-emptive priority M/M/c model with two types of customers and restriction p1190
Nho, E.C., Kim, I.D., and Cho, G.H. see Kim, I.D.
Nicholson, B.F., Hedges, S.J., Adams, M.J., and Chew, N.G. see Hedges, S.J.
Nicholson, G. Use of a fibre loop reflector as downstream receiver and upstream modulator in passive optical network p827
Nielsen, S.K., Hoffmann, B., Jensen, N.G., Bødtker, E., and Broberg, B. see Hoffmann, B.
Nielsen, S.K., van Deventer, M.O., and Spano, P. see van Deventer, M.O.
Nietzke, R., Sacher, J., Elsässer, W., and Göbel, E.O. Mode locking of a semiconductor laser by self-synchronising optoelectronic feedback of the longitudinal mode beats p1016
Nikolayev, V.M., Filippov, V.N., and Kotov, O.I. see Filippov, V.N.
Nikoonahad, M., and Liu, D.C. Medical ultrasound imaging using neural networks p545
Nilsson, S., Öberg, M., Holmberg, B., Klinga, T., and Broberg, B. see Öberg, M.
Nintunze, N., and Wu, A. Modified Hebbian auto-adaptive impulse neural circuits p1561
Nishi, I., Shimizu, M., Horiguchi, M., Yamada, M., Okayasu, M., Takeshita, T., Uehara, S., Noda, J., and Sugita, E. see Shimizu, M.
Nishi, I., Takahashi, H., Suzuki, S., and Kato, K. see Takahashi, H.
Nishi, S., Iwatsuki, K., Saruwatari, M., and Shimizu, M. see Iwatsuki, K.
Nishihara, H., Suhara, T., Fujimura, M., and Kinoshita, K. see Suhara, T.
Nishihara, S., Ohke, S., and Cho, Y. see Ohke, S.
Nishikido, J., Okuno, M., and Himeno, A. 4·65 Gbit/s optical 4-bit pattern matching using silica-based waveguide circuit p1766
Nishimoto, C., Majidi-Ahy, R., Riaziat, M., Glenn, M., Silverman, S., Weng, S., Pao, Y.C., Zdasiuk, G., Bandy, S., and Tan, Z. see Majidi-Ahy, R.
Nishimoto, C., Yuen, C., Pao, Y.C., Day, M., Glenn, M., Bandy, S., and Zdasiuk, G. see Yuen, C.
Nishimoto, H., Soda, H., Furutsu, M., Sato, K., Okazaki, N., Yamazaki, S., and Ishikawa, H. see Soda, H.
Nishiyama, N., Yano, H., Nakajima, S., and Hayashi, H. n-AlInAs/(InAs)$_1$(GaAs)$_1$ superlattice modulation-doped field effect transistor grown by molecular beam epitaxy p885
Nix, A.R., and McGeehan, J.P. Modelling and simulation of frequency selective fading using switched antenna diversity p1868
Noda, J., Shimizu, M., Horiguchi, M., Yamada, M., Okayasu, M., Takeshita, T., Nishi, I., Uehara, S., and Sugita, E. see Shimizu, M.
Noda, S., Yamada, E., Takayama, T., and Sasaki, A. Light-controlled optical bistable device by bistable laser diode and heterojunction phototransistor p1069
Noé, R., Rodler, H., Gaukel, G., Ebberg, A., and Auracher, F. Polarisation- and pattern-independent optical FSK heterodyne system using data-induced polarisation switching p176
Noé, R., Rodler, H., Gaukel, G., Noll, B., and Ebberg, A. High-performance, two-channel optical FSK heterodyne system with polarisation diversity receiver p1109
Noé, R., and Ebberg, A. see Ebberg, A.
Nofal, M., Steele, R., and Eldolil, S. see Steele, R.
Noguchi, K., Hogari, K., Sakano, T., and Matsumoto, T. Rearrangeable multichannel free-space optical switch using polarisation multiplexing technique p1325
Noguchi, K., Norimatsu, S., and Iwashita, K. see Norimatsu, S.
Noguchi, Y., Magari, K., Okamoto, K., Yasaka, H., Nagai, H., and Mikami, O. see Magari, K.
Noll, B., Noé, R., Rodler, H., Gaukel, G., and Ebberg, A. see Noé, R.
Nomura, I., Kaneko, Y., Kikuchi, A., and Kishino, K. see Kaneko, Y.
Nomura, I., Kikuchi, A., Kaneko, Y., and Kishino, K. see Kikuchi, A.
Noonan, J.P., Tzannes, M.A., and Achour, B. Minimum relative entropy enhancement of FFT spectra p979
Norimatsu, S., Iwashita, K., and Noguchi, K. 10 Gbit/s optical PSK homodyne transmission experiments using external cavity DFB LDs p648
Normandin, R., Williams, R.L., and Chatenoud, F. Enhanced surface emitting waveguides for visible, monolithic semiconductor laser sources p2088
Norwood, R.A., and Khanarian, G. Quasi-phase-matched frequency doubling over 5 mm in periodically poled polymer waveguide p2105
Nosu, K., Toba, H., Oda, K., Nakanishi, K., Shibata, N., Takato, N., and Sato, K. see Toba, H.
Nottenburg, R.N., Banu, M., Jalali, B., Humphrey, D.A., Montgomery, R.K., Hamm, R.A., and Panish, M.B. 5 V, DC–12 GHz InP/InGaAs HBT amplifier p2016
Notter, M.J., and Parini, C.G. Modelling of arbitrary shaped M/S patch antennas in multiple substrate media p50
Nouailhat, A., Giroult-Matlakowski, G., Degors, N., Marty, A., and Chantre, A. see Giroult-Matlakowski, G.
Nouet, P., and Girard, P. see Girard, P.
Novák, J., and Malacký, L. Metal-semiconductor-metal photodetector on p-type $In_{0.53}Ga_{0.47}As$ p704
Nowitzki, A., Schilling, M., Schweizer, H., Dütting, K., Idler, W., Kühn, E., and Wünstel, K. see Schilling, M.
Nugroho, I.A., Juy, M., Maurel, R., Rooryck, M., and Hariman, T. see Juy, M.
Nyairo, K.O., White, I.H., Kirkby, P.A., and Armistead, C.J. see White, I.H.

O

O'Donnell, A.C., Pollentier, I., Demeester, P., Van Daele, P., and Carr, A.D. Integration of GaAs MESFETs and lithium niobate optical switches using epitaxial lift-off p1179
O'Gorman, J., Hobson, W.S., Levi, A.F.J., Pearton, S.J., Abernathy, C.R., and Swaminathan, V. see Hobson, W.S.
O'Gorman, J., Rossi, B., Blau, W., König, S., Westland, D., and Skarda, V. see Rossi, B.
O'Gorman, J., and Levi, A.F.J. Calculated chirp in intracavity loss modulated DFB lasers p1784
O'Leary, P., Gatti, U., Liberali, V., and Maloberti, F. see Gatti, U.
O'Leary, P., and Lee, P. see Lee, P.
O'Leary, P., and Maloberti, F. Bit stream adder for oversampling coded data p1708
O'Mahony, M.J., Wake, D., Judge, S.N., Spooner, T.P., Harlow, M.J., Duncan, W.J., and Henning, I.D. see Wake, D.
O'Neill, A.G., and Gilman, J.M.A. see Gilman, J.M.A.
O'Neill, A.W., Barnes, N.M., Healey, P., McKee, P.,

Rejman-Greene, M.A.Z., Scott, E.G., Webb, R.P., and Wood, D. see Barnes, N.M.
O'Neill, A.W., and Webb, R.P. All-optical loop mirror switch employing an asymmetric amplifier/attenuator combination p2008
O'Neill, M., Marsh, J.H., De La Rue, R.M., Roberts, J.S., Button, C., and Gwilliam, R. Reduction of the propagation losses in impurity disordered quantum well waveguides p1613
O'Reilly, E.P., and Ghiti, A. see Ghiti, A.
Oakley, K.P., Birks, T.A., Kenny, R.P., and Cryan, C.V. see Birks, T.A.
Obara, H., Okamoto, S., Uematsu, H., and Matsunaga, H. Self-routing planar network for guided-wave optical switching systems p520
Obara, H., Uematsu, H., Okamoto, S., and Matsunaga, H. Self-routing space switch network comprising fast and uniform switch elements p352
Obara, H., and Okamoto, S. Self-routing fast packet switch with in-service modulator growth p1286
Obara, M., Akagi, J., Kuriyama, Y., Morizuka, K., Asaka, M., Tsuda, K., and Yamakawa, H. see Akagi, J.
Obara, M., Yamakawa, H., Ibe, H., Akagi, J., Kuriyama, Y., and Morizuka, K. see Yamakawa, H.
Öberg, M., Nilsson, S., Holmberg, B., Klinga, T., and Broberg, B. Influence of leakage currents between electrodes in tunable DBR-lasers p1089
Oda, K., Toba, H., Nakanishi, K., Shibata, N., Nosu, K., Takato, N., and Sato, K. see Toba, H.
Oehler, A.M., Hauff, T.M., Moratzky, M., and Heinlein, W.E. High-contrast measurement of refractive-index profile in fused single-mode fibre couplers with high resolution by deconvolution p12
Offsey, S.D., Tasker, P.J., Schaff, W.J., Kapitan, L., Shealy, J.R., and Eastman, L.F. Vertical integration of an $In_{0.14}Ga_{0.86}As$ modulation-doped field effect transistor and GaAs laser grown by molecular beam epitaxy p350
Ogawa, K., Hashimoto, K., Uwano, T., and Ota, Y. 50 GHz MIC amplifiers using AlGaAs/GaAs HBTs p2134
Ogawa, K., Ikeda, H., Ishizaki, T., Hashimoto, K., and Ota, Y. 25 GHz dielectric resonantor oscillator using an AlGaAs/GaAs HBT p1514
Ogawa, M., Yamamoto, T., Miyamoto, Y., Inamura, E., and Furuya, K. see Yamamoto, T.
Ogita, S., Kawamura, H., Kamite, K., Yonetani, H., Soda, H., and Ishikawa, H. see Kawamura, H.
Ogose, S., and Furuno, T. see Furuno, T.
Ogura, I., Tashiro, Y., Sugimoto, M., Hamao, N., and Kasahara, K. see Tashiro, Y.
Ogura, M., Mukai, S., Shimada, M., Asaka, T., Yamasaki, Y., Seki, T., and Iwano, H. Surface-emitting laser diode with distributed Bragg reflector and buried heterostructure p18
Oh, D.-S., Cho, K.-Y., Hong, S.-S., and Youn, M.-J. see Cho, K.-Y.
Oh, D.S., Ko, J.H., and Youn, M.J. see Ko, J.H.
Oh, D.S., and Youn, M.J. Automated adaptive hysteresis current control technique for a voltage-fed PWM inverter p2044
Oh, S., Ungar, J., Bar-Chaim, N., Mazed, M., Mittelstein, M., and Ury, I. see Ungar, J.
Oh, Y.S., Bien, Z., and Suh, I.H. Fast line detection algorithm using multivalued image coding p1400
Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., Kato, N., Hagimoto, K., and Hirayama, M. 13 Gb/s D-Type flip-flop IC using GaAs MESFETs p1039
Ohhata, M., Yamane, Y., Enoki, T., Sugitani, S., Kato, N., and Hirayama, M. 11 Gbit/s multiplexer and demultiplexer using 0·15 μm GaAs MESFETs p467
Ohishi, T., Abe, Y., Sugimoto, H., Ohtsuka, K., and Matsui, T. Ultra-high current gain InGaAsP/InP heterojunction bipolar transistor p392
Ohkawa, N., Imai, T., Hayashi, Y., Sugie, T., Ichihashi, Y., and Ito, T. see Imai, T.
Ohkawa, N., Imai, T., Ichihashi, Y., Sugie, T., and Ito, T. see Imai, T.
Ohkawa, N., Saito, S., Imai, T., Sugie, T., Ichihashi, Y., and Ito, T. see Saito, S.
Ohke, S., Nishihara, S., and Cho, Y. TM-mode selective filter using lossy layer cladding optical waveguide p98
Ohkita, M., and Kobayashi, Y. Implementation of integration of Walsh series by flowgraphs p887
Ohmori, Y., Kominato, T., Okazaki, H., and Yasu, M. see Kominato, T.
Ohno, S., Fukuda, H., and Arakawa, T. see Fukuda, H.
Ohno, S., Uchiyama, A., Fukuda, H., Hayashi, T., and Iwabuchi, T. see Uchiyama, A.
Ohshima, S., and Nakamura, M.S. see Nakamura, M.S.
Ohtsu, M., and Shin, C.-H. see Shin, C.-H.
Ohtsuka, K., Ohishi, T., Abe, Y., Sugimoto, H., and Matsui, T. see Ohishi, T.
Okai, M., Kitajima, S., Sasaki, S., Tsushima, H., and Yamashita, K. see Kitajima, S.
Okai, M., Uomi, K., Sasaki, S., Tsuchiya, T., Aoki, M., and Chinone, N. see Uomi, K.
Okamoto, E., and Masumoto, H. ID-based authentication system for computer virus detection p1169
Okamoto, K., Magari, K., Noguchi, Y., Yasaka, H., Nagai, H., and Mikami, O. see Magari, K.
Okamoto, K., Wakatsuki, A., and Mikami, O. see Wakatsuki, A.
Okamoto, S., Obara, H., Uematsu, H., and Matsunaga, H. see Obara, H.
Okamoto, S., and Obara, H. see Obara, H.
Okamura, H., Iwatsuki, K., and Saruwatari, M. see Iwatsuki, K.
Okamura, H., and Iwatsuki, K. Spectral linewidth broadening in Er-doped-fibre amplifiers measured with less than 1·4 kHz linewidth light source p1965
Okayama, H., Ushikubo, T., and Ishida, T. Low drive voltage directional coupler optical switch with reduced voltage-length product p374
Okayasu, M., Shimizu, M., Horiguchi, M., Yamada, M., Takeshita, T., Nishi, I., Uehara, S., Noda, J., and Sugita, E. see Shimizu, M.
Okayasu, M., Shimizu, M., Yamada, M., Horiguchi, M., and Takeshita, T. see Shimizu, M.
Okayasu, M., Yamada, M., Shimizu, M., and Horiguchi, M. see Yamada, M.
Okazaki, H., Kominato, T., Ohmori, Y., and Yasu, M. see Kominato, T.
Okazaki, N., Soda, H., Furutsu, M., Sato, K., Yamazaki, S., Nishimoto, H., and Ishikawa, H. see Soda, H.
Okazaki, Y., Kado, Y., Suzuki, M., and Kobayashi, T. see Kado, Y.
Okoshi, T., and Cheng, Y.H. see Cheng, Y.H.
Okuno, M., Nishikido, J., and Himeno, A. see Nishikido, J.
Olesen, H., Pan, X., and Tromborg, B. see Pan, X.
Oliveira, J.E.B., and Adler, E.L. Wide angular aperture acousto-optic configurations in biaxial crystals p931
Olivier, J.C., and McNamara, D.A. Analysis of edge slots in rectangular waveguide using finite-difference time-domain method p1135
Olofsson, H., Granestrand, P., Lagerström, B., Svensson, P., Thylén, L., Stoltz, B., Bergvall, K., and Falk, J.-E. see Granestrand, P.
Olsen, T. 2·2 GHz dual-detector lightwave receiver employing current shunt feedback amplifier design p510
Olsson, N.A., Andrekson, P.A., Simpson, J.R., Tanbun-Ek, T., Logan, R.A., Becker, P.C., and Wecht, K.W. see Andrekson, P.A.
Omnes, F., Bradley, M.A., Julien, F.H., Gilles, J.P., Gao, Y., Rao, E.V.K., and Razeghi, M. see Bradley, M.A.
Onodera, K., Imai, Y., Tokumitsu, M., and Asai, K. see Imai, Y.
Oostlander, R., Antar, Y.M.M., Ittipiboon, A., and Cuhaci, M. Aperture coupled microstrip antenna element design p224
Orikasa, T., Sato, S., Iso, A., and Sugimoto, T. see Sato, S.
Oron, M., Koren, U., Young, M.G., Miller, B.I., De Miguel, J.L., Raybon, G., and Chien, M. see Koren, U.
Ortgies, G., Rücker, F., and Dintelmann, F. Statistics of clear-air attenuation on satellite links at 20 and 30 GHz p358
Osgood, R.M., Willner, A.E., and Podlesnik, D.V. see Willner, A.E.
Osiński, M., and Mahbobzadeh, M. see Mahbobzadeh, M.
Osowski, S. Neural network for estimation of parameters of sinewave p689
Österberg, U. Growth of third-harmonic signal in optical glass fibre p103
Ostrowsky, D.B., Lallier, E., Pocholle, J.P., Papuchon, M., De Micheli, M., Li, M.J., He, Q., Grezes-Besset, C., and Pelletier, E. see Lallier, E.
Ota, Y., Hirose, T., Ryoji, A., and Inada, M. AlGaAs/GaAs heterojunction bipolar transistors fabricated with various collector-carrier concentrations p203
Ota, Y., Ogawa, K., Hashimoto, K., and Uwano, T. see Ogawa, K.
Ota, Y., Ogawa, K., Ikeda, H., Ishizaki, T., and Hashimoto, K. see Ogawa, K.
Otsuka, Y. 1 Gbit/s high-speed bit-synchronisation LSI for B-ISDN p622
Ott, J.M., and Jayasumana, A.P. Register insertion bus architecture for fibre optic local area networks p1957
Ouellette, F. Axial dependence of $\chi^{(2)}$ gratings in optical fibre: Effect of the intensity-dependent detuning p740
Ouslimani, A., Vernet, G., Hafdallah, H., and Adde, R. Large amplitude picosecond step generation with FETs p1563
Owen, B., Delavaux, J.M., Park, Y.K., Tench, R.E., Barski, S., Tzeng, L.D., and Twu, Y. see Delavaux, J.M.
Owens, R.P., and Smith, A.C. Low-profile dual band, dual polarised array antenna module p1433
Özbay, E., Bloom, D.M., and Diamond, S.K. Pulse forming and triggering using resonant tunnelling diode structures p1046

P

Packeiser, G., Tews, H., Zwicknagl, P., Neumann, R., Jaeger, G., Hoepfner, A., and Schleicher, L. see Tews, H.
Paek, E.G., Yoo, H.-J., Hayes, J.R., Harbison, J.P., Florez, L.T., and Kwon, Y.-S. see Yoo, H.-J.
Page-Jones, M.A., and Everard, J.K.A. Optical-fibre spectrum analyser p117
Pahlavan, K., Zhang, K., and Ganesh, R. see Zhang, K.
Pahlavan, K., and Ganesh, R. see Ganesh, R.
Pahlavan, K., and Howard, S.J. see Howard, S.J.
Pahlavan, K., and Howard, S.J. Statistical AR models for the frequency selective indoor radio channel p1133
Pahlavan, K., and Zhang, K. see Zhang, K.
Pain, G.N., Leech, P.W., Gwynn, P.J., Petkovic, N., and Thompson, J. see Leech, P.W.
Pain, G.N., Leech, P.W., Petkovic, N., Gwynn, P.J., and Thompson, J. see Leech, P.W.
Pak, K., Yonezu, H., Himeno, T., Kanamori, K., and Takano, Y. see Yonezu, H.
Paleczny, E., Kinowski, D., Legier, J.F., Pribetich, P., and Kennis, P. Comparison of full wave approaches for determinations of microstrip conductor losses for MMIC applications p2076
Palmateer, L., Bouregba, R., Lippens, D., Bockenhoff, E., Bogey, M., Destombes, J.L., and Lecluse, A. see Bouregba, R.
Pan, S.-G., and Wolff, I. Full wave finite element analysis of slot-coupled microstrip antennas p1465
Pan, S.M., and Dodds, D.E. see Dodds, D.E.
Pan, X., Olesen, H., and Tromborg, B. Influence of nonlinear gain on DFB laser linewidth p1074
Panayirci, E., Ertüzün, A., and Kayran, A.H. see Ertüzün, A.
Panish, M.B., Nottenburg, R.N., Banu, M., Jalali, B., Humphrey, D.A., Montgomery, R.K., and Hamm, R.A. see Nottenburg, R.N.
Pankove, J., Radehaus, C., and Wagner, K. Winner-take-all neural net with memory p349
Pankove, J.I., Kuijk, M., Pereira, R., Van Hove, M., Mertens, R.P., and Borghs, G. see Kuijk, M.
Pao, Y.C., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Silverman, S., Weng, S., Zdasiuk, G., Bandy, S., and Tan, Z. see Majidi-Ahy, R.
Pao, Y.C., Yuen, C., Day, M., Nishimoto, C., Glenn, M., Bandy, S., and Zdasiuk, G. see Yuen, C.
Papadopoulo, A.C., Favennnec, P.N., L'Haridon, H., Moutonnet, D., and Salvi, M. see Favennnec, P.N.
Papiernik, A., and Croq, F. see Croq, F.
Papiernik, A., and Fenelon, J.P. see Fenelon, J.P.
Papillon, D., Delacourt, D., Pocholle, J.P., Schnell, J.P., and Papuchon, M. see Delacourt, D.
Papuchon, M., Delacourt, D., Papillon, D., Pocholle, J.P., and Schnell, J.P. see Delacourt, D.
Papuchon, M., Lallier, E., Pocholle, J.P., De Micheli, M., Li, M.J., He, Q., Ostrowsky, D.B., Grezes-Besset, C., and Pelletier, E. see Lallier, E.
Parikh, N.R., Humphreys, T.P., Nemanich, R.J., Das, K., and Posthill, J.B. see Humphreys, T.P.
Parini, C.G., and Notter, M.J. see Notter, M.J.
Park, I.-C., Hong, S.-K., and Kyung, C.-M. Optimal encoding of microcommands in microprogrammed processors p393
Park, K.O., Lee, J.I., Lee, M.B., Lee, Y.J., Han, I.K., and Kang, K.N. see Lee, J.I.
Park, K.O., Lee, J.I., Lee, M.B., and Kang, K.N. see Lee, J.I.
Park, S.B., and Song, T.K. see Song, T.K.
Park, S.S., and Cho, G.H. Rotor flux controlled induction motor drive for high performance applications p439
Park, Y.K., Delavaux, J.-M.P., Barski, S., Lefevre, H., Failes, M., and Warner, C. see Delavaux, J.-M.P.
Park, Y.K., Delavaux, J.M., Tench, R.E., Barski, S., Owen, B., Tzeng, L.D., and Twu, Y. see Delavaux, J.M.
Parke, R., Waarts, R., Welch, D., Mehuys, D., Streifer, W., and Scifres, D. see Waarts, R.
Parke, R., Waarts, R., Welch, D.F., Hardy, A., and Streifer, W. High efficiency, high uniformity, grating coupled surface emitting lasers p125
Parke, R., Waarts, R.G., Welch, D.F., Hardy, A., and Streifer, W. see Waarts, R.G.
Parke, R., Welch, D., Mehuys, D., Waarts, R., Craig, R., and Scifres, D. Electronically steerable, monolithically integrated, master oscillator power amplifier p1076
Parke, R., Welch, D.F., Hardy, A., Waarts, R., Streifer, W., and Scifres, D.R. see Welch, D.F.
Parke, R., Welch, D.F., Mehuys, D., Waarts, R., Scifres, D., and Streifer, W. see Welch, D.F.
Parker, E.A., and Mokhtar, M.M. see Mokhtar, M.M.
Parker, G.J., and Starbuck, C.M.K. Selective silicon epitaxial growth by LPCVD using silane p831
Parr, R.J., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Stevens, M.L., and White, D.W. see Alexander, S.B.
Parry, G., Ghisoni, M., Gibson, M., Rivers, A., Boyd, I.W., and Roberts, J.S. see Ghisoni, M.
Parry, G., Whitehead, M., Rivers, A., and Roberts, J.S. see Whitehead, M.
Parry, G., Zouganeli, P., Whitehead, M., Stevens, P.J., Rivers, A., Roberts, J.S., and Button, C. see Zouganeli, P.
Pascal, D., Constant, M., Boussekey, L., Decoster, D., and Bartenlian, B. see Constant, M.
Pask, C., and Sammut, R.A. see Sammut, R.A.
Passenberg, W., Trommer, D., Umbach, A., Mekonnen, G., and Unterbörsch, G. see Trommer, D.
Pasternak, J.H., and Salama, C.A.T. GaAs MESFET differential pass-transistor logic

p1597
Pastol, Y., Arjavalingam, G., and Halbout, J.-M. Characterisation of an optoelectronically pulsed equiangular spiral antenna p133
Pastorino, M., Caorsi, S., and Gragnani, G.L. see Caorsi, S.
Pate, M.A., Woodhead, J., Claxton, P.A., Grey, R., Sale, T.E., David, J.P.R., Liu, L., Hill, G., and Robson, P.N. see Woodhead, J.
Patel, P., Nayar, V., and Boyd, I.W. see Nayar, V.
Paterson, A.S., Lin, M.S., and Ghaffari, H.T. see Lin, M.S.
Patnaik, L.M., and Sriram, K.B. see Sriram, K.B.
Patterson, D.R., Carlson, N.W., Stabile, P.J., Liew, S.K., Bour, D.P., and Evans, G.A. see Carlson, N.W.
Pattnaik, S.S., Mishra, R.K., and Das, N. Elliptical microstrip antenna on ferrite substrate p1906
Pattnaik, S.S., and Mishra, R.K. see Mishra, R.K.
Pattullo, D.M., Hughes, B., and Macbeth, I.C. see Hughes, B.
Pattullo, D.M., Toumazou, C., and Hughes, J.B. see Toumazou, C.
Patzak, E., Langenhorst, R., and Pieper, W. see Langenhorst, R.
Pavlidis, D., Kwon, Y., Tutt, M., Ng, G.I., Lai, R., and Brock, T. see Kwon, Y.
Pavlidis, D., Weiss, M., and Ng, G.I. see Weiss, M.
Payne, A., Toumazou, C., and Ryan, P. Differential current input cell with common mode feedback p1718
Payne, D.B., Hill, A.M., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Wyatt, R., Massicott, J.F., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. see Hill, A.M.
Payne, D.B., Hill, A.M., Wyatt, R., Massicott, J.F., Blyth, K.J., Forrester, D.S., Lobbett, R.A., and Smith, P.J. see Hill, A.M.
Payne, D.N., Cowle, G.J., Morkel, P.R., and Laming, R.I. see Cowle, G.J.
Payne, D.N., Grubb, S.G., Barnes, W.L., and Taylor, E.R. see Grubb, S.G.
Payne, D.N., Morkel, P.R., Taylor, E.M., and Townsend, J.E. see Morkel, P.R.
Payne, D.N., Morkel, P.R., and Cowle, G.J. see Morkel, P.R.
Payne, D.N., Morkel, P.R., and Laming, R.I. see Morkel, P.R.
Payne, D.N., Richardson, D.J., and Laming, R.I. see Richardson, D.J.
Payne, D.N., Suyama, M., and Laming, R.I. see Suyama, M.
Payne, F.P., Holmes, M.J., and Spirit, D.M. see Holmes, M.J.
Payne, F.P., and Mackenzie, H.S. see Mackenzie, H.S.
Pérez, F., and Alonso, J.I. see Alonso, J.I.
Peacock, D.C., Kelly, M.J., Brown, R.J., Pepper, M., Hasko, D.G., Ahmed, H., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Kelly, M.J.
Peacock, D.C., Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Pepper, M., Ahmed, H., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Pearton, S.J., Hobson, W.S., Levi, A.F.J., O'Gorman, J., Abernathy, C.R., and Swaminathan, V. see Hobson, W.S.
Pearton, S.J., Ren, F., Abernathy, C.R., Fullowan, T.R., Lothian, J., and Jordan, A.S. see Ren, F.
Pedersen, B., Povlsen, J.H., Bjarklev, A., Vendeltorp-Pommer, H., and Rottwitt, K. see Povlsen, J.H.
Pedersen, J.E., Brierley, M.C., Carter, S.F., and France, P.W. Amplification in the 1300 nm telecommunications window in a Nd-doped fluoride fibre p329 e555 e555
Pedersen, J.E., and Brierley, M. High saturation output power from a neodymium-doped fluoride fibre amplifier operating in the 1300 nm telecommunications window p819
Pei, S.-C., and Jaw, S.-B. see Jaw, S.-B.
Pei, S.-C., and Jaw, S.-B. Improved design of minimum-phase FIR digital filters by cepstrum and fast Hardtley transform p1063
Pei, S.-C., and Jaw, S.-B. Vector Hartley transform d94
Pelletier, E., Lallier, E., Pocholle, J.P., Papuchon, M., De Micheli, M., Li, M.J., He, Q., Ostrowsky, D.B., and Grezes-Besset, C. see Lallier, E.
Pena, T.F., Cabaleiro, J.C., Bruguera, J.D., and Zapata, E.L. Filtering with the fast T transform p718
Peng, G.-D. Step-by-step BSRS amplification in long-span optical fibre communication p334
Peng, G.-D., and Ankiewicz, A. Parametric design features of twin-elliptical-core optical fibres p1496 e1922
Peng, G.D., Tjugiarto, T., and Chu, P.L. Polarisation beam splitting using twin-elliptic-core optical fibres p682
Peng, X.H., and Farrell, P.G. Novel multifunctional decoder for MLD codes p1706 e1986
Peng, Z.Z., Urai, T., Frey, J., and Goldsman, N. see Urai, T.
Pepper, M., Kelly, M.J., Brown, R.J., Hasko, D.G., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Kelly, M.J.
Pepper, M., Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Ahmed, H., Peacock, D.C., Frost, J.E.F., Ritchie, D.A., and Jones, G.A.C. see Matthews, P.
Perales, A., Goldstein, L., Accard, A., Fernier, B., Leblond, F., Gourdain, C., and Brosson, P. High performance DFB-MQW lasers at 1·5 μm grown by GSMBE p236
Pereira, M.S., Vasconcelos, N.M., and Alves, A.P. Frequency accommodation and synchronisation in digital TV CODEC p2104
Pereira, R., Kuijk, M., Van Hove, M., Mertens, R.P., Borghs, G., and Pankove, J.I. see Kuijk, M.
Pereira, R., Van Hove, M., de Potter, M., and Van Rossum, M. Use of a methane/hydrogen plasma for gate recessing of E/D MESFETs p462
Perez-Aloe, R., and Duque-Carrillo, J.F. see Duque-Carrillo, J.F.
Perfetti, R. L_1 normalisation in neural networks using parallel automatic level control p82
Perfetti, R. Weight error sensitivity of fixed point attractors in associative memory networks p1985
Perucchini, D., Brugia, O., and Carbonelli, M. see Brugia, O.
Pessa, M., Keskinen, J., Näppi, J., and Asonen, H. see Keskinen, J.
Petermann, K. FM–AM noise conversion in dispersive single-mode fibre transmission lines p2097
Petermann, K., Splett, A., Schmidtchen, J., Schüppert, B., Kasper, E., and Kibbel, H. see Splett, A.
Petkovic, N., Leech, P.W., Gwynn, P.J., Pain, G.N., and Thompson, J. see Leech, P.W.
Petrovic, R., and Holmes, S. Orthogonal codes for CDMA optical fibre LANs with variable bit interval p662
Pettengill, D., Hauenschild, J., Rein, H.-M., McFarland, W., and Doernberg, J. see Hauenschild, J.
Peyre, J.-L., Zamkotsian, F., Artigue, C., Lievin, J.-L., Lambert, M., Bonnevie, D., and Benoit, J. see Zamkotsian, F.
Piccirilli, A.B., Dutta, N.K., Wang, S.J., and Werner, W.V. see Dutta, N.K.
Piccirilli, A.B., Wang, S.J., Wang, Y.J., and Dutta, N.K. see Wang, S.J.
Piedade, M.S. New analogue multiplier–divider circuit based on cyclic data convertors p2
Pieper, W., Langenhorst, R., and Patzak, E. see Langenhorst, R.
Pierce, L.E., and Weil, H. Electromagnetic scattering from nonspherical particles: A new polarisability model with application to agglomerating spheres p180
Pintzos, S.G. Dispersion characteristic of the double-sided slotline p813 e1738
Piotrowski, J., and Bartolucci, G. see Bartolucci, G.
Piotrowski, J., and Djuric, Z. see Djuric, Z.
Pistorius, C.W.I., and Boonzaaier, J.J. see Boonzaaier, J.J.
Pitts, J.M., Schormans, J.A., and Scharf, E.M. see Schormans, J.A.
Pitts, J.M., and Schormans, J.A. Analysis of ATM switch model (GEO/ATD/1) with time priorities p1192
Planel, R., Yang, D.D., Boucaud, P., Julien, F.H., Chusseau, L., and Lourtioz, J.-M. see Yang, D.D.
Ploog, K., Dämbkes, H., Marschall, P., and Zhang, Y.H. see Dämbkes, H.
Plotkin, E.I., Wulich, D., and Swamy, M.N.S. see Wulich, D.
Po, L.-M., and Chan, C.-K. Novel subspace distortion measurement for efficient implementation of image vector quantiser p480
Po, L.M., and Chan, C.K. Hierarchical mean-residual image vector quantiser using gradient-Laplacian subspace distortion p1362
Pöbl, M., Dalle, C., Freyer, J., and Harth, W. CW mm-wave GaAs TUNNETT diode p1540
Pocholle, J.P., Delacourt, D., Papillon, D., Schnell, J.P., and Papuchon, M. see Delacourt, D.
Pocholle, J.P., Lallier, E., Papuchon, M., De Micheli, M., Li, M.J., He, Q., Ostrowsky, D.B., Grezes-Besset, C., and Pelletier, E. see Lallier, E.
Podlesnik, D.V., Willner, A.E., and Osgood, R.M. see Willner, A.E.
Poggiolini, P., and Benedetto, S. see Benedetto, S.
Poignant, H., Allain, J.Y., and Monerie, M. see Allain, J.Y.
Poignant, H., Ronarc'h, D., Allain, J.Y., Guibert, M., and Monerie, M. see Ronarc'h, D.
Poisel, H., Trommer, G.F., Bühler, W., Hartl, E., and Müller, R. Low-cost fibre-optic gyroscope p69
Poladian, L., Snyder, A.W., Chen, Y., and Mitchell, D.J. see Snyder, A.W.
Poliashenko, M.F., Belogortsev, A.B., Tret'jakov, O.A., and Vavriv, D.M. see Belogortsev, A.B.
Polky, J.N., Valera, J., Darzi, A., Walker, A.C., Krug, W., Miao, E., and Derstine, M. see Valera, J.
Pollentier, I., Buydens, L., Ackaert, A., Demeester, P., Van Daele, P., De Pestel, F., Lootens, D., and Baets, R. Monolithic integration of an InGaAs/GaAs/AlGaAs strained layer SQW LED and GaAs MESFET using epitaxial lift-off p925 e1324
Pollentier, I., Demeester, P., Ackaert, A., Buydens, L., Van Daele, P., and Baets, R. Epitaxial lift-off of GaAs LEDs to Si for fabrication of optoelectronic integrated circuits p193
Pollentier, I., O'Donnell, A.C., Demeester, P., Van Daele, P., and Carr, A.D. see O'Donnell, A.C.
Ponchak, G.E., and Simons, R.N. see Simons, R.N.
Pons, D., Schmidt, P.E., Barbier, E., Collot, P., Gaonach, C., and Champagne, M. see Schmidt, P.E.
Pontes, M.S., Migliora, C.G.S., and Silva Mello, L.A.R. see Migliora, C.G.S.
Poole, C.R. Subharmonic injection locking phenomena in synchronous oscillators p1748
Pophillat, L. Novel linecoding scheme for optical transmission p2129
Popović, B.M. Complementary sets based on sequences with ideal periodic autocorrelation p1430
Popović, N. Novel method of DRO frequency tuning with varactor diode p1162
Porta, S., Martinez, P., Carlosena, A., and Celma, S. see Martinez, P.
Porter, B., and Mohamed, S.S. Iterative learning control of completely irregular plants with initial impulsive action p851
Porter, B., and Mohamed, S.S. Iterative learning control of completely irregular plants with initial state shifting p106
Post, I.R.C., and Ashburn, P. Electrical method for measuring emitter depth of shallow bipolar transistors p30
Posthill, J.B., Humphreys, T.P., Nemanich, R.J., Das, K., and Parikh, N.R. see Humphreys, T.P.
Potenza, M., Accornero, R., Artiglia, M., Coppa, G., Di Vita, P., Lapenta, G., and Ravetto, P. see Accornero, R.
Pottbäcker, A., Wüppermann, B., and Langmann, U. see Wüppermann, B.
Potter, J., and Frayne, P.G. see Frayne, P.G.
Povlsen, J.H., Bjarklev, A., Pedersen, B., Vendeltorp-Pommer, H., and Rottwitt, K. Optimum design of erbium fibre amplifiers pumped with sources emitting at 1480 nm p1419
Powazinik, W., Meland, E., Holmstrom, R., Schlafer, J., and Lauer, R.B. see Meland, E.
Powazinik, W., Rideout, W., Holmstrom, R., LaCourse, J., and Meland, E. see Rideout, W.
Pozar, D.M. Rigorous closed-form expressions for the surface wave loss of printed antennas p954
Pozar, D.M., Jackson, R.W., and Svitak, A. Microstrip antennas with integrated fibre optic feeds p1889
Prabhu, K.M.M., Anupindi, N., and Narayanan, S.B. see Anupindi, N.
Prabhu, K.M.M., and Anupindi, N. see Anupindi, N.
Prasad, R., Bertheau Johannessen, A., Bons, J.H., and Weyland, N.B.J. see Bertheau Johannessen, A.
Prasad, R., Misser, H.S., and Kegel, A. Performance analysis of direct-sequence spread-spectrum multiple-access communication in an indoor Rician-fading channel with DPSK modulation p1366
Prasad, R., and Weyland, N.B.J. see Weyland, N.B.J.
Prasad, R., and Zigic, A. see Zigic, A.
Prasad, S., Vai, M.-K., and Ng, D. see Vai, M.-K.
Prasad, V.C. Equations of nonlinear analogue circuit for fault dictionary generation p24
Preece, A.W., Jenkins, S., Hodgetts, T.E., Symm, G.T., Warham, A.G.P., and Clarke, R.N. see Jenkins, S.
Prewett, A. Transmissive quasidistributed optical fibre sensing scheme for two-state sensors p840
Pribetich, J., and Allam, R. see Allam, R.
Pribetich, P., Kinowski, D., Seguinot, C., and Kennis, P. see Kinowski, D.
Pribetich, P., Paleczny, E., Kinowski, D., Legier, J.F., and Kennis, P. see Paleczny, E.
Prokhorov, A.M., Khrushchëv, I.Yu., Grudinin, A.B., Dianov, E.M., Korobkin Jun, D.V., and Semënov, V.A. see Khrushchëv, I.Yu.
Prucnal, P.R., Goel, K.K., Shimazu, Y., Milbrodt, M., Desurvire, E., and Tell, B. see Goel, K.K.
Prucnal, P.R., and Kwong, W.C. see Kwong, W.C.
Psychalinos, C., and Haritantis, I. Parasitic insensitive single amplifier switched capacitor bandpass biquad p253
Pun, E.Y.B., Kong, T.C., Chung, P.S., and Chan, H.P. Index profile of proton-exchanged waveguides in $LiNbO_3$ using pyrophosphoric acid p81 e555 e555
Putland, P.A. Characterisation and comparison of failure modes in III-V avalanche photodiodes p298

Q

Qian, H.-S., and Zhao, Z.-J. Conjugate pair fast Fourier transform d541
Qian, S.-E., and Morris, J.M. Fast algorithm for real joint time–frequency transformations of time-varying signals p537
Qiu, B., and Hartley, M.G. Real-world image segmentation using edge detection and subtraction p353
Qua, G.J., Chandrasekhar, S., Dentai, A.G., Joyner, C.H., Johnson, B.C., and Gnauck, A.H. see Chandrasekhar, S.
Quemerais, A., Jezequel, G., L'Haridon, H., Favennec, P.N., and Salvi, M. Angle resolved X-ray photoemission study of rapid thermal annealing applied to different GaAs and InP samples p1119
Quillec, M., Kazmierski, C., Blez, M., Allovon, M., and Sermage, B. see Kazmierski, C.

Rabinovici, R. Three phase high frequency DC–DC convertor p829

Rabrenović, D., and Lutovac, M. see Lutovac, M.

Rabrenović, D., and Lutovac, M. Low Q equiripple functions of nonminimum order p447

Radehaus, C., Pankove, J., and Wagner, K. see Pankove, J.

Radev, P. General approach to designing the XX2B-AMI coding family p1043

Radmore, P.M., and Bayvel, P. see Bayvel, P.

Radoslovich-Cibicki, V., Lott, J.A., Kiem, J.F., Weaver, H.T., and Tigges, C.P. see Lott, J.A.

Ragay, F.W., Aite, K., and Middelhoek, J. see Aite, K.

Ragdale, C.M., Reid, D.C.J., Bennion, I., Robbins, D.J., Buus, J., and Stewart, W.J. see Reid, D.C.J.

Rahmat-Samii, Y., and Duan, D.W. see Duan, D.W.

Railton, C.J., and McGeehan, J.P. Characterisation of microstrip open-end with rectangular and trapezoidal cross-section p685

Rajeswari, K.R., Moharir, P.S., and Rao, K.V. see Moharir, P.S.

Ramakrishna, P.V., and Chadha, D. Perturbation analysis of finlines containing anisotropic media p571

Ramamurthi, B., and Jegannathan, S. see Jegannathan, S.

Ramos, J., Marcerou, J.F., Fevrier, H., Auge, J., and Dursin, A. see Marcerou, J.F.

Ramos, P.A., Allison, S.W., and Gillies, G.T. see Allison, S.W.

Ramos, R.T., and Seeds, A.J. Delay, linewidth and bandwidth limitations in optical phase-locked loop design p389 e1922

Ramponi, G., Sicuranza, G.L., and Marsi, S. see Sicuranza, G.L.

Ranson, D., Carter, S.F., Moore, M.W., Szebesta, D., Williams, J.R., and France, P.W. see Carter, S.F.

Rao, E.V.K., Bradley, M.A., Julien, F.H., Gilles, J.P., Gao, Y., Razeghi, M., and Omnes, F. see Bradley, M.A.

Rao, K.V., Moharir, P.S., and Rajeswari, K.R. see Moharir, P.S.

Rao, M.V., Chang, G.-K., and Hong, W.-P. High-sensitivity and high-speed InGaAs photoconductive detector p756

Rao, P., and Taylor, F.J. Estimation of instantaneous frequency using the discrete Wigner distribution p246

Rao, T.C.K. Attenuation characteristics of a circular chirowaveguide p1767

Rappaport, D.A., Devasirvatham, D.M.J., Krain, M.J., and Banerjee, C. see Devasirvatham, D.M.J.

Rappaport, T.S., Seidel, S.Y., and Singh, R. see Seidel, S.Y.

Rappaport, T.S., and Hawbaker, D.A. see Hawbaker, D.A.

Ravaioli, U., and Lee, C. see Lee, C.

Raven, M.S., Sellai, A., Steenson, D.P., Chamberlain, J.M., Henini, M., and Hughes, O.H. see Sellai, A.

Raven, M.S., Zarea, A., Sellai, A., Steenson, D.P., Chamberlain, J.M., Henini, M., and Hughes, O.H. see Zarea, A.

Ravetto, P., Accornero, R., Artiglia, M., Coppa, G., Di Vita, P., Lapenta, G., and Potenza, M. see Accornero, R.

Ravikumar, K.G., Kikugawa, T., Aizawa, T., Arai, S., and Suematsu, Y. see Kikugawa, T.

Ray, S., Griem, H.T., Fuji, H.S., Williams, T.J., Harrang, J.P., Daniels, R.R., LaGasse, M.J., and West, D.L. see Griem, H.T.

Ray, S.K., Maiti, C.K., and Chakrabarti, N.B. Electrical properties of silicon dioxide deposited at low temperature by metal-organic microwave plasma CVD technique p1082

Ray Liu, K.J. VLSI computing architectures for Haar transform p1962

Raybon, G., Koren, U., Oron, M., Young, M.G., Miller, B.I., De Miguel, J.L., and Chien, M. see Koren, U.

Razeghi, M., Bradley, M.A., Julien, F.H., Gilles, J.P., Gao, Y., Rao, E.V.K., and Omnes, F. see Bradley, M.A.

Reddy, V.K., Tsao, A.J., and Neikirk, D.P. High peak-to-valley current ratio AlGaAs/AlAs/GaAs double barrier resonant tunnelling diodes p1742

Redstall, R.M., Skeats, A.P., Cooper, D.M., and Burness, A.L. Preliminary reliability studies of 1·55 μm graded index separate confinement buried heterostructure (GRINSCH) multiple quantum well (MQW) lasers grown by metalorganic vapour phase epitaxy (MOVPE) p1132

Reed, J., Ünlü, M.S., Kishino, K., Chyi, J.-I., Arsenault, L., and Morkoç, H. see Ünlü, M.S.

Reekie, L., Mwarania, E.K., Wang, J., and Wilkinson, J.S. see Mwarania, E.K.

Reeve, H.C., Siller, Jun, C.A., and Debus, W. see Siller, Jun, C.A.

Regnault, J.C., Bird, D.M., Fatah, R.M., Cox, M.K., Constantine, P.D., and Cameron, K.H. see Bird, D.M.

Regnault, J.E., Al-Chalabi, S.A., Mellis, J., Hollier, M., Cameron, K.H., Wyatt, R., Devlin, W.J., and Brain, M.C. see Al-Chalabi, S.A.

Reich, M. Novel method for linearising the power response of optical time domain reflectometers p1029 e1738

Reichenbach, D., Zah, C.E., Andreadakis, N., Favire, F.J., Menocal, S.G., Vodhanel, R., Yi-Yan, A., and Lee, T.P. Phase modulation characteristics of 1·5 μm strained-layer multiple quantum well laser amplifiers p1858

Reichert, W.F., Evans, G.A., Carlson, N.W., Bour, D.P., Hammer, J.M., Lurie, M., Butler, J.K., Amantea, R., Liew, S.K., Kirk, J.B., DeFreez, R.K., and Bossert, D.J. see Evans, G.A.

Reid, D.C.J., Kirkby, C.J.G., and Jou, D.C. see Kirkby, C.J.G.

Reid, D.C.J., Ragdale, C.M., Bennion, I., Robbins, D.J., Buus, J., and Stewart, W.J. Phase-shifted Moiré grating fibre resonators p10

Reid, I., Learmouth, M.D., Hewett, N.P., and Robertson, M.J. see Learmouth, M.D.

Reid, I., MacBean, M.D.A., Hewett, N.P., and Learmouth, M.D. see MacBean, M.D.A.

Rein, H.-M., Hauenschild, J., McFarland, W., Doernberg, J., and Pettengill, D. see Hauenschild, J.

Rein, H.-M., Hauenschild, J., Schmidt, L., and Wörner, K. see Hauenschild, J.

Rein, H.-M., and Schmidt, L. see Schmidt, L.

Reineix, A., Vaudon, P., and Jecko, B. see Vaudon, P.

Reinhart, F.K., Wüthrich, C., James, J.H., and Ganière, J.D. see Wüthrich, C.

Reinhart, F.K., Wüthrich, C., and Faist, J. see Wüthrich, C.

Reithmaier, J.-P., Riechert, H., Bernklau, D., and Schnell, R.D. see Riechert, H.

Rejman-Greene, M.A.Z., Barnes, N., Healey, P., Scott, E.G., and Webb, R.P. see Barnes, N.

Rejman-Greene, M.A.Z., Barnes, N.M., Healey, P., McKee, P., O'Neill, A.W., Scott, E.G., Webb, R.P., and Wood, D. see Barnes, N.M.

Rejman-Greene, M.A.Z., and Scott, E.G. Packaged 2×2 array of InGaAs/InP multiple quantum well modulators grown by double-sided epitaxy p946

Ren, F., Abernathy, C.R., Pearton, S.J., Fullowan, T.R., Lothian, J., and Jordan, A.S. 0GaAs–AlGaAs HBT with carbon doped base layer grown by MOMBE p724

Ren, F., Kuo, T.Y., Chiu, T.H., Cunningham, J.E., Goossen, K.W., and Fonstad, C.G. see Kuo, T.Y.

Ren, F., Kuo, T.Y., Cunningham, J.E., Goossen, K.W., Jan, W.Y., and Fonstad, C.G. see Kuo, T.Y.

Renaud, M., Cavaillès, J.A., Jarry, P., Erman, M., Vinchant, J.F., and Goutelle, A. see Cavaillès, J.A.

Renner, H. Excess loss in practical depressed-cladding fibres d1546

Reyneri, L.M., and Filippi, E. Modified back-propagation algorithm for fast learning in neural networks p1564

Riaziat, M., Majidi-Ahy, R., Nishimoto, C., Glenn, M., Silverman, S., Weng, S., Pao, Y.C., Zdasiuk, G., Bandy, S., and Tan, Z. see Majidi-Ahy, R.

Richardson, D.J., Laming, R.I., and Payne, D.N. Very low threshold Sagnac switch incorporating an erbium doped fibre amplifier p1779

Rideout, W., Holmstrom, R., LaCourse, J., Meland, E., and Powazinik, W. Ultra-low-reflectivity semiconductor optical amplifiers without anti-reflection coatings p36

Riechert, H., Bernklau, D., Reithmaier, J.-P., and Schnell, R.D. High performance resonant tunnelling structures on GaAs substrates p340

Riggs, L.S., German, F.J., and Gothard, G.K. see German, F.J.

Riggs, R., and Delavaux, J-M.P. see Delavaux, J-M.P.

Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Young, J., Cheung, N.K., and Tarbox, E.J. 11 Gbit/s, 260 km transmission experiment using a directly-modulated 1536 nm DFB laser with two Er-doped fibre amplifiers and clock recovery p330

Ripamonti, G., Ghioni, M., and Vanoli, S. Photon timing OTDR: A multiphoton backscattered pulse approach p1569

Ritchie, D.A., Kelly, M.J., Brown, R.J., Pepper, M., Hasko, D.G., Ahmed, H., Peacock, D.C., Frost, J.E.F., and Jones, G.A.C. see Kelly, M.J.

Ritchie, D.A., Matthews, P., Kelly, M.J., Law, V.J., Hasko, D.G., Pepper, M., Ahmed, H., Peacock, D.C., Frost, J.E.F., and Jones, G.A.C. see Matthews, P.

Rivers, A., Ghisoni, M., Gibson, M., Boyd, I.W., Parry, G., and Roberts, J.S. see Ghisoni, M.

Rivers, A., Whitehead, M., Parry, G., and Roberts, J.S. see Whitehead, M.

Rivers, A., Zouganeli, P., Whitehead, M., Stevens, P.J., Parry, G., Roberts, J.S., and Button, C. see Zouganeli, P.

Riviere, L., Saulnier, J., Huet, F., Carre, M., and Caumont, G. see Saulnier, J.

Rizzoli, V., and Neri, A. Expanding the power-handling capabilities of harmonic-balance analysis by a parametric formulation of the MESFET model p1359

Röll, G., Kluitmans, J.T.M., Kuindersma, P.I., Meier, M., Mink, J., and Will, D.J. see Kluitmans, J.T.M.

Robbins, D.J., Farries, M.C., and Buus, J. see Farries, M.C.

Robbins, D.J., Moseley, A.J., Thompson, J., Kearley, M.Q., and Goodwin, M.J. see Moseley, A.J.

Robbins, D.J., Reid, D.C.J., Ragdale, C.M., Bennion, I., Buus, J., and Stewart, W.J. see Reid, D.C.J.

Roberts, J., Krauss, T., and Laybourn, P.J.R. see Krauss, T.

Roberts, J.S., Ghisoni, M., Gibson, M., Rivers, A., Boyd, I.W., and Parry, G. see Ghisoni, M.

Roberts, J.S., McIlvaney, K., Marsh, J.H., and Button, C. see McIlvaney, K.

Roberts, J.S., O'Neill, M., Marsh, J.H., De La Rue, R.M., Button, C., and Gwilliam, R. see O'Neill, M.

Roberts, J.S., Thirstrup, C., Wa, P.L.K., Button, C.C., and Robson, P.N. see Thirstrup, C.

Roberts, J.S., Whitehead, M., Rivers, A., and Parry, G. see Whitehead, M.

Roberts, J.S., Zouganeli, P., Whitehead, M., Stevens, P.J., Rivers, A., Parry, G., and Button, C. see Zouganeli, P.

Robertson, M.J., Learmouth, M.D., Hewett, N.P., and Reid, I. see Learmouth, M.D.

Robson, P.N., Thirstrup, C., Wa, P.L.K., Button, C.C., and Roberts, J.S. see Thirstrup, C.

Robson, P.N., Woodhead, J., Claxton, P.A., Grey, R., Sale, T.E., David, J.P.R., Liu, L., Pate, M.A., and Hill, G. see Woodhead, J.

Rock, F., Levinson, M., Rossoni, P., and Ditchek, B.M. see Levinson, M.

Rodler, H., Noé, R., Gaukel, G., Ebberg, A., and Auracher, F. see Noé, R.

Rodler, H., Noé, R., Gaukel, G., Noll, B., and Ebberg, A. see Noé, R.

Rodwell, M.J.W., Yu, R.Y., Case, M., Kamegawa, M., Sundaram, M., and Gossard, A.W. see Yu, R.Y.

Roentgen, P., Korn, M., Körfer, T., and Forchel, A. see Korn, M.

Rogers, A.J., Chen, S., and Meggitt, B.T. see Chen, S.

Rogers, P.H., Ballance, J.W., and Halls, M.F. see Ballance, J.W.

Rogers, T.J., Deppe, D.G., Campbell, J.C., Kuchibhotla, R., and Streetman, B.G. see Deppe, D.G.

Rolland, C., Keyworth, B.P., Cada, M., Glinski, J.M., SpringThorpe, A.J., and Hill, K.O. see Keyworth, B.P.

Ronarc'h, D., Allain, J.Y., Guibert, M., Monerie, M., and Poignant, H. Erbium-doped fluoride optical amplifier operating around 2·75 μm p903

Rondi, D., Blondeau, R., Krakowski, M., Glastre, G., and Vilain, G. see Blondeau, R.

Rong, A. Accurate modelling of unilateral finline–coplanar waveguide transition p1123

Rong, A. Extension of spectral domain approach to unilateral finlines with finite metallisation thickness and substrate supporting grooves p1728

Rong, A. Transmission characteristics of suspended striplines with finite metallisation thickness and substrate supporting grooves p431

Rong, A., and Li, S. Effects of finite metallisation thickness and substrate supporting grooves on the characteristics of E plane strip in a finline p760

Rong, A., and Li, S. Frequency dependent transmission characteristics of microstrip lines on the finite width substrate or near a substrate edge p782

Rong, A.S. Attractive behaviours of NRD leaky wave antenna with tuning aperture p1887

Rooryck, M., Juy, M., Maurel, R., Nugroho, I.A., and Hariman, T. see Juy, M.

Rosen, H.J., Krantz, M.C., and Lenth, W. see Krantz, M.C.

Rosenzweig, M., Ludwig, R., Moehrle, M., Schnabel, R., Schunk, N., and Weber, H.G. see Ludwig, R.

Rosher, P.A., and Fenning, S.C. Multichannel video transmission over 100 km of step index single-mode fibre using a directly modulated 1537 nm distributed feedback laser p534

Rossi, B., Blau, W., O'Gorman, J., König, S., Westland, D., and Skarda, V. Diode laser waveguiding in polydiacetylene films p312

Rossoni, P., Levinson, M., Rock, F., and Ditchek, B.M. see Levinson, M.

Rottwitt, K., Povlsen, J.H., Bjarklev, A., Pedersen, B., and Vendeltorp-Pommer, H. see Povlsen, J.H.

Rowe, C.J., Moore, M.W., Wilkinson, I.J., and Achurch, N.E. Fused taper couplers in multimode fluorozirconate fibre p316

Rowe, C.J., and Wilkinson, I.J. see Wilkinson, I.J.

Rücker, F., Ortgies, G., and Dintelmann, F. see Ortgies, G.

Rubio, A., Figueras, J., and Segura, J. Quiescent current sensor circuits in digital VLSI CMOS testing p1204

Runge, K., Young, J., Bagheri, M., Millicker, D., Kipnis, I., and Snapp, C. Hybrid 11 Gbit/s parallel processing decision circuit using submicron silicon bipolar ICs p1402

Runham, M., and Baden Fuller, A.J. see Baden Fuller, A.J.

Russell, P.St. J., and Hand, D.P. Rocking filter formation in photosensitive high birefringence optical fibres p1846

Russer, P., Anzill, W., Goeller, T., Kaertner, F.X., and Buechler, J. see Anzill, W.

Rutherford, M., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Trivett, D., and Brain, M. see Creaner, M.J.

Rutherford, M., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J.,

Al Chalabi, S., Hale, W., Sturgess, I., Trivett, D., and Brain, M. see Creaner, M.J.
Rutkovsky, P.F., Medved, A.V., and Mishkinis, R.A. see Medved, A.V.
Ryan, P., Payne, A., and Toumazou, C. see Payne, A.
Ryoji, A., Ota, Y., Hirose, T., and Inada, M. see Ota, Y.

S

Sabatier, C., Behe, R., and Brachat, P. Approximate formulas for step discontinuities in circular waveguides p173
Sacher, J., Nietzke, R., Elsässer, W., and Göbel, E.O. see Nietzke, R.
Saguet, P., Ndagijimana, F., and Bouthinon, M. see Ndagijimana, F.
Saifi, M., Way, W.I., Maeda, M.W., Yi-Yan, A., Andrejco, M.J., Choy, M.M., and Lin, C. see Way, W.I.
Saifi, M.A., Tohme, H.E., and Lo, C.N. see Tohme, H.E.
Saito, S., Imai, T., Sugie, T., Ohkawa, N., Ichihashi, Y., and Ito, T. Coherent transmission experiment over 2223 km at 2·5 Gbit/s using erbium-doped fibre amplifiers p669
Saitoh, Y., and Imai, H. Some classes of burst asymmetric or unidirectional error correcting codes p286
Sakamoto, M., Cardinal, M.R., Endriz, J.G., Welch, D.F., and Scifres, D.R. Performance characteristics of high power CW, 1 cm wide monolithic AlGaAs laser diode arrays with a 2 mm total aperture width p422
Sakamoto, M., Welch, D.F., Yao, H., Endriz, G., and Scifres, D.R. High power, high brightness 2 W (200 μm) and 3 W (500 μm) CW AlGaAs laser diode arrays with long lifetimes p729
Sakano, T., Noguchi, K., Hogari, K., and Matsumoto, T. see Noguchi, K.
Salama, C.A.T., and Pasternak, J.H. see Pasternak, J.H.
Sale, T.E., Woodhead, J., Claxton, P.A., Grey, R., David, J.P.R., Liu, L., Pate, M.A., Hill, G., and Robson, P.N. see Woodhead, J.
Saleh, A.A.M., Stone, J., and Stulz, L.W. see Stone, J.
Salvi, M., Favennnec, P.N., L'Haridon, H., Moutonnet, D., and Papadopoulo, A.C. see Favennnec, P.N.
Salvi, M., Kechouane, M., L'Haridon, H., Favennec, P.N., Moutonnet, D., Gauneau, M., and Mercier, J.P. see Kechouane, M.
Salvi, M., Quemerais, A., Jezequel, G., L'Haridon, H., and Favennec, P.N. see Quemerais, A.
Sammut, R.A., and Pask, C. Variational approach to nonlinear waveguides—Gaussian approximations p1131
Sampson, D.D., and Jackson, D.A. Spread-spectrum optical fibre network based on pulsed coherent correlation p1550
Samson, P.J. Analysis of the wavelength dependence of Raman backscatter in optical fibre thermometry p163
Sandbank, C.P., Drewery, J.O., and Weston, M. Compatible enhancement of terrestrial PAL TV transmission p195
Sanders, S., Eng, L., and Yariv, A. Passive mode-locking of monolithic InGaAs/AlGaAs double quantum well lasers at 42 GHz repetition rate p1087
Sandler, M.B., and Ben-Tzvi, D. see Ben-Tzvi, D.
Sandler, M.B., and Hayat, L. see Hayat, L.
Sangalli, M., Canali, C., Magistrali, F., Tedesco, C., and Zanoni, E. see Canali, C.
Sangalli, M., Canali, C., Tedesco, C., Zanoni, E., Castellaneta, G., and Magistrali, F. see Canali, C.
Sansen, W., Silva-Martinez, J., and Steyaert, M. see Silva-Martinez, J.
Sarkady, K.A., Havlicek, J.P., Katz, G.R., and McKeeman, J.C. see Havlicek, J.P.
Saruwatari, M., Iwatsuki, K., Nishi, S., and Shimizu, M. see Iwatsuki, K.
Saruwatari, M., Iwatsuki, K., and Okamura, H. see Iwatsuki, K.
Sasaki, A., Noda, S., Yamada, E., and Takayama, T. see Noda, S.
Sasaki, G., Yano, H., Aga, K., Kamei, H., and Hayashi, H. see Yano, H.
Sasaki, S., Kitajima, S., Tsushima, H., Okai, M., and Yamashita, K. see Kitajima, S.
Sasaki, S., Nakano, H., Tsuji, S., Uomi, K., and Yamashita, K. see Nakano, H.
Sasaki, S., Tsushima, H., Takeyari, R., Kitajima, S., Kuboki, K., and Uomi, K. see Tsushima, H.
Sasaki, S., Uomi, K., Tsuchiya, T., Okai, M., Aoki, M., and Chinone, N. see Uomi, K.
Sato, K., Soda, H., Furutsu, M., Okazaki, N., Yamazaki, S., Nishimoto, H., and Ishikawa, H. see Soda, H.
Sato, K., Toba, H., Oda, K., Nakanishi, K., Shibata, N., Nosu, K., and Takato, N. see Toba, H.
Sato, S., Iso, A., Orikasa, T., and Sugimoto, T. Ku band electric models for large deployable mesh reflector antenna p2091
Sauer, N., Zucker, J.E., Jones, K.L., Chang, T.Y., Tell, B., Brown-Goebeler, K., Wegener, M., and Chemla, D.S. see Zucker, J.E.
Saulnier, G.J., and Thiel, T.E. see Thiel, T.E.
Saulnier, J., Huet, F., Riviere, L., Carre, M., and Caumont, G. Interferometric-type polarisation splitter on Z-propagating $LiNbO_3$: Ti p1940
Saunier, P., and Tserng, H.Q. see Tserng, H.Q.
Sawaya, K., Yatabe, S., and Adachi, S. Exterior moment method analysis of conducting scatterers by using the interior Green's function p631
Sayano, M., and Goodman, R.M. see Goodman, R.M.
Sayles, A., Smyth, P.P., Wyatt, R., Fidler, A., Eardley, P., and Craig-Ryan, S. see Smyth, P.P.
Scaramuzza, R., and Lowery, A.J. Hybrid symmetrical condensed node for the TLM method p1947
Schaff, W.J., Offsey, S.D., Tasker, P.J., Kapitan, L., Shealy, J.R., and Eastman, L.F. see Offsey, S.D.
Schanen, C., Illek, S., Thulke, W., Lang, H., and Amann, M.-C. see Illek, S.
Scharf, E.M., Schormans, J.A., and Pitts, J.M. see Schormans, J.A.
Schaumann, R., and Wu, P. see Wu, P.
Scheffer, H., Dombek, K.-P., Hombach, V., and Thielen, H. see Dombek, K.-P.
Scherer, A., Lee, Y.H., Jewell, J.L., Tell, B., Brown-Goebeler, K.F., Harbison, J.P., and Florez, L.T. see Lee, Y.H.
Schiebel, R.A., Dodge, J., and Gooch, R. 0HgCdTe sampling circuit p702
Schilling, M., Schweizer, H., Dütting, K., Idler, W., Kühn, E., Nowitzki, A., and Wünstel, K. Widely tunable Y-coupled cavity integrated interferometric injection laser p243
Schimpe, R., and Amann, M.-C. see Amann, M.-C.
Schlafer, J., Meland, E., Holmstrom, R., Lauer, R.B., and Powazinik, W. see Meland, E.
Schleicher, L., Tews, H., Zwicknagl, P., Neumann, R., Jaeger, G., Hoepfner, A., and Packeiser, G. see Tews, H.
Schmalz, K., Skorupa, W., and Kögler, R. see Skorupa, W.
Schmidt, L., Hauenschild, J., Rein, H.-M., and Wörner, K. see Hauenschild, J.
Schmidt, L., and Rein, H.-M. New high-speed bipolar XOR gate with absolutely symmetrical circuit configuration p430
Schmidt, P.E., Barbier, E., Collot, P., Gaonach, C., Champagne, M., and Pons, D. Transconductance dependence on gate length for GaAs gate pseudomorphic and conventional SISFETs at 300 and 77 K p210
Schmidtchen, J., Splett, A., Schüppert, B., Petermann, K., Kasper, E., and Kibbel, H. see Splett, A.
Schnabel, R., Ludwig, R., Moehrle, M., Rosenzweig, M., Schunk, N., and Weber, H.G. see Ludwig, R.
Schnell, J.P., Delacourt, D., Papillon, D., Pocholle, J.P., and Papuchon, M. see Delacourt, D.
Schnell, R.D., Riechert, H., Bernklau, D., and Reithmaier, J.-P. see Riechert, H.
Schöpflin, A., Kugelmeier, S., Gottwald, E., Felicio, D., and Fischer, G. PSK optical homodyne system with nonlinear phase-locked loop p395
Schoepflin, A. 565 Mbit/s optical DPSK and PSK heterodyne transmission experiment using Nd : YAG lasers at 1·3 μm p255
Schormans, J.A., Scharf, E.M., and Pitts, J.M. Analysis of telecommunications switch model (GEO/D/1) with time priorities p325
Schormans, J.A., and Pitts, J.M. see Pitts, J.M.
Schorp, B., Wallmeroth, K., Wandernoth, B., Franz, J., and Meier, H. see Wallmeroth, K.
Schremer, A.T., Loh, W.H., and Tang, C.L. see Loh, W.H.
Schüppert, B., Splett, A., Schmidtchen, J., Petermann, K., Kasper, E., and Kibbel, H. see Splett, A.
Schütz, R., Matsushita, K., Hartnagel, H.L., Longère, J.Y., and Krawczyk, S.K. Suppression of InP substrate degradation by hydrogen plasma caused by the presence of phosphorus vapour p564
Schulte-Roth, G., Müller, G., Stoll, L., and Wolff, U. see Müller, G.
Schultes, G., Bonek, E., Weger, P., and Herzog, W. Basic performance of a direct conversion DECT receiver p1746
Schumacher, H., Lin, P.S.D., Hong, W.-P., Kim, O.-H., Bhat, R., and Van Der Gaag, B. see Lin, P.S.D.
Schumacher, H., Shah, D.M., Chan, W.K., Gmitter, T.J., Florez, L.T., and Van der Gaag, B.P. see Shah, D.M.
Schumacher, H., Shantharama, L.G., Leblanc, H.P., Esagui, R., Bhat, R., and Koza, M. see Shantharama, L.G.
Schumacher, H., Soole, J.B.D., LeBlanc, H.P., Bhat, R., and Koza, M.A. Noise behaviour of InAlAs/GaInAs MSM photodetectors p612
Schunk, N., Ludwig, R., Moehrle, M., Rosenzweig, M., Schnabel, R., and Weber, H.G. see Ludwig, R.
Schweizer, H., Schilling, M., Dütting, K., Idler, W., Kühn, E., Nowitzki, A., and Wünstel, K. see Schilling, M.
Scifres, D., Parke, R., Welch, D., Mehuys, D., Waarts, R., and Craig, R. see Parke, R.
Scifres, D., Waarts, R., Parke, R., Welch, D., Mehuys, D., and Streifer, W. see Waarts, R.
Scifres, D., Welch, D., Craig, R., and Streifer, W. see Welch, D.
Scifres, D., Welch, D.F., Cardinal, M., and Streifer, B. see Welch, D.F.
Scifres, D., Welch, D.F., Mehuys, D., Parke, R., Waarts, R., and Streifer, W. see Welch, D.F.
Scifres, D.R., Mehuys, D., Welch, D.F., and Nam, D.W. see Mehuys, D.
Scifres, D.R., Sakamoto, M., Cardinal, M.R., Endriz, J.G., and Welch, D.F. see Sakamoto, M.
Scifres, D.R., Sakamoto, M., Welch, D.F., Yao, H., and Endriz, G. see Sakamoto, M.
Scifres, D.R., Streifer, W., Hardy, A., Welch, D.F., and Cross, P.S. see Streifer, W.
Scifres, D.R., Welch, D.F., Parke, R., Hardy, A., Waarts, R., and Streifer, W. see Welch, D.F.
Scott, E.G., Barnes, N., Healey, P., Rejman-Greene, M.A.Z., and Webb, R.P. see Barnes, N.
Scott, E.G., Barnes, N.M., Healey, P., McKee, P., O'Neill, A.W., Rejman-Greene, M.A.Z., Webb, R.P., and Wood, D. see Barnes, N.M.
Scott, E.G., and Rejman-Greene, M.A.Z. see Rejman-Greene, M.A.Z.
Scrivener, P.L., Maton, P.D., Appleyard, A.P., and Tarbox, E.J. Fabrication and properties of large core, high NA, high Nd^{3+} content multimode optical fibres for temperature sensor applications p872
Séguin, G., Bhargava, V.K., and Allard, P.E. see Bhargava, V.K.
Sealy, B.J., and Whitehead, N.J. see Whitehead, N.J.
Sedra, A.S., Duncan, R.A., and Smith, K.C. see Duncan, R.A.
Sedra, A.S., Wania, X.F., and Johns, D.A. see Wania, X.F.
Seeds, A.J., Benjamin, R., and Zaglanikis, C.D. see Benjamin, R.
Seeds, A.J., and Ramos, R.T. see Ramos, R.T.
Seevinck, E. Companding current-mode integrator: a new circuit principle for continuous-time monolithic filters p2046
Seferidis, V., and Ghanbari, M. Use of co-occurrence matrices in the temporal domain p1116
Segawa, T., Maekawa, Y., Chang, N.S., and Miyazaki, A. see Maekawa, Y.
Seguinot, C., Kinowski, D., Pribetich, P., and Kennis, P. see Kinowski, D.
Segura, J., Rubio, A., and Figueras, J. see Rubio, A.
Seidel, S.Y., Rappaport, T.S., and Singh, R. Path loss and multipath delay statistics in four European cities for 900 MHz cellular and microcellular communications p1713
Seki, T., Ogura, M., Mukai, S., Shimada, M., Asaka, T., Yamasaki, Y., and Iwano, H. see Ogura, M.
Sekine, K., Dooi, Y., Iso, A., Funaki, H., and Takei, I. UHF band high-efficiency linear power amplifier for mobile communication satellites p441
Selker, M.D., and Lawandy, N.M. Stimulated Raman scattering seeded by a fibre continuum p409
Sellai, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., Henini, M., and Hughes, O.H. Double-barrier resonant tunnelling diode three-state logic p61
Sellai, A., Zarea, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., Henini, M., and Hughes, O.H. see Zarea, A.
Selle, D., Carisetti, D., Ducourant, T., Bertsch, P., and Boissenot, P. 8 GHz full Nyquist HBT comparator p919
Seltzer, C.P., Bagley, M., Wyatt, R., Elton, D.J., Wickes, H.J., Spurdens, P.C., Cooper, D.M., and Devlin, W.J. see Bagley, M.
Selviah, D.R., Mao, Z.Q., and Midwinter, J.E. Opto-electronic high order feedback neural network p1954
Semënov, V.A., Khrushchëv, I.Yu., Grudinin, A.B., Dianov, E.M., Korobkin Jun, D.V., and Prokhorov, A.M. see Khrushchëv, I.Yu.
Semkow, M., Mørk, J., and Tromborg, B. see Mørk, J.
Semnani, S., and Holt, M.J.J. see Holt, M.J.J.
Senani, R., Tripathi, M.P., Bhaskar, D.R., and Kumar, B.A. Systematic generation of OTA-C sinusoidal oscillators p1457
Senani, R., and Singh, V.K. see Singh, V.K.
Sergent, A.M., Tsang, W.T., Wu, M.C., Yang, L., and Chen, Y.K. see Tsang, W.T.
Serio, M., Aina, L., Mattingly, M., Hempfling, E., and Chien, H. see Aina, L.
Serio, M., Aina, O., Mattingly, M., and Hempfling, E. see Aina, O.
Sermage, B., Kazmierski, C., Blez, M., Quillec, M., and Allovon, M. see Kazmierski, C.
Seto, M., Shahar, A., and Tomlinson, W.J. see Shahar, A.
Seto, M., Yi-Yan, A., Gmitter, T.J., Hwang, D.M., and Florez, L.T. see Yi-Yan, A.
Sevenhans, J., Bijker, W., Vorenkamp, P., and Steyaert, M. Performance of an ECL-compatible 75 Ω line driver/receiver realised in a 1·2 μm CMOS technology p764
Sewell, J.I., Toumazou, C., Haigh, D.G., Harrold, S.J., Steptoe, K., and Bayruns, R. see Toumazou, C.
Shafi, M., Chen, S.X., Smith, P.J., and Vere-Jones, D. see Chen, S.X.
Shagurin, I.I., Izosimov, O.A., and Tsylyov, V.V. see Izosimov, O.A.
Shah, D.M., Chan, W.K., Gmitter, T.J., Florez, L.T., Schumacher, H., and Van der Gaag, B.P. DC and RF performance of GaAs MESFET fabricated on silicon substrate using epitaxial lift-off technique p1865
Shahar, A., Tomlinson, W.J., and Seto, M. Modified configuration for a high-finesse compact loop resonator for semiconductor integrated optics

p1528 e1922
Shaklan, S. Measurement of intermodal coupling in weakly multimode fibre optics p2022
Shakouri, M.S., Marsland, R.A., and Bloom, D.M. see Marsland, R.A.
Shana, Z.A., Josse, F., Haworth, D.T., and Kelkar, U.R. see Josse, F.
Shani, Y., Kuo, C.Y., Ackerman, D.A., Henry, C.H., Dahbura, M.I., Kistler, R., and Wagner, E.J. see Kuo, C.Y.
Shank, S.M., and Wicks, G.W. Enhanced electro-optic polarisation rotation in AlGaAs/GaAs (111) quantum wells p1769
Shantharama, L.G., Schumacher, H., Leblanc, H.P., Esagui, R., Bhat, R., and Koza, M. Evaluation of single ohmic metallisations for contacting both *p*- and *n*-type GaInAs p1127
Shaout, A., and Colagiovanni, L. see Colagiovanni, L.
Sharaiha, A., and Terret, C. Overlapping quadrifilar resonant helix antenna p1090
Shaw, D.I., Bennett, J.C., and Clements, A.M. Analysis of 'D type' flip-flop frequency changers p1995
Shaw, G.-T., and Liu, B.-D. see Liu, B.-D.
Shaw, H.J., Fesler, K., Digonnet, M., Liu, K., and Kim, B.Y. see Fesler, K.
Shaw, M., Honary, B., and Darnell, M. see Honary, B.
Shawe-Taylor, J., and Cohen, D. see Cohen, D.
Shealy, J.R., Offsey, S.D., Tasker, P.J., Schaff, W.J., Kapitan, L., and Eastman, L.F. see Offsey, S.D.
Sheat, D.E., Leggatt, J.S., and McCartney, D.J. Position tunable volume reflection gratings for narrowband filtering applications (FWHM <5 nm) in optical fibre systems p42
Sheikh, A.U.H., and Yao, Y.-D. see Yao, Y.-D.
Shen, H., Tong, Q.-Y., and Xu, X.-L. see Tong, Q.-Y.
Shen, Q. Fuzzy intraframe smoothing of a noisy image p908
Shen, Q., and Guo, G. see Guo, G.
Shen, Z.X., Lou, X.M., and Li, S.F. Analysis of groove guides with grooves of arbitrary shape p472
Shen, Z.X., Lou, X.M., and Li, S.F. Transverse resonance method for analysing T-septum waveguides p78
Sheng, L.G., and Xing, L.D. see Xing, L.D.
Shepherd, C., Gibson, G., and Hayes, D. Simple method to calculate the maximum user density for microwave point-to-point links p1554
Shepherd, D.P., Field, S.J., Hanna, D.C., Tropper, A.C., Chandler, P.J., Townsend, P.D., and Zhang, L. see Field, S.J.
Shepherd, F.R., Blaauw, C., Devenyi, T.F., Capron, B., and Springthorpe, A.J. see Blaauw, C.
Shepherd, T.J., Broomhead, D.S., Jones, R., and McWhirter, J.G. see Broomhead, D.S.
Sheridan, J.T., and Solymar, L. Boundary diffraction coefficients for calculating spurious beams produced by volume gratings p1840
Sherlock, G., Bagley, M., Cooper, D.M., Westbrook, L.D., Elton, D.J., Wickes, H.J., Spurdens, P.C., and Devlin, W.J. see Bagley, M.
Sherlock, G., Ellis, A.D., Cox, J.D., Bird, D.M., Cameron, K., Elton, D.J., and Stallard, W.A. see Ellis, A.D.
Shi, T.-T., and Chi, S. see Chi, S.
Shibata, N., Toba, H., Oda, K., Nakanishi, K., Nosu, K., Takato, N., and Sato, K. see Toba, H.
Shih, C.-H., Jen, B.-S., Chang, M.-W., Sun, S.-W., and Wu, T.-M. see Jen, B.-S.
Shikada, M., Fujita, S., Suzaki, T., Matsuoka, A., Miyazaki, S., Torikai, T., and Nakata, T. see Fujita, S.
Shikada, M., Suzaki, T., Suzuki, Y., Yamada, H., Fujita, S., Hida, H., and Kitamura, M. see Suzaki, T.
Shima, A., Kamizato, T., Takami, A., Karakida, S., Isshiki, K., and Matsubara, H. 780 nm, low threshold current laser fabricated by two-step, solid-phase Zn diffusion p915 e1739
Shimada, M., Ogura, M., Mukai, S., Asaka, T., Yamasaki, Y., Seki, T., and Iwano, H. see Ogura, M.
Shimazu, Y., Goel, K.K., Prucnal, P.R., Milbrodt, M., Desurvire, E., and Tell, B. see Goel, K.K.
Shimazu, Y., and Tsukada, M. see Tsukada, M.
Shimbo, A., and Kawamura, S. Factorisation attack on certain server-aided computation protocols for the RSA secret transformation p1387
Shimizu, J., Suzaki, T., Terakado, T., Fujita, S., Kasahara, K., Itoh, T., and Suzuki, A. High sensitivity, high gain, long wavelength OEIC receiver with monolithically integrated three-stage preamplifier p824
Shimizu, M., Horiguchi, M., Yamada, M., Okayasu, M., Takeshita, T., Nishi, I., Uehara, S., Noda, J., and Sugita, E. Highly efficient integrated optical fibre amplifier module pumped by a 0·98 μm laser diode p498
Shimizu, M., Horiguchi, M., Yamada, M., Yoshino, K., and Hanafusa, H. see Horiguchi, M.
Shimizu, M., Iwatsuki, K., Nishi, S., and Saruwatari, M. see Iwatsuki, K.
Shimizu, M., Yamada, M., Horiguchi, M., Takeshita, T., and Okayasu, M. Erbium-doped fibre amplifiers with an extremely high gain coefficient of 11·0 dB/mW p1641
Shimizu, M., Yamada, M., Okayasu, M., and Horiguchi, M. see Yamada, M.
Shimony, O., Ben-Yaakov, S., Edry, D., and Amran, Y. see Ben-Yaakov, S.
Shimoyama, K., Suzuki, Y., Yajima, H., Inoue, Y., Katoh, M., and Gotoh, H. see Suzuki, Y.
Shin, C.-H., and Ohtsu, M. Improved Allan variance real-time processing system to measure frequency tracking error of heterodyne optical phase-locked loops p1571
Shin, H., Tasch, A.F., and Maziar, C.M. see Tasch, A.F.
Shinagawa, M., and Nagatsuma, T. Electro-optic sampling using an external GaAs probe tip p1341
Shinkai, J., Katsuyama, T., Yoshida, I., Hashimoto, J., and Hayashi, H. see Katsuyama, T.
Shiozawa, H., Ishikawa, M., Tsuburai, Y., and Uematsu, Y. see Ishikawa, M.
Shirafuji, J., Sugino, T., and Ito, H. see Sugino, T.
Shirasaki, M., Yokota, I., and Touge, T. 20 Gbit/s no-chirp intensity modulation by DPSH-IM method and its fibre transmission through 330 ps/nm dispersion p33
Shore, K.A., and Chan, D.A.S. Kramers–Kronig relations for nonlinear optics p1206
Short, K.T., Goossen, K.W., and White, A.E. see Goossen, K.W.
Shui, Y., Yin, J.H., Zhang, D., Yu, J., and Wu, P. see Yin, J.H.
Shukla, V.S., Singh, M.P., and Kearns, R.F. Modal noise power penalty in high speed short single-mode fibre interconnections p732
Shum, H.Y., and Tso, S.K. see Tso, S.K.
Shur, M.S., Zou, J., Gopinath, A., and Akinwande, T. see Zou, J.
Shuster, E.M., Manasson, V.A., and Tovstyuk, K.D. see Manasson, V.A.
Shyn, J.-S., Hsieh, C.-H., Lu, P.-C., and Lu, E.-H. see Hsieh, C.-H.
Sibbett, W., and Burns, D. see Burns, D.
Sicuranza, G.L., Ramponi, G., and Marsi, S. Artificial neural network for image compression p477
Siddiqui, A.S., and Yu, A. Effect of enhancing the Raman gain factor on the linearity of Raman fibre amplifiers p1661
Siebert, J.P., and Urquhart, C.W. Active stereo: Texture enhanced reconstruction p427
Sihvola, A.H., and Lindell, I.V. Chiral Maxwell–Garnett mixing formula p118
Sihvola, A.H., and Lindell, I.V. Polarisability and mixing formula for chiral ellipsoids p1007
Siller, Jun, C.A., Reeve, H.C., and Debus, W. Digital passband filtering of megabaud transmitted data stream p2024
Sillitoe, I.P.W., and Szumko, S. Novel robust sensor for surface edge location in robotic applications p1811
Silva Mello, L.A.R., Migliora, C.G.S., and Pontes, M.S. see Migliora, C.G.S.
Silva-Martinez, J., Steyaert, M., and Sansen, W. Very linear CMOS floating resistor p1610
Silverman, S., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Weng, S., Pao, Y.C., Zdasiuk, G., Bandy, S., and Tan, Z. see Majidi-Ahy, R.
Silvestro, J., and Butler, C.M. Acceleration of series form of the Green's function for a magnetic line current in the presence of a conducting wedge p975
Simons, N.R.S., and Bridges, E. Method for modelling free space boundaries in TLM simulations p453
Simons, R.N., and Lee, R.Q. Coplanar-waveguide/microstrip probe coupler and applications to antennas p1998
Simons, R.N., and Ponchak, G.E. Coax-to-channelised coplanar waveguide in-phase, N-way, radial power divider p754
Simpson, A., Davies, R., and McGeehan, J.P. see Davies, R.
Simpson, J.R., Andrekson, P.A., Olsson, N.A., Tanbun-Ek, T., Logan, R.A., Becker, P.C., and Wecht, K.W. see Andrekson, P.A.
Simpson, J.R., Ko, Y.T., DiGiovanni, D.J., and MacChesney, J.B. see Ko, Y.T.
Singer, K.E., and Khamsehpour, B. see Khamsehpour, B.
Singh, M.P., Shukla, V.S., and Kearns, R.F. see Shukla, V.S.
Singh, R., Seidel, S.Y., and Rappaport, T.S. see Seidel, S.Y.
Singh, V.K., and Senani, R. New multifunction active filter configuration employing current conveyors p1814
Siu, W.-C., and Chan, Y.-H. see Chan, Y.-H.
Siu, W.-C., and Lun, D.P.-K. see Lun, D.P.-K.
Sivco, D.L., Dutta, N.K., Wynn, J.D., Lopata, J., and Cho, A.Y. see Dutta, N.K.
Skarda, V., Rossi, B., Blau, W., O'Gorman, J., König, S., and Westland, D. see Rossi, B.
Skeats, A.P., Redstall, R.M., Cooper, D.M., and Burness, A.L. see Redstall, R.M.
Skellern, D.J., and Lau, Y.-H. see Lau, Y.-H.
Skevington, P.J., Cole, S., Duncan, W.J., Marsh, E.M., and Spiller, G.D.T. see Cole, S.
Skinner, I., Hill, K.O., Malo, B., Vineberg, K.A., Bilodeau, F., and Johnson, D.C. see Hill, K.O.
Skorupa, W., Kögler, R., and Schmalz, K. Carrier lifetime increase in silicon by gettering with a MeV-implanted carbon-rich layer p1898
Smart, R.G., Carter, J.N., Hanna, D.C., and Tropper, A.C. see Carter, J.N.
Smart, R.G., Carter, J.N., Hanna, D.C., and Tropper, A.C. Erbium doped fluorozirconate fibre laser operating at 1·66 and 1·72 μm p649
Smit, M.K., Hammes, P.C.A., Krijnen, G.J.M., and Driessen, A. see Hammes, P.C.A.
Smith, A.C., and Owens, R.P. see Owens, R.P.
Smith, K., Armitage, J.R., Wyatt, R., Doran, N.J., and Kelly, S.M.J. Erbium fibre soliton laser p1149
Smith, K.C., Duncan, R.A., and Sedra, A.S. see Duncan, R.A.
Smith, K.C., and Ho, H.-L. see Ho, H.-L.
Smith, P., Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Wyatt, R., Massicott, J.F., Lobbett, R.A., and Hodgkinson, T.G. see Hill, A.M.
Smith, P.A., Davis, L.E., McN Alford, N., and Button, T.W. Frequency dependence of surface resistance of bulk high temperature superconductor p1486 e1738
Smith, P.J., Chen, S.X., Shafi, M., and Vere-Jones, D. see Chen, S.X.
Smith, P.J., Hill, A.M., Wyatt, R., Massicott, J.F., Blyth, K.J., Forrester, D.S., Lobbett, R.A., and Payne, D.B. see Hill, A.M.
Smith, P.M., Avramov, I.D., and Edmonson, P.J. see Avramov, I.D.
Smith, P.M., Chao, P.C., Ho, P., Duh, K.H.G., Ballingall, J.M., Jabra, A.A., Lewis, N., and Hall, E.L. see Chao, P.C.
Smith, P.R., Jeong, J., Lum, R.M., Klingert, J.K., Bylsma, R., and Vella-Coleiro, G.P. see Jeong, J.
Smith, P.R., Lunardi, L.M., Archer, V.D., Swartz, R.G., Kuo, J.M., Kopf, R.F., and Malik, R.J. see Lunardi, L.M.
Smuk, J.W., Stubbs, M.G., and Wight, J.S. Enhanced microwave characterisation technique for cryogenic temperatures p2127
Smyth, P.P., Wyatt, R., Fidler, A., Eardley, P., Sayles, A., and Craig-Ryan, S. 152 photons per bit detection at 622 Mbit/s to 2·5 Gbit/s using an erbium fibre preamplifier p1604
Snapp, C., Runge, K., Young, J., Bagheri, M., Millicker, D., and Kipnis, I. see Runge, K.
Snowden, C.M., Xue, H., and Howes, M.J. see Xue, H.
Snyder, A.W., Chen, Y., Poladian, L., and Mitchell, D.J. Fundamental mode of highly nonlinear fibres p643
Snyder, A.W., Chen, Y., and Mitchell, D.J. see Chen, Y.
Snyder, A.W., Mitchell, D.J., and Chen, Y. see Mitchell, D.J.
Soda, H., Furutsu, M., Sato, K., Okazaki, N., Yamazaki, S., Nishimoto, H., and Ishikawa, H. High-power and high-speed semi-insulating BH structure monolithic electroabsorption modulator/DFB laser light source p9
Soda, H., Kawamura, H., Kamite, K., Yonetani, H., Ogita, S., and Ishikawa, H. see Kawamura, H.
Soda, H., Sugano, M., Sudo, H., Kusunoki, T., and Ishikawa, H. see Sugano, M.
Soddu, C., Cacopardi, S., Caporicci, L., and Falzini, S. see Cacopardi, S.
Sodha, J., and Tait, D.J. Soft-decision syndrome based node synchronisation p1108 e1738
Sokolov, I.A., and Stepanov, S.I. Nonsteady-state photovoltage in crystals with long photoconductivity relaxation times p1275
Soltz, B.A., Yellen, S.L., Waters, R.G., Chen, Y.C., Fischer, S.E., Fekete, D., and Ballantyne, J.M. see Yellen, S.L.
Solymar, L., and Sheridan, J.T. see Sheridan, J.T.
Sombra, A.S.B., Ainslie, B.J., Blow, K.J., Gouveia-Neto, A.S., Wigley, P.G.J., and Taylor, J.R. see Ainslie, B.J.
Some, Y.K., and Tan, B.T. see Tan, B.T.
Son, H., Cho, Y.K., and Hong, J.P. see Cho, Y.K.
Song, J., and Kim, M. Improved ICMA/CD protocol in packet mobile radio networks p182
Song, T.K., and Park, S.B. Novel multirate sampling technique for ultrasound electronic sector scanning p71
Soole, J.B.D., Schumacher, H., LeBlanc, H.P., Bhat, R., and Koza, M.A. see Schumacher, H.
Soole, J.B.D., Tsang, H.K., White, I.H., LeBlanc, H.P., Bhat, R., and Koza, M.A. High performance QCSE phase modulator for the 1·5–1·55 μm fibre band p1421
Soraghan, J.J., Liu, Y., and Durrani, T. see Liu, Y.
Soref, R.A., Lareau, R.D., and Friedman, L. see Lareau, R.D.
Sotom, M., Flaarønning, N., Frorud, J.O., Vendrôme, G., Da Loura, G., Gabriagues, J.M., Jacquet, J., Leclerc, D., and Benoit, J. see Flaarønning, N.
Spano, P., Hui, R., Mecozzi, A., and D'Ottavi, A. see Hui, R.
Spano, P., van Deventer, M.O., and Nielsen, S.K. see van Deventer, M.O.
Spear, D.A.H., Lee, W.S., Agnew, M.J., Dawe, P.J.G., and Bland, S.W. see Lee, W.S.
Spear, D.A.H., Lee, W.S., Dawe, P.J.G., and Bland, S.W. see Lee, W.S.
Spiller, G.D.T., Cole, S., Duncan, W.J., Marsh, E.M., and Skevington, P.J. see Cole, S.
Spirit, D., Creaner, M.J., Steele, R.C., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Spirit, D., Creaner, M.J., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and

Brain, M. see Creaner, M.J.
Spirit, D.M., Blank, L.C., Williams, D.L., Davey, S.T., and Ainslie, B.J. 5 Gbit/s, +10 dBm lossless transmission in 10 km distributed erbium fibre amplifier p1658
Spirit, D.M., Bryant, E.G., Carter, S.F., Lewis, R.B.J., Widdowson, T., and Wright, J.V. see Bryant, E.G.
Spirit, D.M., Davey, S.T., Williams, D.L., and Ainslie, B.J. see Davey, S.T.
Spirit, D.M., Holmes, M.J., and Payne, F.P. see Holmes, M.J.
Spirit, D.M., Walker, G.R., France, P.W., Carter, S.F., and Szebesta, D. Characterisation of diode-pumped erbium-doped fluorozirconate fibre optical amplifier p1218 e1739
Spirit, D.M., Williams, D.L., Davey, S.T., and Ainslie, B.J. see Williams, D.L.
Splett, A., Schmidtchen, J., Schüppert, B., Petermann, K., Kasper, E., and Kibbel, H. Low loss optical ridge waveguides in a strained GeSi epitaxial layer grown on silicon p1035
Spooner, T.P., Wake, D., Judge, S.N., Harlow, M.J., Duncan, W.J., Henning, I.D., and O'Mahony, M.J. see Wake, D.
Sprey, M.A., and Bird, T.S. see Bird, T.S.
SpringThorpe, A.J., Keyworth, B.P., Cada, M., Glinski, J.M., Rolland, C., and Hill, K.O. see Keyworth, B.P.
Springthorpe, A.J., Blaauw, C., Devenyi, T.F., Capron, B., and Shepherd, F.R. see Blaauw, C.
Spurdens, P.C., Bagley, M., Sherlock, G., Cooper, D.M., Westbrook, L.D., Elton, D.J., Wickes, H.J., and Devlin, W.J. see Bagley, M.
Spurdens, P.C., Bagley, M., Wyatt, R., Elton, D.J., Wickes, H.J., Seltzer, C.P., Cooper, D.M., and Devlin, W.J. see Bagley, M.
Sridharan, S., Dawson, E., and Goldburg, B. Speech encryption in the transform domain p655
Srikanthan, S., Hill, A.M., and Wright, J.V. see Hill, A.M.
Srikanthan, S., and Gordon, J. see Gordon, J.
Sriram, K.B., and Patnaik, L.M. Neural network approach for the two-dimensional assignment problem p809
St J Russell, P., Culverhouse, D., and Farahi, F. Experimental observation of forward stimulated Brillouin scattering in dual-mode single-core fibre p1195
Stabile, P.J., Carlson, N.W., Patterson, D.R., Liew, S.K., Bour, D.P., and Evans, G.A. see Carlson, N.W.
Stallard, W.A., Boggis, J., Lord, A., Violas, M., and Heatley, D. see Boggis, J.
Stallard, W.A., Bryant, E.G., Carter, S.F., Ellis, A.D., Wright, J.V., and Wyatt, R. see Bryant, E.G.
Stallard, W.A., Cox, J.D., Boggis, J.M., Bryant, E.G., and Hunter, C.A. see Cox, J.D.
Stallard, W.A., Ellis, A.D., Cox, J.D., Bird, D.M., Cameron, K., Elton, D.J., and Sherlock, G. see Ellis, A.D.
Stallard, W.A., Lord, A., Wilkinson, I.J., Ellis, A., Cleland, D., and Garnham, R.A. see Lord, A.
Stallard, W.A., Sundaresan, H., Kwan, S., Lord, A., Duncan, W.J., Henning, I.D., and Broughton, C. see Sundaresan, H.
Stallard, W.A., and Malyon, D.J. see Malyon, D.J.
Standley, R.D., Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Young, J., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Stanley, C.R., Adams, J.A., Thayne, I.G., Taylor, M.R.S., Wilkinson, C.D.W., Beaumont, S.P., Johnson, N.P., and Kean, A.H. see Adams, J.A.
Stapleton, S.P., Deen, M.J., Berolo, E., and Hardy, R.H.S. Experimental study of microwave reflection gain of AlAs/GaAs/AlAs quantum well structures p84
Stapleton, S.P., Deen, M.J., and Hardy, R.H.S. Novel power combining technique for MMIC oscillators p300
Starbuck, C.M.K., and Parker, G.J. see Parker, G.J.
Stasiński, R. Extending sizes of effective convolution algorithms p1602
Steele, R., Nofal, M., and Eldolil, S. Adaptive algorithm for variable teletraffic demand in highway microcells p988
Steele, R.C., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Steele, R.C., and Walker, G.R. 622 Mbit/s AMI FSK optical transmission experiment using a semiconductor optical preamplifier and a Fabry–Perot etalon demodulator p539
Steenson, D.P., Sellai, A., Raven, M.S., Chamberlain, J.M., Henini, M., and Hughes, O.H. see Sellai, A.
Steenson, D.P., Zarea, A., Sellai, A., Raven, M.S., Chamberlain, J.M., Henini, M., and Hughes, O.H. see Zarea, A.
Stefanelli, B., and Kaiser, A. CMOS triode transconductor with high dynamic range p880
Stefanović, M., and Drača, D. see Drača, D.
Stegeman, G.I., Aramaki, S., and Assanto, G. see Aramaki, S.
Stegeman, G.I., Hibino, Y., and Mizrahi, V. see Hibino, Y.
Stegeman, G.I., LaRochelle, S., Hibino, Y., and Mizrahi, V. see LaRochelle, S.
Stepanov, S.I., and Sokolov, I.A. see Sokolov, I.A.
Steptoe, K., Toumazou, C., Haigh, D.G., Harrold, S.J., Sewell, J.I., and Bayruns, R. see Toumazou, C.
Stevens, M.L., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., and White, D.W. see Alexander, S.B.
Stevens, P.J., Zouganeli, P., Whitehead, M., Rivers, A., Parry, G., Roberts, J.S., and Button, C. see Zouganeli, P.
Stewart, W.J., Reid, D.C.J., Ragdale, C.M., Bennion, I., Robbins, D.J., and Buus, J. see Reid, D.C.J.
Steyaert, M., Sevenhans, J., Bijker, W., and Vorenkamp, P. see Sevenhans, J.
Steyaert, M., Silva-Martinez, J., and Sansen, W. see Silva-Martinez, J.
Stocker, K.E., and Landstorfer, F.M. Optimisation of UHF antennas p241
Stoffel, N.G., Chang-Hasnain, C.J., Maeda, M.W., Harbison, J.P., Florez, L.T., and Jewell, J. see Chang-Hasnain, C.J.
Stoffel, N.G., Lo, Y.H., Bagheri, M., Lin, P.S.D., Grabbe, P., Bhat, R., Lee, T.P., and Kong, D.T. see Lo, Y.H.
Stoll, L., Müller, G., Schulte-Roth, G., and Wolff, U. see Müller, G.
Stoltz, B., Granestrand, P., Lagerström, B., Svensson, P., Thylén, L., Bergvall, K., Falk, J.-E., and Olofsson, H. see Granestrand, P.
Stone, J., Jopson, R.M., Stulz, L.W., and Licht, S.J. Enhancement of Faraday rotation in a fibre Fabry–Perot cavity p849
Stone, J., Stulz, L.W., and Saleh, A.A.M. Three-mirror fibre Fabry–Perot filters of optimal design p1073
Stone, J., and Stulz, L.W. FiEnd filters: Passive multilayer thin-film optical filters deposited on fibre ends p1290
Stoyanov, G.K., and Topalov, I.P. see Topalov, I.P.
Streetman, B.G., Deppe, D.G., Campbell, J.C., Kuchibhotla, R., and Rogers, T.J. see Deppe, D.G.
Strege, K.E., Twu, Y., Wang, S.J., Kuo, C.Y., Wynn, J.D., Brown, R.L., Gruezke, L.A., Lin, M.S., and Dutta, N.K. see Twu, Y.
Streifer, B., Welch, D.F., Cardinal, M., and Scifres, D. see Welch, D.F.
Streifer, W., Hardy, A., Welch, D.F., Scifres, D.R., and Cross, P.S. Improved Y–X junction laser array p1730
Streifer, W., Parke, R., Waarts, R., Welch, D.F., and Hardy, A. see Parke, R.
Streifer, W., Waarts, R., Parke, R., Welch, D., Mehuys, D., and Scifres, D. see Waarts, R.
Streifer, W., Waarts, R.G., Mehuys, D., and Welch, D.F. see Waarts, R.G.
Streifer, W., Waarts, R.G., Welch, D.F., Parke, R., and Hardy, A. see Waarts, R.G.
Streifer, W., Welch, D., Craig, R., and Scifres, D. see Welch, D.
Streifer, W., Welch, D.F., Mehuys, D., Parke, R., Waarts, R., and Scifres, D. see Welch, D.F.
Streifer, W., Welch, D.F., Parke, R., Hardy, A., Waarts, R., and Scifres, D.R. see Welch, D.F.
Strite, S., Ünlü, M.S., Adomi, K., Gao, G.B., and Morkoç, H. see Ünlü, M.S.
Stuart, T.A., and Chen, K. see Chen, K.
Stubbs, M.G., Smuk, J.W., and Wight, J.S. see Smuk, J.W.
Stuckman, B.E., and Hill, J.C. Method of null steering in phased array antenna systems p1216
Stulz, L.W., Stone, J., Jopson, R.M., and Licht, S.J. see Stone, J.
Stulz, L.W., Stone, J., and Saleh, A.A.M. see Stone, J.
Stulz, L.W., and Stone, J. see Stone, J.
Sturgess, I., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Sturgess, I., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Stylianou, A., and Vardaxoglou, J.C. Improved convergence of iterative scheme for analysing arrays of finite size p641 e1324
Sudo, H., Sugano, M., Soda, H., Kusunoki, T., and Ishikawa, H. see Sugano, M.
Suematsu, Y., Kikugawa, T., Ravikumar, K.G., Aizawa, T., and Arai, S. see Kikugawa, T.
Sugano, M., Sudo, H., Soda, H., Kusunoki, T., and Ishikawa, H. Effects of zinc doping in DFB lasers emitting at 1·3 and 1·55 μm p95
Sugawa, T., Miyajima, Y., and Komukai, T. see Miyajima, Y.
Sugawa, T., Miyajima, Y., and Komukai, T. 10 dB gain and high saturation power in a Nd^{3+}-doped fluorozirconate fibre amplifier p2042
Sugie, T., Imai, T., Hayashi, Y., Ohkawa, N., Ichihashi, Y., and Ito, T. see Imai, T.
Sugie, T., Imai, T., Ohkawa, N., Ichihashi, Y., and Ito, T. see Imai, T.
Sugie, T., Imai, T., and Ito, T. Over 350 km CPFSK repeaterless transmission at 2·5 Gbit/s employing high-output power erbium-doped fibre amplifiers p1577
Sugie, T., Saito, S., Imai, T., Ohkawa, N., Ichihashi, Y., and Ito, T. see Saito, S.
Sugimoto, H., Ohishi, T., Abe, Y., Ohtsuka, K., and Matsui, T. see Ohishi, T.
Sugimoto, M., Tashiro, Y., Ogura, I., Hamao, N., and Kasahara, K. see Tashiro, Y.
Sugimoto, T., Sato, S., Iso, A., and Orikasa, T. see Sato, S.
Sugimoto, Y., Hidaka, H., Akita, K., and Taneya, M. see Hidaka, H.
Sugino, T., Ito, H., and Shirafuji, J. Barrier height enhancement of InP Schottky junctions by treatment with photo-decomposed PH3 e2137
Sugita, A., Jinguji, K., Takato, N., and Kawachi, M. see Jinguji, K.
Sugita, E., Shimizu, M., Horiguchi, M., Yamada, M., Okayasu, M., Takeshita, T., Nishi, I., Uehara, S., and Noda, J. see Shimizu, M.
Sugitani, S., Ohhata, M., Yamane, Y., Enoki, T., Kato, N., Hagimoto, K., and Hirayama, M. see Ohhata, M.
Sugitani, S., Ohhata, M., Yamane, Y., Enoki, T., Kato, N., and Hirayama, M. see Ohhata, M.
Sugiura, T., Nakano, H., Vichien, K., and Yamauchi, J. see Nakano, H.
Suh, I.H., Oh, Y.S., and Bien, Z. see Oh, Y.S.
Suhara, T., Fujimura, M., Kinoshita, K., and Nishihara, H. Reduction of DC drift in $LiNbO_3$ waveguide electro-optic devices by phosphorus doping in SiO_2 buffer layer p1409
Suman, P. Some results on Reed-Muller coefficients p1026
Sumida, M. Polarisation insensitive configuration of semiconductor laser amplifier p1913
Summerfield, S. Simple multiplexer circuit for CMOS VLSI p878
Sun, S.-W., Jen, R.-S., Chang, M.-W., Shih, C.-H., and Wu, T.-M. see Jen, R.-S.
Sundaram, M., Yu, R.Y., Case, M., Kamegawa, M., Rodwell, M.J.W., and Gossard, A.W. see Yu, R.Y.
Sundaresan, H., Kwan, S., Lord, A., Duncan, W.J., Henning, I.D., Stallard, W.A., and Broughton, C. Highly reproducible ridge waveguide multi-electrode DFB lasers for optical communication systems p1876
Sundaresan, H., and Fletcher, N.C. Correlation of relative intensity noise with linewidth floors in narrow linewidth DFB lasers p2002
Sundaresan, H., and Fletcher, N.C. Direct observation of shot noise in linewidth broadening of DBR lasers p2004
Sundaresan, H., and Wickens, G.E. Very high amplitude, minimal chirp optical pulse generation at 1·55 μm using multicontact DFBs and an erbium doped fibre amplifier p725
Suyama, M., Laming, R.I., and Payne, D.N. Temperature dependent gain and noise characteristics of a 1480 nm-pumped erbium-doped fibre amplifier p1756
Suyama, M., and Minelly, J.D. see Minelly, J.D.
Suyten, F.M.M., Diemeer, M.B.J., Trommel, E.S., McDonach, A., Copeland, J.M., Jenneskens, L.W., and Horsthuis, W.H.G. see Diemeer, M.B.J.
Suzaki, T., Fujita, S., Matsuoka, A., Miyazaki, S., Torikai, T., Nakata, T., and Shikada, M. see Fujita, S.
Suzaki, T., Shimizu, J., Terakado, T., Fujita, S., Kasahara, K., Itoh, T., and Suzuki, A. see Shimizu, J.
Suzaki, T., Suzuki, Y., Yamada, H., Fujita, S., Hida, H., Kitamura, M., and Shikada, M. 10 Gbit/s optical transmitter module with MQW DFB-LD and DMT driver IC p151
Suzuki, A., Shimizu, J., Suzaki, T., Terakado, T., Fujita, S., Kasahara, K., and Itoh, T. see Shimizu, J.
Suzuki, H. Performance of a new adaptive diversity-equalisation for digitial mobile radio p626
Suzuki, K., Kimura, Y., and Nakazawa, M. High gain Er^{3+}-doped fibre amplifier pumped by 820 nm GaAlAs laser diodes p948
Suzuki, K., Nakazawa, M., Kimura, Y., and Yoshida, E. see Nakazawa, M.
Suzuki, K., Nakazawa, M., Yamada, E., and Kimura, Y. see Nakazawa, M.
Suzuki, K., Nakazawa, M., Yamada, E., and Kimura, Y. 5 Gbit/s, 250 km error-free soliton transmission with Er^{3+}-doped fibre amplifiers and repeaters p551
Suzuki, K., Nakazawa, M., and Kimura, Y. see Nakazawa, M.
Suzuki, K., Nakazawa, M., and Yamada, E. see Nakazawa, M.
Suzuki, K., and Nakazawa, M. Automatic optical soliton control using cascaded Er^{3+}-doped fibre amplifiers p1032
Suzuki, M., Aoki, M., Uomi, K., Tsuchiya, T., and Chinone, N. see Aoki, M.
Suzuki, M., Kado, Y., Okazaki, Y., and Kobayashi, T. see Kado, Y.
Suzuki, M., Tanaka, H., and Matsushima, Y. see Tanaka, H.
Suzuki, S., Kobayashi, S., Kitoh, T., Hida, Y., and Yamaguchi, M. see Kobayashi, S.
Suzuki, S., Takahashi, H., Kato, K., and Nishi, I. see Takahashi, H.
Suzuki, Y., Suzaki, T., Yamada, H., Fujita, S., Hida, H., Kitamura, M., and Shikada, M. see Suzaki, T.
Suzuki, Y., Yajima, H., Shimoyama, K., Inoue, Y., Katoh, M., and Gotoh, H. Heterojunction field effect transistor laser p1632
Svedin, J.A.M. Finite-element analysis of chirowaveguides p928
Svensson, A. Reduced state sequence detection of full response continuous phase modulation p652
Svensson, P., Granestrand, P., Lagerström, B., Thylén, L., Stoltz, B., Bergvall, K., Falk, J.-E., and

Olofsson, H. see Granestrand, P.
Sverdlov, B., Both, W., Bochkarev, A., and Drakin, A. see Both, W.
Svitak, A., Pozar, D.M., and Jackson, R.W. see Pozar, D.M.
Swaminathan, V., Hobson, W.S., Levi, A.F.J., O'Gorman, J., Pearton, S.J., and Abernathy, C.R. see Hobson, W.S.
Swamy, M.N.S., Wulich, D., and Plotkin, E.I. see Wulich, D.
Swanson, J.G., and Luck, J. see Luck, J.
Swart, P.L., and Lacquet, B.M. see Lacquet, B.M.
Swartz, R.G., Lunardi, L.M., Archer, V.D., Kuo, J.M., Kopf, R.F., Malik, R.J., and Smith, P.R. see Lunardi, L.M.
Sweeney, D.G., and McKeeman, J.C. Design of a hybrid receiver for the OLYMPUS spacecraft beacons p934
Syme, R.T., Kelly, M.J., Condie, A., and Dale, I. Asymmetric resonant tunnelling diodes as microwave detectors p1904
Symm, G.T., Jenkins, S., Hodgetts, T.E., Warham, A.G.P., Clarke, R.N., and Preece, A.W. see Jenkins, S.
Syrzycki, M. Electrical test structure for measuring polysilicon-to-active mask misalignment p1009
Szebesta, D., Carter, S.F., Moore, M.W., Williams, J.R., Ranson, D., and France, P.W. see Carter, S.F.
Szebesta, D., Spirit, D.M., Walker, G.R., France, P.W., and Carter, S.F. see Spirit, D.M.
Szumko, S., and Sillitoe, I.P.W. see Sillitoe, I.P.W.

T

Tabuchi, H., and Ishikawa, H. External grating tunable MQW laser with wide tuning range of 240 nm p742
Taga, H., Edagawa, N., Yoshida, Y., Yamamoto, S., Mochizuki, K., and Wakabayashi, H. see Edagawa, N.
Taga, H., Yoshida, Y., Edagawa, N., Yamamoto, S., and Wakabayashi, H. 459 km, 2·4 Gbit/s four wavelength multiplexing optical fibre transmission experiment using six Er-doped fibre amplifiers p500
Tai, K., Hasnain, G., Wynn, J.D., Fischer, R.J., Wang, Y.H., Weir, B., Gamelin, J., and Cho, A.Y. 90% coupling of top surface emitting GaAs/AlGaAs quantum well laser output into 8 μm diameter core silica fibre p1628
Tai, K., Hasnain, G., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Tai, K.L., Lin, M.S., and Engvik, A.H. see Lin, M.S.
Tait, D.J., and Sodha, J. see Sodha, J.
Tajima, K. Er^{3+}-doped single-polarisation optical fibres p1498
Takachio, N., Iwashita, K., Nakanishi, K., and Koike, S. 8 Gbit/s 202 km optical CPFSK transmission experiment using 1·3 μm zero dispersion fibre p506
Takada, A., and Masuda, H. see Masuda, H.
Takada, A., and Miyazawa, H. 30 GHz picosecond pulse generation from actively mode-locked erbium-doped fibre laser p216
Takagi, A., Jinguji, K., and Kawachi, M. Broadband silica-based optical waveguide coupler with asymmetric structure p132
Takagi, S., and Czarnul, Z. see Czarnul, Z.
Takahashi, H., Suzuki, S., Kato, K., and Nishi, I. Arrayed-waveguide grating for wavelength division multi/demultiplexer with nanometre resolution p87
Takahashi, S., Koguchi, N., Chikyow, T., Kiyosawa, T., Fujiwara, J., and Yoshihara, K. PbS/PbSrS multi-quantum well laser emitting in the mid-infrared wavelength region p1715
Takahashi, Y., Ando, K., Miyata, M., and Amada, E. New retiming and synchronisation scheme for optical ATM switching systems p99
Takahashi, Y., Hartman, D.H., and Inoue, H. see Hartman, D.H.
Takami, A., Shima, A., Kamizato, T., Karakida, S., Isshiki, K., and Matsubara, H. see Shima, A.
Takanashi, H., Aikawa, S., and Nakamura, Y. BER improvement due to transversal equaliser in trellis-coded multi-level QAM digital microwave radio p406
Takanashi, Y., Fukano, H., Kawamura, Y., Asai, H., and Fujimoto, M. see Fukano, H.
Takano, Y., Yonezu, H., Himeno, T., Kanamori, K., and Pak, K. see Yonezu, H.
Takato, N., Jinguji, K., Sugita, A., and Kawachi, M. see Jinguji, K.
Takato, N., Toba, H., Oda, K., Nakanishi, K., Shibata, N., Nosu, K., and Sato, K. see Toba, H.
Takayama, T., Noda, S., Yamada, E., and Sasaki, A. see Noda, S.
Takefuji, Y., Kurokawa, T., Lee, K.C., and Cho, Y.B. see Kurokawa, T.
Takei, I., Sekine, K., Dooi, Y., Iso, A., and Funaki, H. see Sekine, K.
Takemoto, K., Hakamata, Y., and Isido, K. see Hakamata, Y.
Takemoto, K., Yokota, N., and Hakamata, Y. see Yokota, N.
Takeshita, T., Shimizu, M., Horiguchi, M., Yamada, M., Okayasu, M., Nishi, I., Uehara, S., Noda, J., and Sugita, E. see Shimizu, M.
Takeshita, T., Shimizu, M., Yamada, M., Horiguchi, M., and Okayasu, M. see Shimizu, M.
Takeyari, R., Tsushima, H., Sasaki, S., Kitajima, S., Kuboki, K., and Uomi, K. see Tsushima, H.
Talty, T., Lee, K.F., and Lee, R.Q. see Lee, K.F.
Talty, T., Lee, R.Q., and Lee, K.F. see Lee, R.Q.
Tan, B.T., and Some, Y.K. Crest factor minimisation in FDM PSK systems p859
Tan, M.R.T., Kim, I., Chang, J., and Wang, S.Y. Velocity matching of III-V travelling-wave electro-optic modulator structures p32
Tan, Y.K., and Lim, Y.C. Self-timed system design technique p284
Tan, Z., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Silverman, S., Weng, S., Pao, Y.C., Zdasiuk, G., and Bandy, S. see Majidi-Ahy, R.
Tanaka, H., Suzuki, M., and Matsushima, Y. Reduction of thermal interference on lasing wavelength for DFB LD/EA modulator integrated light source p2124
Tanaka, S., Hayama, N., Furukawa, A., Baba, T., Mizuta, M., and Honjo, K. Low-frequency noise performance of self-aligned InAlAs/InGaAs heterojunction bipolar transistors p1439
Tanaka, S., Kusuda, Y., and Yamashita, K. see Kusuda, Y.
Tanaka, T., and Minagawa, S. Carrier-induced refractive-index change, mode gain and spontaneous-emission factor in AlGaInP SQW-SCH laser diodes p766
Tanbun-Ek, T., Andrekson, P.A., Olsson, N.A., Simpson, J.R., Logan, R.A., Becker, P.C., and Wecht, K.W. see Andrekson, P.A.
Taneya, M., Hidaka, H., Akita, K., and Sugimoto, Y. see Hidaka, H.
Tang, C.L., Loh, W.H., and Schremer, A.T. see Loh, W.H.
Tang, H.K., Huang, S.J., and Koh, S.N. see Huang, S.J.
Tang, Y.S., Cheung, R., and Wilkinson, C.D.W. Fabrication of sub-50 nm poly-Si/SiO_2/Si narrow wires using electron beam lithography and CF_4/O_2 reactive ion etching p1823
Tang, Z., Ishizuka, O., and Matsumoto, H. MOS triangle-to-sine wave convertor based on subthreshold operation p1983
Tangonan, G., Ng, W., Walston, A., Lee, J.J., and Newberg, I. see Ng, W.
Taniuchi, T., Mizuuchi, K., and Yamamoto, K. see Mizuuchi, K.
Tao, J.W., Chan, B., and Baudrand, H. Rigorous theoretical study of longitudinally magnetised partially filled TEM phase shifter p1329
Taori, R., Cain, G.D., and Lever, K.V. Correlation windowing and spectral biasing in the design of noise generators having specified probability densities and power spectra p1041
Tarassenko, L., Brownlow, M.J., and Murray, A.F. see Brownlow, M.J.
Tarbox, E.J., Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Young, J., and Cheung, N.K. see Righetti, A.
Tarbox, E.J., Scrivener, P.L., Maton, P.D., and Appleyard, A.P. see Scrivener, P.L.
Tasch, A.F., Shin, H., and Maziar, C.M. New submicron MOSFET structural concept for suppression of hot carriers p39
Tashiro, Y., Ogura, I., Sugimoto, M., Hamao, N., and Kasahara, K. Uniformity in the performance characteristics of an 8 × 8 vertical to surface transmission electro-photonic device matrix p628
Tasker, P.J., Offsey, S.D., Schaff, W.J., Kapitan, L., Shealy, J.R., and Eastman, L.F. see Offsey, S.D.
Tasselli, J., Vannel, J.P., Marty, A., Cazarré, A., and Bailbé, J.P. see Vannel, J.P.
Tawfik, A.N., and Vilar, E. Statistics of duration and intensity of path loss in a microwave trans-horizon sea-path p474
Taylor, E.M., Morkel, P.R., Townsend, J.E., and Payne, D.N. see Morkel, P.R.
Taylor, E.R., Grubb, S.G., Barnes, W.L., and Payne, D.N. see Grubb, S.G.
Taylor, F.J., and Rao, P. see Rao, P.
Taylor, G.C., Liu, S.G., Klatskin, J., Camisa, R.L., and Capewell, D.R. see Liu, S.G.
Taylor, J.R., Ainslie, B.J., Blow, K.J., Gouveia-Neto, A.S., Wigley, P.G.J., and Sombra, A.S.B. see Ainslie, B.J.
Taylor, J.R., Greer, E.J., and Wigley, P.G.J. see Greer, E.J.
Taylor, J.R., Wigley, P.G.J., and French, P.M.W. see Wigley, P.G.J.
Taylor, J.T., and Betts, A.K. see Betts, A.K.
Taylor, J.T., and Houselander, P. see Houselander, P.
Taylor, J.T., and Houselander, P.K. see Houselander, P.K.
Taylor, M.R.S., Adams, J.A., Thayne, I.G., Wilkinson, C.D.W., Beaumont, S.P., Johnson, N.P., Kean, A.H., and Stanley, C.R. see Adams, J.A.
Tedesco, C., Canali, C., Magistrali, F., Sangalli, M., and Zanoni, E. see Canali, C.
Tedesco, C., Canali, C., Zanoni, E., Castellaneta, G., Magistrali, F., and Sangalli, M. see Canali, C.
Tell, B., Goel, K.K., Prucnal, P.R., Shimazu, Y., Milbrodt, M., and Desurvire, E. see Goel, K.K.
Tell, B., Lee, Y.H., Brown-Goebeler, K., Jewell, J.L., Leibenguth, R.E., Asom, M.T., Livescu, G., Luther, L., and Mattera, V.D. see Lee, Y.H.
Tell, B., Lee, Y.H., Brown-Goebeler, K., Jewell, J.L., and Hove, J.V. see Lee, Y.H.
Tell, B., Lee, Y.H., Jewell, J.L., Brown-Goebeler, K.F., Scherer, A., Harbison, J.P., and Florez, L.T. see Lee, Y.H.
Tell, B., Zucker, J.E., Jones, K.L., Chang, T.Y., Sauer, N., Brown-Goebeler, K., Wegener, M., and Chemla, D.S. see Zucker, J.E.
Telle, H.R., and Li, H. Phase-locking of laser diodes p858
Temes, G.C., and Ki, W.-H. see Ki, W.-H.
Tench, R.E., Delavaux, J.M., Park, Y.K., Barski, S., Owen, B., Tzeng, L.D., and Twu, Y. see Delavaux, J.M.
Tepereck, R.J., and Muir, A. see Muir, A.
Terakado, T., Shimizu, J., Suzaki, T., Fujita, S., Kasahara, K., Itoh, T., and Suzuki, A. see Shimizu, J.
Terret, C., and Sharaiha, A. see Sharaiha, A.
Tews, H., Zwicknagl, P., Neumann, R., Jaeger, G., Hoepfner, A., Schleicher, L., and Packeiser, G. Mg-doped graded base GaAs/AlGaAs heterojunction bipolar transistors grown by metalorganic vapour phase epitaxy p58
Thayne, I.G., Adams, J.A., Taylor, M.R.S., Wilkinson, C.D.W., Beaumont, S.P., Johnson, N.P., Kean, A.H., and Stanley, C.R. see Adams, J.A.
Theodorou, N., Tzafestas, S., and Kanellakis, A. see Tzafestas, S.
Thiel, T.E., and Saulnier, G.J. Simplified complex digital sampling demodulator p419
Thielen, H., Dombek, K.-P., Hombach, V., and Scheffer, H. see Dombek, K.-P.
Thirstrup, C., Wa, P.L.K., Button, C.C., Roberts, J.S., and Robson, P.N. Lateral drift and recombination of photogenerated carriers in multiple quantum well hetero *nipi* structures p1935
Thomas, A.P., McGuire, A., and Booth, R.C. see McGuire, A.
Thomas, H., Goostray, J., Morgan, D.V., Kohn, E., Christou, A., and Mottet, S. see Goostray, J.
Thompson, J., Leech, P.W., Gwynn, P.J., Pain, G.N., and Petkovic, N. see Leech, P.W.
Thompson, J., Leech, P.W., Petkovic, N., Gwynn, P.J., and Pain, G.N. see Leech, P.W.
Thompson, J., Moseley, A.J., Kearley, M.Q., Robbins, D.J., and Goodwin, M.J. see Moseley, A.J.
Thompson, P.E., Anderson, W.T., Christou, A., Gossett, C.R., Eridon, J.M., Hatzopoulos, Z., Efthimiopoulos, T., Kudumas, M., Michelakis, C., and Morgan, D.V. see Anderson, W.T.
Thorburn, M., Biswas, A., and Tripathi, V.K. Application of the method of lines to cylindrical inhomogeneous propagation structures p170
Thouroude, D., Himdi, M., and Daniel, J.P. CAD-oriented cavity model for rectangular patches p842
Thouroude, D., Khellaf, A., and Daniel, J.P. see Khellaf, A.
Thulke, W., Illek, S., Schanen, C., Lang, H., and Amann, M.-C. see Illek, S.
Thulke, W., and Illek, S. 1·53 μm DFB laser on semi-insulating InP substrate with very low threshold current p933
Thylén, L., Granestrand, P., Lagerström, B., Svensson, P., Stoltz, B., Bergvall, K., Falk, J.-E., and Olofsson, H. see Granestrand, P.
Tigges, C.P., Lott, J.A., Klem, J.F., Weaver, H.T., and Radoslovich-Cibicki, V. see Lott, J.A.
Ting, W., Lo, G.Q., and Kwong, D.L. Novel gate voltage ramping technique for the characterisation of metal-oxide-semiconductor capacitor charge trapping properties p1257
Tjugiarto, T., Peng, G.D., and Chu, P.L. see Peng, G.D.
Tóth, L., Tsividis, Y.P., and Gopinathan, V. see Tsividis, Y.P.
Toba, H., Ishida, O., and Kano, F. see Ishida, O.
Toba, H., Oda, K., Nakanishi, K., Shibata, N., Nosu, K., Takato, N., and Sato, K. 100-channel optical FDM transmission/distribution at 622 Mbit/s over 50 km utilising a waveguide frequency selection switch p376
Tobin, G.R., and Cahill, L.W. Maximum zeros scheduling for satellite switched TDMA p970
Todd, T.D., and Bignell, A.M. see Bignell, A.M.
Tohme, H.E., Lo, C.N., and Saifi, M.A. Simultaneous transmission and amplification of 622 Mbit/s, 10 FM NTSC video channels and 3 FM HDTV components using a high gain erbium doped fibre amplifier p1280
Toida, M., Kondo, M., Ichimura, T., and Inaba, H. Experimental verification of image detection in highly scattering media using antenna properties of optical heterodyne microscope scheme p700
Tokui, N., Mizumoto, T., Chihara, H., and Naito, Y. see Mizumoto, T.
Tokumitsu, M., Imai, Y., Onodera, K., and Asai, K. see Imai, Y.
Tomesen, M.T., Hooijmans, P.W., and Wright, K.G. 140 Mbit/s and 560 Mbit/s FSK heterodyne polarisation diversity receiver using nearly perfect square law demodulators p1870
Tomesen, M.T., and Hooijmans, P.W. see Hooijmans, P.W.
Tomlinson, W.J., Shahar, A., and Seto, M. see Shahar, A.
Toms, D.J. Training binary node feedforward neural networks by back propagation of error p1745
Tong, Q.-Y., Xu, X.-L., and Shen, H. Diffusion and oxide viscous flow mechanism in SDB process

and silicon wafer rapid thermal bonding p697
Tonguz, O.K. Impact of spontaneous emission noise on the sensitivity of direct-detection lightwave receivers using optical amplifiers p1343
Topalov, I.P., and Stoyanov, G.K. Low-sensitivity universal first-order digital filter sections without limit cycles p25
Toratani, H., Yanagita, H., Masuda, I., and Yamashita, T. see Yanagita, H.
Torikai, T., Fujita, S., Suzaki, T., Matsuoka, A., Miyazaki, S., Nakata, T., and Shikada, M. see Fujita, S.
Torrence, G.W., Vogel, W.J., and Allnutt, J.E. see Vogel, W.J.
Totovski, D., Djuric, Z., Djinovic, Z., and Jaksic, Z. see Djuric, Z.
Touge, T., Shirasaki, M., and Yokota, I. see Shirasaki, M.
Toumazou, C., Battersby, N.C., and Maglaras, C. High-performance algorithmic switched-current memory cell p1593 e1922
Toumazou, C., Haigh, D.G., Harrold, S.J., Steptoe, K., Sewell, J.I., and Bayruns, R. 400 MHz switching rate GaAs switched capacitor filter p460
Toumazou, C., Haigh, D.G., and Fopma, J.M. High frequency gallium arsenide four-quadrant analogue multiplier p1650
Toumazou, C., Hughes, J.B., and Pattullo, D.M. Regulated cascode switched-current memory cell p303
Toumazou, C., Payne, A., and Ryan, P. see Payne, A.
Toumazou, C., and Haigh, D.G. see Haigh, D.G.
Toumazou, C., and Haigh, D.G. High frequency gallium arsenide current mirror p1802
Toumazou, C., and Makris, C.A. see Makris, C.A.
Tovstyuk, K.D., Manasson, V.A., and Shuster, E.M. see Manasson, V.A.
Townsend, J.E., Morkel, P.R., Taylor, E.M., and Payne, D.N. see Morkel, P.R.
Townsend, J.E., and Barnes, W.L. see Barnes, W.L.
Townsend, P.D., Chandler, P.J., Wood, R.A., Zhang, L., McCallum, J., and McHargue, C.W. Chemically stabilised ion implanted waveguides in sapphire p1193
Townsend, P.D., Chandler, P.S., and Zhang, L. see Chandler, P.S.
Townsend, P.D., Field, S.J., Hanna, D.C., Shepherd, D.P., Tropper, A.C., Chandler, P.J., and Zhang, L. see Field, S.J.
Townsend, P.D., Keys, R.W., Loni, A., De La Rue, R.M., Ironside, C.N., Marsh, J.H., and Luff, B.J. see Keys, R.W.
Townsend, P.D., and Mahdavi, S.M. see Mahdavi, S.M.
Tredgold, R.H., Young, M.C.J., Lu, W.X., Hodge, P., and Abbasi, F. see Young, M.C.J.
Tret'jakov, O.A., Belogortsev, A.B., Poliashenko, M.F., and Vavriv, D.M. see Belogortsev, A.B.
Tripathi, M.P., Senani, R., Bhaskar, D.R., and Kumar, B.A. see Senani, R.
Tripathi, V.K., Thorburn, M., and Biswas, A. see Thorburn, M.
Trivett, D., Creaner, M.J., Spirit, D., Walker, G.R., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., and Brain, M. see Creaner, M.J.
Trivett, D., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., and Brain, M. see Creaner, M.J.
Tromborg, B., Mørk, J., and Semkow, M. see Mørk, J.
Tromborg, B., Pan, X., and Olesen, H. see Pan, X.
Trommel, E.S., Diemeer, M.B.J., Suyten, F.M.M., McDonach, A., Copeland, J.M., Jenneskens, L.W., and Horsthuis, W.H.G. see Diemeer, M.B.J.
Trommer, D., Umbach, A., Passenberg, W., Mekonnen, G., and Unterbörsch, G. Superior microwave performance of InGaAs JFETs grown by MBE p734
Trommer, G.F., Poisel, H., Bühler, W., Hartl, E., and Müller, R. see Poisel, H.
Tropper, A.C., Carter, J.N., Smart, R.G., and Hanna, D.C. see Carter, J.N.
Tropper, A.C., Field, S.J., Hanna, D.C., Shepherd, D.P., Chandler, P.J., Townsend, P.D., and Zhang, L. see Field, S.J.
Tropper, A.C., Smart, R.G., Carter, J.N., and Hanna, D.C. see Smart, R.G.
Trutna, W.R., Nazarathy, M., and Newton, S.A. see Nazarathy, M.
Tsai, Y.-W., and Hwang, T. ID based public key cryptosystems based on Okamoto and Tanaka's ID based one way communication scheme p666
Tsalides, Ph. Cellular automata-based built-in self-test structures for VLSI systems p1350
Tsang, H.K., Soole, J.B.D., White, I.H., LeBlanc, H.P., Bhat, R., and Koza, M.A. see Soole, J.B.D.
Tsang, W.T., Wu, M.C., Yang, L., Chen, Y.K., and Sergent, A.M. Strained-layer 1·5 μm wavelength InGaAs/InP multiple quantum well lasers grown by chemical beam epitaxy p2035
Tsao, A.J., Reddy, V.K., and Neikirk, D.P. see Reddy, V.K.
Tsao, H.-W., Liu, S.-I., Wu, J., and Lin, T.-K. see Liu, S.-I.
Tsao, H.-W., Liu, S.-I., and Wu, J. see Liu, S.-I.
Tserng, H.Q., and Saunier, P. High-efficiency AlGaAs/InGaAs heterostructure FET oscillators at V-band p2048
Tsiligirides, T. Backlog performance of some controlled slotted Aloha systems p1612
Tsividis, Y.P., Gopinathan, V., and Tóth, L. Companding in signal processing p1331
Tso, S.K., and Shum, H.Y. Robust model reference adaptive control algorithm for a class of plants with bounded input disturbances p1220
Tsuburai, Y., Ishikawa, M., Shiozawa, H., and Uematsu, Y. see Ishikawa, M.
Tsuchiya, T., Aoki, M., Uomi, K., Suzuki, M., and Chinone, N. see Aoki, M.
Tsuchiya, T., Uomi, K., Sasaki, S., Okai, M., Aoki, M., and Chinone, N. see Uomi, K.
Tsuda, K., Akagi, J., Kuriyama, Y., Morizuka, K., Asaka, M., Obara, M., and Yamakawa, H. see Akagi, J.
Tsuji, S., Nakano, H., Uomi, K., Sasaki, S., and Yamashita, K. see Nakano, H.
Tsukada, M., and Shimazu, Y. 40 Gbit/s optical time-division cell multiplexer for a photonic ATM switch p1895
Tsushima, H., Kitajima, S., Sasaki, S., Okai, M., and Yamashita, K. see Kitajima, S.
Tsushima, H., Sasaki, S., Takeyari, R., Kitajima, S., Kuboki, K., and Uomi, K. 0AMI-CPFSK heterodyne transmission experiment using a novel delay-line demodulation method p1269
Tsylyov, V.V., Izosimov, O.A., and Shagurin, I.I. see Izosimov, O.A.
Tur, M., Iztkovich, M., Hardy, A., and Croituro, N. see Iztkovich, M.
Turner, G.W., Chen, C.L., Connors, M.K., Mahoney, L.J., and McGilvary, W.L. Selective plasma etching of Si from GaAs-on-Si wafers for microwave via-hole formation p854
Tutt, M., Kwon, Y., Pavlidis, D., Ng, G.I., Lai, R., and Brock, T. see Kwon, Y.
Twu, Y., Delavaux, J.M., Park, Y.K., Tench, R.E., Barski, S., Owen, B., and Tzeng, L.D. see Delavaux, J.M.
Twu, Y., Wang, S.J., Dutta, N.K., and Hartman, R.L. see Wang, S.J.
Twu, Y., Wang, S.J., Kuo, C.Y., Wynn, J.D., Brown, R.L., Gruezke, L.A., Strege, K.E., Lin, M.S., and Dutta, N.K. Long-cavity, multi-electrode DFB lasers for coherent FSK systems p708
Tzafestas, S., Kanellakis, A., and Theodorou, N. Method for computing the stability margin of 2-D discrete systems p1139
Tzannes, M.A., Noonan, J.P., and Achour, B. see Noonan, J.P.
Tzeng, L.D., Delavaux, J.M., Park, Y.K., Tench, R.E., Barski, S., Owen, B., and Twu, Y. see Delavaux, J.M.
Tzuang, C.-K.C., Lee, C.-Y., and Kuo, J.-T. Complex codes in lossless nonreciprocal finline p1919
Tzuang, C.-K.C., and Kuo, J.-T. Modal current distributions on closely coupled microstrip lines: a comparative study of the SDA basis functions p464
Tzuang, C.K.C., and Wang, W.K. Rigorous dispersive analysis of skin effects on a printed microstrip line containing finite conductor losses p1334

U

Ucci, D.R., and Hsieh, J. see Hsieh, J.
Uchiyama, A., Fukuda, H., Hayashi, T., Iwabuchi, T., and Ohno, S. High performance p^+-gate pMOSFETs with N_2O-nitrided SiO_2 gate films p1932
Uehara, S., Shimizu, M., Horiguchi, M., Yamada, M., Okayasu, M., Takeshita, T., Nishi, I., Noda, J., and Sugita, E. see Shimizu, M.
Uematsu, H., Obara, H., Okamoto, S., and Matsunaga, H. see Obara, H.
Uematsu, Y., Ishikawa, M., Shiozawa, H., and Tsuburai, Y. see Ishikawa, M.
Uematsu, Y., Itaya, K., Hatakoshi, G., Watanabe, Y., and Ishikawa, M. see Itaya, K.
Uematsu, Y., Itaya, K., and Ishikawa, M. see Itaya, K.
Ueno, Y., Endo, K., Fujii, H., Kobayashi, K., Hara, K., and Yuasa, T. Continuous-wave high-power (75 mW) operation of a transverse-mode stabilised window-structure 680 nm AlGaInP visible laser diode p1726
Uetsuka, H., Kurosawa, M., and Imoto, K. Novel method for centre wavelength tuning of silica waveguide type Mach–Zehnder multi/demultiplexers p251
Ulrich, R., and Brinkmeyer, E. see Brinkmeyer, E.
Umbach, A., Trommer, D., Passenberg, W., Mekonnen, G., and Unterbörsch, G. see Trommer, D.
Un, C.K., and Jeon, H.B. see Jeon, H.B.
Un, C.K., and Koo, J.M. see Koo, J.M.
Un, C.K., and Koo, M.W. see Koo, M.W.
Un, C.K., and Lim, B.K. see Lim, B.K.
Un, C.K., and Nam, S.H. see Nam, S.H.
Un, C.K., and Yoon, C.H. see Yoon, C.H.
Un, C.K., and Youn, W.S. see Youn, W.S.
Unbehauen, R., and Cichocki, A. see Cichocki, A.
Ungar, J., Bar-Chaim, N., Mazed, M., Mittelstein, M., Oh, S., and Ury, I. GaAlAs window lasers emitting 500 mW CW in fundamental mode p1441 e1922
Ünlü, M.S., Chen, J., Gao, G.B., and Morkoç, H. see Chen, J.
Ünlü, M.S., Kishino, K., Chyi, J.-I., Reed, J., Arsenault, L., and Morkoç, H. Wavelength demultiplexing heterojunction phototransistor p1857
Ünlü, M.S., Strite, S., Adomi, K., Gao, G.B., and Morkoç, H. Extremely low-resistance nonalloyed ohmic contacts on molecular beam epitaxially grown p-type Ge p89
Unnikrishnan, R., and Gupta, A. Model reduction for discrete time systems p282
Unterbörsch, G., Trommer, D., Umbach, A., Passenberg, W., and Mekonnen, G. see Trommer, D.
Ünver, Z., and Gökçek, C. see Gökçek, C.
Uomi, K., Aoki, M., Tsuchiya, T., Suzuki, M., and Chinone, N. see Aoki, M.
Uomi, K., Nakano, H., Tsuji, S., Sasaki, S., and Yamashita, K. see Nakano, H.
Uomi, K., Nakano, H., Yamashita, K., and Yagiu, Y. see Nakano, H.
Uomi, K., Sasaki, S., Tsuchiya, T., Okai, M., Aoki, M., and Chinone, N. Spectral linewidth reduction by low spatial hole burning in 1·5 μm multi-quantum-well λ/4-shifted DFB lasers p52
Uomi, K., Tsushima, H., Sasaki, S., Takeyari, R., Kitajima, S., and Kuboki, K. see Tsushima, H.
Urai, T., Frey, J., Peng, Z.Z., and Goldsman, N. Simulation of EPROM programming characteristics p716
Urquhart, C.W., and Siebert, J.P. see Siebert, J.P.
Ury, I., Ungar, J., Bar-Chaim, N., Mazed, M., Mittelstein, M., and Oh, S. see Ungar, J.
Ushikubo, T., Okayama, H., and Ishida, T. see Okayama, H.
Uwano, T., Ogawa, K., Hashimoto, K., and Ota, Y. see Ogawa, K.

V

Vai, M.-K., Ng, D., and Prasad, S. Model minimisation for electron devices using simulated annealing in conjunction with parameter extraction p892
Vajda, I. AGC based on hard detected FFH signal matrices p218
Valera, J., Darzi, A., Walker, A.C., Krug, W., Miao, E., Derstine, M., and Polky, J.N. Observation of self-lensing in a 4BCMU-polydiacetylene thin-film waveguide p222
Valette, S., Grand, G., Jadot, J.P., Denis, H., Fournier, A., and Grouillet, A.M. see Grand, G.
Valin, I., Vanbremeersch, J., Constant, E., Zimmermann, J., Godts, P., and Leroy, A. see Vanbremeersch, J.
Valster, A., Boermans, M.J.B., Hagen, S.H., Finke, M.N., and van der Heyden, J.M.M. see Boermans, M.J.B.
Van Daele, P., Pollentier, I., Demeester, P., Ackaert, A., Buydens, L., and Baets, R. see Pollentier, I.
Van Lil, E., Cao, C., Van de Capelle, A., and Van't Klooster, K. Plane-polar near-field to far-field transformation with the near-field interpolation method p1886
Van der heyden, J.M.M., Boermans, M.J.B., Hagen, S.H., Valster, A., and Finke, M.N. see Boermans, M.J.B.
Van't Klooster, K., Van Lil, E., Cao, C., and Van de Capelle, A. see Van Lil, E.
Van Daele, P., O'Donnell, A.C., Pollentier, I., Demeester, P., and Carr, A.D. see O'Donnell, A.C.
Van Daele, P., Pollentier, I., Buydens, L., Ackaert, A., Demeester, P., De Pestel, F., Lootens, D., and Baets, R. see Pollentier, I.
Van Der Gaag, B., Lin, P.S.D., Hong, W.-P., Kim, O.-H., Bhat, R., and Schumacher, H. see Lin, P.S.D.
van Deventer, M.O. Full duplex coherent optical communication with one in-line polarisation controller p758
van Deventer, M.O., Spano, P., and Nielsen, S.K. Comparison of DFB laser linewidth measurement techniques: Results from COST 215 round robin p2018
Van Eijk, P., Koonen, A.M.J., Van Heijningen, P.H., and Mosch, T.W.M. see Koonen, A.M.J.
Van Heijningen, P.H., Koonen, A.M.J., Van Eijk, P., and Mosch, T.W.M. see Koonen, A.M.J.
Van Hoof, C., Genoe, J., Van Hove, M., Jansen, Ph., Van Rossum, M., and Borghs, G. Resonant tunnelling structures with very thin contact layers using nonalloyed Ge/Pd contacts p797
Van Hove, M., Dobbelaere, W., De Boeck, J., Deneffe, K., De Raedt, W., Mertens, R., and Borghs, G. see Dobbelaere, W.
Van Hove, M., Kuijk, M., Pereira, R., Mertens, R.P., Borghs, G., and Pankove, J.I. see Kuijk, M.
Van Hove, M., Pereira, R., de Potter, M., and Van Rossum, M. see Pereira, R.
Van Hove, M., Van Hoof, C., Genoe, J., Jansen, Ph., Van Rossum, M., and Borghs, G. see Van Hoof, C.
Van Rossum, M., Pereira, R., Van Hove, M., and de Potter, M. see Pereira, R.
Van Rossum, M., Van Hoof, C., Genoe, J., Van Hove, M., Jansen, Ph., and Borghs, G. see Van Hoof, C.
van Schalkwyk, J.J., Bortz, G., and Louw, W. see Bortz, G.
Van de Capelle, A., Van Lil, E., Cao, C., and Van't Klooster, K. see Van Lil, E.
Van der Gaag, B.P., Shah, D.M., Chan, W.K., Gmitter, T.J., Florez, L.T., and Schumacher, H.

see Shah, D.M.
Vanbesien, O., De Saint Pol, L., and Lippens, D. see De Saint Pol, L.
Vanbremeersch, J., Constant, E., Zimmermann, J., Valin, I., Godts, P., and Leroy, A. Design and realisation of very high performance 0·2 μm gate GaAs MESFETs p152
Vandewalle, J., and Moonen, M. see Moonen, M.
Vankwikelberge, P., David, K., Morthier, G., and Baets, R. see David, K.
Vannel, J.P., Marty, A., Tasselli, J., Cazarré, A., and Bailbé, J.P. Double heterojunction GaAlAs/GaAs I^2L integrated circuits p969
Vanner, K.C., Bestwick, P.R., and Davies, I. see Bestwick, P.R.
Vanoli, S., Ripamonti, G., and Ghioni, M. see Ripamonti, G.
Vanstone, S.A., Agnew, G.B., and Mullin, R.C. see Agnew, G.B.
Vardaxoglou, J.C., and Stylianou, A. see Stylianou, A.
Vasconcelos, N.M., Pereira, M.S., and Alves, A.P. see Pereira, M.S.
Vasilescu, G., Alquie, G., and Krim, M. Exact computation of two port noise parameters p1889
Vasilev, V.N., and Aidemirski, P.P. Time delay estimation with gradient type adaptive algorithm p1797
Vaudon, P., Reineix, A., and Jecko, B. Asymptotic method in prediction of E plane radiation pattern of rectangular microstrip patch antennas on finite ground p956
Vaudry, C., Loualiche, S., Le Corre, A., Ginudi, A., Henry, L., and Clerot, F. see Loualiche, S.
Vaughan, R.C., and Nandi, A.K. see Nandi, A.K.
Vavriv, D.M., Belogortsev, A.B., Poliashenko, M.F., and Tret'jakov, O.A. see Belogortsev, A.B.
Vecchi, M.P., Kobrinski, H., Chapuran, T.E., Georges, J.B., Zah, C.E., Caneau, C., Menocal, S.G., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.
Vella-Coleiro, G.P., Jeong, J., Lum, R.M., Klingert, J.K., Bylsma, R., and Smith, P.R. see Jeong, J.
Vella-Coleiro, G.P., Jeong, J., and Yee, C.M.L. see Jeong, J.
Vendeltorp-Pommer, H., Povlsen, J.H., Bjarklev, A., Pedersen, B., and Rottwitt, K. see Povlsen, J.H.
Vendik, O.G., Gaĭdukov, M.M., Kolesov, S.G., Kowalewicz, L., and Kozyrev, A.B. see Gaĭdukov, M.M.
Vendrôme, G., Flaarønning, N., Frorud, J.O., Sotom, M., Da Loura, G., Gabriagues, J.M., Jacquet, J., Leclerc, D., and Benoit, J. see Flaarønning, N.
Vere-Jones, D., Chen, S.X., Smith, P.J., and Shafi, M. see Chen, S.X.
Vernet, G., Ouslimani, A., Hafdallah, H., and Adde, R. see Ouslimani, A.
Veteran, J.L., Ismail, M.S., Bower, R.W., and Marsh, O.J. see Ismail, M.S.
Vicente de Vera, E.G., and Glance, B. Suppression of laser frequency drifts caused by thermal transients in optical WDM packet switching systems p1930
Vichien, K., Nakano, H., Sugiura, T., and Yamauchi, J. see Nakano, H.
Vilain, G., Blondeau, R., Rondi, D., Krakowski, M., and Glastre, G. see Blondeau, R.
Vilar, E., and Tawfik, A.N. see Tawfik, A.N.
Vilbe, P., Calvez, L.C., and Boulbry, J.C. see Calvez, L.C.
Vilcot, J.P., Constant, M., Boussekey, L., and Decoster, D. see Constant, M.
Villasenor, J.D., and Bracewell, R.N. Vector Hartley transform d94
Vinchant, J.F., Cavaillès, J.A., Renaud, M., Jarry, P., Erman, M., and Goutelle, A. see Cavaillès, J.A.
Vineberg, K.A., Hill, K.O., Malo, B., Bilodeau, F., Johnson, D.C., and Skinner, I. see Hill, K.O.
Violas, M., Boggis, J., Lord, A., Heatley, D., and Stallard, W.A. see Boggis, J.
Violas, M.A.R., Heatley, D.J.T., Duarte, A.M.O., and Beddow, D.M. 10 GHz bandwidth low-noise optical receiver using discrete commercial devices p35
Visintin, M., and Lo Presti, L. see Lo Presti, L.
Vo, K.T., Foley, B.M., and Melman, P. see Foley, B.M.
Vodhanel, R., Reichenbach, D., Zah, C.E., Andreadakis, N., Favire, F.J., Menocal, S.G., Yi-Yan, A., and Lee, T.P. see Reichenbach, D.
Vogel, W.J., Torrence, G.W., and Allnutt, J.E. Measured radiometric satellite link attenuation estimation error statistics at 11·2 GHz p1503
Voges, E., Jestel, D., and Baus, A. see Jestel, D.
Vohra, S., Koo, K.P., Dagenais, D.M., and Bucholtz, F. see Koo, K.P.
von Wendorff, W.C., Welters, M., and Jäger, D. Optoelectronic switching in travelling-wave MSM photodetectors using photon energies below bandgap p1874
Vorenkamp, P., Sevenhans, J., Bijker, W., and Steyaert, M. see Sevenhans, J.
Vu Dinh, T., Cabon, B., and Chilo, J. New skin-effect equivalent circuit p1582
Vu Dinh, T., Cabon, B., and Chilo, J. Time domain analysis of skin effect on lossy interconnections p2057
Vucetic, B., Zhang, L., and Khachatrian, G. Construction of block modulation codes over rings for fading channels p2020
Vucetic, B., and Du, J. see Du, J.
Vucetic, B., and Zhang, L. see Zhang, L.

W

Wa, P.L.K., Thirstrup, C., Button, C.C., Roberts, J.S., and Robson, P.N. see Thirstrup, C.
Waarts, R., Parke, R., Welch, D., Mehuys, D., Craig, R., and Scifres, D. see Parke, R.
Waarts, R., Parke, R., Welch, D., Mehuys, D., Streifer, W., and Scifres, D. 1 W, coherent, monolithically integrated master oscillator power amplifier p1926
Waarts, R., Parke, R., Welch, D.F., Hardy, A., and Streifer, W. see Parke, R.
Waarts, R., Welch, D.F., Mehuys, D., Parke, R., Scifres, D., and Streifer, W. see Welch, D.F.
Waarts, R., Welch, D.F., Parke, R., Hardy, A., Streifer, W., and Scifres, D.R. see Welch, D.F.
Waarts, R.G., Mehuys, D., Welch, D.F., and Streifer, W. 675 mW diffraction limited operation and thermal characteristics of laser diode arrays in an external cavity p1586
Waarts, R.G., Welch, D.F., Parke, R., Hardy, A., and Streifer, W. Coherent linear arrays of grating coupled surface-emitting lasers p129
Wada, M., and Kato, K. High microwave performance ion-implanted GaAs MESFETs on InP substrates p197
Wada, O., Deri, R.J., Yasuoka, N., Makiuchi, M., and Kuramata, A. see Deri, R.J.
Wada, O., Kumai, T., Hamaguchi, H., Makiuchi, M., Kuramata, A., and Mikawa, T. High-reliability flip-chip GaInAs/InP *pin* photodiode p1484
Wagner, E.J., Kuo, C.Y., Ackerman, D.A., Henry, C.H., Shani, Y., Dahbura, M.I., and Kistler, R. see Kuo, C.Y.
Wagner, K., Pankove, J., and Radehaus, C. see Pankove, J.
Wagner, S.S., Menendez, R.C., and Lemberg, H.L. see Menendez, R.C.
Wagner, S.S., and Chapuran, T.E. Broadband high-density WDM transmission using superluminescent diodes p696
Wait, J.R. Launching vertically polarised ground waves from a vertical magnetic dipole over an anisotropic surface p1080
Wait, J.R. Radiation from vertical electric dipole located over laterally anisotropic groundplane p74
Wakabayashi, H., Edagawa, N., Yoshida, Y., Taga, H., Yamamoto, S., and Mochizuki, K. see Edagawa, N.
Wakabayashi, H., Taga, H., Yoshida, Y., Edagawa, N., and Yamamoto, S. see Taga, H.
Wakatsuki, A., Okamoto, K., and Mikami, O. Proposed semiconductor narrow-band wavelength filter using directional coupler p1573
Wake, D., Judge, S.N., Spooner, T.P., Harlow, M.J., Duncan, W.J., Henning, I.D., and O'Mahony, M.J. Monolithic integration of 1·5 μm optical preamplifier and pin photodetector with a gain of 20 dB and a bandwidth of 35 GHz p1166
Wale, M.J., Edge, C., and Duthie, P.J. see Edge, C.
Walker, A.C., Valera, J., Darzi, A., Krug, W., Miao, E., Derstine, M., and Polky, J.N. see Valera, J.
Walker, G.R., Creaner, M.J., Spirit, D., Walker, N.G., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Walker, G.R., Creaner, M.J., Steele, R.C., Spirit, D., Walker, N.G., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Walker, G.R., Spirit, D.M., France, P.W., Carter, S.F., and Szebesta, D. see Spirit, D.M.
Walker, G.R., and Steele, R.C. see Steele, R.C.
Walker, N.G., Creaner, M.J., Spirit, D., Walker, G.R., Steele, R.C., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Walker, N.G., Creaner, M.J., Steele, R.C., Spirit, D., Walker, G.R., Mellis, J., Al Chalabi, S., Hale, W., Sturgess, I., Rutherford, M., Trivett, D., and Brain, M. see Creaner, M.J.
Wallmeroth, K., Wandernoth, B., Franz, J., Meier, H., and Schorp, B. Towards a coherent optical free-space communication system p572
Walston, A., Ng, W., Tangonan, G., Lee, J.J., and Newberg, I. see Ng, W.
Walton, A.J., Gammie, W., Fallon, M., Ward, D., and Holwill, R.J. Passive electrical vernier for measuring mask misalignment p1173
Wan, H.W., Chong, T.C., and Chua, S.J. see Chong, T.C.
Wandernoth, B., Wallmeroth, K., Franz, J., Meier, H., and Schorp, B. see Wallmeroth, K.
Wang, G.W., Feng, M., Kaliski, R., and Kuang, J.B. Submicron-gate ion-implanted $In_{0.15}Ga_{0.85}As/GaAs$ MESFETs with graded indium composition p190
Wang, J., Fralich, R., Wu, G., and Litva, J. Multifunctional aperture coupled stack patch antenna p2067
Wang, J., Mwarania, E.K., Reekie, L., and Wilkinson, J.S. see Mwarania, E.K.
Wang, J.-I., and Chang, C.-J. see Chang, C.-J.
Wang, Q., and Clarke, R.J. Motion compensated sequence coding using image pyramids p575
Wang, Q., and Clarke, R.J. Use of Fourier descriptors for the estimation of general motion in image sequences p1877
Wang, S., Hsin, W., Du, G., Gamelin, J.K., Malloy, K.J., Whinnery, J.R., Yang, Y.J., Dziura, T.G., and Wang, S.C. see Hsin, W.
Wang, S., Liu, X., and Lee, H.P. see Liu, X.
Wang, S.-C., and Chi, S. see Chi, S.
Wang, S.C., Hsin, W., Du, G., Gamelin, J.K., Malloy, K.J., Wang, S., Whinnery, J.R., Yang, Y.J., and Dziura, T.G. see Hsin, W.
Wang, S.J., Dutta, N.K., Piccirilli, A.B., and Werner, W.V. see Dutta, N.K.
Wang, S.J., Piccirilli, A.B., Wang, Y.J., and Dutta, N.K. Temperature dependence of the second harmonic distortion of buried heterostructure distributed feedback lasers p1095
Wang, S.J., Twu, Y., Dutta, N.K., and Hartman, R.L. Two-section distributed feedback lasers for incoherent frequency-shift-keying transmission systems p1243
Wang, S.J., Twu, Y., Kuo, C.Y., Wynn, J.D., Brown, R.L., Gruezke, L.A., Strege, K.E., Lin, M.S., and Dutta, N.K. see Twu, Y.
Wang, S.Y., Tan, M.R.T., Kim, I., and Chang, J. see Tan, M.R.T.
Wang, W.I., Luo, L.F., and Longenbach, K.F. see Luo, L.F.
Wang, W.K., and Tzuang, C.K.C. see Tzuang, C.K.C.
Wang, Y., and Gu, K. see Gu, K.
Wang, Y.H., Hasnain, G., Tai, K., Wynn, J.D., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Wang, Y.H., Tai, K., Hasnain, G., Wynn, J.D., Fischer, R.J., Weir, B., Gamelin, J., and Cho, A.Y. see Tai, K.
Wang, Y.J., Wang, S.J., Piccirilli, A.B., and Dutta, N.K. see Wang, S.J.
Wang, Z. 2-MOSFET transresistor with extremely low distortion for output reaching supply voltages p951 d2127
Wang, Z. Interpolation using type I discrete cosine transform p1170
Wang, Z. Making CMOS OTA a linear transconductor p1448
Wang, Z. Novel linearisation technique for implementing large-signal MOS tunable transconductor p138
Wang, Z. Novel voltage-controlled grounded resistor p1711
Wang, Z. Wideband class AB (push–pull) current amplifier in CMOS technology p543
Wang, Z., Cheeke, J.D.N., and Jen, C.K. Unified approach to analyse mass sensitivities of acoustic gravimetric sensors p1511
Wania, X.F., Johns, D.A., and Sedra, A.S. Programmable multiplexed switched-capacitor filters p1051
Wanuga, S., Ackerman, E., Kasemsei, D., and Chinn, S. see Ackerman, E.
Ward, D., Walton, A.J., Gammie, W., Fallon, M., and Holwill, R.J. see Walton, A.J.
Warham, A.G.P., Jenkins, S., Hodgetts, T.E., Symm, G.T., Clarke, R.N., and Preece, A.W. see Jenkins, S.
Warner, C., Delavaux, J.-M.P., Park, Y.K., Barski, S., Lefevre, H., and Failes, M. see Delavaux, J.-M.P.
Wasilewski, Z., Janega, P.L., and Chatenoud, F. see Janega, P.L.
Watanabe, Y., Itaya, K., Hatakoshi, G., Ishikawa, M., and Uematsu, Y. see Itaya, K.
Waterhouse, K., Crookes, C.G., Lancefield, D., Adams, A.R., Greene, P.D., and Glew, R.W. see Crookes, C.G.
Waters, J.P., Ball, G.A., and Morey, W.W. see Ball, G.A.
Waters, R.G., Chen, Y.C., and Dalby, R.J. see Chen, Y.C.
Waters, R.G., Yellen, S.L., Chen, Y.C., Soltz, B.A., Fischer, S.E., Fekete, D., and Ballantyne, J.M. see Yellen, S.L.
Watts, J.J.S., White, I.H., Carroll, J.E., Armistead, C.J., Moule, D.J., and Champelovier, J.A. see White, I.H.
Way, W.I., Maeda, M.W., Yi-Yan, A., Andrejco, M.J., Choy, M.M., Saifi, M., and Lin, C. 160-channel FM-video transmission using optical FM/FDM and subcarrier multiplexing and an erbium doped optical fibre amplifier p139
Wayman, C.M., Favaro, M.E., Alwan, J.J., Bryan, R.P., Miller, L.M., Coleman, J.J., and Kim, J. see Favaro, M.E.
Weaver, H.T., Lott, J.A., Klem, J.F., Tigges, C.P., and Radoslovich-Cibicki, V. see Lott, J.A.
Webb, J.A.C., and Laverty, S.J. Extension of the T-gate concept to a hybrid U-gate architecture for ternary and higher order logic systems p1629
Webb, R.P., Barnes, N., Healey, P., Rejman-Greene, M.A.Z., and Scott, E.G. see Barnes, N.
Webb, R.P., Barnes, N.M., Healey, P., McKee, P., O'Neill, A.W., Rejman-Greene, M.A.Z., Scott, E.G., and Wood, D. see Barnes, N.M.
Webb, R.P., and O'Neill, A.W. see O'Neill, A.W.
Weber, H.G., Ludwig, R., Moehrle, M., Rosenzweig, M., Schnabel, R., and Schunk, N. see Ludwig, R.
Weber, N. New reflection-type optoelectronic microwave switch for CW applications p455
Wecht, K.W., Andrekson, P.A., Olsson, N.A., Simpson, J.R., Tanbun-Ek, T., Logan, R.A., and

Becker, P.C. see Andrekson, P.A.
Wegener, M., Zucker, J.E., Jones, K.L., Chang, T.Y., Sauer, N., Tell, B., Brown-Goebeler, K., and Chemla, D.S. see Zucker, J.E.
Weger, P., Felder, A., Kerber, M., and Klose, H. Versatile divider circuits up to 9 GHz input-frequency realised in high-speed BICMOS p1942
Weger, P., Schultes, G., Bonek, E., and Herzog, W. see Schultes, G.
Wei, C.-H., and Guu, J.-A. see Guu, J.-A.
Wei, C.-H., and Liu, G.-S. see Liu, G.-S.
Weil, H., and Pierce, L.E. see Pierce, L.E.
Weinrichter, H., Crohn, I., and Bonek, E. see Crohn, I.
Weir, B., Tai, K., Hasnain, G., Wynn, J.D., Fischer, R.J., Wang, Y.H., Gamelin, J., and Cho, A.Y. see Tai, K.
Weir, B.E., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Weiss, M., Ng, G.I., and Pavlidis, D. New generation MMIC amplifier using InGaAs/InAlAs HEMTs p264
Welch, D., Craig, R., Streifer, W., and Scifres, D. High reliability, high power, single mode laser diodes p1481
Welch, D., Parke, R., Mehuys, D., Waarts, R., Craig, R., and Scifres, D. see Parke, R.
Welch, D., Waarts, R., Parke, R., Mehuys, D., Streifer, W., and Scifres, D. see Waarts, R.
Welch, D.F., Cardinal, M., Streifer, B., and Scifres, D. High-power single mode InGaAs/AlGaAs laser diodes at 910 nm p233
Welch, D.F., Mehuys, D., Nam, D.W., and Scifres, D.R. see Mehuys, D.
Welch, D.F., Mehuys, D., Parke, R., Waarts, R., Scifres, D., and Streifer, W. Coherent operation of monolithically integrated master oscillator power amplifiers p1327
Welch, D.F., Parke, R., Hardy, A., Waarts, R., Streifer, W., and Scifres, D.R. High power, 16 W, grating surface emitting laser with a superlattice substrate reflector p757
Welch, D.F., Parke, R., Waarts, R., Hardy, A., and Streifer, W. see Parke, R.
Welch, D.F., Sakamoto, M., Cardinal, M.R., Endriz, J.G., and Scifres, D.R. see Sakamoto, M.
Welch, D.F., Sakamoto, M., Yao, H., Endriz, G., and Scifres, D.R. see Sakamoto, M.
Welch, D.F., Streifer, W., Hardy, A., Scifres, D.R., and Cross, P.S. see Streifer, W.
Welch, D.F., Waarts, R.G., Mehuys, D., and Streifer, W. see Waarts, R.G.
Welch, D.F., Waarts, R.G., Parke, R., Hardy, A., and Streifer, W. see Waarts, R.G.
Wells, G., and Kumar, S. see Kumar, S.
Welters, M., von Wendorff, W.C., and Jäger, D. see von Wendorff, W.C.
Wendel, H., and Herdeg, W.F. see Herdeg, W.F.
Weng, S., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Silverman, S., Pao, Y.C., Zdasiuk, G., Bandy, S., and Tan, Z. see Majidi-Ahy, R.
Werner, W.V., Dutta, N.K., Wang, S.J., and Piccirilli, A.B. see Dutta, N.K.
West, D.L., Griem, H.T., Fuji, H.S., Williams, T.J., Harrang, J.P., Daniels, R.R., Ray, S., and LaGasse, M.J. see Griem, H.T.
Westbrook, L.D., Bagley, M., Sherlock, G., Cooper, D.M., Elton, D.J., Wickes, H.J., Spurdens, P.C., and Devlin, W.J. see Bagley, M.
Westermeier, H., Wolf, T., and Amann, M.-C. see Wolf, T.
Westland, D., Rossi, B., Blau, W., O'Gorman, J., König, S., and Skarda, V. see Rossi, B.
Weston, M., Sandbank, C.P., and Drewery, J.O. see Sandbank, C.P.
Wetenkamp, L. Efficient CW operation of a 2·9 μm Ho^{3+}-doped fluorozirconate fibre laser pumped at 640 nm p883
Weyland, N.B.J., Bertheau Johannessen, A., Bons, J.H., and Prasad, R. see Bertheau Johannessen, A.
Weyland, N.B.J., and Prasad, R. Characterisation of line drawings using generalised Fourier descriptors p1794
Whalley, M., Botha, L., and Ferreira, H.C. see Botha, L.
Whinnery, J.R., Hsin, W., Du, G., Gamelin, J.K., Malloy, K.J., Wang, S., Yang, Y.J., Dziura, T.G., and Wang, S.C. see Hsin, W.
White, A.E., Goossen, K.W., and Short, K.T. see Goossen, K.W.
White, D.W., Alexander, S.B., Barry, R., Castagnozzi, D.M., Chan, V.W.S., Hodsdon, D.M., Jeromin, L.L., Kaufmann, J.E., Materna, D.M., Parr, R.J., and Stevens, M.L. see Alexander, S.B.
White, I.H., Cunningham, D.G., and Coles, A.N. see Cunningham, D.G.
White, I.H., Nyairo, K.O., Kirkby, P.A., and Armistead, C.J. Demonstration of a 1 × 2 multichannel grating cavity laser for wavelength division multiplexing (WDM) applications p832
White, I.H., Soole, J.B.D., Tsang, H.K., LeBlanc, H.P., Bhat, R., and Koza, M.A. see Soole, J.B.D.
White, I.H., Watts, J.J.S., Carroll, J.E., Armistead, C.J., Moule, D.J., and Champelovier, J.A. InGaAsP 400 × 200 μm active crosspoint switch operating at 1·5 μm using novel reflective Y-coupler components p617
Whiteaway, J.E.A., Bhumbra, B.S., Glew, R.W., Greene, P.D., Henshall, G.D., and Lowney, C.M. see Bhumbra, B.S.
Whitehead, M., Rivers, A., Parry, G., and Roberts, J.S. Very low voltage, normally-off asymmetric Fabry–Perot reflection modulator p1588
Whitehead, M., Zouganeli, P., Stevens, P.J., Rivers, A., Parry, G., Roberts, J.S., and Button, C. see Zouganeli, P.
Whitehead, N.J., and Sealy, B.J. The effect of n-type dopant species on the compensating effects of oxygen implantation in GaAs p866
Wickens, G.E., and Sundaresan, H. see Sundaresan, H.
Wickes, H.J., Bagley, M., Sherlock, G., Cooper, D.M., Westbrook, L.D., Elton, D.J., Spurdens, P.C., and Devlin, W.J. see Bagley, M.
Wickes, H.J., Bagley, M., Wyatt, R., Elton, D.J., Spurdens, P.C., Seltzer, C.P., Cooper, D.M., and Devlin, W.J. see Bagley, M.
Wickman, C., Ahlbom, G., and Egnell, L. see Ahlbom, G.
Wicks, G.W., and Shank, S.M. see Shank, S.M.
Wicks, M.C., Haycocks, P.R., and Hori, T. AC Josephson effect in superconducting niobium nitride tunnel junctions at up to 2·5 THz p610
Widdowson, T., Bryant, E.G., Carter, S.F., Lewis, R.B.J., Spirit, D.M., and Wright, J.V. see Bryant, E.G.
Wieder, H.H., Lin, C.L., and Zuleeg, R. see Lin, C.L.
Wight, J.S., Smuk, J.W., and Stubbs, M.G. see Smuk, J.W.
Wigley, P.G.J., Ainslie, B.J., Blow, K.J., Gouveia-Neto, A.S., Sombra, A.S.B., and Taylor, J.R. see Ainslie, B.J.
Wigley, P.G.J., French, P.M.W., and Taylor, J.R. Mode locking of a continuous wave neodymium doped fibre laser with a linear external cavity p1238
Wigley, P.G.J., Greer, E.J., and Taylor, J.R. see Greer, E.J.
Wilkinson, C.D.W., Adams, J.A., Thayne, I.G., Taylor, M.R.S., Beaumont, S.P., Johnson, N.P., Kean, A.H., and Stanley, C.R. see Adams, J.A.
Wilkinson, C.D.W., Tang, Y.S., and Cheung, R. see Tang, Y.S.
Wilkinson, I.J., Lord, A., Ellis, A., Cleland, D., Garnham, R.A., and Stallard, W.A. see Lord, A.
Wilkinson, I.J., Rowe, C.J., Moore, M.W., and Achurch, N.E. see Rowe, C.J.
Wilkinson, I.J., and Rowe, C.J. Close-spaced fused fibre wavelength division multiplexers with very low polarisation sensitivity p382
Wilkinson, J.S., Mwarania, E.K., Reekie, L., and Wang, J. see Mwarania, E.K.
Will, D.J., Kluitmans, J.T.M., Kuindersma, P.I., Meier, M., Mink, J., and Röll, G. see Kluitmans, J.T.M.
Williams, D.L., Davey, S.T., Spirit, D.M., and Ainslie, B.J. see Davey, S.T.
Williams, D.L., Davey, S.T., Spirit, D.M., and Ainslie, B.J. Transmission over 10 km of erbium doped fibre with ultralow signal power excursion p1517
Williams, D.L., Kashyap, R., Armitage, J.R., Wyatt, R., and Davey, S.T. see Kashyap, R.
Williams, D.L., Spirit, D.M., Blank, L.C., Davey, S.T., and Ainslie, B.J. see Spirit, D.M.
Williams, J.R., Carter, S.F., Moore, M.W., Szebesta, D., Ranson, D., and France, P.W. see Carter, S.F.
Williams, P.J., Charles, P.M., Griffith, I., Considine, L., and Carter, A.C. High performance buried ridge DFB lasers monolithically integrated with butt coupled strip loaded passive waveguides for OEIC p142
Williams, R.L., Normandin, R., and Chatenoud, F. see Normandin, R.
Williams, T.J., Griem, H.T., Fuji, H.S., Harrang, J.P., Daniels, R.R., Ray, S., LaGasse, M.J., and West, D.L. see Griem, H.T.
Williamson, A.G., Wu, Z., Maclean, T.S.M., Jayasundere, N., and Carter, L.J. see Wu, Z.
Willner, A.E., Podlesnik, D.V., and Osgood, R.M. 600 μm/min laser-induced nonthermal etching of GaAs in an HF solution p568
Willsch, R. High performance metal-clad fibre-optic polarisers p1113
Wilson, G., and Chan, P.K. Low-distortion CMOS transconductor p720
Wirth, K.-H. New model for time domain simulation of lossy coupled lines p1723
Wlodarczyk, W., and Besch, V. Skin effect losses of interconnect lines in frequency and time domain p1237
Wörner, K., Hauenschild, J., Rein, H.-M., and Schmidt, L. see Hauenschild, J.
Wolf, T., Kuhl, D., Hieronymi, F., Böttcher, E.H., Krost, A., and Bimberg, D. see Kuhl, D.
Wolf, T., Westermeier, H., and Amann, M.-C. Continuously tunable metal-clad ridge-waveguide distributed feedback laser diode p1845
Wolff, I., and Pan, S.-G. see Pan, S.-G.
Wolff, U., Müller, G., Stoll, L., and Schulte-Roth, G. see Müller, G.
Wong, D. Effect of mechanical inhomogeneity on intrinsic stress birefringence in birefringent optical fibres p967
Wong, D., Chiang, K.S., and Chu, P.L. see Chiang, K.S.
Wong, D., and Chiang, K.S. see Chiang, K.S.
Wong, D., and Chu, P.L. Calculation of phase shift sensitivity in polarimetric fibre sensors p607
Wood, D., Barnes, N.M., Healey, P., McKee, P., O'Neill, A.W., Rejman-Greene, M.A.Z., Scott, E.G., and Webb, R.P. see Barnes, N.M.
Wood, R.A., Townsend, P.D., Chandler, P.J., Zhang, L., McCallum, J., and McHargue, C.W. see Townsend, P.D.
Woodhead, J., Claxton, P.A., Grey, R., Sale, T.E., David, J.P.R., Liu, L., Pate, M.A., Hill, G., and Robson, P.N. Low voltage strained layer asymmetric Fabry–Perot reflection modulator p2117
Woods, R.C., Khamas, S., Cook, G.G., and Kingsley, S.P. see Khamas, S.
Wright, J.V., Bryant, E.G., Carter, S.F., Ellis, A.D., Stallard, W.A., and Wyatt, R. see Bryant, E.G.
Wright, J.V., Bryant, E.G., Carter, S.F., Lewis, R.B.J., Spirit, D.M., and Widdowson, T. see Bryant, E.G.
Wright, J.V., Hill, A.M., and Srikanthan, S. see Hill, A.M.
Wright, K.G., Tomesen, M.T., and Hooijmans, P.W. see Tomesen, M.T.
Wu, A., and Nintunze, N. see Nintunze, N.
Wu, D.M., Jiang, Q., and Xie, L.Z. see Jiang, Q.
Wu, G., Wang, J., Fralich, R., and Litva, J. see Wang, J.
Wu, H., and Zhuang, N. see Zhuang, N.
Wu, H.-S. Minimum entropy deconvolution for restoration of blurred two-tone images p1183
Wu, J., Liu, S.-I., Tsao, H.-W., and Lin, T.-K. see Liu, S.-I.
Wu, J., Liu, S.-I., and Tsao, H.-W. see Liu, S.-I.
Wu, J., and Kao, M-S see Kao, M-S
Wu, J., and Kao, M-S. see Kao, M-S.
Wu, J., and Kao, M.-S. see Kao, M.-S.
Wu, J.-L., Chen, G.-S., and Lee, L.-S. see Chen, G.-S.
Wu, K.-L., Bi, Z.-Q., and Litva, J. see Bi, Z.-Q.
Wu, K.-L., and Litva, J. Boundary element method for modelling MIC devices p518
Wu, M.C., Tsang, W.T., Yang, L., Chen, Y.K., and Sergent, A.M. see Tsang, W.T.
Wu, P., Yin, J.H., Shui, Y., Zhang, D., and Yu, J. see Yin, J.H.
Wu, P., and Schaumann, R. 2-MOSFET transresistor with extremely low distortion for output reaching supply voltages d2127
Wu, P.H., Min, Q., and Xue, K.Z. see Min, Q.
Wu, T.-M., Jen, B.-S., Chang, M.-W., Sun, S.-W., and Shih, C.-H. see Jen, B.-S.
Wu, Z., Gong, J., and Maclean, T.S.M. see Gong, J.
Wu, Z., Maclean, T.S.M., Jayasundere, N., Carter, L.J., and Williamson, A.G. Recovery effect in radiowave propagation p162
Wünstel, K., Schilling, M., Schweizer, H., Dütting, K., Idler, W., Kühn, E., and Nowitzki, A. see Schilling, M.
Wüppermann, B., Langmann, U., and Pottbäcker, A. 3·4 GHz silicon bipolar versatile shift register and 6·8 Gbit/s word generator p553
Wüthrich, C., Faist, J., and Reinhart, F.K. Polarisation independent switching and active separation of TE and TM modes with a GaAs/AlGaAs 2 × 2 switch p476
Wüthrich, C., James, J.H., Ganière, J.D., and Reinhart, F.K. Room temperature vertical cavity GaAs/AlGaAs surface emitting injection laser p1600
Wulich, D., Plotkin, E.I., and Swamy, M.N.S. Stability of second order time-varying constrained notch filters p1508
Wyatt, R., Al-Chalabi, S.A., Mellis, J., Hollier, M., Cameron, K.H., Regnault, J.E., Devlin, W.J., and Brain, M.C. see Al-Chalabi, S.A.
Wyatt, R., Bagley, M., Elton, D.J., Wickes, H.J., Spurdens, P.C., Seltzer, C.P., Cooper, D.M., and Devlin, W.J. see Bagley, M.
Wyatt, R., Bryant, E.G., Carter, S.F., Ellis, A.D., Stallard, W.A., and Wright, J.V. see Bryant, E.G.
Wyatt, R., Hill, A.M., Massicott, J.F., Blyth, K.J., Forrester, D.S., Lobbett, R.A., Smith, P.J., and Payne, D.B. see Hill, A.M.
Wyatt, R., Hill, A.M., Payne, D.B., Blyth, K.J., Forrester, D.S., Arkwright, J.W., Massicott, J.F., Lobbett, R.A., Smith, P., and Hodgkinson, T.G. see Hill, A.M.
Wyatt, R., Kashyap, R., Armitage, J.R., Davey, S.T., and Williams, D.L. see Kashyap, R.
Wyatt, R., Massicott, J.F., Ainslie, B.J., and Craig-Ryan, S.P. see Massicott, J.F.
Wyatt, R., Massicott, J.F., Armitage, J.R., Ainslie, B.J., and Craig-Ryan, S.P. see Massicott, J.F.
Wyatt, R., Smith, K., Armitage, J.R., Doran, N.J., and Kelly, S.M.J. see Smith, K.
Wyatt, R., Smyth, P.P., Fidler, A., Eardley, P., Sayles, A., and Craig-Ryan, S. see Smyth, P.P.
Wynn, J.D., Dutta, N.K., Lopata, J., Sivco, D.L., and Cho, A.Y. see Dutta, N.K.
Wynn, J.D., Hasnain, G., Tai, K., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Zydzik, G.J., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.
Wynn, J.D., Tai, K., Hasnain, G., Fischer, R.J., Wang, Y.H., Weir, B., Gamelin, J., and Cho, A.Y. see Tai, K.
Wynn, J.D., Twu, Y., Wang, S.J., Kuo, C.Y., Brown, R.L., Gruezke, L.A., Strege, K.E., Lin, M.S., and Dutta, N.K. see Twu, Y.

X

Xie, J., Joshi, A.B., Lo, G.Q., and Kwong, D.L. see Joshi, A.B.

Xie, J.M., Chusseau, L., Duvillaret, L., Lourtioz, J.M., Accard, A., and Hebert, J-P. see Chusseau, L.
Xie, L.Z., Jiang, Q., and Wu, D.M. see Jiang, Q.
Xie, S., and Conn, D.R. see Conn, D.R.
Xing, L.D., and Sheng, L.G. Cryptanalysis of new modified Lu–Lee cryptosystems p1601
Xinmei, W. Digital signature scheme based on error-correcting codes p898
Xinmei, Wang, and Jianhua, Ma see Jianhua, Ma
Xu, G., Gong, M., Han, K., and Zhai, G. see Gong, M.
Xu, X.-L., Tong, Q.-Y., and Shen, H. see Tong, Q.-Y.
Xue, H., Howes, M.J., and Snowden, C.M. New distributed package model for the dual gate FET p1207
Xue, K.Z., Min, Q., and Wu, P.H. see Min, Q.
Xue, L., Huang, Y., and Lin, W. see Huang, Y.

Y

Yagiu, Y., Nakano, H., Uomi, K., and Yamashita, K. see Nakano, H.
Yajima, H., Suzuki, Y., Shimoyama, K., Inoue, Y., Katoh, M., and Gotoh, H. see Suzuki, Y.
Yakuwa, N., Kominami, M., and Kusaka, H. see Kominami, M.
Yamada, E., Nakazawa, M., Suzuki, K., and Kimura, Y. see Nakazawa, M.
Yamada, E., Nakazawa, M., and Suzuki, K. see Nakazawa, M.
Yamada, E., Noda, S., Takayama, T., and Sasaki, A. see Noda, S.
Yamada, E., Suzuki, K., Nakazawa, M., and Kimura, Y. see Suzuki, K.
Yamada, H., Suzaki, T., Suzuki, Y., Fujita, S., Hida, H., Kitamura, M., and Shikada, M. see Suzaki, T.
Yamada, M., Horiguchi, M., Shimizu, M., Yoshino, K., and Hanafusa, H. see Horiguchi, M.
Yamada, M., Shimizu, M., Horiguchi, M., Okayasu, M., Takeshita, T., Nishi, I., Uehara, S., Noda, J., and Sugita, E. see Shimizu, M.
Yamada, M., Shimizu, M., Horiguchi, M., Takeshita, T., and Okayasu, M. see Shimizu, M.
Yamada, M., Shimizu, M., Okayasu, M., and Horiguchi, M. Temperature insensitive Er^{3+}-doped optical fibre amplifiers p1649
Yamada, T., and Kawai, Y. see Kawai, Y.
Yamaguchi, M., Hashimoto, K.-Y., and Kaneda, H. Dependence of propagation loss of magnetostatic forward volume waves on device parameters p581
Yamaguchi, M., Kobayashi, S., Kitoh, T., Hida, Y., and Suzuki, S. see Kobayashi, S.
Yamakawa, H., Akagi, J., Kuriyama, Y., Morizuka, K., Asaka, M., Tsuda, K., and Obara, M. see Akagi, J.
Yamakawa, H., Ibe, H., Akagi, J., Kuriyama, Y., Morizuka, K., and Obara, M. 9·5 GHz bandwidth HBT gain controllable amplifier IC with an amplitude detection circuit p602
Yamamoto, K., Mizuuchi, K., and Taniuchi, T. see Mizuuchi, K.
Yamamoto, S., Edagawa, N., Yoshida, Y., Taga, H., Mochizuki, K., and Wakabayashi, H. see Edagawa, N.
Yamamoto, S., Taga, H., Yoshida, Y., Edagawa, N., and Wakabayashi, H. see Taga, H.
Yamamoto, T., Miyamoto, Y., Ogawa, M., Inamura, E., and Furuya, K. Buried rectangular GaInAs/InP corrugations of 70 nm pitch fabricated by OMVPE p875
Yamanaka, N., Kikuchi, S., and Miyanaga, H. Newly structured expandable 52 Mbit/s, 48-channel time-division switching LSI with 2·4 Gbit/s throughput p524
Yamane, Y., Ohhata, M., Enoki, T., Sugitani, S., Kato, N., Hagimoto, K., and Hirayama, M. see Ohhata, M.
Yamane, Y., Ohhata, M., Enoki, T., Sugitani, S., Kato, N., and Hirayama, M. see Ohhata, M.
Yamasaki, Y., Ogura, M., Mukai, S., Shimada, M., Asaka, T., Seki, T., and Iwano, H. see Ogura, M.
Yamashita, K., Kitajima, S., Sasaki, S., Tsushima, H., and Okai, M. see Kitajima, S.
Yamashita, K., Kusuda, Y., and Tanaka, S. see Kusuda, Y.
Yamashita, K., Nakano, H., Tsuji, S., Uomi, K., and Sasaki, S. see Nakano, H.
Yamashita, K., Nakano, H., Uomi, K., and Yagiu, Y. see Nakano, H.
Yamashita, T., Yanagita, H., Masuda, I., and Toratani, H. see Yanagita, H.
Yamauchi, J., Kikuchi, S., Hirooka, T., and Nakano, H. Beam-propagation analysis of bent step-index slab waveguides p822
Yamauchi, J., Nakano, H., Vichien, K., and Sugiura, T. see Nakano, H.
Yamauchi, J., and Nakano, H. Hallen-type integral equation to a system composed by wires with dielectric coating p1412
Yamaura, S., Miyamoto, Y., and Furuya, K. High current gain GaInAs/InP hot electron transistor p1055
Yamazaki, S., Soda, H., Furutsu, M., Sato, K., Okazaki, N., Nishimoto, H., and Ishikawa, H. see Soda, H.
Yanagita, H., Masuda, I., Yamashita, T., and Toratani, H. Diode laser pumped Er^{3+} fibre laser operation between 2·7–2·8 μm p1836
Yang, C-D., Chung, H.-Y., and Chang, J.-L. Optimal model matching: H^2 or H^∞? p2089
Yang, D. Fast discrete radon transform and 2-D discrete Fourier transform p550
Yang, D. Prime factor fast Hartley transform p119
Yang, D.D., Boucaud, P., Julien, F.H., Chusseau, L., Lourtioz, J.-M., and Planel, R. Laser diode modulation of 10·6 μm radiation in GaAs/AlGaAs quantum wells p1531
Yang, H., and Kim, M. Estimation of traffic intensity in global bus computer communications networks p1079
Yang, L., Chen, J.F., and Cho, A.Y. New GaSb/AlSb/GaSb/AlSb/InAs/AlSb/InAs triple-barrier interband tunnelling diode p1277
Yang, L., Tsang, W.T., Wu, M.C., Chen, Y.K., and Sergent, A.M. see Tsang, W.T.
Yang, Q., and Bhargava, V.K. Reducing time delay of ARQ protocols by simple error-correcting codes p1447
Yang, X.H., and Zhang, W.X. Coplanar waveguide antenna arrays for MIC/MMIC at millimetre wave frequencies p1464
Yang, Y.J., Hsin, W., Du, G., Gamelin, J.K., Malloy, K.J., Wang, S., Whinnery, J.R., Dziura, T.G., and Wang, S.C. see Hsin, W.
Yano, H., Aga, K., Kamei, H., Sasaki, G., and Hayashi, H. Monolithic *pin*-HEMT receiver with internal equaliser for long-wavelength fibre optic communications p305
Yano, H., Nishiyama, N., Nakajima, S., and Hayashi, H. see Nishiyama, N.
Yao, H., Sakamoto, M., Welch, D.F., Endriz, G., and Scifres, D.R. see Sakamoto, M.
Yao, Y.-D., and Sheikh, A.U.H. Outage probability analysis for microcell mobile radio systems with cochannel interferers in Rician/Rayleigh fading environment p864
Yariv, A., Chen, T.R., Zhuang, Y.H., Blauvelt, H., and Bar-Chaim, N. see Chen, T.R.
Yariv, A., Eng, L.E., Mehuys, D.G., and Mittelstein, M. see Eng, L.E.
Yariv, A., Sanders, S., and Eng, L. see Sanders, S.
Yasaka, H., Magari, K., Noguchi, Y., Okamoto, K., Nagai, H., and Mikami, O. see Magari, K.
Yasu, M., Kominato, T., Ohmori, Y., and Okazaki, H. see Kominato, T.
Yasuda, Y., and Lee, M.H. see Lee, M.H.
Yasuoka, N., Deri, R.J., Makiuchi, M., Kuramata, A., and Wada, O. see Deri, R.J.
Yatabe, S., Sawaya, K., and Adachi, S. see Sawaya, K.
Yee, C.M.L., Jeong, J., and Vella-Coleiro, G.P. see Jeong, J.
Yeh, C.-C., Jeng, Y.-J., and Chiueh, T.D. see Jeng, Y.-J.
Yellen, S.L., Waters, R.G., Chen, Y.C., Soltz, B.A., Fischer, S.E., Fekete, D., and Ballantyne, J.M. 20 000 h InGaAs quantum well lasers p2083
Yeo, T.S., Kooi, P.S., Leong, M.S., and Ng, S.S. Microwave attenuation due to rainfall at 21·255 GHz in the Singapore environment p1021
Yi-Yan, A., Reichenbach, D., Zah, C.E., Andreadakis, N., Favire, F.J., Menocal, S.G., Vodhanel, R., and Lee, T.P. see Reichenbach, D.
Yi-Yan, A., Seto, M., Gmitter, T.J., Hwang, D.M., and Florez, L.T. Grafted GaAlAs rib waveguides on an InP substrate p1567
Yi-Yan, A., Way, W.I., Maeda, M.W., Andrejco, M.J., Choy, M.M., Saifi, M., and Lin, C. see Way, W.I.
Yie, H., Guoxiang, C., and Yuanming, W. Novel method to control numerical solution oscillation of diffusion-drift equation p1487
Yih, S.-J., and Lee, S.-C. AlGaAs/GaAs surface emitting laser diode with curved reflector p1506
Yin, J.H., Shui, Y., Zhang, D., Yu, J., and Wu, P. Simple method for calculating optimum cut of piezoelectric material with small BAW generation by IDTs p1175
Yip, G.L., and Goto, N. see Goto, N.
Yokota, I., Shirasaki, M., and Touge, T. see Shirasaki, M.
Yokota, N., Hakamata, Y., and Takemoto, K. Time-division 8 : 1 multiplexing and demultiplexing system adapting 7B1C code operating at 5 Gbit/s p923
Yonetani, H., Kawamura, H., Kamite, K., Ogita, S., Soda, H., and Ishikawa, H. see Kawamura, H.
Yonezu, H., Himeno, T., Kanamori, K., Pak, K., and Takano, Y. Optoelectronic synaptic connection circuit with variable analogue weights p910
Yoo, D.S., and Chung, M.J. Performance improvement of output feedback control systems using the theory of variable structure systems p1210
Yoo, H.-J., Hayes, J.R., Paek, E.G., Harbison, J.P., Florez, L.T., and Kwon, Y.-S. Phase-locked two-dimensional arrays of implant isolated vertical cavity surface emitting lasers p1944
Yoo, H.-J., Hayes, J.R., and Kwon, Y.-S. Analysis of coupling coefficient between two vertical cavity surface emitting lasers for two-dimensional phase-locked array p896
Yoon, C.H., and Un, C.K. Unslotted CSMA-CD protocol with combined retransmission strategy for fibre optic bus and ring networks p998
York, R.A., Martinez, R.D., and Compton, R.C. Active patch antenna element for array applications p494
Yoshida, E., Nakazawa, M., Kimura, Y., and Suzuki, K. see Nakazawa, M.
Yoshida, I., Katsuyama, T., Shinkai, J., Hashimoto, J., and Hayashi, H. see Katsuyama, T.
Yoshida, N., Kashiwa, T., and Fukai, I. see Kashiwa, T.
Yoshida, Y. Resequencing delay characteristics of multilink system in packet switched networks p1971
Yoshida, Y., Edagawa, N., Taga, H., Yamamoto, S., Mochizuki, K., and Wakabayashi, H. see Edagawa, N.
Yoshida, Y., Taga, H., Edagawa, N., Yamamoto, S., and Wakabayashi, H. see Taga, H.
Yoshihara, K., Takahashi, S., Koguchi, N., Chikyow, T., Kiyosawa, T., and Fujiwara, J. see Takahashi, S.
Yoshino, K., Horiguchi, M., Shimizu, M., Yamada, M., and Hanafusa, H. see Horiguchi, M.
Youn, M.-J., Cho, K.-Y., Hong, S.-S., and Oh, D.-S. see Cho, K.-Y.
Youn, M.J., Ko, J.H., and Oh, D.S. see Ko, J.H.
Youn, M.J., and Oh, D.S. see Oh, D.S.
Youn, W.S., and Un, C.K. Eigenstructure method for robust array processing p678
Young, J., Righetti, A., Fontana, F., Delrosso, G., Grasso, G., Iqbal, M.Z., Gimlett, J.L., Standley, R.D., Cheung, N.K., and Tarbox, E.J. see Righetti, A.
Young, J., Runge, K., Bagheri, M., Millicker, D., Kipnis, I., and Snapp, C. see Runge, K.
Young, M.C.J., Lu, W.X., Tredgold, R.H., Hodge, P., and Abbasi, F. Optical second harmonic generation from laminated polymeric Langmuir-Blodgett multilayers p993
Young, M.G., Koren, U., Oron, M., Miller, B.I., De Miguel, J.L., Raybon, G., and Chien, M. see Koren, U.
Young, T.P., Dillon, B.M., and Ferrari, R.L. see Dillon, B.M.
Young, T.P., and Croston, I.R. see Croston, I.R.
Yu, A., and Siddiqui, A.S. see Siddiqui, A.S.
Yu, J., Yin, J.H., Shui, Y., Zhang, D., and Wu, P. see Yin, J.H.
Yu, Q., Zongo, P.-H., and Facq, P. see Zongo, P.-H.
Yu, R.Y., Case, M., Kamegawa, M., Sundaram, M., Rodwell, M.J.W., and Gossard, A.W. 275 GHz 3-mask integrated GaAs sampling circuit p949
Yu, X-H., and Cheng, S-X. Training algorithms for backpropagation neural networks with optimal descent factor p1698
Yuanming, W., Yie, H., and Guoxiang, C. see Yie, H.
Yuasa, T., Ueno, Y., Endo, K., Fujii, H., Kobayashi, K., and Hara, K. see Ueno, Y.
Yuen, C., Pao, Y.C., Day, M., Nishimoto, C., Glenn, M., Bandy, S., and Zdasiuk, G. Monolithic InP cascode HEMT distributed amplifier from 5 to 40 GHz p1411
Yuen, C., Pao, Y.C., Day, M., Nishimoto, C., Glenn, M., Bandy, S., and Zdasiuk, G. Ultra-high gain, low noise monolithic InP HEMT distributed amplifier from 5 to 40 GHz p515
Yumin, W., and Hailin, Z. see Hailin, Z.

Z

Zablocky, P.G., and Engheta, N. see Engheta, N.
Zaglanikis, C.D., Benjamin, R., and Seeds, A.J. see Benjamin, R.
Zah, C.E., Kobrinski, H., Vecchi, M.P., Chapuran, T.E., Georges, J.B., Caneau, C., Menocal, S.G., Lin, P.S.D., Gozdz, A.S., and Favire, F.J. see Kobrinski, H.
Zah, C.E., Reichenbach, D., Andreadakis, N., Favire, F.J., Menocal, S.G., Vodhanel, R., Yi-Yan, A., and Lee, T.P. see Reichenbach, D.
Zamkotsian, F., Artigue, C., Peyre, J.-L., Lievin, J.-L., Lambert, M., Bonnevie, D., and Benoit, J. Electro-optic polarisation convertor on (110) InP p1560
Zander, J. Slotted ALOHA multihop packet radio networks with directional antennas p2098
Zanoni, E., Canali, C., Magistrali, F., Sangalli, M., and Tedesco, C. see Canali, C.
Zanoni, E., Canali, C., Tedesco, C., Castellaneta, G., Magistrali, F., and Sangalli, M. see Canali, C.
Zapata, E.L., Pena, T.F., Cabaleiro, J.C., and Bruguera, J.D. see Pena, T.F.
Zapata, E.L., and Argüello, F. see Argüello, F.
Zarea, A., Sellai, A., Raven, M.S., Steenson, D.P., Chamberlain, J.M., Henini, M., and Hughes, O.H. Impedance analysis of GaAs/Al(Ga)As resonant tunnel diodes in the NDR region p1522
Zdasiuk, G., Majidi-Ahy, R., Riaziat, M., Nishimoto, C., Glenn, M., Silverman, S., Weng, S., Pao, Y.C., Bandy, S., and Tan, Z. see Majidi-Ahy, R.
Zdasiuk, G., Yuen, C., Pao, Y.C., Day, M., Nishimoto, C., Glenn, M., and Bandy, S. see Yuen, C.
Zelinski, R. Noise reduction based on microphone array with LMS adaptive post-filtering p2036
Zerguerras, A., Dubost, G., and Desclos, S. see Dubost, G.
Zerguerras, A., and Dubost, G. see Dubost, G.
Zerguine, A., El-Hennawey, M.S., and Hassan, E.E. see El-Hennawey, M.S.
Zervas, M.N. Algorithm for large-phase-modulation measurements p112
Zhai, G., Gong, M., Xu, G., and Han, K. see Gong, M.

Zhang, D., Yin, J.H., Shui, Y., Yu, J., and Wu, P. see Yin, J.H.
Zhang, K., Pahlavan, K., and Ganesh, R. Slotted ALOHA radio networks with PSK modulation in Rayleigh fading channels d593
Zhang, K., and Pahlavan, K. CSMA local radio networks with BPSK modulation in Rayleigh fading channels p1655
Zhang, L., Chandler, P.S., and Townsend, P.D. see Chandler, P.S.
Zhang, L., Field, S.J., Hanna, D.C., Shepherd, D.P., Tropper, A.C., Chandler, P.J., and Townsend, P.D. see Field, S.J.
Zhang, L., Townsend, P.D., Chandler, P.J., Wood, R.A., McCallum, J., and McHargue, C.W. see Townsend, P.D.
Zhang, L., Vucetic, B., and Khachatrian, G. see Vucetic, B.
Zhang, L., and Henry, R.M. see Henry, R.M.
Zhang, L., and Vucetic, B. Bandwidth efficient block codes for Rayleigh fading channels p301
Zhang, W.X., and Yang, X.H. see Yang, X.H.
Zhang, X., and Jiang, P. Error probability of optical heterodyne MSK communication system with limiter–discriminator–integrator detector p136 e1832
Zhang, Y.H., Dämbkes, H., Marschall, P., and Ploog, K. see Dämbkes, H.
Zhao, Z.-J., and Qian, H.-S. see Qian, H.-S.
Zhao, Z.-L., Lai, S.-L., and Liu, A.-S. $Ba(Zn_{1/3}Ta_{2/3})O_3$–$Ba(Cd_{1/3}Nb_{2/3})O_3$ dielectric ceramics with low microwave loss p1605
Zheng, D., and Michalski, K.A. Analysis of arbitrarily shaped coax-fed microstrip antennas with thick substrates p794 e1324
Zheng, F., McLaughlin, S., and Mulgrew, B. Robust blind deconvolution algorithm: Variance approximation and series decoupling p921
Zheng, X.H., and Carroll, J.E. Competition between second and third harmonic generation in silica fibres p2065
Zhou, F., and Ferguson, A.I. Tunable single frequency operation of a diode laser pumped Nd : YAG microchip at 1·3 μm p490
Zhou, P., and Lee, G.S. Chirped grating $\lambda/4$-shifted distributed feedback laser with uniform longitudinal field distribution p1660
Zhu, N.Y., and Landstorfer, F.M. Application of MFIE to three-dimensional conducting waveguide transitions of arbitrary shape p143
Zhuang, N., and Wu, H. Novel ternary JKL flip-flop p1145
Zhuang, Y.H., Chen, T.R., Yariv, A., Blauvelt, H., and Bar-Chaim, N. see Chen, T.R.
Zigic, A., and Prasad, R. Computer simulation of indoor data channels with a linear adaptive equaliser p1596
Zimmermann, J., Vanbremeersch, J., Constant, E., Valin, I., Godts, P., and Leroy, A. see Vanbremeersch, J.
Zirngibl, M., Bischoff, J.C., Ilegems, M., Hirtz, J.P., Bartenlian, B., Beaud, P., and Hodel, W. High speed 1·3 μm InGaAs/GaAs superlattice on Si photodetector p1027
Zongo, P.-H., Blanchard, P., and Facq, P. see Blanchard, P.
Zongo, P.-H., Yu, Q., and Facq, P. Micro-optic adjustable coupler p1813
Zou, J., Gopinath, A., Akinwande, T., and Shur, M.S. Heterostructure field effect transistor with doping dipole in charge control layer p964 e1832
Zouganeli, P., Whitehead, M., Stevens, P.J., Rivers, A., Parry, G., Roberts, J.S., and Button, C. Temperature sensitivity of asymmetric Fabry–Perot modulators p1384
Zounon, A., Crozat, P., and Adde, R. Time domain CAD and measurements of lossy coupled lines p473
Zucker, J.E., Goossen, K.W., Bar-Joseph, I., Kuo, J.M., Kopf, R.M., Miller, D.A.B., and Chemla, D.S. see Goossen, K.W.
Zucker, J.E., Jones, K.L., Chang, T.Y., Sauer, N., Tell, B., Brown-Goebeler, K., Wegener, M., and Chemla, D.S. Compact low-voltage InGaAs/InAlAs multiple quantum well waveguide interferometers p2029
Zuleeg, R., Lin, C.L., and Wieder, H.H. see Lin, C.L.
Zuo, Z.P., and Deen, M.J. see Deen, M.J.
Zwicknagl, P., Tews, H., Neumann, R., Jaeger, G., Hoepfner, A., Schleicher, L., and Packeiser, G. see Tews, H.
Zydzik, G.J., Hasnain, G., Tai, K., Wynn, J.D., Wang, Y.H., Fischer, R.J., Hong, M., Weir, B.E., Mannaerts, J.P., Gamelin, J., and Cho, A.Y. see Hasnain, G.

Subject index

ACOUSTIC TRANSDUCERS

Unified approach to analyse mass sensitivities of acoustic gravimetric sensors. Z. Wang, J.D.N. Cheeke and C.K. Jen p1511

ACOUSTICS

$LiNbO_3$ acoustic plate mode sensor for dilute ionic solutions. F. Josse, D.T. Haworth, U.R. Kelkar and Z.A. Shana p834
Simple method for calculating optimum cut of piezoelectric material with small BAW generation by IDTs. J.H. Yin, Y. Shui, D. Zhang, J. Yu and P. Wu p1175

ACOUSTO-OPTICS

Wide angular aperture acousto-optic configurations in biaxial crystals. J.E.B. Oliveira and E.L. Adler p931

ACTIVE FILTERS

Cascadable current-mode single CCII biquads. S.-I. Liu, H.-W. Tsao and J. Wu p2005
Improved version of the inverse Chebyshev filter. M. Lutovac and D. Rabrenović p1256
Low Q equiripple functions of nonminimum order. D. Rabrenović and M. Lutovac p447
New multifunction active filter configuration employing current conveyors. V.K. Singh and R. Senani p1814
Very linear CMOS floating resistor. J. Silva-Martinez, M. Steyaert and W. Sansen p1610

ACTIVE NETWORKS

Series impedance simulators using one CCII. A. Himura, Y. Fukui, M. Ishida and M. Higashimura p269

ADAPTIVE FILTERS

Mean square convergence analysis of LMS algorithm. V.A. Gholkar p1705
Range determination in a multipath prone environment. G. Bortz, J.J. van Schalkwyk and W. Louw p1253
Systolic array for nonlinear multidimensional interpolation using radial basis functions. D.S. Broomhead, R. Jones, J.G. McWhirter and T.J. Shepherd p7

ADAPTIVE SYSTEMS AND CONTROL

Continuous adaptive speech analysis based on a time-varying ARMA model. B.K. Lim and C.K. Un p674
Iterative learning control of completely irregular plants with initial impulsive action. B. Porter and S.S. Mohamed p851
Modified Hebbian auto-adaptive impulse neural circuits. N. Nintunze and A. Wu p1561
Modified backpropagation algorithm for fast learning in neural networks. L.M. Reyneri and E. Filippi p1564
New adaptive Viterbi detector for fast-fading mobile-radio channels. E. Dahlman p1572
Performance of packet reservation multiple access for digital mobile radio using variable rate speech coder. J. Dunlop and J.Y. Khan p2074
Reducing the effect of pointing errors on the performance of an adaptive array. K.W. Lo p1646
Self adjusting weights for hardware neural networks. R.M. Iñigo, A. Bonde and B. Holcombe p1630
Simple derivation of adaptive algorithms for arbitrary filter structures. U. Forssén p1764
Time delay estimation with gradient type adaptive algorithm. V.N. Vasilev and P.P. Aidemirski p1797
Training algorithms for backpropagation neural networks with optimal descent factor. X-H. Yu and S-X. Cheng p1698
Training binary node feedforward neural networks by back propagation of error. D.J. Toms p1745

ADDERS

Bit stream adder for oversampling coded data. P. O'Leary and F. Maloberti p1708
Carry–save adders for computing the product AB modulo N. C.K. Koç and C.Y. Hung p899
Multi-operand modulo addition using carry save adders. Ç.K. Koç and C.Y. Hung p361

ALGORITHMS

Adaptive algorithm for variable teletraffic demand in highway microcells. R. Steele, M. Nofal and S. Eldolil p988
Algorithm for computing two-dimensional discrete Hartley transform of size $p^n \times p^n$. W. Ma p1795
Algorithm for large-phase-modulation measurements. M.N. Zervas p112
Algorithm for prime length discrete cosine transforms. Y.-H. Chan and W.-C. Siu p206
Analysis of telecommunications switch model (GEO/D/1) with time priorities. J.A. Schormans, E.M. Scharf and J.M. Pitts p325
Bearing estimation of coherent sources by circular spatial modulation averaging (CSMA) technique. B.L. Lim, S.K. Hui and Y.L. Lim p343
Design of IIR group delay equalisers. L. Lo Presti and M. Visintin p200
Fast cosine transform based on the successive doubling method. F. Argüello and E.L. Zapata p1616
Fast odd discrete cosine transform algorithms. S.C. Chan and K.L. Ho p503
Filtering with the fast T transform. T.F. Pena, J.C. Cabaleiro, J.D. Bruguera and E.L. Zapata p718
Hexagonally connected processor array for Jacobi-type matrix algorithms. M. Moonen and J. Vandewalle p400
Image compression algorithm for fast parallel thinning of binary images. L. Hayat and M.B. Sandler p1056
Motion estimation algorithm using interblock correlation. C.-H. Hsieh, P.-C. Lu, J.-S. Shyn and E.-H. Lu p276
Multi-operand modulo addition using carry save adders. Ç.K. Koç and C.Y. Hung p361
New radix-3 FHT algorithm. N. Anupindi, S.B. Narayanan and K.M.M. Prabhu p1537
Noise reduction based on microphone array with LMS adaptive post-filtering. R. Zelinski p2036
Nonlinear circuit analysis using the Newton-SOR continuation method. K.K.M. Cheng and J.K.A. Everard p2120
Prime factor fast Hartley transform. D. Yang p119
Robust blind deconvolution algorithm: Variance approximation and series decoupling. F. Zheng, S. McLaughlin and B. Mulgrew p921
Robust model reference adaptive control algorithm for a class of plants with bounded input disturbances. S.K. Tso and H.Y. Shum p1220
Scattering from a circular dielectric cylindrical shell: A fast algorithm. S. Jegannathan and B. Ramamurthi p484
Simple derivation of adaptive algorithms for arbitrary filter structures. U. Forssén p1764
Single sided switching networks. J. Gordon and S. Srikanthan p248
Slotted ALOHA multihop packet radio networks with directional antennas. J. Zander p2098
Time delay estimation with gradient type adaptive algorithm. V.N. Vasilev and P.P. Aidemirski p1797

AMPLIFIERS

10 GHz bandwidth low-noise optical receiver using discrete commercial devices. M.A.R. Violas, D.J.T. Heatley, A.M.O. Duarte and D.M. Beddow p35
10 GHz bandwidth, 20 dB gain low-noise direct-coupled amplifier ICs using Au/WSiN GaAs MESFET. Y. Imai, M. Tokumitsu, K. Onodera and K. Asai p699
10 Gbit/s, 100 km nonrepeatered fibre transmission experiment using a high-sensitivity semiconductor optical preamplifier. H. Nakano, S. Tsuji, K. Uomi, S. Sasaki and K. Yamashita p1364
10 dB gain and high saturation power in a Nd^{3+}-doped fluorozirconate fibre amplifier. T. Sugawa, Y. Miyajima and T. Komukai p2042
152 photons per bit detection at 622 Mbit/s to 2·5 Gbit/s using an erbium fibre preamplifier. P.P. Smyth, R. Wyatt, A. Fidler, P. Eardley, A. Sayles and S. Craig-Ryan p1604
1·2 Gbit/s fully integrated transimpedance optical receiver OEIC for 1·3–1·55 μm transmission systems. W.S. Lee, D.A.H. Spear, M.J. Agnew, P.J.G. Dawe and S.W. Bland p377
1 W, coherent, monolithically integrated master oscillator power amplifier. R. Waarts, R. Parke, D. Welch, D. Mehuys, W. Streifer and D. Scifres p1926
20 dB Gain at 1·55 μm wavelength in 50 cm long Er^{3+}-doped fluoride fibre amplifier. Y. Miyajima, T. Sugawa and T. Komukai p1527
39·5 million-way WDM broadcast network employing two stages of erbium-doped fibre amplifiers. A.M. Hill, R. Wyatt, J.F. Massicott, K.J. Blyth, D.S. Forrester, R.A. Lobbett, P.J. Smith and D.B. Payne p1882
50 GHz MIC amplifiers using AlGaAs/GaAs HBTs. K. Ogawa, K. Hashimoto, T. Uwano and Y. Ota p2134
5 Gbit/s, +10 dBm lossless transmission in 10 km distributed erbium fibre amplifier. D.M. Spirit, L.C. Blank, D.L. Williams, S.T. Davey and B.J. Ainslie p1658
5 V, DC–12 GHz InP/InGaAs HBT amplifier. R.N. Nottenburg, M. Banu, B. Jalali, D.A. Humphrey, R.K. Montgomery, R.A. Hamm and M.B. Panish p2016
7203-user WDM broadcast network employing one erbium-doped fibre power amplifier. A.M. Hill, D.B. Payne, K.J. Blyth, D.S. Forrester, J.W. Arkwright, R. Wyatt, J.F. Massicott, R.A. Lobbett, P. Smith and T.G. Hodgkinson p605
94 GHz InP MMIC five-section distributed amplifier. R. Majidi-Ahy, M. Riaziat, C. Nishimoto, M. Glenn, S. Silverman, S. Weng, Y.C. Pao, G. Zdasiuk, S. Bandy and Z. Tan p91
9·5 GHz bandwidth HBT gain controllable amplifier IC with an amplitude detection circuit. H. Yamakawa, H. Ibe, J. Akagi, Y. Kuriyama, K. Morizuka and M. Obara p602
Amplification of femtosecond pulses in Er^{3+}-doped single-mode optical fibres. I.Yu. Khrushchëv, A.B. Grudinin, E.M. Dianov, D.V. Korobkin Jun, V.A. Semënov and A.M. Prokhorov p456
Broadband operation of InGaAsP–InGaAs GRIN-SC-MQW BH amplifiers with 115 mW output power. M. Bagley, G. Sherlock, D.M. Cooper, L.D. Westbrook, D.J. Elton, H.J. Wickes, P.C. Spurdens and W.J. Devlin p512
Coherent transmission experiment over 2223 km at 2·5 Gbit/s using erbium-doped fibre amplifiers. S. Saito, T. Imai, T. Sugie, N. Ohkawa, Y. Ichihashi and T. Ito p669
Effect of enhancing the Raman gain factor on the linearity of Raman fibre amplifiers. A.S. Siddiqui and A. Yu p1661
Efficient 1·3 μm-band amplification in a Nd^{3+}-doped single-mode fluoride fibre. Y. Miyajima, T. Sugawa and T. Komukai p1397
Efficient erbium-doped fibre amplifier pumped at 820 nm. M. Nakazawa, Y. Kimura, E. Yoshida and K. Suzuki p1936
Efficient, high power, high gain, Er^{3+} doped silica fibre amplifier. J.F. Massicott, R. Wyatt, B.J. Ainslie and S.P. Craig-Ryan p1038
Erbium-doped fibre amplifiers with an extremely high gain coefficient of 11·0 dB/mW. M. Shimizu, M. Yamada, M. Horiguchi, T. Takeshita and M. Okayasu p1641
Erbium-doped fluoride optical amplifier operating around 2·75 μm. D. Ronarc'h, J.Y. Allain, M. Guibert, M. Monerie and H. Poignant p903
Evanescent field amplification in a tapered single-mode optical fibre. H.S. Mackenzie and F.P. Payne p130
Feasibility demonstration of low pump power operation for 1·48 μm diode-pumped erbium-doped fibre amplifier module. J.F. Marcerou, H. Fevrier, J. Auge, J. Ramos and A. Dursin p1102
Femtosecond soliton amplification in erbium doped silica fibre. B.J. Ainslie, K.J. Blow, A.S. Gouveia-Neto, P.G.J. Wigley, A.S.B. Sombra and J.R. Taylor p186
Field demonstration of coherent transmission system with diode-pumped erbium doped fibre amplifiers. M.J. Creaner, D. Spirit, G.R. Walker, N.G. Walker, R.C. Steele, J. Mellis, S. Al Chalabi, W. Hale, I. Sturgess, M. Rutherford, D. Trivett and M. Brain p442
GaAs MESFET amplifiers fabricated on InP substrates. J. Jeong, G.P. Vella-Coleiro and C.M.L. Yee p135
Generalised formula for optical-amplifier noise and its application to erbium-doped fibre amplifiers. K. Kikuchi p1851
High gain erbium fibre amplifier pumped by 800 nm band. M. Nakazawa, Y. Kimura and K. Suzuki p548
High gain two-stage amplification with erbium-doped fibre amplifier. H. Masuda and A. Takada p661
High gain, broadband, 1·6 μm Er^{3+} doped silica fibre amplifier. J.F. Massicott, J.R. Armitage, R. Wyatt, B.J. Ainslie and S.P. Craig-Ryan p1645
High performance CMOS comparator for analogue-digital convertors. C.A. Leme and J.E. Franca p1725
High-bandwidth CMOS test buffer with very small input capacitance. J.F. Duque-Carrillo and R. Perez-Aloe p2084

Highly efficient integrated optical fibre amplifier module pumped by a 0·98 μm laser diode. M. Shimizu, M. Horiguchi, M. Yamada, M. Okayasu, T. Takeshita, I. Nishi, S. Uehara, J. Noda and E. Sugita p498
Highly efficient optical fibre amplifier pumped by a 0·8 μm band laser diode. M. Horiguchi, M. Shimizu, M. Yamada, K. Yoshino and H. Hanafusa p1758
Impact of spontaneous emission noise on the sensitivity of direct-detection lightwave receivers using optical amplifiers. O.K. Tonguz p1343
Lasing and amplification in the 0·8 μm region in thulium doped fluorozirconate fibres. J.N. Carter, R.G. Smart, D.C. Hanna and A.C. Tropper p1759
Low-distortion CMOS transconductor. G. Wilson and P.K. Chan p720
Making CMOS OTA a linear transconductor. Z. Wang p1448
Novel AlInAs/InP HEMT. O. Aina, M. Serio, M. Mattingly and E. Hempfling p651
Optimisation of refractive index profile for high gain fibre amplifiers. M.J. Holmes, D.M. Spirit and F.P. Payne p1873
Optimum design of erbium fibre amplifiers pumped with sources emitting at 1480 nm. J.H. Povlsen, A. Bjarklev, B. Pedersen, H. Vendeltorp-Pommer and K. Rottwitt p1419
Over 350 km CPFSK repeaterless transmission at 2·5 Gbit/s employing high-output power erbium-doped fibre amplifiers. T. Sugie, T. Imai and T. Ito p1577
Potential of the distributed amplifier as a photo-diode detector amplifier in high bit rate optical communication systems. C.S. Aitchison p1693
Repeaterless transmission with 62·9 dB power budget using a highly efficient erbium-doped fibre amplifier module. B. Clesca, A. Auge, B. Biotteau, P. Bousselet, A. Dursin, C. Clergeaud, P. Kretzmeyer, V. Lemaire, O. Gautheron, G. Grandpierre, E. Leclerc and P. Gabla p1426
Soliton collision interaction force dependence on wavelength separation in fibre amplifier based systems. P.A. Andrekson, N.A. Olsson, J.R. Simpson, T. Tanbun-Ek, R.A. Logan, P.C. Becker and K.W. Wecht p1499
Spectral broadening due to fibre amplifier phase noise. G.J. Cowle, P.R. Morkel, R.I. Laming and D.N. Payne p424
Spectral linewidth broadening in Er-doped-fibre amplifiers measured with less than 1·4 kHz linewidth light source. H. Okamura and K. Iwatsuki p1965
Temperature dependent gain and noise characteristics of a 1480 nm-pumped erbium-doped fibre amplifier. M. Suyama, R.I. Laming and D.N. Payne p1756
UHF band high-efficiency linear power amplifier for mobile communication satellites. K. Sekine, Y. Dooi, A. Iso, H. Funaki and I. Takei p441
Ultra-high gain, low noise monolithic InP HEMT distributed amplifier from 5 to 40 GHz. C. Yuen, Y.C. Pao, M. Day, C. Nishimoto, M. Glenn, S. Bandy and G. Zdasiuk p515
Ultra-low reflectivity broadband 1·5 μm GaInAsP semiconductor optical amplifiers. P.E. Barnsley, J.J. Isaac and D.J. Elton p825
Unrepeatered 2·4 Gbit/s transmission experiment over 250 km of step-index fibre using erbium power amplifier. E.G. Bryant, S.F. Carter, A.D. Ellis, W.A. Stallard, J.V. Wright and R. Wyatt p528
Wideband class AB (push–pull) current amplifier in CMOS technology. Z. Wang p543
$x^{(3)}$ measurements in a bistable GaAlAs Fabry–Perot amplifier. R. Calvani and R. Caponi p1513

ANALOGUE COMPUTERS

Analogue computation using VLSI neural network devices. M.J. Brownlow, L. Tarassenko and A.F. Murray p1297

ANALOGUE-DIGITAL CONVERSION

High performance CMOS comparator for analogue-digital convertors. C.A. Leme and J.E. Franca p1725
Interpolative bandpass A/D conversion—Experimental results. H.-J. Dressler p1652
New analogue multiplier–divider circuit based on cyclic data convertors. M.S. Piedade p2
New design technique for two-step flash A/D convertors. R.E. Ahmed p1185
Noise performance comparison for third and fourth order cascaded sigma–delta modulators having parameter tolerance errors. M.I. Mathew and C.P. Lewis p158
Some structures for neural based A/D conversion. G. Avitabile and S. Manetti p1516

ANNEALING

Angle resolved X-ray photoemission study of rapid thermal annealing applied to different GaAs and InP samples. A. Quemerais, G. Jezequel, H. L'Haridon, P.N. Favennec and M. Salvi p1119
Laser-annealed refractory metal silicide films on GaAs. W.T. Anderson, A. Christou, P.E. Thompson, C.R. Gossett, J.M. Eridon, Z. Hatzopoulos, T. Efthimiopoulos, M. Kudumas, C. Michelakis and D.V. Morgan p62
Measurement of the increase in the SHG coefficient of proton exchanged $LiNbO_3$ after annealing using a grating diffraction technique. R.W. Keys, A. Loni and R.M. De La Rue p624
Novel low temperature RF plasma annealing using NH_3–N_2 gas mixture. K. Aite, F.W. Ragay and J. Middelhoek p733

ANTENNA ARRAYS

Array synthesis using a simple computer-aided approach. B.P. Ng p337
Computer-aided design of array pattern. M.H. Er p2113
Coplanar waveguide antenna arrays for MIC/MMIC at millimetre wave frequencies. X.H. Yang and W.X. Zhang p1464
Dual-loop slot array antenna radiating circularly polarised wave. K. Hirose, H. Horiuchi and H. Nakano p179
Eigenstructure method for robust array processing. W.S. Youn and C.K. Un p678
Method of null steering in phased array antenna systems. B.E. Stuckman and J.C. Hill p1216
Mismatch in dielectric-loaded rectangular waveguide antenna. T.S. Bird and S.G. Hay p59
Null steering in monopulse planar array using amplitude only control. K.W. Lo p1700
Sensitivity of the radiation pattern of a small slotted waveguide array to the finiteness of its elliptical groundplane. D.A. McNamara and L. Botha p387
Simple-iterative method for pattern synthesis using nonuniformly spaced arrays. M.A. Hassan p891
Synthetis of single sets of 2ⁿ mutually orthogonal phase codes. E.R. McKinnon p1240

ANTENNA FEEDERS

Aperture coupled microstrip antenna element design. R. Oostlander, Y.M.M. Antar, A. Ittipiboon and M. Cuhaci p224

ANTENNA THEORY

Conjugate gradient computation of the current distribution on a tripole FSS array element. M.M. Mokhtar and E.A. Parker p227
Radiation from vertical electric dipole located over laterally anisotropic groundplane. J.R. Wait p74

ANTENNAS

Active patch antenna element for array applications. R.A. York, R.D. Martinez and R.C. Compton p494
Analysis of arbitrarily shaped coax-fed microstrip antennas with thick substrates. D. Zheng and K.A. Michalski p794 e1324
Aperture coupled microstrip antenna element design. R. Oostlander, Y.M.M. Antar, A. Ittipiboon and M. Cuhaci p224
Array synthesis using a simple computer-aided approach. B.P. Ng p337
Asymptotic method in prediction of E plane radiation pattern of rectangular microstrip patch antennas on finite ground. P. Vaudon, A. Reineix and B. Jecko p956
Attractive behaviours of NRD leaky wave antenna with tuning aperture. A.S. Rong p1887
CAD-oriented cavity model for rectangular patches. D. Thouroude, M. Himdi and J.P. Daniel p842
Characterisation of an optoelectronically pulsed equiangular spiral antenna. Y. Pastol, G. Arjavalingam and J.-M. Halbout p133
Circular polarisation characteristics of stacked microstrip antennas. R.Q. Lee, T. Talty and K.F. Lee p2109
Conjugate gradient computation of the current distribution on a tripole FSS array element. M.M. Mokhtar and E.A. Parker p227
Coplanar-waveguide/microstrip probe coupler and applications to antennas. R.N. Simons and R.Q. Lee p1998
Design of a broadband high-frequency antenna on gallium arsenide using the effective index method. L.J. Baca and J.G. McInerney p1083
Dispersion characteristic of the double-sided slotline. S.G. Pintzos p813 e1738
Dual-loop slot array antenna radiating circularly polarised wave. K. Hirose, H. Horiuchi and H. Nakano p179
Effects on polarisation of inclined conducting strip located in front of radiating slot. J. Hur and C.W. Lee p713
Efficient power transfer through small apertures. P.G. Frayne and J. Potter p2070
Elliptical microstrip antenna on ferrite substrate. S.S. Pattnaik, R.K. Mishra and N. Das p1906
Full wave finite element analysis of slot-coupled microstrip antennas. S.-G. Pan and I. Wolff p1465
Generalised formulas for beam squint prediction in conic-section reflector antennas. D.W. Duan and Y. Rahmat-Samii p722
Hallen-type integral equation to a system composed by wires with dielectric coating. J. Yamauchi and H. Nakano p1412
Hankel transform domain analysis of dual-frequency stacked circular disc microstrip antenna. Z. Fan and K.F. Lee p1467
Helical antenna and spiral antenna with fast switch selection of the polarisation sense. G. Mönich and B. Littmann p1918
Improved convergence of iterative scheme for analysing arrays of finite size. A. Stylianou and J.C. Vardaxoglou p641 e1324
Improved feed-system for a printed antenna composed of strip dipoles and slots. M. Naito and K. Ito p1228
Ku band electric models for large deployable mesh reflector antenna. S. Sato, A. Iso, T. Orikasa and T. Sugimoto p2091
Large bandwidth aperture-coupled microstrip antenna. F. Croq and A. Papiernik p1293
Launching vertically polarised ground waves from a vertical magnetic dipole over an anisotropic surface. J.R. Wait p1080
Low-profile dual band, dual polarised array antenna module. R.P. Owens and A.C. Smith p1433
Method of null steering in phased array antenna systems. B.E. Stuckman and J.C. Hill p1216
Microstrip antennas with integrated fibre optic feeds. D.M. Pozar, R.W. Jackson and A. Svitak p1889
Microstrip subarray with coplanar and stacked parasitic elements. K.F. Lee, R.Q. Lee and T. Talty p668
Mismatch in dielectric-loaded rectangular waveguide antenna. T.S. Bird and S.G. Hay p59
Modelling and simulation of frequency selective fading using switched antenna diversity. A.R. Nix and J.P. McGeehan p1868
Modelling of arbitrary shaped M/S patch antennas in multiple substrate media. M.J. Notter and C.G. Parini p50
Modelling of wideband proximity coupled microstrip array elements. J.S. Herd p1282
Multifunctional aperture coupled stack patch antenna. J. Wang, R. Fralich, G. Wu and J. Litva p2067
New radiating edges coupling model for the gap between two rectangular microstrip patch antennas. Y.K. Cho, J.P. Hong and H. Son p1295
Optical steering of dual band microwave phased array antenna using semiconductor laser switching. W. Ng, A. Walston, G. Tangonan, J.J. Lee and I. Newberg p791
Optimisation of UHF antennas. K.E. Stocker and F.M. Landstorfer p241
Overlapping quadrifilar resonant helix antenna. A. Sharaiha and C. Terret p1090
Phased array beam steering using phase-locked loops. P.V. Brennan and A.W. Houghton p165
Plane-polar near-field to far-field transformation with the near-field interpolation method. E. Van Lil, C. Cao, A. Van de Capelle and K. Van't Klooster p1886
Radiation from vertical electric dipole located over laterally anisotropic groundplane. J.R. Wait p74
Reducing the effect of pointing errors on the performance of an adaptive array. K.W. Lo p1646
Resonant frequency of wedge shaped microstrip antenna. R.K. Mishra and S.S. Pattnaik p912
Rigorous closed-form expressions for the surface wave loss of printed antennas. D.M. Pozar p954
Rigorous feed model for coaxially fed microstrip antenna. R.C. Hall and J.R. Mosig p64 e345
Scan limitations of shaped dual-offset reflector antennas for multiple satellite access. T.S. Bird and M.A. Sprey p228
Sidelobe suppression in an *E*-plane sectoral horn antenna. O.W. Ata, T.M. Benson and A. Marincic p231
Significance of matching networks in enhanced performance of small antennas when supercooled. S. Khamas, G.G. Cook, S.P. Kingsley and R.C. Woods p654
Simple-iterative method for pattern synthesis using nonuniformly spaced arrays.

M.A. Hassan p891
Singly-fed patch antenna radiating a circularly polarised conical beam. H. Nakano, K. Vichien, T. Sugiura and J. Yamauchi p638
Synthesis procedure for active integrated radiating elements. V.F. Fusco and H.O. Burns p263
Tapered slot antenna analysis with 3-D TLM method. F. Ndagijimana, P. Saguet and M. Bouthinon p468
Thin wire dipoles—a finite-difference time-domain approach. J.J. Boonzaaier and C.W.I. Pistorius p1891
Transmission line model analysis of arbitrary shape symmetrical patch antenna coupled with a director. G. Dubost and A. Zerguerras p952
Use of closely-spaced height diversity antennas to alleviate the effects of low angle non-absorptive fading on satellite slant paths. D.L. Bryant and J.E. Allnutt p479

ARTIFICIAL INTELLIGENCE

Comparing performance of Hebbian- and delta-trained Hopfield networks. P.K. Houselander and J.T. Taylor p85
L_1 normalisation in neural networks using parallel automatic level control. R. Perfetti p82

ATMOSPHERIC PROPAGATION

Extension of the multiparabolic ionospheric model to the F1-layer L-condition. D.C. Baker p1301
Potential use of optimal polarisations in sensing the canting angle distribution of raindrops. A.P. Agrawal p157
Statistics of duration and intensity of path loss in a microwave transhorizon sea-path. A.N. Tawfik and E. Vilar p474

ATTENUATION

1·31–1·36 μm optical amplification in Nd^{3+}-doped fluorozirconate fibre. Y. Miyajima, T. Komukai and T. Sugawa p194
Fabrication of long lengths of low excess loss erbium-doped optical fibre. S.P. Craig-Ryan, B.J. Ainslie and C.A. Millar p185
Measured radiometric satellite link attenuation estimation error statistics at 11·2 GHz. W.J. Vogel, G.W. Torrence and J.E. Allnutt p1503
Microwave attenuation due to rainfall at 21·255 GHz in the Singapore environment. T.S. Yeo, P.S. Kooi, M.S. Leong and S.S. Ng p1021
Propagation measurements at 1·7 GHz for microcellular urban communications. R. Davies, A. Simpson and J.P. McGeehan p1053
Radio propagation over trapeozoidal plateau with sloping front face. J. Gong, T.S.M. Maclean and Z. Wu p604
Radiometric rain attenuation measurements at 11·6 GHz in Peru. A.W. Dissanayake, J.E. Allnutt and D.K. McCarthy p168
Rain rate measurements in Indonesia. M. Juy, R. Maurel, M. Rooryck, I.A. Nugroho and T. Hariman p596
Real-time prediction of attenuation for applications to fade countermeasures in satellite communications. L. Dossi p250
Results of site-diversity radiometric measurements at Ku-band in Brazil. C.G.S. Migliora, M.S. Pontes and L.A.R. Silva Mello p1552
Rigorous calculation of losses of single and coupled groove-guides. J. Meissner p41
Satellite Earth path attenuation at 11 GHz in Indonesia. M. Juy, R. Maurel, M. Rooryck, I.A. Nugroho and T. Hariman p1404
Slant path 30 to 12·5 GHz copolar phase difference, first results from measurements using the Olympus satellite. A. Mawira p1138
Statistics of clear-air attenuation on satellite links at 20 and 30 GHz. G. Ortgies, F. Rücker and F. Dintelmann p358
Very low rain statistics for the design of low availability satellite communication systems. F. Barbaliscia and M. Boumis p417
Water and hydrogen equilibrium for different cable constructions. W. Griffioen p1122

ATTENUATORS

Micro-optic adjustable coupler. P.-H. Zongo, Q. Yu and P. Facq p1813

AUTOMATIC CONTROL

AGC based on hard detected FFH signal matrices. I. Vajda p218

AVALANCHE DIODES

Gigabit high sensitivity receiver using InGaAs/InAlAs superlattice APD. Y. Miyamoto, K. Hagimoto and T. Kagawa p491
IMPATT operation below the avalanche frequency. J.-F. Luy p1960
Strong dependence of time resolution on detector diameter in single photon avalanche diodes. A. Lacaita and M. Mastrapasqua p2053

BINARY SEQUENCES

Infinite families of quasiperfect and doubly quasiperfect binary arrays. J. Jedwab and C.J. Mitchell p294
Proposal for a versatile monolithic multi-Gbit/s m-sequence test system. M. Bußmann and U. Langmann p1625

BIOELECTRICAL PHENOMENA

Interconnection-free set logic network based on a bio-device model. T. Aoki, M. Kameyama and T. Higuchi p1015

BIPOLAR DEVICES

10 Gbit/s AlGaAs/GaAs heterojunction bipolar transistor decision circuit IC. J. Akagi, Y. Kuriyama, K. Morizuka, M. Asaka, K. Tsuda, M. Obara and H. Yamakawa p122
20 Gbit/s time-division multiplexer IC in silicon bipolar technology. J. Hauenschild, H.-M. Rein, W. McFarland, J. Doernberg and D. Pettengill e2137
3·4 GHz silicon bipolar versatile shift register and 6·8 Gbit/s word generator. B. Wüppermann, U. Langmann and A. Pottbäcker p553
4 Gbit/s *pin*/HBT monolithic photoreceiver. S. Chandrasekhar, A.G. Dentai, C.H. Joyner, B.C. Johnson, A.H. Gnauck and G.J. Qua p1880
50 GHz MIC amplifiers using AlGaAs/GaAs HBTs. K. Ogawa, K. Hashimoto, T. Uwano and Y. Ota p2134
Electrical method for measuring emitter depth of shallow bipolar transistors. I.R.C. Post and P. Ashburn p30
Fully differential operational amplifiers using CMOS compatible lateral bipolar transistors with improved common-mode regulation. J.-P. Bardyn and A. Kaiser p798
GaAs–GaAsSb based heterojunction bipolar transistor. B. Khamsehpour and K.E. Singer p965
Heterostructure bipolar transistor employing carbon-doped base grown with trimethyl-Ga and arsine. T.Y. Kuo, T.H. Chiu, J.E. Cunningham, K.W. Goossen, C.G. Fonstad and F. Ren p1260
High frequency *Pnp* AlGaAs/InGaAs heterojunction bipolar transistor with an ultrathin strained base. W.U. Liu, D. Hill, D. Costa and J.S. Harris, Jun p2000
High speed linear array circuit with AlGaAs/GaAs heterojunction bipolar transistors (HBTs). L.M. Lunardi, V.D. Archer, R.G. Swartz, J.M. Kuo, R.F. Kopf, R.J. Malik and P.R. Smith p1157
High-frequency output characteristics of AlGaAs/GaAs heterojunction bipolar transistors. J. Chen, G.B. Gao, M.S. Ünlü and H. Morkoç p2058
High-speed fully self-aligned single-crystal contacted silicon bipolar transistor. J.L. Glenn and G.W. Neudeck p1677
Hybrid 11 Gbit/s parallel processing decision circuit using submicron silicon bipolar ICs. K. Runge, J. Young, M. Bagheri, D. Millicker, I. Kipnis and C. Snapp p1402
Improving the characteristics of InAlAs/InGaAs heterojunction bipolar transistors by employing thin base and collector layers. H. Fukano, Y. Kawamura, H. Asai, Y. Takanashi and M. Fujimoto p1101
Influence of the interfacial oxide layer on the gain of polycrystalline silicon emitter bipolar transistors processed in VLSI BiCMOS technology. G. Giroult-Matlakowski, N. Degors, A. Marty, A. Chantre and A. Nouailhat p1002
Low-frequency noise performance of self-aligned InAlAs/InGaAs heterojunction bipolar transistors. S. Tanaka, N. Hayama, A. Furukawa, T. Baba, M. Mizuta and K. Honjo p1439
MOCVD grown carbon-doped graded-base AlGaAs/GaAs HBTs. H. Ito p1977
Mg-doped graded base GaAs/AlGaAs heterojunction bipolar transistors grown by metalorganic vapour phase epitaxy. H. Tews, P. Zwicknagl, R. Neumann, G. Jaeger, A. Hoepfner, L. Schleicher and G. Packeiser p58
Newly structured expandable 52 Mbit/s, 48-channel time-division switching LSI with 2·4 Gbit/s throughput. N. Yamanaka, S. Kikuchi and H. Miyanaga p524
Novel doubly self-aligned AlGaAs/GaAs HBT. W.U. Liu, D. Costa and J. Harris p1361
Ultra-high current gain InGaAsP/InP heterojunction bipolar transistor. T. Ohishi, Y. Abe, H. Sugimoto, K. Ohtsuka and T. Matsui p392
Using constant base current as a boundary condition for one-dimensional AlGaAs/GaAs heterojunction bipolar transistor simulation. L.L. Liou and C.I. Huang p1501
Versatile divider circuits up to 9 GHz input-frequency realised in high-speed BICMOS. P. Weger, A. Felder, M. Kerber and H. Klose p1942
Versatile silicon bipolar XOR gate for signal processing up to 8 Gbit/s. J. Hauenschild, H.-M. Rein, L. Schmidt and K. Wörner p114

BIREFRINGENCE

Effect of mechanical inhomogeneity on intrinsic stress birefringence in birefringent optical fibres. D. Wong p967
Enhanced electro-optic polarisation rotation in AlGaAs/GaAs (111) quantum wells. S.M. Shank and G.W. Wicks p1769
Hydrostatic pressure induced birefringence in a highly birefringent optical fibre. K.S. Chiang and D. Wong p1952
Polarisation-maintaining fibre using a novel glass system. Y.T. Ko, D.J. DiGiovanni, J.B. MacChesney and J.R. Simpson p876
Rocking filter formation in photosensitive high birefringence optical fibres. P.St. J. Russell and D.P. Hand p1846
Simple method for calculation of stress-induced birefringence in fibres with arbitrary structures. H. Jin and Q. Jingren p598
Strain-induced birefringence in a highly birefringent optical fibre. K.S. Chiang, D. Wong and P.L. Chu p1344

BOOLEAN ALGEBRA

On the relevance of the strict avalanche criterion. S. Babbage p461

CABLES

Water and hydrogen equilibrium for different cable constructions. W. Griffioen p1122

CAPACITORS AND CAPACITANCE

1·2 Gbit/s fully integrated transimpedance optical receiver OEIC for 1·3–1·55 μm transmission systems. W.S. Lee, D.A.H. Spear, M.J. Agnew, P.J.G. Dawe and S.W. Bland p377

CELLULAR ARRAYS

Performance of CT2/CAI systems in small cell environments. J.E. Button p1434

CHARACTER RECOGNITION

Characterisation of line drawings using generalised Fourier descriptors. N.B.J. Weyland and R. Prasad p1794
Optical Chinese character recognition with a hidden Markov model classifier—A novel approach. B.-S. Jen, M.-W. Chang, S.-W. Sun, C.-H. Shih and T.-M. Wu p1530

CIRCUIT THEORY AND DESIGN

10 GHz bandwidth, 20 dB gain low-noise direct-coupled amplifier ICs using Au/WSiN GaAs MESFET. Y. Imai, M. Tokumitsu, K. Onodera and K. Asai p699
2-MOSFET transresistor with extremely low distortion for output reaching supply voltages. Z. Wang p951 d2127
3·2 GHz 0·2 μm gate CMOS 1/8 dynamic frequency divider. Y. Kado, Y. Okazaki, M. Suzuki and T. Kobayashi p1684
8 GHz full Nyquist HBT comparator. D. Selle, D. Carisetti, T. Ducourant, P. Bertsch and P. Boissenot p919
CMOS VHF transconductance-C lowpass filter. B. Nauta p421
CMOS triode transconductor with high dynamic range. B. Stefanelli and A. Kaiser p880
Current mode allpass/notch and bandpass filters with reduced sensitivities. A. Fabre, F. Martin and M. Hanafi p1495
Current-mode active compensation techniques. C.A. Makris and C. Toumazou p1792
Design of a hybrid receiver for the OLYMPUS spacecraft beacons. D.G.

Sweeney and J.C. McKeeman p934
Design of linear tunable CMOS differential transconductor cells. Z. Czarnul and S. Takagi p1809
Differential current input cell with common mode feedback. A. Payne, C. Toumazou and P. Ryan p1718
Equations of nonlinear analogue circuit for fault dictionary generation. V.C. Prasad p24
Fast timing extraction method for an optical passive bus. Y. Nagasako and T. Nakashima p1168
Fully differential operational amplifiers using CMOS compatible lateral bipolar transistors with improved common-mode regulation. J.-P. Bardyn and A. Kaiser p798
High frequency gallium arsenide current mirror. C. Toumazou and D.G. Haigh p1802
High frequency gallium arsenide four-quadrant analogue multiplier. C. Toumazou, D.G. Haigh and J.M. Fopma p1650
High frequency gallium arsenide linearised transconductor for communications. D.G. Haigh and C. Toumazou p497
Highly-linear transconductor cell realised by double MOS transistor differential pairs. Z. Czarnul and N. Fujii p1819
In-*situ* investigation of coupling between a fibre and a slab waveguide. M. Iztkovich, M. Tur, A. Hardy and N. Croituro p1104
InGaAsP 400 × 200 μm active crosspoint switch operating at 1·5 μm using novel reflective Y-coupler components. I.H. White, J.J.S. Watts, J.E. Carroll, C.J. Armistead, D.J. Moule and J.A. Champelovier p617
L_1 normalisation in neural networks using parallel automatic level control. R. Perfetti p82
Latch-up property and dynamic stability in sinusoidal oscillators. P. Martinez, A. Carlosena, S. Porta and S. Celma p542
Low-distortion CMOS transconductor. G. Wilson and P.K. Chan p720
Low-phase-error offset-compensated switched-capacitor integrator. W.-H. Ki and G.C. Temes p957
Low-sensitivity universal first-order digital filter sections without limit cycles. I.P. Topalov and G.K. Stoyanov p25
MOS triangle-to-sine wave convertor based on subthreshold operation. Z. Tang, O. Ishizuka and H. Matsumoto p1983
MOSFET capacitor filters using unity gain CMOS current conveyors. S.-I. Liu, H.-W. Tsao, J. Wu and T.-K. Lin p1430
Micro-optic adjustable coupler. P.-H. Zongo, Q. Yu and P. Facq p1813
Minimisation of MOSFET-C filters sensitivity by changing connections of capacitors. B. Galiński p784
New analogue four-quadrant voltage divider. A. Cichocki and R. Unbehauen p1580
New analogue multiplier–divider circuit based on cyclic data convertors. M.S. Piedade p2
New high-speed bipolar XOR gate with absolutely symmetrical circuit configuration. L. Schmidt and H.-M. Rein p430
New impedance transforming rat-race hybrid ring. H.R. Mgombelo, H.O. Ali and M.M. Kissaka p837
New multifunction active filter configuration employing current conveyors. V.K. Singh and R. Senani p1814
New switched-current integrator. B. Hughes, I.C. Macbeth and D.M. Pattullo p694
Newly structured expandable 52 Mbit/s, 48-channel time-division switching LSI with 2·4 Gbit/s throughput. N. Yamanaka, S. Kikuchi and H. Miyanaga p524
Novel linearisation technique for implementing large-signal MOS tunable transconductor. Z. Wang p138
Novel pipelined serial/parallel multiplier. D. Ait-Boudaoud, M.K. Ibrahim and B.R. Hayes-Gill p582
Novel voltage-controlled grounded resistor. Z. Wang p1711
Optimum dielectric overlay thickness for equal even- and odd-mode phase velocities in coupled microstrip circuits. J.L. Klein and K. Chang p274
Parasitic insensitive single amplifier switched capacitor bandpass biquad. C. Psychalinos and I. Haritantis p253
Phase lead compensator design. E.P. McCarthy p1817
Regulated cascode switched-current memory cell. C. Toumazou, J.B. Hughes and D.M. Pattullo p303
SC and pass transistor combined circuits. H.-L. Ho and K.C. Smith p769
SPICE simulation of quasi-resonant zero-current-switching DC–DC convertors. S. Ben-Yaakov, D. Edry, Y. Amran and O. Shimony p847
Self-timed system design technique. Y.K. Tan and Y.C. Lim p284
Series impedance simulators using one CCII. A. Himura, Y. Fukui, M. Ishida and M. Higashimura p269
Simple multiplexer circuit for CMOS VLSI. S. Summerfield p878
Simplified complex digital sampling demodulator. T.E. Thiel and G.J. Saulnier p419
Simulation of EPROM programming characteristics. T. Urai, J. Frey, Z.Z. Peng and N. Goldsman p716
Single ended resonant power supply for induction heating. J.M. Leisten, A.K. Lefedjiev and L. Hobson p814
Soft switch-avalanche IGBT convertor. K. Chen and T.A. Stuart p1623
Stable quarter-plane 2-D lattice filters. A. Ertüzün, A.H. Kayran and E. Panayirci p806
Stochastic instability of oscillator with coupled stabilising resonator. A.B. Belogortsev, M.F. Poliashenko, O.A. Tret'jakov and D.M.-Vavriv p1354
Switched-capacitor lowpass filters based on recursive running sum cells. G. Fischer p557
Systematic generation of OTA-C sinusoidal oscillators. R. Senani, M.P. Tripathi, D.R. Bhaskar and B.A. Kumar p1457
Systolic band-matrix multipliers. W. Luk p403
Temperature-stable VCO based on operational transconductance amplifiers. W.-S. Chung, H.-W. Cha and K.-H. Kim p1900
Very linear CMOS floating resistor. J. Silva-Martinez, M. Steyaert and W. Sansen p1610
Wideband class AB (push–pull) current amplifier in CMOS technology. Z. Wang p543

CLOCKS

11 Gbit/s, 260 km transmission experiment using a directly-modulated 1536 nm DFB laser with two Er-doped fibre amplifiers and clock recovery. A. Righetti, F. Fontana, G. Delrosso, G. Grasso, M.Z. Iqbal, J.L. Gimlett, R.D. Standley, J. Young, N.K. Cheung and E.J. Tarbox p330

CODES AND CODING

130 Mbit/s (H4 rate) HDTV CODEC based on the DCT algorithm. T. Kinoshita, T. Nakahashi and Y. Eto p1245
2.26 Gbit/s optical transmission system with 5B6B line coding. A.M.J. Koonen, P. Van Eijk, P.H. Van Heijningen and T.W.M. Mosch p799
BER improvement due to transversal equaliser in trellis-coded multi-level QAM digital microwave radio. H. Takanashi, S. Aikawa and Y. Nakamura p406
Bandwidth efficient block codes for Rayleigh fading channels. L. Zhang and B. Vucetic p301
Class of shortened cyclic codes over GF(2^8) for byte-oriented systems. V.K. Bhargava, G. Séguin and P.E. Allard p438
Coding and interleaving for meteor-burst communications. A.K. Al-Jabri p1907
Combined Huffman and convolutional codes: Concatenated form without feedback. B. Honary, M. Darnell and M. Shaw p367
Comparison of NRZ and AMI coding schemes using three-electrode and conventional DFB laser transmitters in a 636 Mbit/s SF-FSK coherent system. B. Hoffmann, N.G. Jensen, E. Bødtker, S.K. Nielsen and B. Broberg p1903
Compatible enhancement of terrestrial PAL TV transmission. C.P. Sandbank, J.O. Drewery and M. Weston p195
Complementary correlation OTDR with three codewords. M. Nazarathy, S.A. Newton and W.R. Trutna p70
Complementary sets based on sequences with ideal periodic autocorrelation. B.M. Popović p1430
Computation of the right-inverse of $G(D)$ and the left-inverse of $H(D)$. L.H.C. Lee p904
Construction of block modulation codes over rings for fading channels. B. Vucetic, L. Zhang and G. Khachatrian p2020
Cryptanalysis of new modified Lu–Lee cryptosystems. L.D. Xing and L.G. Sheng p1601
Digital signature scheme based on error-correcting codes. W. Xinmei p898
Efficient probabilistic public-key cryptosystem based on the Diffie–Hellman problem. C.-S. Laih and J.-Y. Lee p326
Extension of the Smith construction for self orthogonal array codes. V.C. da Rocha and P.G. Farrell p1313
Factorisation attack on certain server-aided computation protocols for the RSA secret transformation. A. Shimbo and S. Kawamura p1387
Fast computational algorithm for transform coding. Y. Kato and T. Murakami p944
Fast encoding algorithm for VQ-based image coding. S.-H. Huang and S.-H. Chen p1618
General approach to designing the XX2B-AMI coding family. P. Radev p1043
Generalised type-II hybrid ARQ. Ma Jianhua and Wang Xinmei p88
ID based public key cryptosystems based on Okamoto and Tanaka's ID based one way communication scheme. Y.-W. Tsai and T. Hwang p666
Improved digital signature scheme based on discrete exponentiation. G.B. Agnew, R.C. Mullin and S.A. Vanstone p1024
Information rate of McEliece's public-key cryptosystem. M.-C. Lin, T.-C. Chang and H.-L. Fu p16
Line coding for very high speed LANs. D. Muñoz-Rodriguez and J.B. Arevalo-Galarza p205
Motion compensated sequence coding using image pyramids. Q. Wang and R.J. Clarke p575
Multiring differential chain codes for line drawings. A. Bertheau Johannessen, J.H. Bons, N.B.J. Weyland and R. Prasad p677
New M-PSK trellis codes for fading channels. J. Du and B. Vucetic p1267
New multilevel complementary pairs of sequences. S.Z. Budišin p1861
New optimisation technique of error propagation over M-PSK modem. B. Honary and G. Markarian p408
Noninteractive oblivious transfer. L. Harn and H.Y. Lin p635
Note on the generation of p_0 for RSA keysets. M.J. Ganley p369
Novel linecoding scheme for optical transmission. L. Pophillat p2129
Novel multifunctional decoder for MLD codes. X.H. Peng and P.G. Farrell p1706 e1986
On the relevance of the strict avalanche criterion. S. Babbage p461
Orthogonal codes for CDMA optical fibre LANs with variable bit interval. R. Petrovic and S. Holmes p662
Performance analysis of the error monitoring methodologies recommended for SDH systems. O. Brugia, M. Carbonelli and D. Perucchini p1394 e1832
Performance evaluation of high-speed concatenated codes of low complexity. S. Chakrabarti and S.L. Maskara p1799
RSA blocking and multisignature schemes with no bit expansion. T. Kiesler and L. Harn p1490
Rate 1/2 180° phase-invariant convolutional coding with differentially-encoded coherent QPSK for band-limited AWGN channels. L.H.C. Lee p1141
Size limits on phased burst error correcting array codes. R.M. Goodman and M. Sayano p55
Some classes of burst asymmetric or unidirectional error correcting codes. Y. Saitoh and H. Imai p286
Some comments on Damgard's hashing principle. J.K. Gibson p1178
Speech encryption in the transform domain. S. Sridharan, E. Dawson and B. Goldburg p655
Synthetis of single sets of 2^n mutually orthogonal phase codes. E.R. McKinnon p1240
Theorem with applications in coding and matching problems. A.K. Nandi and R.C. Vaughan p1928
Time-division 8 : 1 multiplexing and demultiplexing system adapting 7B1C code operating at 5 Gbit/s. N. Yokota, Y. Hakamata and K. Takemoto p923
Two new equalisation schemes for high-density digital magnetic recording systems with quad-phase modulation code. J.W.M. Bergmans and S. Mita p13
Two new ternary line codes. L. Botha, H.C. Ferreira and M. Whalley p1989
Vector quantisation of image sequences using variable size and variable shape blocks. L. Corte-Real and A.P. Alves p1483

COHERENCE

Bit error probability of phase-coherent communication systems in the presence of noise and interference. D. Drača and M. Stefanović p1234
High resolution laser LIDAR utilising two-section distributed feedback semiconductor laser as a coherent source. E.C. Burrows and K.-Y. Liou p577
Optimal noncoherent detection of PSK signals. D. Makrakis and K. Feher p398

COMMUNICATION NETWORKS

'Synchronous' CDMA demonstration for fibre-optic networks with optical processing. W.C. Kwong and P.R. Prucnal p1990
Bit error probability of phase-coherent communication systems in the presence of noise and interference. D. Drača and M. Stefanović p1234
Estimation of traffic intensity in global bus computer communications networks. H. Yang and M. Kim p1079
Simple implementation of load-sharing banyan network and its throughput performance. T.-H. Lee p79

COMPARATORS (CIRCUITS)

Automatic switching of substrate bias or well bias in CMOS-ICs. U. Gatti, V. Liberali, F. Maloberti and P. O'Leary p1381

High performance CMOS comparator for analogue-digital convertors. C.A. Leme and J.E. Franca p1725

COMPUTER APPLICATIONS

DC B–H curve tracer with error correction and constant measuring and drawing speed using microcomputer. S. Kusui, M. Kosukegawa and M. Inoue p902

COMPUTER SOFTWARE

Optimal encoding of microcommands in microprogrammed processors. I.-C. Park, S.-K. Hong and C.-M. Kyung p393

COMPUTER-AIDED DESIGN

Array synthesis using a simple computer-aided approach. B.P. Ng p337
Automatic production of the pseudo-circuit Boolean for the failure bounds analogue diagnosis scheme. C. Garrett p1377
Computer design of broadband lumped component microwave phase shifter amplifiers. A.J. Baden Fuller and M. Runham p1849
Computer-aided design of array pattern. M.H. Er p2113
Equations of nonlinear analogue circuit for fault dictionary generation. V.C. Prasad p24

COMPUTERS

Behaviour of circuit-switched multistage networks in presence of memory hot spot. T.-H. Lee d546
Determining the number of hidden nodes by progressive training. T. Lee and F.L. Chung p1318
Efficient systolic string matching. G.M. Megson p2040
ID-based authentication system for computer virus detection. E. Okamoto and H. Masumoto p1169
Modal noise power penalty in high speed short single-mode fibre interconnections. V.S. Shukla, M.P. Singh and R.F. Kearns p732
Optoelectronic synaptic connection circuit with variable analogue weights. H. Yonezu, T. Himeno, K. Kanamori, K. Pak and Y. Takano p910
Some results on Reed-Muller coefficients. P. Suman p1026

CONDUCTIVITY

Strip edge shape effects on conductor loss calculations using the Lewin/Vainshtein method. E.L. Barsotti, J.M. Dunn and E.F. Kuester p983
Temperature dependence of electron saturation velocity in GaAs. R. Allam and J. Pribetich p688
Thermal resistivity of quaternary solid solutions InGaSbAs and GaAlSbAs lattice-matched to GaSb. W. Both, A. Bochkarev, A. Drakin and B. Sverdlov p418

CONTROL SYSTEMS

GPS relative navigation in rendezvous operations. S. Cacopardi, L. Caporicci, S. Falzini and C. Soddu p1640
Model reduction for discrete time systems. R. Unnikrishnan and A. Gupta p282
Performance improvement of output feedback control systems using the theory of variable structure systems. D.S. Yoo and M.J. Chung p1210
Robust model reference adaptive control algorithm for a class of plants with bounded input disturbances. S.K. Tso and H.Y. Shum p1220

CONTROL THEORY

Algorithm for optimal layouts of CMOS complex logic modules. Y.-J. Kwon and C.-M. Kyung p1388
Automated adaptive hysteresis current control technique for a voltage-fed PWM inverter. D.S. Oh and M.J. Youn p2044
Crest factor minimisation in FDM PSK systems. B.T. Tan and Y.K. Some p859
Derivation of discrete and continuous time ramp invariant representations. S. Bingulac and D.L. Cooper p664
Effect of initial conditions on limit cycle performance of second order sampled data sigma delta modulator. N. Bridgett and C.P. Lewis p817
Effective mapping of continuous-time controllers to their discrete equivalents. M.C.F. de Oliveira and P.J. Fleming p562
Improved current mode control technique for quantum series resonant convertors. J.H. Ko, D.S. Oh and M.J. Youn p936
Iterative learning control of completely irregular plants with initial impulsive action. B. Porter and S.S. Mohamed p851
Iterative learning control of completely irregular plants with initial state shifting. B. Porter and S.S. Mohamed p106
Iterative learning controller for linear systems with a periodic disturbance. H.S. Ahn and C.H. Choi p1542
Model reduction by least-squares moment matching. T.N. Lucas and I.F. Beat p1213
Neural network approach for the two-dimensional assignment problem. K.B. Sriram and L.M. Patnaik p809
New optimisation technique of error propagation over M-PSK modem. B. Honary and G. Markarian p408
Optimal model matching: H^2 or H^∞?. C-D. Yang, H.-Y. Chung and J.-L. Chang p2089
Optimisation of UHF antennas. K.E. Stocker and F.M. Landstorfer p241
Optimisation of refractive index profile for high gain fibre amplifiers. M.J. Holmes, D.M. Spirit and F.P. Payne p1873
Optimum design of erbium fibre amplifiers pumped with sources emitting at 1480 nm. J.H. Povlsen, A. Bjarklev, B. Pedersen, H. Vendeltorp-Pommer and K. Rottwitt p1419
Optimum optical modulation index of laser transmitters in SCM systems. K. Alameh and R.A. Minasian p1273
Rotor flux controlled induction motor drive for high performance applications. S.S. Park and G.H. Cho p439
Speed control of permanent magnet synchronous motor using boundary layer state observer. K.-Y. Cho, S.-S. Hong, D.-S. Oh and M.-J. Youn p2081
Synthesis procedure for active integrated radiating elements. V.F. Fusco and H.O. Burns p263

CONTROLLERS

Iterative learning control of completely irregular plants with initial state shifting. B. Porter and S.S. Mohamed p106
New transmitter-receiver for power system protection based on microprocessor. S.F. Chu and Z.D. Gao p1006

CONVERTORS

Cyclic quasi-resonant convertor: a new quasi-resonant DC/DC convertor with improved characteristics. J.G. Cho and G.H. Cho p1821
Improved current mode control technique for quantum series resonant convertors. J.H. Ko, D.S. Oh and M.J. Youn p936
New analogue multiplier–divider circuit based on cyclic data convertors. M.S. Piedade p2
New zero-voltage-switching constant-frequency PWM DC/DC convertor with low switch stress and wide linearity. I.D. Kim, E.C. Nho and G.H. Cho p1320
Performance of an ECL-compatible 75 Ω line driver/receiver realised in a 1·2 μm CMOS technology. J. Sevenhans, W. Bijker, P. Vorenkamp and M. Steyaert p764
SPICE simulation of quasi-resonant zero-current-switching DC–DC convertors. S. Ben-Yaakov, D. Edry, Y. Amran and O. Shimony p847
Soft switch-avalanche IGBT convertor. K. Chen and T.A. Stuart p1623
Three phase high frequency DC–DC convertor. R. Rabinovici p829

CONVOLUTION

Extending sizes of effective convolution algorithms. R. Stasiński p1602

CORRELATION AND CORRELATORS

Autocorrelation at 1·3–1·5 μm using POM crystal. L. Chusseau, D. Bouchon, L. Duvillaret and J.M. Lourtioz p589
Correlation windowing and spectral biasing in the design of noise generators having specified probability densities and power spectra. R. Taori, G.D. Cain and K.V. Lever p1041
Effect of unequal rise and fall times on the autocorrelation function of a PN sequence. F.E. Churchill p1838
Shadowing variability in an urban land mobile environment at 900 MHz. M.J. Marsan, G.C. Hess and S.S. Gilbert p646
Short delay measurement by polarity cross correlation. R.M. Henry and L. Zhang p202
Simple parameter estimation technique in manoeuvring target tracking system. J.-A. Guu and C.-H. Wei p508

CROSSTALK

Crosstalk injection when testing transmission systems. J.W. Cook and K.T. Foster p1181
Crosstalk measurements for a dual emitter laser. N.K. Dutta, S.J. Wang, A.B. Piccirilli and W.V. Werner p1643
Measurements of crosstalk between closely-packed lossy microstrips on silicon substrates. M.S. Lin, A.H. Engvik and J.S. Loos p714
New model for time domain simulation of lossy coupled lines. K.-H. Wirth p1723

CRYSTAL GROWTH

Growth of single crystal β-SiC films on a Si substrate by a direct carbonisation method. Y. Hirano and T. Inada p1638

CRYSTAL RESONATORS

Frequency-stabilised LD module with a Z-cut quartz Fabry–Perot resonator for coherent communication. M.S. Nakamura and S. Ohshima p405

CRYSTALS

Autocorrelation at 1·3–1·5 μm using POM crystal. L. Chusseau, D. Bouchon, L. Duvillaret and J.M. Lourtioz p589
Doping level anomalies in p-InP resulting from exposure to dopant precursors during cool-down in MOVPE. S. Cole, W.J. Duncan, E.M. Marsh, P.J. Skevington and G.D.T. Spiller p391
Electroabsorption by semiconductor microcrystallites in glass: observation of Franz–Keldysh oscillations. D. Cotter and H.P. Girdlestone p183
Fabrication of domain reversed gratings for SHG in $LiNbO_3$ by electron beam bombardment. R.W. Keys, A. Loni, R.M. De La Rue, C.N. Ironside, J.H. Marsh, B.J. Luff and P.D. Townsend p188
Nonsteady-state photovoltage in crystals with long photoconductivity relaxation times. I.A. Sokolov and S.I. Stepanov p1275
Wide angular aperture acousto-optic configurations in biaxial crystals. J.E.B. Oliveira and E.L. Adler p931

CURRENT CONVEYORS

Applications of a first-generation current conveyor in current-mode circuits. P. Aronhime, D. Nelson and C. Adams p1456
Current mode allpass/notch and bandpass filters with reduced sensitivities. A. Fabre, F. Martin and M. Hanafi p1495
Current-mode active compensation techniques. C.A. Makris and C. Toumazou p1792
Differential current input cell with common mode feedback. A. Payne, C. Toumazou and P. Ryan p1718
High frequency gallium arsenide current mirror. C. Toumazou and D.G. Haigh p1802
MOSFET capacitor filters using unity gain CMOS current conveyors. S.-I. Liu, H.-W. Tsao, J. Wu and T.-K. Lin p1430
New multifunction active filter configuration employing current conveyors. V.K. Singh and R. Senani p1814
Series impedance simulators using one CCII. A. Himura, Y. Fukui, M. Ishida and M. Higashimura p269

DATA COMPRESSION

Video compression using 3D wavelet transforms. A.S. Lewis and G. Knowles p396

DATA PROCESSING

Minimum area analogue-digital calibration network for high-resolution data converters. C.A. Leme and J.E. Franca p1491

DATA TRANSMISSION

ATM access through a passive optical network. J.W. Ballance, P.H. Rogers and M.F. Halls p558
Backlog performance of some controlled slotted Aloha systems. T. Tsiligirides p1612

Correlation of interference and bit error activity in a digital transmission system. R.A. Butler and P. Cochrane p363
Design method for optimal data transmission filters. C. Gökçek and Z. Ünver p373
Field test measurement for 128 Kbit/s QPSK signal transmission and delay time spread in 1·5 GHz-band land mobile radio. T. Furuno and S. Ogose p789
Improved ICMA/CD protocol in packet mobile radio networks. J. Song and M. Kim p182
Low noise balanced receiver for coherent transmission systems. I. Hardcastle and A. Hadjifotiou p750
Measurements of pulse propagation on unterminated lossy microstrips with small dimensions. M.S. Lin, A.H. Engvik and K.L. Tai p747
Medium access control protocol for the integration of voice/data on a local area network. A.D. Malyan and R.L. Brewster p592
Modal noise power penalty in high speed short single-mode fibre interconnections. V.S. Shukla, M.P. Singh and R.F. Kearns p732
Multichannel reservation protocol for packet multiple-access communications. V.C.M. Leung p1637
Performance of M-ary PSK signals in slow Rayleigh fading channels. N. Ekanayake p618
Polarisation- and pattern-independent optical FSK heterodyne system using data-induced polarisation switching. R. Noé, H. Rodler, G. Gaukel, A. Ebberg and F. Auracher p176
Soft-decision syndrome based node synchronisation. J. Sodha and D.J. Tait p1108 e1738
Some continuous multidestination ARQ schemes for high error rate conditions. T.H. Lee p1686
Symbol synchronisation for binary baseband PAM operating at only one sample per symbol. M. Moeneclaey and T. Batsele p691
Synchronisation preamble design: new results. M. Grayson and M. Darnell p1775
Throughput performance of some continuous ARQ schemes with memory. T.-H. Lee and J.-K. Hu p1972

DECODING

Class of shortened cyclic codes over GF(2^8) for byte-oriented systems. V.K. Bhargava, G. Séguin and P.E. Allard p438
Novel multifunctional decoder for MLD codes. X.H. Peng and P.G. Farrell p1706 e1986

DELTA MODULATION

Bit stream adder for oversampling coded data. P. O'Leary and F. Maloberti p1708
Maximum SQNR formula for delta-sigma modulation. A.J.R.M. Coenen p1115

DEMODULATORS AND DEMODULATION

622 Mbit/s AMI FSK optical transmission experiment using a semiconductor optical preamplifier and a Fabry–Perot etalon demodulator. R.C. Steele and G.R. Walker p539
Digital demodulation by a non-coherent differential PSK modem. S. Maslamani and M. Ghanbari p2028
Digital demodulation for optical FSK signals. G. Ahlbom, L. Egnell and C. Wickman p290
Interpolative bandpass A/D conversion—Experimental results. H.-J. Dressler p1652
Simplified complex digital sampling demodulator. T.E. Thiel and G.J. Saulnier p419
Surface transverse wave based FM modulator/demodulator. I.D. Avramov, P.J. Edmonson and P.M. Smith p364

DETECTORS AND DETECTOR CIRCUITS

New adaptive Viterbi detector for fast-fading mobile-radio channels. E. Dahlman p1572
Optimal noncoherent detection of PSK signals. D. Makrakis and K. Feher p398

DIELECTRIC LOSSES

$Ba(Zn_{1/3}Ta_{2/3})O_3$–$Ba(Cd_{1/3}Nb_{2/3})O_3$ dielectric ceramics with low microwave loss. Z.-L. Zhao, S.-L. Lai and A.-S. Liu p1605

DIELECTRICS AND DIELECTRIC DEVICES

A step towards determining transient response of chiral materials: Kramers–Kronig relations for chiral parameters. N. Engheta and P.G. Zablocky p2132
Chiral Maxwell–Garnett mixing formula. A.H. Sihvola and I.V. Lindell p118
Dielectric resonator antenna using aperture coupling. J.T.H. St. Martin, Y.M.M. Antar, A.A. Kishk, A. Ittipiboon and M. Cuhaci p2015
Dimensional correction of high dielectric and magnetic constants determined by S parameters measurements. J.C. Henaux and P. Crozat p1151
Generalised boundary conditions for a material sheet with both sides coated by a dielectric layer. A. Büyükaksoy and M. İdemen p1967
High performance p^+-gate pMOSFETs with N_2O-nitrided SiO_2 gate films. A. Uchiyama, H. Fukuda, T. Hayashi, T. Iwabuchi and S. Ohno p1932
Mismatch in dielectric-loaded rectangular waveguide antenna. T.S. Bird and S.G. Hay p59
Optical activity induced in $Bi_4Ge_3O_{12}$ waveguides by ion implantation. S.M. Mahdavi and P.D. Townsend p371

DIFFRACTION

Parabolic equation modelling of propagation over irregular terrain. M.F. Levy p1153

DIFFUSION

Diffusion and oxide viscous flow mechanism in SDB process and silicon wafer rapid thermal bonding. Q.-Y. Tong, X.-L. Xu and H. Shen p697
Electrical characterisation of the p-type dopant diffusion of highly doped AlGaAs/GaAs heterojunction bipolar transistors grown by MOCVD. J. Dangla, C. Dubon-Chevallier, M. Filoche and R. Azoulay p1061

DIGITAL CIRCUITS

Carry–save adders for computing the product AB modulo N. C.K. Koç and C.Y. Hung p899
Design of IIR group delay equalisers. L. Lo Presti and M. Visintin p200
Digital demodulation for optical FSK signals. G. Ahlbom, L. Egnell and C. Wickman p290
Distortion minimisation in pulse width modulated systems using a digital sampling process. S.P. Leigh, P.H. Mellor and B.M.G. Cheetham p1310
Generalised systolic ring serial floating point multiplier. W. Marwood p753
Novel pipelined serial/parallel multiplier. D. Ait-Boudaoud, M.K. Ibrahim and B.R. Hayes-Gill p582
Performance of an ECL-compatible 75 Ω line driver/receiver realised in a 1·2 μm CMOS technology. J. Sevenhans, W. Bijker, P. Vorenkamp and M. Steyaert p764
Self-timed system design technique. Y.K. Tan and Y.C. Lim p284

DIGITAL COMMUNICATION SYSTEMS

Computation of the right-inverse of $G(D)$ and the left-inverse of $H(D)$. L.H.C. Lee p904
Digital DPSK demodulator employing bandpass subsampling. B. Haller and H. Kaufmann p1536
Digital demodulation by a non-coherent differential PSK modem. S. Maslamani and M. Ghanbari p2028
Factorisation attack on certain server-aided computation protocols for the RSA secret transformation. A. Shimbo and S. Kawamura p1387
General approach to designing the XX2B-AMI coding family. P. Radev p1043
Performance of packet reservation multiple access for digital mobile radio using variable rate speech coder. J. Dunlop and J.Y. Knan p2074

DIGITAL FILTERS

Design of IIR group delay equalisers. L. Lo Presti and M. Visintin p200
Digital passband filtering of megabaud transmitted data stream. C.A. Siller, Jun, H.C. Reeve and W. Debus p2024
Frequency-hopping radio filter design using the DSP16 processor. T.G. Clarkson p586
Low-sensitivity universal first-order digital filter sections without limit cycles. I.P. Topalov and G.K. Stoyanov p25
Novel systolic array for realising a second-order digital filter. D. Ait-Boudaoud and M.K. Ibrahim p388
Range determination in a multipath prone environment. G. Bortz, J.J. van Schalkwyk and W. Louw p1253

DIGITAL SYSTEMS

BITL format: A way of representing boundary scan test vectors. F. De Jong p1072
Quiescent current sensor circuits in digital VLSI CMOS testing. A. Rubio, J. Figueras and J. Segura p1204

DIGITAL TRANSMISSION

Correlation of interference and bit error activity in a digital transmission system. R.A. Butler and P. Cochrane p363
Simplified data transition tracking loop—a new NRZ maximum likelihood symbol synchroniser. J.-H. Chiu and L.-S. Lee p1417

DIODES

High power (>100 mW), low crosstalk (<0·4%), individually addressed laser diodes. D. Mehuys, D.F. Welch, D.W. Nam and D.R. Scifres p1955
High reliability, high power, single mode laser diodes. D. Welch, R. Craig, W. Streifer and D. Scifres p1481
High-power single mode InGaAs/AlGaAs laser diodes at 910 nm. D.F. Welch, M. Cardinal, B. Streifer and D. Scifres p233
IMPATT operation below the avalanche frequency. J.-F. Luy p1960
Strong dependence of time resolution on detector diameter in single photon avalanche diodes. A. Lacaita and M. Mastrapasqua p2053
Temperature dependent barrier heights in bulk unipolar diodes leading to improved temperature stable performance. M.J. Kearney, M.J. Kelly, A. Condie and I. Dale p671

DIPOLE ANTENNAS

Improved convergence of iterative scheme for analysing arrays of finite size. A. Stylianou and J.C. Vardaxoglou p641 e1324
Optimisation of UHF antennas. K.E. Stocker and F.M. Landstorfer p241
Thin wire dipoles—a finite-difference time-domain approach. J.J. Boonzaaier and C.W.I. Pistorius p1891

DIRECTIONAL COUPLERS

Digital optical logic using optically switched directional couplers. A.F. Benner p1037
Multiple quantum well directional coupler as a self-electro-optic effect device. B.P. Keyworth, M. Cada, J.M. Glinski, A.J. SpringThorpe, C. Rolland and K.O. Hill p2011
Rigorous calculation of losses of single and coupled groove-guides. J. Meissner p41

DISCRETE SYSTEMS

Derivation of discrete and continuous time ramp invariant representations. S. Bingulac and D.L. Cooper p664
Effective mapping of continuous-time controllers to their discrete equivalents. M.C.F. de Oliveira and P.J. Fleming p562
Method for computing the stability margin of 2-D discrete systems. S. Tzafestas, A. Kanellakis and N. Theodorou p1139
Note on the generation of p_0 for RSA keysets. M.J. Ganley p369

DISCRETE-TIME SYSTEMS

Model reduction for discrete time systems. R. Unnikrishnan and A. Gupta p282

DISPERSION (WAVE)

Dispersion characteristic of the double-sided slotline. S.G. Pintzos p813 e1738
High-resolution OCDR in dispersive waveguides. E. Brinkmeyer and R. Ulrich p413
Multichannel video transmission over 100 km of step index singlemode fibre using a directly modulated 1537 nm distributed feedback laser. P.A. Rosher and S.C. Fenning p534

Numerical dispersion characteristics and stability factor for the TD–FD method. I.S. Kim and W.J.R. Hoefer p485
Performance of the DECT system in fading dispersive channels. L.B. Lopes p1416

DISTORTION

Distortion minimisation in pulse width modulated systems using a digital sampling process. S.P. Leigh, P.H. Mellor and B.M.G. Cheetham p1310
Low-distortion CMOS transconductor. G. Wilson and P.K. Chan p720
Simple model for calculation of distortion in an optical analogue subcarrier multiplexed CATV system. J.H. Angenent p2049

DOPING

Efficient, high power, high gain, Er^{3+} doped silica fibre amplifier. J.F. Massicott, R. Wyatt, B.J. Ainslie and S.P. Craig-Ryan p1038
Electrical characterisation of the p-type dopant diffusion of highly doped AlGaAs/GaAs heterojunction bipolar transistors grown by MOCVD. J. Dangla, C. Dubon-Chevallier, M. Filoche and R. Azoulay p1061
Erbium doped fluorozirconate fibre laser operating at 1·66 and 1·72 μm. R.G. Smart, J.N. Carter, D.C. Hanna and A.C. Tropper p649
Femtosecond soliton amplification in erbium doped silica fibre. B.J. Ainslie, K.J. Blow, A.S. Gouveia-Neto, P.G.J. Wigley, A.S.B. Sombra and J.R. Taylor p186
Ground-state and excited-state absorption in rare-earth doped optical fibres. M. Monerie, T. Georges, P.L. Francois, J.Y. Allain and D. Neveux p320
Heterostructure bipolar transistor employing carbon-doped base grown with trimethyl-Ga and arsine. T.Y. Kuo, T.H. Chiu, J.E. Cunningham, K.W. Goossen, C.G. Fonstad and F. Ren p1260
High gain two-stage amplification with erbium-doped fibre amplifier. H. Masuda and A. Takada p661
Highly efficient integrated optical fibre amplifier module pumped by a 0·98 μm laser diode. M. Shimizu, M. Horiguchi, M. Yamada, M. Okayasu, T. Takeshita, I. Nishi, S. Uehara, J. Noda and E. Sugita p498
Highly tunable and efficient diode pumped operation of m^{3+} doped fibre lasers. W.L. Barnes and J.E. Townsend p746
Lateral nonuniform doping technique and its application to the fabrication of GaAs MESFETs with a lateral linear doping channel. H. Dejun p432
Monolayer Be δ-doped heterostructure bipolar transistor fabricated using doping selective base contact. T.Y. Kuo, J.E. Cunningham, K.W. Goossen, W.Y. Jan, C.G. Fonstad and F. Ren p1187
The effect of *n*-type dopant species on the compensating effects of oxygen implantation in GaAs. N.J. Whitehead and B.J. Sealy p866

ELECTRO-OPTICS

Electro-optic sampling using an external GaAs probe tip. M. Shinagawa and T. Nagatsuma p1341
Low voltage strained layer asymmetric Fabry–Perot reflection modulator. J. Woodhead, P.A. Claxton, R. Grey, T.E. Sale, J.P.R. David, L. Liu, M.A. Pate, G. Hill and P.N. Robson p2117
Polarisation dependence of field-induced refractive index variation in strained and unstrained quantum well structures. T.C. Chong, H.W. Wan and S.J. Chua p1060
Velocity matching of III-V travelling-wave electro-optic modulator structures. M.R.T. Tan, I. Kim, J. Chang and S.Y. Wang p32

ELECTROLUMINESCENCE

1·54 μm electroluminescence in MeV ion implanted Er-doped GaAs. P.B. Klein, F.G. Moore and H.B. Dietrich p1299

ELECTROMAGNETIC INTERFERENCE

Characterisation of electromagnetic fields in buildings. P.-K. Lau and M.M. Cohen p1778

ELECTROMAGNETIC WAVES

Acceleration of series form of the Green's function for a magnetic line current in the presence of a conducting wedge. J. Silvestro and C.M. Butler p975
Application of MFIE to three-dimensional conducting waveguide transitions of arbitrary shape. N.Y. Zhu and F.M. Landstorfer p143
Application of the FD-TD method to the analysis of H-plane waveguide discontinuities. Z.-Q. Bi, K.-L. Wu and J. Litva p1897
Boundary diffraction coefficients for calculating spurious beams produced by volume gratings. J.T. Sheridan and L. Solymar p1840
Chiral Maxwell–Garnett mixing formula. A.H. Sihvola and I.V. Lindell p118
Conjugate gradient computation of the current distribution on a tripole FSS array element. M.M. Mokhtar and E.A. Parker p227
Dependence of propagation loss of magnetostatic forward volume waves on device parameters. M. Yamaguchi, K.-Y. Hashimoto and H. Kaneda p581
Dispersion characteristics of ring line through the conformal mapping approach. J.P. Fenelon and A. Papiernik p621
Electromagnetic scattering from nonspherical particles: A new polarisability model with application to agglomerating spheres. L.E. Pierce and H. Weil p180
Exterior moment method analysis of conducting scatterers by using the interior Green's function. K. Sawaya, S. Yatabe and S. Adachi p631
Impedance of TEM cells with equipment under test. K.M. Huang and W. Lin p560
Launching vertically polarised ground waves from a vertical magnetic dipole over an anisotropic surface. J.R. Wait p1080
New three dimensional symmetrical condensed lossy node for solution of electromagnetic wave problems by TLM. P. Naylor and R.A. Desai p492
Numerical dispersion characteristics and stability factor for the TD–FD method. I.S. Kim and W.J.R. Hoefer p485
Overconstrained version of moment method for prediction of electromagnetic energy deposition inside dielectric objects. S. Caorsi, G.L. Gragnani and M. Pastorino p1997
Perturbation analysis of finlines containing anisotropic media. P.V. Ramakrishna and D. Chadha p571
Position of the travelling wave lobes in the backscatter pattern of cylinders. M.C. de Villiers and J.A.G. Malherbe p147
RCS of three-dimensional scatterers using the symmetrical condensed TLM method. F.J. German, G.K. Gothard and L.S. Riggs p673
Radiation from vertical electric dipole located over laterally anisotropic groundplane. J.R. Wait p74
Scattering from a circular dielectric cylindrical shell: A fast algorithm. S. Jegannathan and B. Ramamurthi p484

ELECTROMAGNETISM

Application of MFIE to three-dimensional conducting waveguide transitions of arbitrary shape. N.Y. Zhu and F.M. Landstorfer p143
Asymptotic solution for line source radiation from a curved perfectly conducting wedge. A. Michaeli p1249 e1832
Electromagnetic field inside a surface current distribution. L.P. Ivrissimtzis p1933
Generalised boundary conditions for a material sheet with both sides coated by a dielectric layer. A. Büyükaksoy and M. İdemen p1967
Hybrid symmetrical condensed node for the TLM method. R. Scaramuzza and A.J. Lowery p1947
Method for modelling free space boundaries in TLM simulations. N.R.S. Simons and E. Bridges p453
Variational finite element analysis of dielectric waveguides with no spurious solutions. F.A. Fernandez and Y. Lu p2125

ELECTRON DEVICES

High speed electron-beam testing of VLSI circuits by backscattered electron detection. A. Khursheed p1657
Model minimisation for electron devices using simulated annealing in conjunction with parameter extraction. M.-K. Vai, D. Ng and S. Prasad p892
Room temperature negative differential resistance in the quasi-one-dimensional ballistic resistor. M.J. Kelly, R.J. Brown, M. Pepper, D.G. Hasko, H. Ahmed, D.C. Peacock, J.E.F. Frost, D.A. Ritchie and G.A.C. Jones p171
Strained layer AlGaAs–GaAs–InGaAs real-space transferred electron devices. M.E. Favaro, J.J. Alwan, R.P. Bryan, L.M. Miller, J.J. Coleman, J. Kim and C.M. Wayman p1264
Two-dimensional electron gas base hot electron transistor. P. Matthews, M.J. Kelly, V.J. Law, D.G. Hasko, M. Pepper, H. Ahmed, D.C. Peacock, J.E.F. Frost, D.A. Ritchie and G.A.C. Jones p862

EPITAXY AND EPITAXIAL GROWTH

1·55 μm high-gain polarisation-insensitive semiconductor travelling wave amplifier with low driving current. B. Mersali, G. Gelly, A. Accard, J.-L. Lafragette, P. Doussiere, M. Lambert and B. Fernier p124
Doping level anomalies in *p*-InP resulting from exposure to dopant precursors during cool-down in MOVPE. S. Cole, W.J. Duncan, E.M. Marsh, P.J. Skevington and G.D.T. Spiller p391
Kink-free AlInAs/GaInAs/InP HEMTs grown by molecular beam epitaxy. L.F. Luo, K.F. Longenbach and W.I. Wang p779
Mg-doped graded base GaAs/AlGaAs heterojunction bipolar transistors grown by metalorganic vapour phase epitaxy. H. Tews, P. Zwicknagl, R. Neumann, G. Jaeger, A. Hoepfner, L. Schleicher and G. Packeiser p58
Reliable 1·3 μm gain guided stripe lasers grown by MOCVD using ethyldimethylindium as the In source. C. Blaauw, T.F. Devenyi, B. Capron, F.R. Shepherd and A.J. Springthorpe p1291
Selective silicon epitaxial growth by LPCVD using silane. G.J. Parker and C.M.K. Starbuck p831
Superior microwave performance of InGaAs JFETs grown by MBE. D. Trommer, A. Umbach, W. Passenberg, G. Mekonnen and G. Unterbörsch p734
Vertical integration of an $In_{0.15}Ga_{0.85}As$ modulation-doped field effect transistor and GaAs laser grown by molecular beam epitaxy. S.D. Offsey, P.J. Tasker, W.J. Schaff, L. Kapitan, J.R. Shealy and L.F. Eastman p350
Yellow light (576 nm) lasing emission of GaInP/AlInP multiple quantum well lasers prepared by gas-source-molecular-beam-epitaxy. Y. Kaneko, A. Kikuchi, I. Nomura and K. Kishino p657

EQUALISERS

8 Gbit/s 202 km optical CPFSK transmission experiment using 1·3 μm zero dispersion fibre. N. Takachio, K. Iwashita, K. Nakanishi and S. Koike p506
Non-equally fractionally-spaced equalisers. M.S. El-Hennawey, A. Zerguine and E.E. Hassan p1254
Performance of a new adaptive diversity-equalisation for digitial mobile radio. H. Suzuki p626
Two new equalisation schemes for high-density digital magnetic recording systems with quad-phase modulation code. J.W.M. Bergmans and S. Mita p13

EQUIVALENT CIRCUITS

Effects of finite metallisation thickness and substrate supporting grooves on the characteristics of E plane strip in a finline. A. Rong and S. Li p760
Negative R_g and R_d in GaAs FET and HEMT equivalent circuits. P.H. Ladbrooke, A.J. Hill and J.P. Bridge p680
New skin-effect equivalent circuit. T. Vu Dinh, B. Cabon and J. Chilo p1582

ERRORS

Automatic production of the pseudo-circuit Boolean for the failure bounds analogue diagnosis scheme. C. Garrett p1377
BER improvement due to transversal equaliser in trellis-coded multi-level QAM digital microwave radio. H. Takanashi, S. Aikawa and Y. Nakamura p406
Bandwidth efficient block codes for Rayleigh fading channels. L. Zhang and B. Vucetic p301
Bit error probability of phase-coherent communication systems in the presence of noise and interference. D. Drača and M. Stefanović p1234
Class of shortened cyclic codes over $GF(2^8)$ for byte-oriented systems. V.K. Bhargava, G. Séguin and P.E. Allard p438
Correlation of interference and bit error activity in a digital transmission system. R.A. Butler and P. Cochrane p363
Error control strategies for cut-through switching network. C.-J. Chang and J.-I. Wang p1894
Error surface analysis of adaptive comb filter. J.F. Chicharo p587
Multitone jamming of hybrid SFH/DS-MFSK communication systems. M.A. Laxpati p323
Performance analysis of the error monitoring methodologies recommended for SDH systems. O. Brugia, M. Carbonelli and D. Perucchini p1394 e1832
Some classes of burst asymmetric or unidirectional error correcting codes. Y. Saitoh and H. Imai p286
Some continuous multidestination ARQ schemes for high error rate conditions. T.H. Lee p1686

FAST FOURIER TRANSFORMS

Fast discrete radon transform and 2-D discrete Fourier transform. D. Yang p550
Scattering from a circular dielectric cylindrical shell: A fast algorithm. S. Jegan-

nathan and B. Ramamurthi p484

FEEDBACK

Derivation of the feedback taps of an LFSR from a sequence fragment. D.H. Green p1352
FiEnd filters: Passive multilayer thin-film optical filters deposited on fibre ends. J. Stone and L.W. Stulz p1290
Performance improvement of output feedback control systems using the theory of variable structure systems. D.S. Yoo and M.J. Chung p1210
Pulsed operation of an optical feedback frequency synthetiser. T.G. Hodgkinson and P. Coppin p1155
Rotor flux controlled induction motor drive for high performance applications. S.S. Park and G.H. Cho p439

FERROMAGNETIC RELAXATION

Programmable multiplexed switched-capacitor filters. X.F. Wania, D.A. Johns and A.S. Sedra p1051

FIBRE OPTICS

'Synchronous' CDMA demonstration for fibre-optic networks with optical processing. W.C. Kwong and P.R. Prucnal p1990
10 dB gain and high saturation power in a Nd^{3+}-doped fluorozirconate fibre amplifier. T. Sugawa, Y. Miyajima and T. Komukai p2042
High gain, wide dynamic range L-band externally modulated fibre optic. E. Ackerman, D. Kasemsei, S. Wanuga and S. Chinn p1339
Low-cost fibre-optic gyroscope. H. Poisel, G.F. Trommer, W. Bühler, E. Hartl and R. Müller p69
Microstrip antennas with integrated fibre optic feeds. D.M. Pozar, R.W. Jackson and A. Svitak p1889
Noise characteristics of high-power doped-fibre superluminescent sources. P.R. Morkel, R.I. Laming and D.N. Payne p96
Over 300 km CPFSK transmission experiment using 67 photon/bit sensitivity receiver at 2·5 Gbit/s. T. Imai, N. Ohkawa, Y. Ichihashi, T. Sugie and T. Ito p357
Unslotted CSMA-CD protocol with combined retransmission strategy for fibre optic bus and ring networks. C.H. Yoon and C.K. Un p998

FIELD-EFFECT DEVICES

Electron detrapping enhanced by electric field in AlGaAs/GaAs HEMTs. C. Canali, F. Magistrali, M. Sangalli, C. Tedesco and E. Zanoni p313
GaAs MESFET amplifiers fabricated on InP substrates. J. Jeong, G.P. Vella-Coleiro and C.M.L. Yee p135
Microchannel plate intensifier response in transverse magnetic field. S.W. Allison, P.A. Ramos and G.T. Gillies p770
Submicron-gate ion-implanted $In_{0.15}Ga_{0.85}As$/GaAs MESFETs with graded indium composition. G.W. Wang, M. Feng, R. Kaliski and J.B. Kuang p190
Use of a methane/hydrogen plasma for gate recessing of E/D MESFETs. R. Pereira, M. Van Hove, M. de Potter and M. Van Rossum p462

FIELD-EFFECT TRANSISTORS

Active patch antenna element for array applications. R.A. York, R.D. Martinez and R.C. Compton p494
Anisotype, enhancement-mode, heterojunction gate field-effect transistors. C.L. Lin, H.H. Wieder and R. Zuleeg p846
Charge storage in InAlAs/InGaAs/InP floating gate heterostructures. J.A. Lott, J.F. Klem, H.T. Weaver, C.P. Tigges and V. Radoslovich-Cibicki p972
Design and realisation of very high performance 0·2 μm gate GaAs MESFETs. J. Vanbremeersch, E. Constant, J. Zimmermann, I. Valin, P. Godts and A. Leroy p152
Effect of statistical variation on threshold voltage in narrow-channel MOSFETs. E.H. Li, C.K. Liu and H.C. Ng p1390
Heterojunction field effect transistor laser. Y. Suzuki, H. Yajima, K. Shimoyama, Y. Inoue, M. Katoh and H. Gotoh p1632
Heterostructure field effect transistor with doping dipole in charge control layer. J. Zou, A. Gopinath, T. Akinwande and M.S. Shur p964 e1832
High performance $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As$ HFETs. H. Dämbkes, P. Marschall, Y.H. Zhang and K. Ploog p488
High voltage floating gate array transistors. M. Levinson, P. Rossoni, F. Rock and B.M. Ditchek p777
High-efficiency AlGaAs/InGaAs heterostructure FET oscillators at V-band. H.Q. Tserng and P. Saunier p2048
Large amplitude picosecond step generation with FETs. A. Ouslimani, G. Vernet, H. Hafdallah and R. Adde p1563
Laser-annealed refractory metal silicide films on GaAs. W.T. Anderson, A. Christou, P.E. Thompson, C.R. Gossett, J.M. Eridon, Z. Hatzopoulos, T. Efthimiopoulos, M. Kudumas, C. Michelakis and D.V. Morgan p62
New submicron MOSFET structural concept for suppression of hot carriers. A.F. Tasch, H. Shin and C.M. Maziar p39
Simple extraction method for mobility parameters in Si-MOSFETs at 77 K. J.I. Lee, M.B. Lee, K.N. Kang and K.O. Park p852
Superior microwave performance of InGaAs JFETs grown by MBE. D. Trommer, A. Umbach, W. Passenberg, G. Mekonnen and G. Unterbörsch p734
Vertical integration of an $In_{0.15}Ga_{0.85}As$ modulation-doped field effect transistor and GaAs laser grown by molecular beam epitaxy. S.D. Offsey, P.J. Tasker, W.J. Schaff, L. Kapitan, J.R. Shealy and L.F. Eastman p350
n-AlInAs/$(InAs)_5(GaAs)_1$ superlattice modulation-doped field effect transistor grown by molecular beam epitaxy. N. Nishiyama, H. Yano, S. Nakajima and H. Hayashi p885

FILTERING AND PREDICTION THEORY

Noise reduction based on microphone array with LMS adaptive post-filtering. R. Zelinski p2036

FILTERS

400 MHz switching rate GaAs switched capacitor filter. C. Toumazou, D.G. Haigh, S.J. Harrold, K. Steptoe, J.I. Sewell and R. Bayruns p460
Bandpass characteristics of split-modes in asymmetric ring resonators. G.K. Gopalakrishnan and K. Chang p774
CMOS VHF transconductance-C lowpass filter. B. Nauta p421
CMOS triode transconductor with high dynamic range. B. Stefanelli and A. Kaiser p880
Companding current-mode integrator: a new circuit principle for continuous-time monolithic filters. E. Seevinck p2046
Companding in signal processing. Y.P. Tsividis, V. Gopinathan and L. Tóth p1331
Current mode allpass/notch and bandpass filters with reduced sensitivities. A. Fabre, F. Martin and M. Hanafi p1495
Design criteria for video sampling rate conversion filters. A.M. Böck p1259
Design method for optimal data transmission filters. C. Gökçek and Z. Ünver p373
Design of linear tunable CMOS differential transconductor cells. Z. Czarnul and S. Takagi p1809
Digital passband filtering of megabaud transmitted data stream. C.A. Siller, Jun, H.C. Reeve and W. Debus p2024
Error surface analysis of adaptive comb filter. J.F. Chicharo p587
Fast, efficient median filters with even length windows. J.P. Havlicek, K.A. Sarkady, G.R. Katz and J.C. McKeeman p1736
Finite-gain-insensitive circulating-delay type pseudo-N-path filter. A.K. Betts and J.T. Taylor p1941
Frequency-hopping radio filter design using the DSP16 processor. T.G. Clarkson p586
Highly-linear transconductor cell realised by double MOS transistor differential pairs. Z. Czarnul and N. Fujii p1819
Improved design of minimum-phase FIR digital filters by cepstrum and fast Hardtley transform. S.-C. Pei and S.-B. Jaw p1063
Improved version of the inverse Chebyshev filter. M. Lutovac and D. Rabrenović p1256
Low Q equiripple functions of nonminimum order. D. Rabrenović and M. Lutovac p447
Low-sensitivity universal first-order digital filter sections without limit cycles. I.P. Topalov and G.K. Stoyanov p25
MOSFET capacitor filters using unity gain CMOS current conveyors. S.-I. Liu, H.-W. Tsao, J. Wu and T.-K. Lin p1430
Mean square convergence analysis of LMS algorithm. V.A. Gholkar p1705
Minimisation of MOSFET-C filters sensitivity by changing connections of capacitors. B. Galiński p784
Modified configuration for a high-finesse compact loop resonator for semiconductor integrated optics. A. Shahar, W.J. Tomlinson and M. Seto p1528 e1922
Neural network for adaptive FIR filtering. M. Forti, S. Manetti and M. Marini p1018
Nondestructive measurement of phase velocity of surface acoustic waves using matched filters. M. Hirabayashi p411
Novel systolic array for realising a second-order digital filter. D. Ait-Boudaoud and M.K. Ibrahim p388
Parasitic insensitive single amplifier switched capacitor bandpass biquad. C. Psychalinos and I. Haritantis p253
Passively temperature-compensated fibre Fabry–Perot filter and its application in wavelength division multiple access computer network. C.M. Miller and F.J. Janniello p2122
Planar InP/InGaAs avalanche photodetector with integrated dielectric wavelength filter. M.D.A. MacBean, N.P. Hewett, M.D. Learmouth and I. Reid p804
Programmable fractional sample delay filter with Lagrange interpolation. G.-S. Liu and C.-H. Wei p1608
Proposed semiconductor narrow-band wavelength filter using directional coupler. A. Wakatsuki, K. Okamoto and O. Mikami p1573
Rocking filter formation in photosensitive high birefringence optical fibres. P.St. J. Russell and D.P. Hand p1846
Simple derivation of adaptive algorithms for arbitrary filter structures. U. Forssén p1764
Stability of second order time-varying constrained notch filters. D. Wulich, E.I. Plotkin and M.N.S. Swamy p1508
Stable quarter-plane 2-D lattice filters. A. Ertüzün, A.H. Kayran and E. Panayirci p806
Three-mirror fibre Fabry–Perot filters of optimal design. J. Stone, L.W. Stulz and A.A.M. Saleh p1073
Two-band IIR quadrature mirror filter design. S.-B. Jaw and S.-C. Pei p1687

FLIP-FLOPS

Analysis of 'D type' flip-flop frequency changers. D.I. Shaw, J.C. Bennett and A.M. Clements p1995
Novel ternary JKL flip-flop. N. Zhuang and H. Wu p1145

FOURIER TRANSFORMS

Conjugate pair fast Fourier transform. I. Kamar and Y. Elcherif d541
Derivation of Fourier transform of discrete series from z-transform. R. Ishii p1938
Fast algorithm for real joint time–frequency transformations of time-varying signals. S.-E. Qian and J.M. Morris p537
Minimum relative entropy enhancement of FFT spectra. J.P. Noonan, M.A. Tzannes and B. Achour p979
Novel mapping scheme for transforms with lengths equal to products of prime squares. D.P.-K. Lun and W.-C. Siu p21
On computing the discrete Wigner–Ville distribution. S.C. Chan and K.L. Ho p636
Optical-fibre spectrum analyser. M.A. Page-Jones and J.K.A. Everard p117
Spectral analysis of waiting time jitter in the presence of stuff threshold modulation. R.G. Kusyk, T.E. Moore and W.A. Krzymien p526

FREQUENCY DIVIDERS

3·2 GHz 0·2 μm gate CMOS 1/8 dynamic frequency divider. Y. Kado, Y. Okazaki, M. Suzuki and T. Kobayashi p1684
Versatile divider circuits up to 9 GHz input-frequency realised in high-speed BICMOS. P. Weger, A. Felder, M. Kerber and H. Klose p1942

FREQUENCY MODULATION

Demodulation of multi-gigahertz frequency-modulated optical signals in an injection-locked distributed feedback laser oscillator. H. Nakajima p1129
Estimation of instantaneous frequency using the discrete Wigner distribution. P. Rao and F.J. Taylor p246
Interferometric fibre displacement/strain sensor based on source coherence synthesis. T.A. Berkoff and A.D. Kersey p452
Maximum SQNR formula for delta-sigma modulation. A.J.R.M. Coenen p1115
Two-channel coherent optical FDM transmission system with a new frequency stabilisation scheme. Q. Jiang, D.M. Wu and L.Z. Xie p310
Uniform frequency modulation responses in narrow linewidth ($\leq$200 kHz) compact hybrid lasers. C.Y. Kuo, D.A. Ackerman, C.H. Henry, Y. Shani, M.I. Dahbura, R. Kistler and E.J. Wagner p270

FREQUENCY MULTIPLIERS

Quasi-phase-matched frequency doubling over 5 mm in periodically poled polymer waveguide. R.A. Norwood and G. Khanarian p2105

FREQUENCY SHIFT KEYING

1·5 Gbit/s FSK transmission system using two electrode DFB laser as a tunable FSK discriminator/photodetector. M.J. Chawki, R. Auffret and L. Berthou p1146

44-ary FSK coherent optical communication system. S.B. Alexander, R. Barry, D.M. Castagnozzi, V.W.S. Chan, D.M. Hodsdon, L.L. Jeromin, J.E. Kaufmann, D.M. Materna, R.J. Parr, M.L. Stevens and D.W. White p1346

622 Mbit/s AMI FSK optical transmission experiment using a semiconductor optical preamplifier and a Fabry–Perot etalon demodulator. R.C. Steele and G.R. Walker p539

Comparison of NRZ and AMI coding schemes using three-electrode and conventional DFB laser transmitters in a 636 Mbit/s SF-FSK coherent system. B. Hoffmann, N.G. Jensen, E. Bødtker, S.K. Nielsen and B. Broberg p1903

Digital demodulation for optical FSK signals. G. Ahlbom, L. Egnell and C. Wickman p290

Error correcting coding of a 220 Mbit/s coherent optical communication channel. D.M. Castagnozzi, S.B. Alexander, E.P. Colagiuri, E.A. Bucher and L.L. Jeromin p1288

Error probability of optical heterodyne MSK communication system with limiter–discriminator–integrator detector. X. Zhang and P. Jiang p136 e1832

Fast wavelength switching and simultaneous FSK modulation using tunable DBR laser. H. Kobrinski, M.P. Vecchi, T.E. Chapuran, J.B. Georges, C.E. Zah, C. Caneau, S.G. Menocal, P.S.D. Lin, A.S. Gozdz and F.J. Favire p308

High performance 140 Mbit/s FSK coherent system. I. Hardcastle, Y. Large, F. Davis and A. Hadjifotiou p1523

Kink effect, transconductance increase and field enhanced electron emission in AlGaAs/GaAs HEMTs. C. Canali, C. Tedesco, E. Zanoni, G. Castellaneta, F. Magistrali and M. Sangalli p1520

Multichannel FSK experiment using an optical amplifier repeater and wavelength tunable direct detection receiver. D.J. Malyon and W.A. Stallard p1863

Multichannel FSK transmission experiment at 565 Mbit/s using tunable three-electrode DFB lasers. N. Flaarønning, J.O. Frorud, M. Sotom, G. Vendrôme, G. Da Loura, J.M. Gabriagues, J. Jacquet, D. Leclerc and J. Benoit p869

Polarisation- and pattern-independent optical FSK heterodyne system using data-induced polarisation switching. R. Noé, H. Rodler, G. Gaukel, A. Ebberg and F. Auracher p176

Two-section distributed feedback lasers for incoherent frequency-shift-keying transmission systems. S.J. Wang, Y. Twu, N.K. Dutta and R.L. Hartman p1243

GALLIUM ARSENIDE

13 Gb/s D-Type flip-flop IC using GaAs MESFETs. M. Ohhata, Y. Yamane, T. Enoki, S. Sugitani, N. Kato, K. Hagimoto and M. Hirayama p1039

275 GHz 3-mask integrated GaAs sampling circuit. R.Y. Yu, M. Case, M. Kamegawa, M. Sundaram, M.J.W. Rodwell and A.W. Gossard p949

400 MHz switching rate GaAs switched capacitor filter. C. Toumazou, D.G. Haigh, S.J. Harrold, K. Steptoe, J.I. Sewell and R. Bayruns p460

600 μm/min laser-induced nonthermal etching of GaAs in an HF solution. A.E. Willner, D.V. Podlesnik and R.M. Osgood p568

9·5 GHz bandwidth HBT gain controllable amplifier IC with an amplitude detection circuit. H. Yamakawa, H. Ibe, J. Akagi, Y. Kuriyama, K. Morizuka and M. Obara p602

AlGaAs/GaAs heterojunction bipolar transistors fabricated with various collector-carrier concentrations. Y. Ota, T. Hirose, A. Ryoji and M. Inada p203

Broadband operation of InGaAsP–InGaAs GRIN-SC-MQW BH amplifiers with 115 mW output power. M. Bagley, G. Sherlock, D.M. Cooper, L.D. Westbrook, D.J. Elton, H.J. Wickes, P.C. Spurdens and W.J. Devlin p512

CW mm-wave GaAs TUNNETT diode. M. Pöbl, C. Dalle, J. Freyer and W. Harth p1540

DC and RF performance of GaAs MESFET fabricated on silicon substrate using epitaxial lift-off technique. D.M. Shah, W.K. Chan, T.J. Gmitter, L.T. Florez, H. Schumacher and B.P. Van der Gaag p1865

Damaged depth in GaAs processed by Ar plasma etching. H. Hidaka, K. Akita, M. Taneya and Y. Sugimoto p1112

Design of a broadband high-frequency antenna on gallium arsenide using the effective index method. L.J. Baca and J.G. McInerney p1083

Detectivity of gallium arsenide on silicon substrate photoconductive detectors. M. Constant, L. Boussekey, D. Decoster, B. Bartenlian and D. Pascal p239

Double-heterostructure AlGaAs/GaAs lasers grown on the mesas of trenched Si substrate by molecular beam epitaxy. X. Liu, H.P. Lee and S. Wang p590

Electro-optic sampling using an external GaAs probe tip. M. Shinagawa and T. Nagatsuma p1341

Extremely low-resistance nonalloyed ohmic contacts on molecular beam epitaxially grown *p*-type Ge. M.S. Ünlü, S. Strite, K. Adomi, G.B. Gao and H. Morkoç p89

First-order, switched-capacitor, low-pass filter implemented with GaAs insulated-gate FET switches. J. Luck and J.G. Swanson p1843

GaAs W-band impatt diodes for very low-noise oscillators. H. Eisele p109

Gallium arsenide MBE structure comprising mixer diodes and FETs for monolithic millimetre-wave receivers. J.A. Archer p384

High frequency gallium arsenide current mirror. C. Toumazou and D.G. Haigh p1802

High frequency gallium arsenide four-quadrant analogue multiplier. C. Toumazou, D.G. Haigh and J.M. Fopma p1650

High frequency gallium arsenide linearised transconductor for communications. D.G. Haigh and C. Toumazou p497

High microwave performance ion-implanted GaAs MESFETs on InP substrates. M. Wada and K. Kato p197

High performance DFB-MQW lasers at 1·5 μm grown by GSMBE. A. Perales, L. Goldstein, A. Accard, B. Fernier, F. Leblond, C. Gourdain and P. Brosson p236

High performance GaAs MESFETs grown on InP substrates by MOCVD using tertiarybutylarsine. J. Jeong, R.M. Lum, J.K. Klingert, R. Bylsma, G.P. Vella-Coleiro and P.R. Smith p482

High performance resonant tunnelling structures on GaAs substrates. H. Riechert, D. Bernklau, J.-P. Reithmaier and R.D. Schnell p340

High performance submicron pseudo-MODFETs and 2:1 multiplexers using GaAs on InP heteroepitaxial technology. Y.H. Lo, M. Bagheri, P.S.D. Lin, P. Grabbe, R. Bhat, N.G. Stoffel, T.P. Lee and D.T. Kong p807

High speed GaAs 32 × 8 embeddable dual port SRAM register array for 200 Mbyte/s packet switching applications. K.S. Lowe p516

High speed linear array circuit with AlGaAs/GaAs heterojunction bipolar transistors (HBTs). L.M. Lunardi, V.D. Archer, R.G. Swartz, J.M. Kuo, R.F. Kopf, R.J. Malik and P.R. Smith p1157

High speed low power GaAs crosspoint switch design. M. Bagheri p1142

High-efficiency GaAs microwave power MESFETs with an n^+n^-n doping formed by buried-shallow-implant (BSI). S.G. Liu, G.C. Taylor, J. Klatskin, R.L. Camisa and D.R. Capewell p1373

High-power single mode InGaAs/AlGaAs laser diodes at 910 nm. D.F. Welch, M. Cardinal, B. Streifer and D. Scifres p233

Laser-annealed refractory metal silicide films on GaAs. W.T. Anderson, A. Christou, P.E. Thompson, C.R. Gossett, J.M. Eridon, Z. Hatzopoulos, T. Efthimiopoulos, M. Kudumas, C. Michelakis and D.V. Morgan p62

Lateral nonuniform doping technique and its application to the fabrication of GaAs MESFETs with a lateral linear doping channel. H. Dejun p432

MOCVD grown carbon-doped graded-base AlGaAs/GaAs HBTs. H. Ito p1977

Modelling DC characteristics of GaAs MESFET devices using a simple and accurate analytic tool. S.A. Ibrahim and S. El-Rabaie p1892

New generation MMIC amplifier using InGaAs/InAlAs HEMTs. M. Weiss, G.I. Ng and D. Pavlidis p264

Post growth tailoring of the optical properties of GaAs-AlGaAs multiple quantum wells. M. Ghisoni, M. Gibson, A. Rivers, I.W. Boyd, G. Parry and J.S. Roberts p1058

Pressure measurement by GaAs piezoelectric sensors. K. Fricke and H.-L. Hartnagel p693

Submicron-gate ion-implanted $In_{0.15}Ga_{0.85}As/GaAs$ MESFETs with graded indium composition. G.W. Wang, M. Feng, R. Kaliski and J.B. Kuang p190

Temperature dependence of electron saturation velocity in GaAs. R. Allam and J. Pribetich p688

The effect of *n*-type dopant species on the compensating effects of oxygen implantation in GaAs. N.J. Whitehead and B.J. Sealy p866

Top-surface-emitting GaAs four-quantum-well lasers emitting at 0·85 μm. Y.H. Lee, B. Tell, K. Brown-Goebeler, J.L. Jewell and J.V. Hove p710

Transconductance dependence on gate length for GaAs gate pseudomorphic and conventional SISFETs at 300 and 77 K. P.E. Schmidt, E. Barbier, P. Collot, C. Gaonach, M. Champagne and D. Pons p210

Ultra high transconductance 0·25 μm gate MESFET with strained InGaAs buffer layer. A. Cappy, G. Dambrine, Y. Cordier, Y. Druelle and P. Legry p161

Ultra-high current gain InGaAsP/InP heterojunction bipolar transistor. T. Ohishi, Y. Abe, H. Sugimoto, K. Ohtsuka and T. Matsui p392

Very high frequency performance of nanometre scale GaAs MESFETs. J.A. Adams, I.G. Thayne, M.R.S. Taylor, C.D.W. Wilkinson, S.P. Beaumont, N.P. Johnson, A.H. Kean and C.R. Stanley p1019

Very low-noise $Al_{0.3}Ga_{0.7}As/Ga_{0.65}In_{0.35}As/GaAs$ single quantum-well pseudomorphic HEMTs. P.C. Chao, P. Ho, K.H.G. Duh, P.M. Smith, J.M. Ballingall, A.A. Jabra, N. Lewis and E.L. Hall p27

GALLIUM COMPOUNDS

Buried rectangular GaInAs/InP corrugations of 70 nm pitch fabricated by OMVPE. T. Yamamoto, Y. Miyamoto, M. Ogawa, E. Inamura and K. Furuya p875

GUNN DEVICES AND EFFECTS

Monte Carlo comparison of heterojunction cathode Gunn oscillators. C. Lee and U. Ravaioli p425

HARMONIC GENERATION

30 GHz picosecond pulse generation from actively mode-locked erbium-doped fibre laser. A. Takada and H. Miyazawa p216

Cerenkov third-harmonic generation in optical glass fibre. K. Hayata and M. Koshiba p1566

Error surface analysis of adaptive comb filter. J.F. Chicharo p587

Frequency multiplication using resonant tunnelling diode with output at submillimetre wavelengths. R. Bouregba, D. Lippens, L. Palmateer, E. Bockenhoff, M. Bogey, J.L. Destombes and A. Lecluse p1804

Measurement of the increase in the SHG coefficient of proton exchanged $LiNbO_3$ after annealing using a grating diffraction technique. R.W. Keys, A. Loni and R.M. De La Rue p624

Millimetre-wave second harmonic generation on a nonlinear transmission line. R.A. Marsland, M.S. Shakouri and D.M. Bloom p1235

Nondestructive measurement of phase velocity of surface acoustic waves using matched filters. M. Hirabayashi p411

Temperature dependence of second harmonic generation in germania-doped silica optical fibres. Y. Hibino, V. Mizrahi and G.I. Stegeman p1578

Temperature dependence of the second harmonic distortion of buried heterostructure distributed feedback lasers. S.J. Wang, A.B. Piccirilli, Y.J. Wang and N.K. Dutta p1095

HIGH-FIELD EFFECTS

High voltage floating gate array transistors. M. Levinson, P. Rossoni, F. Rock and B.M. Ditchek p777

HOLOGRAPHY

Boundary diffraction coefficients for calculating spurious beams produced by volume gratings. J.T. Sheridan and L. Solymar p1840

Position tunable volume reflection gratings for narrowband filtering applications (FWHM < 5 nm) in optical fibre systems. D.E. Sheat, J.S. Leggatt and D.J. McCartney p42

HYSTERESIS

CMOS layout design of the hysteresis McCulloch–Pitts neuron. T. Kurokawa, K.C. Lee, Y.B. Cho and Y. Takefuji p2093

IMAGE PROCESSING

Active stereo: Texture enhanced reconstruction. J.P. Siebert and C.W. Urquhart p427

Analogue MOS current-mode circuits for three-dimensional integrated smart image sensor. S. Kawahito, M. Ishida and T. Nakamura p177

Artificial neural network for image compression. G.L. Sicuranza, G. Ramponi and S. Marsi p477

Coarse-to-fine least squares stereo matching for 3-D reconstruction. F. Argenti and L. Alparone p812

Estimation method for normalised feature Jacobian matrix using only one camera. W. Jang and Z. Bien p2100

Experimental verification of image detection in highly scattering media using

antenna properties of optical heterodyne microscope scheme. M. Toida, M. Kondo, T. Ichimura and H. Inaba p700
Fast calculation of co-occurrence matrix parameters for image segmentation. L. Alparone, F. Argenti and G. Benelli p23
Fast encoding algorithm for VQ-based image coding. S.-H. Huang and S.-H. Chen p1618
Fast line detection algorithm using multivalued image coding. Y.S. Oh, Z. Bien and I.H. Suh p1400
Formula for the steady-state gain of a recursive estimator. S.N. Efstratiadis and A.K. Katsaggelos p1682
Fuzzy intraframe smoothing of a noisy image. Q. Shen p908
Hierarchical mean-residual image vector quantiser using gradient-Laplacian subspace distortion. L.M. Po and C.K. Chan p1362
Image compression algorithm for fast parallel thinning of binary images. L. Hayat and M.B. Sandler p1056
Infinite families of quasiperfect and doubly quasiperfect binary arrays. J. Jedwab and C.J. Mitchell p294
Medical ultrasound imaging using neural networks. M. Nikoonahad and D.C. Liu p545
Modulated QMF filter banks with perfect reconstruction. H.S. Malvar p906
Motion compensated sequence coding using image pyramids. Q. Wang and R.J. Clarke p575
Motion estimation algorithm using interblock correlation. C.-H. Hsieh, P.-C. Lu, J.-S. Shyn and E.-H. Lu p276
Nonlinear prediction in image coding with DPCM. J. Li and C.N. Manikopoulos p1357
Novel multirate sampling technique for ultrasound electronic sector scanning. T.K. Song and S.B. Park p71
Novel subspace distortion measurement for efficient implementation of image vector quantiser. L.-M. Po and C.-K. Chan p480
Real-world image segmentation using edge detection and subtraction. B. Qiu and M.G. Hartley p353
Recognising partially occluded objects by rigid body relaxation matching. T. Lee, R. Li and S.H. Kong p856
Silicon implementation of a function of visual peripheral processes. H. Li and C.-H. Chen p2013
Simple systolic array algorithm for Hadamard transform. M.H. Lee and Y. Yasuda p1478
Six-bit DPCM video signal processing and implementation using systolic arrays. M.K. Ibrahim and A. Aggoun p1225
Use of Fourier descriptors for the estimation of general motion in image sequences. Q. Wang and R.J. Clarke p1877
Use of co-occurrence matrices in the temporal domain. V. Seferidis and M. Ghanbari p1116
VLSI computing architectures for Haar transform. K.J. Ray Liu p1962
Vector quantisation of image sequences using variable size and variable shape blocks. L. Corte-Real and A.P. Alves p1483
Video compression using 3D wavelet transforms. A.S. Lewis and G. Knowles p396

IMPATTS

GaAs W-band impatt diodes for very low-noise oscillators. H. Eisele p109
IMPATT operation below the avalanche frequency. J.-F. Luy p1960

INDIUM COMPOUNDS

40 GHz measurement on InP/air gap line by picosecond electro-optic sampling. S. Loualiche, F. Clerot and G. Audibert p266
Buried rectangular GaInAs/InP corrugations of 70 nm pitch fabricated by OMVPE. T. Yamamoto, Y. Miyamoto, M. Ogawa, E. Inamura and K. Furuya p875
Growth of high quality InP with metal organic molecular beam epitaxy. H. Heinecke, R. Höger, B. Baur and A. Miklis p213
High performance $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As$ HFETs. H. Dämbkes, P. Marschall, Y.H. Zhang and K. Ploog p488
High performance DFB-MQW lasers at 1·5 μm grown by GSMBE. A. Perales, L. Goldstein, A. Accard, B. Fernier, F. Leblond, C. Gourdain and P. Brosson p236
High performance submicron pseudo-MODFETs and 2 : 1 multiplexers using GaAs on InP heteroepitaxial technology. Y.H. Lo, M. Bagheri, P.S.D. Lin, P. Grabbe, R. Bhat, N.G. Stoffel, T.P. Lee and D.T. Kong p807
Hydrogen passivation of high purity *n*-type InP. C.G. Crookes, D. Lancefield, K. Waterhouse, A.R. Adams, P.D. Greene and R.W. Glew p369
InP optical switch array module high frequency performance: Measurements and analysis. D.H. Hartman, Y. Takahashi and H. Inoue p436
New generation MMIC amplifier using InGaAs/InAlAs HEMTs. M. Weiss, G.I. Ng and D. Pavlidis p264
Pseudomorphic GaInP Schottky diode and MSM detector on InP. S. Loualiche, A. Le Corre, A. Ginudi, L. Henry, C. Vaudry and F. Clerot p487
Submicron-gate ion-implanted $In_{0.15}Ga_{0.85}As/GaAs$ MESFETs with graded indium composition. G.W. Wang, M. Feng, R. Kaliski and J.B. Kuang p190
Suppression of InP substrate degradation by hydrogen plasma caused by the presence of phosphorus vapour. R. Schütz, K. Matsushita, H.L. Hartnagel, J.Y. Longère and S.K. Krawczyk p564
Transconductance dependence on gate length for GaAs gate pseudomorphic and conventional SISFETs at 300 and 77 K. P.E. Schmidt, E. Barbier, P. Collot, C. Gaonach, M. Champagne and D. Pons p210
Ultra-high current gain InGaAsP/InP heterojunction bipolar transistor. T. Ohishi, Y. Abe, H. Sugimoto, K. Ohtsuka and T. Matsui p392
Ultra-high gain, low noise monolithic InP HEMT distributed amplifier from 5 to 40 GHz. C. Yuen, Y.C. Pao, M. Day, C. Nishimoto, M. Glenn, S. Bandy and G. Zdasiuk p515

INFORMATION THEORY

Efficient probabilistic public-key cryptosystem based on the Diffie–Hellman problem. C.-S. Laih and J.-Y. Lee p326
Generalised type-II hybrid ARQ. Ma Jianhua and Wang Xinmei p88
Information rate of McEliece's public-key cryptosystem. M.-C. Lin, T.-C. Chang and H.-L. Fu p16
Merit factor of Chu and Frank sequences. M. Antweiler and L. Bömer p2068
New class of codes suitable for computer error control. Pingzhi Fan and Fan Jin d1215
Novel multifunctional decoder for MLD codes. X.H. Peng and P.G. Farrell p1706 e1986
Reducing time delay of ARQ protocols by simple error-correcting codes. Q. Yang and V.K. Bhargava p1447
Size limits on phased burst error correcting array codes. R.M. Goodman and M. Sayano p55
Some classes of burst asymmetric or unidirectional error correcting codes. Y. Saitoh and H. Imai p286

INFRA-RED DETECTORS

IR photodetector with exclusion effect and self-filtering n^+ layer. Z. Djuric, V. Jovic, M. Matic and Z. Jaksic p929
Long wavelength infra-red photoconductive InAsSb detectors grown in Si wells by molecular beam epitaxy. W. Dobbelaere, J. De Boeck, M. Van Hove, K. Deneffe, W. De Raedt, R. Mertens and G. Borghs p259

INFRA-RED SOURCES

Room temperature observation of mid-infrared inter-subband absorption activated by near-infrared illumination in multiple quantum wells. D. Delacourt, D. Papillon, J.P. Pocholle, J.P. Schnell and M. Papuchon p277

INSTRUMENTATION

Metallic glass ribbon probe for the measurement of the magnetic field, first and second order field gradients. M.D. Mermelstein and A. Dandridge p501
Minimum area analogue-digital calibration network for high-resolution data converters. C.A. Leme and J.E. Franca p1491
PC sampling oscillograph for subnanosecond time region. J. Červeň and R. Kukuča p1950

INSULATING MATERIALS AND INSULATORS

Competition between second and third harmonic generation in silica fibres. X.H. Zheng and J.E. Carroll p2065
Growth of third-harmonic signal in optical glass fibre. U. Österberg p103
Single-step buried waveguides in glass by field-assisted copper ion-exchange. S.S. Gevorgyan p38

INTEGRATED CIRCUITS

0HgCdTe sampling circuit. R.A. Schiebel, J. Dodge and R. Gooch p702
10 GHz bandwidth, 20 dB gain low-noise direct-coupled amplifier ICs using Au/WSiN GaAs MESFET. Y. Imai, M. Tokumitsu, K. Onodera and K. Asai p699
13 Gb/s D-Type flip-flop IC using GaAs MESFETs. M. Ohhata, Y. Yamane, T. Enoki, S. Sugitani, N. Kato, K. Hagimoto and M. Hirayama p1039
1 Gbit/s high-speed bit-synchronisation LSI for B-ISDN. Y. Otsuka p622
3·2 GHz 0·2 μm gate CMOS 1/8 dynamic frequency divider. Y. Kado, Y. Okazaki, M. Suzuki and T. Kobayashi p1684
3·4 GHz silicon bipolar versatile shift register and 6·8 Gbit/s word generator. B. Wüppermann, U. Langmann and A. Pottbäcker p553
400 MHz switching rate GaAs switched capacitor filter. C. Toumazou, D.G. Haigh, S.J. Harrold, K. Steptoe, J.I. Sewell and R. Bayruns p460
94 GHz InP MMIC five-section distributed amplifier. R. Majidi-Ahy, M. Riaziat, C. Nishimoto, M. Glenn, S. Silverman, S. Weng, Y.C. Pao, G. Zdasiuk, S. Bandy and Z. Tan p91
9·5 GHz bandwidth HBT gain controllable amplifier IC with an amplitude detection circuit. H. Yamakawa, H. Ibe, J. Akagi, Y. Kuriyama, K. Morizuka and M. Obara p602
Algorithm for prime length discrete cosine transforms. Y.-H. Chan and W.-C. Siu p206
Analogue MOS current-mode circuits for three-dimensional integrated smart image sensor. S. Kawahito, M. Ishida and T. Nakamura p177
Automatic switching of substrate bias or well bias in CMOS-ICs. U. Gatti, V. Liberali, F. Maloberti and P. O'Leary p1381
Diffusion and oxide viscous flow mechanism in SDB process and silicon wafer rapid thermal bonding. Q.-Y. Tong, X.-L. Xu and H. Shen p697
Double heterojunction GaAlAs/GaAs I^2L integrated circuits. J.P. Vannel, A. Marty, J. Tasselli, A. Cazarré and J.P. Bailbé p969
Epitaxial lift-off of GaAs LEDs to Si for fabrication of opto-electronic integrated circuits. I. Pollentier, P. Demeester, A. Ackaert, L. Buydens, P. Van Daele and R. Baets p193
Evaluation of currents in the fA range. P. Girard and P. Nouet p844
Frequency dependent transmission characteristics of microstrip lines on the finite width substrate or near a substrate edge. A. Rong and S. Li p782
Gallium arsenide MBE structure comprising mixer diodes and FETs for monolithic millimetre-wave receivers. J.A. Archer p384
Measurements of crosstalk between closely-packed lossy microstrips on silicon substrates. M.S. Lin, A.H. Engvik and J.S. Loos p714
Model for the potential drop in the silicon substrate for thin-film SOI MOSFETs. J.A. Martino, L. Lauwers, J.P. Colinge and K. De Meyer p1462
Monolithic *pin*-HEMT receiver with internal equaliser for long-wavelength fibre optic communications. H. Yano, K. Aga, H. Kamei, G. Sasaki and H. Hayashi p305
New submicron MOSFET structural concept for suppression of hot carriers. A.F. Tasch, H. Shin and C.M. Maziar p39
Novel 4 : 1 multiplexer circuit for Gbit/s data rates. D. Daniel p1092
Proposal for a versatile monolithic multi-Gbit/s m-sequence test system. M. Bußmann and U. Langmann p1625
Proposed ultrahigh frequency microstrip utilising buried silicide groundplane. K.W. Goossen, A.E. White and K.T. Short p49 e555 e555
Silicon nitride direct bonding. M.S. Ismail, R.W. Bower, J.L. Veteran and O.J. Marsh p1045
Some structures for neural based A/D conversion. G. Avitabile and S. Manetti p1516
Speed limitations of multilayer digital packages. D.R. Conn and S. Xie p1751
Suppression of InP substrate degradation by hydrogen plasma caused by the presence of phosphorus vapour. R. Schütz, K. Matsushita, H.L. Hartnagel, J.Y. Longère and S.K. Krawczyk p564
Transmission characteristics of suspended striplines with finite metallisation thickness and substrate supporting grooves. A. Rong p431
VLSI architecture for the discrete wavelet transform. G. Knowles p1184
Versatile divider circuits up to 9 GHz input-frequency realised in high-speed BICMOS. P. Weger, A. Felder, M. Kerber and H. Klose p1942
Versatile silicon bipolar XOR gate for signal processing up to 8 Gbit/s. J. Hauenschild, H.-M. Rein, L. Schmidt and K. Wörner p114

INTEGRATED OPTICS

0Mach–Zehnder interferometer type optical waveguide coupler with wavelength-flattened coupling ratio. K. Jinguji, N. Takato, A. Sugita and M. Kawachi p1326
10 Gbit/s optical transmitter module with MQW DFB-LD and DMT driver IC. T. Suzaki, Y. Suzuki, H. Yamada, S. Fujita, H. Hida, M. Kitamura and M. Shikada p151
Asymmetric coplanar-strip transmission lines for MMIC and integrated optic applications. S.S. Gevorgian and I.G. Mironenko p1916
Broadband polarisation splitting couplers in ion-exchanged glass. R.A. Betts and F. Lui p450

Chemically stabilised ion implanted waveguides in sapphire. P.D. Townsend, P.J. Chandler, R.A. Wood, L. Zhang, J. McCallum and C.W. McHargue p1193
Design of an InGaAlAs/InP '3mi' wavelength division demultiplexer employing a novel mode transformer. I.R. Croston and T.P. Young p336
Diode laser waveguiding in polydiacetylene films. B. Rossi, W. Blau, J. O'Gorman, S. König, D. Westland and V. Skarda p312
Directional-coupler-based planar concentrator networks. A. Jajszczyk p886
Electro-optic polarisation convertor on (110) InP. F. Zamkotsian, C. Artigue, J.-L. Peyre, J.-L. Lievin, M. Lambert, D. Bonnevie and J. Benoit p1560
Explicit finite difference beam propagation method: Application to semiconductor rib waveguide Y-junction analysis. Y. Chung and N. Dagli p711
Finite difference methods for the analysis of integrated optical waveguides. R. Accornero, M. Artiglia, G. Coppa, P. Di Vita, G. Lapenta, M. Potenza and P. Ravetto p1959
Grafted GaAlAs rib waveguides on an InP substrate. A. Yi-Yan, M. Seto, T.J. Gmitter, D.M. Hwang and L.T. Florez p1567
High efficiency small-size planar hyperbolical lenses. P.C.A. Hammes, G.J.M. Krijnen, A. Driessen and M.K. Smit p1064
High performance buried ridge DFB lasers monolithically integrated with butt coupled strip loaded passive waveguides for OEIC. P.J. Williams, P.M. Charles, I. Griffith, L. Considine and A.C. Carter p142
High speed 1·3 μm InGaAs/GaAs superlattice on Si photodetector. M. Zirngibl, J.C. Bischoff, M. Ilegems, J.P. Hirtz, B. Bartenlian, P. Beaud and W. Hodel p1027
High-resolution OCDR in dispersive waveguides. E. Brinkmeyer and R. Ulrich p413
Hybrid finite element/boundary element method for analysis of discontinuities in planar dielectric waveguides. B.M. Dillon, R.L. Ferrari and T.P. Young p47
IR photodetector with exclusion effect and self-filtering n^+ layer. Z. Djuric, V. Jovic, M. Matic and Z. Jaksic p929
Index profile of proton-exchanged waveguides in $LiNbO_3$ using pyrophosphoric acid. E.Y.B. Pun, T.C. Kong, P.S. Chung and H.P. Chan p81 e555 e555
Integrated optics 4 × 4 switch matrix with digital optical switches. P. Granestrand, B. Lagerström, P. Svensson, L. Thylén, B. Stoltz, K. Bergvall, J.-E. Falk and H. Olofsson p4
Integrated-optic interferometric microdisplacement sensor in glass with thermo-optic phase modulation. D. Jestel, A. Baus and E. Voges p1144
Integration of GaAs MESFETs and lithium niobate optical switches using epitaxial lift-off. A.C. O'Donnell, I. Pollentier, P. Demeester, P. Van Daele and A.D. Carr p1179
Integration of detectors with GaInAsP/InP carrier depletion optical switches. J.A. Cavaillès, M. Renaud, P. Jarry, M. Erman, J.F. Vinchant and A. Goutelle p1783
Low current plasma effect optical switch on InP. G. Müller, L. Stoll, G. Schulte-Roth and U. Wolff p115
Low threshold distributed Bragg reflector surface emitting laser diode with semiconductor air-bridge-supported top mirror. W. Hsin, G. Du, J.K. Gamelin, K.J. Malloy, S. Wang, J.R. Whinnery, Y.J. Yang, T.G. Dziura and S.C. Wang p307 e828
Low-threshold monomode ion-exchanged waveguide lasers in neodymium-doped BK-7 glass. E.K. Mwarania, L. Reekie, J. Wang and J.S. Wilkinson p1317
Modified configuration for a high-finesse compact loop resonator for semiconductor integrated optics. A. Shahar, W.J. Tomlinson and M. Seto p1528 e1922
Monolithic integration of 1·5 μm optical preamplifier and pin photodetector with a gain of 20 dB and a bandwidth of 35 GHz. D. Wake, S.N. Judge, T.P. Spooner, M.J. Harlow, W.J. Duncan, I.D. Henning and M.J. O'Mahony p1166
Monolithic integration of an InGaAs/GaAs/AlGaAs strained layer SQW LED and GaAs MESFET using epitaxial lift-off. I. Pollentier, L. Buydens, A. Ackaert, P. Demeester, P. Van Daele, F. De Pestel, D. Lootens and R. Baets p925 e1324
Monolithic integration of an InP/InGaAs four-channel transimpedance optical receiver array. W.S. Lee, D.A.H. Spear, P.J.G. Dawe and S.W. Bland p1833
Nonlinear Y-junction coupler. S. Chi and T.-T. Shi p339
Novel distributed-feedback resonant-periodic-gain structure for vertical-cavity surface-emitting semiconductor lasers. M. Mahbobzadeh and M. Osiński p1716
Passive integrated optical polarisation mode-splitter in lithium niobate employing a resonant metal-loaded structure. C. Edge, P.J. Duthie and M.J. Wale p1855
Post growth tailoring of the optical properties of GaAs-AlGaAs multiple quantum wells. M. Ghisoni, M. Gibson, A. Rivers, I.W. Boyd, G. Parry and J.S. Roberts p1058
Power distribution in symmetric integrated optic X junction. S. Gevorgyan and A. Hovsepyan p788
Reduction of DC drift in $LiNbO_3$ waveguide electro-optic devices by phosphorus doping in SiO_2 buffer layer. T. Suhara, M. Fujimura, K. Kinoshita and H. Nishihara p1409
Reduction of the propagation losses in impurity disordered quantum well waveguides. M. O'Neill, J.H. Marsh, R.M. De La Rue, J.S. Roberts, C. Button and R. Gwilliam p1613
Single-quantum-well laser with 11·2 degree transverse beam divergence. Y.C. Chen, R.G. Waters and R.J. Dalby p1348
Single-step buried waveguides in glass by field-assisted copper ion-exchange. S.S. Gevorgyan p38
TM-mode selective filter using lossy layer cladding optical waveguide. S. Ohke, S. Nishihara and Y. Cho p98
Tunable couplers fabricated in K^+/Na^+ ion exchanged glass. R.A. Betts, F. Lui and E. Gauja p786

INTERFACE STATES

Gate oxide thickness dependence of high-field-induced interface state generation in thin thermal oxides. G.Q. Lo and D.L. Kwong p1124
Process dependence of interface state generation due to irradiation and hot carrier stress in rapid thermally nitrided thin gate oxides. A.B. Joshi, G.Q. Lo and D.L. Kwong p1248

INTERFERENCE

Analysis of the interference signal arising from the transmission of a pulse sequence through a monomode fibre. J. Capmany and M.A. Muriel p149
Monte Carlo estimates of incidence of basic access ISDN generated EMI. W.D. Davies p1048
Multitone jamming of hybrid SFH/DS-MFSK communication systems. M.A. Laxpati p323
Outage probability analysis for microcell mobile radio systems with cochannel interferers in Rician/Rayleigh fading environment. Y.-D. Yao and A.U.H. Sheikh p864
Reduction of thermal interference on lasing wavelength for DFB LD/EA modulator integrated light source. H. Tanaka, M. Suzuki and Y. Matsushima p2124

INTERFEROMETERS

'On-spot' interferometric optical coherence domain polarimetry for quasi-distributed temperature sensors. S. Chen and I.P. Giles p1607
All-optical loop mirror switch employing an asymmetric amplifier/attenuator combination. A.W. O'Neill and R.P. Webb p2008
Compact low-voltage InGaAs/InAlAs multiple quantum well waveguide interferometers. J.E. Zucker, K.L. Jones, T.Y. Chang, N. Sauer, B. Tell, K. Brown-Goebeler, M. Wegener and D.S. Chemla p2029
Electronically-scanned white light interferometry with enhanced dynamic range. S. Chen, B.T. Meggitt and A.J. Rogers p1663
Interferometric fibre displacement/strain sensor based on source coherence synthesis. T.A. Berkoff and A.D. Kersey p452
Quadrature phase sampling of a fibre interferometer by input-polarisation switching. A.D. Kersey and M.J. Marrone p686

INTERMODULATION

Calculation of third order intermodulation spectrum. Y.-H. Lau and D.J. Skellern p1776
Effect of varying threshold gain on second order intermodulation distortion in distributed feedback lasers. H. Kawamura, K. Kamite, H. Yonetani, S. Ogita, H. Soda and H. Ishikawa p1720
Reduction of intermodulation distortion of interferometric optical modulators through incoherent mixing of optical waves. Z.-Q. Lin and W.S.C. Chang p1980

INVERTERS

Automated adaptive hysteresis current control technique for a voltage-fed PWM inverter. D.S. Oh and M.J. Youn p2044

ION IMPLANTATION

Effects of etch depth and ion implantation on surface emitting microlasers. Y.H. Lee, J.L. Jewell, B. Tell, K.F. Brown-Goebeler, A. Scherer, J.P. Harbison and L.T. Florez p225
High microwave performance ion-implanted GaAs MESFETs on InP substrates. M. Wada and K. Kato p197
Ion implanted waveguides in doped $LiNbO_3$. P.S. Chandler, L. Zhang and P.D. Townsend p332
Ion-implanted Nd : YAP planar waveguide laser. S.J. Field, D.C. Hanna, D.P. Shepherd, A.C. Tropper, P.J. Chandler, P.D. Townsend and L. Zhang p1826
Lateral nonuniform doping technique and its application to the fabrication of GaAs MESFETs with a lateral linear doping channel. H. Dejun p432
Optical activity induced in $Bi_4Ge_3O_{12}$ waveguides by ion implantation. S.M. Mahdavi and P.D. Townsend p371
The effect of n-type dopant species on the compensating effects of oxygen implantation in GaAs. N.J. Whitehead and B.J. Sealy p866

IONISATION

Low temperature dependence of the hole impact ionisation constants determined from PMOS transistors. M.J. Deen and Z.P. Zuo p1975

LARGE-SCALE INTEGRATION

Algorithm for prime length discrete cosine transforms. Y.-H. Chan and W.-C. Siu p206
Cellular automata-based built-in self-test structures for VLSI systems. Ph. Tsalides p1350
Measurements of pulse propagation on unterminated lossy microstrips with small dimensions. M.S. Lin, A.H. Engvik and K.L. Tai p747
Newly structured expandable 52 Mbit/s, 48-channel time-division switching LSI with 2·4 Gbit/s throughput. N. Yamanaka, S. Kikuchi and H. Miyanaga p524

LASER-BEAM INTERACTIONS

Interferometric fibre displacement/strain sensor based on source coherence synthesis. T.A. Berkoff and A.D. Kersey p452

LASERS AND LASER APPLICATIONS

10 Gbit/s optical PSK homodyne transmission experiments using external cavity DFB LDs. S. Norimatsu, K. Iwashita and K. Noguchi p648
10 Gbit/s optical transmitter module with MQW DFB-LD and DMT driver IC. T. Suzaki, Y. Suzuki, H. Yamada, S. Fujita, H. Hida, M. Kitamura and M. Shikada p151
14 W peak power grating surface-emitting laser array. G.A. Evans, N.W. Carlson, D.P. Bour, M. Lurie, R.K. DeFreez and D.J. Bossert p1380
160-channel FM-video transmission using optical FM/FDM and subcarrier multiplexing and an erbium doped optical fibre amplifier. W.I. Way, M.W. Maeda, A. Yi-Yan, M.J. Andrejco, M.M. Choy, M. Saifi and C. Lin p139
1·53 μm DFB laser on semi-insulating InP substrate with very low threshold current. W. Thulke and S. Illek p933
1·55 μm high-gain polarisation-insensitive semiconductor travelling wave amplifier with low driving current. B. Mersali, G. Gelly, A. Accard, J.-L. Lafragette, P. Doussiere, M. Lambert and B. Fernier p124
20 000 h InGaAs quantum well lasers. S.L. Yellen, R.G. Waters, Y.C. Chen, B.A. Soltz, S.E. Fischer, D. Fekete and J.M. Ballantyne p2083
242 nm continuous tuning from a GRIN-SC-MQW-BH InGaAsP laser in an extended cavity. M. Bagley, R. Wyatt, D.J. Elton, H.J. Wickes, P.C. Spurdens, C.P. Seltzer, D.M. Cooper and W.J. Devlin p267
30 GHz picosecond pulse generation from actively mode-locked erbium-doped fibre laser. A. Takada and H. Miyazawa p216
40 GHz measurement on InP/air gap line by picosecond electro-optic sampling. S. Loualiche, F. Clerot and G. Audibert p266
44-ary FSK coherent optical communication system. S.B. Alexander, R. Barry, D.M. Castagnozzi, V.W.S. Chan, D.M. Hodsdon, L.L. Jeromin, J.E. Kaufmann, D.M. Materna, R.J. Parr, M.L. Stevens and D.W. White p1346
565 Mbit/s 219 km transmission experiment using four gain controlled packaged semiconductor laser amplifiers. A.D. Ellis, J.D. Cox, D.M. Bird, K. Cameron, D.J. Elton, G. Sherlock and W.A. Stallard p385
565 Mbit/s optical DPSK and PSK heterodyne transmission experiment using Nd : YAG lasers at 1·3 μm. A. Schoepflin p255
636 nm room temperature CW operation by heterobarrier blocking structure

InGaAlP laser diodes. K. Itaya, M. Ishikawa and Y. Uematsu p839
675 mW diffraction limited operation and thermal characteristics of laser diode arrays in an external cavity. R.G. Waarts, D. Mehuys, D.F. Welch and W. Streifer p1586
780 nm, low threshold current laser fabricated by two-step, solid-phase Zn diffusion. A. Shima, T. Kamizato, A. Takami, S. Karakida, K. Isshiki and H. Matsubara p915 e1739
90% coupling of top surface emitting GaAs/AlGaAs quantum well laser output into 8 μm diameter core silica fibre. K. Tai, G. Hasnain, J.D. Wynn, R.J. Fischer, Y.H. Wang, B. Weir, J. Gamelin and A.Y. Cho p1628
AlGaAs/GaAs surface emitting laser diode with curved reflector. S.-J. Yih and S.-C. Lee p1506
Analysis of antireflection coatings on angled facet semiconductor laser amplifiers. M.C. Farries, J. Buus and D.J. Robbins p381
Analysis of coupling coefficient between two vertical cavity surface emitting lasers for two-dimensional phase-locked array. H.-J. Yoo, J.R. Hayes and Y.-S. Kwon p896
Analysis of the spontaneous emission rate of multiple-phase-shift distributed feedback semiconductor lasers. T. Makino p629
Asymmetric gain induced by longitudinal spatial carrier burning in semiconductor lasers. V.-Z. Huang p783
Bandwidth-limited 0·3W picosecond pulses (4 ps) from a 1·53 μm microwave modulated DFB laser with fibre compression. L. Chusseau, J.M. Xie, L. Duvillaret, J.M. Lourtioz, A. Accard and J-P. Hebert p1085
Blue upconversion fluorozirconate fibre laser. J.Y. Allain, M. Monerie and H. Poignant p166
Broadband tuning (170 nm) of InGaAs quantum well lasers. L.E. Eng, D.G. Mehuys, M. Mittelstein and A. Yariv p1675
CW diode-pumped operation of 1·97 μm thulium-doped fluorozirconate fibre laser. J.N. Carter, R.G. Smart, D.C. Hanna and A.C. Tropper p599
CW operation of semiconductor ring lasers. T. Krauss, P.J.R. Laybourn and J. Roberts p2095
Calculated chirp in intracavity loss modulated DFB lasers. J. O'Gorman and A.F.J. Levi p1784
Carrier-induced refractive-index change, mode gain and spontaneous-emission factor in AlGaInP SQW-SCH laser diodes. T. Tanaka and S. Minagawa p766
Chemically stabilised ion implanted waveguides in sapphire. P.D. Townsend, P.J. Chandler, R.A. Wood, L. Zhang, J. McCallum and C.W. McHargue p1193
Chirp and linewidth enhancement factor α of current modulated Ga(Al)As-GRINSCH-SQW-MCRW flared waveguide lasers. M. Heinrich and M. Claassen p1598
Chirped grating λ/4-shifted distributed feedback laser with uniform longitudinal field distribution. P. Zhou and G.S. Lee p1660
Coherent linear arrays of grating coupled surface-emitting lasers. R.G. Waarts, D.F. Welch, R. Parke, A. Hardy and W. Streifer p129
Combined high power and high frequency operation of InGaAsP/InP lasers at 1·3 μm. T.R. Chen, Y.H. Zhuang, A. Yariv, H. Blauvelt and N. Bar-Chaim p985
Comparison of DFB laser linewidth measurement techniques: Results from COST 215 round robin. M.O. van Deventer, P. Spano and S.K. Nielsen p2018
Continuous wave top surface emitting quantum well lasers using hybrid metal/semiconductor reflectors. G. Hasnain, K. Tai, J.D. Wynn, Y.H. Wang, R.J. Fischer, M. Hong, B.E. Weir, G.J. Zydzik, J.P. Mannaerts, J. Gamelin and A.Y. Cho p1590
Continuous-wave high-power (75 mW) operation of a transverse-mode stabilised window-structure 680 nm AlGaInP visible laser diode. Y. Ueno, K. Endo, H. Fujii, K. Kobayashi, K. Hara and T. Yuasa p1726
Continuously tunable metal-clad ridge-waveguide distributed feedback laser diode. T. Wolf, H. Westermeier and M.-C. Amann p1845
Controlled amplifier modelocked Er^{3+} fibre ring laser. D. Burns and W. Sibbett p505
Correlation of relative intensity noise with linewidth floors in narrow linewidth DFB lasers. H. Sundaresan and N.C. Fletcher p2002
Crosstalk measurements for a dual emitter laser. N.K. Dutta, S.J. Wang, A.B. Piccirilli and W.V. Werner p1643
Demodulation of multi-gigahertz frequency-modulated optical signals in an injection-locked distributed feedback laser oscillator. H. Nakajima p1129
Demonstration of a 1 × 2 multichannel grating cavity laser for wavelength division multiplexing (WDM) applications. I.H. White, K.O. Nyairo, P.A. Kirkby and C.J. Armistead p832
Demonstration of digital pulse modulation of a grating-surface-emitting diode laser. N.W. Carlson, D.R. Patterson, P.J. Stabile, S.K. Liew, D.P. Bour and G.A. Evans p1695
Diode laser pumped Er^{3+} fibre laser operation between 2·7–2·8 μm. H. Yanagita, I. Masuda, T. Yamashita and H. Toratani p1836
Diode-laser pumped erbium-doped fluorozirconate fibre amplifier for the 1530 nm communications window. C.A. Millar and P.W. France p634
Diode-pumped 1·36 μm Nd-doped fibre laser. S.G. Grubb, W.L. Barnes, E.R. Taylor and D.N. Payne p121
Direct observation of shot noise in linewidth broadening of DBR lasers. H. Sundaresan and N.C. Fletcher p2004
Double-heterostructure AlGaAs/GaAs lasers grown on the mesas of trenched Si substrate by molecular beam epitaxy. X. Liu, H.P. Lee and S. Wang p590
Effect of varying threshold gain on second order intermodulation distortion in distributed feedback lasers. H. Kawamura, K. Kamite, H. Yonetani, S. Ogita, H. Soda and H. Ishikawa p1720
Effects of etch depth and ion implantation on surface emitting microlasers. Y.H. Lee, J.L. Jewell, B. Tell, K.F. Brown-Goebeler, A. Scherer, J.P. Harbison and L.T. Florez p225
Effects of zinc doping in DFB lasers emitting at 1·3 and 1·55 μm. M. Sugano, H. Sudo, H. Soda, T. Kusunoki and H. Ishikawa p95
Efficient CW operation of a 2·9 μm Ho^{3+}-doped fluorozirconate fibre laser pumped at 640 nm. L. Wetenkamp p883
Efficient Nd : MgO : $LiNbO_3$ waveguide laser. E. Lallier, J.P. Pocholle, M. Papuchon, M. De Micheli, M.J. Li, Q. He, D.B. Ostrowsky, C. Grezes-Besset and E. Pelletier p927
Enhanced relaxation oscillation frequency and reduced nonlinear K-factor in InGaAs/InGaAsP MQW λ/4-shifted DFB lasers. M. Aoki, K. Uomi, T. Tsuchiya, M. Suzuki and N. Chinone p1841
Enhanced surface emitting waveguides for visible, monolithic semiconductor laser sources. R. Normandin, R.L. Williams and F. Chatenoud p2088
Erbium doped fluorozirconate fibre laser operating at 1·66 and 1·72 μm. R.G. Smart, J.N. Carter, D.C. Hanna and A.C. Tropper p649
Erbium fibre soliton laser. K. Smith, J.R. Armitage, R. Wyatt, N.J. Doran and S.M.J. Kelly p1149
Excess linewidth broadening in wavelength-tunable laser diodes. M.-C. Amann and R. Schimpe p279
External grating tunable MQW laser with wide tuning range of 240 nm. H. Tabuchi and H. Ishikawa p742
Extremely high-frequency (24 GHz) InGaAsP diode lasers with excellent modulation efficiency. E. Meland, R. Holmstrom, J. Schlafer, R.B. Lauer and W. Powazinik p1827
Fabrication and optical characterisation of first order DFB GaInP/AlGaInP laser structures at 639 nm. M. Korn, T. Körfer, A. Forchel and P. Roentgen p614
Fabrication of domain reversed gratings for SHG in $LiNbO_3$ by electron beam bombardment. R.W. Keys, A. Loni, R.M. De La Rue, C.N. Ironside, J.H. Marsh, B.J. Luff and P.D. Townsend p188
Fast wavelength switching and simultaneous FSK modulation using tunable DBR laser. H. Kobrinski, M.P. Vecchi, T.E. Chapuran, J.B. Georges, C.E. Zah, C. Caneau, S.G. Menocal, P.S.D. Lin, A.S. Gozdz and F.J. Favire p308
Femtosecond optical pulse generation using a distributed-feedback laser diode. M. Nakazawa, K. Suzuki and E. Yamada p2038
Fundamental limitation on large-signal modulation of semiconductor lasers and its implications for lightwave transmission. G.P. Agrawal p916
GRINSCH GaAs/AlGaAs laser structures grown by OMVPE using a novel aluminium source. W.S. Hobson, A.F.J. Levi, J. O'Gorman, S.J. Pearton, C.R. Abernathy and V. Swaminathan p1762
GaAlAs window lasers emitting 500 mW CW in fundamental mode. J. Ungar, N. Bar-Chaim, M. Mazed, M. Mittelstein, S. Oh and I. Ury p1441 e1922
Generation of <3 ps optical pulses by fibre compression of gain-switched InGaAsP DFB laser diode pulses. R.T. Hawkins p292
Glass waveguide laser operated around 1·3 μm. H. Aoki, O. Maruyama and Y. Asahara p1910
Heterojunction field effect transistor laser. Y. Suzuki, H. Yajima, K. Shimoyama, Y. Inoue, M. Katoh and H. Gotoh p1632
High efficiency (1·2 mW/mA) top-surface-emitting GaAs quantum well lasers. Y.H. Lee, B. Tell, K. Brown-Goebeler, J.L. Jewell, R.E. Leibenguth, M.T. Asom, G. Livescu, L. Luther and V.D. Mattera p1308
High efficiency, high uniformity, grating coupled surface emitting lasers. R. Parke, R. Waarts, D.F. Welch, A. Hardy and W. Streifer p125
High gain Er^{3+}-doped fibre amplifier pumped by 820 nm GaAlAs laser diodes. K. Suzuki, Y. Kimura and M. Nakazawa p948
High gain, wide dynamic range L-band externally modulated fibre optic. E. Ackerman, D. Kasemsei, S. Wanuga and S. Chinn p1339
High performance DFB-MQW lasers at 1·5 μm grown by GSMBE. A. Perales, L. Goldstein, A. Accard, B. Fernier, F. Leblond, C. Gourdain and P. Brosson p236
High performance buried ridge DFB lasers monolithically integrated with butt coupled strip loaded passive waveguides for OEIC. P.J. Williams, P.M. Charles, I. Griffith, L. Considine and A.C. Carter p142
High power (>100 mW), low crosstalk ($<0·4\%$), individually addressed laser diodes. D. Mehuys, D.F. Welch, D.W. Nam and D.R. Scifres p1955
High power InGaAs/GaAs laser array. N.K. Dutta, J.D. Wynn, J. Lopata, D.L. Sivco and A.Y. Cho p1816
High power operation of GaInAsP/GaInAs MQW ridge lasers emitting at 1·48 μm. B.S. Bhumbra, R.W. Glew, P.D. Greene, G.D. Henshall, C.M. Lowney and J.E.A. Whiteaway p1755
High power, 16 W, grating surface emitting laser with a superlattice substrate reflector. D.F. Welch, R. Parke, A. Hardy, R. Waarts, W. Streifer and D.R. Scifres p757
High power, high brightness 2 W (200 μm) and 3 W (500 μm) CW AlGaAs laser diode arrays with long lifetimes. M. Sakamoto, D.F. Welch, H. Yao, G. Endriz and D.R. Scifres p729
High reliability, high power, single mode laser diodes. D. Welch, R. Craig, W. Streifer and D. Scifres p1481
High resolution laser LIDAR utilising two-section distributed feedback semiconductor laser as a coherent source. E.C. Burrows and K.-Y. Liou p577
High-efficiency coupling of laser diodes in tapered proton-exchanged waveguides. K. Mizuuchi, K. Yamamoto and T. Taniuchi p1992
High-power CW operation of broad area InGaAlP visible light laser diodes. K. Itaya, G. Hatakoshi, Y. Watanabe, M. Ishikawa and Y. Uematsu p214
High-power and high-speed semi-insulating BH structure monolithic electro-absorption modulator/DFB laser light source. H. Soda, M. Furutsu, K. Sato, N. Okazaki, S. Yamazaki, H. Nishimoto and H. Ishikawa p9
High-power single mode InGaAs/AlGaAs laser diodes at 910 nm. D.F. Welch, M. Cardinal, B. Streifer and D. Scifres p233
Highly reproducible ridge waveguide multielectrode DFB lasers for optical communication systems. H. Sundaresan, S. Kwan, A. Lord, W.J. Duncan, I.D. Henning, W.A. Stallard and C. Broughton p1876
Highly tunable and efficient diode pumped operation of Tm^{3+} doped fibre lasers. W.L. Barnes and J.E. Townsend p746
Hybrid-integrated laser/driver module for 10 Gbit/s optical fibre transmission. H. Nakano, K. Uomi, K. Yamashita and Y. Yagiu p145
Hysteresis and multistable behaviour in a polarisation self-modulated external ring cavity semiconductor laser. W.H. Loh, A.T. Schremer and C.L. Tang p1666
Improved Y–X junction laser array. W. Streifer, A. Hardy, D.F. Welch, D.R. Scifres and P.S. Cross p1730
Influence of leakage currents between electrodes in tunable DBR-lasers. M. Öberg, S. Nilsson, B. Holmberg, T. Klinga and B. Broberg p1089
Influence of nonlinear gain on DFB laser linewidth. X. Pan, H. Olesen and B. Tromborg p1074
Investigation of TE and TM polarised laser emission in GaInP/AlGaInP lasers by growth-controlled strain. M.J.B. Boermans, S.H. Hagen, A. Valster, M.N. Finke and J.M.M. van der Heyden p1438 e1986
Ion implanted waveguides in doped $LiNbO_3$. P.S. Chandler, L. Zhang and P.D. Townsend p332
Ion-implanted Nd : YAP planar waveguide laser. S.J. Field, D.C. Hanna, D.P. Shepherd, A.C. Tropper, P.J. Chandler, P.D. Townsend and L. Zhang p1826
Kramers–Kronig relations for nonlinear optics. K.A. Shore and D.A.S. Chan p1206
Laser diode modulation of 10·6 μm radiation in GaAs/AlGaAs quantum wells. D.D. Yang, P. Boucaud, F.H. Julien, L. Chusseau, J.-M. Lourtioz and R. Planel p1531
Light-controlled optical bistable device by bistable laser diode and heterojunction phototransistor. S. Noda, E. Yamada, T. Takayama and A. Sasaki p1069
Linewidth enhancement in distributed-feedback semiconductor lasers. M.-C. Amann p569
Localised temperature dynamics of GaAlAs laser facets investigated by Raman microprobe measurements. M.C. Krantz, H.J. Rosen and W. Lenth p990
Long-cavity, multi-electrode DFB lasers for coherent FSK systems. Y. Twu, S.J. Wang, C.Y. Kuo, J.D. Wynn, R.L. Brown, L.A. Gruezke, K.E. Strege, M.S. Lin and N.K. Dutta p708
Low temperature-stressed aging test of 1·3–1·45 μm laser diodes under high power operation. Y. Kawai and T. Yamada p53
Low threshold distributed Bragg reflector surface emitting laser diode with semiconductor air-bridge-supported top mirror. W. Hsin, G. Du, J.K. Gamelin, K.J. Malloy, S. Wang, J.R. Whinnery, Y.J. Yang, T.G. Dziura and S.C. Wang p307 e828

Low threshold highly efficient strained quantum well lasers at 1·5 micrometre wavelength. U. Koren, M. Oron, M.G. Young, B.I. Miller, J.L. De Miguel, G. Raybon and M. Chien p465

Low-threshold GRIN-SCH AlGaInAs 1·55 μm quantum well buried ridge structure lasers grown by molecular beam epitaxy. C. Kazmierski, M. Blez, M. Quillec, M. Allovon and B. Sermage p889

Low-threshold monomode ion-exchanged waveguide lasers in neodymium-doped BK-7 glass. E.K. Mwarania, L. Reekie, J. Wang and J.S. Wilkinson p1317

Measurement and theory of mode hopping in external cavity lasers. J. Mørk, M. Semkow and B. Tromborg p609 e1324

Miniature packaged actively mode-locked semiconductor laser with tunable 20 ps transform limited pulses. D.M. Bird, R.M. Fatah, M.K. Cox, P.D. Constantine, J.C. Regnault and K.H. Cameron p2086

Mode locking of a continuous wave neodymium doped fibre laser with a linear external cavity. P.G.J. Wigley, P.M.W. French and J.R. Taylor p1238

Mode locking of a semiconductor laser by self-synchronising optoelectronic feedback of the longitudinal mode beats. R. Nietzke, J. Sacher, W. Elsässer and E.O. Göbel p1016

Multichannel FSK transmission experiment at 565 Mbit/s using tunable three-electrode DFB lasers. N. Flaarønning, J.O. Frorud, M. Sotom, G. Vendrôme, G. Da Loura, J.M. Gabriagues, J. Jacquet, D. Leclerc and J. Benoit p869

Nd : MgO : $LiNbO_3$ self-frequency-doubled laser pumped by a flashlamp at room temperature. M. Gong, G. Xu, K. Han and G. Zhai p2062

New laser structure on semi-insulating substrate, grown by MOCVD, for high speed operation. R. Blondeau, D. Rondi, M. Krakowski, G. Glastre and G. Vilain p458

Nonlinear gain effects in strained-layer lasers. A. Ghiti and E.P. O'Reilly p1978

Novel distributed-feedback resonant-periodic-gain structure for vertical-cavity surface-emitting semiconductor lasers. M. Mahbobzadeh and M. Osiński p1716

Novel measurement technique of α factor in DFB semiconductor lasers by injection locking. R. Hui, A. Mecozzi, A. D'Ottavi and P. Spano p997

Novel method for centre wavelength tuning of silica waveguide type Mach–Zehnder multi/demultiplexers. H. Uetsuka, M. Kurosawa and K. Imoto p251

Novel optical frequency comb synthesis using optical feedback. P. Coppin and T.G. Hodgkinson p28

Operating characteristics of CW CO_2–N_2O laser. C.-M. Kim, S. Han, J.-K. Ji and Y. Kim p15

Optical steering of dual band microwave phased array antenna using semiconductor laser switching. W. Ng, A. Walston, G. Tangonan, J.J. Lee and I. Newberg p791

Optical travelling wave amplifiers with multi-section semiconductor-laser structures. R. Ludwig, M. Moehrle, M. Rosenzweig, R. Schnabel, N. Schunk and H.G. Weber p1704

Optimum facet reflectivity for high speed lasers. A. Mar, P.A. Morton and J.E. Bowers p1382 e1922

Over 7 nm (875 GHz) continuous wavelength tuning by tunable twin-guide (TTG) laser diode. S. Illek, W. Thulke, C. Schanen, H. Lang and M.-C. Amann p46

Passive mode-locking of monolithic InGaAs/AlGaAs double quantum well lasers at 42 GHz repetition rate. S. Sanders, L. Eng and A. Yariv p1087

PbS/PbSrS multi-quantum well laser emitting in the mid-infrared wavelength region. S. Takahashi, N. Koguchi, T. Chikyow, T. Kiyosawa, J. Fujiwara and K. Yoshihara p1715

Performance characteristics of high power CW, 1 cm wide monolithic AlGaAs laser diode arrays with a 2 mm total aperture width. M. Sakamoto, M.R. Cardinal, J.G. Endriz, D.F. Welch and D.R. Scifres p422

Phase modulation characteristics of 1·5 μm strained-layer multiple quantum well laser amplifiers. D. Reichenbach, C.E. Zah, N. Andreadakis, F.J. Favire, S.G. Menocal, R. Vodhanel, A. Yi-Yan and T.P. Lee p1858

Phase-locked two-dimensional arrays of implant isolated vertical cavity surface emitting lasers. H.-J. Yoo, J.R. Hayes, E.G. Paek, J.P. Harbison, L.T. Florez and Y.-S. Kwon p1944

Phase-locking of laser diodes. H.R. Telle and H. Li p858

Preliminary reliability studies of 1·55 μm graded index separate confinement buried heterostructure (GRINSCH) multiple quantum well (MQW) lasers grown by metalorganic vapour phase epitaxy (MOVPE). R.M. Redstall, A.P. Skeats, D.M. Cooper and A.L. Burness p1132

Reduction of thermal interference on lasing wavelength for DFB LD/EA modulator integrated light source. H. Tanaka, M. Suzuki and Y. Matsushima p2124

Reliable 1·3 μm gain guided stripe lasers grown by MOCVD using ethyldimethylindium as the In source. C. Blaauw, T.F. Devenyi, B. Capron, F.R. Shepherd and A.J. Springthorpe p1291

Residual and absolute timing jitter in actively mode-locked semiconductor lasers. D.J. Derickson, A. Mar and J.E. Bowers p2026

Room temperature CW tunable green upconversion holmium fibre laser. J.Y. Allain, M. Monerie and H. Poignant p261

Room temperature continuous wave operation of GaInP/AlInP visible-light laser with GaInP/AlInP superlattice confinement layer grown by gas source molecular beam epitaxy. A. Kikuchi, Y. Kaneko, I. Nomura and K. Kishino p1668

Room temperature vertical cavity GaAs/AlGaAs surface emitting injection laser. C. Wüthrich, J.H. James, J.D. Ganière and F.K. Reinhart p1600

SEM direct observation of the degradation in Ga(Al)As GRIN-SCH lasers grown on a silicon substrate. R.B. Martins, P. Henoc and B. Akamatsu p448

Short-wavelength (638 nm) room-temperature CW operation of InGaAlP laser diodes with quaternary active layer. M. Ishikawa, H. Shiozawa, Y. Tsuburai and Y. Uematsu p211

Simple model for calculation of distortion in an optical analogue subcarrier multiplexed CATV system. J.H. Angenent p2049

Single-quantum-well laser with 11·2 degree transverse beam divergence. Y.C. Chen, R.G. Waters and R.J. Dalby p1348

Spectral linewidth reduction by low spatial hole burning in 1·5 μm multi-quantum-well $\lambda/4$-shifted DFB lasers. K. Uomi, S. Sasaki, T. Tsuchiya, M. Okai, M. Aoki and N. Chinone p52

Spectrum stability of a broadband 1060 nm Nd-doped fibre laser. K. Fesler, M. Digonnet, K. Liu, B.Y. Kim and H.J. Shaw p870

Stabilisation of mode-locked pulses using travelling-wave semiconductor laser amplifier. A.J. Lowery and I.W. Marshall p104

Strained-layer 1·5 μm wavelength InGaAs/InP multiple quantum well lasers grown by chemical beam epitaxy. W.T. Tsang, M.C. Wu, L. Yang, Y.K. Chen and A.M. Sergent p2035

Surface emitting laser arrays with uniformly separated wavelengths. C.J. Chang-Hasnain, M.W. Maeda, N.G. Stoffel, J.P. Harbison, L.T. Florez and J. Jewell p940

Surface-emitting laser diode with distributed Bragg reflector and buried heterostructure. M. Ogura, S. Mukai, M. Shimada, T. Asaka, Y. Yamasaki, T. Seki and H. Iwano p18

Technique for alignment of semiconductor lasers to bevelled single-mode fibres. B.M. Foley, P. Melman and K.T. Vo p2118

Temperature and mechanical vibration characteristics of a miniature long external cavity semiconductor laser. S.A. Al-Chalabi, J. Mellis, M. Hollier, K.H. Cameron, R. Wyatt, J.E. Regnault, W.J. Devlin and M.C. Brain p1159

Temperature dependence of the second harmonic distortion of buried heterostructure distributed feedback lasers. S.J. Wang, A.B. Piccirilli, Y.J. Wang and N.K. Dutta p1095

Time-resolved chirp in mode-locked semiconductor lasers. A.J. Lowery p939

Top-surface-emitting GaAs four-quantum-well lasers emitting at 0·85 μm. Y.H. Lee, B. Tell, K. Brown-Goebeler, J.L. Jewell and J.V. Hove p710

Travelling-wave erbium fibre ring laser with 60 kHz linewidth. P.R. Morkel, G.J. Cowle and D.N. Payne p632

Tunable CW fibre Raman ring laser centred at 1·41 μm. E.J. Greer, P.G.J. Wigley and J.R. Taylor p579

Tunable single frequency operation of a diode laser pumped Nd : YAG microchip at 1·3 μm. F. Zhou and A.I. Ferguson p490

Two dimensional grating surface emitting laser arrays with wide lateral extent. G.A. Evans, N.W. Carlson, D.P. Bour, J.M. Hammer, M. Lurie, J.K. Butler, R. Amantea, S.K. Liew, J.B. Kirk, W.F. Reichert, R.K. DeFreez and D.J. Bossert p907

Two-section distributed feedback lasers for incoherent frequency-shift-keying transmission systems. S.J. Wang, Y. Twu, N.K. Dutta and R.L. Hartman p1243

Ultra-low-reflectivity semiconductor optical amplifiers without antireflection coatings. W. Rideout, R. Holmstrom, J. LaCourse, E. Meland and W. Powazinik p36

Uniform frequency modulation responses in narrow linewidth ($\lesssim$200 kHz) compact hybrid lasers. C.Y. Kuo, D.A. Ackerman, C.H. Henry, Y. Shani, M.I. Dahbura, R. Kistler and E.J. Wagner p270

Vertical integration of an $In_{0.15}Ga_{0.85}As$ modulation-doped field effect transistor and GaAs laser grown by molecular beam epitaxy. S.D. Offsey, P.J. Tasker, W.J. Schaff, L. Kapitan, J.R. Shealy and L.F. Eastman p350

Very high amplitude, minimal chirp optical pulse generation at 1·55 μm using multicontact DFBs and an erbium doped fibre amplifier. H. Sundaresan and G.E. Wickens p725

Very low threshold current AlGaInP/$Ga_xIn_{1-x}P$ strained single quantum well visible laser diode. T. Katsuyama, I. Yoshida, J. Shinkai, J. Hashimoto and H. Hayashi p1375

Wavelength-tunable single-frequency and single-polarisation Er-doped fibre ring-laser with 1·4 kHz linewidth. K. Iwatsuki, H. Okamura and M. Saruwatari p2033

Widely tunable Y-coupled cavity integrated interferometric injection laser. M. Schilling, H. Schweizer, K. Dütting, W. Idler, E. Kühn, A. Nowitzki and K. Wünstel p243

Yellow light (576 nm) lasing emission of GaInP/AlInP multiple quantum well lasers prepared by gas-source-molecular-beam-epitaxy. Y. Kaneko, A. Kikuchi, I. Nomura and K. Kishino p657

Yield analysis of non-AR-coated DFB lasers with combined index and gain coupling. K. David, G. Morthier, P. Vankwikelberge and R. Baets p238

$x^{(3)}$ measurements in a bistable GaAlAs Fabry–Perot amplifier. R. Calvani and R. Caponi p1513

LIGHT-EMITTING DIODES

Broadband high-density WDM transmission using superluminescent diodes. S.S. Wagner and T.E. Chapuran p696

Low temperature-stressed aging test of 1·3–1·45 μm laser diodes under high power operation. Y. Kawai and T. Yamada p53

Optically-coupled mirror-quantum well InGaAs-GaAs light emitting diode. D.G. Deppe, J.C. Campbell, R. Kuchibhotla, T.J. Rogers and B.G. Streetman p1665

Over 7 nm (875 GHz) continuous wavelength tuning by tunable twin-guide (TTG) laser diode. S. Illek, W. Thulke, C. Schanen, H. Lang and M.-C. Amann p46

Single quantum well edge emitting broadband LED. J. Mantz, H. Hager, E. Chan and C.S. Hong p1807

Surface-emitting laser diode with distributed Bragg reflector and buried heterostructure. M. Ogura, S. Mukai, M. Shimada, T. Asaka, Y. Yamasaki, T. Seki and H. Iwano p18

Two-phase clock driven self-scanning light emitting device (SLED). Y. Kusuda, S. Tanaka and K. Yamashita p1406

LINEAR SYSTEMS

2-MOSFET transresistor with extremely low distortion for output reaching supply voltages. Z. Wang p951 d2127

Derivation of the feedback taps of an LFSR from a sequence fragment. D.H. Green p1352

Iterative learning control of completely irregular plants with initial state shifting. B. Porter and S.S. Mohamed p106

Linear approximation of fractional transfer functions of distributed parameter systems. C.S. Hsu and D. Hou p1211

Novel method for linearising the power response of optical time domain reflectometers. M. Reich p1029 e1738

LITHOGRAPHY

Epitaxial lift-off of GaAs LEDs to Si for fabrication of opto-electronic integrated circuits. I. Pollentier, P. Demeester, A. Ackaert, L. Buydens, P. Van Daele and R. Baets p193

Fabrication of domain reversed gratings for SHG in $LiNbO_3$ by electron beam bombardment. R.W. Keys, A. Loni, R.M. De La Rue, C.N. Ironside, J.H. Marsh, B.J. Luff and P.D. Townsend p188

LOGIC AND LOGIC DESIGN

Interconnection-free set logic network based on a bio-device model. T. Aoki, M. Kameyama and T. Higuchi p1015

Multi-operand modulo addition using carry save adders. Ç.K. Koç and C.Y. Hung p361

New high-speed bipolar XOR gate with absolutely symmetrical circuit configuration. L. Schmidt and H.-M. Rein p430

Novel ternary JKL flip-flop. N. Zhuang and H. Wu p1145

SC and pass transistor combined circuits. H.-L. Ho and K.C. Smith p769

Some results on Reed-Muller coefficients. P. Suman p1026

LOGIC CIRCUITS

Algorithm for optimal layouts of CMOS complex logic modules. Y.-J. Kwon and C.-M. Kyung p1388

Double-barrier resonant tunnelling diode three-state logic. A. Sellai, M.S.

Raven, D.P. Steenson, J.M. Chamberlain, M. Henini and O.H. Hughes p61
Performance of an ECL-compatible 75Ω line driver/receiver realised in a 1·2 μm CMOS technology. J. Sevenhans, W. Bijker, P. Vorenkamp and M. Steyaert p764
Removal of sign-extension circuitry from Booth's algorithm multiplier–accumulators. N. Burgess p1413
Versatile silicon bipolar XOR gate for signal processing up to 8 Gbit/s. J. Hauenschild, H.-M. Rein, L. Schmidt and K. Wörner p114

LOGIC DEVICES

Double-barrier resonant tunnelling diode three-state logic. A. Sellai, M.S. Raven, D.P. Steenson, J.M. Chamberlain, M. Henini and O.H. Hughes p61
Extension of the T-gate concept to a hybrid U-gate architecture for ternary and higher order logic systems. J.A.C. Webb and S.J. Laverty p1629
Fault equivalence in PLAs and prevention design. B.-D. Liu and G.-T. Shaw p1925
GaAs MESFET differential pass-transistor logic. J.H. Pasternak and C.A.T. Salama p1597
Gallium arsenide pseudo-current-mode logic. R.A. Duncan, K.C. Smith and A.S. Sedra p2130

LOSSES

Bend performance of fibre-matched optical waveguides on InP. R.J. Deri, N. Yasuoka, M. Makiuchi, A. Kuramata and O. Wada p321
Comparison of full wave approaches for determinations of microstrip conductor losses for MMIC applications. E. Paleczny, D. Kinowski, J.F. Legier, P. Pribetich and P. Kennis p2076
Low loss fluoride fibre by reduced pressure casting. S.F. Carter, M.W. Moore, D. Szebesta, J.R. Williams, D. Ranson and P.W. France p2115
Matching fibres for low loss coupling into fibre amplifiers. M.J. Holmes, F.P. Payne and D.M. Spirit p2102
Skin effect losses of interconnect lines in frequency and time domain. W. Wlodarczyk and V. Besch p1237
Time domain CAD and measurements of lossy coupled lines. A. Zounon, P. Crozat and R. Adde p473
Very low-loss GeO_2-doped silica waveguides fabricated by flame hydrolysis deposition method. T. Kominato, Y. Ohmori, H. Okazaki and M. Yasu p327

LUMINESCENCE

Luminescent Er doped microparticles in a semiconductor matrix. P.N. Favennec, H. L'Haridon, D. Moutonnet, M. Salvi and A.C. Papadopoulo p1556

LUMINESCENT DEVICES

High efficiency 1·3 μm superluminescent diode with absorbing tapered waveguide. K. Magari, Y. Noguchi, K. Okamoto, H. Yasaka, H. Nagai and O. Mikami p1445

MAGNETIC DEVICES

DC B–H curve tracer with error correction and constant measuring and drawing speed using microcomputer. S. Kusui, M. Kosukegawa and M. Inoue p902
Magnetostatic wave mixer. P. Hyben, R. Ceskovic, P. Kabos, J. Cermak and A. Abraham p1994
Metallic glass ribbon probe for the measurement of the magnetic field, first and second order field gradients. M.D. Mermelstein and A. Dandridge p501
Microchannel plate intensifier response in transverse magnetic field. S.W. Allison, P.A. Ramos and G.T. Gillies p770

MAGNETIC STORAGE

Size limits on phased burst error correcting array codes. R.M. Goodman and M. Sayano p55
Two new equalisation schemes for high-density digital magnetic recording systems with quad-phase modulation code. J.W.M. Bergmans and S. Mita p13

MAGNETOSTATIC WAVES

Magnetostatic wave mixer. P. Hyben, R. Ceskovic, P. Kabos, J. Cermak and A. Abraham p1994

MATHEMATICAL TECHNIQUES

Application of the method of lines to cylindrical inhomogeneous propagation structures. M. Thorburn, A. Biswas and V.K. Tripathi p170
Calculation of phase shift sensitivity in polarimetric fibre sensors. D. Wong and P.L. Chu p607
Coarse-to-fine least squares stereo matching for 3-D reconstruction. F. Argenti and L. Alparone p812
Computational improvement in the calculation of the natural log of a square matrix. D.L. Cooper and S. Bingulac p861
Computer-aided design of array pattern. M.H. Er p2113
Determination of solutions to Bezout identity through eigenvalue placement. C.H. Fang and F.R. Chang p644
Dispersion characteristics of ring line through the conformal mapping approach. J.P. Fenelon and A. Papiernik p621
Effect of statistical variation on threshold voltage in narrow-channel MOSFETs. E.H. Li, C.K. Liu and H.C. Ng p1390
Estimation of instantaneous frequency using the discrete Wigner distribution. P. Rao and F.J. Taylor p246
Exact singular integral equation approach for planar transmission lines. Y. Huang, L. Xue and W. Lin p360
Explicit finite difference beam propagation method: Application to semiconductor rib waveguide Y-junction analysis. Y. Chung and N. Dagli p711
Fast algorithm for real joint time–frequency transformations of time-varying signals. S.-E. Qian and J.M. Morris p537
Fast calculation of co-occurrence matrix parameters for image segmentation. L. Alparone, F. Argenti and G. Benelli p23
Fast odd discrete cosine transform algorithms. S.C. Chan and K.L. Ho p503
Fuzzy algorithm for error-correcting estimation of radar signals. G. Guo and Q. Shen p1321
Novel mapping scheme for transforms with lengths equal to products of prime squares. D.P.-K. Lun and W.-C. Siu p21
Perturbation feedback method for analysing rectangular dielectric waveguides. Y. Cai, T. Mizumoto and Y. Naito p521
Radio propagation measurements at 850 MHz, 1·7 GHz and 4 GHz inside two dissimilar office buildings. D.M.J. Devasirvatham, M.J. Krain, D.A. Rappaport and C. Banerjee p445
Signal extrapolation from Hartley transform magnitudes. G.-S. Chen, J.-L. Wu and L.-S. Lee p793
Solutions of the SBS equations in single mode optical fibres and implications for fibre transmission systems. P. Bayvel and P.M. Radmore p434
Statistics of clear-air attenuation on satellite links at 20 and 30 GHz. G. Ortgies, F. Rücker and F. Dintelmann p358
Two-dimensional modified Cauer form: circuit and state space realisation. G.E. Antoniou, C.N. Manikopoulos and S.E. Mentzelopoulou p258

MATRIX ALGEBRA

Bearing estimation of coherent sources by circular spatial modulation averaging (CSMA) technique. B.L. Lim, S.K. Hui and Y.L. Lim p343
Hexagonally connected processor array for Jacobi-type matrix algorithms. M. Moonen and J. Vandewalle p400
Infinite families of quasiperfect and doubly quasiperfect binary arrays. J. Jedwab and C.J. Mitchell p294
Matrix and vector multiplications using a 2½-dimensional systolic array. S.P.S. Lam p1453
Polarimetric optimisation based on the target covariance matrix. S.R. Cloude p1670
Systolic band-matrix multipliers. W. Luk p403
Two-dimensional modified Cauer form: circuit and state space realisation. G.E. Antoniou, C.N. Manikopoulos and S.E. Mentzelopoulou p258
Variational finite element analysis of dielectric waveguides with no spurious solutions. F.A. Fernandez and Y. Lu p2125

MEASUREMENT

AC Josephson effect in superconducting niobium nitride tunnel junctions at up to 2·5 THz. M.C. Wicks, P.R. Haycocks and T. Hori p610
Autocorrelation at 1·3–1·5 μm using POM crystal. L. Chusseau, D. Bouchon, L. Duvillaret and J.M. Lourtioz p589
Calculation of phase shift sensitivity in polarimetric fibre sensors. D. Wong and P.L. Chu p607
Comparison of a diffraction based radiowave propagation model with measurements. P. Eggers and P. Barry p530 e1097
Dimensional correction of high dielectric and magnetic constants determined by S parameters measurements. J.C. Henaux and P. Crozat p1151
Electrical test structure for measuring polysilicon-to-active mask misalignment. M. Syrzycki p1009
Electronically-scanned white light interferometry with enhanced dynamic range. S. Chen, B.T. Meggitt and A.J. Rogers p1663
Fabrication and properties of large core, high NA, high Nd^{3+} content multimode optical fibres for temperature sensor applications. P.L. Scrivener, P.D. Maton, A.P. Appleyard and E.J. Tarbox p872
Field test measurement for 128 Kbit/s QPSK signal transmission and delay time spread in 1·5 GHz-band land mobile radio. T. Furuno and S. Ogose p789
Impedance of TEM cells with equipment under test. K.M. Huang and W. Lin p560
Intensity to frequency conversion technique in intensity modulated fibre optic sensing systems. G. Adamovsky and T.W. Carr p1450
Interferometric fibre displacement/strain sensor based on source coherence synthesis. T.A. Berkoff and A.D. Kersey p452
Localised temperature dynamics of GaAlAs laser facets investigated by Raman microprobe measurements. M.C. Krantz, H.J. Rosen and W. Lenth p990
Measurement and theory of mode hopping in external cavity lasers. J. Mørk, M. Semkow and B. Tromborg p609 e1324
Measurement of polarisation beat length in single-mode optical fibres with a polarisation modulator. V.N. Filippov, O.I. Kotov and V.M. Nikolayev p658
Metallic glass ribbon probe for the measurement of the magnetic field, first and second order field gradients. M.D. Mermelstein and A. Dandridge p501
Neural network for estimation of parameters of sinewave. S. Osowski p689
Nondestructive measurement of phase velocity of surface acoustic waves using matched filters. M. Hirabayashi p411
Nonsteady-state photovoltage in crystals with long photoconductivity relaxation times. I.A. Sokolov and S.I. Stepanov p1275
Novel electronic scanner for coherence multiplexing in a quasi-distributed pressure sensor. S. Chen, B.T. Meggitt and A.J. Rogers p1367 e1738
Novel gate voltage ramping technique for the characterisation of metal-oxide-semiconductor capacitor charge trapping properties. W. Ting, G.Q. Lo and D.L. Kwong p1257
Novel measurement technique of α factor in DFB semiconductor lasers by injection locking. R. Hui, A. Mecozzi, A. D'Ottavi and P. Spano p997
Novel robust sensor for surface edge location in robotic applications. I.P.W. Sillitoe and S. Szumko p1811
Optical fibre microbending sensors by micromachining techniques. J.H.C. Chao and G.W. Neudeck p513
PC sampling oscillograph for subnanosecond time region. J. Červeň and R. Kukuča p1950
Passive electrical vernier for measuring mask misalignment. A.J. Walton, W. Gammie, M. Fallon, D. Ward and R.J. Holwill p1173
Performance characteristics of high power CW, 1 cm wide monolithic AlGaAs laser diode arrays with a 2 mm total aperture width. M. Sakamoto, M.R. Cardinal, J.G. Endriz, D.F. Welch and D.R. Scifres p422
Photon timing OTDR: A multiphoton backscattered pulse approach. G. Ripamonti, M. Ghioni and S. Vanoli p1569
Radio propagation measurements at 850 MHz, 1·7 GHz and 4 GHz inside two dissimilar office buildings. D.M.J. Devasirvatham, M.J. Krain, D.A. Rappaport and C. Banerjee p445
Reduction of internal current measurements within the failure bounds analogue diagnosis scheme. C. Garrett p583
SEM direct observation of the degradation in Ga(Al)As GRIN-SCH lasers grown on a silicon substrate. R.B. Martins, P. Henoc and B. Akamatsu p448
Short delay measurement by polarity cross correlation. R.M. Henry and L. Zhang p202
Simple microprocessor-based load angle measurement instrument. A.M. Alsuwailem p1336
Thermal resistivity of quaternary solid solutions InGaSbAs and GaAlSbAs lattice-matched to GaSb. W. Both, A. Bochkarev, A. Drakin and B. Sverdlov p418

MEMORIES

13 Gb/s D-Type flip-flop IC using GaAs MESFETs. M. Ohhata, Y. Yamane, T. Enoki, S. Sugitani, N. Kato, K. Hagimoto and M. Hirayama p1039
Analysis of 'D type' flip-flop frequency changers. D.I. Shaw, J.C. Bennett and A.M. Clements p1995
Behaviour of circuit-switched multistage networks in presence of memory hot

spot. T.-H. Lee d546
Cache memory replacement policy for a uniprocessor system. L. Colagiovanni and A. Shaout p509
Calculating the upper and lower bounds on capacity of two modified Hebbian trained Hopfield networks. P. Houselander and J.T. Taylor p1266
Comparing performance of Hebbian- and delta-trained Hopfield networks. P.K. Houselander and J.T. Taylor p85
Exponential bidirectional associative memories. Y.-J. Jeng, C.-C. Yeh and T.D. Chiueh p717
High speed GaAs 32 × 8 embeddable dual port SRAM register array for 200 Mbyte/s packet switching applications. K.S. Lowe p516
High-performance algorithmic switched-current memory cell. C. Toumazou, N.C. Battersby and C. Maglaras p1593 e1922
Improving the Hamming binary associative memory. P. Houselander and J.T. Taylor p705
Optimal encoding of microcommands in microprogrammed processors. I.-C. Park, S.-K. Hong and C.-M. Kyung p393
Regulated cascode switched-current memory cell. C. Toumazou, J.B. Hughes and D.M. Pattullo p303
Throughput performance of multistage interconnection networks in presence of multiple memory hot spots. T.-H. Lee p536
Weight error sensitivity of fixed point attractors in associative memory networks. R. Perfetti p1985

METAL-INSULATOR-SEMICONDUCTOR STRUCTURES AND DEVICES

10 Gbit/s optical transmitter module with MQW DFB-LD and DMT driver IC. T. Suzaki, Y. Suzuki, H. Yamada, S. Fujita, H. Hida, M. Kitamura and M. Shikada p151

METAL-OXIDE-SEMICONDUCTOR STRUCTURES AND DEVICES

Automatic switching of substrate bias or well bias in CMOS-ICs. U. Gatti, V. Liberali, F. Maloberti and P. O'Leary p1381
Effect of statistical variation on threshold voltage in narrow-channel MOSFETs. E.H. Li, C.K. Liu and H.C. Ng p1390
Electrical transient study of negative resistance in SOI MOS transistors. O. Le Néel and M. Haond p73
Engineering model of MOS transistors for the 60–300 K temperature range. C.-L. Huang and G.S. Gildenblat p365
Evaluation of currents in the fA range. P. Girard and P. Nouet p844
Frequency dependence of admittance of distributed surface states in MOS structures. S.R. Dhariwal and B.M. Deoraj p2110
Highly reliable thin nitrided SiO_2 films formed by rapid thermal processing in an N_2O ambient. H. Fukuda, T. Arakawa and S. Ohno p1505
Low temperature dependence of the hole impact ionisation constants determined from PMOS transistors. M.J. Deen and Z.P. Zuo p1975
New submicron MOSFET structural concept for suppression of hot carriers. A.F. Tasch, H. Shin and C.M. Maziar p39
Novel linearisation technique for implementing large-signal MOS tunable transconductor. Z. Wang p138

MICROPROCESSORS AND MICROPROCESSOR APPLICATIONS

Cryogenic performance of a CMOS 32-bit microprocessor subsystem built on the silicon-substrate-based multichip packaging technology. M.S. Lin, A.S. Paterson and H.T. Ghaffari p1025
Factorisation attack on certain server-aided computation protocols for the RSA secret transformation. A. Shimbo and S. Kawamura p1387
New transmitter-receiver for power system protection based on microprocessor. S.F. Chu and Z.D. Gao p1006
Simple microprocessor-based load angle measurement instrument. A.M. Alsuwailem p1336

MICROSCOPES AND MICROSCOPY

Experimental verification of image detection in highly scattering media using antenna properties of optical heterodyne microscope scheme. M. Toida, M. Kondo, T. Ichimura and H. Inaba p700

MICROSTRIP

40 GHz measurement on InP/air gap line by picosecond electro-optic sampling. S. Loualiche, F. Clerot and G. Audibert p266
Active patch antenna element for array applications. R.A. York, R.D. Martinez and R.C. Compton p494
Analysis of arbitrarily shaped coax-fed microstrip antennas with thick substrates. D. Zheng and K.A. Michalski p794 e1324
Analysis of dispersion characteristics of cylindrical microstrip line with method of lines. K. Gu and Y. Wang p748
Aperture coupled microstrip antenna element design. R. Oostlander, Y.M.M. Antar, A. Ittipiboon and M. Cuhaci p224
Approximate analysis of electromagnetically coupled microstrip dipoles. M. Kominami, N. Yakuwa and H. Kusaka p1901
Asymptotic method in prediction of E plane radiation pattern of rectangular microstrip patch antennas on finite ground. P. Vaudon, A. Reineix and B. Jecko p956
Bandpass characteristics of split-modes in asymmetric ring resonators. G.K. Gopalakrishnan and K. Chang p774
Characterisation of microstrip open-end with rectangular and trapezoidal cross-section. C.J. Railton and J.P. McGeehan p685
Circular polarisation characteristics of stacked microstrip antennas. R.Q. Lee, T. Talty and K.F. Lee p2109
Comparison of full wave approaches for determinations of microstrip conductor losses for MMIC applications. E. Paleczny, D. Kinowski, J.F. Legier, P. Pribetich and P. Kennis p2076
Coplanar-waveguide/microstrip probe coupler and applications to antennas. R.N. Simons and R.Q. Lee p1998
Elliptical microstrip antenna on ferrite substrate. S.S. Pattnaik, R.K. Mishra and N. Das p1906
Frequency dependent transmission characteristics of microstrip lines on the finite width substrate or near a substrate edge. A. Rong and S. Li p782
Full wave finite element analysis of slot-coupled microstrip antennas. S.-G. Pan and I. Wolff p1465
Hankel transform domain analysis of dual-frequency stacked circular disc microstrip antenna. Z. Fan and K.F. Lee p1467
High voltage microwave DC block for microstrip ground planes. T.E. Koscica p1287
Inclusion of dispersive effects of microstrip lines in formulation using state-space approach of nonlinear microwave circuits. J.I. Alonso and F. Pérez p795
Large bandwidth aperture-coupled microstrip antenna. F. Croq and A. Papiernik p1293
Measurements of crosstalk between closely-packed lossy microstrips on silicon substrates. M.S. Lin, A.H. Engvik and J.S. Loos p714
Measurements of pulse propagation on unterminated lossy microstrips with small dimensions. M.S. Lin, A.H. Engvik and K.L. Tai p747
Microstrip antennas with integrated fibre optic feeds. D.M. Pozar, R.W. Jackson and A. Svitak p1889
Microstrip balanced diode mixers for X-band frequencies. B. Mayer and R. Knöchel p1272
Microstrip inversion transition. T.E. Koscica p2051
Microstrip subarray with coplanar and stacked parasitic elements. K.F. Lee, R.Q. Lee and T. Talty p668
Modal current distributions on closely coupled microstrip lines: a comparative study of the SDA basis functions. C.-K.C. Tzuang and J.-T. Kuo p464
Modelling of arbitrary shaped M/S patch antennas in multiple substrate media. M.J. Notter and C.G. Parini p50
Modelling of wideband proximity coupled microstrip array elements. J.S. Herd p1282
New broadband branchline coupler. B. Mayer p1477
New model for time domain simulation of lossy coupled lines. K.-H. Wirth p1723
New radiating edges coupling model for the gap between two rectangular microstrip patch antennas. Y.K. Cho, J.P. Hong and H. Son p1295
Optimum dielectric overlay thickness for equal even- and odd-mode phase velocities in coupled microstrip circuits. J.L. Klein and K. Chang p274
Proposed ultrahigh frequency microstrip utilising buried silicide groundplane. K.W. Goossen, A.E. White and K.T. Short p49 e555 e555
Radiation of arbitrary shape symmetrical patch antenna coupled with a director. G. Dubost, S. Desclos and A. Zerguerras p1539
Resonant frequency of wedge shaped microstrip antenna. R.K. Mishra and S.S. Pattnaik p912
Rigorous dispersive analysis of skin effects on a printed microstrip line containing finite conductor losses. C.K.C. Tzuang and W.K. Wang p1334
Rigorous feed model for coaxially fed microstrip antenna. R.C. Hall and J.R. Mosig p64 e345
Simple expression of rectangular patch's resistance at resonance. A. Khellaf, D. Thouroude and J.P. Daniel p1188
Strip edge shape effects on conductor loss calculations using the Lewin/Vainshtein method. E.L. Barsotti, J.M. Dunn and E.F. Kuester p983
Synthesis procedure for active integrated radiating elements. V.F. Fusco and H.O. Burns p263
Time domain CAD and measurements of lossy coupled lines. A. Zounon, P. Crozat and R. Adde p473

MICROWAVE AMPLIFIERS

94 GHz InP MMIC five-section distributed amplifier. R. Majidi-Ahy, M. Riaziat, C. Nishimoto, M. Glenn, S. Silverman, S. Weng, Y.C. Pao, G. Zdasiuk, S. Bandy and Z. Tan p91
New generation MMIC amplifier using InGaAs/InAlAs HEMTs. M. Weiss, G.I. Ng and D. Pavlidis p264

MICROWAVE ANTENNAS

Dielectric resonator antenna using aperture coupling. J.T.H. St. Martin, Y.M.M. Antar, A.A. Kishk, A. Ittipiboon and M. Cuhaci p2015
Helical antenna and spiral antenna with fast switch selection of the polarisation sense. G. Mönich and B. Littmann p1918
Optical beam former for phased arrays with independent control of radiated frequency and phase. R. Benjamin, C.D. Zaglanikis and A.J. Seeds p1853
Optical steering of dual band microwave phased array antenna using semiconductor laser switching. W. Ng, A. Walston, G. Tangonan, J.J. Lee and I. Newberg p791
Sidelobe suppression in an *E*-plane sectoral horn antenna. O.W. Ata, T.M. Benson and A. Marincic p231

MICROWAVE CIRCUITS AND SYSTEMS

2.75 GHz–4.75 GHz QPSK modulator with low amplitude and phase errors. S. Kumar and G. Wells p961
25 GHz dielectric resonantor oscillator using an AlGaAs/GaAs HBT. K. Ogawa, H. Ikeda, T. Ishizaki, K. Hashimoto and Y. Ota p1514
Accurate modelling of unilateral finline–coplanar waveguide transition. A. Rong p1123
Application of Kramers–Kronig transform to determination of cavity impedance for both small and large couplings. Q. Min, K.Z. Xue and P.H. Wu p44
BER improvement due to transversal equaliser in trellis-coded multi-level QAM digital microwave radio. H. Takanashi, S. Aikawa and Y. Nakamura p406
Boundary element method for modelling MIC devices. K.-L. Wu and J. Litva p518
Characterisation of microstrip open-end with rectangular and trapezoidal cross-section. C.J. Railton and J.P. McGeehan p685
Comparison of three numerical treatments for the open-ended coaxial line sensor. S. Jenkins, T.E. Hodgetts, G.T. Symm, A.G.P. Warham, R.N. Clarke and A.W. Preece p234
Computer design of broadband lumped component microwave phase shifter amplifiers. A.J. Baden Fuller and M. Runham p1849
Effects of finite metallisation thickness and substrate supporting grooves on the characteristics of E plane strip in a finline. A. Rong and S. Li p760
Exact computation of two port noise parameters. G. Vasilescu, G. Alquie and M. Krim p1889
Expanding the power-handling capabilities of harmonic-balance analysis by a parametric formulation of the MESFET model. V. Rizzoli and A. Neri p1359
GaAs W-band impatt diodes for very low-noise oscillators. H. Eisele p109
Generalised theory of a non-TEM transmission line taper without discontinuities. J.C. Coetzee and J.A.G. Malherbe p1549 e2056
Inclusion of dispersive effects of microstrip lines in formulation using state-space approach of nonlinear microwave circuits. J.I. Alonso and F. Pérez p795
Microstrip balanced diode mixers for X-band frequencies. B. Mayer and R. Knöchel p1272
Microwave scattering by metal cubes and the effect of perturbing the cube geometry. L.J. Auchterlonie, P.N. Fletcher and A.L. Hume p295
New broadband branchline coupler. B. Mayer p1477
Noise tuning of GaAs-MESFET oscillators. L. Kreischer p315
Novel method of DRO frequency tuning with varactor diode. N. Popović p1162
Novel power combining technique for MMIC oscillators. S.P. Stapleton, M.J. Deen and R.H.S. Hardy p300
Self-consistent simulation of a high-power 73 GHz integrated IMPATT oscillator. W. Anzill, T. Goeller, F.X. Kaertner, P. Russer and J. Buechler p1697
Verification of waveguide-type optical circulator operation. T. Mizumoto, H.

Chihara, N. Tokui and Y. Naito p199

MICROWAVE DEVICES AND COMPONENTS

0GaAs–AlGaAs HBT with carbon doped base layer grown by MOMBE. F. Ren, C.R. Abernathy, S.J. Pearton, T.R. Fullowan, J. Lothian and A.S. Jordan p724
Analysis of dispersion characteristics of cylindrical microstrip line with method of lines. K. Gu and Y. Wang p748
Asymmetric coplanar-strip transmission lines for MMIC and integrated optic applications. S.S. Gevorgian and I.G. Mironenko p1916
Asymmetric resonant tunnelling diodes as microwave detectors. R.T. Syme, M.J. Kelly, A. Condie and I. Dale p1904
Bandpass characteristics of split-modes in asymmetric ring resonators. G.K. Gopalakrishnan and K. Chang p774
Chiroshield: A Salisbury/Dallenbach shield alternative. D.L. Jaggard, N. Engheta and J. Liu p1332
Complex codes in lossless nonreciprocal finline. C.-K.C. Tzuang, C.-Y. Lee and J.-T. Kuo p1919
DC and microwave performance of OMVPE-grown AlInAs/InP HEMTs. L. Aina, M. Serio, M. Mattingly, E. Hempfling and H. Chien p1912
Experimental study of microwave reflection gain of AlAs/GaAs/AlAs quantum well structures. S.P. Stapleton, M.J. Deen, E. Berolo and R.H.S. Hardy p84
Frequency dependent transmission characteristics of microstrip lines on the finite width substrate or near a substrate edge. A. Rong and S. Li p782
Frequency multiplication using resonant tunnelling diode with output at sub-millimetre wavelengths. R. Bouregba, D. Lippens, L. Palmateer, E. Bockenhoff, M. Bogey, J.L. Destombes and A. Lecluse p1804
Gallium arsenide MBE structure comprising mixer diodes and FETs for monolithic millimetre-wave receivers. J.A. Archer p384
High microwave performance ion-implanted GaAs MESFETs on InP substrates. M. Wada and K. Kato p197
High performance $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As$ HFETs. H. Dämbkes, P. Marschall, Y.H. Zhang and K. Ploog p488
High-efficiency GaAs microwave power MESFETs with an n^+n^-n doping formed by buried-shallow-implant (BSI). S.G. Liu, G.C. Taylor, J. Klatskin, R.L. Camisa and D.R. Capewell p1373
Magnetostatic wave mixer. P. Hyben, R. Ceskovic, P. Kabos, J. Cermak and A. Abraham p1994
Microwave conductivity of optically excited gap in a semiconductor microstrip. S.S. Gevorgian p1921
Modal current distributions on closely coupled microstrip lines: a comparative study of the SDA basis functions. C.-K.C. Tzuang and J.-T. Kuo p464
Monolithic InP cascode HEMT distributed amplifier from 5 to 40 GHz. C. Yuen, Y.C. Pao, M. Day, C. Nishimoto, M. Glenn, S. Bandy and G. Zdasiuk p1411
Novel integral heatsink structures for power MMICs. P.R. Bestwick, I. Davies and K.C. Vanner p1050
Novel power combining technique for MMIC oscillators. S.P. Stapleton, M.J. Deen and R.H.S. Hardy p300
Optimum dielectric overlay thickness for equal even- and odd-mode phase velocities in coupled microstrip circuits. J.L. Klein and K. Chang p274
Selective plasma etching of Si from GaAs-on-Si wafers for microwave via-hole formation. G.W. Turner, C.L. Chen, M.K. Connors, L.J. Mahoney and W.L. McGilvary p854
Self-aligned 0·25 μm W/Ti/Au gate process for high-performance pseudomorphic InAlAs/InGaAs HEMT. P.S.D. Lin, W.-P. Hong, O.-H. Kim, R. Bhat, B. Van Der Gaag and H. Schumacher p763
Slow wave propagation using interconnexions for IC technologies. P.G. Gammand and D. Bajon p1443
Structures and microwave losses in Ni/Cu/Ni/Au coatings on alumina. L.G. Bhatgadde and D. Choudhury p1203
Superior microwave performance of InGaAs JFETs grown by MBE. D. Trommer, A. Umbach, W. Passenberg, G. Mekonnen and G. Unterbörsch p734
Transmission characteristics of suspended striplines with finite metallisation thickness and substrate supporting grooves. A. Rong p431
Verification of waveguide-type optical circulator operation. T. Mizumoto, H. Chihara, N. Tokui and Y. Naito p199
Very high frequency performance of nanometre scale GaAs MESFETs. J.A. Adams, I.G. Thayne, M.R.S. Taylor, C.D.W. Wilkinson, S.P. Beaumont, N.P. Johnson, A.H. Kean and C.R. Stanley p1019
W-band monolithic oscillator using InAlAs/InGaAs HEMT. Y. Kwon, D. Pavlidis, M. Tutt, G.I. Ng, R. Lai and T. Brock p1425

MICROWAVE FILTERS

TM triple-mode microwave filter. S.-L. Lai and W.-G. Lin p2112

MICROWAVE LINKS

Simple method to calculate the maximum user density for microwave point-to-point links. C. Shepherd, G. Gibson and D. Hayes p1554

MICROWAVE MEASUREMENT

275 GHz 3-mask integrated GaAs sampling circuit. R.Y. Yu, M. Case, M. Kamegawa, M. Sundaram, M.J.W. Rodwell and A.W. Gossard p949
Application of Kramers–Kronig transform to determination of cavity impedance for both small and large couplings. Q. Min, K.Z. Xue and P.H. Wu p44
Comparison of three numerical treatments for the open-ended coaxial line sensor. S. Jenkins, T.E. Hodgetts, G.T. Symm, A.G.P. Warham, R.N. Clarke and A.W. Preece p234
Enhanced microwave characterisation technique for cryogenic temperatures. J.W. Smuk, M.G. Stubbs and J.S. Wight p2127
Microwave scattering by metal cubes and the effect of perturbing the cube geometry. L.J. Auchterlonie, P.N. Fletcher and A.L. Hume p295

MICROWAVES

$7Ba(Zn_{1/3}Ta_{2/3})O_3$–$Ba(Cd_{1/3}Nb_{2/3})O_3$ dielectric ceramics with low microwave loss. Z.-L. Zhao, S.-L. Lai and A.-S. Liu p1605
CW mm-wave GaAs TUNNETT diode. M. Pöbl, C. Dalle, J. Freyer and W. Harth p1540
Microwave scattering by metal cubes and the effect of perturbing the cube geometry. L.J. Auchterlonie, P.N. Fletcher and A.L. Hume p295
Tapered slot antenna analysis with 3-D TLM method. F. Ndagijimana, P. Saguet and M. Bouthinon p468

MIXERS

AC Josephson effect in superconducting niobium nitride tunnel junctions at up to 2·5 THz. M.C. Wicks, P.R. Haycocks and T. Hori p610
Magnetostatic wave mixer. P. Hyben, R. Ceskovic, P. Kabos, J. Cermak and A. Abraham p1994

MOBILE RADIO SYSTEMS

'Fibre/radio' for the provision of cordless/mobile telephony services in the access network. A.J. Cooper p2054
Improved ICMA/CD protocol in packet mobile radio networks. J. Song and M. Kim p182
Modified scatterer distribution model for fast fading mobile communication channel. I. Crohn, E. Bonek and H. Weinrichter p1575
New adaptive Viterbi detector for fast-fading mobile-radio channels. E. Dahlman p1572
Optimal noncoherent detection of PSK signals. D. Makrakis and K. Feher p398
Propagation measurements at 1·7 GHz for microcellular urban communications. R. Davies, A. Simpson and J.P. McGeehan p1053

MODELLING

Approximate analytical model for the poly-silicon thin film transistor. M.J. Izzard, P. Migliorato and W.K. Milne p1284
Approximate formulas for step discontinuities in circular waveguides. C. Sabatier, R. Behe and P. Brachat p173
Autoregressive modelling of an indoor radio channel. S.J. Howard and K. Pahlavan p816
Boundary element method for modelling MIC devices. K.-L. Wu and J. Litva p518
CAD-oriented cavity model for rectangular patches. D. Thouroude, M. Himdi and J.P. Daniel p842
Calculation of third order intermodulation spectrum. Y.-H. Lau and D.J. Skellern p1776
Continuous adaptive speech analysis based on a time-varying ARMA model. B.K. Lim and C.K. Un p674
Determination of solutions to Bezout identity through eigenvalue placement. C.H. Fang and F.R. Chang p644
Electrical method for measuring emitter depth of shallow bipolar transistors. I.R.C. Post and P. Ashburn p30
Engineering model of MOS transistors for the 60–300 K temperature range. C.-L. Huang and G.S. Gildenblat p365
Exact singular integral equation approach for planar transmission lines. Y. Huang, L. Xue and W. Lin p360
Fast odd discrete cosine transform algorithms. S.C. Chan and K.L. Ho p503
Fault modelling of ECL devices. S.M. Menon, A.P. Jayasumana and Y.K. Malaiya p1105
Ground-state and excited-state absorption in rare-earth doped optical fibres. M. Monerie, T. Georges, P.L. Francois, J.Y. Allain and D. Neveux p320
Heavily doped emitter as a lossy transmission line. D. Jankovic p675
Method for modelling free space boundaries in TLM simulations. N.R.S. Simons and E. Bridges p453
Minimal state space realisation of product factorable 2-D systems. G.E. Antoniou p1232
Modal current distributions on closely coupled microstrip lines: a comparative study of the SDA basis functions. C.-K.C. Tzuang and J.-T. Kuo p464
Model minimisation for electron devices using simulated annealing in conjunction with parameter extraction. M.-K. Vai, D. Ng and S. Prasad p892
Model reduction by least-squares moment matching. T.N. Lucas and I.F. Beat p1213
Model reduction for discrete time systems. R. Unnikrishnan and A. Gupta p282
Modelling DC characteristics of GaAs MESFET devices using a simple and accurate analytic tool. S.A. Ibrahim and S. El-Rabaie p1892
Modelling of arbitrary shaped M/S patch antennas in multiple substrate media. M.J. Notter and C.G. Parini p50
Modelling of electron mobility in silicon MOS inversion and accumulation layers at liquid helium temperature. I.M. Hafez, A. Emrani, G. Ghibaudo and F. Balestra p1633
Modelling of materials with electric and magnetic losses with the symmetrical condensed TLM method. F.J. German, G.K. Gothard and L.S. Riggs p1307
Monte Carlo comparison of heterojunction cathode Gunn oscillators. C. Lee and U. Ravaioli p425
Neural network approach for the two-dimensional assignment problem. K.B. Sriram and L.M. Patnaik p809
New distributed package model for the dual gate FET. H. Xue, M.J. Howes and C.M. Snowden p1207
Optimal property of class of finite-energy signals with application to estimation of duration, power and amplitude of transients. L.C. Calvez, P. Vilbe and J.C. Boulbry e219 e219
Periodically time-varying two-dimensional systems. D.C. McLernon p412
Potential use of optimal polarisations in sensing the canting angle distribution of raindrops. A.P. Agrawal p157
Radio propagation over trapezoidal plateau with sloping front face. J. Gong, T.S.M. Maclean and Z. Wu p604
Rigorous feed model for coaxially fed microstrip antenna. R.C. Hall and J.R. Mosig p64 e345
Rigorous theoretical study of longitudinally magnetised partially filled TEM phase shifter. J.W. Tao, B. Chan and H. Baudrand p1329
Silicon implementation of a function of visual peripheral processes. H. Li and C.-H. Chen p2013
Simulation of EPROM programming characteristics. T. Urai, J. Frey, Z.Z. Peng and N. Goldsman p716
Solution of Poisson equation in p-$Al_yGa_{1-y}As$/p-$Al_{0.45}Ga_{0.55}As$/n-GaAs structures. S.C. Kwok p894
Some improvements to conventional importance sampling techniques for coded systems using Viterbi decoding. S.X. Chen, P.J. Smith, M. Shafi and D. Vere-Jones p802
Stabilisation of mode-locked pulses using travelling-wave semiconductor laser amplifier. A.J. Lowery and I.W. Marshall p104
Statistical AR models for the frequency selective indoor radio channel. K. Pahlavan and S.J. Howard p1133
Superposition technique for the generalised stochastic Petri net modelling of degradable systems. J. Hsieh and D.R. Ucci p942
Time domain CAD and measurements of lossy coupled lines. A. Zounon, P. Crozat and R. Adde p473
Using constant base current as a boundary condition for one-dimensional AlGaAs/GaAs heterojunction bipolar transistor simulation. L.L. Liou and C.I. Huang p1501
Yield analysis of non-AR-coated DFB lasers with combined index and gain coupling. K. David, G. Morthier, P. Vankwikelberge and R. Baets p238

MODULATION

2.75 GHz–4.75 GHz QPSK modulator with low amplitude and phase errors. S. Kumar and G. Wells p961

565 Mbit/s optical DPSK and PSK heterodyne transmission experiment using Nd : YAG lasers at 1·3 μm. A. Schoepflin p255
Construction of block modulation codes over rings for fading channels. B. Vucetic, L. Zhang and G. Khachatrian p2020
Effect of initial conditions on limit cycle performance of second order sampled data sigma delta modulator. N. Bridgett and C.P. Lewis p817
Fast wavelength switching and simultaneous FSK modulation using tunable DBR laser. H. Kobrinski, M.P. Vecchi, T.E. Chapuran, J.B. Georges, C.E. Zah, C. Caneau, S.G. Menocal, P.S.D. Lin, A.S. Gozdz and F.J. Favire p308
Fundamental limitation on large-signal modulation of semiconductor lasers and its implications for lightwave transmission. G.P. Agrawal p916
Laser diode modulation of 10·6 μm radiation in GaAs/AlGaAs quantum wells. D.D. Yang, P. Boucaud, F.H. Julien, L. Chusseau, J.-M. Lourtioz and R. Planel p1531
Low voltage InGaAs/InP multiple quantum well reflective Fabry–Perot modulator. A.J. Moseley, J. Thompson, M.Q. Kearley, D.J. Robbins and M.J. Goodwin p913
Multitone jamming of hybrid SFH/DS-MFSK communication systems. M.A. Laxpati p323
Noise performance comparison for third and fourth order cascaded sigma–delta modulators having parameter tolerance errors. M.I. Mathew and C.P. Lewis p158
Novel high precision alignment technique for polarisation maintaining fibres using a frequency modulated tunable laser. A. Ebberg and R. Noé p2009
Novel type of baseband phase-reversal electrode for optical modulators with linear phase response. A. Djupsjöbacka p318
Optimum optical modulation index of laser transmitters in SCM systems. K. Alameh and R.A. Minasian p1273
Packaged 2 × 2 array of InGaAs/InP multiple quantum well modulators grown by double-sided epitaxy. M.A.Z. Rejman-Greene and E.G. Scott p946
Performance evaluation of multilevel polarisation shift keying modulation schemes. S. Benedetto and P. Poggiolini p244
Performance evaluation of polarisation shift keying modulation schemes. S. Benedetto and P. Poggiolini p256
Photocurrent saturation in short-period superlattice modulators. K.W. Goossen, J.E. Zucker, I. Bar-Joseph, J.M. Kuo, R.M. Kopf, D.A.B. Miller and D.S. Chemla p736
Reduced state sequence detection of full response continuous phase modulation. A. Svensson p652
Spectral analysis of waiting time jitter in the presence of stuff threshold modulation. R.G. Kusyk, T.E. Moore and W.A. Krzymien p526
Strained-layer InGaAs/InAlAs multiple quantum wells for efficient optical waveguide modulation at 1·55 μm. E. Bigan, M. Allovon, M. Carre and A. Carenco p355
Surface transverse wave based FM modulator/demodulator. I.D. Avramov, P.J. Edmonson and P.M. Smith p364
Unrepeatered 2·4 Gbit/s transmission experiment over 250 km of step-index fibre using erbium power amplifier. E.G. Bryant, S.F. Carter, A.D. Ellis, W.A. Stallard, J.V. Wright and R. Wyatt p528
Use of a fibre loop reflector as downstream receiver and upstream modulator in passive optical network. G. Nicholson p827

MODULATORS

Compact low-voltage InGaAs/InAlAs multiple quantum well waveguide interferometers. J.E. Zucker, K.L. Jones, T.Y. Chang, N. Sauer, B. Tell, K. Brown-Goebeler, M. Wegener and D.S. Chemla p2029
High gain, wide dynamic range L-band externally modulated fibre optic. E. Ackerman, D. Kasemsei, S. Wanuga and S. Chinn p1339
High-power and high-speed semi-insulating BH structure monolithic electro-absorption modulator/DFB laser light source. H. Soda, M. Furutsu, K. Sato, N. Okazaki, S. Yamazaki, H. Nishimoto and H. Ishikawa p9
Low voltage strained layer asymmetric Fabry–Perot reflection modulator. J. Woodhead, P.A. Claxton, R. Grey, T.E. Sale, J.P.R. David, L. Liu, M.A. Pate, G. Hill and P.N. Robson p2117
Temperature sensitivity of asymmetric Fabry–Perot modulators. P. Zouganeli, M. Whitehead, P.J. Stevens, A. Rivers, G. Parry, J.S. Roberts and C. Button p1384
Velocity matching of III-V travelling-wave electro-optic modulator structures. M.R.T. Tan, I. Kim, J. Chang and S.Y. Wang p32

MONTE CARLO METHODS

Monte Carlo comparison of heterojunction cathode Gunn oscillators. C. Lee and U. Ravaioli p425
Monte Carlo estimates of incidence of basic access ISDN generated EMI. W.D. Davies p1048
New method of analysing transient processes in picosecond photoconductive switch. Y. Lu p444
Some improvements to conventional importance sampling techniques for coded systems using Viterbi decoding. S.X. Chen, P.J. Smith, M. Shafi and D. Vere-Jones p802

MULTIPLEXERS AND MULTIPLEXING

100-channel optical FDM transmission/distribution at 622 Mbit/s over 50 km utilising a waveguide frequency selection switch. H. Toba, K. Oda, K. Nakanishi, N. Shibata, K. Nosu, N. Takato and K. Sato p376
11 Gbit/s multiplexer and demultiplexer using 0·15 μm GaAs MESFETs. M. Ohhata, Y. Yamane, T. Enoki, S. Sugitani, N. Kato and M. Hirayama p467
160-channel FM-video transmission using optical FM/FDM and subcarrier multiplexing and an erbium doped optical fibre amplifier. W.I. Way, M.W. Maeda, A. Yi-Yan, M.J. Andrejco, M.M. Choy, M. Saifi and C. Lin p139
20 Gbit/s time-division multiplexer IC in silicon bipolar technology. J. Hauenschild, H.-M. Rein, W. McFarland, J. Doernberg and D. Pettengill e2137
40 Gbit/s optical time-division cell multiplexer for a photonic ATM switch. M. Tsukada and Y. Shimazu p1895
459 km, 2·4 Gbit/s four wavelength multiplexing optical fibre transmission experiment using six Er-doped fibre amplifiers. H. Taga, Y. Yoshida, N. Edagawa, S. Yamamoto and H. Wakabayashi p500
Close-spaced fused fibre wavelength division multiplexers with very low polarisation sensitivity. I.J. Wilkinson and C.J. Rowe p382
Comparison of WDM coupler technologies for use in erbium doped fibre amplifier systems. A. Lord, I.J. Wilkinson, A. Ellis, D. Cleland, R.A. Garnham and W.A. Stallard p900
Demonstration of a 1 × 2 multichannel grating cavity laser for wavelength division multiplexing (WDM) applications. I.H. White, K.O. Nyairo, P.A. Kirkby and C.J. Armistead p832
Demonstration of the nonlinear fibre loop mirror as an ultrafast all-optical demultiplexer. K.J. Blow, N.J. Doran and B.P. Nelson p962
Error propagation through the European demultiplexer hierarchy—An analysis. J.E. Deslandes, P. Cochrane and E.V. Jones p1469
Multichannel local lightwave network with grouping property. S.H. Nam and C.K. Un p1436
Novel electronic scanner for coherence multiplexing in a quasi-distributed pressure sensor. S. Chen, B.T. Meggitt and A.J. Rogers p1367 e1738
Novel method for centre wavelength tuning of silica waveguide type Mach–Zehnder multi/demultiplexers. H. Uetsuka, M. Kurosawa and K. Imoto p251
Passive fibre-loop architecture providing both switched and broadcast transport. R.C. Menendez, S.S. Wagner and H.L. Lemberg p273
Performance of the leaky bucket policing mechanism for small bucket depths. D.A. Hughes, G. Anido and H.S. Bradlow p1305
Programmable multiplexed switched-capacitor filters. X.F. Wania, D.A. Johns and A.S. Sedra p1051
Time-division 8 : 1 multiplexing and demultiplexing system adapting 7B1C code operating at 5 Gbit/s. N. Yokota, Y. Hakamata and K. Takemoto p923

MULTIVARIABLE SYSTEMS

Two-dimensional modified Cauer form: circuit and state space realisation. G.E. Antoniou, C.N. Manikopoulos and S.E. Mentzelopoulou p258

NEGATIVE RESISTANCE

Electrical transient study of negative resistance in SOI MOS transistors. O. Le Néel and M. Haond p73
Estimation of temperature limit for negative differential resistance using resonant tunnelling. L. De Saint Pol, O. Vanbesien and D. Lippens p342
Negative R_s and R_g in GaAs FET and HEMT equivalent circuits. P.H. Ladbrooke, A.J. Hill and J.P. Bridge p680
New GaSb/AlSb/GaSb/AlSb/InAs/AlSb/InAs triple-barrier interband tunnelling diode. L. Yang, J.F. Chen and A.Y. Cho p1277
Room temperature negative differential resistance in a triple well rectifying resonant tunnelling diode. C.R. Bolognesi, R.S. Mand and A.R. Boothroyd p1163
Strained layer AlGaAs–GaAs–InGaAs real-space transferred electron devices. M.E. Favaro, J.J. Alwan, R.P. Bryan, L.M. Miller, J.J. Coleman, J. Kim and C.M. Wayman p1264

NETWORK TOPOLOGY

Contention-based reservation protocol in fibre optic local area network with passive star topology. H.B. Jeon and C.K. Un p780
Determining the number of hidden nodes by progressive training. T. Lee and F.L. Chung p1318
Integrated structure for generalised connection networks employing optical switches. A.M. Hill, J.V. Wright and S. Srikanthan p1474 e1831
Neural network for adaptive FIR filtering. M. Forti, S. Manetti and M. Marini p1018

NETWORKS AND NETWORK THEORY

ATM access through a passive optical network. J.W. Ballance, P.H. Rogers and M.F. Halls p558
Analogue computation using VLSI neural network devices. M.J. Brownlow, L. Tarassenko and A.F. Murray p1297
Analytic node model for deflection routing networks. A.M. Bignell and T.D. Todd p67
Approximate expression for normalised throughput of multistage interconnection networks. T.-H. Lee and J.-J. Chou p2031
Artificial neural network for image compression. G.L. Sicuranza, G. Ramponi and S. Marsi p477
Behaviour of circuit-switched multistage networks in presence of memory hot spot. T.-H. Lee d546
CMOS layout design of the hysteresis McCulloch–Pitts neuron. T. Kurokawa, K.C. Lee, Y.B. Cho and Y. Takefuji p2093
CSMA local radio networks with BPSK modulation in Rayleigh fading channels. K. Zhang and K. Pahlavan p1655
Calculating the upper and lower bounds on capacity of two modified Hebbian trained Hopfield networks. P. Houselander and J.T. Taylor p1266
Coherent subcarrier multiplexed star distribution system using local oscillator. M-S. Kao and J. Wu p1680
Comparing performance of Hebbian- and delta-trained Hopfield networks. P.K. Houselander and J.T. Taylor p85
Convergence of back-propagation in neural networks using a log-likelihood cost function. M.J.J. Holt and S. Semnani p1964
Daugman's Gabor transform as a simple generative back propagation network. D. Cohen and J. Shawe-Taylor p1241
Diverse routing in wavelength selective networks. P.J. Chidgey and G.R. Hill p1709
Improving the Hamming binary associative memory. P. Houselander and J.T. Taylor p705
L_1 normalisation in neural networks using parallel automatic level control. R. Perfetti p82
Medical ultrasound imaging using neural networks. M. Nikoonahad and D.C. Liu p545
Medium access control protocol for the integration of voice/data on a local area network. A.D. Malyan and R.L. Brewster p592
Neural network approach for the two-dimensional assignment problem. K.B. Sriram and L.M. Patnaik p809
Neural network for estimation of parameters of sinewave. S. Osowski p689
New impedance transforming rat-race hybrid ring. H.R. Mgombelo, H.O. Ali and M.M. Kissaka p837
Nonlinear circuit analysis using the Newton-SOR continuation method. K.K.M. Cheng and J.K.A. Everard p2120
Novel algorithm for Clos-type networks. J. Gordon and S. Srikanthan p1770
Novel learning method for analogue neural networks. T. Matsumoto and M. Koga p1136
Orthogonal codes for CDMA optical fibre LANs with variable bit interval. R. Petrovic and S. Holmes p662
Register insertion bus architecture for fibre optic local area networks. J.M. Ott and A.P. Jayasumana p1957
SYMFONET: ultra-high-capacity distributed packet switching network for telecoms and multiprocessor computer applications. P.A. Kirkby p19
Self-routing planar network for guided-wave optical switching systems. H. Obara, S. Okamoto, H. Uematsu and H. Matsunaga p520
Simple implementation of load-sharing banyan network and its throughput performance. T.-H. Lee p79
Single sided switching networks. J. Gordon and S. Srikanthan p248
Slotted ALOHA radio networks with PSK modulation in Rayleigh fading channels. K. Zhang, K. Pahlavan and R. Ganesh d593
Switched-capacitor neural networks using pulse based arithmetic. B. Maundy and E. El-Masry p1118

Throughput performance of multistage interconnection networks in presence of multiple memory hot spots. T.-H. Lee p536
Velocity field computation using neural networks. J. Hanbing p1787
Winner-take-all neural net with memory. J. Pankove, C. Radehaus and K. Wagner p349

NOISE

Application of Hartley transform to tracking moving objects in noisy environments. Y.-S. Huang and C.-Y. Hsu p1878
Companding in signal processing. Y.P. Tsividis, V. Gopinathan and L. Tóth p1331
Correlation of relative intensity noise with linewidth floors in narrow linewidth DFB lasers. H. Sundaresan and N.C. Fletcher p2002
Crosstalk injection when testing transmission systems. J.W. Cook and K.T. Foster p1181
Direct observation of shot noise in linewidth broadening of DBR lasers. H. Sundaresan and N.C. Fletcher p2004
FM–AM noise conversion in dispersive single-mode fibre transmission lines. K. Petermann p2097
Generalised formula for optical-amplifier noise and its application to erbium-doped fibre amplifiers. K. Kikuchi p1851
Low noise balanced receiver for coherent transmission systems. I. Hardcastle and A. Hadjifotiou p750
Low-frequency noise performance of self-aligned InAlAs/InGaAs heterojunction bipolar transistors. S. Tanaka, N. Hayama, A. Furukawa, T. Baba, M. Mizuta and K. Honjo p1439
New multilevel complementary pairs of sequences. S.Z. Budišin p1861
Noise behaviour of InAlAs/GaInAs MSM photodetectors. H. Schumacher, J.B.D. Soole, H.P. LeBlanc, R. Bhat and M.A. Koza p612
Noise characteristics of high-power doped-fibre superluminescent sources. P.R. Morkel, R.I. Laming and D.N. Payne p96
Noise characteristics of polarisation sensitive optically preamplified receivers. D.G. Cunningham, A.N. Coles and I.H. White p1619
Noise reduction based on microphone array with LMS adaptive post-filtering. R. Zelinski p2036
Noise tuning of GaAs-MESFET oscillators. L. Kreischer p315
Novel passive phase noise cancelling technique for interferometric fibre optic sensors. A.D. Kersey and T.A. Berkoff p640
Simple parameter estimation technique in manoeuvring target tracking system. J.-A. Guu and C.-H. Wei p508
Spectral broadening due to fibre amplifier phase noise. G.J. Cowle, P.R. Morkel, R.I. Laming and D.N. Payne p424

NONLINEAR NETWORKS

Equations of nonlinear analogue circuit for fault dictionary generation. V.C. Prasad p24
Nonlinear prediction in image coding with DPCM. J. Li and C.N. Manikopoulos p1357
Opto-electronic high order feedback neural network. D.R. Selviah, Z.Q. Mao and J.E. Midwinter p1954

NONLINEAR OPTICS

2·8 Gbit/s optical soliton transmission employing all laser diodes. K. Iwatsuki, S. Nishi, M. Saruwatari and M. Shimizu p1
Amplification of femtosecond pulses in Er^{3+}-doped single-mode optical fibres. I.Yu. Khrushchëv, A.B. Grudinin, E.M. Dianov, D.V. Korobkin Jun, V.A. Semënov and A.M. Prokhorov p456
Competition between second and third harmonic generation in silica fibres. X.H. Zheng and J.E. Carroll p2065
Demonstration of the nonlinear fibre loop mirror as an ultrafast all-optical demultiplexer. K.J. Blow, N.J. Doran and B.P. Nelson p962
Enhanced surface emitting waveguides for visible, monolithic semiconductor laser sources. R. Normandin, R.L. Williams and F. Chatenoud p2088
Fundamental mode of highly nonlinear fibres. A.W. Snyder, Y. Chen, L. Poladian and D.J. Mitchell p643
Growth of third-harmonic signal in optical glass fibre. U. Österberg p103
Ideal optical switching by nonlinear multiple (parasitic) core couplers. Y. Chen, A.W. Snyder and D.J. Mitchell p77
Kramers–Kronig relations for nonlinear optics. K.A. Shore and D.A.S. Chan p1206
Nonlinear Y-junction coupler. S. Chi and T.-T. Shi p339
Nonlinear triple core couplers. D.J. Mitchell, A.W. Snyder and Y. Chen p1164 e1831
Observation of femtosecond beats using Raman radiation from SiO_2 optical fibres. L.H. Acioli, A.S.L. Gomes and C.B. de Araújo p92
Saturable absorption in a tapered single-mode optical fibre. H.S. Mackenzie and F.P. Payne p1744
Second-order nonlinearity of a disazo dye attached polymer. M. Amano and T. Kaino p981
Twin core nonlinear couplers with saturable nonlinearity. Y. Chen p1374
Variational approach to nonlinear waveguides—Gaussian approximations. R.A. Sammut and C. Pask p1131

NONLINEAR SYSTEMS

Attractor dimension, entropy and modelling of speech time series. A. Kumar and S.K. Mullick p1790
Automated adaptive hysteresis current control technique for a voltage-fed PWM inverter. D.S. Oh and M.J. Youn p2044
Effect of initial conditions on limit cycle performance of second order sampled data sigma delta modulator. N. Bridgett and C.P. Lewis p817
Expanding the power-handling capabilities of harmonic-balance analysis by a parametric formulation of the MESFET model. V. Rizzoli and A. Neri p1359
Hysteresis and multistable behaviour in a polarisation self-modulated external ring cavity semiconductor laser. W.H. Loh, A.T. Schremer and C.L. Tang p1666
Inclusion of dispersive effects of microstrip lines in formulation using state-space approach of nonlinear microwave circuits. J.I. Alonso and F. Pérez p795
Nonlinear gain effects in strained-layer lasers. A. Ghiti and E.P. O'Reilly p1978

NUMERICAL METHODS AND NUMBER THEORY

Analysis of edge slots in rectangular waveguide using finite-difference time-domain method. J.C. Olivier and D.A. McNamara p1135
Analysis of groove guides with grooves of arbitrary shape. Z.X. Shen, X.M. Lou and S.F. Li p472
Carry delayed save adders for computing the product $A \cdot B$ modulo N in $\log_2 N$ steps. C.H.N. Forster, S.S. Dlay and R.N. Gorgui-Naguib p1544
Comparison of three numerical treatments for the open-ended coaxial line sensor. S. Jenkins, T.E. Hodgetts, G.T. Symm, A.G.P. Warham, R.N. Clarke and A.W. Preece p234
Novel method to control numerical solution oscillation of diffusion-drift equation. H. Yie, C. Guoxiang and W. Yuanming p1487
Solutions of the SBS equations in single mode optical fibres and implications for fibre transmission systems. P. Bayvel and P.M. Radmore p434

OPERATIONAL AMPLIFIERS

Fully differential operational amplifiers using CMOS compatible lateral bipolar transistors with improved common-mode regulation. J.-P. Bardyn and A. Kaiser p798
Parasitic insensitive single amplifier switched capacitor bandpass biquad. C. Psychalinos and I. Haritantis p253
Two-way transmission at 2·488 Gbit/s over a 132 km operational submerged cable using erbium-doped fibre power amplifiers. E.G. Bryant, S.F. Carter, R.B.J. Lewis, D.M. Spirit, T. Widdowson and J.V. Wright p1355

OPTICAL COMMUNICATION

'Fibre/radio' for the provision of cordless/mobile telephony services in the access network. A.J. Cooper p2054
0AMI-CPFSK heterodyne transmission experiment using a novel delay-line demodulation method. H. Tsushima, S. Sasaki, R. Takeyari, S. Kitajima, K. Kuboki and K. Uomi p1269
100-channel optical FDM transmission/distribution at 622 Mbit/s over 50 km utilising a waveguide frequency selection switch. H. Toba, K. Oda, K. Nakanishi, N. Shibata, K. Nosu, N. Takato and K. Sato p376
10 GHz bandwidth low-noise optical receiver using discrete commercial devices. M.A.R. Violas, D.J.T. Heatley, A.M.O. Duarte and D.M. Beddow p35
10 Gbit/s AlGaAs/GaAs heterojunction bipolar transistor decision circuit IC. J. Akagi, Y. Kuriyama, K. Morizuka, M. Asaka, K. Tsuda, M. Obara and H. Yamakawa p122
10 Gbit/s optical PSK homodyne transmission experiments using external cavity DFB LDs. S. Norimatsu, K. Iwashita and K. Noguchi p648
10 Gbit/s, 100 km nonrepeatered fibre transmission experiment using a high-sensitivity semiconductor optical preamplifier. H. Nakano, S. Tsuji, K. Uomi, S. Sasaki and K. Yamashita p1364
11 Gbit/s multiplexer and demultiplexer using 0·15 μm GaAs MESFETs. M. Ohhata, Y. Yamane, T. Enoki, S. Sugitani, N. Kato and M. Hirayama p467
11 Gbit/s, 260 km transmission experiment using a directly-modulated 1536 nm DFB laser with two Er-doped fibre amplifiers and clock recovery. A. Righetti, F. Fontana, G. Delrosso, G. Grasso, M.Z. Iqbal, J.L. Gimlett, R.D. Standley, J. Young, N.K. Cheung and E.J. Tarbox p330
140 Mbit/s and 560 Mbit/s FSK heterodyne polarisation diversity receiver using nearly perfect square law demodulators. M.T. Tomesen, P.W. Hooijmans and K.G. Wright p1870
152 photons per bit detection at 622 Mbit/s to 2·5 Gbit/s using an erbium fibre preamplifier. P.P. Smyth, R. Wyatt, A. Fidler, P. Eardley, A. Sayles and S. Craig-Ryan p1604
16-channel parallel optical interconnect demonstration with an InGaAs/InP MQW modulator array. N. Barnes, P. Healey, M.A.Z. Rejman-Greene, E.G. Scott and R.P. Webb p1126
160-channel FM-video transmission using optical FM/FDM and subcarrier multiplexing and an erbium doped optical fibre amplifier. W.I. Way, M.W. Maeda, A. Yi-Yan, M.J. Andrejco, M.M. Choy, M. Saifi and C. Lin p139
1·2 Gbit/s fully integrated transimpedance optical receiver OEIC for 1·3–1·55 μm transmission systems. W.S. Lee, D.A.H. Spear, M.J. Agnew, P.J.G. Dawe and S.W. Bland p377
1·55 μm high-gain polarisation-insensitive semiconductor travelling wave amplifier with low driving current. B. Mersali, G. Gelly, A. Accard, J.-L. Lafragette, P. Doussiere, M. Lambert and B. Fernier p124
1·5 Gbit/s FSK transmission system using two electrode DFB laser as a tunable FSK discriminator/photodetector. M.J. Chawki, R. Auffret and L. Berthou p1146
1·7 Gbit/s, 1·5 μm Coherent lightwave regenerator. J.M. Delavaux, Y.K. Park, R.E. Tench, S. Barski, B. Owen, L.D. Tzeng and Y. Twu p1480
1 W, coherent, monolithically integrated master oscillator power amplifier. R. Waarts, R. Parke, D. Welch, D. Mehuys, W. Streifer and D. Scifres p1926
2 Gbit/s PSK heterodyne communication system using optical phase-locked loop. D.A. Atlas and L.G. Kazovsky p1030
2.26 Gbit/s optical transmission system with 5B6B line coding. A.M.J. Koonen, P. Van Eijk, P.H. Van Heijningen and T.W.M. Mosch p799
20 Gbit/s no-chirp intensity modulation by DPSH-IM method and its fibre transmission through 330 ps/nm dispersion. M. Shirasaki, I. Yokota and T. Touge p33
20 Gbit/s soliton transmission over 200 km using erbium-doped fibre repeaters. M. Nakazawa, K. Suzuki, E. Yamada and Y. Kimura p1592
2·2 GHz dual-detector lightwave receiver employing current shunt feedback amplifier design. T. Olsen p510
2·488 Gbit/s transmission experiment at 1550 nm over 153 km standard single-mode fibre. J.T.M. Kluitmans, P.I. Kuindersma, M. Meier, J. Mink, G. Röll and D.J. Will p566
2·55 μm, 400 Mbit/s transmission experiment with single-mode fluoride optical fibre. T. Komukai, Y. Miyajima and Y. Katsuyama p584
44-ary FSK coherent optical communication system. S.B. Alexander, R. Barry, D.M. Castagnozzi, V.W.S. Chan, D.M. Hodsdon, L.L. Jeromin, J.E. Kaufmann, D.M. Materna, R.J. Parr, M.L. Stevens and D.W. White p1346
459 km, 2·4 Gbit/s four wavelength multiplexing optical fibre transmission experiment using six Er-doped fibre amplifiers. H. Taga, Y. Yoshida, N. Edagawa, S. Yamamoto and H. Wakabayashi p500
565 Mbit/s 219 km transmission experiment using four gain controlled packaged semiconductor laser amplifiers. A.D. Ellis, J.D. Cox, D.M. Bird, K. Cameron, D.J. Elton, G. Sherlock and W.A. Stallard p385
5 Gbit/s, 250 km error-free soliton transmission with Er^{3+}-doped fibre amplifiers and repeaters. K. Suzuki, M. Nakazawa, E. Yamada and Y. Kimura p551
5 Gbit/s, +10 dBm lossless transmission in 10 km distributed erbium fibre amplifier. D.M. Spirit, L.C. Blank, D.L. Williams, S.T. Davey and B.J. Ainslie p1658
622 Mbit/s AMI FSK optical transmission experiment using a semiconductor optical preamplifier and a Fabry–Perot etalon demodulator. R.C. Steele and G.R. Walker p539
7203-user WDM broadcast network employing one erbium-doped fibre power amplifier. A.M. Hill, D.B. Payne, K.J. Blyth, D.S. Forrester, J.W. Arkwright, R. Wyatt, J.F. Massicott, R.A. Lobbett, P. Smith and T.G. Hodgkinson p605
8 Gbit/s 202 km optical CPFSK transmission experiment using 1·3 μm zero dispersion fibre. N. Takachio, K. Iwashita, K. Nakanishi and S. Koike p506
904 km, 1·2 Gbit/s non-regenerative optical fibre transmission experiment using 12 Er-doped fibre amplifiers. N. Edagawa, Y. Yoshida, H. Taga, S. Yamamoto, K. Mochizuki and H. Wakabayashi p66

ATM access through a passive optical network. J.W. Ballance, P.H. Rogers and M.F. Halls p558
Amplification in the 1300 nm telecommunications window in a Nd-doped fluoride fibre. J.E. Pedersen, M.C. Brierley, S.F. Carter and P.W. France p329 e555 e555
Analytic node model for deflection routing networks. A.M. Bignell and T.D. Todd p67
Arrayed-waveguide grating for wavelength division multi/demultiplexer with nanometre resolution. H. Takahashi, S. Suzuki, K. Kato and I. Nishi p87
Balanced 3 × 3 port phase diversity receiver with reduced impact of thermal noise. R. Langenhorst, E. Patzak and W. Pieper p595
Broadband high-density WDM transmission using superluminescent diodes. S.S. Wagner and T.E. Chapuran p696
Broadband polarisation splitting couplers in ion-exchanged glass. R.A. Betts and F. Lui p450
Broadband, high sensitivity erbium amplifier receiver for operation over wide wavelength range. J. Boggis, A. Lord, M. Violas, D. Heatley and W.A. Stallard p532
Coherent linear arrays of grating coupled surface-emitting lasers. R.G. Waarts, D.F. Welch, R. Parke, A. Hardy and W. Streifer p129
Coherent optical ring using common local oscillator. M-S Kao and J. Wu p1013
Coherent subcarrier multiplexed star distribution system using local oscillator. M-S. Kao and J. Wu p1680
Coherent transmission experiment over 2223 km at 2·5 Gbit/s using erbium-doped fibre amplifiers. S. Saito, T. Imai, T. Sugie, N. Ohkawa, Y. Ichihashi and T. Ito p669
Combined amplitude and polarisation shift keying optical coherent modulation. S. Benedetto and P. Poggiolini p918
Combined high power and high frequency operation of InGaAsP/InP lasers at 1·3 μm. T.R. Chen, Y.H. Zhuang, A. Yariv, H. Blauvelt and N. Bar-Chaim p985
Comparison of DFB laser linewidth measurement techniques: Results from COST 215 round robin. M.O. van Deventer, P. Spano and S.K. Nielsen p2018
Contention-based reservation protocol in fibre optic local area network with passive star topology. H.B. Jeon and C.K. Un p780
Continuously tunable metal-clad ridge-waveguide distributed feedback laser diode. T. Wolf, H. Westermeier and M.-C. Amann p1845
DPSK polarisation diversity receiver with novel switching-demodulators and maximal-ratio combining. S. Neidlinger p1070
Delay, linewidth and bandwidth limitations in optical phase-locked loop design. R.T. Ramos and A.J. Seeds p389 e1922
Demonstration of a 1 × 2 multichannel grating cavity laser for wavelength division multiplexing (WDM) applications. I.H. White, K.O. Nyairo, P.A. Kirkby and C.J. Armistead p832
Demonstration of the nonlinear fibre loop mirror as an ultrafast all-optical demultiplexer. K.J. Blow, N.J. Doran and B.P. Nelson p962
Diode-pumped 1·36 μm Nd-doped fibre laser. S.G. Grubb, W.L. Barnes, E.R. Taylor and D.N. Payne p121
Effects of zinc doping in DFB lasers emitting at 1·3 and 1·55 μm. M. Sugano, H. Sudo, H. Soda, T. Kusunoki and H. Ishikawa p95
Efficient mode conversion in telecommunication fibre using externally written gratings. K.O. Hill, B. Malo, K.A. Vineberg, F. Bilodeau, D.C. Johnson and I. Skinner p1270
Erbium fibre soliton laser. K. Smith, J.R. Armitage, R. Wyatt, N.J. Doran and S.M.J. Kelly p1149
Error correcting coding of a 220 Mbit/s coherent optical communication channel. D.M. Castagnozzi, S.B. Alexander, E.P. Colagiuri, E.A. Bucher and L.L. Jeromin p1288
Error probability of optical heterodyne MSK communication system with limiter–discriminator–integrator detector. X. Zhang and P. Jiang p136 e1832
Evanescent field amplification in a tapered single-mode optical fibre. H.S. Mackenzie and F.P. Payne p130
Excess linewidth broadening in wavelength-tunable laser diodes. M.-C. Amann and R. Schimpe p279
Experimental demonstration of a three channel WDM system over 110 km using superluminescent diodes. P.D.D. Kilkelly, P.J. Chidgey and G. Hill e2137
Exploiting fibre optics transmission capacity: 4-quadrature multilevel signalling. S. Betti, F. Curti, G. De Marchis and E. Iannone p992
FM–AM noise conversion in dispersive single-mode fibre transmission lines. K. Petermann p2097
Fast timing extraction method for an optical passive bus. Y. Nagasako and T. Nakashima p1168
Field demonstration of coherent transmission system with diode-pumped erbium doped fibre amplifiers. M.J. Creaner, D. Spirit, G.R. Walker, N.G. Walker, R.C. Steele, J. Mellis, S. Al Chalabi, W. Hale, I. Sturgess, M. Rutherford, D. Trivett and M. Brain p442
Field demonstration of two channel coherent transmission with a diode-pumped fibre amplifier repeater. M.J. Creaner, R.C. Steele, D. Spirit, G.R. Walker, N.G. Walker, J. Mellis, S. Al Chalabi, W. Hale, I. Sturgess, M. Rutherford, D. Trivett and M. Brain p1621
First field demonstration of in-service fault location/supervisory using optical time domain reflectometry. J.D. Cox, J.M. Boggis, E.G. Bryant, C.A. Hunter and W.A. Stallard p110
Frequency-stabilised LD module with a Z-cut quartz Fabry–Perot resonator for coherent communication. M.S. Nakamura and S. Ohshima p405
Full duplex coherent optical communication with one in-line polarisation controller. M.O. van Deventer p758
Gain limitation of fibre Raman amplifiers considering third Stokes wavelength generation. M.-S. Kao and J. Wu p191
General approach to designing the XX2B-AMI coding family. P. Radev p1043
Gigabit high sensitivity receiver using InGaAs/InAlAs superlattice APD. Y. Miyamoto, K. Hagimoto and T. Kagawa p491
High efficiency, high uniformity, grating coupled surface emitting lasers. R. Parke, R. Waarts, D.F. Welch, A. Hardy and W. Streifer p125
High performance 140 Mbit/s FSK coherent system. I. Hardcastle, Y. Large, F. Davis and A. Hadjifotiou p1523
High performance packaged optical coherent hybrid. J-M.P. Delavaux and R. Riggs p1022
High sensitivity 5 Gbit/s optical receiver module using Si IC and GaInAs APD. S. Fujita, T. Suzaki, A. Matsuoka, S. Miyazaki, T. Torikai, T. Nakata and M. Shikada p175
High-performance, two-channel optical FSK heterodyne system with polarisation diversity receiver. R. Noé, H. Rodler, G. Gaukel, B. Noll and A. Ebberg p1109
Highly bandwidth efficient transmission through continuous polarisation modulation. S. Benedetto and P. Poggiolini p1392
Highly reproducible ridge waveguide multielectrode DFB lasers for optical communication systems. H. Sundaresan, S. Kwan, A. Lord, W.J. Duncan, I.D. Henning, W.A. Stallard and C. Broughton p1876
Hybrid-integrated laser/driver module for 10 Gbit/s optical fibre transmission. H. Nakano, K. Uomi, K. Yamashita and Y. Yagiu p145
Improved Allan variance real-time processing system to measure frequency tracking error of heterodyne optical phase-locked loops. C.-H. Shin and M. Ohtsu p1571
InGaAsP 400 × 200 μm active crosspoint switch operating at 1·5 μm using novel reflective Y-coupler components. I.H. White, J.J.S. Watts, J.E. Carroll, C.J. Armistead, D.J. Moule and J.A. Champelovier p617
Integrated dielectric wavelength filters on InGaAs PIN photodetectors. M.D. Learmouth, N.P. Hewett, I. Reid and M.J. Robertson p576
Integrated optics 4 × 4 switch matrix with digital optical switches. P. Granestrand, B. Lagerström, P. Svensson, L. Thylén, B. Stoltz, K. Bergvall, J.-E. Falk and H. Olofsson p4
Lightwave scalar network analyser employing optical heterodyne detection. O. Ishida, H. Toba and F. Kano p297
Linewidth enhancement in distributed-feedback semiconductor lasers. M.-C. Amann p569
Lossless transmission over 10 km of low-dispersion erbium doped fibre using only 15 mW pump power. S.T. Davey, D.L. Williams, D.M. Spirit and B.J. Ainslie p1148
Low-loss PECVD silica channel waveguides for optical communications. G. Grand, J.P. Jadot, H. Denis, S. Valette, A. Fournier and A.M. Grouillet p2135
Maximum bitrate-length product in the high density WDM optical fibre communication system. S. Chi and S.-C. Wang p1509
Maximum transmission capacity of a soliton communication system with lumped amplifiers. H. Kubota and M. Nakazawa p1454
Monolithic *pin*-HEMT receiver with internal equaliser for long-wavelength fibre optic communications. H. Yano, K. Aga, H. Kamei, G. Sasaki and H. Hayashi p305
Multichannel FSK experiment using an optical amplifier repeater and wavelength tunable direct detection receiver. D.J. Malyon and W.A. Stallard p1863
Multichannel FSK transmission experiment at 565 Mbit/s using tunable three-electrode DFB lasers. N. Flaarønning, J.O. Frorud, M. Sotom, G. Vendrôme, G. Da Loura, J.M. Gabriagues, J. Jacquet, D. Leclerc and J. Benoit p869
Multichannel DPSK coherent optical communication systems. Y.H. Cheng and T. Okoshi p1378
Multichannel local lightwave network with grouping property. S.H. Nam and C.K. Un p1436
Multichannel video transmission over 100 km of step index singlemode fibre using a directly modulated 1537 nm distributed feedback laser. P.A. Rosher and S.C. Fenning p534
New retiming and synchronisation scheme for optical ATM switching systems. Y. Takahashi, K. Ando, M. Miyata and E. Amada p99
Novel 4:1 multiplexer circuit for Gbit/s data rates. D. Daniel p1092
Novel method for centre wavelength tuning of silica waveguide type Mach–Zehnder multi/demultiplexers. H. Uetsuka, M. Kurosawa and K. Imoto p251
Novel optical frequency comb synthesis using optical feedback. P. Coppin and T.G. Hodgkinson p28
Novel random access tunable heterodyne receiver using beat counting method for multichannel coherent systems. S. Kitajima, S. Sasaki, H. Tsushima, M. Okai and K. Yamashita p127
Novel type of baseband phase-reversal electrode for optical modulators with linear phase response. A. Djupsjöbacka p318
On/off ratio degradation of high density WDM systems due to raman crosstalk. M.-S. Kao p1034
Optical QPSK homodyne transmission of 280 Mbit/s. F. Derr p401
Optical domain frequency translation of a modulated optical carrier. T.G. Hodgkinson and P. Coppin p1262
Optimum optical modulation index of laser transmitters in SCM systems. K. Alameh and R.A. Minasian p1273
Optimum transmission conditions of solitons by pre-emphasis technique. S. Chi and M.-C. Lin p1473
Orthogonal codes for CDMA optical fibre LANs with variable bit interval. R. Petrovic and S. Holmes p662
Over 300 km CPFSK transmission experiment using 67 photon/bit sensitivity receiver at 2·5 Gbit/s. T. Imai, N. Ohkawa, Y. Ichihashi, T. Sugie and T. Ito p357
Over 7 nm (875 GHz) continuous wavelength tuning by tunable twin-guide (TTG) laser diode. S. Illek, W. Thulke, C. Schanen, H. Lang and M.-C. Amann p46
PSK optical homodyne system with nonlinear phase-locked loop. A. Schöpflin, S. Kugelmeier, E. Gottwald, D. Felicio and G. Fischer p395
Passive fibre-loop architecture providing both switched and broadcast transport. R.C. Menendez, S.S. Wagner and H.L. Lemberg p273
Passive integrated optical polarisation mode-splitter in lithium niobate employing a resonant metal-loaded structure. C. Edge, P.J. Duthie and M.J. Wale p1855
Performance evaluation of multilevel polarisation shift keying modulation schemes. S. Benedetto and P. Poggiolini p244
Performance evaluation of polarisation shift keying modulation schemes. S. Benedetto and P. Poggiolini p256
Phase-locking of laser diodes. H.R. Telle and H. Li p858
Phase-shifted Moiré grating fibre resonators. D.C.J. Reid, C.M. Ragdale, I. Bennion, D.J. Robbins, J. Buus and W.J. Stewart p10
Photocurrent saturation in short-period superlattice modulators. K.W. Goossen, J.E. Zucker, I. Bar-Joseph, J.M. Kuo, R.M. Kopf, D.A.B. Miller and D.S. Chemla p736
Polarisation insensitive configuration of semiconductor laser amplifier. M. Sumida p1913
Polarisation- and pattern-independent optical FSK heterodyne system using data-induced polarisation switching. R. Noé, H. Rodler, G. Gaukel, A. Ebberg and F. Auracher p176
Position tunable volume reflection gratings for narrowband filtering applications (FWHM < 5 nm) in optical fibre systems. D.E. Sheat, J.S. Leggatt and D.J. McCartney p42
Potential of the distributed amplifier as a photo-diode detector amplifier in high bit rate optical communication systems. C.S. Aitchison p1693
Proposal for an all-optical code-division multiple access for local area networks. P.C. Neusy and M. Kavehrad p1471
Pulsed operation of an optical feedback frequency synthetiser. T.G. Hodgkinson and P. Coppin p1155
Reduction of intermodulation distortion of interferometric optical modulators through incoherent mixing of optical waves. Z.-Q. Lin and W.S.C. Chang p1980
SYMFONET: ultra-high-capacity distributed packet switching network for telecoms and multiprocessor computer applications. P.A. Kirkby p19
Simultaneous transmission and amplification of 622 Mbit/s, 10 FM NTSC video channels and 3 FM HDTV components using a high gain erbium doped fibre

amplifier. H.E. Tohme, C.N. Lo and M.A. Saifi p1280
Spread-spectrum optical fibre network based on pulsed coherent correlation. D.D. Sampson and D.A. Jackson p1550
Step-by-step BSRS amplification in long-span optical fibre communication. G.-D. Peng p334
Strained-layer InGaAs/InAlAs multiple quantum wells for efficient optical waveguide modulation at 1·55 μm. E. Bigan, M. Allovon, M. Carre and A. Carenco p355
Suppression of laser frequency drifts caused by thermal transients in optical WDM packet switching systems. E.G. Vicente de Vera and B. Glance p1930
Towards a coherent optical free-space communication system. K. Wallmeroth, B. Wandernoth, J. Franz, H. Meier and B. Schorp p572
Transfer matrix model for evaluation of optical switch structures. J.J. Dharmadi, H. Mulder, A. Diekema and A.G. de Waal p6
Transmission experiment at 5 Gbit/s using 1300 nm Fabry–Perot type LD and PIN PD. Y. Hakamata, K. Isido and K. Takemoto p739
Transmissive quasidistributed optical fibre sensing scheme for two-state sensors. A. Prewett p840
Tunable couplers fabricated in K^+/Na^+ ion exchanged glass. R.A. Betts, F. Lui and E. Gauja p786
Two-channel coherent optical FDM transmission system with a new frequency stabilisation scheme. Q. Jiang, D.M. Wu and L.Z. Xie p310
Two-way transmission at 2·488 Gbit/s over a 132 km operational submerged cable using erbium-doped fibre power amplifiers. E.G. Bryant, S.F. Carter, R.B.J. Lewis, D.M. Spirit, T. Widdowson and J.V. Wright p1355
Ultra-low reflectivity broadband 1·5 μm GaInAsP semiconductor optical amplifiers. P.E. Barnsley, J.J. Isaac and D.J. Elton p825
Ultra-low-reflectivity semiconductor optical amplifiers without antireflection coatings. W. Rideout, R. Holmstrom, J. LaCourse, E. Meland and W. Powazinik p36
Use of a fibre loop reflector as downstream receiver and upstream modulator in passive optical network. G. Nicholson p827
Very high amplitude, minimal chirp optical pulse generation at 1·55 μm using multicontact DFBs and an erbium doped fibre amplifier. H. Sundaresan and G.E. Wickens p725
Very low voltage, normally-off asymmetric Fabry–Perot reflection modulator. M. Whitehead, A. Rivers, G. Parry and J.S. Roberts p1588
Waiting time jitter results for a reduced complexity SONET interface circuit. T.E. Moore, R.G. Kusyk and W.A. Krzymien p1884
Widely tunable Y-coupled cavity integrated interferometric injection laser. M. Schilling, H. Schweizer, K. Dütting, W. Idler, E. Kühn, A. Nowitzki and K. Wünstel p243
Y-branch wavelength multi/demultiplexer for $\lambda = 1{\cdot}30$ and 1·55 μm. N. Goto and G.L. Yip p102
Yield analysis of non-AR-coated DFB lasers with combined index and gain coupling. K. David, G. Morthier, P. Vankwikelberge and R. Baets p238

OPTICAL CONNECTORS & COUPLERS

0Mach–Zehnder interferometer type optical waveguide coupler with wavelength-flattened coupling ratio. K. Jinguji, N. Takato, A. Sugita and M. Kawachi p1326
16-channel parallel optical interconnect demonstration with an InGaAs/InP MQW modulator array. N. Barnes, P. Healey, M.A.Z. Rejman-Greene, E.G. Scott and R.P. Webb p1126
7 × 7 monolithic single-mode star coupler. J.W. Arkwright and D.B. Mortimore p1534
Broadband silica-based optical waveguide coupler with asymmetric structure. A. Takagi, K. Jinguji and M. Kawachi p132
Fused taper couplers in multimode fluorozirconate fibre. C.J. Rowe, M.W. Moore, I.J. Wilkinson and N.E. Achurch p316
High-contrast measurement of refractive-index profile in fused single-mode fibre couplers with high resolution by deconvolution. A.M. Oehler, T.M. Hauff, M. Moratzky and W.E. Heinlein p12
Ideal optical switching by nonlinear multiple (parasitic) core couplers. Y. Chen, A.W. Snyder and D.J. Mitchell p77
Low-cost fibre-optic gyroscope. H. Poisel, G.F. Trommer, W. Bühler, E. Hartl and R. Müller p69
Micro-optic adjustable coupler. P.-H. Zongo, Q. Yu and P. Facq p1813
Nonlinear Y-junction coupler. S. Chi and T.-T. Shi p339
Power flow in triple-core couplers. Y. Chen, A.W. Snyder and D.J. Mitchell p76

OPTICAL DETECTORS

10 GHz bandwidth low-noise optical receiver using discrete commercial devices. M.A.R. Violas, D.J.T. Heatley, A.M.O. Duarte and D.M. Beddow p35
Error probability of optical heterodyne MSK communication system with limiter–discriminator–integrator detector. X. Zhang and P. Jiang p136 e1832
Light-controlled optical bistable device by bistable laser diode and heterojunction phototransistor. S. Noda, E. Yamada, T. Takayama and A. Sasaki p1069

OPTICAL DISPERSION

20 Gbit/s no-chirp intensity modulation by DPSH-IM method and its fibre transmission through 330 ps/nm dispersion. M. Shirasaki, I. Yokota and T. Touge p33
Use of constrained minimisation method in study of optical fibres. R. Kamala and V. Kudalkar p100 e1097

OPTICAL FIBRES

'On-spot' interferometric optical coherence domain polarimetry for quasi-distribute temperature sensors. S. Chen and I.P. Giles p1607
11 Gbit/s, 260 km transmission experiment using a directly-modulated 1536 nm DFB laser with two Er-doped fibre amplifiers and clock recovery. A. Righetti, F. Fontana, G. Delrosso, G. Grasso, M.Z. Iqbal, J.L. Gimlett, R.D. Standley, J. Young, N.K. Cheung and E.J. Tarbox p330
152 photons per bit detection at 622 Mbit/s to 2·5 Gbit/s using an erbium fibre preamplifier. P.P. Smyth, R. Wyatt, A. Fidler, P. Eardley, A. Sayles and S. Craig-Ryan p1604
1·31–1·36 μm optical amplification in Nd^{3+}-doped fluorozirconate fibre. Y. Miyajima, T. Komukai and T. Sugawa p194
20 Gbit/s soliton transmission over 200 km using erbium-doped fibre repeaters. M. Nakazawa, K. Suzuki, E. Yamada and Y. Kimura p1592
20 dB Gain at 1·55 μm wavelength in 50 cm long Er^{3+}-doped fluoride fibre amplifier. Y. Miyajima, T. Sugawa and T. Komukai p1527
2·488 Gbit/s transmission experiment at 1550 nm over 153 km standard single-mode fibre. J.T.M. Kluitmans, P.I. Kuindersma, M. Meier, J. Mink, G. Röll and D.J. Will p566
2·55 μm, 400 Mbit/s transmission experiment with single-mode fluoride optical fibre. T. Komukai, Y. Miyajima and Y. Katsuyama p584
2·8 Gbit/s optical soliton transmission employing all laser diodes. K. Iwatsuki, S. Nishi, M. Saruwatari and M. Shimizu p1
39·5 million-way WDM broadcast network employing two stages of erbium-doped fibre amplifiers. A.M. Hill, R. Wyatt, J.F. Massicott, K.J. Blyth, D.S. Forrester, R.A. Lobbett, P.J. Smith and D.B. Payne p1882
4 Gbit/s, 233-km optical fibre transmission experiment using newly proposed direct-modulation PSK. T. Naito, T. Chikama, G. Ishikawa and H. Kuwahara p1734
459 km, 2·4 Gbit/s four wavelength multiplexing optical fibre transmission experiment using six Er-doped fibre amplifiers. H. Taga, Y. Yoshida, N. Edagawa, S. Yamamoto and H. Wakabayashi p500
5 Gbit/s, +10 dBm lossless transmission in 10 km distributed erbium fibre amplifier. D.M. Spirit, L.C. Blank, D.L. Williams, S.T. Davey and B.J. Ainslie p1658
904 km, 1·2 Gbit/s non-regenerative optical fibre transmission experiment using 12 Er-doped fibre amplifiers. N. Edagawa, Y. Yoshida, H. Taga, S. Yamamoto, K. Mochizuki and H. Wakabayashi p66
90% coupling of top surface emitting GaAs/AlGaAs quantum well laser output into 8 μm diameter core silica fibre. K. Tai, G. Hasnain, J.D. Wynn, R.J. Fischer, Y.H. Wang, B. Weir, J. Gamelin and A.Y. Cho p1628
Accurate reflectance and optical fibre backscatter parameter measurements using an OTDR. P. Blanchard, P.-H. Zongo and P. Facq p2060
All-fibre narrowband reflection gratings at 1500 nm. R. Kashyap, J.R. Armitage, R. Wyatt, S.T. Davey and D.L. Williams p730
All-fibre optical hybrid for coherent polarisation diversity receivers. J.-M.P. Delavaux, Y.K. Park, S. Barski, H. Lefevre, M. Failes and C. Warner p1303
Amplification in the 1300 nm telecommunications window in a Nd-doped fluoride fibre. J.E. Pedersen, M.C. Brierley, S.F. Carter and P.W. France p329 e555 e555
Amplification of femtosecond pulses in Er^{3+}-doped single-mode optical fibres. I.Yu. Khrushchëv, A.B. Grudinin, E.M. Dianov, D.V. Korobkin Jun, V.A. Semënov and A.M. Prokhorov p456
Analysis of the wavelength dependence of Raman backscatter in optical fibre thermometry. P.J. Samson p163
Automatic optical soliton control using cascaded Er^{3+}-doped fibre amplifiers. K. Suzuki and M. Nakazawa p1032
Axial dependence of $\chi^{(2)}$ gratings in optical fibre: Effect of the intensity-dependent detuning. F. Ouellette p740
Blue upconversion fluorozirconate fibre laser. J.Y. Allain, M. Monerie and H. Poignant p166
Broadband, high sensitivity erbium amplifier receiver for operation over wide wavelength range. J. Boggis, A. Lord, M. Violas, D. Heatley and W.A. Stallard p532
Calculation of phase shift sensitivity in polarimetric fibre sensors. D. Wong and P.L. Chu p607
Cerenkov third-harmonic generation in optical glass fibre. K. Hayata and M. Koshiba p1566
Characterisation of diode-pumped erbium-doped fluorozirconate fibre optical amplifier. D.M. Spirit, G.R. Walker, P.W. France, S.F. Carter and D. Szebesta p1218 e1739
Close-spaced fused fibre wavelength division multiplexers with very low polarisation sensitivity. I.J. Wilkinson and C.J. Rowe p382
Coherent transmission experiment over 2223 km at 2·5 Gbit/s using erbium-doped fibre amplifiers. S. Saito, T. Imai, T. Sugie, N. Ohkawa, Y. Ichihashi and T. Ito p669
Comparison of WDM coupler technologies for use in erbium doped fibre amplifier systems. A. Lord, I.J. Wilkinson, A. Ellis, D. Cleland, R.A. Garnham and W.A. Stallard p900
Competition between second and third harmonic generation in silica fibres. X.H. Zheng and J.E. Carroll p2065
Controlled amplifier modelocked Er^{3+} fibre ring laser. D. Burns and W. Sibbett p505
Diode laser pumped Er^{3+} fibre laser operation between 2·7–2·8 μm. H. Yanagita, I. Masuda, T. Yamashita and H. Toratani p1836
Diode-laser pumped erbium-doped fluorozirconate fibre amplifier for the 1530 nm communications window. C.A. Millar and P.W. France p634
Diode-pumped 1·36 μm Nd-doped fibre laser. S.G. Grubb, W.L. Barnes, E.R. Taylor and D.N. Payne p121
Dual excitation scheme for direct suppression of residual signal in fibre-optic magnetometers. K.P. Koo, D.M. Dagenais, S. Vohra and F. Bucholtz p1867
Effect of enhancing the Raman gain factor on the linearity of Raman fibre amplifiers. A.S. Siddiqui and A. Yu p1661
Effect of mechanical inhomogeneity on intrinsic stress birefringence in birefringent optical fibres. D. Wong p967
Efficient 1·3 μm-band amplification in a Nd^{3+}-doped single-mode fluoride fibre. Y. Miyajima, T. Sugawa and T. Komukai p1397
Efficient CW operation of a 2·9 μm Ho^{3+}-doped fluorozirconate fibre laser pumped at 640 nm. L. Wetenkamp p883
Efficient erbium-doped fibre amplifier pumped at 820 nm. M. Nakazawa, Y. Kimura, E. Yoshida and K. Suzuki p1936
Efficient mode conversion in telecommunication fibre using externally written gratings. K.O. Hill, B. Malo, K.A. Vineberg, F. Bilodeau, D.C. Johnson and I. Skinner p1270
Efficient up-conversion pumping at 800 nm of an erbium-doped fluoride fibre laser operating at 850 nm. C.A. Millar, M.C. Brierley, M.H. Hunt and S.F. Carter p1871
Efficient, high power, high gain, Er^{3+} doped silica fibre amplifier. J.F. Massicott, R. Wyatt, B.J. Ainslie and S.P. Craig-Ryan p1038
Elimination of water peak in optical fibre taper components. T.A. Birks, R.P. Kenny, K.P. Oakley and C.V. Cryan p1761
Enhancement of Faraday rotation in a fibre Fabry–Perot cavity. J. Stone, R.M. Jopson, L.W. Stulz and S.J. Licht p849
Er^{3+}-doped single-polarisation optical fibres. K. Tajima p1498
Erbium doped fluorozirconate fibre laser operating at 1·66 and 1·72 μm. R.G. Smart, J.N. Carter, D.C. Hanna and A.C. Tropper p649
Erbium-doped fibre amplifiers with an extremely high gain coefficient of 11·0 dB/mW. M. Shimizu, M. Yamada, M. Horiguchi, T. Takeshita and M. Okayasu p1641
Erbium-doped fluoride optical amplifier operating around 2·75 μm. D. Ronarc'h, J.Y. Allain, M. Guibert, M. Monerie and H. Poignant p903
Evanescent field amplification in a tapered single-mode optical fibre. H.S. Mackenzie and F.P. Payne p130
Excess loss in practical depressed-cladding fibres. J.D. Love and W.M. Henry p727 d1546
Experimental demonstration of a three channel WDM system over 110 km using superluminescent diodes. P.D.D. Kilkelly, P.J. Chidgey and G. Hill e2137
Experimental observation of forward stimulated Brillouin scattering in dual-mode single-core fibre. P. St J Russell, D. Culverhouse and F. Farahi p1195
Fabrication and properties of large core, high NA, high Nd^{3+} content multimode optical fibres for temperature sensor applications. P.L. Scrivener, P.D.

Maton, A.P. Appleyard and E.J. Tarbox p872
Fabrication of long lengths of low excess loss erbium-doped optical fibre. S.P. Craig-Ryan, B.J. Ainslie and C.A. Millar p185
Feasibility demonstration of low pump power operation for 1·48 μm diode-pumped erbium-doped fibre amplifier module. J.F. Marcerou, H. Fevrier, J. Auge, J. Ramos and A. Dursin p1102
Femtosecond fibre laser. M.E. Fermann, M. Hofer, F. Haberl and S.P. Craig-Ryan p1738
Femtosecond soliton amplification in erbium doped silica fibre. B.J. Ainslie, K.J. Blow, A.S. Gouveia-Neto, P.G.J. Wigley, A.S.B. Sombra and J.R. Taylor p186
FiEnd filters: Passive multilayer thin-film optical filters deposited on fibre ends. J. Stone and L.W. Stulz p1290
Field demonstration of 2·5 Gbit/s coherent optical transmission through installed submarine fibre cables. T. Imai, Y. Hayashi, N. Ohkawa, T. Sugie, Y. Ichihashi and T. Ito p1407
Field demonstration of two channel coherent transmission with a diode-pumped fibre amplifier repeater. M.J. Creaner, R.C. Steele, D. Spirit, G.R. Walker, N.G. Walker, J. Mellis, S. Al Chalabi, W. Hale, I. Sturgess, M. Rutherford, D. Trivett and M. Brain p1621
Fundamental mode of highly nonlinear fibres. A.W. Snyder, Y. Chen, L. Poladian and D.J. Mitchell p643
Fused taper couplers in multimode fluorozirconate fibre. C.J. Rowe, M.W. Moore, I.J. Wilkinson and N.E. Achurch p316
Generalised formula for optical-amplifier noise and its application to erbium-doped fibre amplifiers. K. Kikuchi p1851
Generation of <3 ps optical pulses by fibre compression of gain-switched InGaAsP DFB laser diode pulses. R.T. Hawkins p292
Glass waveguide laser operated around 1·3 μm. H. Aoki, O. Maruyama and Y. Asahara p1910
Ground-state and excited-state absorption in rare-earth doped optical fibres. M. Monerie, T. Georges, P.L. Francois, J.Y. Allain and D. Neveux p320
Growth of third-harmonic signal in optical glass fibre. U. Österberg p103
High gain Er^{3+}-doped fibre amplifier pumped by 820 nm GaAlAs laser diodes. K. Suzuki, Y. Kimura and M. Nakazawa p948
High gain erbium fibre amplifier pumped by 800 nm band. M. Nakazawa, Y. Kimura and K. Suzuki p548
High gain two-stage amplification with erbium-doped fibre amplifier. H. Masuda and A. Takada p661
High gain, broadband, 1·6 μm Er^{3+} doped silica fibre amplifier. J.F. Massicott, J.R. Armitage, R. Wyatt, B.J. Ainslie and S.P. Craig-Ryan p1645
High performance metal-clad fibre-optic polarisers. R. Willsch p1113
High performance single mode OTDR using coherent detection and fibre amplifiers. Y. Koyamada and H. Nakamoto p573
High saturation output power from a neodymium-doped fluoride fibre amplifier operating in the 1300 nm telecommunications window. J.E. Pedersen and M. Brierley p819
High-contrast measurement of refractive-index profile in fused single-mode fibre couplers with high resolution by deconvolution. A.M. Oehler, T.M. Hauff, M. Moratzky and W.E. Heinlein p12
Highly efficient integrated optical fibre amplifier module pumped by a 0·98 μm laser diode. M. Shimizu, M. Horiguchi, M. Yamada, M. Okayasu, T. Takeshita, I. Nishi, S. Uehara, J. Noda and E. Sugita p498
Highly efficient optical fibre amplifier pumped by a 0·8 μm band laser diode. M. Horiguchi, M. Shimizu, M. Yamada, K. Yoshino and H. Hanafusa p1758
Hydrostatic pressure induced birefringence in a highly birefringent optical fibre. K.S. Chiang and D. Wong p1952
Ideal optical switching by nonlinear multiple (parasitic) core couplers. Y. Chen, A.W. Snyder and D.J. Mitchell p77
In-*situ* investigation of coupling between a fibre and a slab waveguide. M. Iztkovich, M. Tur, A. Hardy and N. Croituro p1104
Influence of stimulated Brillouin scattering on phase modulated signals in optical fibres. A. Höök, A. Bolle, G. Grosso and M. Martinelli p470
Intensity to frequency conversion technique in intensity modulated fibre optic sensing systems. G. Adamovsky and T.W. Carr p1450
Intrinsic safety of optical fibres in combustible environments. P.C. Hills p1982
Investigation on spectral behaviour of novel direct coupling compound fibre ring resonator. J. Capmany and M.A. Muriel p772
Lasing and amplification in the 0·8 μm region in thulium doped fluorozirconate fibres. J.N. Carter, R.G. Smart, D.C. Hanna and A.C. Tropper p1759
Latching type single-mode fibre switch. S. Nagaoka p744
Limitations in long haul IM/DD optical fibre systems caused by chromatic dispersion and nonlinear Kerr effect. J.P. Hamaide, Ph. Emplit and J.M. Gabriagues p1451
Lossless transmission over 10 km of low-dispersion erbium doped fibre using only 15 mW pump power. S.T. Davey, D.L. Williams, D.M. Spirit and B.J. Ainslie p1148
Low loss fluoride fibre by reduced pressure casting. S.F. Carter, M.W. Moore, D. Szebesta, J.R. Williams, D. Ranson and P.W. France p2115
Low-cost fibre-optic gyroscope. H. Poisel, G.F. Trommer, W. Bühler, E. Hartl and R. Müller p69
Matching fibres for low loss coupling into fibre amplifiers. M.J. Holmes, F.P. Payne and D.M. Spirit p2102
Measurement of intermodal coupling in weakly multimode fibre optics. S. Shaklan p2022
Measurement of polarisation beat length in single-mode optical fibres with a polarisation modulator. V.N. Filippov, O.I. Kotov and V.M. Nikolayev p658
Modal noise power penalty in high speed short single-mode fibre interconnections. V.S. Shukla, M.P. Singh and R.F. Kearns p732
Mode locking of a continuous wave neodymium doped fibre laser with a linear external cavity. P.G.J. Wigley, P.M.W. French and J.R. Taylor p1238
Nd^{3+} fibre laser utilising intra-core Bragg reflectors. G.A. Ball, W.W. Morey and J.P. Waters p1829
Noise characteristics of high-power doped-fibre superluminescent sources. P.R. Morkel, R.I. Laming and D.N. Payne p96
Nonlinear triple core couplers. D.J. Mitchell, A.W. Snyder and Y. Chen p1164 e1831
Novel electronic scanner for coherence multiplexing in a quasi-distributed pressure sensor. S. Chen, B.T. Meggitt and A.J. Rogers p1367 e1738
Novel high precision alignment technique for polarisation maintaining fibres using a frequency modulated tunable laser. A. Ebberg and R. Noé p2009
Novel passive phase noise cancelling technique for interferometric fibre optic sensors. A.D. Kersey and T.A. Berkoff p640
Observation of femtosecond beats using Raman radiation from SiO_2 optical fibres. L.H. Acioli, A.S.L. Gomes and C.B. de Araújo p92
Observation of self-lensing in a 4BCMU-polydiacetylene thin-film waveguide. J. Valera, A. Darzi, A.C. Walker, W. Krug, E. Miao, M. Derstine and J.N. Polky p222
Open loop fibre optic gyroscope with phase shift nulling signal processing. A.D. Kersey and R.P. Moeller p1251
Optical QPSK homodyne transmission of 280 Mbit/s. F. Derr p401
Optical TAP based on D-fibre. N.E. Achurch p1909
Optical fibre microbending sensors by micromachining techniques. J.H.C. Chao and G.W. Neudeck p513
Optical-fibre spectrum analyser. M.A. Page-Jones and J.K.A. Everard p117
Optimisation of refractive index profile for high gain fibre amplifiers. M.J. Holmes, D.M. Spirit and F.P. Payne p1873
Optimum design of erbium fibre amplifiers pumped with sources emitting at 1480 nm. J.H. Povlsen, A. Bjarklev, B. Pedersen, H. Vendeltorp-Pommer and K. Rottwitt p1419
Over 350 km CPFSK repeaterless transmission at 2·5 Gbit/s employing high-output power erbium-doped fibre amplifiers. T. Sugie, T. Imai and T. Ito p1577
Parametric design features of twin-elliptical-core optical fibres. G.-D. Peng and A. Ankiewicz p1496 e1922
Passively temperature-compensated fibre Fabry–Perot filter and its application in wavelength division multiple access computer network. C.M. Miller and F.J. Janniello p2122
Performance tuning of 1 × 7 wavelength-flattened fused fibre couplers. D.B. Mortimore and J.W. Arkwright p1442
Phase-shifted Moiré grating fibre resonators. D.C.J. Reid, C.M. Ragdale, I. Bennion, D.J. Robbins, J. Buus and W.J. Stewart p10
Polarisation beam splitting using twin-elliptic-core optical fibres. G.D. Peng, T. Tjugiarto and P.L. Chu p682
Polarisation-maintaining fibre using a novel glass system. Y.T. Ko, D.J. DiGiovanni, J.B. MacChesney and J.R. Simpson p876
Position tunable volume reflection gratings for narrowband filtering applications (FWHM <5 nm) in optical fibre systems. D.E. Sheat, J.S. Leggatt and D.J. McCartney p42
Power flow in triple-core couplers. Y. Chen, A.W. Snyder and D.J. Mitchell p76
Programmable splice-free quasi-monolithic 2 Gbit/s optical fibre pulse code generator. C.J.G. Kirkby, D.C.J. Reid and D.C. Jou p1673
Proposal for an all-optical code-division multiple access for local area networks. P.C. Neusy and M. Kavehrad p1471
Quadrature phase sampling of a fibre interferometer by input-polarisation switching. A.D. Kersey and M.J. Marrone p686
Register insertion bus architecture for fibre optic local area networks. J.M. Ott and A.P. Jayasumana p1957
Repeaterless transmission with 62·9 dB power budget using a highly efficient erbium-doped fibre amplifier module. B. Clesca, A. Auge, B. Biotteau, P. Bousselet, A. Dursin, C. Clergeaud, P. Kretzmeyer, V. Lemaire, O. Gautheron, G. Grandpierre, E. Leclerc and P. Gabla p1426
Rocking filter formation in photosensitive high birefringence optical fibres. P.St. J. Russell and D.P. Hand p1846
Room temperature CW tunable green upconversion holmium fibre laser. J.Y. Allain, M. Monerie and H. Poignant p261
Saturable absorption in a tapered single-mode optical fibre. H.S. Mackenzie and F.P. Payne p1744
Simple method for calculation of stress-induced birefringence in fibres with arbitrary structures. H. Jin and Q. Jingren p598
Simultaneous transmission and amplification of 622 Mbit/s, 10 FM NTSC video channels and 3 FM HDTV components using a high gain erbium doped fibre amplifier. H.E. Tohme, C.N. Lo and M.A. Saifi p1280
Soliton collision interaction force dependence on wavelength separation in fibre amplifier based systems. P.A. Andrekson, N.A. Olsson, J.R. Simpson, T. Tanbun-Ek, R.A. Logan, P.C. Becker and K.W. Wecht p1499
Solutions of the SBS equations in single mode optical fibres and implications for fibre transmission systems. P. Bayvel and P.M. Radmore p434
Spectral broadening due to fibre amplifier phase noise. G.J. Cowle, P.R. Morkel, R.I. Laming and D.N. Payne p424
Spectral linewidth broadening in Er-doped-fibre amplifiers measured with less than 1·4 kHz linewidth light source. H. Okamura and K. Iwatsuki p1965
Spectrum stability of a broadband 1060 nm Nd-doped fibre laser. K. Fesler, M. Digonnet, K. Liu, B.Y. Kim and H.J. Shaw p870
Step-by-step BSRS amplification in long-span optical fibre communication. G.-D. Peng p334
Stimulated Raman scattering seeded by a fibre continuum. M.D. Selker and N.M. Lawandy p409
Strain-induced birefringence in a highly birefringent optical fibre. K.S. Chiang, D. Wong and P.L. Chu p1344
Technique for alignment of semiconductor lasers to bevelled single-mode fibres. B.M. Foley, P. Melman and K.T. Vo p2118
Temperature dependence of bending loss in monomode optical fibres. R. Morgan, J.S. Barton, P.G. Harper and J.D.C. Jones p937
Temperature dependence of second harmonic generation in germania-doped silica optical fibres. Y. Hibino, V. Mizrahi and G.I. Stegeman p1578
Temperature dependent gain and noise characteristics of a 1480 nm-pumped erbium-doped fibre amplifier. M. Suyama, R.I. Laming and D.N. Payne p1756
Temperature insensitive Er^{3+}-doped optical fibre amplifiers. M. Yamada, M. Shimizu, M. Okayasu and M. Horiguchi p1649
Transmission over 10 km of erbium doped fibre with ultralow signal power excursion. D.L. Williams, S.T. Davey, D.M. Spirit and B.J. Ainslie p1517
Two-section distributed feedback lasers for incoherent frequency-shift-keying transmission systems. S.J. Wang, Y. Twu, N.K. Dutta and R.L. Hartman p1243
Unrepeatered 2·4 Gbit/s transmission experiment over 250 km of step-index fibre using erbium power amplifier. E.G. Bryant, S.F. Carter, A.D. Ellis, W.A. Stallard, J.V. Wright and R. Wyatt p528
Use of a fibre loop reflector as downstream receiver and upstream modulator in passive optical network. G. Nicholson p827
Use of constrained minimisation method in study of optical fibres. R. Kamala and V. Kudalkar p100 e1097
Variational approach to nonlinear waveguides—Gaussian approximations. R.A. Sammut and C. Pask p1131
Very high amplitude, minimal chirp optical pulse generation at 1·55 μm using multicontact DFBs and an erbium doped fibre amplifier. H. Sundaresan and G.E. Wickens p725
Very low threshold Sagnac switch incorporating an erbium doped fibre amplifier. D.J. Richardson, R.I. Laming and D.N. Payne p1779
Water and hydrogen equilibrium for different cable constructions. W. Griffioen p1122
Wavelength combining fused-taper couplers with low sensitivity to polarisation for use with 1480 nm-pumped erbium-doped fibre amplifiers. J.D. Minelly and M. Suyama p523
Wavelength stability of Nd^{3+}-doped fibre fluorescent sources. P.R. Morkel, E.M. Taylor, J.E. Townsend and D.N. Payne p873

OPTICAL FILTERS

FiEnd filters: Passive multilayer thin-film optical filters deposited on fibre ends. J. Stone and L.W. Stulz p1290

Integrated dielectric wavelength filters on InGaAs PIN photodetectors. M.D. Learmouth, N.P. Hewett, I. Reid and M.J. Robertson p576
Passively temperature-compensated fibre Fabry–Perot filter and its application in wavelength division multiple access computer network. C.M. Miller and F.J. Janniello p2122
Phase-shifted Moiré grating fibre resonators. D.C.J. Reid, C.M. Ragdale, I. Bennion, D.J. Robbins, J. Buus and W.J. Stewart p10
Position tunable volume reflection gratings for narrowband filtering applications (FWHM <5 nm) in optical fibre systems. D.E. Sheat, J.S. Leggatt and D.J. McCartney p42
TM-mode selective filter using lossy layer cladding optical waveguide. S. Ohke, S. Nishihara and Y. Cho p98
Three-mirror fibre Fabry–Perot filters of optimal design. J. Stone, L.W. Stulz and A.A.M. Saleh p1073

OPTICAL LOGIC

Digital optical logic using optically switched directional couplers. A.F. Benner p1037

OPTICAL MEASUREMENT

Algorithm for large-phase-modulation measurements. M.N. Zervas p112
Analysis of the wavelength dependence of Raman backscatter in optical fibre thermometry. P.J. Samson p163
Comparison of DFB laser linewidth measurement techniques: Results from COST 215 round robin. M.O. van Deventer, P. Spano and S.K. Nielsen p2018
Complementary correlation OTDR with three codewords. M. Nazarathy, S.A. Newton and W.R. Trutna p70
First field demonstration of in-service fault location/supervisory using optical time domain reflectometry. J.D. Cox, J.M. Boggis, E.G. Bryant, C.A. Hunter and W.A. Stallard p110
High-contrast measurement of refractive-index profile in fused single-mode fibre couplers with high resolution by deconvolution. A.M. Oehler, T.M. Hauff, M. Moratzky and W.E. Heinlein p12
Lightwave scalar network analyser employing optical heterodyne detection. O. Ishida, H. Toba and F. Kano p297

OPTICAL MODULATION

20 Gbit/s no-chirp intensity modulation by DPSH-IM method and its fibre transmission through 330 ps/nm dispersion. M. Shirasaki, I. Yokota and T. Touge p33
4 Gbit/s, 233-km optical fibre transmission experiment using newly proposed direct-modulation PSK. T. Naito, T. Chikama, G. Ishikawa and H. Kuwahara p1734
Algorithm for large-phase-modulation measurements. M.N. Zervas p112
All-optical switching of grating transmission using cross-phase modulation in optical fibres. S. LaRochelle, Y. Hibino, V. Mizrahi and G.I. Stegeman p1459
Combined amplitude and polarisation shift keying optical coherent modulation. S. Benedetto and P. Poggiolini p918
Demonstration of digital pulse modulation of a grating-surface-emitting diode laser. N.W. Carlson, D.R. Patterson, P.J. Stabile, S.K. Liew, D.P. Bour and G.A. Evans p1695
Extremely high-frequency (24 GHz) InGaAsP diode lasers with excellent modulation efficiency. E. Meland, R. Holmstrom, J. Schlafer, R.B. Lauer and W. Powazinik p1827
High performance QCSE phase modulator for the 1·5–1·55 μm fibre band. J.B.D. Soole, H.K. Tsang, I.H. White, H.P. LeBlanc, R. Bhat and M.A. Koza p1421
High-power and high-speed semi-insulating BH structure monolithic electroabsorption modulator/DFB laser light source. H. Soda, M. Furutsu, K. Sato, N. Okazaki, S. Yamazaki, H. Nishimoto and H. Ishikawa p9
Matrix-addressed 4 × 4 spatial light modulator using the quantum confined stark effect in GaAs/AlGaAs quantum wells. K. McIlvaney, J.H. Marsh, J.S. Roberts and C. Button p1691
Reduction of intermodulation distortion of interferometric optical modulators through incoherent mixing of optical waves. Z.-Q. Lin and W.S.C. Chang p1980
Very low voltage, normally-off asymmetric Fabry–Perot reflection modulator. M. Whitehead, A. Rivers, G. Parry and J.S. Roberts p1588
Waveguided electro-optical intensity modulation in a Si/Ge_xSi_{1-x}/Si heterojunction bipolar transistor. R.D. Lareau, L. Friedman and R.A. Soref p1653

OPTICAL MULTIDEMULTIPLEXERS

Arrayed-waveguide grating for wavelength division multi/demultiplexer with nanometre resolution. H. Takahashi, S. Suzuki, K. Kato and I. Nishi p87
Design of an InGaAlAs/InP '3mi' wavelength division demultiplexer employing a novel mode transformer. I.R. Croston and T.P. Young p336
Stabilisation of mode-locked pulses using travelling-wave semiconductor laser amplifier. A.J. Lowery and I.W. Marshall p104
Transmissive quasidistributed optical fibre sensing scheme for two-state sensors. A. Prewett p840
Wavelength combining fused-taper couplers with low sensitivity to polarisation for use with 1480 nm-pumped erbium-doped fibre amplifiers. J.D. Minelly and M. Suyama p523
Y-branch wavelength multi/demultiplexer for $\lambda = 1{\cdot}30$ and $1{\cdot}55\,\mu$m. N. Goto and G.L. Yip p102

OPTICAL PROPERTIES OF SUBSTANCES

Bend performance of fibre-matched optical waveguides on InP. R.J. Deri, N. Yasuoka, M. Makiuchi, A. Kuramata and O. Wada p321
Blue upconversion fluorozirconate fibre laser. J.Y. Allain, M. Monerie and H. Poignant p166
Design and fabrication of two layer anti-reflection coatings for semiconductor optical amplifiers. M.C. Farries, J. Buus and M. Kearley p1626
Finite-element analysis of chirowaveguides. J.A.M. Svedin p928
Fused taper couplers in multimode fluorozirconate fibre. C.J. Rowe, M.W. Moore, I.J. Wilkinson and N.E. Achurch p316
Growth of high quality InP with metal organic molecular beam epitaxy. H. Heinecke, R. Höger, B. Baur and A. Miklis p213
Lateral drift and recombination of photogenerated carriers in multiple quantum well hetero *nipi* structures. C. Thirstrup, P.L.K. Wa, C.C. Button, J.S. Roberts and P.N. Robson p1935
Observation of self-lensing in a 4BCMU-polydiacetylene thin-film waveguide. J. Valera, A. Darzi, A.C. Walker, W. Krug, E. Miao, M. Derstine and J.N. Polky p222
Optical second harmonic generation from laminated polymeric Langmuir-Blodgett multilayers. M.C.J. Young, W.X. Lu, R.H. Tredgold, P. Hodge and F. Abbasi p993
Photoinduced channel waveguide formation in nonlinear optical polymers. M.B.J. Diemeer, F.M.M. Suyten, E.S. Trommel, A. McDonach, J.M. Copeland, L.W. Jenneskens and W.H.G. Horsthuis p379
Polarisability and mixing formula for chiral ellipsoids. A.H. Sihvola and I.V. Lindell p1007
Polarisation-maintaining fibre using a novel glass system. Y.T. Ko, D.J. DiGiovanni, J.B. MacChesney and J.R. Simpson p876
Room temperature CW tunable green upconversion holmium fibre laser. J.Y. Allain, M. Monerie and H. Poignant p261

OPTICAL RADAR

0AMI-CPFSK heterodyne transmission experiment using a novel delay-line demodulation method. H. Tsushima, S. Sasaki, R. Takeyari, S. Kitajima, K. Kuboki and K. Uomi p1269

OPTICAL RECEIVERS

10 GHz bandwidth low-noise optical receiver using discrete commercial devices. M.A.R. Violas, D.J.T. Heatley, A.M.O. Duarte and D.M. Beddow p35
10 Gbit/s, 100 km nonrepeatered fibre transmission experiment using a high-sensitivity semiconductor optical preamplifier. H. Nakano, S. Tsuji, K. Uomi, S. Sasaki and K. Yamashita p1364
140 Mbit/s and 560 Mbit/s FSK heterodyne polarisation diversity receiver using nearly perfect square law demodulators. M.T. Tomesen, P.W. Hooijmans and K.G. Wright p1870
152 photons per bit detection at 622 Mbit/s to 2·5 Gbit/s using an erbium fibre preamplifier. P.P. Smyth, R. Wyatt, A. Fidler, P. Eardley, A. Sayles and S. Craig-Ryan p1604
2·2 GHz dual-detector lightwave receiver employing current shunt feedback amplifier design. T. Olsen p510
Adaptive coherent optical receiver array. L.B. Mercer p1518
All-fibre optical hybrid for coherent polarisation diversity receivers. J.-M.P. Delavaux, Y.K. Park, S. Barski, H. Lefevre, M. Failes and C. Warner p1303
Balanced 3 × 3 port phase diversity receiver with reduced impact of thermal noise. R. Langenhorst, E. Patzak and W. Pieper p595
Broadband, high sensitivity erbium amplifier receiver for operation over wide wavelength range. J. Boggis, A. Lord, M. Violas, D. Heatley and W.A. Stallard p532
DPSK polarisation diversity receiver with novel switching-demodulators and maximal-ratio combining. S. Neidlinger p1070
Digital demodulation for optical FSK signals. G. Ahlbom, L. Egnell and C. Wickman p290
Error probability of optical heterodyne MSK communication system with limiter–discriminator–integrator detector. X. Zhang and P. Jiang p136 e1832
Gigabit high sensitivity receiver using InGaAs/InAlAs superlattice APD. Y. Miyamoto, K. Hagimoto and T. Kagawa p491
High sensitivity, high gain, long wavelength OEIC receiver with monolithically integrated three-stage preamplifier. J. Shimizu, T. Suzaki, T. Terakado, S. Fujita, K. Kasahara, T. Itoh and A. Suzuki p824
High-performance, two-channel optical FSK heterodyne system with polarisation diversity receiver. R. Noé, H. Rodler, G. Gaukel, B. Noll and A. Ebberg p1109
Impact of spontaneous emission noise on the sensitivity of direct-detection lightwave receivers using optical amplifiers. O.K. Tonguz p1343
Monolithic *pin*-HEMT receiver with internal equaliser for long-wavelength fibre optic communications. H. Yano, K. Aga, H. Kamei, G. Sasaki and H. Hayashi p305
Monolithic integration of an InP/InGaAs four-channel transimpedance optical receiver array. W.S. Lee, D.A.H. Spear, P.J.G. Dawe and S.W. Bland p1833
Monolithically integrated $In_{0.53}Ga_{0.47}As/In_{0.52}Al_{0.48}As$ (on InP) MSM/HFET photoreceiver grown by MBE. H.T. Griem, H.S. Fuji, T.J. Williams, J.P. Harrang, R.R. Daniels, S. Ray, M.J. LaGasse and D.L. West p1198
New retiming and synchronisation scheme for optical ATM switching systems. Y. Takahashi, K. Ando, M. Miyata and E. Amada p99
Noise characteristics of polarisation sensitive optically preamplified receivers. D.G. Cunningham, A.N. Coles and I.H. White p1619
Novel random access tunable heterodyne receiver using beat counting method for multichannel coherent systems. S. Kitajima, S. Sasaki, H. Tsushima, M. Okai and K. Yamashita p127
Optical 90° hybrid for Costas-type receivers. W.R. Leeb p1431
Two-channel coherent optical FDM transmission system with a new frequency stabilisation scheme. Q. Jiang, D.M. Wu and L.Z. Xie p310
Wavelength demultiplexing heterojunction phototransistor. M.S. Ünlü, K. Kishino, J.-I. Chyi, J. Reed, L. Arsenault and H. Morkoç p1857

OPTICAL ROTATION

Chiroshield: A Salisbury/Dallenbach shield alternative. D.L. Jaggard, N. Engheta and J. Liu p1332

OPTICAL SENSORS

Analysis of the wavelength dependence of Raman backscatter in optical fibre thermometry. P.J. Samson p163
Transmissive quasidistributed optical fibre sensing scheme for two-state sensors. A. Prewett p840

OPTICAL SWITCHING

40 Gbit/s optical time-division cell multiplexer for a photonic ATM switch. M. Tsukada and Y. Shimazu p1895
All-optical loop mirror switch employing an asymmetric amplifier/attenuator combination. A.W. O'Neill and R.P. Webb p2008
All-optical switching of grating transmission using cross-phase modulation in optical fibres. S. LaRochelle, Y. Hibino, V. Mizrahi and G.I. Stegeman p1459
Directional-coupler-based planar concentrator networks. A. Jajszczyk p886
Diverse routing in wavelength selective networks. P.J. Chidgey and G.R. Hill p1709
Error control strategies for cut-through switching network. C.-J. Chang and J.-I. Wang p1894
Ideal optical switching by nonlinear multiple (parasitic) core couplers. Y. Chen, A.W. Snyder and D.J. Mitchell p77
Integrated optics 4 × 4 switch matrix with digital optical switches. P. Granestrand, B. Lagerström, P. Svensson, L. Thylén, B. Stoltz, K. Bergvall, J.-E. Falk and H. Olofsson p4
Integrated structure for generalised connection networks employing optical switches. A.M. Hill, J.V. Wright and S. Srikanthan p1474 e1831

Integration of detectors with GaInAsP/InP carrier depletion optical switches. J.A. Cavaillès, M. Renaud, P. Jarry, M. Erman, J.F. Vinc[illegible]nt and A. Goutelle p1783
Interferometric-type polarisation splitter on Z-propagating $LiNbO_3$: Ti. J. Saulnier, F. Huet, L. Riviere, M. Carre and G. Caumont p1940
Low current plasma effect optical switch on InP. G. Müller, L. Stoll, G. Schulte-Roth and U. Wolff p115
Multiple quantum well directional coupler as a self-electro-optic effect device. B.P. Keyworth, M. Cada, J.M. Glinski, A.J. SpringThorpe, C. Rolland and K.O. Hill p2011
New retiming and synchronisation scheme for optical ATM switching systems. Y. Takahashi, K. Ando, M. Miyata and E. Amada p99
Optimisation of $LiNbO_3$ BOA waveguide switches operating at 1·3 μm. A. McGuire, A.P. Thomas and R.C. Booth p2077
Optoelectronic switching in travelling-wave MSM photodetectors using photon energies below bandgap. W.C. von Wendorff, M Welters and D. Jäger p1874
Polarisation independent switching and active separation of TE and TM modes with a GaAs/AlGaAs 2 × 2 switch. C. Wüthrich, J. Faist and F.K. Reinhart p476
Rearrangeable multichannel free-space optical switch using polarisation multiplexing technique. K. Noguchi, K. Hogari, T. Sakano and T. Matsumoto p1325
SYMFONET: ultra-high-capacity distributed packet switching network for telecoms and multiprocessor computer applications. P.A. Kirkby p19
Self-routing planar network for guided-wave optical switching systems. H. Obara, S. Okamoto, H. Uematsu and H. Matsunaga p520
Transfer matrix model for evaluation of optical switch structures. J.J. Dharmadi, H. Mulder, A. Diekema and A.G. de Waal p6
Twin core nonlinear couplers with saturable nonlinearity. Y. Chen p1374
Very low threshold Sagnac switch incorporating an erbium doped fibre amplifier. D.J. Richardson, R.I. Laming and D.N. Payne p1779

OPTICAL TRANSMISSION

10 Gbit/s, 100 km nonrepeatered fibre transmission experiment using a high-sensitivity semiconductor optical preamplifier. H. Nakano, S. Tsuji, K. Uomi, S. Sasaki and K. Yamashita p1364
20 Gbit/s no-chirp intensity modulation by DPSH-IM method and its fibre transmission through 330 ps/nm dispersion. M. Shirasaki, I. Yokota and T. Touge p33
2·8 Gbit/s optical soliton transmission employing all laser diodes. K. Iwatsuki, S. Nishi, M. Saruwatari and M. Shimizu p1
4 Gbit/s, 233-km optical fibre transmission experiment using newly proposed direct-modulation PSK. T. Naito, T. Chikama, G. Ishikawa and H. Kuwahara p1734
904 km, 1·2 Gbit/s non-regenerative optical fibre transmission experiment using 12 Er-doped fibre amplifiers. N. Edagawa, Y. Yoshida, H. Taga, S. Yamamoto, K. Mochizuki and H. Wakabayashi p66
All-optical switching of grating transmission using cross-phase modulation in optical fibres. S. LaRochelle, Y. Hibino, V. Mizrahi and G.I. Stegeman p1459
Field demonstration of 2·5 Gbit/s coherent optical transmission through installed submarine fibre cables. T. Imai, Y. Hayashi, N. Ohkawa, T. Sugie, Y. Ichihashi and T. Ito p1407
Field demonstration of coherent transmission system with diode-pumped erbium doped fibre amplifiers. M.J. Creaner, D. Spirit, G.R. Walker, N.G. Walker, R.C. Steele, J. Mellis, S. Al Chalabi, W. Hale, I. Sturgess, M. Rutherford, D. Trivett and M. Brain p442
Gain limitation of fibre Raman amplifiers considering third Stokes wavelength generation. M.-S. Kao and J. Wu p191
High-performance, two-channel optical FSK heterodyne system with polarisation diversity receiver. R. Noé, H. Rodler, G. Gaukel, B. Noll and A. Ebberg p1109
Highly bandwidth efficient transmission through continuous polarisation modulation. S. Benedetto and P. Poggiolini p1392
Hybrid-integrated laser/driver module for 10 Gbit/s optical fibre transmission. H. Nakano, K. Uomi, K. Yamashita and Y. Yagiu p145
Impact of spontaneous emission noise on the sensitivity of direct-detection lightwave receivers using optical amplifiers. O.K. Tonguz p1343
Multichannel video transmission over 100 km of step index singlemode fibre using a directly modulated 1537 nm distributed feedback laser. P.A. Rosher and S.C. Fenning p534
Novel linecoding scheme for optical transmission. L. Pophillat p2129
Novel optical frequency comb synthesis using optical feedback. P. Coppin and T.G. Hodgkinson p28
Over 350 km CPFSK repeaterless transmission at 2·5 Gbit/s employing high-output power erbium-doped fibre amplifiers. T. Sugie, T. Imai and T. Ito p1577
Repeaterless transmission with 62·9 dB power budget using a highly efficient erbium-doped fibre amplifier module. B. Clesca, A. Auge, B. Biotteau, P. Bousselet, A. Dursin, C. Clergeaud, P. Kretzmeyer, V. Lemaire, O. Gautheron, G. Grandpierre, E. Leclerc and P. Gabla p1426
Transmission experiment at 5 Gbit/s using 1300 nm Fabry–Perot type LD and PIN PD. Y. Hakamata, K. Isido and K. Takemoto p739
Two-channel coherent optical FDM transmission system with a new frequency stabilisation scheme. Q. Jiang, D.M. Wu and L.Z. Xie p310

OPTICAL WAVEGUIDE COMPONENTS

Arrayed-waveguide grating for wavelength division multi/demultiplexer with nanometre resolution. H. Takahashi, S. Suzuki, K. Kato and I. Nishi p87
Broadband silica-based optical waveguide coupler with asymmetric structure. A. Takagi, K. Jinguji and M. Kawachi p132
New TE/TM polarisation splitter made in Ti: $LiNbO_3$ using X-cut and Z-axis propagation. C. Duchet and N. Flaarønning p995
Optimisation of $LiNbO_3$ BOA waveguide switches operating at 1·3 μm. A. McGuire, A.P. Thomas and R.C. Booth p2077
TM-mode selective filter using lossy layer cladding optical waveguide. S. Ohke, S. Nishihara and Y. Cho p98
Y branching silica waveguide 1 × 8 splitter module. S. Kobayashi, T. Kitoh, Y. Hida, S. Suzuki and M. Yamaguchi p707
Y-branch wavelength multi/demultiplexer for $\lambda = 1{\cdot}30$ and $1{\cdot}55\,\mu$m. N. Goto and G.L. Yip p102

OPTICAL WAVEGUIDES

0Mach–Zehnder interferometer type optical waveguide coupler with wavelength-flattened coupling ratio. K. Jinguji, N. Takato, A. Sugita and M. Kawachi p1326
4·65 Gbit/s optical 4-bit pattern matching using silica-based waveguide circuit. J. Nishikido, M. Okuno and A. Himeno p1766
Arrayed-waveguide grating for wavelength division multi/demultiplexer with nanometre resolution. H. Takahashi, S. Suzuki, K. Kato and I. Nishi p87
Broadband polarisation splitting couplers in ion-exchanged glass. R.A. Betts and F. Lui p450
Broadband silica-based optical waveguide coupler with asymmetric structure. A. Takagi, K. Jinguji and M. Kawachi p132
Chemically stabilised ion implanted waveguides in sapphire. P.D. Townsend, P.J. Chandler, R.A. Wood, L. Zhang, J. McCallum and C.W. McHargue p1193
Diode laser waveguiding in polydiacetylene films. B. Rossi, W. Blau, J. O'Gorman, S. König, D. Westland and V. Skarda p312
Grafted GaAlAs rib waveguides on an InP substrate. A. Yi-Yan, M. Seto, T.J. Gmitter, D.M. Hwang and L.T. Florez p1567
Index profile of proton-exchanged waveguides in $LiNbO_3$ using pyrophosphoric acid. E.Y.B. Pun, T.C. Kong, P.S. Chung and H.P. Chan p81 e555 e555
Ion implanted waveguides in doped $LiNbO_3$. P.S. Chandler, L. Zhang and P.D. Townsend p332
Kramers–Kronig relations for nonlinear optics. K.A. Shore and D.A.S. Chan p1206
Low current plasma effect optical switch on InP. G. Müller, L. Stoll, G. Schulte-Roth and U. Wolff p115
Low drive voltage directional coupler optical switch with reduced voltage-length product. H. Okayama, T. Ushikubo and T. Ishida p374
Low loss optical ridge waveguides in a strained GeSi epitaxial layer grown on silicon. A. Splett, J. Schmidtchen, B. Schüppert, K. Petermann, E. Kasper and H. Kibbel p1035
Optical activity induced in $Bi_4Ge_3O_{12}$ waveguides by ion implantation. S.M. Mahdavi and P.D. Townsend p371
Power distribution in symmetric integrated optic X junction. S. Gevorgyan and A. Hovsepyan p788
Reduction of DC drift in $LiNbO_3$ waveguide electro-optic devices by phosphorus doping in SiO_2 buffer layer. T. Suhara, M. Fujimura, K. Kinoshita and H. Nishihara p1409
Reduction of the propagation losses in impurity disordered quantum well waveguides. M. O'Neill, J.H. Marsh, R.M. De La Rue, J.S. Roberts, C. Button and R. Gwilliam p1613
Single-quantum-well laser with 11·2 degree transverse beam divergence. Y.C. Chen, R.G. Waters and R.J. Dalby p1348
Single-step buried waveguides in glass by field-assisted copper ion-exchange. S.S. Gevorgyan p38
TM-mode selective filter using lossy layer cladding optical waveguide. S. Ohke, S. Nishihara and Y. Cho p98
Tunable couplers fabricated in K^+/Na^+ ion exchanged glass. R.A. Betts, F. Lui and E. Gauja p786
Very low-loss GeO_2-doped silica waveguides fabricated by flame hydrolysis deposition method. T. Kominato, Y. Ohmori, H. Okazaki and M. Yasu p327
Y-branch wavelength multi/demultiplexer for $\lambda = 1{\cdot}30$ and $1{\cdot}55\,\mu$m. N. Goto and G.L. Yip p102

OPTICS

2·8 Gbit/s optical soliton transmission employing all laser diodes. K. Iwatsuki, S. Nishi, M. Saruwatari and M. Shimizu p1
Competition between second and third harmonic generation in silica fibres. X.H. Zheng and J.E. Carroll p2065
Enhanced electro-optic polarisation rotation in AlGaAs/GaAs (111) quantum wells. S.M. Shank and G.W. Wicks p1769
Experimental observation of forward stimulated Brillouin scattering in dual-mode single-core fibre. P. St J Russell, D. Culverhouse and F. Farahi p1195
Growth of third-harmonic signal in optical glass fibre. U. Österberg p103
High performance single mode OTDR using coherent detection and fibre amplifiers. Y. Koyamada and H. Nakamoto p573
Ion implanted waveguides in doped $LiNbO_3$. P.S. Chandler, L. Zhang and P.D. Townsend p332
Low drive voltage directional coupler optical switch with reduced voltage-length product. H. Okayama, T. Ushikubo and T. Ishida p374
Noise characteristics of high-power doped-fibre superluminescent sources. P.R. Morkel, R.I. Laming and D.N. Payne p96
Novel method for linearising the power response of optical time domain reflectometers. M. Reich p1029 e1738
Observation of femtosecond beats using Raman radiation from SiO_2 optical fibres. L.H. Acioli, A.S.L. Gomes and C.B. de Araújo p92
Second-order nonlinearity of a disazo dye attached polymer. M. Amano and T. Kaino p981
Towards a coherent optical free-space communication system. K. Wallmeroth, B. Wandernoth, J. Franz, H. Meier and B. Schorp p572
Tunable single frequency operation of a diode laser pumped Nd : YAG microchip at 1·3 μm. F. Zhou and A.I. Ferguson p490
Verification of waveguide-type optical circulator operation. T. Mizumoto, H. Chihara, N. Tokui and Y. Naito p199

OPTIMAL CONTROL

Systolic linear quadratic optimal controller. F.M.F. Gaston and G.W. Irwin p1000

OPTIMAL FILTERING

Three-mirror fibre Fabry–Perot filters of optimal design. J. Stone, L.W. Stulz and A.A.M. Saleh p1073

OPTOELECTRONICS

10 Gbit/s optical transmitter module with MQW DFB-LD and DMT driver IC. T. Suzaki, Y. Suzuki, H. Yamada, S. Fujita, H. Hida, M. Kitamura and M. Shikada p151
30 GHz picosecond pulse generation from actively mode-locked erbium-doped fibre laser. A. Takada and H. Miyazawa p216
Analysis of the interference signal arising from the transmission of a pulse sequence through a monomode fibre. J. Capmany and M.A. Muriel p149
Broadband silica-based optical waveguide coupler with asymmetric structure. A. Takagi, K. Jinguji and M. Kawachi p132
Characterisation of an optoelectronically pulsed equiangular spiral antenna. Y. Pastol, G. Arjavalingam and J.-M. Halbout p133
Demonstration of packet switching through an integrated-optic tree switch using photo-conductive logic gates. K.K. Goel, P.R. Prucnal, Y. Shimazu, M. Milbrodt, E. Desurvire and B. Tell p287
Design of an InGaAlAs/InP '3mi' wavelength division demultiplexer employing a novel mode transformer. I.R. Croston and T.P. Young p336
Detectivity of gallium arsenide on silicon substrate photoconductive detectors. M. Constant, L. Boussekey, D. Decoster, B. Bartenlian and D. Pascal p239

Electroabsorption by semiconductor microcrystallites in glass: observation of Franz–Keldysh oscillations. D. Cotter and H.P. Girdlestone p183
Epitaxial lift-off of GaAs LEDs to Si for fabrication of opto-electronic integrated circuits. I. Pollentier, P. Demeester, A. Ackaert, L. Buydens, P. Van Daele and R. Baets p193
GaAs photoconductor array as new detector in multichannel spectroscopic system. M. Constant, L. Boussekey, D. Decoster and J.P. Vilcot p56
High performance buried ridge DFB lasers monolithically integrated with butt coupled strip loaded passive waveguides for OEIC. P.J. Williams, P.M. Charles, I. Griffith, L. Considine and A.C. Carter p142
High sensitivity 5 Gbit/s optical receiver module using Si IC and GaInAs APD. S. Fujita, T. Suzaki, A. Matsuoka, S. Miyazaki, T. Torikai, T. Nakata and M. Shikada p175
High sensitivity, high gain, long wavelength OEIC receiver with monolithically integrated three-stage preamplifier. J. Shimizu, T. Suzaki, T. Terakado, S. Fujita, K. Kasahara, T. Itoh and A. Suzuki p824
High speed opto-electronic neural network. N.M. Barnes, P. Healey, P. McKee, A.W. O'Neill, M.A.Z. Rejman-Greene, E.G. Scott, R.P. Webb and D. Wood p1110 e1739
High-power CW operation of broad area InGaAlP visible light laser diodes. K. Itaya, G. Hatakoshi, Y. Watanabe, M. Ishikawa and Y. Uematsu p214
High-power and high-speed semi-insulating BH structure monolithic electro-absorption modulator/DFB laser light source. H. Soda, M. Furutsu, K. Sato, N. Okazaki, S. Yamazaki, H. Nishimoto and H. Ishikawa p9
Hybrid-integrated laser/driver module for 10 Gbit/s optical fibre transmission. H. Nakano, K. Uomi, K. Yamashita and Y. Yagiu p145
Improved InP/InGaAs/InP *pin* detector response using a transparent conductor contact. J. Lee Russell, F. Kellert, E. Ehlers and D. Monahan p1231
InP optical switch array module high frequency performance: Measurements and analysis. D.H. Hartman, Y. Takahashi and H. Inoue p436
Integration of GaAs MESFETs and lithium niobate optical switches using epitaxial lift-off. A.C. O'Donnell, I. Pollentier, P. Demeester, P. Van Daele and A.D. Carr p179
Interdiffusion of InGaAs/InP quantum wells by germanium ion implantation. M.A. Bradley, F.H. Julien, J.P. Gilles, Y. Gao, E.V.K. Rao, M. Razeghi and F. Omnes p208
Lightwave scalar network analyser employing optical heterodyne detection. O. Ishida, H. Toba and F. Kano p297
Low current plasma effect optical switch on InP. G. Müller, L. Stoll, G. Schulte-Roth and U. Wolff p115
Low loss optical ridge waveguides in a strained GeSi epitaxial layer grown on silicon. A. Splett, J. Schmidtchen, B. Schüppert, K. Petermann, E. Kasper and H. Kibbel p1035
Microwave conductivity of optically excited gap in a semiconductor microstrip. S.S. Gevorgian p1921
Monolithic integration of an InP/InGaAs four-channel transimpedance optical receiver array. W.S. Lee, D.A.H. Spear, P.J.G. Dawe and S.W. Bland p1833
New electro-optic materials using guest-host systems. C.L. Adler and N.M. Lawandy p217
New reflection-type optoelectronic microwave switch for CW applications. N. Weber p455
Noise behaviour of InAlAs/GaInAs MSM photodetectors. H. Schumacher, J.B.D. Soole, H.P. LeBlanc, R. Bhat and M.A. Koza p612
Optical-fibre spectrum analyser. M.A. Page-Jones and J.K.A. Everard p117
Opto-electronic high order feedback neural network. D.R. Selviah, Z.Q. Mao and J.E. Midwinter p1954
Optoelectronic switch with low holding power. M. Kuijk, R. Pereira, M. Van Hove, R.P. Mertens, G. Borghs and J.I. Pankove p280 e555 e555
Optoelectronic synaptic connection circuit with variable analogue weights. H. Yonezu, T. Himeno, K. Kanamori, K. Pak and Y. Takano p910
Polarisation independent switching and active separation of TE and TM modes with a GaAs/AlGaAs 2 × 2 switch. C. Wüthrich, J. Faist and F.K. Reinhart p476
Reduction of the propagation losses in impurity disordered quantum well waveguides. M. O'Neill, J.H. Marsh, R.M. De La Rue, J.S. Roberts, C. Button and R. Gwilliam p1613
Surface-emitting laser diode with distributed Bragg reflector and buried heterostructure. M. Ogura, S. Mukai, M. Shimada, T. Asaka, Y. Yamasaki, T. Seki and H. Iwano p18
Uniformity in the performance characteristics of an 8 × 8 vertical to surface transmission electro-photonic device matrix. Y. Tashiro, I. Ogura, M. Sugimoto, N. Hamao and K. Kasahara p628
Velocity matching of III-V travelling-wave electro-optic modulator structures. M.R.T. Tan, I. Kim, J. Chang and S.Y. Wang p32
Widely tunable Y-coupled cavity integrated interferometric injection laser. M. Schilling, H. Schweizer, K. Dütting, W. Idler, E. Kühn, A. Nowitzki and K. Wünstel p243
Winner-take-all neural net with memory. J. Pankove, C. Radehaus and K. Wagner p349

OSCILLATION

Electroabsorption by semiconductor microcrystallites in glass: observation of Franz–Keldysh oscillations. D. Cotter and H.P. Girdlestone p183
Novel method to control numerical solution oscillation of diffusion-drift equation. H. Yie, C. Guoxiang and W. Yuanming p1487

OSCILLATORS

25 GHz dielectric resonantor oscillator using an AlGaAs/GaAs HBT. K. Ogawa, H. Ikeda, T. Ishizaki, K. Hashimoto and Y. Ota p1514
CW mm-wave GaAs TUNNETT diode. M. Pöbl, C. Dalle, J. Freyer and W. Harth p1540
Coherent operation of monolithically integrated master oscillator power amplifiers. D.F. Welch, D. Mehuys, R. Parke, R. Waarts, D. Scifres and W. Streifer p1327
Coherent optical ring using common local oscillator. M-S Kao and J. Wu p1013
Demodulation of multi-gigahertz frequency-modulated optical signals in an injection-locked distributed feedback laser oscillator. H. Nakajima p1129
Efficient power transfer through small apertures. P.G. Frayne and J. Potter p2070
Electronically steerable, monolithically integrated, master oscillator power amplifier. R. Parke, D. Welch, D. Mehuys, R. Waarts, R. Craig and D. Scifres p1076
High-efficiency AlGaAs/InGaAs heterostructure FET oscillators at V-band. H.Q. Tserng and P. Saunier p2048
Latch-up property and dynamic stability in sinusoidal oscillators. P. Martinez, A. Carlosena, S. Porta and S. Celma p542
Low phase noise heterojunction bipolar transistor oscillator. M. Ali Khatibzadeh and B. Bayraktaroglu p1246
Monte Carlo comparison of heterojunction cathode Gunn oscillators. C. Lee and U. Ravaioli p425
Noise tuning of GaAs-MESFET oscillators. L. Kreischer p315
Subharmonic injection locking phenomena in synchronous oscillators. C.R. Poole p1748
Synthesis procedure for active integrated radiating elements. V.F. Fusco and H.O. Burns p263
Systematic generation of OTA-C sinusoidal oscillators. R. Senani, M.P. Tripathi, D.R. Bhaskar and B.A. Kumar p1457
Temperature-stable VCO based on operational transconductance amplifiers. W.-S. Chung, H.-W. Cha and K.-H. Kim p1900
W-band monolithic oscillator using InAlAs/InGaAs HEMT. Y. Kwon, D. Pavlidis, M. Tutt, G.I. Ng, R. Lai and T. Brock p1425

PARALLEL PROCESSING

Real-world image segmentation using edge detection and subtraction. B. Qiu and M.G. Hartley p353

PATTERN RECOGNITION

Characterisation of line drawings using generalised Fourier descriptors. N.B.J. Weyland and R. Prasad p1794
Computation of Wigner–Ville distribution for complex data. S.S. Abeysekera p1315
Efficient systolic string matching. G.M. Megson p2040
Fast line detection algorithm using multivalued image coding. Y.S. Oh, Z. Bien and I.H. Suh p1400
Fuzzy intraframe smoothing of a noisy image. Q. Shen p908
L_1 normalisation in neural networks using parallel automatic level control. R. Perfetti p82
Recognising partially occluded objects by rigid body relaxation matching. T. Lee, R. Li and S.H. Kong p856
Systolic array for nonlinear multidimensional interpolation using radial basis functions. D.S. Broomhead, R. Jones, J.G. McWhirter and T.J. Shepherd p7

PHASE MODULATION

Algorithm for large-phase-modulation measurements. M.N. Zervas p112
Axial dependence of $\chi^{(2)}$ gratings in optical fibre: Effect of the intensity-dependent detuning. F. Ouellette p740
Influence of stimulated Brillouin scattering on phase modulated signals in optical fibres. A. Höök, A. Bolle, G. Grosso and M. Martinelli p470
Integrated-optic interferometric microdisplacement sensor in glass with thermo-optic phase modulation. D. Jestel, A. Baus and E. Voges p1144
Phase modulation characteristics of 1·5 μm strained-layer multiple quantum well laser amplifiers. D. Reichenbach, C.E. Zah, N. Andreadakis, F.J. Favire, S.G. Menocal, R. Vodhanel, A. Yi-Yan and T.P. Lee p1858
Reduced state sequence detection of full response continuous phase modulation. A. Svensson p652

PHASE-LOCKED LOOPS

10 Gbit/s optical PSK homodyne transmission experiments using external cavity DFB LDs. S. Norimatsu, K. Iwashita and K. Noguchi p648
2 Gbit/s PSK heterodyne communication system using optical phase-locked loop. D.A. Atlas and L.G. Kazovsky p1030
Delay, linewidth and bandwidth limitations in optical phase-locked loop design. R.T. Ramos and A.J. Seeds p389 e1922
Improved Allan variance real-time processing system to measure frequency tracking error of heterodyne optical phase-locked loops. C.-H. Shin and M. Ohtsu p1571
PSK optical homodyne system with nonlinear phase-locked loop. A. Schöpflin, S. Kugelmeier, E. Gottwald, D. Felicio and G. Fischer p395
Phase-locking of laser diodes. H.R. Telle and H. Li p858
Phased array beam steering using phase-locked loops. P.V. Brennan and A.W. Houghton p165

PHASE-SHIFT KEYING

2 Gbit/s PSK heterodyne communication system using optical phase-locked loop. D.A. Atlas and L.G. Kazovsky p1030
565 Mbit/s optical DPSK and PSK heterodyne transmission experiment using Nd : YAG lasers at 1·3 μm. A. Schoepflin p255
CSMA local radio networks with BPSK modulation in Rayleigh fading channels. K. Zhang and K. Pahlavan p1655
Crest factor minimisation in FDM PSK systems. B.T. Tan and Y.K. Some p859
Multichannel DPSK coherent optical communication systems. Y.H. Cheng and T. Okoshi p1378
New optimisation technique of error propagation over M-PSK modem. B. Honary and G. Markarian p408
PSK optical homodyne system with nonlinear phase-locked loop. A. Schöpflin, S. Kugelmeier, E. Gottwald, D. Felicio and G. Fischer p395
Performance of *M*-ary PSK signals in slow Rayleigh fading channels. N. Ekanayake p618
Slotted ALOHA radio networks with PSK modulation in Rayleigh fading channels. K. Zhang, K. Pahlavan and R. Ganesh d593

PHOTOCONDUCTING DEVICES

Detectivity of gallium arsenide on silicon substrate photoconductive detectors. M. Constant, L. Boussekey, D. Decoster, B. Bartenlian and D. Pascal p239
GaAs photoconductor array as new detector in multichannel spectroscopic system. M. Constant, L. Boussekey, D. Decoster and J.P. Vilcot p56
High-sensitivity and high-speed InGaAs photoconductive detector. M.V. Rao, G.-K. Chang and W.-P. Hong p756
Long wavelength infra-red photoconductive InAsSb detectors grown in Si wells by molecular beam epitaxy. W. Dobbelaere, J. De Boeck, M. Van Hove, K. Deneffe, W. De Raedt, R. Mertens and G. Borghs p259

PHOTODETECTORS

4 Gbit/s *pin*/HBT monolithic photoreceiver. S. Chandrasekhar, A.G. Dentai, C.H. Joyner, B.C. Johnson, A.H. Gnauck and G.J. Qua p1880
Chaotic behaviour in an illuminated semiconductor–(thin insulator)–semiconductor structure. V.A. Manasson, K.D. Tovstyuk and E.M. Shuster p1391
GaAs photoconductor array as new detector in multichannel spectroscopic system. M. Constant, L. Boussekey, D. Decoster and J.P. Vilcot p56
High speed 1·3 μm InGaAs/GaAs superlattice on Si photodetector. M. Zirngibl, J.C. Bischoff, M. Ilegems, J.P. Hirtz, B. Bartenlian, P. Beaud and W. Hodel p1027

Integration of detectors with GaInAsP/InP carrier depletion optical switches. J.A. Cavaillès, M. Renaud, P. Jarry, M. Erman, J.F. Vinchant and A. Goutelle p1783
Local growth of HgCdTe Layers by isothermal vapour phase epitaxy. Z. Djuric, Z. Djinovic, Z. Jaksic and D. Totovski p1005
Metal-semiconductor-metal photodetector on *p*-type $In_{0.53}Ga_{0.47}As$. J. Novák and L. Malacký p704
Metal–semiconductor–metal (MSM) photodetectors fabricated on MOCVD grown $Hg_{1-x}Cd_xTe$. P.W. Leech, N. Petkovic, P.J. Gwynn, G.N. Pain and J. Thompson p1848
Microwave conductivity of optically excited gap in a semiconductor microstrip. S.S. Gevorgian p1921
Monolithic integration of 1·5 μm optical preamplifier and pin photodetector with a gain of 20 dB and a bandwidth of 35 GHz. D. Wake, S.N. Judge, T.P. Spooner, M.J. Harlow, W.J. Duncan, I.D. Henning and M.J. O'Mahony p1166
Noise behaviour of InAlAs/GaInAs MSM photodetectors. H. Schumacher, J.B.D. Soole, H.P. LeBlanc, R. Bhat and M.A. Koza p612
Optoelectronic switching in travelling-wave MSM photodetectors using photon energies below bandgap. W.C. von Wendorff, M. Welters and D. Jäger p1874
Planar InP/InGaAs avalanche photodetector with integrated dielectric wavelength filter. M.D.A. MacBean, N.P. Hewett, M.D. Learmouth and I. Reid p804
Potential of the distributed amplifier as a photo-diode detector amplifier in high bit rate optical communication systems. C.S. Aitchison p1693
Room temperature IR photodetector with electromagnetic carrier depletion. Z. Djuric and J. Piotrowski p1689
Very high-speed metal–semiconductor–metal InGaAs : Fe photodetectors with InP : Fe barrier enhancement layer grown by low pressure metalorganic chemical vapour deposition. D. Kuhl, F. Hieronymi, E.H. Böttcher, T. Wolf, A. Krost and D. Bimberg p2107

PHOTODIODES

Characterisation and comparison of failure modes in III-V avalanche photodiodes. P.A. Putland p298
Gigabit high sensitivity receiver using InGaAs/InAlAs superlattice APD. Y. Miyamoto, K. Hagimoto and T. Kagawa p491
High-reliability flip-chip GaInAs/InP *pin* photodiode. O. Wada, T. Kumai, H. Hamaguchi, M. Makiuchi, A. Kuramata and T. Mikawa p1484
Integrated dielectric wavelength filters on InGaAs PIN photodetectors. M.D. Learmouth, N.P. Hewett, I. Reid and M.J. Robertson p576
Lateral Si avalanche photodiode fabricated over an etched interdigital mesa. M.-H. Chung, Y.-I. Choi and S.-K. Chung p1946
Role of satellite valleys in ionisation rate enhancement in multiple quantum well avalanche photodiodes. I.K. Czajkowski, J. Allam and A.R. Adams p1311

PHOTOELECTRIC DEVICES

High-sensitivity and high-speed InGaAs photoconductive detector. M.V. Rao, G.-K. Chang and W.-P. Hong p756
Long wavelength infra-red photoconductive InAsSb detectors grown in Si wells by molecular beam epitaxy. W. Dobbelaere, J. De Boeck, M. Van Hove, K. Deneffe, W. De Raedt, R. Mertens and G. Borghs p259
New method of analysing transient processes in picosecond photoconductive switch. Y. Lu p444
Optoelectronic synaptic connection circuit with variable analogue weights. H. Yonezu, T. Himeno, K. Kanamori, K. Pak and Y. Takano p910
Room temperature observation of mid-infrared inter-subband absorption activated by near-infrared illumination in multiple quantum wells. D. Delacourt, D. Papillon, J.P. Pocholle, J.P. Schnell and M. Papuchon p277

PHOTOEMISSION

Amplification in the 1300 nm telecommunications window in a Nd-doped fluoride fibre. J.E. Pedersen, M.C. Brierley, S.F. Carter and P.W. France p329 e555 e555

PHOTOTRANSISTORS

Wavelength demultiplexing heterojunction phototransistor. M.S. Ünlü, K. Kishino, J.-I. Chyi, J. Reed, L. Arsenault and H. Morkoç p1857

PIEZOELECTRIC DEVICES AND MATERIALS

Simple method for calculating optimum cut of piezoelectric material with small BAW generation by IDTs. J.H. Yin, Y. Shui, D. Zhang, J. Yu and P. Wu p1175

PIEZOELECTRIC TRANSDUCERS

Pressure measurement by GaAs piezoelectric sensors. K. Fricke and H.-L. Hartnagel p693

PLASMA WAVES

Auger recombination in quantum well InGaAs. A. Haug p1415
Highly tunable and efficient diode pumped operation of Tm^{3+} doped fibre lasers. W.L. Barnes and J.E. Townsend p746

POLARISATION

140 Mbit/s and 560 Mbit/s FSK heterodyne polarisation diversity receiver using nearly perfect square law demodulators. M.T. Tomesen, P.W. Hooijmans and K.G. Wright p1870
Chiral Maxwell–Garnett mixing formula. A.H. Sihvola and I.V. Lindell p118
Chiroshield: A Salisbury/Dallenbach shield alternative. D.L. Jaggard, N. Engheta and J. Liu p1332
Close-spaced fused fibre wavelength division multiplexers with very low polarisation sensitivity. I.J. Wilkinson and C.J. Rowe p382
Combined amplitude and polarisation shift keying optical coherent modulation. S. Benedetto and P. Poggiolini p918
Control of radar cross-section and crosspolarisation characteristics of an isotropic chiral sphere. A.K. Bhattacharyya p1066
DPSK polarisation diversity receiver with novel switching-demodulators and maximal-ratio combining. S. Neidlinger p1070
Dual-loop slot array antenna radiating circularly polarised wave. K. Hirose, H. Horiuchi and H. Nakano p179
Effects on polarisation of inclined conducting strip located in front of radiating slot. J. Hur and C.W. Lee p713
Electro-optic polarisation convertor on (110) InP. F. Zamkotsian, C. Artigue, J.-L. Peyre, J.-L. Lievin, M. Lambert, D. Bonnevie and J. Benoit p1560
Electromagnetic scattering from nonspherical particles: A new polarisability model with application to agglomerating spheres. L.E. Pierce and H. Weil p180
Enhanced electro-optic polarisation rotation in AlGaAs/GaAs (111) quantum wells. S.M. Shank and G.W. Wicks p1769
Er^{3+}-doped single-polarisation optical fibres. K. Tajima p1498
Exploiting fibre optics transmission capacity: 4-quadrature multilevel signalling. S. Betti, F. Curti, G. De Marchis and E. Iannone p992
Full duplex coherent optical communication with one in-line polarisation controller. M.O. van Deventer p758
Helical antenna and spiral antenna with fast switch selection of the polarisation sense. G. Mönich and B. Littmann p1918
High performance metal-clad fibre-optic polarisers. R. Willsch p1113
High performance packaged optical coherent hybrid. J-M.P. Delavaux and R. Riggs p1022
High-performance, two-channel optical FSK heterodyne system with polarisation diversity receiver. R. Noé, H. Rodler, G. Gaukel, B. Noll and A. Ebberg p1109
Highly bandwidth efficient transmission through continuous polarisation modulation. S. Benedetto and P. Poggiolini p1392
Interferometric-type polarisation splitter on Z-propagating $LiNbO_3$: Ti. J. Saulnier, F. Huet, L. Riviere, M. Carre and G. Caumont p1940
Measurement of polarisation beat length in single-mode optical fibres with a polarisation modulator. V.N. Filippov, O.I. Kotov and V.M. Nikolayev p658
New TE/TM polarisation splitter made in Ti : $LiNbO_3$ using X-cut and Z-axis propagation. C. Duchet and N. Flaarønning p995
Novel high precision alignment technique for polarisation maintaining fibres using a frequency modulated tunable laser. A. Ebberg and R. Noé p2009
Passive integrated optical polarisation mode-splitter in lithium niobate employing a resonant metal-loaded structure. C. Edge, P.J. Duthie and M.J. Wale p1855
Performance evaluation of multilevel polarisation shift keying modulation schemes. S. Benedetto and P. Poggiolini p244
Performance evaluation of polarisation shift keying modulation schemes. S. Benedetto and P. Poggiolini p256
Polarisation beam splitting using twin-elliptic-core optical fibres. G.D. Peng, T. Tjugiarto and P.L. Chu p682
Polarisation dependence of field-induced refractive index variation in strained and unstrained quantum well structures. T.C. Chong, H.W. Wan and S.J. Chua p1060
Polarisation independent switching and active separation of TE and TM modes with a GaAs/AlGaAs 2 × 2 switch. C. Wüthrich, J. Faist and F.K. Reinhart p476
Polarisation insensitive configuration of semiconductor laser amplifier. M. Sumida p1913
Polarisation- and pattern-independent optical FSK heterodyne system using data-induced polarisation switching. R. Noé, H. Rodler, G. Gaukel, A. Ebberg and F. Auracher p176
Polarisation-sensitive photodiode for the 632·8 nm spectral region. V.A. Manasson, Z.D. Kovalyuk, S.I. Drapak and V.N. Katerinchuk p664
Potential use of optimal polarisations in sensing the canting angle distribution of raindrops. A.P. Agrawal p157
Quadrature phase sampling of a fibre interferometer by input-polarisation switching. A.D. Kersey and M.J. Marrone p686
Singly-fed patch antenna radiating a circularly polarised conical beam. H. Nakano, K. Vichien, T. Sugiura and J. Yamauchi p638

POWER SEMICONDUCTOR DEVICES

Electronically steerable, monolithically integrated, master oscillator power amplifier. R. Parke, D. Welch, D. Mehuys, R. Waarts, R. Craig and D. Scifres p1076

POWER-SUPPLY CIRCUITS

Cyclic quasi-resonant convertor: a new quasi-resonant DC/DC convertor with improved characteristics. J.G. Cho and G.H. Cho p1821
Improved current mode control technique for quantum series resonant convertors. J.H. Ko, D.S. Oh and M.J. Youn p936
New zero-voltage-switching constant-frequency PWM DC/DC convertor with low switch stress and wide linearity. I.D. Kim, E.C. Nho and G.H. Cho p1320
Single ended resonant power supply for induction heating. J.M. Leisten, A.K. Lefedjiev and L. Hobson p814

PRINTED CIRCUITS

Rigorous closed-form expressions for the surface wave loss of printed antennas. D.M. Pozar p954

PULSE GENERATION

30 GHz picosecond pulse generation from actively mode-locked erbium-doped fibre laser. A. Takada and H. Miyazawa p216
Bandwidth-limited 0·3W picosecond pulses (4 ps) from a 1·53 μm microwave modulated DFB laser with fibre compression. L. Chusseau, J.M. Xie, L. Duvillaret, J.M. Lourtioz, A. Accard and J-P. Hebert p1085
Femtosecond fibre laser. M.E. Fermann, M. Hofer, F. Haberl and S.P. Craig-Ryan p1738
Femtosecond optical pulse generation using a distributed-feedback laser diode. M. Nakazawa, K. Suzuki and E. Yamada p2038
Generation of <3 ps optical pulses by fibre compression of gain-switched InGaAsP DFB laser diode pulses. R.T. Hawkins p292
Large amplitude picosecond step generation with FETs. A. Ouslimani, G. Vernet, H. Hafdallah and R. Adde p1563
Programmable splice-free quasi-monolithic 2 Gbit/s optical fibre pulse code generator. C.J.G. Kirkby, D.C.J. Reid and D.C. Jou p1673
Pulse forming and triggering using resonant tunnelling diode structures. E. Özbay, D.M. Bloom and S.K. Diamond p1046
Very high amplitude, minimal chirp optical pulse generation at 1·55 μm using multicontact DFBs and an erbium doped fibre amplifier. H. Sundaresan and G.E. Wickens p725

QUANTISATION

Room temperature negative differential resistance in the quasi-one-dimensional ballistic resistor. M.J. Kelly, R.J. Brown, M. Pepper, D.G. Hasko, H. Ahmed, D.C. Peacock, J.E.F. Frost, D.A. Ritchie and G.A.C. Jones p171

QUANTUM OPTICS

242 nm continuous tuning from a GRIN-SC-MQW-BH InGaAsP laser in an extended cavity. M. Bagley, R. Wyatt, D.J. Elton, H.J. Wickes, P.C. Spurdens, C.P. Seltzer, D.M. Cooper and W.J. Devlin p267
Carrier-induced refractive-index change, mode gain and spontaneous-emission factor in AlGaInP SQW-SCH laser diodes. T. Tanaka and S. Minagawa p766
Low threshold highly efficient strained quantum well lasers at 1·5 micrometre wavelength. U. Koren, M. Oron, M.G. Young, B.I. Miller, J.L. De Miguel, G. Raybon and M. Chien p465
Observation of field induced refractive index variation in GaInAs/InP quantum wire (QW) structure. T. Kikugawa, K.G. Ravikumar, T. Aizawa, S. Arai and Y. Suematsu p1012
Spectral linewidth reduction by low spatial hole burning in 1·5 μm multi-quantum-well $\lambda/4$-shifted DFB lasers. K. Uomi, S. Sasaki, T. Tsuchiya, M. Okai, M. Aoki and N. Chinone p52

QUEUING THEORY

Analysis of ATM switch model (GEO/ATD/1) with time priorities. J.M. Pitts and J.A. Schormans p1192
Analysis of a pre-emptive priority M/M/c model with two types of customers and restriction. B. Ngo and H. Lee p1190
Analysis of telecommunications switch model (GEO/D/1) with time priorities. J.A. Schormans, E.M. Scharf and J.M. Pitts p325
Analytic node model for deflection routing networks. A.M. Bignell and T.D. Todd p67
Multichannel local lightwave network with grouping property. S.H. Nam and C.K. Un p1436
Performance of the leaky bucket policing mechanism for small bucket depths. D.A. Hughes, G. Anido and H.S. Bradlow p1305
Reducing time delay of ARQ protocols by simple error-correcting codes. Q. Yang and V.K. Bhargava p1447
Resequencing delay characteristics of multilink system in packet switched networks. Y. Yoshida p1971

RADAR

Absolute phase of the radar target scattering matrix. E. Krogager p1834
Bistatic high resolution imaging on a monostatic range. W.F. Herdeg and H. Wendel p1476
Complementary Huffman sequences. S.Z. Budišin p533
Control of radar cross-section and crosspolarisation characteristics of an isotropic chiral sphere. A.K. Bhattacharyya p1066
Effect of unequal rise and fall times on the autocorrelation function of a PN sequence. F.E. Churchill p1838
Fuzzy algorithm for error-correcting estimation of radar signals. G. Guo and Q. Shen p1321
Merit factor of Chu and Frank sequences. M. Antweiler and L. Bömer p2068
New autofocusing technique for SAR images based on the Wigner-Ville distribution. S. Barbarossa p1533
New complementary pairs of sequences. S.Z. Budišin p881
New decomposition of the radar target scattering matrix. E. Krogager p1525
New multilevel complementary pairs of sequences. S.Z. Budišin p1861
Progressive bounds on merit factors. P.S. Moharir, K.R. Rajeswari and K.V. Rao p1584
Range determination in a multipath prone environment. G. Bortz, J.J. van Schalkwyk and W. Louw p1253
Simple parameter estimation technique in manoeuvring target tracking system. J.-A. Guu and C.-H. Wei p508
Simulation of the reduction characteristics of scattering from an aircraft coated with a thin-type absorber by the spatial network method. T. Kashiwa, N. Yoshida and I. Fukai p289

RADAR ANTENNAS

Control of radar cross-section and crosspolarisation characteristics of an isotropic chiral sphere. A.K. Bhattacharyya p1066

RADAR CROSS-SECTIONS

A step towards determining transient response of chiral materials: Kramers–Kronig relations for chiral parameters. N. Engheta and P.G. Zablocky p2132
Chiroshield: A Salisbury/Dallenbach shield alternative. D.L. Jaggard, N. Engheta and J. Liu p1332

RADAR RECEIVERS

AGC based on hard detected FFH signal matrices. I. Vajda p218

RADIATION AND RADIATION EFFECTS

Performance of CT2/CAI systems in small cell environments. J.E. Button p1434
Radiation of arbitrary shape symmetrical patch antenna coupled with a director. G. Dubost, S. Desclos and A. Zerguerras p1539
Tunable CW fibre Raman ring laser centred at 1·41 μm. E.J. Greer, P.G.J. Wigley and J.R. Taylor p579

RADIO LINKS

Computer simulation of indoor data channels with a linear adaptive equaliser. A. Zigic and R. Prasad p1596
Field test measurement for 128 Kbit/s QPSK signal transmission and delay time spread in 1·5 GHz-band land mobile radio. T. Furuno and S. Ogose p789
Outage probability analysis for microcell mobile radio systems with cochannel interferers in Rician/Rayleigh fading environment. Y.-D. Yao and A.U.H. Sheikh p864
Performance of a new adaptive diversity-equalisation for digitial mobile radio. H. Suzuki p626
Performance of the DECT system in fading dispersive channels. L.B. Lopes p1416
Propagation measurements at 1·. GHz for microcellular urban communications. R. Davies, A. Simpson and J.P. McGeehan p1053
Real-time prediction of attenuation for applications to fade countermeasures in satellite communications. L. Dossi p250
Statistics of clear-air attenuation on satellite links at 20 and 30 GHz. G. Ortgies, F. Rücker and F. Dintelmann p358

RADIO TRANSMITTERS

UHF band high-efficiency linear power amplifier for mobile communication satellites. K. Sekine, Y. Dooi, A. Iso, H. Funaki and I. Takei p441

RADIOCOMMUNICATION

Day-to-day variation of HF signal strength and noise. A.J. Gibson p761
Doppler spread measurements of indoor radio channel. S.J. Howard and K. Pahlavan p107
Path loss and multipath delay statistics in four European cities for 900 MHz cellular and microcellular communications. S.Y. Seidel, T.S. Rappaport and R. Singh p1713
Performance analysis of direct-sequence spread-spectrum multiple-access communication in an indoor Rician-fading channel with DPSK modulation. R. Prasad, H.S. Misser and A. Kegel p1366
Slotted ALOHA multihop packet radio networks with directional antennas. J. Zander p2098
Slotted ALOHA radio networks with PSK modulation in Rayleigh fading channels. K. Zhang, K. Pahlavan and R. Ganesh d593

RADIOWAVE PROPAGATION

1·7 GHz propagation measurements for highway microcells. S.T.S. Chia p1279
Application of the method of lines to cylindrical inhomogeneous propagation structures. M. Thorburn, A. Biswas and V.K. Tripathi p170
Autoregressive modelling of an indoor radio channel. S.J. Howard and K. Pahlavan p816
Comparison of a diffraction based radiowave propagation model with measurements. P. Eggers and P. Barry p530 e1097
Day-to-day variation of HF signal strength and noise. A.J. Gibson p761
Doppler spread measurements of indoor radio channel. S.J. Howard and K. Pahlavan p107
Effects of ice depolarisation on Ka-band satellite–earth path in stratus rainfall events. Y. Maekawa, N.S. Chang, A. Miyazaki and T. Segawa p2006
Effects of traffic and local movements on multipath characteristics of an indoor radio channel. R. Ganesh and K. Pahlavan p810
Extension of the multiparabolic ionospheric model to the F1-layer L-condition. D.C. Baker p1301
Indoor wideband radiowave propagation measurements at 1·3 GHz and 4·0 GHz. D.A. Hawbaker and T.S. Rappaport p1800
Measured radiometric satellite link attenuation estimation error statistics at 11·2 GHz. W.J. Vogel, G.W. Torrence and J.E. Allnutt p1503
Microwave attenuation due to rainfall at 21·255 GHz in the Singapore environment. T.S. Yeo, P.S. Kooi, M.S. Leong and S.S. Ng p1021
Modified Lin formula for calculating fading caused by hydrometeors on terrestrial paths in Czechoslovakia. V. Kvičera p1176
Parabolic equation modelling of propagation over irregular terrain. M.F. Levy p1153
Path loss and multipath delay statistics in four European cities for 900 MHz cellular and microcellular communications. S.Y. Seidel, T.S. Rappaport and R. Singh p1713
Radio propagation measurements at 850 MHz, 1·7 GHz and 4 GHz inside two dissimilar office buildings. D.M.J. Devasirvatham, M.J. Krain, D.A. Rappaport and C. Banerjee p445
Radio propagation over trapeozoidal plateau with sloping front face. J. Gong, T.S.M. Maclean and Z. Wu p604
Radiometric rain attenuation measurements at 11·6 GHz in Peru. A.W. Dissanayake, J.E. Allnutt and D.K. McCarthy p168
Rain rate measurements in Indonesia. M. Juy, R. Maurel, M. Rooryck, I.A. Nugroho and T. Hariman p596
Recovery effect in radiowave propagation. Z. Wu, T.S.M. Maclean, N. Jayasundere, L.J. Carter and A.G. Williamson p162
Results of site-diversity radiometric measurements at Ku-band in Brazil. C.G.S. Migliora, M.S. Pontes and L.A.R. Silva Mello p1552
Satellite Earth path attenuation at 11 GHz in Indonesia. M. Juy, R. Maurel, M. Rooryck, I.A. Nugroho and T. Hariman p1404
Shadowing variability in an urban land mobile environment at 900 MHz. M.J. Marsan, G.C. Hess and S.S. Gilbert p646
Slant path 30 to 12·5 GHz copolar phase difference, first results from measurements using the Olympus satellite. A. Mawira p1138
Statistical AR models for the frequency selective indoor radio channel. K. Pahlavan and S.J. Howard p1133
Statistics of duration and intensity of path loss in a microwave transhorizon sea-path. A.N. Tawfik and E. Vilar p474
Use of closely-spaced height diversity antennas to alleviate the effects of low angle non-absorptive fading on satellite slant paths. D.L. Bryant and J.E. Allnutt p479
Very low rain statistics for the design of low availability satellite communication systems. F. Barbaliscia and M. Boumis p417

RECEIVERS

Analytical expressions for the sensitivity penalty caused by large IF bandwidth in coherent optical ASK receivers with non-coherent IF detection. P.W. Hooijmans and M.T. Tomesen p1398
Basic performance of a direct conversion DECT receiver. G. Schultes, E. Bonek, P. Weger and W. Herzog p1746
Design of a hybrid receiver for the OLYMPUS spacecraft beacons. D.G. Sweeney and J.C. McKeeman p934
Low noise balanced receiver for coherent transmission systems. I. Hardcastle and A. Hadjifotiou p750
Robust framing receiver for 2·048 Mbit/s PCM systems. D.E. Dodds and S.M. Pan p1077
Symbol synchronisation for binary baseband PAM operating at only one sample per symbol. M. Moeneclaey and T. Bataele p691
Use of a fibre loop reflector as downstream receiver and upstream modulator in passive optical network. G. Nicholson p827

RECORDING

Two new equalisation schemes for high-density digital magnetic recording systems with quad-phase modulation code. J.W.M. Bergmans and S. Mita p13

RECURSIVE FILTERS

Novel systolic array for realising a second-order digital filter. D. Ait-Boudaoud and M.K. Ibrahim p388
Switched-capacitor lowpass filters based on recursive running sum cells. G. Fischer p557

REFLECTOR ANTENNAS

Corrugated dual feed for offset reflector antennas. K.-P. Dombek, V. Hombach, H. Scheffer and H. Thielen p1679
Ku band electric models for large deployable mesh reflector antenna. S. Sato, A. Iso, T. Orikasa and T. Sugimoto p2091
Scan limitations of shaped dual-offset reflector antennas for multiple satellite access. T.S. Bird and M.A. Sprey p228

REFRACTIVE INDEX PROFILES

High-contrast measurement of refractive-index profile in fused single-mode fibre couplers with high resolution by deconvolution. A.M. Oehler, T.M. Hauff, M. Moratzky and W.E. Heinlein p12
Index profile of proton-exchanged waveguides in $LiNbO_3$ using pyrophosphoric acid. E.Y.B. Pun, T.C. Kong, P.S. Chung and H.P. Chan p81 e555 e555
Polarisation-maintaining fibre using a novel glass system. Y.T. Ko, D.J. DiGiovanni, J.B. MacChesney and J.R. Simpson p876

REPEATERS

5 Gbit/s, 250 km error-free soliton transmission with Er^{3+}-doped fibre amplifiers and repeaters. K. Suzuki, M. Nakazawa, E. Yamada and Y. Kimura p551

RESISTORS

Novel voltage-controlled grounded resistor. Z. Wang p1711

RESONANCE

Elliptical microstrip antenna on ferrite substrate. S.S. Pattnaik, R.K. Mishra and N. Das p1906
High peak-to-valley current ratio AlGaAs/AlAs/GaAs double barrier resonant tunnelling diodes. V.K. Reddy, A.J. Tsao and D.P. Neikirk p1742
Pulse forming and triggering using resonant tunnelling diode structures. E. Özbay, D.M. Bloom and S.K. Diamond p1046
Transverse resonance method for analysing T-septum waveguides. Z.X. Shen, X.M. Lou and S.F. Li p78

RESONATORS

Electric, magnetic and open-wall cylindrical gyromagnetic resonators. A.A.P. Gibson p2073
Enhancement of Faraday rotation in a fibre Fabry–Perot cavity. J. Stone, R.M. Jopson, L.W. Stulz and S.J. Licht p849
Investigation on spectral behaviour of novel direct coupling compound fibre ring resonator. J. Capmany and M.A. Muriel p772
Phase-shifted Moiré grating fibre resonators. D.C.J. Reid, C.M. Ragdale, I. Bennion, D.J. Robbins, J. Buus and W.J. Stewart p10

SAMPLE-AND-HOLD CIRCUITS

0HgCdTe sampling circuit. R.A. Schiebel, J. Dodge and R. Gooch p702

SAMPLED-DATA SYSTEMS

Distortion minimisation in pulse width modulated systems using a digital sampling process. S.P. Leigh, P.H. Mellor and B.M.G. Cheetham p1310
Simplified complex digital sampling demodulator. T.E. Thiel and G.J. Saulnier p419
Some improvements to conventional importance sampling techniques for coded systems using Viterbi decoding. S.X. Chen, P.J. Smith, M. Shafi and D. Vere-Jones p802

SATELLITE LINKS

Effects of ice depolarisation on Ka-band satellite–earth path in stratus rainfall events. Y. Maekawa, N.S. Chang, A. Miyazaki and T. Segawa p2006
Maximum zeros scheduling for satellite switched TDMA. G.R. Tobin and L.W. Cahill p970
Measured radiometric satellite link attenuation estimation error statistics at 11·2 GHz. W.J. Vogel, G.W. Torrence and J.E. Allnutt p1503
Radiometric rain attenuation measurements at 11·6 GHz in Peru. A.W. Dissanayake, J.E. Allnutt and D.K. McCarthy p168
Real-time prediction of attenuation for applications to fade countermeasures in satellite communications. L. Dossi p250
Satellite Earth path attenuation at 11 GHz in Indonesia. M. Juy, R. Maurel, M. Rooryck, I.A. Nugroho and T. Hariman p1404
Scan limitations of shaped dual-offset reflector antennas for multiple satellite access. T.S. Bird and M.A. Sprey p228
Slant path 30 to 12·5 GHz copolar phase difference, first results from measurements using the Olympus satellite. A. Mawira p1138
UHF band high-efficiency linear power amplifier for mobile communication satellites. K. Sekine, Y. Dooi, A. Iso, H. Funaki and I. Takei p441
Use of closely-spaced height diversity antennas to alleviate the effects of low angle non-absorptive fading on satellite slant paths. D.L. Bryant and J.E. Allnutt p479
Very low rain statistics for the design of low availability satellite communication systems. F. Barbaliscia and M. Boumis p417

SCANNING ANTENNAS

Scan limitations of shaped dual-offset reflector antennas for multiple satellite access. T.S. Bird and M.A. Sprey p228

SCATTERING

Absolute phase of the radar target scattering matrix. E. Krogager p1834
Approximate solution to wave scattering by two coaxial spheroids. M.F.R. Cooray and I.R. Ciric p1371
Electromagnetic scattering from nonspherical particles: A new polarisability model with application to agglomerating spheres. L.E. Pierce and H. Weil p180
Experimental observation of forward stimulated Brillouin scattering in dual-mode single-core fibre. P. St J Russell, D. Culverhouse and F. Farahi p1195
Exterior moment method analysis of conducting scatterers by using the interior Green's function. K. Sawaya, S. Yatabe and S. Adachi p631
Influence of stimulated Brillouin scattering on phase modulated signals in optical fibres. A. Höök, A. Bolle, G. Grosso and M. Martinelli p470
Microwave scattering by metal cubes and the effect of perturbing the cube geometry. L.J. Auchterlonie, P.N. Fletcher and A.L. Hume p295
Overconstrained version of moment method for prediction of electromagnetic energy deposition inside dielectric objects. S. Caorsi, G.L. Gragnani and M. Pastorino p1997
RCS of three-dimensional scatterers using the symmetrical condensed TLM method. F.J. German, G.K. Gothard and L.S. Riggs p673
Scattering from a circular dielectric cylindrical shell: A fast algorithm. S. Jegannathan and B. Ramamurthi p484
Simulation of the reduction characteristics of scattering from an aircraft coated with a thin-type absorber by the spatial network method. T. Kashiwa, N. Yoshida and I. Fukai p289
Stimulated Raman scattering seeded by a fibre continuum. M.D. Selker and N.M. Lawandy p409

SCHOTTKY-BARRIER DEVICES

Barrier height enhancement of InP Schottky junctions by treatment with photodecomposed PH3. T. Sugino, H. Ito and J. Shirafuji e2137
MESFET fabrication on MOCVD grown $Hg_{1-x}Cd_xTe$. P.W. Leech, P.J. Gwynn, G.N. Pain, N. Petkovic and J. Thompson p221
Pseudomorphic GaInP Schottky diode and MSM detector on InP. S. Louaiche, A. Le Corre, A. Ginudi, L. Henry, C. Vaudry and F. Clerot p487

SELF-ADJUSTING SYSTEMS

Self-routing space switch network comprising fast and uniform switch elements. H. Obara, H. Uematsu, S. Okamoto and H. Matsunaga p352

SEMICONDUCTOR DEVICES AND MATERIALS

0GaAs–AlGaAs HBT with carbon doped base layer grown by MOMBE. F. Ren, C.R. Abernathy, S.J. Pearton, T.R. Fullowan, J. Lothian and A.S. Jordan p724
1·54 μm electroluminescence in MeV ion implanted Er-doped GaAs. P.B. Klein, F.G. Moore and H.B. Dietrich p1299
275 GHz 3-mask integrated GaAs sampling circuit. R.Y. Yu, M. Case, M. Kamegawa, M. Sundaram, M.J.W. Rodwell and A.W. Gossard p949
4 Gbit/s *pin*/HBT monolithic photoreceiver. S. Chandrasekhar, A.G. Dentai, C.H. Joyner, B.C. Johnson, A.H. Gnauck and G.J. Qua p1880
600 μm/min laser-induced nonthermal etching of GaAs in an HF solution. A.E. Willner, D.V. Podlesnik and R.M. Osgood p568
636 nm room temperature CW operation by heterobarrier blocking structure InGaAlP laser diodes. K. Itaya, M. Ishikawa and Y. Uematsu p839
94 GHz InP MMIC five-section distributed amplifier. R. Majidi-Ahy, M. Riaziat, C. Nishimoto, M. Glenn, S. Silverman, S. Weng, Y.C. Pao, G. Zdasiuk, S. Bandy and Z. Tan p91
AlGaAs/GaAs heterojunction bipolar transistors fabricated with various collector-carrier concentrations. Y. Ota, T. Hirose, A. Ryoji and M. Inada p203
Analysis of antireflection coatings on angled facet semiconductor laser amplifiers. M.C. Farries, J. Buus and D.J. Robbins p381
Analysis of the spontaneous emission rate of multiple-phase-shift distributed feedback semiconductor lasers. T. Makino p629
Angle resolved X-ray photoemission study of rapid thermal annealing applied to different GaAs and InP samples. A. Quemerais, G. Jezequel, H. L'Haridon, P.N. Favennec and M. Salvi p1119
Anisotype, enhancement-mode, heterojunction gate field-effect transistors. C.L. Lin, H.H. Wieder and R. Zuleeg p846
Anomalous drain-induced barrier lowering in short channel nmos devices at 77K. M.J. Deen p1493
Atmospheric pressure, low temperature (< 500°C) UV/ozone oxidation of silicon. V. Nayar, P. Patel and I.W. Boyd p205 e828
Barrier height enhancement of InP Schottky junctions by treatment with photodecomposed PH3. T. Sugino, H. Ito and J. Shirafuji e2137
Bipolar linear transconductor. W.-S. Chung and H.-W. Cha p619
Broadband operation of InGaAsP–InGaAs GRIN-SC-MQW BH amplifiers with 115 mW output power. M. Bagley, G. Sherlock, D.M. Cooper, L.D. Westbrook, D.J. Elton, H.J. Wickes, P.C. Spurdens and W.J. Devlin p512
Buried rectangular GaInAs/InP corrugations of 70 nm pitch fabricated by OMVPE. T. Yamamoto, Y. Miyamoto, M. Ogawa, E. Inamura and K. Furuya p875
Characterisation and comparison of failure modes in III-V avalanche photodiodes. P.A. Putland p298
Charge storage in InAlAs/InGaAs/InP floating gate heterostructures. J.A. Lott, J.F. Klem, H.T. Weaver, C.P. Tigges and V. Radoslovich-Cibicki p972
DC and RF performance of GaAs MESFET fabricated on silicon substrate using epitaxial lift-off technique. D.M. Shah, W.K. Chan, T.J. Gmitter, L.T. Florez, H. Schumacher and B.P. Van der Gaag p1865
DC and microwave performance of OMVPE-grown AlInAs/InP HEMTs. L. Aina, M. Serio, M. Mattingly, E. Hempfling and H. Chien p1912
Deep level transient spectroscopy of *n*-AlGaAs/GaAs high electron mobility transistors. J. Goostray, H. Thomas, D.V. Morgan, E. Kohn, A. Christou and S. Mottet p159
Delta doped tunnel diode: A new negative differential resistance device. J.M.A. Gilman and A.G. O'Neill p601
Design and realisation of very high performance 0·2 μm gate GaAs MESFETs. J. Vanbremeersch, E. Constant, J. Zimmermann, I. Valin, P. Godts and A. Leroy p152
Diode-laser pumped erbium-doped fluorozirconate fibre amplifier for the 1530 nm communications window. C.A. Millar and P.W. France p634
Doping level anomalies in *p*-InP resulting from exposure to dopant precursors during cool-down in MOVPE. S. Cole, W.J. Duncan, E.M. Marsh, P.J. Skevington and G.D.T. Spiller p391
Double heterojunction GaAlAs/GaAs I^2L integrated circuits. J.P. Vannel, A. Marty, J. Tasselli, A. Cazarré and J.P. Bailbé p969
Double-barrier resonant tunnelling diode three-state logic. A. Sellai, M.S. Raven, D.P. Steenson, J.M. Chamberlain, M. Henini and O.H. Hughes p61
Effects of etch depth and ion implantation on surface emitting microlasers. Y.H. Lee, J.L. Jewell, B. Tell, K.F. Brown-Goebeler, A. Scherer, J.P. Harbison and L.T. Florez p225
Effects of reoxidation on the hot-carrier immunity of 0·6 μm MOSFETs with nitrided oxides. G.Q. Lo and D.L. Kwong p1470
Electrical method for measuring emitter depth of shallow bipolar transistors. I.R.C. Post and P. Ashburn p30
Electrical properties of silicon dioxide deposited at low temperature by metal-organic microwave plasma CVD technique. S.K. Ray, C.K. Maiti and N.B. Chakrabarti p1082
Electrical transient study of negative resistance in SOI MOS transistors. O. Le Néel and M. Haond p73
Electron detrapping enhanced by electric field in AlGaAs/GaAs HEMTs. C. Canali, F. Magistrali, M. Sangalli, C. Tedesco and E. Zanoni p313
Enhanced electro-optic polarisation rotation in AlGaAs/GaAs (111) quantum wells. S.M. Shank and G.W. Wicks p1769
Evaluation of single ohmic metallisations for contacting both *p*- and *n*-type

GaInAs. L.G. Shantharama, H. Schumacher, H.P. Leblanc, R. Esagui, R. Bhat and M. Koza p1127
Experimental study of microwave reflection gain of AlAs/GaAs/AlAs quantum well structures. S.P. Stapleton, M.J. Deen, E. Berolo and R.H.S. Hardy p84
Extremely low-resistance nonalloyed ohmic contacts on molecular beam epitaxially grown *p*-type Ge. M.S. Ünlü, S. Strite, K. Adomi, G.B. Gao and H. Morkoç p89
Fabrication of sub-50 nm poly-Si/SiO_2/Si narrow wires using electron beam lithography and CF_4/O_2 reactive ion etching. Y.S. Tang, R. Cheung and C.D.W. Wilkinson p1823
GaAs MESFET amplifiers fabricated on InP substrates. J. Jeong, G.P. Vella-Coleiro and C.M.L. Yee p135
GaAs W-band impatt diodes for very low-noise oscillators. H. Eisele p109
Gallium arsenide pseudo-current-mode logic. R.A. Duncan, K.C. Smith and A.S. Sedra p2130
Gate oxide thickness dependence of high-field-induced interface state generation in thin thermal oxides. G.Q. Lo and D.L. Kwong p1124
Growth of high quality InP with metal organic molecular beam epitaxy. H. Heinecke, R. Höger, B. Baur and A. Miklis p213
Heavily doped base GaInP/GaAs heterojunction bipolar transistor grown by chemical beam epitaxy. F. Alexandre, J.L. Benchimol, J. Dangla, C. Dubon-Chevallier and V. Amarger p1753
Heterostructure bipolar transistor employing carbon-doped base grown with trimethyl-Ga and arsine. T.Y. Kuo, T.H. Chiu, J.E. Cunningham, K.W. Goossen, C.G. Fonstad and F. Ren p1260
Heterostructure field effect transistor with doping dipole in charge control layer. J. Zou, A. Gopinath, T. Akinwande and M.S. Shur p964 e1832
High current gain GaInAs/InP hot electron transistor. S. Yamaura, Y. Miyamoto and K. Furuya p1055
High efficiency 1·3 μm superluminescent diode with absorbing tapered waveguide. K. Magari, Y. Noguchi, K. Okamoto, H. Yasaka, H. Nagai and O. Mikami p1445
High frequency *Pnp* AlGaAs/InGaAs heterojunction bipolar transistor with an ultrathin strained base. W.U. Liu, D. Hill, D. Costa and J.S. Harris, Jun p2000
High peak-to-valley current ratio AlGaAs/AlAs/GaAs double barrier resonant tunnelling diodes. V.K. Reddy, A.J. Tsao and D.P. Neikirk p1742
High performance $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As$ HFETs. H. Dämbkes, P. Marschall, Y.H. Zhang and K. Ploog p488
High performance GaAs MESFETs grown on InP substrates by MOCVD using tertiarybutylarsine. J. Jeong, R.M. Lum, J.K. Klingert, R. Bylsma, G.P. Vella-Coleiro and P.R. Smith p482
High performance resonant tunnelling structures on GaAs substrates. H. Riechert, D. Bernklau, J.-P. Reithmaier and R.D. Schnell p340
High performance submicron pseudo-MODFETs and 2:1 multiplexers using GaAs on InP heteroepitaxial technology. Y.H. Lo, M. Bagheri, P.S.D. Lin, P. Grabbe, R. Bhat, N.G. Stoffel, T.P. Lee and D.T. Kong p807
High voltage floating gate array transistors. M. Levinson, P. Rossoni, F. Rock and B.M. Ditchek p777
High-efficiency coupling of laser diodes in tapered proton-exchanged waveguides. K. Mizuuchi, K. Yamamoto and T. Taniuchi p1992
High-reliability flip-chip GaInAs/InP *pin* photodiode. O. Wada, T. Kumai, H. Hamaguchi, M. Makiuchi, A. Kuramata and T. Mikawa p1484
Hydrogen passivation of high purity *n*-type InP. C.G. Crookes, D. Lancefield, K. Waterhouse, A.R. Adams, P.D. Greene and R.W. Glew p369
Identification and localisation of gate oxide weaknesses in *n*-MOS transistors through Fowler–Nordheim tunnelling and SPICE simulation. D. Krakauer and B.S. Doyle p230
Impedance analysis of GaAs/Al(Ga)As resonant tunnel diodes in the NDR region. A. Zarea, A. Sellai, M.S. Raven, D.P. Steenson, J.M. Chamberlain, M. Henini and O.H. Hughes p1522
Improved InP/InGaAs/InP *pin* detector response using a transparent conductor contact. J. Lee Russell, F. Kellert, E. Ehlers and D. Monahan p1231
Improving the characteristics of InAlAs/InGaAs heterojunction bipolar transistors by employing thin base and collector layers. H. Fukano, Y. Kawamura, H. Asai, Y. Takanashi and M. Fujimoto p1101
InAlAs/InGaAs/InP junction HEMTs. J.B. Boos, S.C. Binari, W. Kruppa and H. Hier p1172
Influence of the interfacial oxide layer on the gain of polycrystalline silicon emitter bipolar transistors processed in VLSI BiCMOS technology. G. Giroult-Matlakowski, N. Degors, A. Marty, A. Chantre and A. Nouailhat p1002
Kink effect, transconductance increase and field enhanced electron emission in AlGaAs/GaAs HEMTs. C. Canali, C. Tedesco, E. Zanoni, G. Castellaneta, F. Magistrali and M. Sangalli p1520
Kink-free AlInAs/GaInAs/InP HEMTs grown by molecular beam epitaxy. L.F. Luo, K.F. Longenbach and W.I. Wang p779
Laser-annealed refractory metal silicide films on GaAs. W.T. Anderson, A. Christou, P.E. Thompson, C.R. Gossett, J.M. Eridon, Z. Hatzopoulos, T. Efthimiopoulos, M. Kudumas, C. Michelakis and D.V. Morgan p62
Lateral Si avalanche photodiode fabricated over an etched interdigital mesa. M.-H. Chung, Y.-I. Choi and S.-K. Chung p1946
Lateral drift and recombination of photogenerated carriers in multiple quantum well hetero *nipi* structures. C. Thirstrup, P.L.K. Wa, C.C. Button, J.S. Roberts and P.N. Robson p1935
Lateral nonuniform doping technique and its application to the fabrication of GaAs MESFETs with a lateral linear doping channel. H. Dejun p432
Local growth of HgCdTe Layers by isothermal vapour phase epitaxy. Z. Djuric, Z. Djinovic, Z. Jaksic and D. Totovski p1005
Low phase noise heterojunction bipolar transistor oscillator. M. Ali Khatibzadeh and B. Bayraktaroglu p1246
Low voltage InGaAs/InP multiple quantum well reflective Fabry–Perot modulator. A.J. Moseley, J. Thompson, M.Q. Kearley, D.J. Robbins and M.J. Goodwin p913
Low-threshold GRIN-SCH AlGaInAs 1·55 μm quantum well buried ridge structure lasers grown by molecular beam epitaxy. C. Kazmierski, M. Blez, M. Quillec, M. Allovon and B. Sermage p889
MESFET fabrication on MOCVD grown $Hg_{1-x}Cd_xTe$. P.W. Leech, P.J. Gwynn, G.N. Pain, N. Petkovic and J. Thompson p221
MOCVD grown carbon-doped graded-base AlGaAs/GaAs HBTs. H. Ito p1977
Matrix-addressed 4 × 4 spatial light modulator using the quantum confined stark effect in GaAs/AlGaAs quantum wells. K. McIlvaney, J.H. Marsh, J.S. Roberts and C. Button p1691
Metal-semiconductor-metal photodetector on *p*-type $In_{0.53}Ga_{0.47}As$. J. Novák and L. Malacký p704
Metal–semiconductor–metal (MSM) photodetectors fabricated on MOCVD grown $Hg_{1-x}Cd_xTe$. P.W. Leech, N. Petkovic, P.J. Gwynn, G.N. Pain and J. Thompson p1848
Methane/hydrogen metal organic reactive ion etching of GaInAsP compounds. J. Keskinen, J. Näppi, H. Asonen and M. Pessa p1369 e1832
Mg-doped graded base GaAs/AlGaAs heterojunction bipolar transistors grown by metalorganic vapour phase epitaxy. H. Tews, P. Zwicknagl, R. Neumann, G. Jaeger, A. Hoepfner, L. Schleicher and G. Packeiser p58
Modelling DC characteristics of GaAs MESFET devices using a simple and accurate analytic tool. S.A. Ibrahim and S. El-Rabaie p1892
Modelling of electron mobility in silicon MOS inversion and accumulation layers at liquid helium temperature. I.M. Hafez, A. Emrani, G. Ghibaudo and F. Balestra p1633
Monolayer Be δ-doped heterostructure bipolar transistor fabricated using doping selective base contact. T.Y. Kuo, J.E. Cunningham, K.W. Goossen, W.Y. Jan, C.G. Fonstad and F. Ren p1187
Monolithic integration of an InGaAs/GaAs/AlGaAs strained layer SQW LED and GaAs MESFET using epitaxial lift-off. I. Pollentier, L. Buydens, A. Ackaert, P. Demeester, P. Van Daele, F. De Pestel, D. Lootens and R. Baets p925 e1324
Monolithically integrated $In_{0.53}Ga_{0.47}As/In_{0.52}Al_{0.48}As$ (on InP) MSM/HFET photoreceiver grown by MBE. H.T. Griem, H.S. Fuji, T.J. Williams, J.P. Harrang, R.R. Daniels, S. Ray, M.J. LaGasse and D.L. West p1198
Negative R_i and R_d in GaAs FET and HEMT equivalent circuits. P.H. Ladbrooke, A.J. Hill and J.P. Bridge p680
New GaSb/AlSb/GaSb/AlSb/InAs/AlSb/InAs triple-barrier interband tunnelling diode. L. Yang, J.F. Chen and A.Y. Cho p1277
New distributed package model for the dual gate FET. H. Xue, M.J. Howes and C.M. Snowden p1207
New generation MMIC amplifier using InGaAs/InAlAs HEMTs. M. Weiss, G.I. Ng and D. Pavlidis p264
New submicron MOSFET structural concept for suppression of hot carriers. A.F. Tasch, H. Shin and C.M. Maziar p39
Novel AlInAs/InP HEMT. O. Aina, M. Serio, M. Mattingly and E. Hempfling p651
Novel distributed-feedback resonant-periodic-gain structure for vertical-cavity surface-emitting semiconductor lasers. M. Mahbobzadeh and M. Osiński p1716
Novel doubly self-aligned AlGaAs/GaAs HBT. W.U. Liu, D. Costa and J. Harris p1361
Novel integral heatsink structures for power MMICs. P.R. Bestwick, I. Davies and K.C. Vanner p1050
Novel low temperature RF plasma annealing using NH_3–N_2 gas mixture. K. Aite, F.W. Ragay and J. Middelhoek p733
Novel merged BiCMOS circuit structures. A. Bellaouar and M.I. Elmasry p1555
Novel pressure sensors with multilayer SOI structures. G.S. Chung, S. Kawahito, M. Ishida and T. Nakamura p775
Observation of field induced refractive index variation in GaInAs/InP quantum wire (QW) structure. T. Kikugawa, K.G. Ravikumar, T. Aizawa, S. Arai and Y. Suematsu p1012
Optically-coupled mirror-quantum well InGaAs-GaAs light emitting diode. D.G. Deppe, J.C. Campbell, R. Kuchibhotla, T.J. Rogers and B.G. Streetman p1665
Optimised design for a 0·5 μm gate length *n*-channel SOI MOSFET. G.A. Armstrong and W.D. French p1196
Packaged 2 × 2 array of InGaAs/InP multiple quantum well modulators grown by double-sided epitaxy. M.A.Z. Rejman-Greene and E.G. Scott p946
Photoluminescence spectroscopy measurements of elastic strain in heteroepitaxial GaAs films. T.P. Humphreys, R.J. Nemanich, K. Das, N.R. Parikh and J.B. Posthill p835
Planar InP/InGaAs avalanche photodetector with integrated dielectric wavelength filter. M.D.A. MacBean, N.P. Hewett, M.D. Learmouth and I. Reid p804
Polarisation-sensitive photodiode for the 632·8 nm spectral region. V.A. Manasson, Z.D. Kovalyuk, S.I. Drapak and V.N. Katerinchuk p664
Polarity dependence of charge to breakdown and interface state generation of oxynitride gate dielectrics prepared by rapid thermal processing. A.B. Joshi, G.Q. Lo, D.L. Kwong and J. Xie p1741
Practical reduction of dislocation density in SIMOX wafers. S. Nakashima and K. Izumi p1647
Pressure measurement by GaAs piezoelectric sensors. K. Fricke and H.-L. Hartnagel p693
Proposed semiconductor narrow-band wavelength filter using directional coupler. A. Wakatsuki, K. Okamoto and O. Mikami p1573
Proposed ultrahigh frequency microstrip utilising buried silicide groundplane. K.W. Goossen, A.E. White and K.T. Short p49 e555 e555
Pseudomorphic GaInP Schottky diode and MSM detector on InP. S. Loualiche, A. Le Corre, A. Ginudi, L. Henry, C. Vaudry and F. Clerot p487
Pulse forming and triggering using resonant tunnelling diode structures. E. Özbay, D.M. Bloom and S.K. Diamond p1046
Resonant tunnelling structures with very thin contact layers using nonalloyed Ge/Pd contacts. C. Van Hoof, J. Genoe, M. Van Hove, Ph. Jansen, M. Van Rossum and G. Borghs p797
Role of satellite valleys in ionisation rate enhancement in multiple quantum well avalanche photodiodes. I.K. Czajkowski, J. Allam and A.R. Adams p1311
Room temperature IR photodetector with electromagnetic carrier depletion. Z. Djuric and J. Piotrowski p1689
Room temperature negative differential resistance in a triple well rectifying resonant tunnelling diode. C.R. Bolognesi, R.S. Mand and A.R. Boothroyd p1163
Selective plasma etching of Si from GaAs-on-Si wafers for microwave via-hole formation. G.W. Turner, C.L. Chen, M.K. Connors, L.J. Mahoney and W.L. McGilvary p854
Selective silicon epitaxial growth by LPCVD using silane. G.J. Parker and C.M.K. Starbuck p831
Simple extraction method for mobility parameters in Si-MOSFETs at 77 K. J.I. Lee, M.B. Lee, K.N. Kang and K.O. Park p852
Simple method to extract gate voltage dependent source/drain resistance in MOSFETs. J.I. Lee, M.B. Lee, Y.J. Lee, I.K. Han, K.N. Kang and K.O. Park p1806
Single quantum well edge emitting broadband LED. J. Mantz, H. Hager, E. Chan and C.S. Hong p1807
Solution of Poisson equation in p-$Al_xGa_{1-x}As$/p-$Al_{0.45}Ga_{0.55}As$/n-GaAs structures. S.C. Kwok p894
Strained layer AlGaAs–GaAs–InGaAs real-space transferred electron devices. M.E. Favaro, J.J. Alwan, R.P. Bryan, L.M. Miller, J.J. Coleman, J. Kim and C.M. Wayman p1264
Submicron-gate ion-implanted $In_{0.15}Ga_{0.85}As$/GaAs MESFETs with graded indium composition. G.W. Wang, M. Feng, R. Kaliski and J.B. Kuang p190
Suppression of InP substrate degradation by hydrogen plasma caused by the presence of phosphorus vapour. R. Schütz, K. Matsushita, H.L. Hartnagel, J.Y. Longère and S.K. Krawczyk p564
Temperature dependence of electron saturation velocity in GaAs. R. Allam and J. Pribetich p688
Temperature dependent barrier heights in bulk unipolar diodes leading to improved temperature stable performance. M.J. Kearney, M.J. Kelly, A. Condie and I. Dale p671

The effect of *n*-type dopant species on the compensating effects of oxygen implantation in GaAs. N.J. Whitehead and B.J. Sealy p866
Transconductance dependence on gate length for GaAs gate pseudomorphic and conventional SISFETs at 300 and 77 K. P.E. Schmidt, E. Barbier, P. Collot, C. Gaonach, M. Champagne and D. Pons p210
Two-dimensional electron gas base hot electron transistor. P. Matthews, M.J. Kelly, V.J. Law, D.G. Hasko, M. Pepper, H. Ahmed, D.C. Peacock, J.E.F. Frost, D.A. Ritchie and G.A.C. Jones p862
Ultra high transconductance 0·25 μm gate MESFET with strained InGaAs buffer layer. A. Cappy, G. Dambrine, Y. Cordier, Y. Druelle and P. Legry p161
Ultra-high gain, low noise monolithic InP HEMT distributed amplifier from 5 to 40 GHz. C. Yuen, Y.C. Pao, M. Day, C. Nishimoto, M. Glenn, S. Bandy and G. Zdasiuk p515
Ultra-low reflectivity broadband 1·5 μm GaInAsP semiconductor optical amplifiers. P.E. Barnsley, J.J. Isaac and D.J. Elton p825
Use of a methane/hydrogen plasma for gate recessing of E/D MESFETs. R. Pereira, M. Van Hove, M. de Potter and M. Van Rossum p462
Using constant base current as a boundary condition for one-dimensional AlGaAs/GaAs heterojunction bipolar transistor simulation. L.L. Liou and C.I. Huang p1501
Vertical integration of an $In_{0.15}Ga_{0.85}As$ modulation-doped field effect transistor and GaAs laser grown by molecular beam epitaxy. S.D. Offsey, P.J. Tasker, W.J. Schaff, L. Kapitan, J.R. Shealy and L.F. Eastman p350
Very low resistivity ohmic contact to *p*-type GaAs using $In_xGa_{1-x}As$ interlayer. P.L. Janega, F. Chatenoud and Z. Wasilewski p1395
Very low-noise $Al_{0.3}Ga_{0.7}As/Ga_{0.65}In_{0.35}As/GaAs$ single quantum-well pseudomorphic HEMTs. P.C. Chao, P. Ho, K.H.G. Duh, P.M. Smith, J.M. Ballingall, A.A. Jabra, N. Lewis and E.L. Hall p27
Waveguided electro-optical intensity modulation in a $Si/Ge_xSi_{1-x}/Si$ heterojunction bipolar transistor. R.D. Lareau, L. Friedman and R.A. Soref p1653
n-AlInAs/$(InAs)_1(GaAs)_1$ superlattice modulation-doped field effect transistor grown by molecular beam epitaxy. N. Nishiyama, H. Yano, S. Nakajima and H. Hayashi p885

SEMICONDUCTOR DEVICES AND MATERIALS TESTING

Chaotic behaviour in an illuminated semiconductor–(thin insulator)–semiconductor structure. V.A. Manasson, K.D. Tovstyuk and E.M. Shuster p1391
Characterisation and comparison of failure modes in III-V avalanche photodiodes. P.A. Putland p298
Estimation of temperature limit for negative differential resistance using resonant tunnelling. L. De Saint Pol, O. Vanbesien and D. Lippens p342
Preliminary reliability studies of 1·55 μm graded index separate confinement buried heterostructure (GRINSCH) multiple quantum well (MQW) lasers grown by metalorganic vapour phase epitaxy (MOVPE). R.M. Redstall, A.P. Skeats, D.M. Cooper and A.L. Burness p1132
Simple method to extract gate voltage dependent source/drain resistance in MOSFETs. J.I. Lee, M.B. Lee, Y.J. Lee, I.K. Han, K.N. Kang and K.O. Park p1806

SEMICONDUCTOR DOPING

Effects of zinc doping in DFB lasers emitting at 1·3 and 1·55 μm. M. Sugano, H. Sudo, H. Soda, T. Kusunoki and H. Ishikawa p95
Interdiffusion of InGaAs/InP quantum wells by germanium ion implantation. M.A. Bradley, F.H. Julien, J.P. Gilles, Y. Gao, E.V.K. Rao, M. Razeghi and F. Omnes p208
Semiconductor-doped glass waveguide electro-absorption modulator. J. Bell and C.N. Ironside p976

SEMICONDUCTOR GROWTH

Extremely low-resistance nonalloyed ohmic contacts on molecular beam epitaxially grown *p*-type Ge. M.S. Ünlü, S. Strite, K. Adomi, G.B. Gao and H. Morkoç p89
Growth of Al:Er:O alloys on silicon. M. Kechouane, H. L'Haridon, M. Salvi, P.N. Favennec, D. Moutonnet, M. Gauneau and J.P. Mercier p1067
Growth of high quality InP with metal organic molecular beam epitaxy. H. Heinecke, R. Höger, B. Baur and A. Miklis p213
High efficiency, high uniformity, grating coupled surface emitting lasers. R. Parke, R. Waarts, D.F. Welch, A. Hardy and W. Streifer p125
Reliable 1·3 μm gain guided stripe lasers grown by MOCVD using ethyldimethylindium as the In source. C. Blaauw, T.F. Devenyi, B. Capron, F.R. Shepherd and A.J. Springthorpe p1291
Surface-emitting laser diode with distributed Bragg reflector and buried heterostructure. M. Ogura, S. Mukai, M. Shimada, T. Asaka, Y. Yamasaki, T. Seki and H. Iwano p18

SEMICONDUCTOR JUNCTIONS

Evaluation of currents in the fA range. P. Girard and P. Nouet p844
Optoelectronic switch with low holding power. M. Kuijk, R. Pereira, M. Van Hove, R.P. Mertens, G. Borghs and J.I. Pankove p280 e555 e555

SEMICONDUCTORS

Electrical test structure for measuring polysilicon-to-active mask misalignment. M. Syrzycki p1009
Extremely low-resistance nonalloyed ohmic contacts on molecular beam epitaxially grown *p*-type Ge. M.S. Ünlü, S. Strite, K. Adomi, G.B. Gao and H. Morkoç p89
Luminescent Er doped microparticles in a semiconductor matrix. P.N. Favennec, H. L'Haridon, D. Moutonnet, M. Salvi and A.C. Papadopoulo p1556
Simple model for space-charge region capacitance of an exponential-constant *p–n* junction. F.D. Ho p2063

SEMICONDUCTORS (III-V)

Interdiffusion of InGaAs/InP quantum wells by germanium ion implantation. M.A. Bradley, F.H. Julien, J.P. Gilles, Y. Gao, E.V.K. Rao, M. Razeghi and F. Omnes p208

SENSITIVITY

Analytical expressions for the sensitivity penalty caused by large IF bandwidth in coherent optical ASK receivers with non-coherent IF detection. P.W. Hooijmans and M.T. Tomesen p1398
Current mode allpass/notch and bandpass filters with reduced sensitivities. A. Fabre, F. Martin and M. Hanafi p1495
Unified approach to analyse mass sensitivities of acoustic gravimetric sensors. Z. Wang, J.D.N. Cheeke and C.K. Jen p1511

SHIFT REGISTERS

3·4 GHz silicon bipolar versatile shift register and 6·8 Gbit/s word generator. B. Wüppermann, U. Langmann and A. Pottbäcker p553

SIGNAL PROCESSING

130 Mbit/s (H4 rate) HDTV CODEC based on the DCT algorithm. T. Kinoshita, T. Nakahashi and Y. Eto p1245
4·65 Gbit/s optical 4-bit pattern matching using silica-based waveguide circuit. J. Nishikido, M. Okuno and A. Himeno p1766
Algorithm for computing two-dimensional discrete Hartley transform of size $p^n \times p^n$. W. Ma p1795
Applications of a first-generation current conveyor in current-mode circuits. P. Aronhime, D. Nelson and C. Adams p1456
Bearing estimation of coherent sources by circular spatial modulation averaging (CSMA) technique. B.L. Lim, S.K. Hui and Y.L. Lim p343
Companding in signal processing. Y.P. Tsividis, V. Gopinathan and L. Tóth p1331
Computational improvement in the calculation of the natural log of a square matrix. D.L. Cooper and S. Bingulac p861
Conjugate pair fast Fourier transform. I. Kamar and Y. Elcherif d541
Counter-based Hough transform. D. Ben-Tzvi and M.B. Sandler p751
Eigenstructure method for robust array processing. W.S. Youn and C.K. Un p678
Error surface analysis of adaptive comb filter. J.F. Chicharo p587
Estimation of instantaneous frequency using the discrete Wigner distribution. P. Rao and F.J. Taylor p246
Fast algorithm for real joint time–frequency transformations of time-varying signals. S.-E. Qian and J.M. Morris p537
Fast computational algorithm for transform coding. Y. Kato and T. Murakami p944
Fast cosine transform based on the successive doubling method. F. Argüello and E.L. Zapata p1616
Fast discrete radon transform and 2-D discrete Fourier transform. D. Yang p550
Filtering with the fast T transform. T.F. Pena, J.C. Cabaleiro, J.D. Bruguera and E.L. Zapata p718
Fuzzy smoothing of HMM parameters in speech recognition. J.M. Koo and C.K. Un p743
Implementation of integration of Walsh series by flowgraphs. M. Ohkita and Y. Kobayashi p887
Interpolation using type I discrete cosine transform. Z. Wang p1170
Mean square convergence analysis of LMS algorithm. V.A. Gholkar p1705
Minimum entropy deconvolution for restoration of blurred two-tone images. H.-S. Wu p1183
Minimum relative entropy enhancement of FFT spectra. J.P. Noonan, M.A. Tzannes and B. Achour p979
Modulated QMF filter banks with perfect reconstruction. H.S. Malvar p906
New analogue multiplier–divider circuit based on cyclic data convertors. M.S. Piedade p2
New complementary pairs of sequences. S.Z. Budišin p881
Noise reduction and deconvolution with sequency diversity. J.-D. Aussel p737
Noise reduction based on microphone array with LMS adaptive post-filtering. R. Zelinski p2036
Novel mapping scheme for transforms with lengths equal to products of prime squares. D.P.-K. Lun and W.-C. Siu p21
Novel multirate sampling technique for ultrasound electronic sector scanning. T.K. Song and S.B. Park p71
On computing the discrete Wigner–Ville distribution. S.C. Chan and K.L. Ho p636
Optimal property of class of finite-energy signals with application to estimation of duration, power and amplitude of transients. L.C. Calvez, P. Vilbe and J.C. Boulbry e219 e219
Parameter estimation using cumulants. Y. Liu, J.J. Soraghan and T. Durrani p820
Prime factor fast Hartley transform. D. Yang p119
Quality of signals reconstructed from degraded Fourier transform phase. A.K. Nandi p1460
Real-time computation of the maximum likelihood criterion for some superimposed signals problems. J.K. Hwang and Y.C. Chen p1969
Regulated cascode switched-current memory cell. C. Toumazou, J.B. Hughes and D.M. Pattullo p303
Robust blind deconvolution algorithm: Variance approximation and series decoupling. F. Zheng, S. McLaughlin and B. Mulgrew p921
Signal extrapolation from Hartley transform magnitudes. G.-S. Chen, J.-L. Wu and L.-S. Lee p793
Systolic array for nonlinear multidimensional interpolation using radial basis functions. D.S. Broomhead, R. Jones, J.G. McWhirter and T.J. Shepherd p7
Training algorithms for backpropagation neural networks with optimal descent factor. X-H. Yu and S-X. Cheng p1698
Unidirectional-flow systolic array for linear discriminant function classifier. F. Klass p1702
VLSI computing architectures for Haar transform. K.J. Ray Liu p1962
Vector Hartley transform. J.D. Villasenor and R.N. Bracewell d94

SILICON

3·4 GHz silicon bipolar versatile shift register and 6·8 Gbit/s word generator. B. Wüppermann, U. Langmann and A. Pottbäcker p553
Carrier lifetime increase in silicon by gettering with a MeV-implanted carbon-rich layer. W. Skorupa, R. Kögler and K. Schmalz p1898
DC and RF performance of GaAs MESFET fabricated on silicon substrate using epitaxial lift-off technique. D.M. Shah, W.K. Chan, T.J. Gmitter, L.T. Florez, H. Schumacher and B.P. Van der Gaag p1865
Epitaxial lift-off of GaAs LEDs to Si for fabrication of opto-electronic integrated circuits. I. Pollentier, P. Demeester, A. Ackaert, L. Buydens, P. Van Daele and R. Baets p193
High sensitivity 5 Gbit/s optical receiver module using Si IC and GaInAs APD. S. Fujita, T. Suzaki, A. Matsuoka, S. Miyazaki, T. Torikai, T. Nakata and M. Shikada p175
Hybrid 11 Gbit/s parallel processing decision circuit using submicron silicon bipolar ICs. K. Runge, J. Young, M. Bagheri, D. Millicker, I. Kipnis and C. Snapp p1402
Low loss optical ridge waveguides in a strained GeSi epitaxial layer grown on silicon. A. Splett, J. Schmidtchen, B. Schüppert, K. Petermann, E. Kasper and H. Kibbel p1035
Newly structured expandable 52 Mbit/s, 48-channel time-division switching LSI with 2·4 Gbit/s throughput. N. Yamanaka, S. Kikuchi and H. Miyanaga p524

Novel pressure sensors with multilayer SOI structures. G.S. Chung, S. Kawahito, M. Ishida and T. Nakamura p775
Practical reduction of dislocation density in SIMOX wafers. S. Nakashima and K. Izumi p1647
Proposed ultrahigh frequency microstrip utilising buried silicide groundplane. K.W. Goossen, A.E. White and K.T. Short p49 e555 e555
Silicon nitride direct bonding. M.S. Ismail, R.W. Bower, J.L. Veteran and O.J. Marsh p1045
Silicon-on-insulator thickness determination by parametric spectral estimation. B.M. Lacquet and P.L. Swart p1781
Versatile silicon bipolar XOR gate for signal processing up to 8 Gbit/s. J. Hauenschild, H.-M. Rein, L. Schmidt and K. Wörner p114
Very low-loss GeO_2-doped silica waveguides fabricated by flame hydrolysis deposition method. T. Kominato, Y. Ohmori, H. Okazaki and M. Yasu p327

SIMULATION

Automatic production of the pseudo-circuit Boolean for the failure bounds analogue diagnosis scheme. C. Garrett p1377
Backlog performance of some controlled slotted Aloha systems. T. Tsiligirides p1612
IMPATT operation below the avalanche frequency. J.-F. Luy p1960
Identification and localisation of gate oxide weaknesses in *n*-MOS transistors through Fowler–Nordheim tunnelling and SPICE simulation. D. Krakauer and B.S. Doyle p230
New model for time domain simulation of lossy coupled lines. K.-H. Wirth p1723
Resequencing delay characteristics of multilink system in packet switched networks. Y. Yoshida p1971
Resource allocation in broadband ISDNs. M. Ilyas p1860
Self-consistent simulation of a high-power 73 GHz integrated IMPATT oscillator. W. Anzill, T. Goeller, F.X. Kaertner, P. Russer and J. Buechler p1697
Simulation of the reduction characteristics of scattering from an aircraft coated with a thin-type absorber by the spatial network method. T. Kashiwa, N. Yoshida and I. Fukai p289
Transfer matrix model for evaluation of optical switch structures. J.J. Dharmadi, H. Mulder, A. Diekema and A.G. de Waal p6

SKIN EFFECT

New skin-effect equivalent circuit. T. Vu Dinh, B. Cabon and J. Chilo p1582
Rigorous dispersive analysis of skin effects on a printed microstrip line containing finite conductor losses. C.K.C. Tzuang and W.K. Wang p1334
Skin effect losses of interconnect lines in frequency and time domain. W. Wlodarczyk and V. Besch p1237
Time domain analysis of skin effect on lossy interconnections. T. Vu Dinh, B. Cabon and J. Chilo p2057

SPECTRAL ANALYSIS

Fault detection method using power supply spectrum analysis. P. Lee and P. O'Leary p1733
On the Cramer–Rao bound of finite-length cepstrum spectral estimators. C. Nadeu and E. Lleida p987
Optical-fibre spectrum analyser. M.A. Page-Jones and J.K.A. Everard p117
Spectral analysis of waiting time jitter in the presence of stuff threshold modulation. R.G. Kusyk, T.E. Moore and W.A. Krzymien p526
Spectral broadening due to fibre amplifier phase noise. G.J. Cowle, P.R. Morkel, R.I. Laming and D.N. Payne p424

SPECTROSCOPY

Deep level transient spectroscopy of *n*-AlGaAs/GaAs high electron mobility transistors. J. Goostray, H. Thomas, D.V. Morgan, E. Kohn, A. Christou and S. Mottet p159
GaAs photoconductor array as new detector in multichannel spectroscopic system. M. Constant, L. Boussekey, D. Decoster and J.P. Vilcot p56
Operating characteristics of CW CO_2–N_2O laser. C.-M. Kim, S. Han, J.-K. Ji and Y. Kim p15
Photoluminescence spectroscopy measurements of elastic strain in heteroepitaxial GaAs films. T.P. Humphreys, R.J. Nemanich, K. Das, N.R. Parikh and J.B. Posthill p835
Silicon-on-insulator thickness determination by parametric spectral estimation. B.M. Lacquet and P.L. Swart p1781

SPEECH PROCESSING

Adaptive dummy spectrum insertion method used in asynchronous speech scrambling. Z. Hailin and W. Yumin p1949
Continuous adaptive speech analysis based on a time-varying ARMA model. B.K. Lim and C.K. Un p674
Modulated QMF filter banks with perfect reconstruction. H.S. Malvar p906
Speech encryption in the transform domain. S. Sridharan, E. Dawson and B. Goldburg p655
Systolic array for nonlinear multidimensional interpolation using radial basis functions. D.S. Broomhead, R. Jones, J.G. McWhirter and T.J. Shepherd p7
Time delay estimation with gradient type adaptive algorithm. V.N. Vasilev and P.P. Aidemirski p1797

SPEECH RECOGNITION

Attractor dimension, entropy and modelling of speech time series. A. Kumar and S.K. Mullick p1790
Fuzzy smoothing of HMM parameters in speech recognition. J.M. Koo and C.K. Un p743
On the Cramer–Rao bound of finite-length cepstrum spectral estimators. C. Nadeu and E. Lleida p987
Speaker adaptation using learning vector quantisation. M.W. Koo and C.K. Un p1731

STABILITY

Backlog performance of some controlled slotted Aloha systems. T. Tsiligirides p1612
Frequency-stabilised LD module with a Z-cut quartz Fabry–Perot resonator for coherent communication. M.S. Nakamura and S. Ohshima p405
Hysteresis and multistable behaviour in a polarisation self-modulated external ring cavity semiconductor laser. W.H. Loh, A.T. Schremer and C.L. Tang p1666
Latch-up property and dynamic stability in sinusoidal oscillators. P. Martinez, A. Carlosena, S. Porta and S. Celma p542
Method for computing the stability margin of 2-D discrete systems. S. Tzafestas, A. Kanellakis and N. Theodorou p1139
Numerical dispersion characteristics and stability factor for the TD–FD method. I.S. Kim and W.J.R. Hoefer p485
Optical steering of dual band microwave phased array antenna using semiconductor laser switching. W. Ng, A. Walston, G. Tangonan, J.J. Lee and I. Newberg p791
Spectral linewidth broadening in Er-doped-fibre amplifiers measured with less than 1·4 kHz linewidth light source. H. Okamura and K. Iwatsuki p1965
Spectrum stability of a broadband 1060 nm Nd-doped fibre laser. K. Fesler, M. Digonnet, K. Liu, B.Y. Kim and H.J. Shaw p870
Stability of second order time-varying constrained notch filters. D. Wulich, E.I. Plotkin and M.N.S. Swamy p1508
Suppression of laser frequency drifts caused by thermal transients in optical WDM packet switching systems. E.G. Vicente de Vera and B. Glance p1930
Temperature dependent gain and noise characteristics of a 1480 nm-pumped erbium-doped fibre amplifier. M. Suyama, R.I. Laming and D.N. Payne p1756
Temperature insensitive Er^{3+}-doped optical fibre amplifiers. M. Yamada, M. Shimizu, M. Okayasu and M. Horiguchi p1649
Wavelength stability of Nd^{3+}-doped fibre fluorescent sources. P.R. Morkel, E.M. Taylor, J.E. Townsend and D.N. Payne p873

STRIPLINES AND STRIPLINE COMPONENTS

Analysis of stripline/slot transition. A. Muir and R.J. Tepereck p1160 e1923
Effects on polarisation of inclined conducting strip located in front of radiating slot. J. Hur and C.W. Lee p713
Power dependent effects observed for a superconducting stripline resonator. S.J. Hedges, M.J. Adams, B.F. Nicholson and N.G. Chew p977
Transmission characteristics of suspended striplines with finite metallisation thickness and substrate supporting grooves. A. Rong p431

SUPERCONDUCTING DEVICES

AC Josephson effect in superconducting niobium nitride tunnel junctions at up to 2·5 THz. M.C. Wicks, P.R. Haycocks and T. Hori p610
Analysis of the superconducting coplanar waveguide by combining spectral domain method and phenomenological equivalence method. K.-S. Kong, C.W. Kuo, T. Kitazawa and T. Itoh p1558
Frequency dependence of surface resistance of bulk high temperature superconductor. P.A. Smith, L.E. Davis, N. McN Alford and T.W. Button p1486 e1738
Microwave power limiter based on high-T_c superconductive film. M.M. Galdukov, S.G. Kolesov, L. Kowalewicz, A.B. Kozyrev and O.G. Vendik p1229
Power dependent effects observed for a superconducting stripline resonator. S.J. Hedges, M.J. Adams, B.F. Nicholson and N.G. Chew p977
Significance of matching networks in enhanced performance of small antennas when supercooled. S. Khamas, G.G. Cook, S.P. Kingsley and R.C. Woods p654
Transmission line model for superconducting coplanar lines. D. Kinowski, C. Seguinot, P. Pribetich and P. Kennis p148

SURFACE PHENOMENA

Surface transverse wave based FM modulator/demodulator. I.D. Avramov, P.J. Edmonson and P.M. Smith p364

SURFACE-ACOUSTIC-WAVE DEVICES

Directivity of group-type single phase unidirectional SAW transducers. D.P. Morgan p1201
Highly sensitive electrostatic voltage sensor on SAW double-waveguides. A.V. Medved, R.A. Mishkinis and P.F. Rutkovsky p973
Performance trade-offs in SAW group-type SPUDTs. D.P. Morgan p1200

SWITCHED CAPACITOR FILTERS

Finite-gain-insensitive circulating-delay type pseudo-N-path filter. A.K. Betts and J.T. Taylor p1941
First-order, switched-capacitor, low-pass filter implemented with GaAs insulated-gate FET switches. J. Luck and J.G. Swanson p1843
Parasitic insensitive single amplifier switched capacitor bandpass biquad. C. Psychalinos and I. Haritantis p253
Programmable multiplexed switched-capacitor filters. X.F. Wania, D.A. Johns and A.S. Sedra p1051
Switched-capacitor lowpass filters based on recursive running sum cells. G. Fischer p557

SWITCHED CAPACITOR NETWORKS

Low-phase-error offset-compensated switched-capacitor integrator. W.-H. Ki and G.C. Temes p957
New analogue four-quadrant voltage divider. A. Cichocki and R. Unbehauen p1580
Switched-capacitor neural networks using pulse based arithmetic. B. Maundy and E. El-Masry p1118

SWITCHES

InP optical switch array module high frequency performance: Measurements and analysis. D.H. Hartman, Y. Takahashi and H. Inoue p436
Low drive voltage directional coupler optical switch with reduced voltage-length product. H. Okayama, T. Ushikubo and T. Ishida p374
New method of analysing transient processes in picosecond photoconductive switch. Y. Lu p444
Optimisation of $LiNbO_3$ BOA waveguide switches operating at 1·3 μm. A. McGuire, A.P. Thomas and R.C. Booth p2077

SWITCHING AND SWITCHING CIRCUITS

100-channel optical FDM transmission/distribution at 622 Mbit/s over 50 km utilising a waveguide frequency selection switch. H. Toba, K. Oda, K. Nakanishi, N. Shibata, K. Nosu, N. Takato and K. Sato p376
10 Gbit/s AlGaAs/GaAs heterojunction bipolar transistor decision circuit IC. J. Akagi, Y. Kuriyama, K. Morizuka, M. Asaka, K. Tsuda, M. Obara and H. Yamakawa p122
11 Gbit/s multiplexer and demultiplexer using 0·15 μm GaAs MESFETs. M. Ohhata, Y. Yamane, T. Enoki, S. Sugitani, N. Kato and M. Hirayama p467
AGC based on hard detected FFH signal matrices. I. Vajda p218
Analysis of telecommunications switch model (GEO/D/1) with time priorities.

J.A. Schormans, E.M. Scharf and J.M. Pitts p325
Approximate expression for normalised throughput of multistage interconnection networks. T.-H. Lee and J.-J. Chou p2031
Demonstration of packet switching through an integrated-optic tree switch using photo-conductive logic gates. K.K. Goel, P.R. Prucnal, Y. Shimazu, M. Milbrodt, E. Desurvire and B. Tell p287
Fast wavelength switching and simultaneous FSK modulation using tunable DBR laser. H. Kobrinski, M.P. Vecchi, T.E. Chapuran, J.B. Georges, C.E. Zah, C. Caneau, S.G. Menocal, P.S.D. Lin, A.S. Gozdz and F.J. Favire p308
High speed GaAs 32 × 8 embeddable dual port SRAM register array for 200 Mbyte/s packet switching applications. K.S. Lowe p516
High speed low power GaAs crosspoint switch design. M. Bagheri p1142
InGaAsP 400 × 200 μm active crosspoint switch operating at 1·5 μm using novel reflective Y-coupler components. I.H. White, J.J.S. Watts, J.E. Carroll, C.J. Armistead, D.J. Moule and J.A. Champelovier p617
Latching type single-mode fibre switch. S. Nagaoka p744
Maximum zeros scheduling for satellite switched TDMA. G.R. Tobin and L.W. Cahill p970
New reflection-type optoelectronic microwave switch for CW applications. N. Weber p455
Optoelectronic switch with low holding power. M. Kuijk, R. Pereira, M. Van Hove, R.P. Mertens, G. Borghs and J.I. Pankove p280 e555 e555
Performance of multistage interconnection networks for integrated services. T.-H. Lee p495
Regulated cascode switched-current memory cell. C. Toumazou, J.B. Hughes and D.M. Pattullo p303
SPICE simulation of quasi-resonant zero-current-switching DC–DC convertors. S. Ben-Yaakov, D. Edry, Y. Amran and O. Shimony p847
SYMFONET: ultra-high-capacity distributed packet switching network for telecoms and multiprocessor computer applications. P.A. Kirkby p19
Self-routing fast packet switch with in-service modulator growth. H. Obara and S. Okamoto p1286
Self-routing space switch network comprising fast and uniform switch elements. H. Obara, H. Uematsu, S. Okamoto and H. Matsunaga p352
Simple implementation of load-sharing banyan network and its throughput performance. T.-H. Lee p79
Single sided switching networks. J. Gordon and S. Srikanthan p248
Transfer matrix model for evaluation of optical switch structures. J.J. Dharmadi, H. Mulder, A. Diekema and A.G. de Waal p6
Uniformity in the performance characteristics of an 8 × 8 vertical to surface transmission electro-photonic device matrix. Y. Tashiro, I. Ogura, M. Sugimoto, N. Hamao and K. Kasahara p628

SYNCHRONISATION

1 Gbit/s high-speed bit-synchronisation LSI for B-ISDN. Y. Otsuka p622
Frequency accommodation and synchronisation in digital TV CODEC. M.S. Pereira, N.M. Vasconcelos and A.P. Alves p2104
Merit factor of Chu and Frank sequences. M. Antweiler and L. Bömer p2068
New retiming and synchronisation scheme for optical ATM switching systems. Y. Takahashi, K. Ando, M. Miyata and E. Amada p99
Robust framing receiver for 2·048 Mbit/s PCM systems. D.E. Dodds and S.M. Pan p1077
Soft-decision syndrome based node synchronisation. J. Sodha and D.J. Tait p1108 e1738
Symbol synchronisation for binary baseband PAM operating at only one sample per symbol. M. Moeneclaey and T. Batsele p691
Synchronisation preamble design: new results. M. Grayson and M. Darnell p1775
Waiting time jitter results for a reduced complexity SONET interface circuit. T.E. Moore, R.G. Kusyk and W.A. Krzymien p1884

SYSTEM THEORY

Derivation of discrete and continuous time ramp invariant representations. S. Bingulac and D.L. Cooper p664
Iterative learning controller for linear systems with a periodic disturbance. H.S. Ahn and C.H. Choi p1542
Minimal state space realisation of product factorable 2-D systems. G.E. Antoniou p1232
Periodically time-varying two-dimensional systems. D.C. McLernon p412
Two-dimensional modified Cauer form: circuit and state space realisation. G.E. Antoniou, C.N. Manikopoulos and S.E. Mentzelopoulou p258

TELECOMMUNICATION

39·5 million-way WDM broadcast network employing two stages of erbium-doped fibre amplifiers. A.M. Hill, R. Wyatt, J.F. Massicott, K.J. Blyth, D.S. Forrester, R.A. Lobbett, P.J. Smith and D.B. Payne p1882
Adaptive algorithm for variable teletraffic demand in highway microcells. R. Steele, M. Nofal and S. Eldolil p988
Analytic node model for deflection routing networks. A.M. Bignell and T.D. Todd p67
Approximate expression for normalised throughput of multistage interconnection networks. T.-H. Lee and J.-J. Chou p2031
Basic performance of a direct conversion DECT receiver. G. Schultes, E. Bonek, P. Weger and W. Herzog p1746
CSMA local radio networks with BPSK modulation in Rayleigh fading channels. K. Zhang and K. Pahlavan p1655
Compatible enhancement of terrestrial PAL TV transmission. C.P. Sandbank, J.O. Drewery and M. Weston p195
Estimation of traffic intensity in global bus computer communications networks. H. Yang and M. Kim p1079
Generalised type-II hybrid ARQ. Ma Jianhua and Wang Xinmei p88
High saturation output power from a neodymium-doped fluoride fibre amplifier operating in the 1300 nm telecommunications window. J.E. Pedersen and M. Brierley p819
Improved ICMA/CD protocol in packet mobile radio networks. J. Song and M. Kim p182
Modified scatterer distribution model for fast fading mobile communication channel. I. Crohn, E. Bonek and H. Weinrichter p1575
Monte Carlo estimates of incidence of basic access ISDN generated EMI. W.D. Davies p1048
Optimal noncoherent detection of PSK signals. D. Makrakis and K. Feher p398
Performance of multistage interconnection networks for integrated services. T.-H. Lee p495
Reducing time delay of ARQ protocols by simple error-correcting codes. Q. Yang and V.K. Bhargava p1447
Resource allocation in broadband ISDNs. M. Ilyas p1860
Simple implementation of load-sharing banyan network and its throughput performance. T.-H. Lee p79
Slotted ALOHA radio networks with PSK modulation in Rayleigh fading channels. K. Zhang, K. Pahlavan and R. Ganesh d593
Some continuous multidestination ARQ schemes for high error rate conditions. T.H. Lee p1686
Throughput performance of some continuous ARQ schemes with memory. T.-H. Lee and J.-K. Hu p1972
UHF band high-efficiency linear power amplifier for mobile communication satellites. K. Sekine, Y. Dooi, A. Iso, H. Funaki and I. Takei p441
Waiting time jitter reduction by fill locking. R. Nawrocki and W. Ehrlich p1227

TELEVISION

Compatible enhancement of terrestrial PAL TV transmission. C.P. Sandbank, J.O. Drewery and M. Weston p195

THIN-FILM DEVICES

Approximate analytical model for the poly-silicon thin film transistor. M.J. Izzard, P. Migliorato and W.K. Milne p1284
Diode laser waveguiding in polydiacetylene films. B. Rossi, W. Blau, J. O'Gorman, S. König, D. Westland and V. Skarda p312
Growth of single crystal β-SiC films on a Si substrate by a direct carbonisation method. Y. Hirano and T. Inada p1638
Highly reliable thin nitrided SiO_2 films formed by rapid thermal processing in an N_2O ambient. H. Fukuda, T. Arakawa and S. Ohno p1505
Model for the potential drop in the silicon substrate for thin-film SOI MOSFETs. J.A. Martino, L. Lauwers, J.P. Colinge and K. De Meyer p1462

THRESHOLD LOGIC

Real-world image segmentation using edge detection and subtraction. B. Qiu and M.G. Hartley p353

THYRISTORS

Two-phase clock driven self-scanning light emitting device (SLED). Y. Kusuda, S. Tanaka and K. Yamashita p1406

TIME-DOMAIN REFLECTOMETRY

Complementary correlation OTDR with three codewords. M. Nazarathy, S.A. Newton and W.R. Trutna p70
First field demonstration of in-service fault location/supervisory using optical time domain reflectometry. J.D. Cox, J.M. Boggis, E.G. Bryant, C.A. Hunter and W.A. Stallard p110

TIME-VARYING SYSTEMS

Periodically time-varying two-dimensional systems. D.C. McLernon p412
Reducing time delay of ARQ protocols by simple error-correcting codes. Q. Yang and V.K. Bhargava p1447

TIMING CIRCUITS

Fast timing extraction method for an optical passive bus. Y. Nagasako and T. Nakashima p1168
Physical approach to CMOS module self-timing. O.A. Izosimov, I.I. Shagurin and V.V. Tsylyov p1835
Self-timed system design technique. Y.K. Tan and Y.C. Lim p284

TRANSFER FUNCTIONS

Improved version of the inverse Chebyshev filter. M. Lutovac and D. Rabrenović p1256
Linear approximation of fractional transfer functions of distributed parameter systems. C.S. Hsu and D. Hou p1211
Low Q equiripple functions of nonminimum order. D. Rabrenović and M. Lutovac p447
Low-sensitivity universal first-order digital filter sections without limit cycles. I.P. Topalov and G.K. Stoyanov p25

TRANSFORMS

Algorithm for computing two-dimensional discrete Hartley transform of size $p^n \times p^n$. W. Ma p1795
Algorithm for generating new orthonormal transforms. S.J. Huang, S.N. Koh and H.K. Tang p1489
Algorithm for prime length discrete cosine transforms. Y.-H. Chan and W.-C. Siu p206
Application of Hartley transform to tracking moving objects in noisy environments. Y.-S. Huang and C.-Y. Hsu p1878
Application of Kramers–Kronig transform to determination of cavity impedance for both small and large couplings. Q. Min, K.Z. Xue and P.H. Wu p44
Conjugate pair fast Fourier transform. I. Kamar and Y. Elcherif d541
Counter-based Hough transform. D. Ben-Tzvi and M.B. Sandler p751
Derivation of Fourier transform of discrete series from z-transform. R. Ishii p1938
Extending sizes of effective convolution algorithms. R. Stasiński p1602
Fast cosine transform based on the successive doubling method. F. Argüello and E.L. Zapata p1616
Fast discrete radon transform and 2-D discrete Fourier transform. D. Yang p550
Fast odd discrete cosine transform algorithms. S.C. Chan and K.L. Ho p503
Filtering with the fast T transform. T.F. Pena, J.C. Cabaleiro, J.D. Bruguera and E.L. Zapata p718
Improved design of minimum-phase FIR digital filters by cepstrum and fast Hardtley transform. S.-C. Pei and S.-B. Jaw p1063
Interpolation using type I discrete cosine transform. Z. Wang p1170
New radix-3 FHT algorithm. N. Anupindi, S.B. Narayanan and K.M.M. Prabhu p1537
Noise reduction and deconvolution with sequency diversity. J.-D. Aussel p737
Novel mapping scheme for transforms with lengths equal to products of prime squares. D.P.-K. Lun and W.-C. Siu p21
Plane-polar near-field to far-field transformation with the near-field interpolation method. E. Van Lil, C. Cao, A. Van de Capelle and K. Van't Klooster p1886
Polynomial transform fast Hartley transform. S.C. Chan and K.L. Ho p1914
Prime factor fast Hartley transform. D. Yang p119
Quality of signals reconstructed from degraded Fourier transform phase. A.K. Nandi p1460
Signal extrapolation from Hartley transform magnitudes. G.-S. Chen, J.-L. Wu and L.-S. Lee p793

Split-radix FHT algorithm for real-symmetric data. N. Anupindi and K.M.M. Prabhu p1973
VLSI architecture for the discrete wavelet transform. G. Knowles p1184
Vector Hartley transform. J.D. Villasenor and R.N. Bracewell d94
Video compression using 3D wavelet transforms. A.S. Lewis and G. Knowles p396

TRANSIENTS

A step towards determining transient response of chiral materials: Kramers–Kronig relations for chiral parameters. N. Engheta and P.G. Zablocky p2132
Characterisation of an optoelectronically pulsed equiangular spiral antenna. Y. Pastol, G. Arjavalingam and J.-M. Halbout p133
Optimal property of class of finite-energy signals with application to estimation of duration, power and amplitude of transients. L.C. Calvez, P. Vilbe and J.C. Boulbry e219 e219

TRANSISTORS

10 Gbit/s AlGaAs/GaAs heterojunction bipolar transistor decision circuit IC. J. Akagi, Y. Kuriyama, K. Morizuka, M. Asaka, K. Tsuda, M. Obara and H. Yamakawa p122
AlGaAs/GaAs heterojunction bipolar transistors fabricated with various collector-carrier concentrations. Y. Ota, T. Hirose, A. Ryoji and M. Inada p203
Approximate analytical model for the poly-silicon thin film transistor. M.J. Izzard, P. Migliorato and W.K. Milne p1284
Electrical method for measuring emitter depth of shallow bipolar transistors. I.R.C. Post and P. Ashburn p30
Electrical transient study of negative resistance in SOI MOS transistors. O. Le Néel and M. Haond p73
Evaluation of currents in the fA range. P. Girard and P. Nouet p844
GaAs–GaAsSb based heterojunction bipolar transistor. B. Khamsehpour and K.E. Singer p965
Heavily doped emitter as a lossy transmission line. D. Jankovic p675
High current gain GaInAs/InP hot electron transistor. S. Yamaura, Y. Miyamoto and K. Furuya p1055
High-efficiency AlGaAs/InGaAs heterostructure FET oscillators at V-band. H.Q. Tserng and P. Saunier p2048
High-frequency output characteristics of AlGaAs/GaAs heterojunction bipolar transistors. J. Chen, G.B. Gao, M.S. Ünlü and H. Morkoç p2058
Mg-doped graded base GaAs/AlGaAs heterojunction bipolar transistors grown by metalorganic vapour phase epitaxy. H. Tews, P. Zwicknagl, R. Neumann, G. Jaeger, A. Hoepfner, L. Schleicher and G. Packeiser p58
Novel doubly self-aligned AlGaAs/GaAs HBT. W.U. Liu, D. Costa and J. Harris p1361
Novel linearisation technique for implementing large-signal MOS tunable transconductor. Z. Wang p138
Two-dimensional electron gas base hot electron transistor. P. Matthews, M.J. Kelly, V.J. Law, D.G. Hasko, M. Pepper, H. Ahmed, D.C. Peacock, J.E.F. Frost, D.A. Ritchie and G.A.C. Jones p862
Very low-noise $Al_{0.3}Ga_{0.7}As/Ga_{0.65}In_{0.35}As$/GaAs single quantum-well pseudomorphic HEMTs. P.C. Chao, P. Ho, K.H.G. Duh, P.M. Smith, J.M. Ballingall, A.A. Jabra, N. Lewis and E.L. Hall p27

TRANSMISSION LINES

Coax-to-channelised coplanar waveguide in-phase, N-way, radial power divider. R.N. Simons and G.E. Ponchak p754
Coplanar waveguide antenna arrays for MIC/MMIC at millimetre wave frequencies. X.H. Yang and W.X. Zhang p1464
Definition of the high frequency characteristic impedance of an overhead conductor. G.E. Bridges p2079
Exact singular integral equation approach for planar transmission lines. Y. Huang, L. Xue and W. Lin p360
Extension of spectral domain approach to unilateral finlines with finite metallisation thickness and substrate supporting grooves. A. Rong p1728
Generalised theory of a non-TEM transmission line taper without discontinuities. J.C. Coetzee and J.A.G. Malherbe p1549 e2056
Heavily doped emitter as a lossy transmission line. D. Jankovic p675
Millimetre-wave second harmonic generation on a nonlinear transmission line. R.A. Marsland, M.S. Shakouri and D.M. Bloom p1235
Modelling of materials with electric and magnetic losses with the symmetrical condensed TLM method. F.J. German, G.K. Gothard and L.S. Riggs p1307
New impedance transforming rat-race hybrid ring. H.R. Mgombelo, H.O. Ali and M.M. Kissaka p837
Slow wave propagation using interconnexions for IC technologies. P.G. Gammand and D. Bajon p1443
Transmission line model analysis of arbitrary shape symmetrical patch antenna coupled with a director. G. Dubost and A. Zerguerras p952
Velocity matching of III-V travelling-wave electro-optic modulator structures. M.R.T. Tan, I. Kim, J. Chang and S.Y. Wang p32

TRANSPORT PROCESSES

Carrier lifetime increase in silicon by gettering with a MeV-implanted carbon-rich layer. W. Skorupa, R. Kögler and K. Schmalz p1898
Electron detrapping enhanced by electric field in AlGaAs/GaAs HEMTs. C. Canali, F. Magistrali, M. Sangalli, C. Tedesco and E. Zanoni p313
Hydrogen passivation of high purity *n*-type InP. C.G. Crookes, D. Lancefield, K. Waterhouse, A.R. Adams, P.D. Greene and R.W. Glew p369
Novel gate voltage ramping technique for the characterisation of metal-oxide-semiconductor capacitor charge trapping properties. W. Ting, G.Q. Lo and D.L. Kwong p1257
Process dependence of interface state generation due to irradiation and hot carrier stress in rapid thermally nitrided thin gate oxides. A.B. Joshi, G.Q. Lo and D.L. Kwong p1248

TRAVELLING-WAVE TUBES

Travelling-wave erbium fibre ring laser with 60 kHz linewidth. P.R. Morkel, G.J. Cowle and D.N. Payne p632

TREES

Demonstration of packet switching through an integrated-optic tree switch using photo-conductive logic gates. K.K. Goel, P.R. Prucnal, Y. Shimazu, M. Milbrodt, E. Desurvire and B. Tell p287

TUNING

242 nm continuous tuning from a GRIN-SC-MQW-BH InGaAsP laser in an extended cavity. M. Bagley, R. Wyatt, D.J. Elton, H.J. Wickes, P.C. Spurdens, C.P. Seltzer, D.M. Cooper and W.J. Devlin p267
Axial dependence of $\chi^{(2)}$ gratings in optical fibre: Effect of the intensity-dependent detuning. F. Ouellette p740
Broadband tuning (170 nm) of InGaAs quantum well lasers. L.E. Eng, D.G. Mehuys, M. Mittelstein and A. Yariv p1675
Design of linear tunable CMOS differential transconductor cells. Z. Czarnul and S. Takagi p1809
External grating tunable MQW laser with wide tuning range of 240 nm. H. Tabuchi and H. Ishikawa p742
Fine tuning of wavevector conservation in guided wave devices by photobleaching. S. Aramaki, G. Assanto and G.I. Stegeman p1300
Highly-linear transconductor cell realised by double MOS transistor differential pairs. Z. Czarnul and N. Fujii p1819
Noise tuning of GaAs-MESFET oscillators. L. Kreischer p315
Novel method of DRO frequency tuning with varactor diode. N. Popović p1162

TUNNEL DIODES

Asymmetric resonant tunnelling diodes as microwave detectors. R.T. Syme, M.J. Kelly, A. Condie and I. Dale p1904
Delta doped tunnel diode: A new negative differential resistance device. J.M.A. Gilman and A.G. O'Neill p601
Double-barrier resonant tunnelling diode three-state logic. A. Sellai, M.S. Raven, D.P. Steenson, J.M. Chamberlain, M. Henini and O.H. Hughes p61
Experimental study of microwave reflection gain of AlAs/GaAs/AlAs quantum well structures. S.P. Stapleton, M.J. Deen, E. Berolo and R.H.S. Hardy p84
Frequency multiplication using resonant tunnelling diode with output at sub-millimetre wavelengths. R. Bouregba, D. Lippens, L. Palmateer, E. Bockenhoff, M. Bogey, J.L. Destombes and A. Lecluse p1804
High peak-to-valley current ratio AlGaAs/AlAs/GaAs double barrier resonant tunnelling diodes. V.K. Reddy, A.J. Tsao and D.P. Neikirk p1742
Impedance analysis of GaAs/Al(Ga)As resonant tunnel diodes in the NDR region. A. Zarea, A. Sellai, M.S. Raven, D.P. Steenson, J.M. Chamberlain, M. Henini and O.H. Hughes p1522
New GaSb/AlSb/GaSb/AlSb/InAs/AlSb/InAs triple-barrier interband tunnelling diode. L. Yang, J.F. Chen and A.Y. Cho p1277
Pulse forming and triggering using resonant tunnelling diode structures. E. Özbay, D.M. Bloom and S.K. Diamond p1046
Room temperature negative differential resistance in a triple well rectifying resonant tunnelling diode. C.R. Bolognesi, R.S. Mand and A.R. Boothroyd p1163

TUNNELLING

Estimation of temperature limit for negative differential resistance using resonant tunnelling. L. De Saint Pol, O. Vanbesien and D. Lippens p342
Experimental study of microwave reflection gain of AlAs/GaAs/AlAs quantum well structures. S.P. Stapleton, M.J. Deen, E. Berolo and R.H.S. Hardy p84
High performance resonant tunnelling structures on GaAs substrates. H. Riechert, D. Bernklau, J.-P. Reithmaier and R.D. Schnell p340
Resonant tunnelling structures with very thin contact layers using nonalloyed Ge/Pd contacts. C. Van Hoof, J. Genoe, M. Van Hove, Ph. Jansen, M. Van Rossum and G. Borghs p797

ULTRASONICS

Directivity of group-type single phase unidirectional SAW transducers. D.P. Morgan p1201
$LiNbO_3$ acoustic plate mode sensor for dilute ionic solutions. F. Josse, D.T. Haworth, U.R. Kelkar and Z.A. Shana p834
Medical ultrasound imaging using neural networks. M. Nikoonahad and D.C. Liu p545
Novel multirate sampling technique for ultrasound electronic sector scanning. T.K. Song and S.B. Park p71
Performance trade-offs in SAW group-type SPUDTs. D.P. Morgan p1200
Simple method for calculating optimum cut of piezoelectric material with small BAW generation by IDTs. J.H. Yin, Y. Shui, D. Zhang, J. Yu and P. Wu p1175

VAPOUR DEPOSITION

Buried rectangular GaInAs/InP corrugations of 70 nm pitch fabricated by OMVPE. T. Yamamoto, Y. Miyamoto, M. Ogawa, E. Inamura and K. Furuya p875
High performance GaAs MESFETs grown on InP substrates by MOCVD using tertiarybutylarsine. J. Jeong, R.M. Lum, J.K. Klingert, R. Bylsma, G.P. Vella-Coleiro and P.R. Smith p482
Reliable 1·3 μm gain guided stripe lasers grown by MOCVD using ethyldimethylindium as the In source. C. Blaauw, T.F. Devenyi, B. Capron, F.R. Shepherd and A.J. Springthorpe p1291
Short-wavelength (638 nm) room-temperature CW operation of InGaAlP laser diodes with quaternary active layer. M. Ishikawa, H. Shiozawa, Y. Tsuburai and Y. Uematsu p211

VARACTORS

Novel method of DRO frequency tuning with varactor diode. N. Popović p1162

VARISTORS

Dispersion characteristics of ring line through the conformal mapping approach. J.P. Fenelon and A. Papiernik p621

VIDEO

160-channel FM-video transmission using optical FM/FDM and subcarrier multiplexing and an erbium doped optical fibre amplifier. W.I. Way, M.W. Maeda, A. Yi-Yan, M.J. Andrejco, M.M. Choy, M. Saifi and C. Lin p139
Design criteria for video sampling rate conversion filters. A.M. Böck p1259
Frequency accommodation and synchronisation in digital TV CODEC. M.S. Pereira, N.M. Vasconcelos and A.P. Alves p2104
Passive fibre-loop architecture providing both switched and broadcast transport. R.C. Menendez, S.S. Wagner and H.L. Lemberg p273
Video compression using 3D wavelet transforms. A.S. Lewis and G. Knowles p396

WAVEGUIDE COMPONENTS

New waveguide-to-coplanar waveguide transition for centimetre and millimetre wave applications. G.C. Dalman p830
Semiconductor-doped glass waveguide electro-absorption modulator. J. Bell and C.N. Ironside p976

WAVEGUIDES

100-channel optical FDM transmission/distribution at 622 Mbit/s over 50 km utilising a waveguide frequency selection switch. H. Toba, K. Oda, K. Nakanishi, N. Shibata, K. Nosu, N. Takato and K. Sato p376

Accurate modelling of unilateral finline–coplanar waveguide transition. A. Rong p1123

Analysis of edge slots in rectangular waveguide using finite-difference time-domain method. J.C. Olivier and D.A. McNamara p1135

Analysis of groove guides with grooves of arbitrary shape. Z.X. Shen, X.M. Lou and S.F. Li p472

Analysis of the superconducting coplanar waveguide by combining spectral domain method and phenomenological equivalence method. K.-S. Kong, C.W. Kuo, T. Kitazawa and T. Itoh p1558

Application of MFIE to three-dimensional conducting waveguide transitions of arbitrary shape. N.Y. Zhu and F.M. Landstorfer p143

Application of the FD-TD method to the analysis of H-plane waveguide discontinuities. Z.-Q. Bi, K.-L. Wu and J. Litva p1897

Approximate formulas for step discontinuities in circular waveguides. C. Sabatier, R. Behe and P. Brachat p173

Attenuation characteristics of a circular chirowaveguide. T.C.K. Rao p1767

Beam-propagation analysis of bent step-index slab waveguides. J. Yamauchi, S. Kikuchi, T. Hirooka and H. Nakano p822

Bend performance of fibre-matched optical waveguides on InP. R.J. Deri, N. Yasuoka, M. Makiuchi, A. Kuramata and O. Wada p321

Characterisation of microstrip open-end with rectangular and trapezoidal cross-section. C.J. Railton and J.P. McGeehan p685

Coax-to-channelised coplanar waveguide in-phase, N-way, radial power divider. R.N. Simons and G.E. Ponchak p754

Cut-off of the first higher order modes in elliptical dielectric waveguide: An experimental approach. R.B. Dyott p1721

Efficient Nd : MgO : $LiNbO_3$ waveguide laser. E. Lallier, J.P. Pocholle, M. Papuchon, M. De Micheli, M.J. Li, Q. He, D.B. Ostrowsky, C. Grezes-Besset and E. Pelletier p927

Explicit finite difference beam propagation method: Application to semiconductor rib waveguide Y-junction analysis. Y. Chung and N. Dagli p711

Fine tuning of wavevector conservation in guided wave devices by photobleaching. S. Aramaki, G. Assanto and G.I. Stegeman p1300

Finite difference methods for the analysis of integrated optical waveguides. R. Accornero, M. Artiglia, G. Coppa, P. Di Vita, G. Lapenta, M. Potenza and P. Ravetto p1959

Finite-element analysis of chirowaveguides. J.A.M. Svedin p928

Full-wave analysis of shielded coplanar waveguide short-end. G. Bartolucci and J. Piotrowski p1615 e1922

GaAlAs window lasers emitting 500 mW CW in fundamental mode. J. Ungar, N. Bar-Chaim, M. Mazed, M. Mittelstein, S. Oh and I. Ury p1441 e1922

High efficiency 1·3 μm superluminescent diode with absorbing tapered waveguide. K. Magari, Y. Noguchi, K. Okamoto, H. Yasaka, H. Nagai and O. Mikami p1445

High performance QCSE phase modulator for the 1·5–1·55 μm fibre band. J.B.D. Soole, H.K. Tsang, I.H. White, H.P. LeBlanc, R. Bhat and M.A. Koza p1421

High-efficiency coupling of laser diodes in tapered proton-exchanged waveguides. K. Mizuuchi, K. Yamamoto and T. Taniuchi p1992

High-resolution OCDR in dispersive waveguides. E. Brinkmeyer and R. Ulrich p413

Highly sensitive electrostatic voltage sensor on SAW double-waveguides. A.V. Medved, R.A. Mishkinis and P.F. Rutkovsky p973

Hybrid finite element/boundary element method for analysis of discontinuities in planar dielectric waveguides. B.M. Dillon, R.L. Ferrari and T.P. Young p47

In-*situ* investigation of coupling between a fibre and a slab waveguide. M. Iztkovich, M. Tur, A. Hardy and N. Croituro p1104

Interferometric-type polarisation splitter on Z-propagating $LiNbO_3$: Ti. J. Saulnier, F. Huet, L. Riviere, M. Carre and G. Caumont p1940

Ion-implanted Nd : YAP planar waveguide laser. S.J. Field, D.C. Hanna, D.P. Shepherd, A.C. Tropper, P.J. Chandler, P.D. Townsend and L. Zhang p1826

Low-loss PECVD silica channel waveguides for optical communications. G. Grand, J.P. Jadot, H. Denis, S. Valette, A. Fournier and A.M. Grouillet p2135

Measurement of the increase in the SHG coefficient of proton exchanged $LiNbO_3$ after annealing using a grating diffraction technique. R.W. Keys, A. Loni and R.M. De La Rue p624

Mismatch in dielectric-loaded rectangular waveguide antenna. T.S. Bird and S.G. Hay p59

Modified configuration for a high-finesse compact loop resonator for semiconductor integrated optics. A. Shahar, W.J. Tomlinson and M. Seto p1528 e1922

New waveguide-to-coplanar waveguide transition for centimetre and millimetre wave applications. G.C. Dalman p830

Observation of self-lensing in a 4BCMU-polydiacetylene thin-film waveguide. J. Valera, A. Darzi, A.C. Walker, W. Krug, E. Miao, M. Derstine and J.N. Polky p222

Optical activity induced in $Bi_4Ge_3O_{12}$ waveguides by ion implantation. S.M. Mahdavi and P.D. Townsend p371

Optimum dielectric overlay thickness for equal even- and odd-mode phase velocities in coupled microstrip circuits. J.L. Klein and K. Chang p274

Perturbation feedback method for analysing rectangular dielectric waveguides. Y. Cai, T. Mizumoto and Y. Naito p521

Photoinduced channel waveguide formation in nonlinear optical polymers. M.B.J. Diemeer, F.M.M. Suyten, E.S. Trommel, A. McDonach, J.M. Copeland, L.W. Jenneskens and W.H.G. Horsthuis p379

Quasi-phase-matched frequency doubling over 5 mm in periodically poled polymer waveguide. R.A. Norwood and G. Khanarian p2105

Rigorous calculation of losses of single and coupled groove-guides. J. Meissner p41

Rigorous theoretical study of longitudinally magnetised partially filled TEM phase shifter. J.W. Tao, B. Chan and H. Baudrand p1329

Self-routing planar network for guided-wave optical switching systems. H. Obara, S. Okamoto, H. Uematsu and H. Matsunaga p520

Sensitivity of the radiation pattern of a small slotted waveguide array to the finiteness of its elliptical groundplane. D.A. McNamara and L. Botha p387

Transverse resonance method for analysing T-septum waveguides. Z.X. Shen, X.M. Lou and S.F. Li p78

Variational approach to nonlinear waveguides—Gaussian approximations. R.A. Sammut and C. Pask p1131

Variational finite element analysis of dielectric waveguides with no spurious solutions. F.A. Fernandez and Y. Lu p2125

Y branching silica waveguide 1 × 8 splitter module. S. Kobayashi, T. Kitoh, Y. Hida, S. Suzuki and M. Yamaguchi p707

Z-TRANSFORMS

Derivation of Fourier transform of discrete series from z-transform. R. Ishii p1938